AO 120 (Rev. 08/10)

TO:

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REPORT ON THE FILING OR DETERMINATION OF AN ACTION REGARDING A PATENT OR TRADEMARK

•	•	-	1116 you are hereby advised that a court act	
	trict Court <u>Central District or</u> ✓ Patents. (the patent ac			on the following
DOCKET NO.	DATE FILED	U.S. DIS	STRICT COURT	
	March 23, 2016		District of California	
PLAINTIFF Nichia Corporation		I	DEFENDANT VIZIO, Inc.	
PATENT OR TRADEMARK NO.	DATE OF PATENT OR TRADEMARK		HOLDER OF PATENT OR TRA	DEMARK
1 7,901,959	March 8, 2011	Nichia	Corporation	
2 7,915,631	March 29, 2011	Nichia	Corporation	
3 8,309,375	November 13, 2012	Nichia	Corporation	
4 7,855,092	December 21, 2010	Nichia	Corporation	
5				
		ne following	patent(s)/ trademark(s) have been included:	
DATE INCLUDED	I			
	INCLUDED BY	mendment	Answer Cross Bill	Other Pleading
PATENT OR TRADEMARK NO.		mendment	Answer Cross Bill HOLDER OF PATENT OR TRA	
PATENT OR	DATE OF PATENT	mendment		
PATENT OR TRADEMARK NO.	DATE OF PATENT	mendment		
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PATENT OR TRADEMARK NO.	DATE OF PATENT	mendment		
PATENT OR TRADEMARK NO. 1 2 3	DATE OF PATENT	mendment		
PATENT OR TRADEMARK NO. 1 2 3 4 5	DATE OF PATENT OR TRADEMARK			DEMARK
PATENT OR TRADEMARK NO. 1 2 3 4 5	DATE OF PATENT OR TRADEMARK		HOLDER OF PATENT OR TRA	DEMARK
PATENT OR TRADEMARK NO. 1 2 3 4 5	DATE OF PATENT OR TRADEMARK the above—entitled case, the		HOLDER OF PATENT OR TRA	DEMARK

Copy 1—Upon initiation of action, mail this copy to Director Copy 3—Upon termination of action, mail this copy to Director Copy 2—Upon filing document adding patent(s), mail this copy to Director Copy 4—Case file copy

AO 120 (Rev. 08/10)

TO:

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REPORT ON THE FILING OR DETERMINATION OF AN ACTION REGARDING A PATENT OR TRADEMARK

filed in the U.S. Dist		or 15 U.S.C. § 1116 you are hereby advised that a cour Central District of California	t action has been on the following
		action involves 35 U.S.C. § 292.):	
DOCKET NO. SACV15-1963-DMG-KI	DATE FILED ESx 11/23/2015	U.S. DISTRICT COURT Central District of C	alifornia
DAGV 15-1305-DIVIG-NI PLAINTIFF	<u> 11/23/2013</u>	DEFENDANT	MINOR THE COMMENT OF
VIZIO, Inc.		Vizo, Inc.	
, 1110.		vizo, mo.	
PATENT OR TRADEMARK NO.	DATE OF PATENT OR TRADEMARK	HOLDER OF PATENT OR	TRADEMARK
1 4621356	10/14/2014	VIZIO, Inc.	***************************************
2 4053025	11/8/2011	VIZIO, Inc.	
3 3235417	4/24/2007	VIZIO, Inc.	
4 4369035	7/16/2013	VIZIO, Inc.	
5			
	In the above—entitled case	the following patent(s)/ trademark(s) have been include	ed:
DATE INCLUDED	INCLUDED BY		
DATE INCLUDED PATENT OR	INCLUDED BY DATE OF PATENT	Amendment Answer Cross Bill	Other Pleading
DATE INCLUDED	INCLUDED BY		Other Pleading
DATE INCLUDED PATENT OR TRADEMARK NO.	INCLUDED BY DATE OF PATENT	Amendment Answer Cross Bill	Other Pleading
DATE INCLUDED PATENT OR TRADEMARK NO.	INCLUDED BY DATE OF PATENT	Amendment Answer Cross Bill	Other Pleading
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PATE INCLUDED PATENT OR TRADEMARK NO. 1	INCLUDED BY DATE OF PATENT	Amendment Answer Cross Bill	Other Pleading
PATENT OR TRADEMARK NO. 1 2	INCLUDED BY DATE OF PATENT	Amendment Answer Cross Bill	Other Pleading
PATENT OR TRADEMARK NO. 1 2 3 4 5	INCLUDED BY DATE OF PATENT OR TRADEMARK	Amendment Answer Cross Bill	Other Pleading
PATENT OR TRADEMARK NO. 1 2 3 4 5	INCLUDED BY DATE OF PATENT OR TRADEMARK	Amendment	Other Pleading
PATENT OR TRADEMARK NO. 1 2 3 4 5 In the above	INCLUDED BY DATE OF PATENT OR TRADEMARK e-entitled case, the follow	Amendment	☐ Other Pleading TRADEMARK
PATENT OR TRADEMARK NO. 1 2 3 4 5 In the abov DECISION/JUDGEMENT Plaintiff's Noti	DATE OF PATENT OR TRADEMARK re—entitled case, the follow ice of Dismissal Purs	Amendment	☐ Other Pleading TRADEMARK

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P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	ISSUE DATE	PATENT NO.	ATTORNEY DOCKET NO.	CONFIRMATION NO.
12/942,792	11/13/2012	8309375	0020-5147PUS12	2357

2292 7590

10/24/2012

BIRCH STEWART KOLASCH & BIRCH PO BOX 747 FALLS CHURCH, VA 22040-0747

ISSUE NOTIFICATION

The projected patent number and issue date are specified above.

Determination of Patent Term Adjustment under 35 U.S.C. 154 (b)

(application filed on or after May 29, 2000)

The Patent Term Adjustment is 0 day(s). Any patent to issue from the above-identified application will include an indication of the adjustment on the front page.

If a Continued Prosecution Application (CPA) was filed in the above-identified application, the filing date that determines Patent Term Adjustment is the filing date of the most recent CPA.

Applicant will be able to obtain more detailed information by accessing the Patent Application Information Retrieval (PAIR) WEB site (http://pair.uspto.gov).

Any questions regarding the Patent Term Extension or Adjustment determination should be directed to the Office of Patent Legal Administration at (571)-272-7702. Questions relating to issue and publication fee payments should be directed to the Application Assistance Unit (AAU) of the Office of Data Management (ODM) at (571)-272-4200.

APPLICANT(s) (Please see PAIR WEB site http://pair.uspto.gov for additional applicants):

Yoshinori Shimizu, Naka-gun, JAPAN; Kensho Sakano, Anan-shi, JAPAN; Yasunobu Noguchi, Naka-gun, JAPAN; Toshio Moriguchi, Anan-shi, JAPAN;

The United States represents the largest, most dynamic marketplace in the world and is an unparalleled location for business investment, innovation, and commercialization of new technologies. The USA offers tremendous resources and advantages for those who invest and manufacture goods here. Through SelectUSA, our nation works to encourage and facilitate business investment. To learn more about why the USA is the best country in the world to develop technology, manufacture products, and grow your business, visit <u>SelectUSA.gov</u>.

PART B - FEE(S) TRANSMITTAL

Complete and send this form, together with applicable fee(s), to: Mail Mail Stop ISSUE FEE

Commissioner for Patents P.O. Box 1450 Alexandria, Virginia 22313-1450

(571)-273-2885

INSTRUCTIONS: This form should be used for transmitting the ISSUE FEE and PUBLICATION FEE (if required). Blocks 1 through 5 should be completed where appropriate. All further correspondence including the Patent, advance orders and notification of maintenance fees will be mailed to the current correspondence address as indicated unless corrected below or directed otherwise in Block 1, by (a) specifying a new correspondence address; and/or (b) indicating a separate "FEE ADDRESS" for maintenance fee notifications. CURRENT CORRESPONDENCE ADDRESS (Note: Use Block 1 for any change of address) Note: A certificate of mailing can only be used for domestic mailings of the Fee(s) Transmittal. This certificate cannot be used for any other accompanying papers. Each additional paper, such as an assignment or formal drawing, must have its own certificate of mailing or transmission. 07/12/2012 BIRCH STEWART KOLASCH & BIRCH, LLP Certificate of Mailing or Transmission I hereby certify that this Fee(s) Transmittal is being deposited with the United States Postal Service with sufficient postage for first class mail in an envelope addressed to the Mail Stop ISSUE FEE address above, or being facsimile transmitted to the USPTO (571) 273-2885, on the date indicated below. PO BOX 747 **FALLS CHURCH, VA 22040-0747** (Signatu (Date APPLICATION NO. FILING DATE FIRST NAMED INVENTOR ATTORNEY DOCKET NO CONFIRMATION NO. 12/942,792 11/09/2010 Yoshinori Shimizu 0020-5147PUS12 TITLE OF INVENTION: LIGHT EMITTING DEVICE AND DISPLAY APPLN, TYPE SMALL ENTITY ISSUE FEE DUE PUBLICATION FEE DUE PREV. PAID ISSUE FEE TOTAL FEE(S) DUE DATE DUE \$1740- 1770 nonprovisional NO \$300 10/12/2012 2070. **EXAMINER** ARTUNIT CLASS-SUBCLASS MUSTAPHA, ABDULFATTAH B 2812 438-021000 1. Change of correspondence address or indication of "Fee Address" (37 CFR 1.363). 2. For printing on the patent front page, list 1 Birch, Stewart, Kolasch & Birch, LLP (1) the names of up to 3 registered patent attorneys or agents OR, alternatively, ☐ Change of correspondence address (or Change of Correspondence Address form PTO/SB/122) attached. (2) the name of a single firm (having as a member a Tree Address" indication (or "Fee Address" Indication form PTO/SB/47; Rev 03-02 or more recent) attached. Use of a Customer registered attorney or agent) and the names of up to 2 registered patent attorneys or agents. If no name is listed, no name will be printed. Number is required. 3. ASSIGNEE NAME AND RESIDENCE DATA TO BE PRINTED ON THE PATENT (print or type) PLEASE NOTE: Unless an assignee is identified below, no assignee data will appear on the patent. If an assignee is identified below, the document has been filed for recordation as set forth in 37 CFR 3.11. Completion of this form is NOT a substitute for filing an assignment. (A) NAME OF ASSIGNEE (B) RESIDENCE: (CITY and STATE OR COUNTRY) Anan-shi, Japan NICHIA CORPORATION Please check the appropriate assignee category or categories (will not be printed on the patent): 🔲 Individual 🖾 Corporation or other private group entity 🚨 Government 4a. The following fee(s) are submitted: 4b. Payment of Fee(s): (Please first reapply any previously paid issue fee shown above) Issue Fee A check is enclosed. Publication Fee (No small entity discount permitted) Payment by credit card. Form PTO-2038 is attached. The Director is hereby authorized to charge the required fee(s), any deficiency, or credit any overpayment, to Deposit Account Number 02-2448 (enclose an extra copy of this fo Advance Order - # of Copies (enclose an extra copy of this form). 5. Change in Entity Status (from status indicated above) ☐ a. Applicant claims SMALL ENTITY status. See 37 b. Applicant is no longer claiming SMALL ENTITY status. See 37 CFR 1.27(g)(2). NOTE: The Issue Fee and Publication Fee (if required will not be accepted from anyone other than the applicant; a registered attorney or agent; or the assignee or other party in interest as shown by the records of the United States Patent and Tradymark Of fige. d Trad∮mark (Authorized Signature October 11, 2012 Typed or printed name _____ D. Richard Anderson Registration No. _

This collection of information is required by 37 CFR 1.311. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 12 minutes to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, Virginia 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, Virginia 22313-1450.

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Electronic Patent Application Fee Transmittal					
Application Number:	129	942792			
Filing Date:	09-	Nov-2010			
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY				
First Named Inventor/Applicant Name:	Yoshinori Shimizu				
Filer:	David Richard Anderson/Patti Young				
Attorney Docket Number:	0020-5147PUS12				
Filed as Large Entity					
Utility under 35 USC 111(a) Filing Fees					
Description		Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Basic Filing:					
Pages:					
Claims:					
Miscellaneous-Filing:					
Petition:					
Patent-Appeals-and-Interference:					
Post-Allowance-and-Post-Issuance:					
Utility Appl issue fee		1501	1	1770	1770
Publ. Fee- early, voluntary, or normal		1504	1	300	300

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Extension-of-Time:				
Miscellaneous:				
	Tot	al in USD	(\$)	2070

Electronic Ack	knowledgement Receipt
EFS ID:	13964292
Application Number:	12942792
International Application Number:	
Confirmation Number:	2357
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY
First Named Inventor/Applicant Name:	Yoshinori Shimizu
Customer Number:	2292
Filer:	David Richard Anderson/Patti Young
Filer Authorized By:	David Richard Anderson
Attorney Docket Number:	0020-5147PUS12
Receipt Date:	11-OCT-2012
Filing Date:	09-NOV-2010
Time Stamp:	16:15:00
Application Type:	Utility under 35 USC 111(a)

Payment information:

Submitted with Payment	yes
Payment Type	Credit Card
Payment was successfully received in RAM	\$2070
RAM confirmation Number	3163
Deposit Account	022448
Authorized User	ANDERSON, RICHARD D.

The Director of the USPTO is hereby authorized to charge indicated fees and credit any overpayment as follows:

Charge any Additional Fees required under 37 C.F.R. Section 1.16 (National application filing, search, and examination fees)

Charge any Additional Fees required under 37 C.F.R. Section 1.17 (Patent application and reexamination processing fees)

Charge ar	ny Additional Fees required under 37 C.F.	R. Section 1.19 (Document supply	fees)		
Document Number	Document Description	File Name	File Size(Bytes)/ Message Digest	Multi Part /.zip	Pages (if appl.)
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Information:					
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2	Fee Worksheet (SB06)	fee-info.pdf	fce7100ff15178123825f208d61f309df9c78f f8	no	2
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Information:					
		Total Files Size (in bytes)	14	7140	

This Acknowledgement Receipt evidences receipt on the noted date by the USPTO of the indicated documents, characterized by the applicant, and including page counts, where applicable. It serves as evidence of receipt similar to a Post Card, as described in MPEP 503.

New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.

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Substitute for	form 1449A/PTC)		Complete if Known		
INIEODI				Application Number	12/942,792	
	INFORMATION DISCLOSURE			Filing Date	11-09-10	
STATE	STATEMENT BY APPLICANT			First Named Inventor	Yoshinori Shimizu	
				Art Unit	2812	
(Us	(Use as many sheets as necessary)			Examiner Name	A.B. MUSTAPHA	
Sheet	1	of	2	Attorney Docket Number	0020-5147PUS12	

			U.S. PATE	NT DOCUMENTS	
Examiner initial *	Cite No.	Document Number	Publication Date	Name of Patentee or	Pages, columns, Lines, Where
	NO.	Number - Kind Code ² (if known)	MM-DD-YYYY	Applicant of Cited Document	Relevant Passages or Relevant Figures Appear
/A.M./	1	US-2012/0132857 -	05-31-2012	Le Toquin	
/A.M./	2	US-3, 882,502	05-06-1975	Peabody et al.	
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		FOREIGN	PATENT DOC	UMENTS		
Examiner	Cite	Foreign Patent Document			Pages, columns, Lines, Where	
Initial *	No. 1	Country ³ Number ⁴ Kind Code (if known) ⁵	Publication Date MM-DD-YYYY	Applicant of Cited Document	Relevant Passages or Relevant Figures Appear	Т
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Examiner Signature	/Abdulfattah Mustapha/	Date Considered	10/02/2012
Signature	// todaliattai iriastapha	Considered	

^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not Considered. Include copy of this form with next communication to applicant. 1. Applicant's unique citation design number (optional). 2 See Kinds Codes of USPTO patent Documents. at www.uspto.gov or MPEP 901.04. 3. Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). 4. For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. 5. Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. 6. Applicant is to place a check mark here if English language Translation is attached.

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Substitute for	form 1449B/PTO			Complete if Known				
INFOR	MATION	DISCI	OSURE	Application Number	12/942,792			
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Filing Date	11-09-10			
OIAII	-iviLivi D	I AFF	LICANI	First Named Inventor	Yoshinori Shimizu			
(U:	se as many sheets	s as neces	sary)	Art Unit	2812			
_				Examiner Name	A.B. MUSTAPHA			
Sheet	2	of	2	Attorney Docket Number	0020-5147PUS12			

		NON PATENT LITE	RATURE DOCUMENTS
Examiner Initial *	Cite No. 1	item (book, magazine, journal, serial, symp	LETTERS), title of the article (when appropriate), title of the osium, catalog, etc.), date, page(s), volume-issue number(s), and/or country where published.
/A.M./	3	U.S. Office Action in co-pending application	no. 12/689,681 dated September 7, 2012.
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Exam Signa		/Abdulfattah Mustapha/	Date

^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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If you need assisstance in completing the form, call 1-800-PTO-9199 and select option 2.

^{1.} Applicants unique citation designation number. (optional) 2. Applicant is to place a check mark here if English language Translation is attached.

This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Cheif Information Officer, U.S. Patent and Trademark Office, P.O. Box 1450 Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS.

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U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE
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(L			Complete	if Known		
	ANI		A	Application Nur	mber	12/942,792	2	Conf. No.: 2357	
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			L	First Named Inv	ventor	Yoshinori S	SHIMIZU		
	-11	0 07.050.4		Examiner Nam	e	A.B. MUST	`APHA		
Applicant claims sma	all entity stat	us. See 37 CFR 1.		Art Unit		2812			
TOTAL AMOUNT OF PAY	MENT (\$) 180.00		Attorney Docke	t No.	0020-5147	PUS12		
METHOD OF PAYMEN	IT (check a	all that apply)							
Check Credit	Card	Money Order	None	Other (please ide	ntify):			
Deposit Account	Deposit Accou	int Number: 02-2448	3	Deposit A	ccount Na	me: Birch,	Stewart, Ko	lasch & Birch, LLP	_
For the above-iden	tified deposi	t account, the Direc	ctor is herel						
Charge fee(s	s) indicated l	below		Charg	ge fee(s)	indicated b	elow, exce	pt for the filing fee	•
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under 37 CF under 37 CF WARNING: Information on the Information and authorization	is form may	become public. Cred	lit card infor	mation should n	ot be incl	uded on this	s form. Prov	ide credit card	
FEE CALCULATION	1011710-203								
1. BASIC FILING, SEA	RCH. AND	EXAMINATION	FEES						
	FILING	FEES	SEARC	H FEES	EXAM	INATION			
Application Type	Fee (\$)	Small Entity Fee (\$)	Fee (\$)	Small Entity Fee (\$)	Fee	<u>Small (</u> (\$) Fee		Fees Paid (\$)	
Utility	380	190	620	310	250				
Design	250	125	120	60	160				
Plant	250	125	380	190	200	0.0			
Reissue	380	190	620	310	750	10			
Provisional	250	125	0	0	0				
2. EXCESS CLAIM FE	ES			v	ŭ			mall Entity	
Fee Description		D : \				_	e (\$)	Fee (\$)	
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Total Claims	Extra Clai	ims Fee (\$)	Fee F	aid (\$)				endent Claims	
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Indep. Claims - 3 or HP =	Extra Clai	ms Fee (\$)		aid (\$) 00					
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3. APPLICATION SIZE	FEE	awaaad 100 ahaa	ta of	(.1	11 61	1		
If the specification and listings under 37 C	FR 1.52(e)), the application	n size fee o	due is \$310 (\$	155 for	small ent	i sequence ity) for ea	ch additional 50	
sheets or fraction th	hereof. Se	e 35 U.S.C. 41(a)(1)(G) an	d 37 CFR 1.1	6(s).				
Total Sheets Extra Sheets Number of each additional 50 or fraction thereof Fee (\$) Fee Paid (\$) - 100 = 0 / 50 = 0 (round up to a whole number) x = 0.00									
4. OTHER FEE(S)									- \$)
Non-English Specification, \$130 fee (no small entity discount)									
Other (e.g., late nume surcharge): 1806 IDS Fee 180.00									
SUBMITTED BY	U /	////	1/ /						
Signature	$\sqrt{2}$	\mathcal{L}	Re (At	gistration No. ₄ tomey/Agent)	0,439	1	elephone 7	703-205-8000	
Name (Print/Type) D. Richard	d Anderson						Date Septer	mber 26, 2012	

This collection of information is required by 37 CFR 1.136. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 30 minutes to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

If you need assistance in completing the form, call 1-800-PTO-9199 and select option 2.



Docket No.: 0020-5147PUS12

(Patent)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

12/942,792

Confirmation No.: 2357

Filed:

November 09, 2010

Art Unit:

2812

For: LIGHT EMITTING DEVICE AND DISPLAY

Examiner:

A.B. MUSTAPHA

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Commissioner:

Applicant(s) hereby submit(s) an Information Disclosure Statement for consideration by the Examiner.

I. LIST OF PATENTS, PUBLICATIONS OR OTHER INFORMATION

The patents, publications, or other information submitted for consideration by the Office are listed on the attached PTO/SB/08.

II. COPIES

a. Copies of foreign patent documents, non-patent literature and other information are provided.

b. <u>REFERENCES PREVIOUSLY CITED OR SUBMITTED</u>: Copies of any information not provided can be found in one or more of the following applications which has been relied upon for an earlier filing date under 35 U.S.C. § 120:

U.S. Application No. and U.S. Filing Date

12/028,062 filed February 8, 2008

for

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 2 of 6

III. CONCISE EXPLANATION OF THE RELEVANCE/OTHER INFORMATION

a. NON-ENGLISH LANGUAGE DOCUMENTS: A concise explanation of the relevance of all non-English language patents, publications, or other information listed is as follows:

- □ b. ENGLISH LANGUAGE SEARCH REPORT OR FOREIGN PATENT OFFICE COMMUNICATION: An English language version of the search report or Foreign Patent Office communication that indicates the degree of relevance is attached.
- c. OTHER: The following additional information is provided.
 US 3,882,502 and US 2012/0132857 were cited in an Office Action issued in co-pending
 US Application 12/689,681 dated September 7, 2012.

IV. STATEMENT UNDER 37 C.F.R. § 1.97(e)

The undersigned hereby states that:

- a. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than <u>30</u> <u>days</u> prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or
- b. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than **three months** prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or

Application No.: 12/942,792 Docket No.: 0020-5147PUS12

Page 3 of 6

C. No item of information contained in the IDS was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing the certification after making reasonable inquiry, no item of IDS was known to any individual designated in 37 C.F.R. § 1.56(c) more than **three months** prior to the filing of the IDS; or

d. Some of the items of information in the IDS were cited in a communication from a foreign patent office. Such items were first cited in a communication from a foreign patent office in a counterpart foreign application not more than **three months** prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office. As to the remaining items of information, to the knowledge of the person signing the certification after making reasonable inquiry, such remaining items were not known to any individual designated in 37 C.F.R. § 1.56(c) more than **three months** prior to the filing of this statement.

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 4 of 6

V. STATEMENT UNDER 37 C.F.R. § 1.704(d)(1)

Patent Term Adjustment Reduction Should Not Apply
☐ The undersigned hereby states:
This Information Disclosure Statement is in compliance with 37 C.F.R. §§ 1.97 and 1.9
and will not be considered a failure to engage in reasonable efforts to conclude prosecutio
(processing or examination) of the present application under 37 C.F.R. § 1.704(c)(6), (c)(8)
(c)(9), or (c)(10), because each item of information contained in the Information Disclosur
Statement:
(i) Was first cited in any communication from a patent office in a counterpart
foreign or international application or from the Office, and this communication was no
received by any individual designated in § 1.56(c) more than thirty days prior to the filing
of the information disclosure statement; or
(ii) Is a communication that was issued by a patent office in a counterpart foreign
or international application or by the Office, and this communication was not received by
any individual designated in § 1.56(c) more than thirty days prior to the filing of the
information disclosure statement.
VI. <u>FEES</u>
a. This Information Disclosure Statement is being filed concurrently with the filing
of a new patent application or Request for Continued Examination. No fee is required.
D b. This Information Disclosure Statement is being filed within three months of the
filing date of an application. No fee is required.
C. This Information Disclosure Statement is being filed before the mailing date of a
first Action on the merits. No fee is required. If a first Office Action on the merits has issued
please consider this IDS under 37 C.F.R. § 1.97(c) and see the statement under 37 C.F.R
§ 1.97(e) above. If no statement has been made, charge our deposit account for the required fee.

d. This Information Disclosure Statement is being filed before the mailing date of a Final Office Action or before the mailing date of a Notice of Allowance or before an action that otherwise closes prosecution in the application (see 37 C.F.R. § 1.97(c)(1)). No statement. The fee as required by 37 C.F.R. § 1.17(p) is provided. or See the above statement. No fee is required. $\overline{\mathbf{Q}}$ e. This Information Disclosure Statement is being filed after the mailing date of a Final Office Action or after the mailing date of a Notice of Allowance or after an action that otherwise closes prosecution in the application (see 37 C.F.R. § 1.97(d)), see the statement above. The fee as required by 37 C.F.R. § 1.17(p) is provided. VII. PAYMENT OF FEES $\sqrt{}$ The required fee is listed on the attached Fee Transmittal. No fee is required.

Application No.: 12/942,792

Docket No.: 0020-5147PUS12

Page 5 of 6

Application No.: 12/942,792 Docket No.: 0020-5147PUS12

Page 6 of 6

If the Examiner has any questions concerning this IDS, please contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the USPTO is requested to consider this IDS under the proper rule and charge the appropriate fee to Deposit Account No. 02-2448.

Dated: September 26, 2012	Respectfully submitted
	By D. Richard Anderson Registration No.: 40,439 BIRCH, STEWART, KOLASCH & BIRCH, LLI
	8110 Gatehouse Road, Suite 100 East
	P.O. Box 747
	Falls Church, VA 22040-0747
	703-205-8000
Attachment(s):	
☑ PTO/SB/08	
☑ Document(s)	

☐ Foreign Patent Office Communication

☐ Foreign Search Report

✓ Fee□ Other:

Under the Paperwork reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number.

S	Substitute f	or form 1449A/PTO	1		Complete if Known				
			-100		Application Number	12/942,792			
		RMATION I			Filing Date	11-09-10			
	STAT	EMENT BY	/ AP	PLICANT	First Named Inventor	Yoshinori Shimizu			
					Art Unit	2812			
	(Use as many sheet	s as nec	cessary)	Examiner Name	A.B. MUSTAPHA			
	Sheet	1	of	2	Attorney Docket Number	0020-5147PUS12			

			U.S. PATE	NT DOCUMENTS	
Examiner Cite No.		Document Number	Publication Date	Name of Patentee or	Pages, columns, Lines, Where
	No.	Number - Kind Code ² (if known)	MM-DD-YYYY	Applicant of Cited Document	Pages, columns, Lines, Where Relevant Passages or Relevant Figures Appear
	1	US-2012/0132857 -	05-31-2012	Le Toquin	
	2	US-3, 882,502	05-06-1975	Peabody et al.	

		FORE	IGN PATENT DOCUM	MENTS		
Examiner Cite		Foreign Patent Document			Pages, columns, Lines, When Relevant Passages or Relevan Figures Appear	
Initial * No. 1	Country ³ Number ⁴ Kind Code (if known) ⁵	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document			
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Examiner	Date	
Signature	Considered	
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This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, P.O. Box 1450 Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS.

SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

(et

If you need assisstance in completing the form, call 1-800-PTO-9199 (1-800-786.9199) and select option 2.

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not Considered. Include copy of this form with next communication to applicant. 1. Applicant's unique citation design number (optional). 2 See Kinds Codes of USPTO patent Documents, at www.uspto.gov or MPEP 901.04. 3. Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). 4. For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. 5. Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. 6. Applicant is to place a check mark here if English language Translation is attached.

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Substitute for form 1449B/PTO				Complete if Known			
INFOR	ΜΔΤΙΩΝ	DISCI	OSURE	Application Number	12/942,792		
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Filing Date	11-09-10		
STATEMENT BY AFFEIGANT				First Named Inventor	Yoshinori Shimizu		
(Use as many sheets as necessary)				Art Unit	2812		
		Examiner Name	A.B. MUSTAPHA				
Sheet	2	of	2	Attorney Docket Number	0020-5147PUS12		

		NON PATENT LITERATURE DOCUMENTS	
Examiner Initial *	Clte No. 1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T 2
	3	U.S. Office Action in co-pending application no. 12/689,681 dated September 7, 2012.	
			<u> </u>
Exam Signa		Date Considered]

Examiner	Date		
Signature	Considered		

If you need assisstance in completing the form, call 1-800-PTO-9199 and select option 2.

^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

^{1.} Applicants unique citation designation number. (optional) 2. Applicant is to place a check mark here if English language Translation is attached. This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Cheif Information Officer, U.S. Patent and Trademark Office, P.O. Box 1450 Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Electronic Patent Application Fee Transmittal						
Application Number:	12	942792				
Filing Date:	09	Nov-2010				
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY					
First Named Inventor/Applicant Name:	Yoshinori Shimizu					
Filer:	David Richard Anderson/Patti Young					
Attorney Docket Number:	0020-5147PUS12					
Filed as Large Entity						
Utility under 35 USC 111(a) Filing Fees						
Description		Fee Code	Quantity	Amount	Sub-Total in USD(\$)	
Basic Filing:						
Pages:						
Claims:						
Miscellaneous-Filing:						
Petition:						
Patent-Appeals-and-Interference:						
Post-Allowance-and-Post-Issuance:					_	
Extension-of-Time:						

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Miscellaneous:				
Submission- Information Disclosure Stmt	1806	1	180	180
	Tot	al in USD	(\$)	180

Electronic Acknowledgement Receipt				
EFS ID:	13846732			
Application Number:	12942792			
International Application Number:				
Confirmation Number:	2357			
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY			
First Named Inventor/Applicant Name:	Yoshinori Shimizu			
Customer Number:	2292			
Filer:	David Richard Anderson/Patti Young			
Filer Authorized By:	David Richard Anderson			
Attorney Docket Number:	0020-5147PUS12			
Receipt Date:	26-SEP-2012			
Filing Date:	09-NOV-2010			
Time Stamp:	17:44:36			
Application Type:	Utility under 35 USC 111(a)			

Payment information:

Submitted with Payment	yes
Payment Type	Credit Card
Payment was successfully received in RAM	\$180
RAM confirmation Number	4817
Deposit Account	022448
Authorized User	ANDERSON, RICHARD D.

The Director of the USPTO is hereby authorized to charge indicated fees and credit any overpayment as follows:

Charge any Additional Fees required under 37 C.F.R. Section 1.16 (National application filing, search, and examination fees)

Charge any Additional Fees required under 37 C.F.R. Section 1.17 (Patent application and reexamination processing fees)

	/ Additional Fees required under 37 C.F	R. Section 1.19 (Document supply	fees)		
Document Number	Document Description	File Name	File Size(Bytes)/ Message Digest	Multi Part /.zip	Pages (if appl.)
1		20120926IDS.pdf	431816	V/OS	9
'		20120920iD3.pdi	edaf928dbe060c0176fc15b07fb5436a7229 f0ae	yes	9
	Multip	part Description/PDF files in .	zip description		
	Document De	scription	Start	E	nd
	Miscellaneous Inco	1		1	
	Transmittal	2	7		
	Foreign Refe	Foreign Reference			
Warnings:					
Information:					
2	Non Patent Literature	20120907FinalRejection.pdf	651775	no	12
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Warnings:					
Information:					
3	Fee Worksheet (SB06)	fee-info.pdf	30282 no		2
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Warnings:					
Information:					
		Total Files Size (in bytes)	. 11	13873	

This Acknowledgement Receipt evidences receipt on the noted date by the USPTO of the indicated documents, characterized by the applicant, and including page counts, where applicable. It serves as evidence of receipt similar to a Post Card, as described in MPEP 503.

New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.

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Substitute	for form 1449A/PTC)		С	complete if Known
=	INFORMATION DISCLOSURE STATEMENT BY APPLICANT				12/942,792
					11-09-10
STA [*]					Yoshinori Shimizu
					2812
	(Use as many sheets as necessary)			Examiner Name	A.B. MUSTAPHA
Sheet	1	of	2	Attorney Docket Number	0020-5147PUS12

			U.S. PATE	NT DOCUMENTS	
		Document Number	Publication Date	Name of Patentee or	Pages, columns, Lines, Where
	Number - Kind Code ² (if known)	MM-DD-YYYY	Applicant of Cited Document	Relevant Passages or Relevant Figures Appear	
/A.M./	1	US-5,247,533	09-21-1993	Okazaki et al.	
/A.M./	2	US-5,408,120	04-18-1995	Manabe et al.	

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Initial * No.	No. 1 Country ³ Number ⁴ Kind Code (if known) ⁵ Code	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Relevant Passages or Relevant Figures Appear	т	
/A.M./	3	JP 7-335942	12-22-1995	Nichla Chem Ind Ltd.		1
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^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not Considered. Include copy of this form with next communication to applicant. 1. Applicant's unique citation design number (optional), 2 See Kinds Codes of USPTO patent Documents, at www.uspto.gov or MPEP 901.04. 3. Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). 4. For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. 5. Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. 6. Applicant is to place a check mark here if English language Translation is attached.

This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, P.O. Box 1450 Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS.

SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

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	Substitute for	form 1449B/PTO			C	omplete if Known
	INFOR	MATION	ISCI	OSLIDE	Application Number	12/942,792
INFORMATION DISCLOSURE STATEMENT BY APPLICANT					Filing Date	11-09-10
	STATEMENT OF APPLICANT				First Named Inventor	Yoshinori Shimizu
	(Use as many sheets as necessary)				Art Unit	2812
	,		Examiner Name	A.B. MUSTAPHA		
	Sheet	2	of	2	Attorney Docket Number	0020-5147PUS12

		NON PATENT LITER	RATURE DOCUMENTS		
Examiner initial *	Cite No. ¹	Include name of the author (in CAPITAL L item (book, magazine, journal, serial, sympo publisher, city a			T 2
/A.M./	4	Singaporean Examination and Search Report Application No. 201007151-2.	issued on July 2, 2012 in cour	nterpart Singapore Patent	•
/A.M./	5	Singaporean Examination and Search Report Application No. 201007150-4.	issued on July 5, 2012 in cour	nterpart Singapore Patent	•
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Exam Signa		/Abdulfattah Mustapha/	Date Considered	08/21/2012	

^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

If you need assisstance in completing the form, call 1-800-PTO-9199 and select option 2.



^{1.} Applicants unique citation designation number, (optional) 2. Applicant is to place a check mark here if English language Translation is attached.

This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Cheif Information Officer, U.S. Patent and Trademark Office, P.O. Box 1450 Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS.

SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
12/942,792	11/09/2010 Yoshinori Shimizu		0020-5147PUS12	2357	
	7590 08/09/201 ART KOLASCH & BI	EXAMINER			
PO BOX 747	CH 3/A 22040 0747	MUSTAPHA, ABDULFATTAH B			
FALLS CHURCH, VA 22040-0747		ART UNIT	PAPER NUMBER		
			2812		
			NOTIFICATION DATE	DELIVERY MODE	
			08/09/2012	ELECTRONIC	

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Notice of the Office communication was sent electronically on above-indicated "Notification Date" to the following e-mail address(es):

mailroom@bskb.com



UNITED STATES DEPARTMENT OF COMMERCE **U.S. Patent and Trademark Office**

Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450

APPLICATION NO./ CONTROL NO.	FILING DATE	FIRST NAMED INVENTOR / PATENT IN REEXAMINATION	A	TTORNEY DOCKET NO.	
12/942,792	09 November, 2010	SHIMIZU ET AL.		0020-5147PUS12	
			E	XAMINER	
BIRCH STEWART KOLA PO BOX 747			ABDULFATTAH MUSTAPHA		
FALLS CHURCH, VA 22	040-0747		ART UNIT	PAPER	
			2812	20120801	
		'	1	ı	

DATE MAILED:

Please find below and/or attached an Office communication concerning this application or proceeding.

Commissioner for Patents

/Charles D. Garber/	
Supervisory Patent Examiner, Art Unit 2812	
PTO-90C (Rev.04-03)	

The IDS of 07/23/2012 is considered.

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	Substitute for	form 1449A/PTO			Complete if Known		
	325-~-		~ : ~ ~	· · · · · · · · · · · · · · · · · · ·	Application Number	12/942,792	
		MATION [Filling Date	11-09-10	
	STATE	MENT BY	'AP	PLICANT	First Named Inventor	Yoshinori Shimizu	
					Art Unit	2812	
(Use as many sheets as necessary)				ressary)	Examiner Name	A.B. MUSTAPHA	
	Sheet	1	of	2	Attorney Docket Number	0020-5147PUS12	

			U.S. PATE	NT DOCUMENTS	
Examiner Cite initial * No.		Gocument Number	Publication Date	Name of Patentee or	Pages, columns, Unes, Where
Nu	Number - Kind Code ² (if known)	MM-DO-YYYY	Applicant of Oiled Document	Pages, polumns, Lines, Where Relevant Passages or Relevant Figures Appear	
/A.M./	1	US-3,560,849	02-02-1971	Anderson	
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	1	US-5,247,533	09-21-1993	Okazaki et al.	1,9			
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PTO/SB/08b (07-09)

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	5	Singaporean Examination and Search Report issued on July 5, 2012 in counterpart Singapore Patent Application No. 201007150-4.	~				
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PATENT ABSTRACTS OF JAPAN

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(21)Application number : 06-131531 (71)Applicant : NICHIA CHEM IND LTD

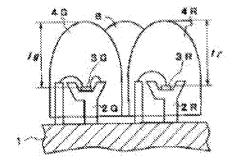
(22)Date of filing: 14.06.1994 (72)Inventor: NAGAI YOSHIFUMI

(54) FULL-COLOR LED DISPLAY

(57)Abstract:

PURPOSE: To obtain the stable white balance with high luminance and small power consumption by a method wherein a green color LED and a blue color LED which have respective light emitting chips made of gallium nitride system compound semiconductor are combined together.

CONSTITUTION: Respective lead frames of a red color LED, a green color LED and a blue color LED (B) are electrically connected to the surface of a board 1 on which wiring patterns are formed. The green color LED has a green light emitting chip 3G which is composed of a sapphire substrate and a gallium nitride system compound semiconductor layer built up on the sapphire substrate and whose dimensions are $100\,\mu$ m thick and $350\,\mu$ m square. The green light emitting chip has a double-hetero structure composed of an InGaN active layer and a GaAlN cladding layer. The blue color LED (B) has a blue light emitting chip whose dimensions, etc., are the same as those of the green light emitting



chip 3G except that the composition of the InGaN active layer is different. Further, in order to adjust directional characteristics, the substrate of the red light emitting chip 3R of the red color LED is polished.

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CLAIMS

[Claim(s)]

[Claim 1]A full color LED display comprising:

A red LED lamp which constitutes stroke matter.

A green LED lamp.

A light emitting chip in which said green LED lamp and a blue LED lamp consist of a gallium nitride system compound semiconductor in a full color LED display which a blue LED lamp is connected on the same board, and changes.

[Claim 2]A full color LED display given in Claim 1 in which a half angle of the directional characteristics of the aforementioned red LED lamp is characterized by being the same as that of a half angle of the directional characteristics of a green LED lamp and a blue LED lamp. [Claim 3]With resin or glass, the mold of the aforementioned red LED lamp, a green LED lamp, and the blue LED lamp is carried out to the shape of a lens, they change, and a light emitting chip The peak of a mold lens of the aforementioned red LED lamp, Distance with the surface of a light emitting chip which it had in the red LED lamp The peak of a mold lens of said green LED lamp and a blue LED lamp, A full color LED display given in Claim 2, wherein it is adjusted so that it may become substantially equal to distance with the surface of a light emitting chip which it had in the green LED lamp and a blue LED lamp, and a half angle of the directional characteristics of a red LED lamp is adjusted.

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DETAILED DESCRIPTION

[Detailed Description of the Invention] [0001]

[Industrial Application] The LED lamp to which the mold of the light emitting chip was carried out with resin, glass, etc. as for the present invention. Red LED, green LED, and blue LED which constitute stroke matter especially are related with the full color LED display which is connected on the same board and changes about the LED display which connects on the same board it (is hereafter called LED). [two or more] [0002]

[Description of the Prior Art] That with which the light emitting chip installed on the leadframe was able to compare regularly LED sealed by lens shape with resin, glass, etc. on the substrate is known by the LED display. Although the thing of the multicolor which used red LED and green LED is already put in practical use by the present LED display, the full color display has not yet resulted in utilization in a trial production stage.

[0003]As for the full color LED display made as an experiment now, SiC is used for red LED as a material of a light emitting chip at GaP and blue LED at GaAlAs, GaAsP, and green LED. However, compared with the luminous intensity of red LED, the luminous intensity of green LED and blue LED was low, and since blue LED in particular had 1/100 or less, there was a fault that a high-intensity display was not obtained.

[0004] The aforementioned display has increased the number of green LED and blue LED to the number of red LED in stroke matter in order to compensate this fault, but when the number of LED in stroke matter increases, the resolution of the whole display worsens and, moreover, there is a fault that power consumption is large. Since the directional characteristics of each LED differed when the light ratio of LED of each luminescent color and what is called a white balance are using LED which consists of three kinds of light emitting chips when displaying white further again, there was a fault of not being fixed.

[0005]

[Problem to be solved by the invention]Accomplish the present invention in order to solve the above-mentioned fault, and the place made into the purpose uses LED with high luminous intensity, and realize little display of power consumption with high-intensity, and. It is in realizing the full color LED display in which the white balance stable by combining LED which can furthermore adjust directional characteristics easily is obtained.

[0006]

[Means for solving problem] In order to improve the luminosity of a full color LED display, it is necessary to use high green LED and blue LED of luminous intensity first. Directional characteristics need to arrange in in order to obtain the stable white balance a few LED which corresponded as much as possible to stroke matter. We newly find out the blue LED and green LED which can satisfy the demand simultaneously, and came to solve the above-mentioned problem. Namely, the full color LED display of the present invention, In the full color LED display in which it is connected on the same substrate and red LED which constitutes stroke matter, green LED, and blue LED change, above-mentioned green LED and blue LED are provided with the light emitting chip which consists of a gallium nitride system compound semiconductor.

[0007] The 2nd of the present invention is characterized by the half angle of the directional characteristics of red LED being the same as the half angle of the directional characteristics of green LED and blue LED. That is, since it is blue LED and a green LED identical material, the directional characteristics of the conventional red LED are adjusted to green and blue LED. [0008] With resin or glass, the mold of the 3rd of the present invention is carried out to the shape of a lens, it changes, and a light emitting chip red LED, green LED, and blue LED The peak of the mold lens of the aforementioned red LED lamp, Distance with the surface of the light emitting chip which it had in the red LED lamp The peak of the mold lens of the above—mentioned green LED lamp and a blue LED lamp, It is adjusted so that it may become substantially equal to distance with the surface of the light emitting chip which it had in the green LED lamp and a blue LED lamp, and the half angle of the directional characteristics of a red LED lamp is adjusted. It cannot be overemphasized that green LED and blue LED are provided with the light emitting chip which consists of a gallium nitride system compound semiconductor.

[0009]In red LED used in the LED display of the present invention, LED provided with the material of the conventional light emitting chip can be used, these LED has the degree of luminescent light of 1 cds or more, and, as for the radiant power output, GaAlAs, GaAsP, etc. have 1 mW or more.

[0010]Next, these are provided with the light emitting chip which consists of a gallium nitride system compound semiconductor (InXAIYGa1-X-YN, 0<=X, 0<=Y, X+Y<=1) as mentioned above although it is green LED and blue LED which are the characteristics of the present invention. As for the light emitting chip, it is preferable that it is terrorism structure in the double which makes InGaN an active layer and makes GaN or GaAIN a cladding layer. Because, the light emitting chip which makes InGaN an active layer can change the luminescent color even to a green region from the region of the wavelength of 380 nm – 580 nm, and purple—blue by making composition ratio (In/Ga) to Ga of In or less into 0.4. Since a gallium nitride system compound semiconductor is a transited [directly] type semiconductor, when it considers it as a light emitting chip, it can realize LED with high luminous intensity. That in which both have 1 cds or more is specifically used for the degree of luminescent light of green LED used for the LED display of the present invention, and blue LED, and, as for optical power, it is preferable to use a thing of 0.5 mW or more.

[0011]As for the half angle of red, green, and blue LED, it is preferable to adjust to the range of **20 degrees - **70 degrees to the center of a LED lens. It is because luminosity will become low if larger [if smaller than 20 degrees, the directivity of a display will become strong and a white balance will not be stabilized easily, and] than 70 degrees.

[0012]Although there are various methods in adjusting the half angle of each LED, when green LED and blue LED are used as the light emitting chip which consists of a gallium nitride system compound semiconductor, the height of the surface of a red LED chip is equalized with the height of a gallium nitride system compound semiconductor light emitting chip, and a half angle is adjusted. Because, the thickness of a gallium nitride system compound semiconductor light emitting chip is only 150 micrometers or less, and the GaAlAs which is a light emitting chip of red LED is not less than 300 micrometers in the thickness to it. The directional characteristics of three kinds of LED can be doubled by using in many cases what has the same shape of lead frame and lens shape for LED used on a display, and doubling the height of the surface of the chip of red LED with green and blue LED, if these are the same. This is a characteristic effect at the time of the thickness of a light emitting chip using a gallium nitride system compound semiconductor light emitting chip of 150 micrometers or less for green LED and blue LED, and using the light emitting chip consisting of material which is different from a gallium nitride system compound semiconductor in a top thicker than 150 micrometers for red LED.

[Function]By using as the identical material the light emitting chip which constitutes green LED and blue LED, the LED display of the present invention can do lens shape of the resin etc. which seal the size of a light emitting chip, the form of the leadframe which places a light

emitting chip, a light emitting chip, and a leadframe as it is the same. Since this green and blue LED are the same, the half angle of a mold lens is also the same, and when a display is constituted, it can do that it is easy to stabilize a white balance.

[0014]A gallium nitride system compound semiconductor is also a transited [directly] type semiconductor, and, as for LED using this, the luminous intensity of 1 cds or more and 0.5 mW or more of optical power have both. therefore, by using such LED as a green component and a blue component, rather than the display constituted from a conventional material, the number of LED is lessened, and is boiled markedly, and what has high luminosity can be realized. [0015]What is necessary is to adjust only red LED for adjusting the half angle of a mold lens, since green LED and blue LED are the same. A half angle can be adjusted by equalizing the distance of the surface of the light emitting chip which is in red LED for that purpose, and the peak of a mold lens with green LED and blue LED. Thereby, all of the half angle of 3 colors will gather, and it becomes possible to obtain the stable white balance. [0016]

[Working example]Fig.1 is a plan view showing one working example of the full color LED display of an application concerned. this shows the display screen — red LED (R), green LED (G), and blue LED (B) — one piece is arranged in the shape of [each] delta, and forms stroke matter, respectively. Fig.2 is a schematic cross section showing the structure of the stroke matter of the display of Fig.1, and the leadframe 2 of red LED (R), and green LED (G) and blue LED (B) is electrically connected to the surface of the substrate 1 by which pattern wiring was carried out, respectively. The leadframe in particular of blue LED is not illustrating.

[0017]Red LED (R) has the red light chip 3R of 100 micrometers in thickness, and a 350-micrometer angle which laminated GaAlAs on a GaAs substrate.

The mold of the leadframe 2R on which the light emitting chip 3R was placed is carried out to the shape of a lens with a transparent epoxy resin, and it forms the mold lens 4.

By grinding a GaAs substrate, the thickness of the red light chip 3R is adjusted so that it may become the same as that of the thickness of a green emission chip and a blue light chip. As for the mold lens 4, the mold of the half angle of the directional characteristics is carried out using B, G, and a mold that will R all be **30 degrees from a lens center. The luminous intensity of this red LED (R) has 2 cds and a luminous wavelength of 640 nm in 10 mA and 2V.

[0018]Next, green LED (G) has the green emission chip 3G of 100 micrometers in thickness, and a 350-micrometer angle which laminated a gallium nitride system compound semiconductor on silicon on sapphire.

A green emission chip makes InGaN an active layer, and let it be terrorism structure to double which makes GaAlN a cladding layer.

This green emission chip 3G is also placed on the leadframe 2R and the leadframe 2G of identical shape, and the mold is carried out with the same lens shape as red LED (R) with the same transparent epoxy resin 4. The luminous intensity of this green LED (G) has 4 cds and a luminous wavelength of 420 nm in 20 mA and 3.6V.

[0019]Next, blue LED (B) only differs in composition of InGaN of the green emission chip 3G and an active layer, it is the same in thickness and all sizes, and the luminous intensity of blue LED has 1 cd and a luminous wavelength of 360 nm in 20 mA and 3.6V.

[0020]By grinding the substrate of the red light chip 3R of the aforementioned red LED (R), in order to adjust directional characteristics, Distance (Ir) from the surface of the chip to the peak of the mold lens 4R is made substantially equal to the distance (Ig) from the surface of the green emission chip 3G of above—mentioned green LED (G) to the peak of the mold lens 4G. It cannot be overemphasized that green LED (G) and blue LED (B) are the same.

[0021] The plan view showing the form of the red light chip 3R seen from the mold lens 4R side and the plan view showing the form of the green emission chip 3G similarly seen from the mold lens 4G side are compared and shown in Fig.3. The slash part of Fig.3 shows the light-emitting part of the light emitting chip. It cannot be overemphasized that the form of the green emission chip 3G and the blue light chip 3B is the same. As mentioned above, since the green emission chip 3G is using sapphire as the substrate, as shown in this figure, positive and negative two

electrodes are formed from the same surface side. The chip central part is made to emit light by arranging the position of the ball at the time of furthermore carrying out the wire bond of the two electrodes on a diagonal line. On the other hand, it arranges the ball on a corner by the present invention that a ball of a red light chip is usually provided by central part of the rectangular chip.

Therefore, a light-emitting part of the red light chip 3R is carried out in the center.

Thus, it becomes possible by doubling the position of the light-emitting part of the red light chip 3R with the green emission chip 3G and the blue light chip 3B to improve the directivity of a LED display further.

[0022]In delta arrangement, LED of R, G, and B every one piece each as mentioned above the pixel carried out, When the full color LED display of the present invention was obtained by arranging the length 480 and width every 640, the luminosity was tens times bright compared with what uses the conventional green LED and blue LED, and usable enough outdoors. Furthermore, the white balance was adjusted very well and this display had the white of the same color tone in the angle of **30 degrees from the display transverse plane. [0023]

[Effect of the Invention]according to [as described above] the present invention — red LED, green LED, and each blue LED — since realization of a full color display is attained by every [a piece], stroke matter can be made small compared with the conventional display, and resolution is markedly alike and improves. Also in directional characteristics, since green LED and blue LED are identical materials, what is necessary is to adjust only red LED, when 3 colors is put in order on a display, and maintenance is also dramatically easy.

[0024] Further again the chip size of the light emitting chip of the conventional red LED as a secondary effect, Usually, by below a 200-micrometer angle making the red light chip size into the 350-micrometer angle of the same size as a green emission chip and a blue light chip by the present invention to very small one, Directional characteristics can be made further easy to double, and the life of the red LED itself becomes good and the reliability of a display improves.

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DESCRIPTION OF DRAWINGS

[Brief Description of the Drawings]

[Drawing 1] The plan view showing one working example of the full color LED display of the present invention.

<u>Drawing 2</u>The schematic cross section showing the structure of the stroke matter of the display of <u>Fig.1</u>.

<u>IDrawing 3</u>The plan view comparing and showing the form of the red light chip 3R seen from the mold lens side, and the form of the green emission chip 3G.

[Explanations of letters or numerals]

- 1 Substrate
- 2 Leadframe
- 3 Light emitting chip
- 4 Mold lens

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審査請求 未請求 請求項の数3 OL (全 4 頁)

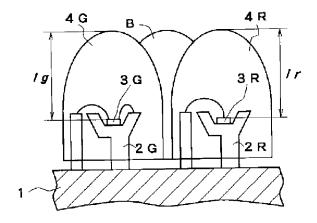
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(54) 【発明の名称】 フルカラーLEDディスプレイ

(57)【要約】

【目的】 光度の高いLEDを使用して、高輝度で消費電力の少ないディスプレイを実現すると共に、さらに指向特性を容易に調整できるLEDを組み合わせることにより安定したホワイトバランスが得られるフルカラーLEDディスプレイを実現する。

【構成】 フルカラーLEDディスプレイで、緑色LEDランプ(G)および青色LEDランプ(B)は窒化ガリウム系化合物半導体よりなる発光チップを備えており、赤色LEDランプ(R)の指向特性の半値角が、緑色LEDランプおよび青色LEDランプの指向特性の半値角と同一となるように調整されている。



【特許請求の範囲】

【請求項1】 一画素を構成する赤色LEDランプと、 緑色LEDランプと、青色LEDランプとが、同一基板 上に接続されて成るフルカラーLEDディスプレイにお いて、前記緑色LEDランプおよび青色LEDランプは 窒化ガリウム系化合物半導体よりなる発光チップを備え ることを特徴とするフルカラーLEDディスプレイ。

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【請求項2】 前記赤色LEDランプの指向特性の半値 角が、緑色LEDランプおよび青色LEDランプの指向 特性の半値角と同一であることを特徴とする請求項1記 載のフルカラーLEDディスプレイ。

【請求項3】 前記赤色LEDランプ、緑色LEDラン プ、および青色LEDランプは発光チップが樹脂または ガラスでレンズ状にモールドされて成り、前記赤色LE Dランプのモールドレンズの頂点と、その赤色 L E Dラ ンプ内に備えられた発光チップの表面との距離が、前記 緑色LEDランプおよび青色LEDランプのモールドレ ンズの頂点と、その緑色LEDランプおよび青色LED ランプ内に備えられた発光チップの表面との距離にほぼ 特性の半値角が調整されていることを特徴とする請求項 2に記載のフルカラーLEDディスプレイ。

【発明の詳細な説明】

[0001]

【産業上の利用分野】本発明は、発光チップが樹脂、ガ ラス等でモールドされたLEDランプ(以下、LEDと いう)を同一基板上に複数接続して成るLEDディスプ レイに関し、特に、一画素を構成する赤色LEDと緑色 LEDと青色LEDとが同一基板上に接続されて成るフ ルカラーLEDディスプレイに関する。

[0002]

【従来の技術】LEDディスプレイには、リードフレー ム上に設置された発光チップが樹脂、ガラス等で例えば レンズ形状に封止されたLEDを、基板上に規則的に並 べられたものが知られている。現在LEDディスプレイ には、赤色LEDと緑色LEDを用いたマルチカラーの ものがすでに実用化されているが、フルカラーディスプ レイは未だ試作段階で実用化には至っていない。

【0003】現在試作されているフルカラーLEDディ スプレイは、発光チップの材料として、赤色LEDにG 40 aAIAs、GaAsP、緑色LEDにGaP、青色L EDにSiCが用いられている。しかし、赤色LEDの 光度に比べて、緑色LEDおよび青色LEDの光度が低 く、特に青色LEDは1/100以下しかないため、高 輝度のディスプレイが得られないという欠点があった。

【0004】この欠点を補う目的で、前記ディスプレイ は一画素中の赤色LEDの数に対して、緑色LED、青 色LEDの数を増やしているが、一画素中のLEDの数 が増えると、ディスプレイ全体の解像度が悪くなり、し かも消費電力が大きいという欠点がある。さらにまた白 50

色を表示する際、各発光色のLEDの光度比、いわゆる ホワイトバランスが、3種類の発光チップからなるLE Dを使用していることにより、各LEDの指向特性が異 なるため、一定しないという欠点があった。

[0005]

【発明が解決しようとする課題】本発明は上記欠点を解 決するために成されたものであって、その目的とすると ころは光度の高いLEDを使用して、高輝度で消費電力 の少ないディスプレイを実現すると共に、さらに指向特 10 性を容易に調整できるLEDを組み合わせることにより 安定したホワイトバランスが得られるフルカラーLED ディスプレイを実現することにある。

[0006]

【課題を解決するための手段】フルカラーLEDディス プレイの輝度を向上させるには、まず光度の高い緑色し EDと青色LEDを用いる必要がある。さらに、安定し たホワイトバランスを得るためには指向特性ができるだ け一致したLEDを一画素に数少なく並べる必要があ る。我々はその要求を同時に満足できる青色LEDと緑 等しくなるように調整されて、赤色LEDランプの指向 20 色LEDとを新たに見いだし、上記問題を解決するに至 った。即ち本発明のフルカラーLEDディスプレイは、 一画素を構成する赤色LEDと、緑色LEDと、青色L EDとが、同一基板上に接続されて成るフルカラーLE Dディスプレイにおいて、前記緑色LEDおよび青色L EDは窒化ガリウム系化合物半導体よりなる発光チップ を備えることを特徴とする。

> 【0007】さらに、本発明の第2は、赤色LEDの指 向特性の半値角が、緑色LEDおよび青色LEDの指向 特性の半値角と同一であることを特徴とする。つまり、 30 青色LEDと緑色LED同一材料であるので、従来の赤 色LEDの指向特性を緑、および青色LEDに調整す る。

【0008】また本発明の第3は、赤色LED、緑色L ED、および青色LEDは発光チップが樹脂またはガラ スでレンズ状にモールドされて成り、前記赤色LEDラ ンプのモールドレンズの頂点と、その赤色LEDランプ 内に備えられた発光チップの表面との距離が、前記緑色 LEDランプおよび青色LEDランプのモールドレンズ の頂点と、その緑色LEDランプおよび青色LEDラン プ内に備えられた発光チップの表面との距離にほぼ等し くなるように調整されて、赤色LEDランプの指向特性 の半値角が調整されていることを特徴とする。なお緑色 LEDと青色LEDとは窒化ガリウム系化合物半導体よ りなる発光チップを備えていることはいうまでもない。 【0009】本発明のLEDディスプレイにおいて使用 する赤色LEDには、GaAIAs、GaAsP等、従 来の発光チップの材料を備えるLEDを使用でき、それ SLEDは発光光度1cd以上、発光出力は1mW以上 を有している。

【0010】次に本発明の特徴である緑色LEDおよび

青色LEDであるが、これらは前記のように窒化ガリウ ム系化合物半導体(In XA | YG a 1- X-YN、0≦ X、0 ≦ Y、X+Y≦ 1)よりなる発光チップを備えている。その 発光チップは、InGaNを活性層にし、GaNまたは GaAINをクラッド層とするダブルへテロ構造である ことが好ましい。なぜなら、InGaNを活性層とする 発光チップは、InのGaに対する組成比(In/G a)を0.4以下とすることにより、波長380nm~ 580 nmと青紫の領域から緑色の領域にまで発光色を 変化させることができる。また、窒化ガリウム系化合物 半導体は直接遷移型の半導体であるため、発光チップと した際に光度の高いLEDを実現できる。具体的には、 本発明のLEDディスプレイに使用する緑色LED、お よび青色LEDの発光光度は、両者とも1cd以上を有 するものを使用し、光出力は0.5mW以上のものを使 用することが好ましい。

【0011】また赤色、緑色、青色LEDの半値角はL

EDレンズの中心に対し± 20°~±70°の範囲に調 整することが好ましい。20°より小さいとディスプレ イの指向性が強くなりホワイトパランスが安定しにく く、70°よりも大きいと輝度が低くなるからである。 【0012】各LEDの半値角を調整するには種々の方 法があるが、緑色LED、および青色LEDを窒化ガリ ウム系化合物半導体よりなる発光チップとした際、赤色 LEDチップの表面の高さを窒化ガリウム系化合物半導 体発光チップの高さと同一にして半値角を調整する。な ぜなら、窒化ガリウム系化合物半導体発光チップの厚さ は150μ m以下しかなく、それに対し、赤色 L E D の 発光チップであるGαAIAs等はその厚さが300μ m以上ある。ディスプレイで使用されるLEDにはリー ドフレーム形状、レンズ形状が同一のものが使用される ことが多く、これらが同一であれば、赤色LEDのチッ プの表面の高さを、緑色、青色LEDに合わせてやるこ とにより、3種類のLEDの指向特性を合わせることが できる。これは発光チップの厚さが150μ m以下の窒 化ガリウム系化合物半導体発光チップを緑色LEDおよ び青色 L E D に使用し、150μ m より厚い上に窒化ガ リウム系化合物半導体と異なる材料よりなる発光チップ を赤色LEDに使用した際の特有の効果である。

[0013]

【作用】本発明のLEDディスプレイは、緑色LED、 青色LEDを構成する発光チップを同一材料としている ことにより、発光チップの大きさ、発光チップを載置す るリードフレームの形状、発光チップおよびリードフレ ームを封止する樹脂等のレンズ形状を同一とできる。こ の緑色と青色のLEDが同一であるから、モールドレン ズの半値角も同一であり、ディスプレイを構成した際に ホワイトパランスを安定させやすくできる。

【0014】また窒化ガリウム系化合物半導体は直接遷 移型の半導体でもあり、これを用いたLEDは両者とも 50 3Gと活性層のInGaNの組成が異なるだけで、厚

光度1cd以上、光出力0.5mW以上ある。従ってこ れらのLEDを緑色成分、および青色成分として用いる ことにより、従来の材料で構成したディスプレイより も、LEDの数を少なくして格段に輝度の高いものを実 現できる。

【0015】さらに、緑色LEDおよび青色LEDが同 ーであるので、モールドレンズの半値角を調整するには 赤色LEDのみを調整してやればよい。そのためには赤 色LEDにある発光チップの表面と、モールドレンズの 10 頂点との距離を緑色LED、および青色LEDと同一に することによって半値角を調整できる。これにより、三 色の半値角が全て揃うことになり、安定したホワイトバ ランスを得ることが可能となる。

[0016]

【実施例】図1は本願のフルカラーLEDディスプレイ の一実施例を示す平面図である。これはディスプレイ画 面を示しており、赤色LED(R)、緑色LED (G)、青色LED(B)それぞれ1個づつが∆状に配 列されて一画素を形成している。また図 2 は図 1 のディ 20 スプレイの一画素の構造を示す模式断面図であり、パタ 一ン配線された基板1の表面に、赤色LED(R)と、 緑色LED(G)と、青色LED(B)のリードフレー ム2がそれぞれ電気的に接続されている。なお、青色L EDのリードフレームは特に図示していない。

【0017】赤色LED(R)は、GaAs基板の上に G a A IAsを積層した厚さ100μ m 、350μ m 角 の赤色発光チップ3Rを有しており、その発光チップ3 Rが載置されたリードフレーム2Rは透明なエポキシ樹 脂でレンズ状にモールドされてモールドレンズ 4 を形成 30 している。なお赤色発光チップ3尺の厚さはGaAs基 板を研磨することにより、緑色発光チップ、および青色 発光チップの厚さと同一になるように調整してある。ま たモールドレンズ4は、その指向特性の半値角がB、 G、R全てレンズ中心から±30°になるような型を用 いてモールドされている。この赤色LED(R)の光度 は10mA、2 Vにおいて2 c d、発光波長6 4 0 n m を有している。

【0018】次に緑色LED(G)は、サファイア基板 の上に窒化ガリウム系化合物半導体を積層した厚さ 10 40 0 µ m、350 µ m角の緑色発光チップ3Gを有してお り、緑色発光チップはInGaNを活性層とし、GaA INをクラッド層とするダブルヘテロ構造とされてい る。この緑色発光チップ3Gもリードフレーム2Rと同 一形状のリードフレーム2G上に載置され、同じく透明 なエポキシ樹脂4で赤色LED(R)と同一のレンズ形 状でモールドされている。この緑色LED(G)の光度 は20mA、3.6 Vにおいて4 c d、発光波長420 nmを有している。

【0019】次に青色LED(B)は、緑色発光チップ

さ、サイズ全て同一であり、青色LEDの光度は20mA、3.6Vにおいて1cd、発光波長360nmを有している。

【0020】さらに、指向特性を調整するために、前記赤色LED(R)の赤色発光チップ3Rの基板を研磨することにより、そのチップの表面から、モールドレンズ4Rの頂点迄の距離(Ir)を、前記緑色LED(G)の緑色発光チップ3Gの表面から、モールドレンズ4Gの頂点迄の距離(Ig)とほぼ等しくしている。なお、緑色LED(G)と青色LED(B)とは同一であることはいうまでもない。

【0021】さらに、図3にモールドレンズ4R側から 見た赤色発光チップ3Rの形状を示す平面図と、同じく モールドレンズ4G側から見た緑色発光チップ3Gの形 状を示す平面図を比較して示す。図3の斜線部は発光チ ップの発光部を示している。なお緑色発光チップ3Gと 青色発光チップ3Bの形状は同一であることはいうまで もない。前記のように緑色発光チップ3Gはサファイア を基板としているため、この図に示すように同一面側か ら正、負の両電極が形成される。さらに両電極をワイヤ ーボンドする際のボールの位置を対角線上に配置するこ とにより、チップ中央部を発光させている。一方赤色発 光チップのボールは通常は矩形チップの中央部に設けら れるのが、本発明においては隅部にそのボールを配する ことにより、赤色発光チップ3Rの発光部を中央にして いる。このように、赤色発光チップ3Rの発光部の位置 を緑色発光チップ3G、青色発光チップ3Bと合わせる ことにより、さらにLEDディスプレイの指向性を高め ることが可能となる。

【0022】以上のようにして、R、G、BのLEDが 30 各一個づつ∆配列された画素を、縦480、横640づつ並べることにより本発明のフルカラーLEDディスプレイを得たところ、明るさは従来の緑色LED、および青色LEDを使用したものに比べて数十倍も明るく、十*

* 分屋外で使用可能であった。さらにこのディスプレイは ホワイトバランスが非常に良く調整され、ディスプレイ 正面から±30°の角度内において、同じ色調の白色を 有していた。

[0023]

【発明の効果】以上説明したように本発明によると、赤色LED、緑色LED、青色LEDそれぞれ一個づつでフルカラーディスプレイが実現可能となるので、一画素を従来のディスプレイに比べて小さくでき、解像度が格10 段に向上する。また指向特性においても、緑色LEDと青色LEDとが同一材料であるので、ディスプレイで3色並べたときに赤色LEDのみを調整すれば良く、非常にメインテナンスも楽である。

【0024】さらにまた、副次的な効果として、従来の赤色LEDの発光チップのチップサイズは、通常200μm角以下と非常に小さいのに対し、本発明では赤色発光チップの大きさを、緑色発光チップおよび青色発光チップと同じ大きさの350μm角としていることにより、指向特性をさらに合わせやすくできると共に、赤色20 LED自体の寿命が良くなり、ディスプレイの信頼性が向上する。

【図面の簡単な説明】

【図1】 本発明のフルカラーLEDディスプレイの一 実施例を示す平面図。

【図2】 図1のディスプレイの一画素の構造を示す模式断面図。

【図3】 モールドレンズ側から見た赤色発光チップ3 Rの形状と、緑色発光チップ3Gの形状を比較して示す 平面図。

30 【符号の説明】

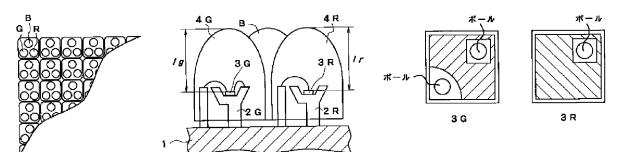
1・・・基板

2・・・・リードフレーム

3・・・・発光チップ

4・・・・モールドレンズ

【図1】 【図2】 【図3】



Searching PAJ 1/1 ページ

PATENT ABSTRACTS OF JAPAN

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KISHI AKITO

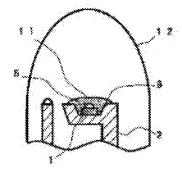
NAKAMURA SHUJI

(54) LIGHT EMITTING DIODE

(57)Abstract:

PURPOSE: To provide a LED capable of avoiding color mixture even if the LEDs in different wavelength are closely arranged when a fluorescent pigment is used while the focussing of converted and emitted light is enhanced for increasing the brightness of the LED when a wavelength conversion material is contained in a resin of LED for wavelength conversion of light emitting chip.

CONSTITUTION: A sealing resin of LED comprises the first resin 11 filling up the inside of a cup 3 and the second resin 12 encircling the first resin 11 while the first resin 11 contains the fluorescent material converting the light emitting wavelength of a light emitting chip to the other wavelength or a wavelength converting material 5 such as a filter material, etc., partly absorbing the light emitting wavelength thereby increasing the brightness, focussing efficiency due to the wavelength conversion light reflected on the cup 3.



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CLAIMS

[Claim(s)]

[Claim 1]A light emitting diode which is provided with the following and characterized by a fluorescent substance which converts a luminous wavelength of a light emitting chip to other wavelength, or a filter substance which absorbs a part of luminous wavelength of a light emitting chip containing to said first resin.

First resin in which it is a light emitting diode which seals the whole light emitting device by which a light emitting chip was placed on a bottom part of a cup which reflects luminescence of a light emitting chip in the luminescence observation surface side by resin, and the aforementioned resin is filled up with the aforementioned inside of a cup. Second resin which surrounds the first resin.

[Claim 2] The light emitting diode according to claim 1 which a substance contained in resin of said first resin is a fluorescent substance, and is characterized by filling up with said first resin so that it may become lower than the level surface of an edge of the aforementioned cup.

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DETAILED DESCRIPTION

[Detailed Description of the Invention] [0001]

[Industrial Application] The present invention is converted to wavelength which is applied to a light emitting diode (henceforth LED), especially is different in the luminous wavelength of a light emitting chip, or relates to LED which absorbs a part of luminescence of a light emitting chip. [0002]

[Description of the Prior Art]Fig.2 is a schematic cross section showing one structure of the conventional LED, and the cup provided in order to reflect in a leadframe the light emitting chip in which 1 consists of compound semiconductors, and 2 and for 3 to reflect luminescence of a light emitting chip in the luminescence observation surface side, and 4 are resin which seals the whole light emitting device. Usually, highly transparent resin is chosen in order for the resin 4 to emit luminescence of a light emitting chip efficiently into the air, but. It is the purpose of converting the luminescent color of the light emitting chip to others, or the fluorescent substance which converts luminescence of a light emitting chip to other wavelength, or the filter substance 5 (henceforth the wavelength conversion material 5) which absorbs a part of luminous wavelength of a luminous wavelength may be mixed into the resin 4 in order to correct a color. In this case, usually it is mixed so that the wavelength conversion material 5 may be uniformly distributed to the resin 4.

[Problem to be solved by the invention] However, when the wavelength conversion material 5 is uniformly distributed in the resin 4 for the above—mentioned purpose, as shown in this figure, the light by which wavelength changing was carried out, or the lights into which unnecessary wavelength was cut are scattered about in all directions in the resin 4, and there is a problem that condensing worsens. The arrow of Fig.2 is a figure showing typically signs that the light of a light emitting chip strikes upon the wavelength conversion material 5, and the lights by which wavelength changing was carried out are scattered about. That is, when the lights by which wavelength changing was carried out are scattered about, the light volume by the side of a luminescence observation surface decreases, and luminosity becomes low.

[0004]When the wavelength conversion material 5 is limited to a fluorescent substance, it approaches and LED of the different luminescent color is installed as a new problem, there is a problem of excessive luminescence of the fluorescent substance by other LED luminescence. For example, green LED which contains the fluorescent substance in which green emission is obtained with a blue light chip, If green LED is switched off and blue LED is turned on when it approaches horizontally on the same flat surface and the blue LED which consists only of a mere blue light chip is put in order, by the light which leaks and comes out of blue LED, and the light got blocked and scattered about, The fluorescent substance of green LED is excited, it will be in the state where green LED which went out lit up, and the mixed colors of both LED will occur.

[0005] Therefore, when the place made into the object of this invention makes resin of LED contain a wavelength conversion material and wavelength changing of a light emitting chip is performed, When a fluorescent pigment is used [and] for the purpose of improving condensing

of luminescence converted first and raising the luminosity of LED, it sets it as another purpose to provide LED to which mixed colors do not happen even if it approaches and installs LED from which wavelength differs.

[0006]

[Means for solving problem] The first resin in which LED of the present invention is LED which seals the whole light emitting device by which the light emitting chip was placed on the bottom part of the cup which reflects luminescence of a light emitting chip in the luminescence observation surface side by resin, and the aforementioned resin is filled up with the aforementioned inside of a cup, It consists of second resin which surrounds the first resin, and the fluorescent substance which converts the luminous wavelength of a light emitting chip to other wavelength, or the filter substance which absorbs a part of luminous wavelength of a light emitting chip contains to the above–mentioned first resin.

[0007]

[Function] In first resin for luminescence of a light emitting chip, it converts to desired wavelength or LED of the present invention absorbs a part of unnecessary wavelength. Thus, although the lights by which wavelength changing was carried out are scattered about in all directions, it is reflected by the cup and most scattered lights are condensed at the luminescence observation surface side, that is, since the cup of an application concerned reflects the light by which wavelength changing was carried out with the wavelength conversion material and can be condensed within first resin, the condensing efficiency of converted light is markedly alike, and improves.

[0008]If it is filled up with first resin containing a fluorescent substance so that it may become lower than the level surface of the edge of a cup when a wavelength conversion material is used as a fluorescent substance, the mixed colors between LED can be prevented by interrupting an incident light on the edge of a cup from the exterior, and not reaching even a fluorescent substance. If it says simply, when keeping the first resin that makes the cup depth deep and contains a fluorescent substance from overflowing a cup, the excitation source of a fluorescent substance can be restricted only to the luminous wavelength of a light emitting chip. [0009]

[Working example] Fig.1 is a schematic cross section showing the structure of LED of one working example of an application concerned, and is taken as the structure which sealed the whole light emitting device which placed like Fig.2 the light emitting chip 1 which consists of compound semiconductors on the leadframe 2 which has the cup 3 by resin. However, a different place from Fig.2, sealing resin consists of the first resin 11 filled up with cup 3 inside, and the second resin 12 which surrounds the first resin, to the first resin 11, it converts to other wavelength or the wavelength conversion material 5 which is absorbed in part and to convert contains the luminous wavelength of the light emitting chip.

[0010]An identical material may be sufficient as the material of the first resin 11 and second resin, for example, it constitutes both from an epoxy resin, and should just make only first resin contain the fluorescent substance 5 in LED of the present invention. It cannot be overemphasized that it may be the same as that of the resin 4 of Fig.2. If the wavelength conversion material 5 is a fluorescent substance, fluorescent dye, a fluorescent pigment, a fluorescent substance, etc., As long as it is the material which can convert the luminous wavelength of a light emitting chip to other wavelength, what kind of thing may be used, If it is a filter substance, the unnecessary wavelength of luminescence of a light emitting chip will be absorbed, the material which receives color purity is chosen, and the inorganic and organic filter paints which usually have the same color as the luminescent color of a light emitting chip are used.

[0011]In order to obtain LED of such a structure, for example in an LED manufacturing process, pre dip the inside of a cup which placed the light emitting chip 1 previously by resin in order to usually drive out the air of the cup 3, but. It can obtain by making the first resin 11 contain the wavelength conversion material 5, when pre dipping, and sealing by the second resin 12, after the first resin 11 containing the wavelength conversion material 5 hardens. The first resin 11

that includes the wavelength conversion material 5 previously may be injected into cup 3 inside. thus, the inside of 3 of a cup is filled up with the first resin 11 containing the wavelength conversion material 5, most lights by which wavelength changing was carried out by the first resin 11 return in the reflector of the cup 3, and by reflecting in a luminescence observation surface, condensing of LED is markedly alike and improves.

[0012] The first resin 11 and the second resin 12 are used as a different material, and the external quantum efficiency of the light by which wavelength changing was carried out improves by setting up to make small the refractive index of the first resin 11 and the second resin 12 in order, and become close to the refractive index 1 of air. It cannot be overemphasized that a material smaller than the refractive index of the light emitting chip 1 is selected into the material of the first resin 11 in this case.

[0013]Fig.3 and Fig.4 are the schematic cross sections expanding and showing the portion of the cup 3 of LED concerning other working examples of the present invention, and the state with which Fig.3 became convex, the surface of the first resin 11 hardened it, and the cup 3 was filled up, and the state where Fig.4 became a concave conversely, and it hardened and filled up are shown. Since it fills up so that the first resin 11 containing the fluorescent substance may become lower than the level surface of the edge of the cup 3 and the cup 3 is not overflowed in which state when the wavelength conversion material 5 is used as a fluorescent substance, The extraneous light which excites a fluorescent substance by the edge of the cup 3 can be intercepted, and the mixed colors of LED can be prevented.

[Effect of the Invention] As described above, since converted light reflects inside a cup since LED of the present invention has filled up the inside of a cup with first resin containing a wavelength conversion material, and it is condensed, luminosity improves more than double. When making first resin contain a fluorescent pigment, performing wavelength changing, making the cup depth deep and keeping first resin from overflowing a cup, When the mixed colors between LED do not occur, for example, a planar display is realized by LED, an image with dramatically sufficient resolution can be acquired.

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DESCRIPTION OF DRAWINGS

[Brief Description of the Drawings]

[Drawing 1]The schematic cross section showing the structure of 1LED of the present invention.

[Drawing 2] The schematic cross section showing the structure of the conventional LED.

[Drawing 3] The schematic cross section expanding and showing the portion of the cup 3 of LED concerning other working examples of the present invention.

Drawing 4 The schematic cross section expanding and showing the portion of Kapp 3 of LED concerning other working examples of the present invention.

[Explanations of letters or numerals]

- 1 ... Light emitting chip 2 ... Leadframe
- 3 ... Kapp 5 ... Wavelength conversion material
- 11 ... First resin 12 ... Second resin

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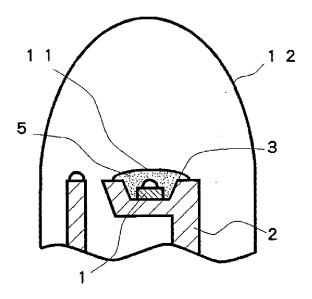
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(54) 【発明の名称】 発光ダイオード

(57)【要約】

【目的】 LEDの樹脂に波長変換材料を含有させて発 光チップの波長変換を行う際、まず変換された発光の集 光をよくしてLEDの輝度を高めることを目的とし、ま た蛍光顔料を使用した際、波長の異なるLEDを近接し て設置しても混色の起こらないLEDを提供する。

【構成】 LEDの封止樹脂が、カップ3内部を充填する第一の樹脂11と、その第一の樹脂を包囲する第二の樹脂12とからなり、第一の樹脂11には発光チップの発光波長を他の波長に変換する蛍光物質、または発光波長を一部吸収するフィルター物質等の波長変換材料5が含有されていることにより、波長変換光がカップ3に反射されるため輝度、集光効率が向上する。



【特許請求の範囲】

【請求項1】 発光チップの発光を発光観測面側に反射 するカップの底部に発光チップが載置された発光素子全 体を、樹脂で封止してなる発光ダイオードであって、前 記樹脂は前記カップ内部を充填する第一の樹脂と、その 第一の樹脂を包囲する第二の樹脂とからなり、前記第一 の樹脂には発光チップの発光波長を他の波長に変換する 蛍光物質、または発光チップの発光波長を一部吸収する フィルター物質が含有されていることを特徴とする発光 ダイオード。

【請求項2】 前記第一の樹脂の樹脂に含まれる物質が 蛍光物質であって、前記第一の樹脂は前記カップの縁部 の水平面よりも低くなるように充填されていることを特 徴とする請求項1に記載の発光ダイオード。

【発明の詳細な説明】

[0001]

【産業上の利用分野】本発明は発光ダイオード(以下し EDという。)に係り、特に発光チップの発光波長を異 なる波長に変換する、または発光チップの発光を一部吸 収するLEDに関する。

[0002]

【従来の技術】図2は従来のLEDの一構造を示す模式 断面図であり、1は化合物半導体よりなる発光チップ、 2はリードフレーム、3は発光チップの発光を発光観測 面側に反射させる目的で設けられたカップ、4は発光素 子全体を封止する樹脂である。通常、樹脂4は発光チッ プの発光を空気中に効率よく放出する目的で透明度の高 い樹脂が選択されるが、他にその発光チップの発光色を 変換する目的で、あるいは色を補正する目的で、その樹 脂4の中に発光チップの発光を他の波長に変換する蛍光 30 物質、または発光波長の発光波長を一部吸収するフィル ター物質5(以下、波長変換材料5という。)が混入さ れる場合がある。この場合、波長変換材料5は樹脂4に 均一に分散するように混入されるのが通常である。

[0003]

【発明が解決しようとする課題】しかしながら、上記の 目的で波長変換材料5を樹脂4中に均一に分散させる と、この図に示すように、波長変換された光、または不 要な波長がカットされた光は樹脂4中で四方八方に散乱 してしまい、集光が悪くなるという問題がある。図2の 40 蛍光物質の励起源を発光チップの発光波長のみに制限で 矢印は発光チップの光が波長変換材料 5 にあたり、波長 変換された光が散乱する様子を模式的に示した図であ る。つまり、波長変換された光が散乱されることによ り、発光観測面側の光量が減少して輝度が低くなるので ある。

【0004】また、波長変換材料5を蛍光物質に限定し た場合、新たな問題点として、異なる発光色のLEDを 接近して設置した際に、他のLED発光による蛍光物質 のよけいな発光の問題がある。例えば、青色発光チップ で緑色発光が得られる蛍光物質を含む緑色LEDと、単 50 には発光チップの発光波長を他の波長に変換、または一

なる青色発光チップのみからなる青色LEDとを同一平 面上に水平に近接して並べた場合、緑色LEDを消灯し

て、青色LEDを点灯すると、青色LEDから洩れ出る 光、つまり散乱する光により、緑色LEDの蛍光物質が 励起され、消灯した緑色LEDがあたかも点灯したよう な状態となり、両LEDの混色が発生する。

2

【0005】従って本発明の目的とするところは、LE Dの樹脂に波長変換材料を含有させて発光チップの波長 変換を行う際、まず変換された発光の集光をよくしてL 10 EDの輝度を高めることを目的とし、また蛍光顔料を使 用した際、波長の異なるLEDを近接して設置しても混 色の起こらないLEDを提供することをもう一つの目的 とする。

[0006]

【課題を解決するための手段】本発明のLEDは、発光 チップの発光を発光観測面側に反射するカップの底部に 発光チップが載置された発光素子全体を、樹脂で封止し てなるLEDであって、前記樹脂は前記カップ内部を充 填する第一の樹脂と、その第一の樹脂を包囲する第二の 20 樹脂とからなり、前記第一の樹脂には発光チップの発光 波長を他の波長に変換する蛍光物質、または発光チップ の発光波長を一部吸収するフィルター物質が含有されて いることを特徴とする。

[0007]

【作用】本発明のLEDは、発光チップの発光を第一の 樹脂内において所望の波長に変換、または不要な波長を 一部吸収する。このようにして波長変換された光は四方 八方に散乱するが、散乱した光のほとんどはカップによ り反射され、発光観測面側に集光される。つまり本願の カップは第一の樹脂内で波長変換材料により波長変換さ れた光を反射して集光できるので、変換光の集光効率が 格段に向上する。

【0008】さらに、波長変換材料を蛍光物質とした場 合、蛍光物質を含む第一の樹脂をカップの縁部の水平面 よりも低くなるように充填すると、外部から入射する光 がカップの縁で遮られ、蛍光物質にまで到達しないこと により、LED間の混色を防止することができる。簡単 にいうと、カップ深さを深くして蛍光物質を含む第一の 樹脂がカップからはみ出さないようにすることにより、 きる。

[0009]

【実施例】図1は本願の一実施例のLEDの構造を示す 模式断面図であり、図2と同様に、カップ3を有するリ ードフレーム2上に化合物半導体よりなる発光チップ1 を載置した発光素子全体を、樹脂で封止した構造として いる。しかし、図2と異なるところは、封止樹脂がカッ プ3内部を充填する第一の樹脂11と、その第一の樹脂 を包囲する第二の樹脂12とからなり、第一の樹脂11

部吸収する変換する波長変換材料5が含有されている。 【0010】本発明のLEDにおいて、第一の樹脂11 と第二の樹脂の材料は同一材料でもよく、例えば両方と もエポキシ樹脂で構成し、第一の樹脂にのみ蛍光物質5 を含有させればよい。さらに、第二の樹脂12の材料は 図2の樹脂4と同一でもよいことはいうまでもない。ま た、波長変換材料5は蛍光物質であれば蛍光染料、蛍光 顔料、蛍光体等、発光チップの発光波長を他の波長に変 換できる材料であればどのようなものを使用してもよ く、またフィルター物質であれば発光チップの発光の不 10 要な波長を吸収し、色純度をよくする材料が選択され、 通常発光チップの発光色と同一色を有する無機、有機の フィルター顔料が使用される。

【0011】このような構造のLEDを得るには、例え ばLED製造工程において、通常カップ3の空気を追い 出す目的で、予め発光チップ 1を載置したカップ内部を 樹脂でプレディップするのであるが、プレディップする 際に第一の樹脂11に波長変換材料5を含有させてお き、波長変換材料5を含む第一の樹脂11が硬化した きる。また予め波長変換材料5を含む第一の樹脂11を カップ3内部に注入してもよい。このようにして、波長 変換材料5を含む第一の樹脂11をカップの3の内部に 充填し、第一の樹脂11で波長変換された光のほとんど がカップ3の反射鏡内に戻り、発光観測面に反射するこ とによりLEDの集光が格段に向上する。

【0012】また第一の樹脂11と第二の樹脂12とを 異なる材料とし、第一の樹脂11、第二の樹脂12の屈 折率を順に小さくして空気の屈折率1に近くなるように 設定することにより波長変換された光の外部量子効率が 30 1・・・発光チップ 向上する。なおこの場合、第一の樹脂11の材料には、 発光チップ 1の屈折率よりも小さい材料を選定すること は言うまでもない。

* 【0013】図3、および図4は本発明の他の実施例に 係るLEDのカップ3の部分を拡大して示す模式断面図 であり、図3は第一の樹脂11の表面が凸状になって硬 化してカップ3に充填された状態、図4は逆に凹状とな って硬化して充填された状態を示している。いずれの状 態においても、波長変換材料5を蛍光物質とした場合、 その蛍光物質を含む第一の樹脂11がカップ3の縁部の 水平面よりも低くなるように充填されており、カップ3 からはみ出していないので、カップ3の縁部により蛍光 物質を励起する外部光を遮断でき、LEDの混色を防止 することができる。

[0014]

【発明の効果】以上説明したように、本発明のLEDは カップ内部に波長変換材料を含有する第一の樹脂を充填 しているため、変換光がカップ内部で反射して集光され るため、輝度は倍以上に向上する。また、蛍光顔料を第 一の樹脂に含有させて波長変換を行う場合、カップ深さ を深くして、第一の樹脂がカップからはみ出さないよう にすることにより、LED間の混色が発生せず、例えば 後、第二の樹脂12で封止することにより得ることがで 20 LEDで平面ディスプレイを実現した際には、非常に解 像度のよい画像を得ることができる。

【図面の簡単な説明】

本発明の一LEDの構造を示す模式断面図。 【図1】

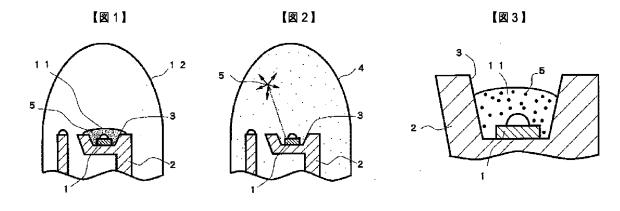
【図2】 従来のLEDの構造を示す模式断面図。

【図3】 本発明の他の実施例に係るLEDのカップ3 の部分を拡大して示す模式断面図。

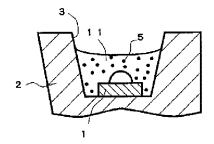
【図4】 本発明の他の実施例に係るLEDのカップ3 の部分を拡大して示す模式断面図。

【符号の説明】

2・・・リードフレーム 3・・・カップ 5・・・波長変換材料 11・・・第一の樹脂 12・・・第二の樹脂



【図4】



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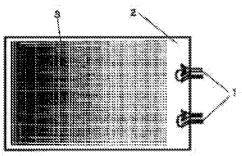
(21)Application number: 05-318276 (71)Applicant: NICHIA CHEM IND LTD (22)Date of filing: 17.12.1993 (72)Inventor: SHIMIZU YOSHINORI

(54) PLANAR LIGHT SOURCE

(57)Abstract:

PURPOSE: To provide a planar light source wherein a blue light emitting diode is used and white luminescence is feasible, and wherein uniform white luminescence can be observed.

CONSTITUTION: Light emitting diodes 1 are optically connected with the end of a transparent light transmitting plate 2. A fluorescent substance that emits light when energized by the luminescence of the blue light emitting diodes 1 and white powder that scatters fluorescence, are mixed. The resultant mixture is applied to either of the major surfaces of the light transmitting plate 2 to form a fluorescence scattering layer 3. The wavelength of the luminescence of the blue light emitting diodes 1 is changed through the fluorescence scattering layer 3.



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CLAIMS

[Claim(s)]

[Claim 1]A fluorescent substance which a blue light—emitting diode is optically connected to at least one place of an end face of a transparent light guide plate, is further excited by luminescence of the aforementioned blue light—emitting diode by either of the main surfaces of the aforementioned light guide plate, and shows a fluorescence, A source of sheet—like light which having the fluorescence scattering layer applied where white powder over which fluorescence is scattered is mixed, carrying out wavelength changing of the luminescence of the aforementioned blue light—emitting diode by the aforementioned fluorescence scattering layer, and observing from the main surface side of a light guide plate of the aforementioned fluorescence scattering layer and an opposite hand.

[Claim 2] The source of sheet-like light according to claim 1, wherein the main-light-emission wavelength of the aforementioned blue light-emitting diode is shorter than 500 nm and a radiant power output is not less than 500 microwatts.

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DETAILED DESCRIPTION

[Detailed Description of the Invention]

[0001]

[Industrial Application] The present invention relates to the source of sheet-like light which starts the light source of the surface state used for the backlight of a display, an illuminated operation switch, etc., especially can be preferably used as a backlight of a liquid crystal display.

[0002]

[Description of the Prior Art]EL and a cold cathode tube are used for the source of sheet-like light for the backlights of the liquid crystal display generally used for a notebook sized personal computer, a word processor, etc., for example. Itself of EL is a source of sheet-like light, a cold cathode tube is made into the source of sheet-like light using a diffusion board, and the luminescent color of the backlight of them is made white [most] now.

[0003]On the other hand, the light emitting diode (it is described as LED below.) is also used in part as a light source for backlights. However, by the former, when obtaining white light using LED, since there is only an about tens of microwatts radiant power output of blue LED, in order to realize white light using other red LED and green LED, there is a fault that a color change is large that it is hard to make the characteristic of these each color luminescence LED agree. Since those LED was recognized visually in the near position as a backlight even if trichromatic LED is gathered and it arranges in the same position geometrically on the same flat surface, it was impossible to have used a uniform white light source. Therefore, if large—sized, the actual condition is properly used with EL, and most backlights of white light using LED are not known by a cold cathode tube, small size — the medium size now at the white source of sheet—like light of the liquid crystal back light.

[0004]Although the trial which surrounds and carries out the convert colors of the circumference of a blue LED chip by resin containing a fluorescent substance also occurs partly as a light source of white light or monochrome, since a chip periphery is exposed to the beam of light of radiant intensity stronger than sunlight, degradation of a fluorescent substance poses a problem, especially it is remarkable at an organic fluorescent pigment. Organic dye of ionicity may cause an electrophoresis by direct—current electric field near the chip, and a color tone may change. Even if the conventional blue LED does not have sufficient output to carry out convert colors but carries out convert colors with a fluorescent substance, it is unusable. [0005]

[Problem to be solved by the invention] The place which was accomplished in order that the present invention might solve such a fault, and is made into the purpose, Realize the source of sheet—like light which can be used mainly as a backlight and in which white light is possible using LED, and. It is in providing the source of sheet—like light which can observe uniform white light, and is in providing the source of sheet—like light which can emit light for arbitrary colors other than white further, using the characteristic of LED excellent in reliability, and using for various operation switches etc.

0006

[Means for solving problem] The fluorescent substance which blue LED is optically connected to

at least one place of the end face of a transparent light guide plate, and the source of sheetlike light of the present invention is further excited by luminescence of the aforementioned blue light-emitting diode by either of the main surfaces of the aforementioned light guide plate, and shows a fluorescence. The fluorescence scattering layer applied where the white powder over which light is scattered is mixed. (the main surface by the side of a fluorescence scattering layer is hereafter called second main surface.) — it has, wavelength changing of a part of luminescence of the aforementioned blue light-emitting diode is carried out by the aforementioned fluorescence scattering layer, and it is observed from the main surface (main surface by the side of luminescence observation is called first main surface below.) side of the light guide plate of the aforementioned fluorescence scattering layer and an opposite hand [0007] Fig. 1 is the plan view which looked at the light guide plate 2 of the source of sheet-like light of the present invention from the fluorescence scattering layer 3 side. The light guide plate 2 consists of transparent materials, such as an acrylic and glass, and the light guide plate 2 and the blue LED 1 are optically connected by embedding the blue LED 1 under the end face of the light guide plate 2. that the blue LED 1 and the end face of the light guide plate 2 are connected optically in the present invention, Not to mention embedding the blue LED 1, as it says introducing the light of blue LED from the end face of the light guide plate 2, for example, is shown in this figure, if it says simply, It is realizable by adhering blue LED and leading luminescence of blue LED to the end face of the light guide plate 2 using an optical fiber etc. [0008] Next, the fluorescence scattering layer 3 is scattering the fluorescence in the light guide plate 2 with the white pigment at the same time it comes to apply the ink which prepared the fluorescent substance and the white pigment and it carries out wavelength changing of the luminescence of the blue LED 1 with a fluorescent substance so that a desired color can be observed. So that the aforementioned fluorescence scattering layer 3 may especially be made into dot form by Fig.1 and the surface brightness by the side of a first main surface may become fixed. It is considered as a pattern which reduces the area of the fluorescence scattering layer 3 per unit area by the side of a second main surface, and area of the end of LED1 and the most distant second main surface is further made small a little slightly as compared with the maximum area as LED1 is approached. Here, ** in Fig.1 expresses the pattern of the fluorescence scattering layer 3. Although blue LED is made into the structure allotted to one end face two pieces in Fig.1, if a light guide plate is a quadrangle, to say nothing of connecting LED, the number of LED will not be limited to all end faces on all sides. The coating form of a fluorescence scattering layer and an application state can be suitably changed so that luminescence observed from the first main surface side may be made into surface state homogeneity according to the arrangement situation of LED. [0009]

[Function] Fig. 2 is a schematic cross section at the time of mounting the source of sheet-like light of the present invention as a backlight of a liquid crystal panel. The scatter reflection layer 6 which is on the second main surface side of the source of sheet-like light which this shows to Fig. 1, for example from barium titanate, titanium oxide, an aluminum oxide, etc., For example, the light reflector with which the base 7 which consists of aluminum was laminated is installed, the optical diffuser 5 by which the surface is considered as unevenness at the first main surface side is installed, and these composition is not different from the backlight in particular that uses a light source as a cold cathode tube.

[0010]As the arrow of Fig.2 shows first, the light which came out of the blue LED 1 is emitted to the exteriors other than a light guide plate in part near the chip, but a great portion of light reaches the end face of a light guide plate in the inside of the light guide plate 2, repeating total internal reflection. It is reflected by the reflecting film 4 formed in all end faces, and the light which reached the end face repeats total internal reflection. At this time, a part of lights are absorbed with a fluorescent substance, and wavelength changing of them is carried out simultaneously, they are emitted [a part of lights are scattered about by the fluorescence scattering layer 3 provided at the second main surface side of the light guide plate 2 and], and the luminescent color observed from the first main surface side of the light guide plate 2 can

observe the light which synthesized such lights. For example, in the source of sheet-like light which provided the fluorescence scattering layer 3 which consists of an orange fluorescent pigment and white pigment, by the operation described previously, the luminescent color from blue LED becomes white, and it can observe. A color tone can be arbitrarily adjusted with the kind of fluorescent substance, and the mixture ratio of a white pigment. At the present invention, the main-light-emission peak of especially the luminous wavelength of one blue LED is shorter than 500 nm, and the radiant power output needs not less than 200 microwatts of outputs of not less than 300 microwatts still more preferably. It is because it is in the tendency for the light source of surface state luminescence with sufficient uniform luminosity to be hard to be obtained even if it increases the number of blue LED which connects with the end face of a light guide plate optically even if when it becomes it difficult to realize all the colors that a luminous wavelength is not less than 500 nm and there are few the radiant power outputs than 200 microwatts.

[0011]

[Working example]

[Working example 1] The fluorescence scattering layer 3 was formed in one side of an acrylic board about 2 mm thick by screen—stencil by the dot form pattern shown in Fig.1. The fluorescent pigment which mixed and product FAmade from SHINROIHI chemistry—001 whose fluorescence scattering layer 3 is a red fluorescent pigment, and the company's FA—005 which are green fluorescence paints, Barium titanate was mixed at a ratio of 1:5 by the weight ratio as white powder, and what distributed it in the acrylic binder was printed and formed.

[0012]Next, after cutting the acrylic board with which the fluorescence scattering layer was formed as mentioned above according to the desired pattern and grinding all the end faces (cutting plane) of an acrylic board, the light guide plate 2 with which the fluorescence scattering layer 3 was formed was obtained by forming the reflecting layer 4 which becomes a polished surface from aluminum.

[0013]Two places and a hole are provided to the end face of the aforementioned light guide plate 2, and it is a luminous wavelength of 480 nm to the hole. By embedding at a time one blue LED which consists of a gallium nitride system compound semiconductor which has 1200 microwatts of radiant power outputs, respectively, the source of sheet-like light of the present invention was acquired. When the blue LED of this source of sheet-like light was made to turn on simultaneously, substantially uniform white surface state luminescence which is a little tinged with yellowness was obtained from the luminescence observation surface side of the light guide plate 2. the place which installed the optical diffuser 5 by which mat processing was previously performed to the luminescence observation surface side, and the light reflector with which the barium titanate layer 6 was applied on the aluminum base 7 at the fluorescence scattering layer 3 side, and was used as the light source for backlights -- from the optical diffuser 5 side -completely -- surface state -- uniform white light was obtained. Luminosity was 55cd/m². [0014][Working example 2] Mix the fluorescence scattering layer 3 as yellow fluorescent dye, and the company's Orenge-240 is substantially mixed in equivalent amount as LumogenF Yellow-083 of BASF A.G., and orange fluorescent dye, When barium titanate was formed using the thing mixed at a ratio of 1(color):200 by the weight ratio as the fluorescent dye which dissolved them in butylcarbitol acetate, and a white substance and also the source of sheet-like light of the present invention was acquired like the working example 1, substantially uniform surface state luminescence was observed. When it was considered as the light source for backlights still more nearly similarly, completely uniform surface state luminescence was observed.

[0015]

[Effect of the Invention] As described above, the source of sheet-like light of the present invention became possible [realizing the source of sheet-like light by LED excellent in reliability] by having a fluorescence scattering layer containing the fluorescent substance which can moreover carry out wavelength changing to the surface of one of the two of a light guide plate by blue LED, and white powder using blue LED. And since the white powder of a

fluorescence scattering layer has the operation which reflects the light by which wavelength changing was carried out with the fluorescent substance, and makes it spread, there is little amount of the fluorescent substance used to be used, and it ends. Since an LED chip and a fluorescent substance do not meet with a convenient thing directly, there is little degradation of a fluorescent substance and it does not cause the tone change of the source of sheet-like light over a long period of time. Any color tones including white can be provided by changing the kind of a fluorescent substance and white powder, a mixed amount, etc. about a color tone. [0016]When the radiant power output of the blue LED most preferably used as a side which excites a fluorescence scattering layer on the other hand considers it as a not less than 200-microwatt thing, wavelength changing can be efficiently carried out with a fluorescent substance, and the source of sheet-like light with a bright big area can be realized. Thus, the source of sheet-like light of an application concerned can also be used for the illuminated operation switch not only using the light source for backlights but a fluorescent substance, etc.

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DESCRIPTION OF DRAWINGS

[Brief Description of the Drawings]

[Drawing 1] The plan view which looked at the light guide plate 2 of the source of sheet-like light of one working example of the present invention from the fluorescence scattering layer 3 side. [Drawing 2] The schematic cross section at the time of mounting the source of sheet-like light of one working example of the present invention as a backlight.

[Explanations of letters or numerals]

- 1 Blue LED
- 2 Light guide plate
- 3 Fluorescence scattering layer
- 4 Reflecting layer
- 5 Optical diffuser
- 6 Scatter reflection layer
- 7 aluminum base

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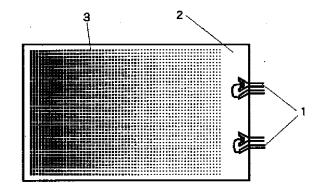
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(54) 【発明の名称】 面状光源

(57)【要約】

【目的】 青色発光ダイオードを用いた白色可能な面状 光源を実現し、均一な白色発光を観測できる面状光源を 提供する。

【構成】 透明な導光板の端面に発光ダイオードが光学 的に接続されており、さらに前記導光板の主面のいずれ か一方に、前記青色発光ダイオードの発光により励起さ れて蛍光を発する蛍光物質と、蛍光を散乱させる白色粉 末とが混合された状態で塗布された蛍光散乱層を有し、 前記青色発光ダイオードの発光が前記蛍光散乱層で波長 変換される。



【特許請求の範囲】

【請求項1】 透明な導光板の端面の少なくとも一箇所に青色発光ダイオードが光学的に接続されており、さらに前記導光板の主面のいずれか一方に、前記青色発光ダイオードの発光により励起されて蛍光を発する蛍光物質と、蛍光を散乱させる白色粉末とが混合された状態で塗布された蛍光散乱層を有し、前記青色発光ダイオードの発光が前記蛍光散乱層で波長変換され、前記蛍光散乱層と反対側の導光板の主面側から観測されることを特徴とする面状光源。

【請求項2】 前記青色発光ダイオードは、その主発光 波長が500nmよりも短く、発光出力が500μW以 上であることを特徴とする請求項1に記載の面状光源。

【発明の詳細な説明】

[0001]

【産業上の利用分野】本発明はディスプレイのバックライト、照光式操作スイッチ等に使用される面状の光源に係り、特に液晶ディスプレイのバックライトとして好適に用いることができる面状光源に関する。

[0002]

【従来の技術】一般にノート型パソコン、ワープロ等に使用される液晶ディスプレイのパックライト用の面状光源には、例えばEL、冷陰極管が使用されている。ELはそれ自体が面状光源であり、冷陰極管は拡散板を用いて面状光源とされ、現在それらのパックライトの発光色はほとんどが白色とされている。

【0003】一方発光ダイオード(以下LEDと記す。)もパックライト用光源として一部利用されている。しかしLEDを用いて白色発光を得る場合、従来では青色LEDの発光出力が数十μWほどしかないため、他の赤色LED、緑色LEDを用いて白色発光を実現させるには、それら各色発光LEDの特性を合致させにく色変化が大きいという欠点がある。また、三原色のLEDを集合させて、同一平面上に幾何学的に同して自ても、バックライトとしてはそれらのLEDを集近した位置で視認するため、均一な白色光源にするランドではであった。従って現在白色の液晶パックライトはいては冷陰極管、LEDを用いた白色発光のパックライトはほとんど知られていない。

【0004】また白色発光、あるいはモノクロの光源として、一部では青色LEDチップの周囲を蛍光物質を含む樹脂で包囲して色変換する試みもあるが、チップ周辺は太陽光よりも強い放射強度の光線にさらされるため、蛍光物質の劣化が問題となり、特に有機蛍光顔料で顕著である。更にイオン性の有機染料はチップ近傍では直流電界により電気泳動を起こし、色調が変化する可能性がある。また従来の青色LEDは蛍光物質で色変換するには十分な出力を有しておらず、たとえ色変換したとしても実用できるものではなかった。

[0005]

【発明が解決しようとする課題】本発明はこのような欠点を解決するために成されたもので、その目的とするところは、LEDを用い、主としてバックライトとして利用できる白色発光可能な面状光源を実現すると共に、均一な白色発光を観測できる面状光源を提供することにあり、さらには白色以外の任意色の発光が可能な面状光源を提供し、信頼性に優れたLEDの特性を利用し、各種操作スイッチ等に利用することにある。

10 [0006]

【課題を解決するための手段】本発明の面状光源は、透明な導光板の端面の少なくとも一箇所に青色LEDが光学的に接続されており、さらに前記導光板の主面のいずれか一方に、前記青色発光ダイオードの発光により励起されて蛍光を発する蛍光物質と、光を散乱させる白色粉末とが混合された状態で塗布された蛍光散乱層(以下、蛍光散乱層側の主面を第二の主面という。)を有し、前記青色発光ダイオードの発光の一部が前記蛍光散乱層で波長変換され、前記蛍光散乱層と反対側の導光板の主面20 (以下発光観測側の主面を第一の主面という。)側から観測されることを特徴とする。

【0007】図1は本発明の面状光源の導光板2を蛍光散乱層3側から見た平面図である。導光板2は例えばアクリル、硝子等の透明な材料よりなり、その導光板2の端面に青色LED1が埋設されることにより、導光板2の端面において、青色LED1と導光板2の端面とが光学的に接続されているとは、簡単に言えば、導光板2の端面から青色LEDの光を導入することをいい、例えばこの図に示すように青色LED1を埋設することはもちろんのこと、青色LEDを接着したり、また、光ファイバー等を用いて導光板2の端面に青色LEDの発光を導くことによって実現可能である。

【0008】次に、蛍光散乱層3は、所望の色が観測で きるように、蛍光物質と白色顔料とを調合したインクが 塗布されてなり、青色LED1の発光を蛍光物質で波長 変換すると同時に、白色顔料でその蛍光を導光板2内に 散乱させている。特に図1では前記蛍光散乱層3をドッ ト状とし、第一の主面側の表面輝度が一定となるよう 40 に、LED1に接近するにつれて、第二の主面側の単位 面積あたりの蛍光散乱層3の面積を減じるようなパター ンとし、さらにはLED1と最も離れた第二の主面の端 部の面積はやや最大面積に比して若干小さくしている。 ここで、図1中の■は蛍光散乱層3のパターンを表して いる。図1では青色LEDを一つの端面に2個配した構 造としているが、導光板が四角形であれば四方の端面全 てにLEDを接続してもよいことはいうまでもなく、L EDの個数も限定するものではない。さらに、LEDの 配置状況により、第一の主面側から観測する発光を面状 50 均一とするように蛍光散乱層の塗布形状、塗布状態を適

宜変更することができる。

[0009]

【作用】図2は本発明の面状光源を例えば液晶パネルの バックライトとして実装した場合の模式断面図である。 これは図1に示す面状光源の第二の主面側に、例えばチ タン酸パリウム、酸化チタン、酸化アルミニウム等より なる散乱反射層 6 と、例えばAIよりなるベース7とが 積層された反射板を設置し、第一の主面側に表面が凹凸 とされている光拡散板5を設置しており、これらの構成 は光源を冷陰極管とするバックライトと特に変わるもの

【0010】まず図2の矢印で示すように、青色LED 1から出た光は、チップ近傍で一部導光板以外の外部に 放射されるが、大部分の光は導光板2の中を全反射を繰 り返しながら、導光板の端面に達する。端面に達した光 は端面全てに形成された反射膜4に反射されて、全反射 を繰り返す。この時、導光板2の第二の主面側に設けら れた蛍光散乱層3により一部の光は散乱され、また一部 の光は蛍光物質により吸収され同時に波長変換されて放 射され、導光板2の第一の主面側から観測する発光色は 20 光が観測された。さらに同様にしてバックライト用光源 これらの光を合成した光が観測できる。例えば橙色の蛍 光顔料と白色顔料からなる蛍光散乱層3を設けた面状光 源では、先に述べた作用により、青色LEDからの発光 色が白色となって観測できる。また色調は蛍光物質の種 類と白色顔料の混合比により任意に調整できる。特に本 発明では一つの青色LEDの発光波長はその主発光ピー クが500nmよりも短く、その発光出力は200μW 以上、更に好ましくは300µW以上の出力が必要であ る。なぜなら発光波長が500mm以上であると全ての よりも少ないと、たとえ導光板の端面に光学的に接続す る青色LEDの数を増やしても、充分な明るさの均一な 面状発光の光源が得られにくい傾向にあるからである。

[0011]

【実施例】

[実施例1]厚さ約2mmのアクリル板の片面に、図1 に示すドット状のパターンで、蛍光散乱層3をスクリー ン印刷により形成した。蛍光散乱層3は、赤色蛍光顔料 であるシンロイヒ化学製FA-001と緑色蛍光顔料で ある同社製FA-005とを等量に混合した蛍光顔料 と、白色粉末としてチタン酸バリウムとを重量比で1: 5の割合で混合し、それをアクリル系パインダー中に分 散したものを印刷して形成した。

【0012】次に上記のようにして蛍光散乱層が形成さ れたアクリル板を、所望のパターンに従って切断し、ア クリル板の端面(切断面)を全て研磨した後、研磨面に A | よりなる反射層 4 を形成することにより、蛍光散乱 層3が形成された導光板2を得た。

【0013】前記導光板2の端面に二箇所、穴を設け、 その穴に発光波長480nm。発光出力1200µWを 50 1···· 青色LED

有する窒化ガリウム系化合物半導体よりなる青色LED をそれぞれ1個づつ埋め込むことにより、本発明の面状 光源を得た。この面状光源の青色LEDを同時に点灯さ せたところ、導光板2の発光観測面側からはやや黄色み を帯びた白色のほぼ均一な面状発光が得られた。さら に、発光観測面側に予めマット加工が施された光拡散板 5と、蛍光散乱層3側にAIベース7上にチタン酸バリ ウム層6が塗布された反射板を設置して、バックライト 用光源としたところ、光拡散板5側から完全に面状均一 10 な白色発光が得られた。輝度は55cd/m²であっ

【0014】「実施例21蛍光散乱層3を、黄色蛍光染 料としてBASF社のLumogenF Yellow - 083と橙色蛍光染料として同社製Orenge - 2 40とをほぼ等量混合し、それらをブチルカルビトール アセテートに溶解した蛍光染料と、白色物質としてチタ ン酸バリウムとを重量比で1(染料):200の割合で 混合したものを用いて形成する他は、実施例1と同様に して本発明の面状光源を得たところ、ほぼ均一な面状発 としたところ、完全に均一な面状発光が観測された。

[0015]

【発明の効果】以上説明したように、本発明の面状光源 は、青色LEDを用い、しかも導光板の片方の面に青色 LEDにより波長変換できる蛍光物質と白色粉末とを含 有した蛍光散乱層を有していることにより、信頼性に優 れたLEDによる面状光源を実現することが可能となっ た。しかも蛍光散乱層の白色粉末は、蛍光物質により波 長変換された光を反射、拡散させる作用があるため、使 色が実現しにくくなり、またその発光出力が200μ W 30 用する蛍光物質の使用量が少なくて済む。更に好都合な ことには、LEDチップと蛍光物質とが直接接すること がないので、蛍光物質の劣化が少なく、長期間に渡って 面状光源の色調変化を起こすことがない。さらに、色調 に関しては、蛍光物質、白色粉末の種類、混合量等を変 更することにより、白色を含め任意の色調を提供するこ とができる。

> 【0016】一方蛍光散乱層を励起する側として、最も 好ましくは使用する青色LEDの発光出力が200μ W 以上のものとすることにより、蛍光物質により効率的に 40 波長変換して大きな面積の明るい面状光源を実現するこ とができる。このように、本願の面状光源は、バックラ イト用光源とだけでなく、蛍光物質を利用した照光式操 作スイッチ等に利用することもできる。

【図面の簡単な説明】

【図1】 本発明の一実施例の面状光源の導光板2を蛍 光散乱層3側から見た平面図。

【図 2】 本発明の一実施例の面状光源をバックライト として実装した場合の模式断面図。

【符号の説明】

Electronic Patent Application Fee Transmittal					
Application Number:	12942792				
Filing Date:	09-Nov-2010				
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY				
First Named Inventor/Applicant Name:	Yoshinori Shimizu				
Filer:	Со	rina E. Tanasa/Patti	Young		
Attorney Docket Number:	0020-5147PUS12				
Filed as Large Entity					
Utility under 35 USC 111(a) Filing Fees					
Description		Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Basic Filing:					
Pages:					
Claims:					
Miscellaneous-Filing:					
Petition:					
Patent-Appeals-and-Interference:					
Post-Allowance-and-Post-Issuance:					
Extension-of-Time:					

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Miscellaneous:				
Submission- Information Disclosure Stmt	1806	1	180	180
	180			

Electronic Acl	Electronic Acknowledgement Receipt				
EFS ID:	13448296				
Application Number:	12942792				
International Application Number:					
Confirmation Number:	2357				
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY				
First Named Inventor/Applicant Name:	Yoshinori Shimizu				
Customer Number:	2292				
Filer:	Corina E. Tanasa/Patti Young				
Filer Authorized By:	Corina E. Tanasa				
Attorney Docket Number:	0020-5147PUS12				
Receipt Date:	08-AUG-2012				
Filing Date:	09-NOV-2010				
Time Stamp:	15:26:53				
Application Type:	Utility under 35 USC 111(a)				

Payment information:

Submitted with Payment	yes
Payment Type	Credit Card
Payment was successfully received in RAM	\$180
RAM confirmation Number	1766
Deposit Account	022448
Authorized User	ANDERSON,RICHARD D.

The Director of the USPTO is hereby authorized to charge indicated fees and credit any overpayment as follows:

Charge any Additional Fees required under 37 C.F.R. Section 1.16 (National application filing, search, and examination fees)

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File Listing:					
Document Number	Document Description	File Name	File Size(Bytes)/ Message Digest	Multi Part /.zip	Pages (if appl.)
1		20120000 DC F	443359		
1		20120808IDS.pdf	81afc2ed7e15cc63aafc686e85af27558a013 ed4	yes	9
	Multi	part Description/PDF files in .	zip description	<u>'</u>	
	Document Do	escription	Start	Eı	nd
	Miscellaneous Ind	coming Letter	1		1
	Transmitta	l Letter	2		7
	Information Disclosure State	ement (IDS) Form (SB08)	8		9
Warnings:					
Information:					
2	Foreign Reference	JP7335942.pdf	4167280	no	11
-	Totalgrifference	31 / 3333 12.pul	e6b0a788aceb9be939b6589012ea8418961 87e0a	110	
Warnings:					
Information:			,		
3	Foreign Reference	JP7099345.pdf	3183622	no	10
	Totalgrifference	31 7 0333 13.pui	a1bd8e4710ca48a4a2dfee2a92c61483d31 b69bf	110	10
Warnings:					
Information:					
4	Foreign Reference	IP7176704 ndf	3820053	na	11
4	Foreign Reference	JP7176794.pdf	25b29adbd35b45886617abbc214cfac31a1 af7b4	no	
Warnings:		ı			
Information:					
5	Non Patent Literature	SGSearch Report dated 2012 070	911518		13
5	Non Patent Literature	2.pdf	1b085df251ebb0508859934ad038a61d043 7b63d	no	13
Warnings:		•	,	<u>'</u>	
Information:					
6	Non Patent Literature	SGSearch Report dated 2012 070	714004	no	9
	Non ratent Literature	5.pdf	ad0e5dded079562712536b7360a5584242 b40021	no	
Warnings:					

7	Fee Worksheet (SB06)	fee-info.pdf	30215	no	2
,	ree worksneet (5500)		f6ede363d9c6eb93800a77ada3e7f1f22535 8015		_
Warnings:					
Information:					
		Total Files Size (in bytes):	13:	270051	

This Acknowledgement Receipt evidences receipt on the noted date by the USPTO of the indicated documents, characterized by the applicant, and including page counts, where applicable. It serves as evidence of receipt similar to a Post Card, as described in MPEP 503.

New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.

Approved for use through 01/31/2014, OMB 0651-0032 U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE Under the Paperwork Reduction Act of 1995 no persons are required to respond to a collection of information unless it displays a valid OMB control number Complete if Known 12/942,792 Conf. No.: 2357 **Application Number** FEE TRANSMITTAL Filing Date November 09, 2010 First Named Inventor Yoshinori SHIMIZU A.B. MUSTAPHA **Examiner Name** Applicant claims small entity status. See 37 CFR 1.27 2812 Art Unit TOTAL AMOUNT OF PAYMENT 180.00 0020-5147PUS12 Attorney Docket No. METHOD OF PAYMENT (check all that apply) Check Credit Card Money Order Other (please identify): Deposit Account Name: Birch, Stewart, Kolasch & Birch, LLP Deposit Account Deposit Account Number: 02-2448 For the above-identified deposit account, the Director is hereby authorized to: (check all that apply) Charge fee(s) indicated below Charge fee(s) indicated below, except for the filing fee Charge any additional fee(s) or underpayments of fee(s) Credit any overpayments under 37 CFR 1.16 and 1.17 WARNING: Information on this form may become public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038. **FEE CALCULATION** 1. BASIC FILING, SEARCH, AND EXAMINATION FEES **FILING FEES** SEARCH FEES **EXAMINATION FEES Small Entity Small Entity Small Entity Application Type** Fee (\$) Fees Paid (\$) Fee (\$) Fee (\$) Fee (\$) Fee (\$) Fee (\$) Utility 380 190 620 250 310 125 Design 250 125 120 60 160 80 Plant 250 125 380 190 200 100 Reissue 380 190 620 750 310 375 Provisional 250 125 0 0 0 0 2. EXCESS CLAIM FEES **Small Entity** Fee (\$) Fee Description <u>Fee (\$)</u> Each claim over 20 (including Reissues) 60 30 Each independent claim over 3 (including Reissues) 250 125 225 Multiple dependent claims 450 **Total Claims** Extra Claims Fee Paid (\$) Multiple Dependent Claims 0 - 20 or HP = Fee Paid (\$) Fee (\$) HP = highest number of total claims paid for, if greater than 20. Indep. Claims Extra Claims Fee (\$) Fee Paid (\$) - 3 or HP = HP = highest number of independent claims paid for, if greater than 3. 3. APPLICATION SIZE FEE If the specification and drawings exceed 100 sheets of paper (excluding electronically filed sequence or computer listings under 37 CFR 1.52(e)), the application size fee due is \$310 (\$155 for small entity) for each additional 50 sheets or fraction thereof. See 35 U.S.C. 41(a)(1)(G) and 37 CFR 1.16(s). Number of each additional 50 or fraction thereof

(round up to a whole number) x **Total Sheets Extra Sheets** Fee (\$) Fee Paid (\$) 0 0.00 4. OTHER FEE(S) Fees Paid (\$) Non-English Specification, \$130 fee (no small entity discount) Other (e.g., late filing surcharge): 1806 - IDS Fee 180.00

SUBMITTED BY				
Signature	Corua Tan	ana R9 NO. 64042	Registration No. 40,439 (Attorney/Agent)	Telephone 703-205-8000
Name (Print/Type)	D. Richard Anderso	" CORINA TAHAS	Ā	Date August 8, 2012

This collection of interest in the complete that the complete the amount of time you required by 37 CFR 1.136. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 30 minutes to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

If you need assistance in completing the form, call 1-800-PTO-9199 and select option 2.

Docket No.: 0020-5147PUS12

(Patent)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

12/942,792

Confirmation No.: 2357

Filed:

November 09, 2010

Art Unit:

2812

For:

LIGHT EMITTING DEVICE AND DISPLAY

Examiner:

A. B.

MUSTAPHA

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Commissioner:

Applicant(s) hereby submit(s) an Information Disclosure Statement for consideration by the Examiner.

I. LIST OF PATENTS, PUBLICATIONS OR OTHER INFORMATION

The patents, publications, or other information submitted for consideration by the Office are listed on the attached PTO/SB/08.

II. COPIES

☑ a. Copies of foreign patent documents, non-patent literature and other information are provided.

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 2 of 6

b. <u>REFERENCES PREVIOUSLY CITED OR SUBMITTED</u>: Copies of any information not provided can be found in one or more of the following applications which has been relied upon for an earlier filing date under 35 U.S.C. § 120:

U.S. Application No. and U.S. Filing Date 12/548,614 filed August 27, 2009

III. CONCISE EXPLANATION OF THE RELEVANCE/OTHER INFORMATION

a. NON-ENGLISH LANGUAGE DOCUMENTS: A concise explanation of the relevance of all non-English language patents, publications, or other information listed is as follows:

An English language abstract and a full English machine translation is provided (as a partial translation) for the following reference(s): JP 7-99345, JP 7-335942 and JP 7-176794.

☑ b. ENGLISH LANGUAGE SEARCH REPORT OR FOREIGN PATENT OFFICE COMMUNICATION:

An English language version of a Singaporean Examination and Search Report issued on July 2, 2012 in foreign counterpart application No. 201007151-2 that indicates the degree of relevance is attached.

An English language version of a Singaporean Examination and Search Report issued on July 5, 2012 in foreign counterpart application No. 201007150-4 that indicates the degree of relevance is attached.

☑ c. OTHER: The following additional information is provided.

JP 7-99345 and US 5,247,533 were cited in the Singaporean Examination and Search Report issued on July 2, 2012. US 3,691,482 cited in the Singaporean Examination and Search Report was previously cited in an IDS in USPTO.

JP 7-335942, JP 7-176794 and US 5,408,120 were cited in the Singaporean Examination and Search Report issued on July 5, 2012.

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 3 of 6

Both JP 7-99345 and JP 7-176794 were previously cited in an IDS filed in the USPTO on November 9, 2010. The full English machine translations for JP 7-99345 and JP 7-176794 are now submitted for Examiner's consideration.

IV. STATEMENT UNDER 37 C.F.R. § 1.97(e)

The undersigned hereby states that:

- a. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than <u>30</u> <u>days</u> prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or
- b. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than **three months** prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or
- □ c. No item of information contained in the IDS was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing the certification after making reasonable inquiry, no item of IDS was known to any individual designated in 37 C.F.R. § 1.56(c) more than **three months** prior to the filing of the IDS; or
- d. Some of the items of information in the IDS were cited in a communication from a foreign patent office. Such items were first cited in a communication from a foreign patent office in a counterpart foreign application not more than **three months** prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 4 of 6

communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office. As to the remaining items of information, to the knowledge of the person signing the certification after making reasonable inquiry, such remaining items were not known to any individual designated in 37 C.F.R. § 1.56(c) more than **three months** prior to the filing of this statement.

V. <u>STATEMENT UNDER 37 C.F.R. § 1.704(d)(1)</u>

• •	<u> </u>	21/12/11 01/22/13 / 0.1 110 3 1.70 ((4)(1)
		Patent Term Adjustment Reduction Should Not Apply
	The ur	ndersigned hereby states:
	This I	nformation Disclosure Statement is in compliance with 37 C.F.R. §§ 1.97 and 1.98
and w	ill not	be considered a failure to engage in reasonable efforts to conclude prosecution
(proces	ssing o	r examination) of the present application under 37 C.F.R. § 1.704(c)(6), (c)(8),
(c)(9),	or (c)(10), because each item of information contained in the Information Disclosure
Statem	ent:	
		(i) Was first cited in any communication from a patent office in a counterpart
	foreign	n or international application or from the Office, and this communication was not
	receive	ed by any individual designated in § 1.56(c) more than thirty days prior to the filing
	of the	information disclosure statement; or
		(ii) Is a communication that was issued by a patent office in a counterpart foreign
	or inte	rnational application or by the Office, and this communication was not received by
	any in	dividual designated in § 1.56(c) more than thirty days prior to the filing of the
	inform	ation disclosure statement.
X 7 T	PPPC	
VI.	<u>FEES</u>	
	a.	This Information Disclosure Statement is being filed concurrently with the filing
of a ne	w paten	at application or Request for Continued Examination. No fee is required.
	b.	This Information Disclosure Statement is being filed within three months of the
filing d	late of a	an application. No fee is required.

c. This Information Disclosure Statement is being filed before the mailing date of a first Action on the merits. No fee is required. If a first Office Action on the merits has issued, please consider this IDS under 37 C.F.R. § 1.97(c) and see the statement under 37 C.F.R. § 1.97(e) above. If no statement has been made, charge our deposit account for the required fee. d. This Information Disclosure Statement is being filed before the mailing date of a Final Office Action or before the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(c)(1)). No statement. The fee as required by 37 C.F.R. § 1.17(p) is provided. or See the above statement. No fee is required. $\sqrt{}$ e. This Information Disclosure Statement is being filed after the mailing date of a Final Office Action or after the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(d)), see the statement above. The fee as required by 37 C.F.R. § 1.17(p) is provided. VII. **PAYMENT OF FEES** $\sqrt{}$ The required fee is listed on the attached Fee Transmittal. No fee is required.

Application No.: 12/942,792

Docket No.: 0020-5147PUS12

Page 5 of 6

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 6 of 6

If the Examiner has any questions concerning this IDS, please contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the USPTO is requested to consider this IDS under the proper rule and charge the appropriate fee to Deposit Account No. 02-2448.

Dated: August 8, 2012 Respectfully submitted,

Rag. No.

D. Richard Anderson

64042

Registration No.: 40,439

CORINA TANASA

BIRCH, STEWART, KOLASCH & BIRCH, LLP

8110 Gatehouse Road, Suite 100 East

P.O. Box 747

Falls Church, VA 22040-0747

703-205-8000

Attachment(s):

☑ PTO/SB/08

☑ Document(s)

☐ Foreign Patent Office Communication

☑ Foreign Search Report

☑ Fee

☑ Other: Full English machine translations for JP 7-99345 and JP 7-176794.

Approved for use through 07/31/2012, OMB 0651-0031

U.S. Patent and Trademark Office: U.S. DEFARTMENT OF COMMERCE.

Under the Paperson's reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid CMB control number.

***************************************	Substitute	for form 1449A/PTC	}			Complete if Known			
	3 A 5 500		~ : ~ e	~ ~ : : : : :	, 2000K	Application Number	12/942,792		
		RMATION				Filing Date	11-09-10		
	STAT	rement b)	/ AP	PLICAN	T	First Named Inventor	Yoshinori Shimizu		
						Art Unit	2812		
		(Use as many sheet	is as ne	cessary)		Examiner Name	A.B. MUSTAPHA		
Sheet 1 of 2						Attorney Docket Number	0020-5147PUS12		

			U.S. PATE	NT DOCUMENTS	
Examiner Initial *	Cite No.	Gocument Number Number - Hind Code ² (# known)	Publication Date MM-DO-YYYY	Name of Patentee or Applicant of Cited Occurrent	Pages, columns, Unies, Where Relevant Passages or Relevant Pigures Appear
*************	1	US-3,560,649	02-02-1971	Anderson	
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FOREIGN PATENT DOCUMENTS							
Examiner Initial *		Foreign Palant Document	Publication Date	Name of Petentes or	Pages, columns, Lines, Whers Relevant Passages or Relevant	8	
10 1147624	740, 1	Country ² Number ⁴ Kind Code (if known) ⁵ Code	MM-DD-YYYY	Applicant of Cited Document	Figures Appear		
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Examiner	Date	
Signature	Considered	
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This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief information Officer, U.S. Parent and Trademark Office, P.C. Box 1450 Alexandria, VA 22313-1450, DO NOT SENO FEES OR COMPLETED FORMS TO THIS ADDRESS.

SENO TO: Commissioner for Patents, P.C. Box 1450, Alexandria, VA 22313-1450.

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^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not Considered, broade copy of this form with next communication to applicant. 1, Applicant's unique citation design number (optional). 2 See Kinds Codes of USPTO patent Occurrents, at www.uspro.gov.or. MPEP 901.04. 3, Enter Office that issued the document, by the two-letter code (WIPO Standard ST 3), 4. For Japanese patent occurrents, the indication of the year of the relign of the Emperor must precede the serial number of the patent document, 5. Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST, 16 if possible, 6. Applicant is to place a check mark here it English language Translation is attached.

PTO/88/08b (07-09)

Appreved for use timough 07/81/2012, OMB 0651-0031

U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

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Substitute for	form 14498/PTO		•••••	Complete If Known			
INIEAE	RMATION D	icai	ACHE	Application Number	12/942,792		
	EMENT BY			Filling Date	11-09-10		
01741	m181771.41 731	See 82. 8	27.17.2.68.1	First Named Inventor	Yoshinori Shimizu		
(Use as many sheets as necessary)				Art Unit	2812		
,			Examiner Name	A.B. MUSTAPHA			
Sheet	2	of	2	Attorney Docket Number	0020-5147PUS12		

NON PATENT LITERATURE DOCUMENTS					
Examiner initial *	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	, 2		
	2	U.S. Office Action issued in co-pending U.S. application no. 12/689,681 on May 10, 2012.			
	***************************************				
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***************************************	**************		~~
* EXAMINER: tritial if reference considered, whether or not citation is in conformance with MPEP 609. Draw lin	e through sitation	if not in conformance and not	
considered. Indude copy of this ferm with next communication to applicant.			

SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

if you need assissiance in completing the form, call 1-800-PTO-9199 and select option 2.

^{1.} Applicante unique offation designation number. (optional) 2. Applicant is to place a check mark here if English language Translation is attached.

This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to fits (and by the DSPTO to process) on application. Confidentiality is governed by 36 U.S.C. 122 and 37 CFR 1.14. This pollection is estimated to take 2 hours to complete, including gathering, emparing, and submitting the completed application form the USETO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing the bunten, should be sent to the Chelf Information Officer, U.S. Patent and Tredemark Office. P.O. Box 1450 Alexandria, VA 22313-1460, DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS.

Electronic Patent Application Fee Transmittal					
Application Number:	Application Number: 12942792				
Filing Date:	09	Nov-2010			
Title of Invention:	LIG	HT EMITTING DEVIC	CE AND DISPLAY	,	
First Named Inventor/Applicant Name: Yoshinori Shimizu					
Filer: Corina E. Tanasa/Patti Young					
Attorney Docket Number:	Attorney Docket Number: 0020-5147PUS12				
Filed as Large Entity					
Utility under 35 USC 111(a) Filing Fees					
Description		Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Basic Filing:					
Pages:					
Claims:					
Miscellaneous-Filing:	Miscellaneous-Filing:				
Petition:					
Patent-Appeals-and-Interference:					
Post-Allowance-and-Post-Issuance:					
Extension-of-Time:					

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Miscellaneous:				
Submission- Information Disclosure Stmt	1806	1	180	180
	Tot	al in USD	(\$)	180

Electronic Ack	Electronic Acknowledgement Receipt				
EFS ID:	13313680				
Application Number:	12942792				
International Application Number:					
Confirmation Number:	2357				
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY				
First Named Inventor/Applicant Name:	Yoshinori Shimizu				
Customer Number:	2292				
Filer:	Corina E. Tanasa/Patti Young				
Filer Authorized By:	Corina E. Tanasa				
Attorney Docket Number:	0020-5147PUS12				
Receipt Date:	23-JUL-2012				
Filing Date:	09-NOV-2010				
Time Stamp:	14:39:24				
Application Type:	Utility under 35 USC 111(a)				

# **Payment information:**

Submitted with Payment	yes
Payment Type	Credit Card
Payment was successfully received in RAM	\$180
RAM confirmation Number	1091
Deposit Account	022448
Authorized User	ARMSTRONG,MARYANNE

The Director of the USPTO is hereby authorized to charge indicated fees and credit any overpayment as follows:

Charge any Additional Fees required under 37 C.F.R. Section 1.16 (National application filing, search, and examination fees)

Charge any Additional Fees required under 37 C.F.R. Section 1.17 (Patent application and reexamination processing fees)

File Listing:					
Document Number	Document Description	File Name	File Size(Bytes)/ Message Digest	Multi Part /.zip	Pages (if appl.)
1		20120723IDS.pdf	4404919	yes	9
'		201207231D3.pd1	60d43ed4380a0241ada91c8faf74e47e710e dd25	yes	9
	Mult	ipart Description/PDF files in	zip description		
	Document D	escription	Start	Eı	nd
	Miscellaneous In	1		1	
	Transmitta	2	7		
	Information Disclosure Stat	8	9		
Warnings:					
Information:					
2	Non Patent Literature	20120510NonfinalRejection.pdf	483853	no	11
-	Trom atem Enclarate		e217f267002443e0a31af9c851620f4a5432 9d78		
Warnings:					
Information:					
,	For Markeline et (CDCC)	6	30215		2
3	Fee Worksheet (SB06)	fee-info.pdf	3372f0eda2b15575297a7f792a0b5a84225 df57c	no	
Warnings:		•		<u>'</u>	
Information:					
		Total Files Size (in bytes)	49	18987	

This Acknowledgement Receipt evidences receipt on the noted date by the USPTO of the indicated documents, characterized by the applicant, and including page counts, where applicable. It serves as evidence of receipt similar to a Post Card, as described in MPEP 503.

### New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

## National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

## New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.

Approved for use through 01/31/2014, GMS 1965-16692 U.S. Patent and Tradsmark Office: U.S. DEPARTMENT OF COMMERCE Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it displays a valid OMS control number

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Same Secus Sensos contino decerb	FEE TRANSMITTAL					942,792	Conf. No.: 2357	
	4N2	)	AL [	Filing Date	No	vember 09, 2010		
				First Named Im	ventor Ye	shinori SHIMIZU		
\$0000g		~ ^ ^ ~	1.00	Examiner Name A.B. MUSTAPHA				
Applicant claims small o	milly statu	s, See 37 CFR	1.27	Art Unit	28	12		
TOTAL AMOUNT OF PAYMENT (\$) 180.00 Attorney Docket No. 0020-5147PUS12								
METHOD OF PAYMENT (check all that apply)								
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For the above-identifie								
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Charge any add			ments of fee	(s) Credi	t any overpa	syments		
under 37 CFR warning this f			redit card info	Soonsood			rovide credit card	
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1. Basic filing, searc				24.555	*******************************			
	FILING	r EES Small Entity	SEAR	OH FEES Small Entity		ATION FEES Small Entity		
Application Type	Fee (S)	Fee (\$)	<u>Fee (\$)</u>	Fee (\$)	Fee (\$)	Fee (\$)	Fees Paid (\$)	
Utility	380	190	620	310	259	125		
Design	250	125	120	60	160	80	*********************	
Plant	250	125	380	190	200	100	***************************************	
Reissue	380	190	620	310	750	375		
Provisional	250	125	0	0	9	0		
2. EXCESS CLAIM FEES	ì					20	Small Entity	
<u>Fee Description</u> Each claim over 20 (in:	slavšiesa P	Sympoin				<u>Fee (\$)</u> 60	<u>Fes (\$)</u> 30	
Each independent claim			issues)			250	125	
Multiple dependent cla						450	225	
	xtra Clair	ns Fee (\$	) Fee	Paid (\$)		Multiple De	pendent Claims	
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HP = highest number of total of Indep. Claims E	aims paid fo Extra Clair			Paid (\$)				
	9		~~	3.00				
HP = highest number of independent clasms paid for, if greater than 3.  3. APPLICATION SIZE FEE								
If the specification and drawings exceed 100 sheets of paper (excluding electronically filed sequence or computer listings under 37 CFR 1.52(e)), the application size fee due is \$310 (\$155 for small entity) for each additional 50								
sheets or fraction thereof. See 35 U.S.C. 41(a)(1)(G) and 37 CFR 1.16(s).								
Total Sheets Extra Sheets Number of each additional 50 or fraction thereof Fee (\$) Fee Paid (\$)  - 100 = 0 / 50 = 0 (round up to a whole number) x = 0.00								
A APTICAL PARTIES								
Non-English Specification, \$130 fee (no small entity discount)  Fees Paid (\$)								
Other (e.g., late filing surcharge): 1806 - IDS Fee 180.00								
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ignature (/g/)////	7.000		64042 7	Registration No. 4	10,439	Telephon	° 703-205-8000	
lame (PrintType) D. Richard A		*****	CORINA	TANASA	<b>}</b>	Dats July	/ 23, 2012	

This collection and the control is required by 37 CFR 1.136. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 30 minutes to complete. including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450, DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS, SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

If you need assistance in completing the form, call 1-800-PTO-9199 and select option 2.

Docket No.: 0020-5147PUS12

(Patent)

# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

12/942,792

Confirmation No.: 2357

Filed:

November 09, 2010

Art Unit:

2812

For: LIGHT EMITTING DEVICE AND DISPLAY Examiner:

A.B. MUSTAPHA

# INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Commissioner:

Applicant(s) hereby submit(s) an Information Disclosure Statement for consideration by the Examiner.

#### Ĭ. LIST OF PATENTS, PUBLICATIONS OR OTHER INFORMATION

The patents, publications, or other information submitted for consideration by the Office are listed on the attached PTO/SB/08.

#### 11 COPIES

V Copies of foreign patent documents, non-patent literature and other information are provided.

Ъ. REFERENCES PREVIOUSLY CITED OR SUBMITTED: Copies of any information not provided can be found in one or more of the following applications which has been relied upon for an earlier filing date under 35 U.S.C. § 120:

> U.S. Application No. and U.S. Filing Date 12/028,062 filed February 8, 2008

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 2 of 6

# III. CONCISE EXPLANATION OF THE RELEVANCE/OTHER INFORMATION

a. NON-ENGLISH LANGUAGE DOCUMENTS: A concise explanation of the relevance of all non-English language patents, publications, or other information listed is as follows:

☐ b. ENGLISH LANGUAGE SEARCH REPORT OR FOREIGN PATENT OFFICE COMMUNICATION: An English language version of the search report or Foreign Patent Office communication that indicates the degree of relevance is attached.

☑ c. OTHER: The following additional information is provided.

A U.S. Office Action (submitted herein) issued in co-pending U.S. application No. 12/689,681 on May 10, 2012 cited US 3,560,649 submitted herein.

# IV. STATEMENT UNDER 37 C.F.R. § 1.97(e)

The undersigned hereby states that:

- a. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than <u>30</u> <u>days</u> prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or
- b. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 3 of 6

No item of information contained in the IDS was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing the certification after making reasonable inquiry, no item of IDS was known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of the IDS; or

d. Some of the items of information in the IDS were cited in a communication from a foreign patent office. Such items were first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office. As to the remaining items of information, to the knowledge of the person signing the certification after making reasonable inquiry, such remaining items were not known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of this statement.

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 4 of 6

# V. STATEMENT UNDER 37 C.F.R. § 1.704(d)(1)

		Patent Term Adjustment Reduction Should Not Apply
	The ur	idersigned hereby states:
	This In	nformation Disclosure Statement is in compliance with 37 C.F.R. §§ 1.97 and 1.98
and w	toa Ilir	be considered a failure to engage in reasonable efforts to conclude prosecution
(proce	ssing o	r examination) of the present application under 37 C.F.R. § 1.704(c)(6), (c)(8),
(c)(9),	or (e)(	10), because each item of information contained in the Information Disclosure
Staten	nent:	
		(i) Was first cited in any communication from a patent office in a counterpart
	foreign	or international application or from the Office, and this communication was not
	receive	ed by any individual designated in § 1.56(c) more than thirty days prior to the filing
	of the	information disclosure statement; or
		(ii) Is a communication that was issued by a patent office in a counterpart foreign
	or inte	mational application or by the Office, and this communication was not received by
	any in	dividual designated in § 1.56(c) more than thirty days prior to the filing of the
	inform	ation disclosure statement.
VI.	<u>FEES</u>	
	a.	This Information Disclosure Statement is being filed concurrently with the filing
of a ne	w pater	at application or Request for Continued Examination. No fee is required.
	b.	This Information Disclosure Statement is being filed within three months of the
filing o	iate of a	n application. No fee is required.
	€.	This Information Disclosure Statement is being filed before the mailing date of a
first A	ction or	the merits. No fee is required. If a first Office Action on the merits has issued,
please	conside	er this IDS under 37 C.F.R. § 1.97(c) and see the statement under 37 C.F.R.
§ 1.97(	(e) abov	e. If no statement has been made, charge our deposit account for the required fee.

d. This Information Disclosure Statement is being filed before the mailing date of a Final Office Action or before the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(c)(1)). No statement. The fee as required by 37 C.F.R. § 1.17(p) is provided. OF See the above statement. No fee is required.  $\square$ O. This Information Disclosure Statement is being filed after the mailing date of a Final Office Action or after the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(d)), see the statement above. The fee as required by 37 C.F.R. § 1.17(p) is provided. VII. PAYMENT OF FEES  $\overline{\mathbb{N}}$ The required fee is listed on the attached Fee Transmittal. No fee is required.

Application No.: 12/942,792

Docket No.: 0020-5147PUS12

Page 5 of 6

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 6 of 6

If the Examiner has any questions concerning this IDS, please contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the USPTO is requested to consider this IDS under the proper rule and charge the appropriate fee to Deposit Account No. 02-2448.

Dated: July 23, 2012	Respectfully submitted,
	By Cornio Tanasa Rog No. 64042
	D. Richard Anderson Registration No.: 40,439
	BIRCH, STEWART, KOLASCH & BIRCH, LLP 8110 Gatehouse Road, Suite 100 East P.O. Box 747 Falls Church, VA 22040-0747
A strack was and find	703-205-8000
Attachment(s):  ☑ PTO/SB/08	
☑ Document(s)	
☐ Foreign Patent Office Communication ☐ Foreign Search Report	1.

☑ Fee ☐ Other:

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.usplo.gov

# NOTICE OF ALLOWANCE AND FEE(S) DUE

BIRCH STEWART KOLASCH & BIRCH PO BOX 747 FALLS CHURCH, VA 22040-0747 EXAMINER

MUSTAPHA, ABDULFATTAH B

ART UNIT PAPER NUMBER

2812

DATE MAILED: 07/12/2012

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
12/942,792	11/09/2010	Yoshinori Shimizu	0020-5147PUS12	2357

TITLE OF INVENTION: LIGHT EMITTING DEVICE AND DISPLAY

APPLN. TYPE	SMALL ENTITY	ISSUE FEE DUE	PUBLICATION FEE DUE	PREV. PAID ISSUE FEE	TOTAL FEE(S) DUE	DATE DUE
nonprovisional	NO	\$1740	\$300	\$0	\$2040	10/12/2012

THE APPLICATION IDENTIFIED ABOVE HAS BEEN EXAMINED AND IS ALLOWED FOR ISSUANCE AS A PATENT. PROSECUTION ON THE MERITS IS CLOSED. THIS NOTICE OF ALLOWANCE IS NOT A GRANT OF PATENT RIGHTS. THIS APPLICATION IS SUBJECT TO WITHDRAWAL FROM ISSUE AT THE INITIATIVE OF THE OFFICE OR UPON PETITION BY THE APPLICANT. SEE 37 CFR 1.313 AND MPEP 1308.

THE ISSUE FEE AND PUBLICATION FEE (IF REQUIRED) MUST BE PAID WITHIN <u>THREE MONTHS</u> FROM THE MAILING DATE OF THIS NOTICE OR THIS APPLICATION SHALL BE REGARDED AS ABANDONED. <u>THIS STATUTORY PERIOD CANNOT BE EXTENDED.</u> SEE 35 U.S.C. 151. THE ISSUE FEE DUE INDICATED ABOVE DOES NOT REFLECT A CREDIT FOR ANY PREVIOUSLY PAID ISSUE FEE IN THIS APPLICATION. IF AN ISSUE FEE HAS PREVIOUSLY BEEN PAID IN THIS APPLICATION (AS SHOWN ABOVE), THE RETURN OF PART B OF THIS FORM WILL BE CONSIDERED A REQUEST TO REAPPLY THE PREVIOUSLY PAID ISSUE FEE TOWARD THE ISSUE FEE NOW DUE.

## HOW TO REPLY TO THIS NOTICE:

I. Review the SMALL ENTITY status shown above.

If the SMALL ENTITY is shown as YES, verify your current SMALL ENTITY status:

A. If the status is the same, pay the TOTAL FEE(S) DUE shown above

B. If the status above is to be removed, check box 5b on Part B - Fee(s) Transmittal and pay the PUBLICATION FEE (if required) and twice the amount of the ISSUE FEE shown above, or

If the SMALL ENTITY is shown as NO:

A. Pay TOTAL FEE(S) DUE shown above, or

B. If applicant claimed SMALL ENTITY status before, or is now claiming SMALL ENTITY status, check box 5a on Part B - Fee(s) Transmittal and pay the PUBLICATION FEE (if required) and 1/2 the ISSUE FEE shown above.

II. PART B - FEE(S) TRANSMITTAL, or its equivalent, must be completed and returned to the United States Patent and Trademark Office (USPTO) with your ISSUE FEE and PUBLICATION FEE (if required). If you are charging the fee(s) to your deposit account, section "4b" of Part B - Fee(s) Transmittal should be completed and an extra copy of the form should be submitted. If an equivalent of Part B is filed, a request to reapply a previously paid issue fee must be clearly made, and delays in processing may occur due to the difficulty in recognizing the paper as an equivalent of Part B.

III. All communications regarding this application must give the application number. Please direct all communications prior to issuance to Mail Stop ISSUE FEE unless advised to the contrary.

IMPORTANT REMINDER: Utility patents issuing on applications filed on or after Dec. 12, 1980 may require payment of maintenance fees. It is patentee's responsibility to ensure timely payment of maintenance fees when due.

### PART B - FEE(S) TRANSMITTAL

# Complete and send this form, together with applicable fee(s), to: Mail Mail Stop ISSUE FEE

Commissioner for Patents P.O. Box 1450

Alexandria, Virginia 22313-1450 (571)-273-2885

INSTRUCTIONS: This form should be used for transmitting the ISSUE FEE and PUBLICATION FEE (if required). Blocks 1 through 5 should be completed where appropriate. All further correspondence including the Patent, advance orders and notification of maintenance fees will be mailed to the current correspondence address as indicated unless corrected below or directed otherwise in Block 1, by (a) specifying a new correspondence address; and/or (b) indicating a separate "FEE ADDRESS" for

or <u>Fax</u>

maintenance fee notifications. Note: A certificate of mailing can only be used for domestic mailings of the Fee(s) Transmittal. This certificate cannot be used for any other accompanying papers. Each additional paper, such as an assignment or formal drawing, must CURRENT CORRESPONDENCE ADDRESS (Note: Use Block 1 for any change of address) have its own certificate of mailing or transmission. 07/12/2012 BIRCH STEWART KOLASCH & BIRCH Certificate of Mailing or Transmission I hereby certify that this Fee(s) Transmittal is being deposited with the United States Postal Service with sufficient postage for first class mail in an envelope addressed to the Mail Stop ISSUE FEE address above, or being facsimile transmitted to the USPTO (571) 273-2885, on the date indicated below. PO BOX 747 FALLS CHURCH, VA 22040-0747 (Depositor's name (Signature (Date APPLICATION NO. FILING DATE FIRST NAMED INVENTOR ATTORNEY DOCKET NO. CONFIRMATION NO. 2357 12/942.792 11/09/2010 Yoshinori Shimizu 0020-5147PUS12 TITLE OF INVENTION: LIGHT EMITTING DEVICE AND DISPLAY DATE DUE ISSUE FEE DUE PUBLICATION FEE DUE PREV. PAID ISSUE FEE TOTAL FEE(S) DUE APPLN, TYPE SMALL ENTITY 10/12/2012 NO \$1740 \$300 \$0 \$2040 nonprovisional **EXAMINER** ART UNIT CLASS-SUBCLASS MUSTAPHA, ABDULFATTAH B 2812 438-021000 1. Change of correspondence address or indication of "Fee Address" (37 CFR 1.363). 2. For printing on the patent front page, list (1) the names of up to 3 registered patent attorneys or agents OR, alternatively, ☐ Change of correspondence address (or Change of Correspondence Address form PTO/SB/122) attached. (2) the name of a single firm (having as a member a registered attorney or agent) and the names of up to "Fee Address" indication (or "Fee Address" Indication form PTO/SB/47; Rev 03-02 or more recent) attached. Use of a Customer Number is required. 2 registered patent attorneys or agents. If no name is listed, no name will be printed. 3. ASSIGNEE NAME AND RESIDENCE DATA TO BE PRINTED ON THE PATENT (print or type) PLEASE NOTE: Unless an assignee is identified below, no assignee data will appear on the patent. If an assignee is identified below, the document has been filed for recordation as set forth in 37 CFR 3.11. Completion of this form is NOT a substitute for filing an assignment. (B) RESIDENCE: (CITY and STATE OR COUNTRY) (A) NAME OF ASSIGNEE 4b. Payment of Fee(s): (Please first reapply any previously paid issue fee shown above) 4a. The following fee(s) are submitted: lssue Fee A check is enclosed. ☐ Publication Fee (No small entity discount permitted) Payment by credit card. Form PTO-2038 is attached. The Director is hereby authorized to charge the required fee(s), any deficiency, or credit any overpayment, to Deposit Account Number ______ (enclose an extra copy of this for Advance Order - # of Copies _ (enclose an extra copy of this form). 5. Change in Entity Status (from status indicated above) ☐ b. Applicant is no longer claiming SMALL ENTITY status. See 37 CFR 1.27(g)(2). a. Applicant claims SMALL ENTITY status. See 37 CFR 1.27. NOTE: The Issue Fee and Publication Fee (if required) will not be accepted from anyone other than the applicant; a registered attorney or agent; or the assignee or other party in interest as shown by the records of the United States Patent and Trademark Office. Authorized Signature Date Typed or printed name Registration No. This collection of information is required by 37 CFR 1.311. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process)

an application. Confidentiality is governed by 37 C.F.R. 1.311. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 12 minutes to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, Virginia 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, Virginia 22313-1450.

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# UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS

P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
12/942,792	11/09/2010 Yoshinori Shimizu		0020-5147PUS12	2357
2292 75	90 07/12/2012		EXAM	INER
	RT KOLASCH & BI	MUSTAPHA, AB	DULFATTAH B	
PO BOX 747 FALLS CHURCH.	VA 22040-0747		ART UNIT	PAPER NUMBER
	,		2812	

DATE MAILED: 07/12/2012

# **Determination of Patent Term Adjustment under 35 U.S.C. 154 (b)**

(application filed on or after May 29, 2000)

The Patent Term Adjustment to date is 0 day(s). If the issue fee is paid on the date that is three months after the mailing date of this notice and the patent issues on the Tuesday before the date that is 28 weeks (six and a half months) after the mailing date of this notice, the Patent Term Adjustment will be 0 day(s).

If a Continued Prosecution Application (CPA) was filed in the above-identified application, the filing date that determines Patent Term Adjustment is the filing date of the most recent CPA.

Applicant will be able to obtain more detailed information by accessing the Patent Application Information Retrieval (PAIR) WEB site (http://pair.uspto.gov).

Any questions regarding the Patent Term Extension or Adjustment determination should be directed to the Office of Patent Legal Administration at (571)-272-7702. Questions relating to issue and publication fee payments should be directed to the Customer Service Center of the Office of Patent Publication at 1-(888)-786-0101 or (571)-272-4200.

# **Privacy Act Statement**

The Privacy Act of 1974 (P.L. 93-579) requires that you be given certain information in connection with your submission of the attached form related to a patent application or patent. Accordingly, pursuant to the requirements of the Act, please be advised that: (1) the general authority for the collection of this information is 35 U.S.C. 2(b)(2); (2) furnishing of the information solicited is voluntary; and (3) the principal purpose for which the information is used by the U.S. Patent and Trademark Office is to process and/or examine your submission related to a patent application or patent. If you do not furnish the requested information, the U.S. Patent and Trademark Office may not be able to process and/or examine your submission, which may result in termination of proceedings or abandonment of the application or expiration of the patent.

The information provided by you in this form will be subject to the following routine uses:

- 1. The information on this form will be treated confidentially to the extent allowed under the Freedom of Information Act (5 U.S.C. 552) and the Privacy Act (5 U.S.C 552a). Records from this system of records may be disclosed to the Department of Justice to determine whether disclosure of these records is required by the Freedom of Information Act.
- 2. A record from this system of records may be disclosed, as a routine use, in the course of presenting evidence to a court, magistrate, or administrative tribunal, including disclosures to opposing counsel in the course of settlement negotiations.
- 3. A record in this system of records may be disclosed, as a routine use, to a Member of Congress submitting a request involving an individual, to whom the record pertains, when the individual has requested assistance from the Member with respect to the subject matter of the record.
- 4. A record in this system of records may be disclosed, as a routine use, to a contractor of the Agency having need for the information in order to perform a contract. Recipients of information shall be required to comply with the requirements of the Privacy Act of 1974, as amended, pursuant to 5 U.S.C. 552a(m).
- 5. A record related to an International Application filed under the Patent Cooperation Treaty in this system of records may be disclosed, as a routine use, to the International Bureau of the World Intellectual Property Organization, pursuant to the Patent Cooperation Treaty.
- 6. A record in this system of records may be disclosed, as a routine use, to another federal agency for purposes of National Security review (35 U.S.C. 181) and for review pursuant to the Atomic Energy Act (42 U.S.C. 218(c)).
- 7. A record from this system of records may be disclosed, as a routine use, to the Administrator, General Services, or his/her designee, during an inspection of records conducted by GSA as part of that agency's responsibility to recommend improvements in records management practices and programs, under authority of 44 U.S.C. 2904 and 2906. Such disclosure shall be made in accordance with the GSA regulations governing inspection of records for this purpose, and any other relevant (i.e., GSA or Commerce) directive. Such disclosure shall not be used to make determinations about individuals.
- 8. A record from this system of records may be disclosed, as a routine use, to the public after either publication of the application pursuant to 35 U.S.C. 122(b) or issuance of a patent pursuant to 35 U.S.C. 151. Further, a record may be disclosed, subject to the limitations of 37 CFR 1.14, as a routine use, to the public if the record was filed in an application which became abandoned or in which the proceedings were terminated and which application is referenced by either a published application, an application open to public inspection or an issued patent.
- 9. A record from this system of records may be disclosed, as a routine use, to a Federal, State, or local law enforcement agency, if the USPTO becomes aware of a violation or potential violation of law or regulation.

	Application No.	Applicant(s)
Notice of Allowability	12/942,792 <b>Examiner</b>	SHIMIZU ET AL.  Art Unit
•		
	ABDULFATTAH MUSTAPHA	2812
The MAILING DATE of this communication appears All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIOF of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in this ap or other appropriate communicatio GHTS. This application is subject	oplication. If not included n will be mailed in due course. <b>THIS</b>
1. $\square$ This communication is responsive to <u>05/30/2012</u> .		
<ol> <li>An election was made by the applicant in response to a rest the restriction requirement and election have been incorporate</li> </ol>		the interview on;
3. ☑ The allowed claim(s) is/are <u>1-19</u> .		
4. ☑ Acknowledgment is made of a claim for foreign priority under a) ☑ All b) ☐ Some* c) ☐ None of the:		
1. Certified copies of the priority documents have		
2. Certified copies of the priority documents have	• • • • • • • • • • • • • • • • • • • •	
3. Copies of the certified copies of the priority do	cuments have been received in this	national stage application from the
International Bureau (PCT Rule 17.2(a)).		
* Certified copies not received:		
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		complying with the requirements
5. A SUBSTITUTE OATH OR DECLARATION must be submit INFORMAL PATENT APPLICATION (PTO-152) which give		
6. CORRECTED DRAWINGS ( as "replacement sheets") must	t be submitted.	
(a) ☐ including changes required by the Notice of Draftspers	on's Patent Drawing Review (PTO	9-948) attached
1) ☐ hereto or 2) ☐ to Paper No./Mail Date		
(b) ☐ including changes required by the attached Examiner's Paper No./Mail Date	s Amendment / Comment or in the	Office action of
Identifying Indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in t		
<ol> <li>DEPOSIT OF and/or INFORMATION about the deposit of B attached Examiner's comment regarding REQUIREMENT FC</li> </ol>		
Attachment(s) 1. ☐ Notice of References Cited (PTO-892)	5. ☐ Notice of Informal I	Patent Application
2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948)	 6.	• •
O. M. Information Disclarate Obstanting (DTO/OD/OD)	Paper No./Mail Da	ate
<ol> <li>Information Disclosure Statements (PTO/SB/08), Paper No./Mail Date 04/05/2012 and 01/20/2012</li> </ol>	7. ☐ Examiner's Amend	Imen/Comment
4.   Examiner's Comment Regarding Requirement for Deposit	8. 🛛 Examiner's Statem	ent of Reasons for Allowance
of Biological Material	9.	
	<u> </u>	
	/Charles D. Garber/	
	Supervisory Patent Ex	aminer, Art Unit 2812

Art Unit: 2812

# **DETAILED ACTION**

# Response to Arguments

Applicant's arguments, see Applicant Arguments/ Remarks, filed 05/30/2012, with respect to Non-Final Rejection have been fully considered and are persuasive. The Non-Final Rejection of 01/30/2012 has been withdrawn.

# Allowable Subject Matter

Claims 1 – 19 are allowed.

The following is an examiner's statement of reasons for allowance:

The closest prior art known by the Examiner are listed on the PTO 892, IDS forms of record.

None of the prior art found by the examiner anticipate or make obvious the claimed;

"preparing a light emitting component having an active layer of a semiconductor, said active layer comprising a gallium nitride based semiconductor containing indium and being capable of emitting a blue color light having a spectrum with a peak wavelength within the range from 420 to 490 nm; preparing a phosphor capable of absorbing a part of the blue color light emitted from said light emitting component and emitting a yellow color light having a broad emission spectrum comprising a peak wavelength existing around the range from 510 to 600 nm and a tail continuing beyond 700 nm, wherein selection of said phosphor is controlled based on an emission wavelength of said light emitting component and

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combining said light emitting component and said phosphor so that the blue color light from said light emitting component and the yellow color light from said phosphor are mixed to make a white color light", as required by Claim 1 and dependent Claims thereof.

Since the reference either singly or in combination do not show all elements of the claims, the subject matter of the claims is properly allowable.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

## Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to ABDULFATTAH MUSTAPHA whose telephone number is (571)272-9736. The examiner can normally be reached on Monday, Tuesday, Wednesday, and Friday. (06:00am - 4:00pm).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Charles Garber can be reached on 571-272-2194. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Application/Control Number: 12/942,792 Page 4

Art Unit: 2812

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/Abdulfattah Mustapha/ Examiner, Art Unit 2812

/Charles D. Garber/ Supervisory Patent Examiner, Art Unit 2812

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		Application Number	<b>₩₩</b> 12/942792			
	INFORMATION DISCLOSURE			Filing Date	Concurrently Herewith 11/09/2	2010
STATEMENT BY APPLICANT		First Named Inventor	Yoshinori SHIMIZU			
411-				Art Unit	<b>WA</b> 2812	
(Use as many sheets as necessary)		Examiner Name	Net-Yet-Assigned Mustapha			
Sheet	1	of	12	Attorney Docket Number	0020-5147PUS12	

			U.S. PA	TENT DOCUMENTS	
Examiner Initials*	Cite No.1	Document Number  Number-Kind Code ² ( if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
/A.M.	AA*	US-5,700,713-A	12-23-1997	Yamazaki et al.	3
	AB*	US-5,257,049	10-26-1993	Van Peteghem	
	AC*	US-6,812,500	11-02-2004	Reeh et al.	
00000000	AD*	US-2001-0030326- A1	10-18-2001	Reeh et al.	
	AE*	US-6,576,930	06-10-2003	Reeh et al.	
	AF*	US-6,784,511	08-31-2004	Kunihara et al.	
	AG*	US-6,066,861	05-23-2000	Hohn et al.	
	AH"	US-5,959,316	09-28-1999	Lowery	
	Al*	US-5,118,985-A	06-02-1992	Patton et al.	
	AJ*	US-4,644,223	02-17-1987	de Hair et al.	
_ Š	AK*	US-6,538,371	03-25-2003	Duggal et al.	
	AL*	US-3,875,456	04-01-1975	Kano et al.	
	AM*	US-3,510,732	05-05-1970	R.L. Amans	
	AN"	US-5,550,657	08-27-1996	Tanaka et al.	
8	AO*	US-5,578,839	11-26-1996	Nakamura et al.	
	AP*	US-6,004,001-A	12-21-1999	Noll	
	AQ*	US-4,905,060	02-27-1990	Chinone et al.	
ě	AR*	US-3,652,956		Pinnow et al.	
/A.M./	AS*	US-4,314,910	02-09-1982	Barnes	

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Initials*	No.1	Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)	Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Where Relevant Passages Or Relevant Figures Appear	T ⁶
<u>/A.M</u>	/ BA	JP-2002-270020-A	09-20-2002	CASIO COMPUTER CO LTD		
	BB	JP-7-321407	12-08-1995	FUJI ELECTRIC CO LTD.		
	BC	JP-6-115158		AGFA GEVAERT NV		$\vdash$
	BD	JP-61-158606	07-18-1986			$\vdash \vdash$
800	BE	JP-2000-512806-A	09-26-2000			
<u>/A.M.</u>	BF	JP-07-288341		NICHIA CHEM IND LTD		

Examiner			
	/Abdulfattah Mustapha/	Date	27107/70/7
Signature	Tribaunattan Mustapha	Considered	07/02/2012

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. * CITE NO.: Those application(s) which are marked with an single asterisk (*) next to the Cite No. are not supplied (under 37 CFR 1.98(a)(2)(iii)) because that application was filed after June 30, 2003 or is available in the IFW. ¹ Applicant's unique citation designation number (optional). ² See Kinds Codes of USPTO Patent Documents at <a href="www.uspto.gov">www.uspto.gov</a> or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.



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				Application Number	NEW 12/942792	
			CLOSURE	Filing Date	Concurrently Herewith 11/09/20	
ST	STATEMENT BY APPLICANT			First Named Inventor	Yoshinori SHIMIZU	
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	(Use as many sheets as necessary)			Examiner Name	Not Yot Accigned Mustapha	
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Initials*	No.1	Number-Kind Code ² ( if known)	MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Relevant Passages or Relevant Figures Appear
_/A.M./	AT*	US-5,006,908	04-09-1991	Matsuoka et al.	
000	AU*	US-5,369,289	11-29-1994	Tamaki et al.	
-8	AV*	US-4,727,283	02-23-1988	van Kemenade et al.	
-	AW*	US-4,298,820	11-03-1981	Bongers et al.	
	AX*_	US-3,699,478	10-17-1972	Pinnow et al.	
	AY*	US-5,798,537	08-25-1998	Nitta	
	AZ*	US-5,202,777	04-13-1993	Sluzky et al.	
000	AA1*	US-3,819,974	06-25-1974	Stevenson et al.	
<b>XXXX</b>	AB1*	US-5,847,507	12-08-1998	Butterworth et al.	
20000	AC1*	US-3,691,482	09-12-1972	Pinnow et al.	
2000	AD1*	US-4,550,256	10-29-1985	Berkstesser et al.	
980	AE1*	US-4,716,337	12-29-1987	Huiskes et al.	
.gg000	AF1*	US-5,471,113	11-28-1995	De Backer et al.	
2000	AG1*	US-5,825,125-A	10-20-1998	Ligthart et al.	
98900	AH1*	US-5,602,418-A	02-11-1997	Imai et al.	
	Al1"	US-5,998,925-A	12-07-1999	Shimizu et al.	
0000	AJ1*	US-6,069,440-A	05-30-2000	Shimizu et al.	
00072	AK1*	US-6,608,332-B2	08-19-2003	Shimizu et al.	
/A.M./	AL1*	US-6,614,179-B1	09-02-2003	Shimizu et al.	

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/A.M./	BG	JP-5-226676	03-09-1993	SHARP CORP				
	ВН	JP-49-122292	11-22-1974					
800	BI	JP-11-500584	01-12-1999					
	BJ	JP-8-78727-A	03-22-1996					
000	BK	JP-03-152898-A	06-28-1991					
/A.M./	BL	JP-06-139973-A	05-20-1994					

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	/Abdulfattah Mustapha/	l Date	07/02/2012
Signature		Considered	07/02/2012
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/A.M./		US-7,329,988-B2	02-12-2008	Shimizu et al.	
	AN1*	US-7,126,274-B2	10-24-2006	Shimizu et al.	
	AO1*	US-7,026,756-B2	04-11-2006	Shimizu et al.	
	AP1*	US-7,215,074-B2	05-08-2007	Shimizu et al.	
	AQ1*	US-7,071,616-B2	07-04-2006	Shimizu et al.	
	AR1*	US-7,531,960-B2	05-12-2009	Shimizu et al.	
	AS1*	US-7,362,048-B2	04-22-2008	Shimizu et al.	
	AT1*	US-5,949,182	09-07-1999	Shealy et al.	
	AU1*	US-3,748,548	07-24-1973	Haisty et al.	
	AV1*	US-5,512,210	04-30-1996	Sluzky et al.	
	AW1*	US-5,630,741	05-20-1997	Potter	
2000	AX1*	US-4,857,228	08-15-1989	Kabay et al.	
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	AA2*	US-5,208,462	05-04-1993	O'Connor et al.	
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900	AD2*	US-6,600,175	07-29-2003	Baretz et al.	
/A.M.	/AE2*	US-20100001258	01-07-2010	Shimizu et al.	

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<u>/A.M./</u>	ВМ	EP-0 500 937-A1	09-02-1992			-			
	BN	JP-2001-320094-A	11-16-2001			_			
	ВО	DE-3804293-A1	08-24-1989						
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Sheet	4	of	12	Attorney Docket Number	0020-5147PUS12	

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Examiner	Cite	Document Number	Publication Date	No.	Pages, Columns, Lines, Where
Initials*	No.1	Number-Kind Code ² ( if known)	MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Relevant Passages or Relevant Figures Appear
	AF2*	US-20090315015	12-24-2009	SHIMIZU et al.	
	AG2*	US-5,221,984	06-22-1993	Furuyama et al.	
	AH:2*	US-5,594,751	01-14-1997	Scott	
	Al2*	US-5,801,435	09-01-1998	Otsuki	
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	BT	JP-59-30107-U	02-24-1984			$\vdash$
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. * CITE NO. Those application(s) which are marked with an single asterisk (*) next to the Cite No. are not supplied (under 37 CFR 1 98(a)(2)(iii)) because that application was filed after June 30, 2003 or is available in the IFW. ¹ Applicant's unique citation designation number (optional). ² See Kinds Codes of USPTO Patent Documents at <a href="www.uspto.gov">www.uspto.gov</a> or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.



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Sub	stitute for form 1449/P	то		Complete if Known			
				Application Number	<b>NEW</b> 12/942792		
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S	TATEMEN	T BY A	PPLICANT	First Named Inventor	Yoshinori SHIMIZU		
	<b>(1100 00</b> 000 000 000			Art Unit	<b>MA</b> 2812		
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Sheet	5	of	12	Attorney Docket Number	0020-5147PUS12		

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Examiner nitials*	Cite No. ¹	Foreign Patent Document	Publication Date	Name of Patentee or	Pages, Columns, Lines, Where Relevant Passages	
/A.M.		Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)	MM-DD-YYYY	Applicant of Cited Document	Or Relevant Figures Appear	
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STA	STATEMENT BY APPLICANT			First Named Inventor	Yoshinori SHIMIZU
	(Uso as man	. abaata		Art Unit	<b>***</b> 2812
	(Use as many sheets as necessary)			Examiner Name	Not Yet Assigned Mustapha
Sheet	6	of	12	Attorney Docket Number	0020-5147PUS12

		FORE	GN PATENT D	OCUMENTS		
Examiner Initials*	Cite	Foreign Patent Document  Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)	Publication Date	Name of Patentee or	Pages, Columns, Lines, Where Relevant Passages	,
7A NA		· · · · · · · · · · · · · · · · · · ·	MM-DD-YYYY	Applicant of Cited Document	Or Relevant Figures Appear	T
/A.M.		JP-863119	03-08-1996			┢
	BP2	JP-10036835-A	02-10-1998			<u> </u>
	BQ2	JP-49106283	12-27-1972			┢
	BR:2	JP-5245181	10-14-1977			┢
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9	BU:2	JP-5472484	11-07-1978			<u> </u>
	BV2	JP-5950445	04-01-1984			┢
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/A.M./	BM4	EP-0-550-937-A1	09-02-1992			<u> </u>

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Substitu	ite for form 1449/PTO			Complete if Known		
				Application Number	<b>WEW</b> 12/942792	
			SCLOSURE	Filing Date	Concurrently Herewith 11/09/	
STA	STATEMENT BY APPLICANT			First Named Inventor	Yoshinori SHIMIZU	
	411			Art Unit	<b>144</b> 2812	
	(Use as many sheets as necessary)			Examiner Name	Nustapha Mustapha	
Sheet	7	of	12	Attorney Docket Number	0020-5147PUS12	

Examiner Initials	Cile No. ¹	NON PATENT LITERATURE DOCUMENTS  Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	<b>T</b> ²
/A.M.	CA	"White LED lamp: Efficient light-emitting; Manufacture cost half", Nikkei Sangyo Shimbun, September 13, 1996, Published by Nihon Keizai Shimbunsha.	
×00000000	СВ	"SIMENS SMT-TOPLED fur die Oberflachenmontage" Frank Mollmer et al. Simens Components, 29 (1991) Hfet 4. Assume December, 1991	
<b>В</b>	СС	"Proceedings of the Institute of Phosphor Society", Translation of pages 1, 5 to 14 of the 264th Proceedings of the Institute of Phosphor Society, Nov. 29, 1996.	
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Abdulfattah Mustapha/	Date	
/Abdullatian Mustapha/	Date	07/00/0040
Signature	Considered	07/02/2012

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¹Applicant's unique citation designation number (optional). ²Applicant is to place a check mark here if English language Translation is attached.



Complete if Known Substitute for form 1449/PTO 12/942792 ₩₩ Application Number **INFORMATION DISCLOSURE** Filing Date Consumently Herowith 11/09/2010 STATEMENT BY APPLICANT First Named Inventor Yoshinori SHIMIZU **N/A** 2812 Art Unit (Use as many sheets as necessary) Examiner Name Net Yet Assigned Mustapha Sheet 8 of 12 Attorney Docket Number 0020-5147PUS12

		NON PATENT LITERATURE DOCUMENTS  Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of			
Examiner nitials	Cite No. ¹	the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	<b>T</b> ²		
/A.M.	/CK	W.W. Holloway, Jr. et at., "Optical Properties of Cerium-Activated Garnet Crystals", 1969 Journal of the Optical Society of America, Vol. 59, No. 1, pp. 60-63 Assume 12/1969			
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Signature		Considered	07/02/2012
	<del></del>	Considered	01/02/2012

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¹Applicant's unique citation designation number (optional). ²Applicant is to place a check mark here if English language Translation is attached.

Substitute for form 1449/PTO				Complete if Known		
				Application Number	NEW 12/942792	
INF	ORMATIC	ON DIS	SCLOSURE	Filing Date	Concurrently Herewith 11/09/201	
STA	ATEMEN'	T BY A	PPLICANT	First Named Inventor	Yoshinori SHIMIZU	
	<i>a</i> 1			Art Unit	N/A 2812	
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Sheet	9	of	12	Attorney Docket Number	0020-5147PUS12	

		NON PATENT LITERATURE DOCUMENTS	
Examiner Initials	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	
/A.M./	CU	Shuji NAKAMURA et al., "P-GaN/N-InGaN/N-GaN Double-Heterostructure Blue-Light-Emitting Diodes", Jpn. J. Appl. Phys. Vol. 32 (1993), pp. L8-L11, Part 2, No. 1A/B, 15, January 1993.	
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Examiner Signature	/Abdulfattah Mustapha/	Date Considered	07/02/2012
		Considered	0110212012

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Complete if Known Substitute for form 1449/PTO Application Number ₩₩₩ 12/942792 INFORMATION DISCLOSURE Filing Date Concurrently Herewith 11/09 2010 STATEMENT BY APPLICANT First Named Inventor Yoshinori SHIMIZU 2812 Art Unit (Use as many sheets as necessary) Examiner Name Not week was tapha Sheet 10 of 12 Attorney Docket Number 0020-5147PUS12

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Examiner Cite No.1  /A.M./Cl2		Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.					
		Office Action issued February 28, 2006, in U.S. Application No. 10/677,382 (U.S. Patent 7,026,756).					
	CJ2	Notice of Allowance and Examiner's Comments on Allowance issued February 13, 2008, in connection with U.S. Application No. 10/609,402 (U.S. Patent 7,362,048).					
CK2		Notice of Allowance and Examiner's Comments on Allowance issued February 11, 2009, in U.S. Application No. 11/682,014 (U.S. Patent 7,531,960).					
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Substitute for form 1449/PTO				Complete if Known		
				Application Number	NEW	
INF	ORMATIC	ON DISC	CLOSURE	Filing Date	Concurrently Herewith	
STATEMENT BY APPLICANT				First Named Inventor	Yoshinori SHIMIZU	
				Art Unit	N/A	
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Sheet	11	of	12	Attorney Docket Number	0020-5147PUS12	

		NON PATENT LITERATURE DOCUMENTS			
Examiner Initials	Cite Nc.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			
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CV2		Office Action issed October 20, 2009, in Japanese Patent Application No. 2009-065948 with partial English translation.			
CW2		Office Action issued April 4, 2007, in U.S. Application 11/653,275 (U.S. Patent 7,329,988 B2).			
CX:2		Notice of Allowance and Examiner's Comments on Allowance issued February 13, 2008, in U.S. Application No. 10/609,402 (U.S. Patent 7,362,048).			
CY2		Notice of Allowance and Examiner's Comments on Allowance issued September 25, 2007, in U.S. Application No. 11/653,275 (U.S. Patent 7,329,988).			
CZ:2		Notice of Allowance and Examiner's Comments on Allowance issued October 8, 1999, in U.S. Application No. 09/300,315 (U.S. Patent 6,069,440).			
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/A.N	¢ <b>B</b> 3	Hide et al., "White light from InGaN/conjugated polymer hybrid light-emitting diodes," Appl. Phys. Lett., Vol. 70 (20), May 19, 1997, http://apl.aip.org/apl/copyright.jsp, pp. 2664-2666.			

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¹Applicant's unique citation designation number (optional). ²Applicant is to place a check mark here if English language Translation is attached.

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				Application Number	NEW 12/942792	
INF	ORMATIC	ON DIS	CLOSURE	Filing Date	Consurrently Herewith 11/09/2	2010
STATEMENT BY APPLICANT				First Named Inventor	Yoshinori SHIMIZU	
	44			Art Unit	N/A 2812	
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Sheet	12	of	12	Attorney Docket Number	0020-5147PUS12	

Examiner Initlals	Cite No.1	NON PATENT LITERATURE DOCUMENTS  Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposlum, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			
/A.M	[/] ссз	NAKAMURA et al., "High-Brightness InGaN Blue, Green and Yellow Light-Emitting Diodes with Quantum Well Structures", Japanese Journal of Applied Physics, Vol. 34, No. 7A, Part 2, July 1, 1995, pp. L797-L799 XP000702022			
000000000000000000000000000000000000000	CD3	Non-Final Office Action issued August 2, 2010, in co-pending U.S. Application Serial No. 12/559,042.			
	CD4	Hoffman, Journal of les, pp. 89-91 (1977).	-		
8	CD5	H. Shinoda et al., Color Research & Application, Vol. 18, No. 5, October 1993, pp. 326-333.	<u> </u>		
0000000000	CD6	G. BLASSE et al., "Investigation of Some Ce3+-Activated Phosphors", Journal of Chemical Physics, Vol. 47, No. 12, 15 December 1967.			
0000000	CD7	E.F. GIBBONS et al., "Some Factors Influencing the Luminous Decay characteristics of Y3Al5O12:Ce3+", J. Electrochem. Soc., Vol. 120, No. 6, June 1973.			
	CD8	D.J. ROBBINS et al., "Lattice Defects and Energy Transfer Phenomena in Y3Al5O12:Ce3+", pp. 1004-1013, printed June 19, 2001.			
888888888888888888888888888888888888888	CD9	Bando et al., Development and applications of highbright white LED lamps, November 29, 1996, The 264 th Proceedings of the Institute of Phosphor Society, pages 4-16 of the English translation.			
	CD10	Office Action issued December 13, 2005, in U.S. Application No. 11/208,729 (U.S. Patent No. 7,215,074).			
99999999	CD11	Office Action issued March 13, 2001, in U.S. Application No. 09/458,024 (U.S. Patent No. 6,614,179).			
00000000	CD12	Office Action issued August 14, 2002, in U.S. Application No. 09/736,425 (U.S. Patent No. 6,608,332).			
9999999	CD13	Office Action issued August 19, 2005, in U.S. Application No. 10/609,402 (U.S. Patent No. 7,362,048).			
X0000000	CD14	Office Action issued July 27, 2007, in U.S. Application No. 10/609,402 (U.S. Patent No. 7,362,048).			
000000000	CD15	Office Action issued January 2, 2008, in U.S. Application No. 10/609,402 (U.S. Patent No. 7,362,048).	Ī		
000000000	CD16	Office Action issued April 8, 2005, in U.S. Application No. 10/677,382 (U.S. Patent No. 7,026,756).			
/Ā.M.	CD17	Office Action issued September 7, 2005, in U.S. Application No. 10/864,544 (U.S. Patent No. 7,126,274).	╏		

Examiner Signature	/Abdulfattah Mustapha/	Date Considered	07/02/2012
		Considered	

^{*}EXAMINER. Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹Applicant's unique citation designation number (optional). ²Applicant is to place a check mark here if English language Translation is attached.



# Search Notes



Application/Control	No.

12942792

Applicant(s)/Patent Under Reexamination

SHIMIZU ET AL.

Examiner

ABDULFATTAH MUSTAPHA

Art Unit

2812

## **SEARCHED**

Class	Subclass	Date	Examiner
438	21-27	12/16/2011	MBA
257	98,E33.044, E33.059	12/16/2011	MBA
349	69-105	12/16/2011	MBA
438	Search updated	6/14/2012	MBA
257	Search updated	6/14/2012	MBA
349	Search updated	6/14/2012	MBA

## **SEARCH NOTES**

Search Notes	Date	Examiner
East search	12/16/2011	MBA
References and suggestions provided by SPE C. Garber.	12/30/2011	MBA
Search updated.	6/14/2012	MBA

#### **INTERFERENCE SEARCH**

Class	Subclass	Date	Examiner
	See report.	12/16/2011	MBA
	Report updated.	6/14/2012	MBA

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	Application/Control No.	Applicant(s)/Patent Under Reexamination
Index of Claims	12942792	SHIMIZU ET AL.
	Examiner	Art Unit
	ABDULFATTAH MUSTAPHA	2812

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	CLA	.IM	DATE												
Fi	inal	Original	12/29/2011	06/14/2012											
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		2	<b>√</b>	=											

# Issue Classification

Application/Control No.	Applicant(s)/Patent Under Reexamination
12942792	SHIMIZU ET AL.
Examiner	Art Unit
ABDULFATTAH MUSTAPHA	2812

ORIGINAL										INTERNATIONAL	CLA	SSI	FIC	ATI	ON
	CLASS SUBCLASS								С	LAIMED		NON-CLAIMED			
438			21			Н	0	1	L	21 / 00 (2006.0)					
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CLASS	SU	BCLASS (ON	NE SUBCLAS	SS PER BLC	OCK)										
438	21	27													
257	E33.044	E33.059	99												
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☐ Claims renumbered in the same order as presented by applicant									СР	Α [	] T.D.		R.1.	47	
Final	Original	Final	Original	Final	Original	Final	Original	Final	Original	Final	Original	Final	Original	Final	Original
	1		17												
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/ABDULFATTAH MUSTAPHA/ Examiner.Art Unit 2812	06/14/2012	Total Claims Allowed:				
(Assistant Examiner)	(Date)	13				
/CHARLES GARBER/ Supervisory Patent Examiner.Art Unit 2812	06/18/2012	O.G. Print Claim(s)	O.G. Print Figure			
(Primary Examiner)	(Date)	1	1			

## **EAST Search History**

## **EAST Search History (Prior Art)**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	488	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:32
S2	17750983	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:33
S3	47	S1 and S2	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:34
S4	53731	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:35
S5	0	S3 and S4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:35
S6	464	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:36
S7	13	S1 and S6	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:37
S8	36	("20010030326"   "3510732"	US-PGPUB;	<b>A</b> DJ	ON	2009/03/09

		"3652956"   "3691482"   "3699478"   "3819974"   "3875456"   "4298820"   "4314910"   "4550256"   "4644223"   "4716337"   "5118985"   "5202777"   "5257049"   "5369289"   "5471113"   "5550657"   "5578839"   "5825125"   "5847507"   "5959316"   "6004001"   "6066861"   "6340824"   "6784511"   "6798537"   "6812500").PN.	USPAT; USOCR			09:40
<b>S</b> 9	0	S1 and S8	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:41
S10	2	S6 and S8	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:41
S11	1	"20080138918".pn.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/09 09:43
S12	33641	((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:44
S13	159	S12 and S6	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:44
S14	11	S13 and S2	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:44
S15	3726370	(oxide or ammonium or fluoride or aluminum)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:47
S16	2125	(ammonium adj3 fluoride) and (aluminum adj3 oxide)	US-PGPUB; USPAT;	<b>A</b> DJ	ON	2009/03/09 09:48

			USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
S17	2125	S15 and S16	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:48
S18	47	S6 and S17	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:49
S19	2	S1 and S18	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:49
S20	35	("20010030326"   "3510732"   "3652956"   "3691482"   "3699478"   "3819974"   "3875456"   "4298820"   "4314910"   "4550256"   "4644223"   "4716337"   "4727283"   "4905060"   "5006908"   "5118985"   "5202777"   "5257049"   "5369289"   "5471113"   "5550657"   "5578839"   "5602418"   "5798537"   "5825125"   "5847507"   "5959316"   "6004001"   "6066861"   "6340824"   "6538371"   "6576930"   "6784511"   "6812500").PN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/09 09:55
S21	1	"4644223".pn.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/09 09:56
S22	24	("2143077"   "3294699"   "3595802"   "3925239"   "4174294"   "4319161").PN. OR ("4644223").URPN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/09 09:56
\$23	334	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 10:00
S24	13	S6 and S23	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 10:00

S25	0	S24 and S2	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 10:00
S26	17750983	@ad< "19970331" or @rlad< "19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:40
S27	464	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:40
S28	334	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:40
S29	13	\$27 and \$28	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:40
S30	0	S26 and S29	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:40
S31	13476	((light adj3 emit\$3) or LED) same nitride	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:42
S32	1482	S26 and S31	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:42
S33	0	S32 and S27	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO;	ADJ	ON	2009/03/09 19:43

			DERWENT; IBM_TDB			
S34	53731	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:43
S35	7	S32 and S34	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:43
S36	7	\$35 and \$35	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:45
S37	7	S35 and S31	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:45
S38	0	S37 and S33	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:45
S39	15	("56016584" "60011069" "3748548" "105061" "4857228" "4991941" "19910307").pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/09 19:49
S40	1833	((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:51
S41	32	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:04
S42	32	S40 and S41	US-PGPUB; USPAT; USOCR;	ADJ	ON	2009/03/09 20:05

			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S43	0	S26 and S42	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:05
S44	696	(light adj3 emit\$3) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:08
S45	9	S26 and S44	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:08
S46	3726370	(oxide or ammonium or fluoride or aluminum)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:58
S47	2125	(ammonium adj3 fluoride) and (aluminum adj3 oxide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:58
S48	2125	S46 and S47	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:58
S49	47	S27 and S48	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:58
S50	86160	fir\$3 near3 (oxide or (ammonium adj3 fluoride) or (aluminum adj3 oxide))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:00
S51	45	S49 and S50	US-PGPUB;	<b>A</b> DJ	ON	2009/03/09

			USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			21:01
S52	0	S26 and S51	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:01
S53	27176	S26 and S50	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:02
S54	89	S53 and S48	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:03
S55	25	fir\$3 near3 (oxide and (ammonium fluoride) and (aluminum oxide))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:05
S56	1	S26 and S55	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:06
S57	1945	dissolv\$3 near5 stoichiometric\$3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:08
S58	1279	S34 and S57	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:08
S59	674	S26 and S58	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;	ADJ	ON	2009/03/09 21:08

			IBM_TDB			
S60	11	S53 and S59	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:09
S61	49	("4924612" "6139162" "5907373" "6014489" "4772780" "5729024" "5786665" "5818062" "5929436" "6036328" "6094404" "5462164" "5519519" "5671028" "5828302" "6102545" "6215535" "6215535" "4405858" "4807026" "4840137" "4864144" "4865196" RE34411 "5266811" "5398170" "5410212" "5467216" "5573107" "5757447" "5841154" "6048071" "6231200" "6249370" "4250575" "4251142" "4259963" "4340292" "4494874" "4616293" "4814948" "4875074" "4916478" "5219418" "5319414" "5408296" "5459000" "5459505" "5471050" "5510869").pn.	US-PGPUB; USPAT; USOCR	OR	ON	2009/03/09 21:44
S62	0	blue color near5 (420-490) adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 18:58
S63	210	blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 18:59
S64	184	blue color near5 ("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:01
S65	5	S63 and S64	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:02
S66	2	phosphor near5 blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:28
S67	788	(light adj3 emit\$3) same (phosphor	US-PGPUB;	ADJ	ON	2009/10/12

		and nitri\$3)	USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			19:30
S68	14	S63 and S67	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:30
S69	16927698	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:33
S70	0	S68 and S69	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:33
S71	14	S68 and S67	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:34
S72	41	S63 and S69	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	ON	2009/10/12 19:35
S73	O	S64 and S72	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:35
S74	733	NICHIA CORPORATION.as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:43
S75	12	NICHIA KAGAKU KOGYO KABUSHIKI KAISHA.as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;	ADJ	ON	2009/10/12 19:43

	***************************************		IBM_TDB			
S76	745	S74 or S75	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	<b>A</b> DJ	ON	2009/10/12 19:44
S77	0	S72 and S76	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	<b>A</b> DJ	ON	2009/10/12 19:44
S78	O	Yoshinori Shimizu.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:46
S79	0	Kensho Sakano.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	<b>A</b> DJ	ON	2009/10/12 19:46
S80	O	Yasunobu Noguchi.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:47
S81	0	Toshio Moriguchi.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	<b>A</b> DJ	ON	2009/10/12 19:47
S89	12	("5798537" "5998925" "6069440" "6608332" "6614179" "7026756" "7071616" "7126274" "7215074" "7329988" "7362048" "7531960").pn.	US-PGPUB; USPAT; USOCR	OR	ON	2009/11/23 09:03
S90	36867	((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:09
S91	12	S90 and S89	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;		ON	2009/11/23 09:09

L			IBM_TDB			
S92	2163	((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:10
S93	40	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:10
S94	40	S92 and S93	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:10
S95	0	S94 and S91	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:10
S96	188	blue color near5 ("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:11
S97	0	S96 and S91	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:11
S98	212	blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:13
S99	0	S98 and S91	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:13
S100	321	blue color near5 (wavelength or wave length) same ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480"	US-PGPUB; USPAT; USOCR; FPRS;	ADJ	ON	2009/11/23 09:14

		or "485" or "490") adj (nm or nanometre or nano meter or ANG)	EPO; JPO; DERWENT; IBM_TDB			
S101	358	blue color near5 (wavelength or wave length) same ("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:15
S102	1	S100 and S91	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:15
S103	1	S101 and S91	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:15
S104	16928194	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:33
S105	0	S94 and S104	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:33
S106	745	NICHIA CORPORATION.as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:39
S107	12	NICHIA KAGAKU KOGYO KABUSHIKI KAISHA.as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:39
S108	757	S106 or S107	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:39
S109	757	S106 or S107	US-PGPUB;	<b>A</b> DJ	ON	2009/11/23

			USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			09:40
S110	9	S100 and S109	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:40
S111	5	S101 and S109	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:40
S112	10	S110 or S111	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:40
S113	0	S112 and S104	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:41
S114	17759950	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:20
S115	520	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:21
S116	460	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:21
S117	13	S115 and S116	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;	ADJ	ON	2010/05/31 14:21

			IBM_TDB			
S118	0	S117 and S114	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:21
S119	104	(LED or light emit\$3) near5 spectrum near3 ("420" or "430" or "440" or "450" or "460" or "470" or "480" or "490" or "500" or "510" or "520" or "530" or "540" or "550" or "560" or "570" or "580" or "590" or "600" or "610" or "620" or "630" or "640" or "650" or "660" or "670" or "680" or "690" or "700") adj (nm or nano meter or nano metre)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:28
S120	15	S114 and S119	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:29
S121	2506	spectrum near3 phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:29
S122	2	S120 and S121	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		ON	2010/05/31 14:29
S123	108	("20010030326"   "3510732"   "3652956"   "3691482"   "3699478"   "3748548"   "3819974"   "3875456"   "4298820"   "4314910"   "4550256"   "4644223"   "4716337"   "4727283"   "4857228"   "4905060"   "5006908"   "5118985"   "5202777"   "5257049"   "5369289"   "5471113"   "5512210"   "5550657"   "5578839"   "5602418"   "5630741"   "5700713"   "5798537"   "5825113"   "5847507"   "5949182"   "5959316"   "5998925"   "6004001"   "6066511"   "6069440"   "6340824"   "6538371"   "6576930"   "6608332"   "6614179"   "6784511"   "6798537"   "6812500"   "7026756"   "7071616"   "7126274"   "7215074"   "7329988"   "7362048"   "7531960").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:32
S124	4.6	((light adj3 emit\$3) or LED) near5 transparent material	US-PGPUB; USPAT;	<b>A</b> DJ	ON	2010/05/31 14:34

			USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
S125	0	S123 and S124	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:34
S126	5	S124 and S121	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:35
S127	0	S120 and S126	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:35
S128	2458	((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:36
S129	46	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:36
S130	46	S128 and S129	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:36
S131	49415	(LCD or liquid crystal display) same color filter	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:37
S132	4	S119 and S131	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:37

S133	236146	"257"/\$	US-PGPUB;	<b>A</b> DJ	ON	2010/05/31
			USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			14:38
S134	195807	"438"/\$	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:38
S135	115041	S133 and S134	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:39
S136	46352	"349"/\$	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:39
S137	3373	S135 and S136	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:39
S138	125801	"359"/\$	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:39
S139	64206	"313"/\$	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:39
S140	3125	S138 and S139	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:40
S141	186	S131 and S140	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO;	ADJ	ON	2010/05/31 14:40

			DERWENT; IBM_TDB			
S142	18	S137 and S141	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:40
S143	111	S128 and S131	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:40
S144	1	S142 and S143	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:41
S145	8649	349/69-105.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:07
S146	1822	S131 and S145	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:07
S147	17	S119 and S121	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:08
S148	0	S146 and S147	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:08
S149	5106	(LCD or liquid crystal display) near3 (glass or transparent) adj (wafer or substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:11
S150	872	liquid crystal near3 (inject\$3 or introduc\$3 or dispens\$3) near5 (glass or transparent) adj (wafer or	US-PGPUB; USPAT; USOCR;	ADJ	ON	2010/05/31 15:14

		substrate)	FPRS; EPO; JPO; DERWENT; IBM_TDB			
S151	129	S149 and S150	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	ON	2010/05/31 15:14
S152	0	S119 and S151	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:15
S153	0	("10677382" "12548614" "12548620" "12559042").ap.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 17:39
S154	0	("10/677382" "12/548614" "12/548620" "12/559042").ap.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 17:40
S155	24	("677382" "548614" "548620" "559042").ap.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 17:40
S156	4	("20090315015" "20100001258" "20090315014" "7026756" "7026756").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 17:45
S157	0	"7362048.pn"	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 19:46
S158	0	"7362048.pn."	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 19:46
S159	1	"7362048".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 19:47
S160	894622	phosphor near5 transparent material same (LED or light emit\$3)	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 19:56
S161	227	blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 19:56
S162	198	blue color near5 ("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 19:56
S163	7	S161 and S162	US-PGPUB; USPAT; USOCR;	ADJ	ON	2010/06/07 19:56

			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S164	67510	("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:02
S165	137544	("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:02
S166	31514	S164 and S165	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:02
S167	13207	S160 and S166	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	ON	2010/06/07 20:02
S168	17760117	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	ON	2010/06/07 20:03
S169	16666	((light adj3 emit\$3) or LED) same nitride	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:03
S170	1488	S168 and S169	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:03
S171	5111	(LCD or liquid crystal display) near3 (glass or transparent) adj (wafer or substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:03
S172	873	liquid crystal near3 (inject\$3 or	EPO; JPO; DERWENT;	ADJ	ON	

		introduc\$3 or dispens\$3) near5 (glass or transparent) adj (wafer or substrate)	USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			20:03
S173	129	S171 and S172	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:03
S174	0	S170 and S173	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:04
S175	61	S170 and S167	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:04
S176	0	transparent adj mateial near5 (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:05
S177	1555	transparent adj material near5 (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:05
S178	0	S175 and S177	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:05
S179	2	"5700713".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/08 13:30
S180	0	bck light near5 (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;	ADJ	OFF	2010/06/08 19:27

			IBM_TDB			
S181	2980	back light near5 (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/08 19:27
S182	5397	liquid crystal near5 glass substrate	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/08 19:28
S183	40	S181 and S182	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/08 19:28
S184	17760148	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/08 19:29
S185	16932587	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/08 19:29
S186	3	S183 and S185	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		OFF	2010/06/08 19:30
S187	56	("20010030326"   "20090315014"   "20090315015"   "20100001258"   "3510732"   "3652956"   "3691482"   "3699478"   "3748548"   "3819974"   "3875456"   "4298820"   "4314910"   "4550256"   "4644223"   "4716337"   "4727283"   "4857228"   "4905060"   "5006908"   "5118985"   "5202777"   "5257049"   "5369289"   "5471113"   "5512210"   "5550657"   "5578839"   "5602418"   "5630741"   "5700713"   "5798537"   "5825125"   "5847507"   "5949182"   "5959316"   "5998925"   "6004001"   "6066861"   "6069440"   "6340824"   "6538371"   "6575930"   "6608332"   "6614179"   "6784511"   "6798537"	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/06/19 13:54

		"6812500"   "7026756"   "7071616"   "7126274"   "7215074"   "7329988"   "7362048"   "7531960").PN.				
S188	24	(diameter or radi\$3) near3 (conduct\$3 or wire) near3 ("10" or "15" or "20" or "25" or "30" or "35" or "40" or "45") adj (mu or micro or meter)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 13:59
S189	0	S187 and S188	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 14:02
S190	1	"20090315014".pn.	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/06/19 14:04
S191	55	S187 and (diameter or radi\$3 or conduct\$3 or wire or ".mu.m" or "10" or "15" or "20" or "25" or "30" or "35" or "40" or "45")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 14:08
S192	75	(LED or Light emit\$3) adj3 chip near5 conduct\$3 adj wire	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 14:44
S193	1	S187 and S192	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	OFF	2010/06/19 14:44
S194	11	("1305111" or "6340824").pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:13
S195	951	diameter near5 conduct\$3 adj wire	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:16
S196	14	S191 and S195	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO;	<b>A</b> DJ	OFF	2010/06/19 15:17

			DERWENT; IBM_TDB			
S197	168	phosphor near3 transparent material	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:18
S198	3	S196 and S197	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:18
S199	178048	shimizu.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:19
S200	161	S197 NOT S199	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:20
S201	2	("5949182" "3748548").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/19 15:28
S202	34	("2913632"   "3173101"   "3179542"   "3209214"   "3229104"   "3234057"   "3260902"   "3270235"   "3283160"   "3372069").PN. OR ("3748548").URPN.	US-PGPUB; USPAT; USOCR	<b>A</b> DJ	OFF	2010/06/19 15:28
S203	21	("3665241"   "3755704"   "3812559"   "4513308"   "5064396"     "5186670"   "5199917"   "5229331"   "5232549"   "5316979"     "5329207"   "5363021"   "5438240"   "5448132"   "5615143").PN. OR ("5949182").URPN.	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/06/19 15:30
S204	2	("5630741" "4857228").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/19 15:34
S205	2	S192 and S197	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:38
S206	16932745	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO;	ADJ	ON	2010/06/19 15:41

			DERWENT; IBM_TDB			
S207	2	S192 and \$206	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:42
S208	318	S195 and S206	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:42
S209	0	S208 and S197	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:43
S210	6	("3699478"   "5221984"   "5594751"   "5801435"   "6015200"   "6600175").PN.	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/10/21 16:00
S211	5	("4001628"   "5208462"   "5706022"   "5743629"   "6600175").PN.	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/10/21 16:09
S212	2	"6600175".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/10/24 13:21
\$213	6	("3699478"   "5221984"   "5594751"   "5801435"   "6015200"     "6600175").PN.	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/10/24 13:25
\$214	3	"3699478".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/04/21 16:56
S215	3	("4992704" "20090315014" "5045867").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2011/04/22 14:59
S216	2	("2009/0315014").URPN.	USPAT	<b>A</b> DJ	OFF	2011/04/22 14:59
\$217	581	(conduct\$3 or electric\$3) adj5 (wire or cable) with (diameter or radius or size) with (("10" "15" "20" "25" "30" "35" "40" "45") adj(".mu.m" or micro or micron or meter or metre))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/04/22 15:19
S218		@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT;	<b>A</b> DJ	ON	2011/04/22 15:20

			USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
S219	82	S217 and S218	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:20
S220	19216	((light adj3 emit\$3) or LED) same nitride	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:21
S221	1245	S218 and S220	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:22
S222	0	S219 and S221	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:22
S223	7	((light adj3 emit\$3) or LED) and S219	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:22
S224	0	(transparent\$3 or visibl\$3) adj5 material with (LED or light emit\$3 diode or light emit\$3) and \$219	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:24
S225	0	(transparent\$3 or visibl\$3) adj5 material with phosphor and \$219	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:25
\$226	2	"4992704".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/13 16:16

S227	2	"20090315015".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 11:44
S228	3	("2009/0315015").URPN.	USPAT	<b>A</b> DJ	OFF	2011/05/17 11:51
S229	550	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius) with (("10" or "15" or "20" or "25" or "30" or "35" or "40" or "45") adj (".mu.m" or micron or nm or mm))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 15:40
S230	2267282	((LCD or liquid crystal display or liquid crystal) or (LED or light emitting diode or light emit\$3) or (bak light))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 15:48
S231	227	S229 and S230	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 15:48
S232	16935137	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/05/17 15:49
S233	18	S232 and S231	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/05/17 15:50
S234	47	phosphor near3 transparent material with (light emit\$3 or LED)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 15:54
\$235	0	S233 and S234	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 15:54
S236	12	S234 and S231	US-PGPUB; USPAT; USOCR;	ADJ	ON	2011/05/17 15:54

			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S237	950368	phosphor near5 transparent material same (LED or light emit\$3)	US-PGPUB; USPAT; USOCR	OR	OFF	2011/05/17 16:55
S238	40	S234 and S237	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/05/17 16:56
S239	0	S233 and S238	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 16:57
S240	195589	S232 and S237	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/05/17 16:57
S241	6	S231 and S240	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/05/17 16:58
S242	283	(wir\$3 or (conduct\$3 adj wire)) near3 (diameter or radius) with (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 13:15
S243	74	(wir\$3 or (conduct\$3 adj wire)) near3 (diameter or radius) with (LED or light emit\$3) and @ad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 13:15
S244	74	(wir\$3 or (conduct\$3 adj wire)) near3 (diameter or radius) with (LED or light emit\$3) and @ad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 14:44
S245	13	S244 and (light emit\$3 or light emit\$3 diode or light emit\$3 display)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO;	ADJ	OFF	2011/06/03 14:44

			DERWENT; IBM_TDB			
S246	74	S244 and (LED or light emit\$3 or light emit\$3 diode or light emit\$3 display)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 14:47
S247	16	(wir\$3 or (conduct\$3 adj wire)) with (diameter or radius) with (light emit\$3 or light emit\$3 diode or light emit\$3 display) and @ad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 15:22
S248	93	(wir\$3 or (conduct\$3 adj wire) or conduct\$3) near3 (diameter or radius) with (LED or light emit\$3) and @ad< "19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 16:05
S249	122	(wir\$3 or (conduct\$3 adj wire) or conduct\$3) near3 (diameter or radi\$3) with (LED or light emit\$3) and @ad< "19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 16:05
S250	20	(wir\$3 or (conduct\$3 adj wire) or conduct\$3) near3 (diameter or radi\$3) with (light emit\$3 or light emit\$3 diode or light emit\$3 display) and @ad< "19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 16:06
S251	20	(wir\$3 or (conduct\$3 adj wire) or conduct\$3) near3 (diameter or radi\$3) with (light emit\$3 or light emit\$3 diode or light emit\$3 display) and @ad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 16:06
S252	20	\$250 and \$251	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 16:06
S253	6501	257/98.cds.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 10:27
S254	6501	(257/98).OCLS.	US-PGPUB; USPAT; USOCR;	OR	OFF	2011/06/08 10:27

			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S255	4900	(257/99).OCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/08 10:27
S256	1730	(257/100).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/08 10:29
S257	78	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and \$253	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 10:30
S258	6	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and \$253 and @ad< "19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 10:30
S259	6	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and \$254 and @ad< "19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 10:33
S260	7	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and \$255 and @ad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 10:34
S261	1	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and \$256 and @ad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 10:35
S262	0	438/106-127.ccls. and light near2 emitting near2 diode and (lead wire wiring conductor) near4 (thickness thick diameter)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 13:33
S263	56	438/106-127.ccls. and light near2	US-PGPUB;	OR	OFF	2011/06/08

		emitting near2 diode and (lead wire wiring conductor) near4 (thickness thick diameter)	USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			13:33
S264	3	("4347655" "5125153" "5885893").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2011/06/08 13:34
S265	1730	(257/100).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/08 13:35
S266	0	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and \$265 and \$264	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 13:35
S267	3	S264 and (wir\$3 or LED or light or emit\$3 or diameter or thick\$3)	US-PGPUB; USPAT; USOCR	OR	OFF	2011/06/08 13:38
S268	6501	257/98.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 13:46
S269	6501	257/98.ccls. and \$268	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 13:46
S270	119519	quantum well and S268	US-PGPUB; USPAT; USOCR	OR	OFF	2011/06/08 13:47
S271	1489	quantum well and S268	US-PGPUB; USPAT; USOCR	ADJ	OFF	2011/06/08 13:47
S272	50	quantum well and S268 and @ad< "19970331"	US-PGPUB; USPAT; USOCR	ADJ	OFF	2011/06/08 13:48
S273	25	((single or multi\$3) adj quantum well) and S268 and @ad<"19970331"	US-PGPUB; USPAT; USOCR	ADJ	OFF	2011/06/08 13:55
	27356	liquid crystal with (glass adj substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		OFF	2011/06/09 12:10
S275	11//63698	@ad<"19970331" or	US-PGPUB;	JADJ	ON	2011/06/09

		@rlad<"19970331"	USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			12:10
S276	4812	S274 and S275	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:11
\$277	6515	257/98.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:11
S278	1493	quantum well and S277	US-PGPUB; USPAT; USOCR	ADJ	OFF	2011/06/09 12:11
S279	0	S278 and S276	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:11
S280	3	S277 and S276	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:11
S281	1071	(inject\$3 or introduc\$3 or insert\$3) with liquid crystal with (glass adj substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:16
S282	0	S281 and S275 and S277	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:16
\$283	505	(inject\$3 or introduc\$3 or insert\$3) with liquid crystal with (glass adj substrate) and color filter	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:19
S284	123	S275 and S283	US-PGPUB; USPAT; USOCR;	ADJ	ON	2011/06/09 12:20

			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S285	0	S277 and S284	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:20
S286	3	(inject\$3 or introduc\$3 or insert\$3) with liquid crystal with (glass adj substrate) and color filter with (LED or light emitting diode or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:22
S287	144	(inject\$3 or introduc\$3 or insert\$3) with liquid crystal with (glass adj substrate) and color filter and (LED or light emitting diode or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:22
S288	55	\$275 and \$287	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:25
S289	7280	liquid crystal with (glass adj substrate) and color filter	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:25
S290	55	\$288 and \$289	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:25
S291	0	\$277 and \$290	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:26
	2596	liquid crystal with (glass adj substrate) with color filter	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:33
\$293	19	S290 and S292	US-PGPUB;	<b>A</b> DJ	OFF	2011/06/09

			USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			12:33
S294	17764738	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/04 17:14
S295	4	("3623867"   "3842306"   "5816677").PN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2011/11/04 17:17
S296	17764740	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:05
S297	4	("3623867"   "3842306"   "5816677").PN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2011/11/05 13:06
S298	1	("3875456").PN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2011/11/05 13:13
\$299	17764740	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:51
<b>300</b>	568	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:51
\$301	47842	((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:51
\$302	239	S301 and S300	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:51
S303	11	S302 and S299	US-PGPUB; USPAT; USOCR;	ADJ	ON	2011/11/05 13:51

			FPRS; EPO; JPO; DERWENT; IBM_TDB			
\$304	11176	phosphor with (concentrat\$3 or quatity or quality or different or mix\$3) with (LED or light or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:04
\$305	1869	S296 and S304	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:04
\$306	773	S301 and S305	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:04
\$307	21084	((light adj3 emit\$3) or LED) same nitride	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:04
\$308	984	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		ON	2011/11/05 14:05
S309	4468235	(oxide or ammonium or fluoride or aluminum)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
\$310	2933	(ammonium adj3 fluoride) and (aluminum adj3 oxide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S311	2933	S309 and S310	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S312	80	S300 and S311	US-PGPUB;	ADJ	ON	2011/11/05

			USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			14:05
S313	3	S308 and S312	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S314	12	("5798537" "5998925" "6069440" "6608332" "6614179" "7026756" "7071616" "7126274" "7215074" "7329988" "7362048" "7531960").pn.	US-PGPUB; USPAT; USOCR	OR	ON	2011/11/05 14:05
S315	47842	((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S316	12	S315 and S314	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S317	260	blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S318	961	NI CHI A CORPORATI ON. as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S319	12	NI CHI A KAGAKU KOGYO KABUSHI KI KAI SHA. as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S320	973	S318 or S319	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S321	4	("6600175" "3842306" "3875456"	US-PGPUB;	OR	OFF	2011/12/16

		"5126214").pn.	USPAT; USOCR			18:21
S322	12	("6600175" "3842306" "3875456" "5126214").pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/12/16 18:30
S323	5002	phosphor with (blue and yellow) with (LED or light or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/16 18:52
S324	16936281	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/16 18:53
S325	110	S323 and S324	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/16 18:53
S326	1681	(light emit\$3 or LED) with (gallium nitride or GaN) with wavelength	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/16 18:54
S327	7	S325 and S326	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/16 18:54
S328	12	("5798537" "5998925" "6069440" "6608332" "6614179" "7026756" "7071616" "7126274" "7215074" "7329988" "7362048" "7531960").pn.	US-PGPUB; USPAT; USOCR	OR	ON	2011/12/16 18:58
S329	48488	((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/16 18:58
S330	12	S329 and S328	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO;	ADJ	ON	2011/12/16 18:58

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S331	0	S325 and S330	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/16 18:59
S332	139566	("5847507" "5966393")".pn"	US-PGPUB; USPAT; USOCR	OR	ON	2011/12/28 12:24
S333	49511	("5847507" "5966393")".pn"	USPAT	OR	ON	2011/12/28 12:34
S334	47932	("5847507" "5966393")".pn"	USPAT	OR	OFF	2011/12/28 12:34
S335	0	("("5847507""5966393")").PN.	USPAT; USOCR	OR	OFF	2011/12/28 12:34
S336	0	("(58475075966393)").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2011/12/28 12:35
S337	0	("(58475075966393)").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2011/12/28 12:35
S338	2	(("5966393") or ("5847507")).PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2011/12/28 12:35
S340	1	("20110053299").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2011/12/28 13:38
S341	55	phosphor with crystal structure with (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 13:51
S342	0	S341 and @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 13:52
S343	0	S341 and @ad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 13:52
S344	1281	phosphor with crystal structure	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 13:54
S345	3622	((light adj3 emit\$3) or LED) same	US-PGPUB;	<b>A</b> DJ	ON	2011/1

		(phosphor and nitri\$3)	USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			13:54
S346	281	S344 and S345	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 13:54
S347	622723	@rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 13:55
S348	16808771	@ad< "19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 13:55
S349	16936334	S347 or S348	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 13:55
S350	0	S346 and S349	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	ON	2011/12/28 13:55
S351	0	S346 and S347	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 13:56
S352	0	S346 and S348	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 13:56
S353	3285	quantum well with (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;	ADJ	ON	2011/12/28 15:06

		]	IBM_TDB			
S354	538	white light with black body	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 15:18
S355	75	S353 and S354	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 15:19
S356	0	S355 and @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 15:19
S357	0	S355 and @ad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 15:19
S358	140	white light with black body with (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 15:20
S359	0	S358 and @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ		2011/12/28 15:20
S360	1	S358 and @ad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/28 15:20
S361	222	mustapha.xa.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/29 10:44
S362	222	mustapha.xa.	US-PGPUB; USPAT; USOCR; FPRS;	ADJ	ON	2011/12/29 11:55

			EPO; JPO; DERWENT; IBM_TDB	-		
S363	190021	Shimizu.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/29 11:56
S364	3	S362 and S363	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/29 11:56
S365	5	(("5998925") or ("6069440") or ("6614179") or ("7362048") or ("7682848")).PN.	USPAT; USOCR	OR	OFF	2011/12/29 11:59
S366	0	("L03orL4").PN.	USPAT; USOCR	OR	OFF	2011/12/29 12:00
S367	7	S364 or S365	USPAT	OR	OFF	2011/12/29 12:00
S368	0	phosphor with ("Al.sub.S3" adj3 "Ga.sub."\$3 adj5 "O.sub."\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	ON	2011/12/29 13:08
S369	0	phosphor with ("Al.sub.S3" near3 "Ga.sub."\$3 near3 "O.sub."\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/29 13:09
\$370	0	(fluorescent adj3 material) with ("Al.sub.S3" near3 "Ga.sub."\$3 near3 "O.sub."\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/29 13:10
\$371	0	fluore\$5 with ("Al.sub.S3" near3 "Ga.sub."\$3 near3 "O.sub."\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/29 13:10
S372		("Al.sub.S3" near3 "Ga.sub."\$3 near3 "O.sub."\$3)	USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		ON	2011/12/29 13:10
S373	0	("Al.sub.S3" near3 "Ga.sub."\$3)	US-PGPUB;	<b>A</b> DJ	ON	2011/12/29

			USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			13:11
S374	43	("Al.sub.\$3" near3 "Ga.sub."\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/29 13:11
S375	26	("Al.sub.\$3" near3 "Ga.sub."\$3 near3 "O.sub."\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/29 13:11
S376	15	phosphor with ("Al.sub.\$3" near3 "Ga.sub."\$3 near3 "O.sub."\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/29 13:11
S377	579	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/29 13:12
S378	48767	((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/29 13:12
S379	249	S378 and S377	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/29 13:12
S380	0	S379 and S376	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/29 13:12
S381	6	S376 and S378	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;	ADJ	ON	2011/12/29 13:12

IBM_TDB

# **EAST Search History (Interference)**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S82	469	NICHIA CORPORATION.as.	USPAT; UPAD	<b>A</b> DJ	ON	2009/10/12 19:51
S83	7	NICHIA KAGAKU KOGYO KABUSHIKI KAISHA.as.	USPAT; UPAD	<b>A</b> DJ	ON	2009/10/12 19:51
S84	99	blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	UPAD	ADJ	ON	2009/10/12 19:51
S85	94	blue color near5 ("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)		ADJ	ON	2009/10/12 19:51
S86	0	S82 and S83	USPAT; UPAD	<b>A</b> DJ	ON	2009/10/12 19:52
S87	1	S84 and S85	USPAT; UPAD	<b>A</b> DJ	ON	2009/10/12 19:52
S88	0	· · · · · · · · · · · · · · · · · · ·	USPAT; UPAD	ADJ	ON	2009/10/12 19:57
S339	49938	("5847507" "5966393")".pn"	USPAT; UPAD	OR	ON	2011/12/28 12:34

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PTO/SB/08a (07-09) Approved for use through 07/31/2012. OMB 0651-0031

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Substitute	for form 1449A/PT	0			Complete if Known
INIEO	INFORMATION DISCLOSURE			Application Number	12/942,792
			·	Filing Date	11-09-10
SIAI	EMENT B	Y AP	PLICANT	First Named Inventor	Yoshinori Shimizu
				Art Unit	2812
	(Use as many shee	ets as nec	essary)	Examiner Name	A.B. MUSTAPHA
Sheet	1	of	2	Attorney Docket Number	0020-5147PUS12

			U.S. PATE	NT DOCUMENTS			
Examiner initial *	Cite No.	Document Number  Number - Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, columns, Lines, Where Relevant Passages or Relevant		
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		US-2006/0067668 - A1	03-30-2006	KITA			
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		FOREIG	N PATENT DOC	UMENTS		
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Initial * No.		Country ³ Number ⁴ Kind Code (if known) ⁵	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Relevant Passages or Relevar	
/A.M./	3	JP 9-116225 - A	05-02-1997	Document	Figures Appear	V
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Examiner Signature	/Abdulfattah Mustapha/	Date	06/14/2012
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Substitute for t	orm 1449B/PTO			Complete if Known			
INFOR	MATION	חופרו	OSLIDE	Application Number	12/942,792		
	MENT BY			Filing Date	11-09-10		
SIAIL		IAFF	LICANI	First Named Inventor	Yoshinori Shimizu		
(Us	e as many sheets	s as neces	sarv)	Art Unit	2812		
,			,,	Examiner Name	A.B. MUSTAPHA		
Sheet	2	of	2	Attorney Docket Number	0020-5147PUS12		

	•	NON PATENT LITERATURE DOCUMENTS	
Examiner initial *	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issu publisher, city and/or country where published.	title of the ue number(s),
/A.M./	4	U.S. Office Action, dated January 9, 2012, for U.S. Application No. 12/947,470.	39000
/A.M./	5	U.S. Office Action, dated March 13, 2012, for U.S. Application No. 13/210,027.	
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war.	See 5 8 8 See 2 W S	mes s	771 C 347 8 1	First Named Inventor	Yoshinori Shimizu		
(0	se as many sheets a	s naces	sary)	Art Unit	2812		
 		*********		Examiner Name	A. Mustapha		
Sheet	1	of	1	Aftorney Docket Number	0020-5147PUS12		
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/A.M./	4	U.S. Office Action issued in co-pending application 12/689,681 on December 5, 2011.						
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Exam Signa		/Abdulfattah Mustapha/ Date Considered 06/14/2012	~~~~~~~~					

^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered, include copy of this form with next communication to applicant.

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^{1.} Applicants unique distribut designation number, (optional) 2. Applicant is to place a check mark here if English language Translation is attached.

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# **BIB DATA SHEET**

#### **CONFIRMATION NO. 2357**

SERIAL NUMBER FILING O		r_ 371(c)	CLASS GR		GROUP ART UNIT		ATTORNEY DOCKET				
12/942,79	2	<b>DAT</b> 11/09/2	_		257		2812		<b>NO.</b> 0020-5147PUS12		
		RUL	E								
APPLICANTS Yoshinori Shimizu, Naka-gun, JAPAN; Kensho Sakano, Anan-shi, JAPAN; Yasunobu Noguchi, Naka-gun, JAPAN; Toshio Moriguchi, Anan-shi, JAPAN;											
This appl wh wh wh wh	** CONTINUING DATA **********************************										
** <b>FOREIGN APPLICATIONS</b> ************************************											
** <b>IF REQUIRE</b> 11/19/20		EIGN FILING	G LICENS	E GRA	NTED **						
Foreign Priority claim		Yes No	☐ Met af	tor	STATE OR		HEETS	ТОТ		INDEPENDENT	
35 USC 119(a-d) conditions met   ✓ Yes   No  Verified and  /ABDULFATTAH B  MUSTAPHA/  Acknowledged  Examiner's Signature			Allowance	ince	<b>COUNTRY</b> JAPAN	DRA	19	CLAII 19		CLAIMS 1	
ADDRESS											
BIRCH STEWART KOLASCH & BIRCH PO BOX 747 FALLS CHURCH, VA 22040-0747 UNITED STATES											
TITLE											
LIGHT E	MITTIN	G DEVICE A	ND DISPL	AY							
							☐ All Fees				
	FEES: Authority has been given in Paper						☐ 1.16 Fees (Filing)				
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BIB (Rev. 05/07).

Docket No.: 0020-5147PUS12

(PATENT)

#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: Yoshinori Shimizu et al.

Application No.: 12/942,792

Filed: November 9, 2010 Art Unit: 2812

For: LIGHT EMITTING DEVICE AND DISPLAY Examiner: Abdulfattah B

**MUSTAPHA** 

Confirmation No.: 2357

## RESPONSE UNDER 37 C.F.R. § 1.111

MS Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

#### **INTRODUCTORY COMMENTS**

In response to the Office Action dated January 30, 2012, the following remarks are submitted in connection with the above-identified U.S. patent application:

A Listing of Claims begins on page 2 of this paper.

Remarks/Arguments begin on page 6 of this paper.

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#### **LISTING OF CLAIMS**

1. (Original) A method for manufacturing a light emitting device comprising:

preparing a light emitting component having an active layer of a semiconductor, said active layer comprising a gallium nitride based semiconductor containing indium and being capable of emitting a blue color light having a spectrum with a peak wavelength within the range from 420 to 490 nm;

preparing a phosphor capable of absorbing a part of the blue color light emitted from said light emitting component and emitting a yellow color light having a broad emission spectrum comprising a peak wavelength existing around the range from 510 to 600 nm and a tail continuing beyond 700 nm, wherein selection of said phosphor is controlled based on an emission wavelength of said light emitting component; and

combining said light emitting component and said phosphor so that the blue color light from said light emitting component and the yellow color light from said phosphor are mixed to make a white color light, wherein a chromaticity point of the white color light is on a straight line connecting a point of chromaticity of the blue color light and a point of chromaticity of the yellow color light, and

wherein a content of said phosphor in said light emitting device is selected to obtain a desired chromaticity of the white color light.

- 2. (Original) The method for manufacturing a light emitting device according to claim 1, wherein said phosphor comprises a garnet fluorescent material activated with cerium.
- 3. (Original) The method for manufacturing a light emitting device according to claim 1, wherein said phosphor comprises two or more kinds of fluorescent materials.

- 4. (Original) The method for manufacturing a light emitting device according to claim 1, wherein the emission spectrum of said phosphor comprises a peak wavelength existing around the range from 530 to 570 nm and a tail continuing beyond 700 nm.
- 5. (Original) The method for manufacturing a light emitting device according to claim 1, wherein said phosphor comprises an yttrium-aluminum-garnet fluorescent material containing Y and Al.
- 6. (Original) The method for manufacturing a light emitting device according to claim 1, wherein said phosphor has a crystal structure.
- 7. (Original) The method for manufacturing a light emitting device according to claim 1, wherein the active layer of said light emitting component has a single quantum well or multi quantum well structure.
- 8. (Original) The method for manufacturing a light emitting device according to claim 1, wherein the active layer of said light emitting component comprises InGaN.
- 9. (Original) The method for manufacturing a light emitting device according to claim 1, wherein said light emitting device is capable of emitting white light substantially along the black body radiation locus.
- 10. (Original) The method for manufacturing a light emitting device according to claim 1, further comprising:

controlling emission color of said light emitting device by changing a content of said phosphor with respect to a content of a resin in a coating material.

11. (Original) The method for manufacturing a light emitting device according to claim 1, wherein said step of controlling selection of said phosphor is used to reduce variation in the

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emission wavelength of said light emitting device, by compensating for a variation of the emission wavelength of said light emitting component.

12. (Original) The method for manufacturing a light emitting device according to claim 3, further comprising:

controlling compositions or quantities of light emitting components and fluorescent materials included in said light emitting device, to control color emitted by said light emitting device.

- 13. (Original) The method for manufacturing a light emitting device according to claim 3, wherein the emission wavelength of the fluorescent materials are selected so that said light emitting device produces RGB components with high luminance.
- 14. (Original) The method for manufacturing a light emitting device according to claim 13, wherein

the emission spectrum of one fluorescent material comprises a peak wavelength around 510 nm, and the emission spectrum tails out to around 700 nm, and

the emission spectrum of a second fluorescent material comprises a peak wavelength around 600 nm, and the emission spectrum tails out to around 750 nm, so that said light emitting device produces RGB components with high luminance.

- 15. (Original) The method for manufacturing a light emitting device according to claim 3, further comprising mixing said two or more kinds of fluorescent materials.
- 16. (Original) The method for manufacturing a light emitting device according to claim 3, wherein said two or more kinds of fluorescent materials are arranged independently to adjust color by laminating the layers of fluorescent materials.

- 17. (Original) The method for manufacturing a light emitting device according to claim 3, wherein one of said fluorescent materials absorbs light of a shorter wavelength and another of said fluorescent materials absorbs light of a longer wavelength, and said fluorescent material that absorbs light of a longer wavelength is arranged away from said light emitting component, while said fluorescent material that absorbs light of a shorter wavelength is arranged near said light emitting component.
- 18. (Original) The method for manufacturing a light emitting device according to claim 1, wherein said phosphor is a fluorescent material represented by formula  $(Re_{1-r}Sm_r)_3$  (Al₁.  ${}_sGa_s)_5O_{12}$ :Ce where  $0 \le r < 1$ ,  $0 \le s \le 1$  and Re is at least one element selected from Y, Gd and La.
- 19. (Original) The method for manufacturing a light emitting device according to claim 1, further comprising:

controlling compositions or quantities of light emitting components included in said light emitting device and controlling composition of said phosphor, to control color emitted by said light emitting device.

#### **REMARKS**

Claims 1-19 are currently pending in the application. Claim 1 is independent. Claims 1-19 were pending prior to the Office Action.

The Examiner is respectfully requested to reconsider the rejections in view of the remarks set forth herein. Applicants respectfully request favorable consideration thereof in light of the comments contained herein, and earnestly seek timely allowance of the pending claims.

#### Request for Acknowledgement of Domestic Priority and Foreign Priority

In the Office Action (page 2), the Examiner alleged that a light emitting component having an active semiconductor layer, and a fluorescent material as recited in claim 18 are not described in the foreign priority documents and in the specification of the parent US application of the present application.

Applicants respectfully disagree with Examiner's assertions, and point out that these features are fully supported by the domestic parent document which is US Patent 5,998,925. Here, it is noted that the present application is a divisional application in a chain of divisional applications starting with US Patent 5,998,925, and thus the specifications of US Patent 5,998,925 and all patent applications in the divisional chain of the present application are identical. Therefore, support is presented below in the text of US Patent 5,998,925.

Specifically, the feature of a light emitting component having an active layer of a semiconductor (as in claim 1) is described at, e.g., col. 13 lines 51- col. 14 line 6, and col. 23 line 65 - col. 24 line 3 in US Patent 5,998,925. The feature of claim 18 is identically described at col. 18 lines 3-7 in US Patent 5,998,925.

These above-mentioned claim features are also described in foreign priority document JP 09-081010 (see below). With respect to claim 18, it is noted that it is supported by at least claim 2 of JP 09-081010 and paragraph [0011] in the English translation.

#### Claim Rejections – 35 USC §103

The Examiner rejected claims 1-17 and 19 under 35 U.S.C. § 103(a) as being made obvious by US 5,847,507 ("Butterworth") in view of US 5,966,393 ("Hide").

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Applicants respectfully submit the Examiner has failed to establish a prima facie case of obviousness.

The present application was filed in the USPTO on November 9, 2010, and is a divisional of U.S. Application No. 12/548,614 (now U.S. Patent 8,148,177) which is a divisional of U.S. Application No. 12/028,062 (now U.S. Patent 7,682,848) which is a divisional of U.S. Application No. 10/609,402 (now U.S. Patent 7,362,048), which is a divisional of U.S. Application No. 09/458,024 (now U.S. Patent 6,614,179), which is a divisional of U.S. Application No. 09/300,315 (now U.S. Patent 6,069,440), which is a divisional of U.S. Application No. 08/902,725 (now U.S. Patent 5,998,925) filed on July 29, 1997 and which claims priority under 35 U.S.C. §119 based on prior foreign applications JP 08-198585 filed July 29, 1996, JP 08-244339 filed September 17, 1996, JP 08-245381 filed September 18, 1996, JP 08-359004 filed December 27, 1996, and JP 09-081010 filed March 31, 1997.

Applicants submit herein a verified English translation of foreign priority application JP 09-081010 to perfect the priority claim. Foreign priority application JP 09-081010 explicitly supports claims 1-3, 5, 7, 8, and 10-19 of the present application.

In connection with claim 1, the verified English translation of JP 09-081010 describes the following features:

- preparing a light emitting component having an active layer of a semiconductor, said active layer comprising a gallium nitride based semiconductor containing indium and being capable of emitting a blue color light having a spectrum with a peak wavelength within the range from 420 to 490 nm - at least paragraphs [0021], [0032], [0051];
- preparing a phosphor capable of absorbing a part of the blue color light emitted from said light emitting component and emitting a yellow color light - at least paragraphs [0021], [0022], [0025], [0054], [0055], [0058], [0059], [0064], [0065];
- the phosphor having a broad emission spectrum comprising a peak wavelength existing around the range from 510 to 600 nm and a tail continuing beyond 700 nm - at least paragraph [0025] and Fig. 4B;
- wherein selection of said phosphor is controlled based on an emission wavelength of said light emitting component - at least paragraphs [0016], [0020];

- combining said light emitting component and said phosphor so that the blue color light from said light emitting component and the yellow color light from said phosphor are mixed to make a white color light at paragraphs [0021], [0022], [0074];
- wherein a chromaticity point of the white color light is on a straight line connecting a point of chromaticity of the blue color light and a point of chromaticity of the yellow color light at least paragraphs [0016], [0020], and Fig. 8;
- wherein a content of said phosphor in said light emitting device is selected to obtain a desired chromaticity of the white color light -at least paragraphs [0016], [0020], [0022].

JP 09-081010 also supports dependent claims 2, 3, 5, 7, 8, and 10-19 (see, e.g., paragraphs [0010], [0011], [0016], [0019], [0020], [0021], [0022], [0023], [0025], [0028], [0029], [0032], [0045], [0051], [0055], [0058], [0059], [0064], [0065], [0066], [0067], [0074]).

Since foreign priority application JP 09-081010 was filed on March 31, 1997 which is before the reference date (U.S. filing date) of July 14, 1997 of Butterworth, Butterworth is not a prior art reference against claims 1, 2, 3, 5, 7, 8, and 10-19 of the present application.

With respect to claim 4 which recites that the emission spectrum of the phosphor comprises a peak wavelength existing around the range from 530 to 570 nm and a tail continuing beyond 700 nm, the Examiner cited to Butterworth, col. 3 lines 58-64 and to the case of *In re Aller*. However, col. 3 lines 58-64 of Butterworth merely describe shifting of wavelength from 488 nm to 605 nm, or to 645 nm or to 685 nm, but do not describe the range of 530 to 570 nm. Furthermore, even though *In re Aller* provides that "[W]here the general conditions of a claim are disclosed in the prior art, it is not inventive to discover the optimum or workable ranges by routine experimentation", it is respectfully submitted that the Examiner has not shown that 1) one of ordinary skill would realize that a phosphor as in claim 4 would be an optimum phosphor for, e.g., Butterworth, or that 2) one of ordinary skill could arrive to a phosphor as in claim 4 by merely routine experimentation. Therefore, Butterworth does not make obvious the feature of claim 4.

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With respect to claim 6 which recites that the phosphor has a crystal structure, the

Examiner has not provided a discussion of this claim in the Office Action, but merely listed it as

rejected on page 2 of the Office Action. Here, it is noted that Butterworth and Hide do not

mention a crystal structure.

With respect to claim 9 which recites that the light emitting device is capable of emitting

white light substantially along the black body radiation locus, the Examiner has not provided a

discussion of this claim in the body of the Office Action, but merely listed it as rejected on page

2 of the Office Action. Here, it is noted that Butterworth and Hide do not discuss a black body

radiation locus or a white light along a black body radiation locus.

For all of the above reasons, taken alone or in combination, Applicants respectfully

request reconsideration and withdrawal of the 35 U.S.C. § 103(a) rejection of claims 1-17 and

19.

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## **Conclusion**

In view of the above remarks, this application appears to be in condition for allowance and the Examiner is, therefore, requested to reexamine the application and pass the claims to issue.

Should there be any outstanding matters that need to be resolved in the present application, the Examiner is respectfully requested to contact Corina Tanasa, Registration No. 64,042, at telephone number (703) 208-4003, located in the Washington, DC area, to conduct an interview in an effort to expedite prosecution in connection with the present application.

If necessary, the Director is hereby authorized in this, concurrent, and future replies to charge any fees required during the pendency of the above-identified application or credit any overpayment to Deposit Account No. 02-2448.

Dated: May 30, 2012

D. Richard Anderson

Respectfully submitted

Registration No.: 40,439

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Attorney for Applicant

Enclosures: Verified English translation of JP 09-081010.

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#### VERIFICATION OF ENGLISH TRANSLATION

I, Hiroshi TAMURA, declare that I am conversant in both the Japanese and English languages and that the English translation as attached hereto is an accurate translation of Japanese Patent Application No. H9-081010 filed March 31, 1997.

Date:

May 29, 2012

Name:

Hiroshi TAMURA

Signature:

Address: c/o AOYAMA & PARTNERS, IMP Building,

1-3-7, Shiromi, Chuo-ku,

Osaka 540-0001 Japan

# PATENT OFFICE JAPANESE GOVERNMENT

This is to certify that the annexed is a true copy of the following application as filed with this Office.

Date of Application:

March 31, 1997

Application Number:

081010/1997

Applicant(s):

Nichia Chemical Industries, Ltd.

May 30, 1997

Commissioner,
Patent Office

Hisamitsu ARAI (seal)

Document Name:

Application for Patent

Docket No.:

P96ST30-2

Date of Application:

March 31, 1997

Addressee:

Mr. Hisamitsu ARAI, Commissioner, Patent Office

**International Patent** 

H01L 33/00

Classification:

Title of the Invention: LIGHT EMITTING DEVICE

Number of Claims:

8

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Priority Claim based on the Earlier Application:

Application No.:

244339/1996

Filing Date:

September 17, 1996

Payment of Fees:

Prepayment Book No.:

010526

Amount to be paid:

¥21,000

# Attached document:

Item:Specification1 copyItem:Drawings1 copyItem:Abstract1 copy

Yes

Proof:

[Document Name] Specification

[Title of the Invention] LIGHT EMITTING DEVICE

[What is claimed is]

- [Claim 1] A light emitting device comprising a light

  5 emitting component whose light emitting layer is a nitride
  compound semiconductor and a phosphor which absorbs at least
  a part of light emitted by the light emitting component to
  emit light of a wavelength longer than that of the light emitted
  by the light emitting component, wherein
- the phosphor is composed of two or more kinds of yttrium-aluminum oxide fluorescent materials activated with cerium having different compositions.
- [Claim 2] The light emitting device according to claim 1, wherein the yttrium-aluminum oxide fluorescent material activated with cerium is (Re_xSm_{1-x})₃(Al_yGa_{1-y})₅O₁₂:Ce where 0<x≤1 and 0≤y≤1 and Re is at least one selected from Y, Gd and La. [Claim 3] The light emitting device according to claim 1, wherein the yttrium-aluminum oxide fluorescent material activated with cerium comprises an yttrium-aluminum oxide fluorescent material activated with cerium which has a main emission wavelength shorter than that of Y₃Al₅O₁₂:Ce and an yttrium-aluminum oxide fluorescent material activated with
- 25 [Claim 4] The light emitting device according to claim

 $Y_3Al_5O_{12}:Ce$ .

cerium has a main emission wavelength longer than that of

- 1, wherein the yttrium-aluminum oxide fluorescent material activated with cerium comprises a first fluorescent material of Y₃ (Al_yGa_{1-y})₅O₁₂:Ce and a second fluorescent material of Re₃Al₅O₁₂:Ce having a main emission wavelength longer than that of the first fluorescent material, where 0≤y≤1 and Re is at least one selected from Y, Gd and La.
- [Claim 5] The light emitting device according to claim

  1, wherein the two or more kinds of yttrium-aluminum oxide

  fluorescent materials activated with cerium having different

  compositions comprise a third fluorescent material containing

  Gd and a fourth fluorescent material having a composition ratio

  of Gd higher than that of the third fluorescent material.
  - [Claim 6] The light emitting device according to claim 1, wherein a main emission peak of the light emitting component is within the range from 400 nm to 530 nm.
- [Claim 7] The light emitting device according to claim 1, which is capable of planar light emission by means of optical coupling of a light emitting component and an optical guide plate via a color converting material having a phosphor arranged on the optical guide plate which is optically coupled with the light emitting component or a color converting material having the phosphor.
  - [Claim 8] A light emitting device which is a light emitting diode comprising a light emitting component placed in a cup of a mount lead, an inner lead electrically connected with

the light emitting component with a conductive wire, a coating material filling the cup and a molding material covering at least part of the coating material, the light emitting component, the conductive wire, the mount lead and the inner lead, wherein

a light emitting layer of the light emitting component is a nitride compound semiconductor and the coating material contains two or more kinds of yttrium-aluminum oxide fluorescent materials activated with cerium having different compositions which absorb at least a part of the light emitted by the light emitting component to emit light of a wavelength longer than that of the light emitted by the light emitting component.

[Detailed Description of the Invention]

[0001]

5

[Industrial Utilization Field]

The present invention relates to a light emitting device used in back light source, illuminating switch, signal, display, LED display, indicator, etc. More particularly, it relates to a light emitting device which emits lights of RGB (red, green, blue) colors with high luminance and high efficiency regardless of the operating environment.

[0002]

[Prior Art]

A light emitting device using a LED chip is compact and emits light of clear color with high efficiency. It is also free from such a trouble as burn-out because it is a

semiconductor element. It has an excellent initial drive characteristic and such an advantage as durability to endure vibration and repetitive ON/OFF operations. Thus it has been used in such applications as various indicators and various light sources. Recently light emitting diodes for RGB (red, green and blue) colors having ultra-high luminance and high efficiency have been developed. Accordingly, planar light sources for full color, which can be used in a liquid crystal back-light, using the three primary colors of RGB have been greatly advancing by making most of the advantages such as low power consumption, long life and light weight.

[0003]

The LED chip can emit light of various wavelengths ranging from ultra violet to infrared, depending on the semiconductor material and conditions to form a light emitting layer to be used. It also has favorable emission spectrum to generate monochromatic light.

[0004]

15

Although because the light emitting diode has
favorable emission spectrum to generate monochromatic light,
making a light source for white light requires it to arrange
the LED chips which are capable of emitting light of RGB colors
closely to each other while diffusing and mixing the light
emitted by them. Although these light emitting diodes are
effective as light emitting devices for emitting various colors

freely, a set of red green and blue light emitting diodes or a set of blue-green and yellow light emitting diodes must be used even when generating white light only. A LED chip is a semiconductor and still includes considerable variations in the color tone and luminance. The LED chip which can emit lights of RGB colors with high luminance has not been yet made from the same semiconductor material. In case the LED chips which are semiconductor light emitting component are made from different materials, different LED chips require different 10 drive voltages which must be supplied from different power sources provided separately. Therefore, white light must be generated by adjusting the current for each semiconductor. Similarly, color tone is subject to variation due to the difference in temperature characteristics and chronological changes, because the LED chips are semiconductor light emitting components. Further, uneven color may result unless the light rays emitted by the LED chips are mixed evenly.

[0005]

Thus, the present applicant previously developed a light emitting diode which converts the color of light emitted by a LED chip by means of a fluorescent material and a planar light source disclosed in Japanese Patent Kokai Nos. 5-152609, 7-176794 and 8-8614. By using the light emitting diode and the planar light source, light of other colors such as white color can be emitted by using a LED chip of one type.

[0006]

Specifically, a LED chip capable of emitting blue light is connected to one end of a transparent optical guide plate and light emitted by the LED chip is converted by a layer containing a fluorescent material provided on the optical guide plate into green and red light, thereby to produce light of white color. These devices can be used as light emitting devices which emit light for an extended period of time with a sufficient luminance, even when used as light emitting device capable of emitting light of white color having RGB light components.

[0007]

[Problems to be solved by the Invention]

There are various fluorescent materials such as fluorescent dye, fluorescent pigment and organic or inorganic compounds which are excited by light emitted by a LED chip.

Excitation wavelengths and emission wavelengths of fluorescent materials also range widely. Also there are fluorescent materials which convert light of shorter wavelength emitted by a light emitting component into light of longer wavelength and those which convert light of longer wavelength emitted by a light emitting component into light of shorter wavelength.

[8000]

However, efficiency of conversion of long-wavelength light into short-wavelength light is extremely low and is not practical. When a light emitting device is used in outdoor

environment such as under direct sunlight, or when a fluorescent material is located in the vicinity of the LED chip, the fluorescent material remains to be irradiated by high-energy radiations such as ultra violet ray of strong intensities for a long period of time. In particular, energy of light emitted by a semiconductor light emitting component having a high energy band gap enough to excite a fluorescent material and emit secondary radiation is inevitably high. Therefore, the fluorescent material itself is subject to deterioration due also to the synergistic effect with the extraneous light such as sun light.

[0009]

There are such cases as the color tone changes as the fluorescent material deteriorates or the fluorescent material is blackened resulting in lowered efficiency of extracting light. Similarly, the fluorescent material is exposed to a high temperature such as rising temperature of the LED chip and from the external environment. Further, although a light emitting device is usually sealed in a plastic casing, it is impossible to completely prevent the entry of moisture from the outside or to completely remove moisture which was contained during production. In the case of some fluorescent materials, such moisture accelerates the deterioration of the fluorescent material due to the high-energy radiation or heat transmitted from the light emitting component.

When it comes to an organic dye of ionic property, direct current electric field in the vicinity of the chip may cause electrophoresis, resulting in a change in the color tone. Therefore, an object of the present invention is to solve the problems described above and provide a light emitting device which is subject only to extremely low degrees of deterioration in light emission efficiency and color shift over a long period of time even when used outdoors, and is capable of emitting light of desired color with a high luminance.

10 [0010]

[Means for Solving the Problems]

The light emitting device of the present invention provides a light emitting device comprising a light emitting component whose light emitting layer is a nitride compound semiconductor and a phosphor which absorbs at least a part of light emitted by the light emitting component to emit light of a wavelength longer than that of the light emitted by the light emitting component, wherein

the phosphor is composed of two or more kinds of yttrium-aluminum oxide fluorescent materials activated with cerium having different compositions.

[0011]

With respect to the light emitting device of claim

2 of the present invention, the yttrium-aluminum oxide

fluorescent material activated with cerium is

 $(Re_xSm_{1-x})_3$   $(Al_yGa_{1-y})_5O_{12}$ :Ce (where  $0< x \le 1$  and  $0 \le y \le 1$  and Re is at least one selected from Y, Gd and La).

With respect to the light emitting device of claim 3 of the present invention, the yttrium-aluminum oxide 5 fluorescent material activated with cerium comprises an yttrium-aluminum oxide fluorescent material activated with cerium which has a main emission wavelength shorter than that of Y₃Al₅O₁₂:Ce and an yttrium-aluminum oxide fluorescent material activated with cerium has a main emission wavelength longer than that of Y₃Al₅O₁₂:Ce.

[0012]

With respect to the light emitting device of claim 4 of the present invention, the yttrium-aluminum oxide fluorescent material activated with cerium comprises a first fluorescent material of  $Y_3$  (Al_yGa_{1-y})₅O₁₂:Ce and a second fluorescent material of Re3Al5Ol2:Ce having a main emission wavelength longer than that of the first fluorescent material (where  $0 \le y \le 1$  and Re is at least one selected from Y, Gd and La).

With respect to the light emitting device of claim

5 of the present invention, the yttrium-aluminum oxide
fluorescent materials activated with cerium having different
compositions comprise a third fluorescent material containing
Gd and a fourth fluorescent material having a composition ratio

25 of Gd higher than that of the third fluorescent material.

[0013]

With respect to the light emitting device of claim 6 of the present invention, a main emission peak of the light emitting component is within the range from 400 nm to 530 nm.

5 [0014]

The light emitting device of claim 7 of the present invention is a light emitting device capable of planar light emission by means of optical coupling of a light emitting component and an optical guide plate via a color converting material having a phosphor arranged on the optical guide plate which is optically coupled with the light emitting component, or via a color converting material having the phosphor.

[0015]

A light emitting device of claim 8 of the present invention is a light emitting diode comprising a light emitting component placed in a cup of a mount lead, an inner lead electrically connected with the light emitting component by means of a conductive wire, a coating material filling the cup and a molding material covering at least part of the coating material, the light emitting component, the conductive wire, the mount lead and the inner lead, wherein

a light emitting layer of the light emitting component is a nitride compound semiconductor and the coating material includes at least two kinds of yttrium-aluminum oxide fluorescent materials activated with cerium of different compositions which

absorb at least a part of light emitted by the light emitting component and emit light of a wavelength longer than that of the light emitted by the light emitting component.

[0016]

## 5 [Action]

The light emitting device of the present invention has a light emitting component and fluorescent materials which are excited by light emitted by the light emitting component to emit light of a wavelength longer than that of the light emitted by the light emitting component. As the fluorescent materials, two or more kinds of yttrium-aluminum oxide fluorescent materials having different compositions are used. This enables the light emitting device to emit light of a desired color with a high efficiency. That is, when the 15 wavelength of the light emitted by the semiconductor light emitting component falls within the range from point A to point B in Fig. 8 depending on the semiconductor light emitting component, the device can emit light of any color within the shaded range enclosed by points C and D in Fig. 8 which are 20 chromaticity points of at least two kinds of yttrium-aluminum oxide fluorescent materials of different compositions. color can be controlled through the selection of composition or quantities of the light emitting component and the fluorescent materials. The light emitting device can be caused to produce light of a desired wavelength by selecting various fluorescent

materials and absorbing the variations in emission of the light emitting component. Also the light emitting device can be caused to generate light which includes RGB components with high luminance, by selecting the wavelengths of light emitted by the fluorescent materials.

[0017]

Moreover, the yttrium-aluminum oxide fluorescent material can be used to make a light emitting device capable of emitting light with a high luminance for a long period of time. Also by using a fluorescent material which emits light of a wavelength longer than that of the light emitted by the light emitting component, light can be emitted with a high efficiency. Because the converted light has a wavelength longer than that of the light emitted by the light emitting chip, it is less than the band gap of the light emitting chip and is less likely to be absorbed by the light emitting component. Therefore, even when light is emitted in isotropic way by the fluorescent material and is directed toward the light emitting component, it is not absorbed by the light emitting component, making it possible to emit light with a high efficiency.

[0018]

20

[Mode for carrying out the Invention]

The present inventors have found, as a result of various experiments, that it is made possible to prevent the decrease

in emission efficiency and color shift through operation with a high luminance over a long period of time by selecting a particular semiconductor and a fluorescent material in a light emitting diode which uses a phosphor to convert the color of light emitted by a LED chip having a relatively high radiation energy in visible region, and have achieved the present invention.

[0019]

The phosphor used in the light emitting device of the present invention must satisfy the following requirements:

- 1. Excellent resistance against light, particularly durability to endure direct sun light in which lights with various high energy are radiated for a long period. And durability to endure light of a radiation illuminance as high as Ee=3Wcm⁻² and more because the fluorescent material is exposed to intense radiation from a tiny region such as a semiconductor light emitting component when used as a light emitting diode.
  - 2. Capability to emit light in blue region, not ultra violet, because mixing of colors with the light emitting elements is used.
- 3. Capability to emit light from green to red regions with high luminance in consideration of mixing with blue light.
  - 4. Good temperature characteristic suitable for location in the outdoor and in the vicinity of the light emitting component.
- 5. Capability to continuously change the color tone

in terms of the proportion of composition or ratio of mixing a plurality of fluorescent materials.

6. Weatherability for the operating environment of the light emitting diode.

5 [0020]

As materials that satisfy the above requirements, the present invention uses a nitride compound semiconductor element having high-energy band gap in the light emitting layer as the light emitting component, and an yttrium-aluminum oxide fluorescent material activated with cerium where two or more kinds of phosphors of different compositions are activated with cerium as the phosphor. With this constitution, the light emitting device can emit light of a desired color tone by controlling two or more kinds of fluorescent materials, even when the wavelength of light emitted by the light emitting component deviates from the desired wavelength due to a problem in the production process of the light emitting component or More specifically,  $(Re_xSm_{1-x})_3(Al_yGa_{1-y})_5O_{12}$ :Ce other causes. is used as the yttrium-aluminum oxide fluorescent material activated with cerium (where  $0 < x \le 1$  and  $0 \le y \le 1$ , and Re is at least one selected from Y, Gd and La). This makes it possible to make a light emitting component which experiences color shift of emitted light and a decrease in luminance of the emitted light, both of very low degrees, even when irradiated with high-energy radiation in the visible light region emitted by

the light emitting component in the vicinity thereof over a long period of time or used outdoors, and emits light of desired component with high luminance.

[0021]

As one embodiment of the light emitting device, a 5 chip type LED is shown in Fig. 1. A LED chip 102 employing gallium nitrate semiconductor is fixed in the casing of the chip type LED by means of epoxy resin or the like. The LED chip 102 employs a light emitting component having a In_{0.4}Ga_{0.6}N semiconductor light emitting layer with a thickness of 470 The light emitting component has a contact layer which is a gallium nitride semiconductor having N type conductivity, a clad layer which is a gallium nitride semiconductor having P type conductivity and a contact layer which is a gallium nitride semiconductor having P type conductivity, formed on a sapphire substrate. Formed between the contact layer having N type conductivity and the clad layer having P type conductivity is a non-doped InGaN active layer of a single quantum well structure of thickness about 3 nm. (The sapphire substrate has a gallium nitride semiconductor formed thereon under a low temperature to make a buffer layer.) Electrodes of the light emitting component 102 and electrodes 105 provided on the casing are electrically connected by means of gold wires 103 which are conductive wires. The LED chip which is a light emitting component, made by mixing and dispersing Y3Al5O12:Ce

as phosphor of green color and  $(Y_{0.8}Gd_{0.2})_3Al_5O_{12}$ :Ce as phosphor of red color in an acrylic resin, and the conductive wires are protected from extraneous stresses by a molding material 101 which is uniformly applied and cured. The LED chip is 5 caused to emit light by supplying electric power to the light emitting device. By mixing blue light emitted by the LED chip and light emitted by two or more kinds of phosphor capable of emitting light of high luminance when excited by the light emitted by the LED chip, the light emitting diode can emit light of white color. The light emitting diode formed as described above does not have the light emitting pattern normally observed during emission of a conventional light emitting diode which does not include fluorescent material. The emission pattern generated by electrodes formed on the light emitting surface of the LED chip causing shadows are eliminated by diffusion caused by the fluorescent material. Thus the light emitting diode can emit light with uniform luminance. Constituents of the present invention will now be described below.

20 [0022]

25

(Phosphor)

The phosphor used in this invention refers to a phosphor which emits light when excited by visible light or ultra violet light emitted by the semiconductor light emitting component. In the present invention, the phosphor uses two

or more kinds of yttrium-aluminum oxide fluorescent materials activated with cerium of different compositions. Desired white color can be produced by mixing light of blue color emitted by a light emitting component employing nitride compound semiconductor in the light emitting layer, light of green color and light of red color emitted by the phosphor with yellow body color for absorbing blue light, or light of yellow color having greenish and reddish hue. In the light emitting device, in order to achieve this color mixture, it is preferable that the phosphor in the form or powder or bulk be contained in various resins such as epoxy resin, acrylic resin and silicone resin, or an inorganic substance such as silicon dioxide or aluminum oxide. Such a substance which includes phosphor can be used in various forms such as dot-shaped construction and a layer formed thin enough to transmit light from the LED chip. Various color colors containing white and incandescent lamp color can be produced by adjusting the mix proportion of phosphor and resin and the amount of coating or filling material and selecting the wavelength of light emitted by the light emitting device.

The light emitting device can be rendered weather-proof and other characteristics by changing the distribution of the phosphor. The distribution can be adjusted by changing the material which includes the phosphor, forming temperature and viscosity and the shape and particle size

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distribution of the phosphor. Therefore, desired concentration of the fluorescent material can be selected depending on the operating conditions.

[0023]

Also the light emitting device can be made capable of emitting light with a high efficiency by arranging two or more fluorescent materials in an order with respect to the incident light coming from the respective light emitting components. That is, reflected light can be utilized effectively by laminating a color converting material which includes a fluorescent material having an absorbing wavelength on longer wavelength side and capable of emitting light of a long wavelength, and a color converting material which has an absorbing wavelength on further longer wavelength side and capable of emitting light of a long wavelength, on the light emitting component which has a reflecting material.

[0024]

By using the phosphor of the present invention, the light emitting device can be given enough light resistance for high-efficient operation even when arranged adjacent to or in the vicinity of a LED chip of radiation illuminance (Ee) in a range from 3 Wcm⁻² up to 10 Wcm⁻².

[0025]

YAG fluorescent material capable of emitting green 25 light which is yttrium-aluminum oxide fluorescent material

activated with cerium used in the present invention has garnet structure, and is therefore resistant to heat, light and moisture, thereby to be capable of absorbing excitation light having a peak at a wavelength near 450 nm as indicated by the solid line in Fig. 4(A). It emits light of broad spectrum having a peak near 510 nm tailing out to 700 nm as indicated by the solid line in Fig. 4(B). YAG fluorescent material capable of emitting red light which is yttrium-aluminum oxide fluorescent material activated with cerium used in the present invention, too, has garnet structure and is therefore resistant to heat, light and moisture, and is capable of absorbing excitation light having a peak near 450 nm as indicated by the wavy line in Fig. 4(A). It also emits light of broad spectrum having a peak near 600 nm tailing out to 750 nm as indicated by the

[0026]

Wavelength of the emitted light is shifted to a shorter wavelength by substituting part of Al, among the constituents of the YAG fluorescent material having garnet structure, with 20 Ga, and the wavelength of the emitted light can be shifted to a longer wavelength by substituting part of Y with Gd and/or La. Proportion of substituting Al with Ga is preferably from Ga:Al=1:1 to 4:6 in consideration of the light emitting efficiency and the wavelength of emission. Similarly, proportion of substituting Y with Gd and/or La is preferably

from Y:Gd and/or La=9:1 to 1:9, or more preferably from Y:Gd and/or La=1:4 to 2:3. Substitution of less than 20% results in an increase of green component and a decrease of red component.

Substitution of 80% or greater part, on the other hand, increases red component but decreases the luminance steeply.

[0027]

Material for making such a phosphor is made by using oxides of Y, Gd, Ce, La, Al, Sm and Ga or compounds which can be easily converted into these oxides at high temperatures, and sufficiently mixing these materials in stoichiometrical proportions. Otherwise, mixture material is obtained by dissolving rare earth elements Y, Gd, Ce, La and Sm in stoichiometrical proportions in an acid, coprecipitating the solution oxalic acid and sintering the coprecipitate to obtain an oxide of the coprecipitate, which is then mixed with aluminum oxide and gallium oxide. This mixture is mixed with an appropriate quantity of a fluoride such as ammonium fluoride used as a flux, and sintered in a crucible at a temperature from 1350 to 1450 °C in air for 2 to 5 hours. Then the sintered material is ground by ball mill in water, washed, separated, dried and sieved thereby to obtain the desired material.

[0028]

The two or more kinds of yttrium-aluminum oxide fluorescent materials activated with cerium of different compositions may be either used by mixing or arranged

independently. When arranging the fluorescent materials independently, it is preferable to arrange in the order of a fluorescent material that absorbs light from the light emitting component of a shorter wavelength, then a fluorescent material that absorbs light of a longer wavelength. This arrangement enables efficient absorption and emission of light.

[0029]

(Light emitting components 102, 202, 302)

As the light emitting component used in the present invention, a nitride compound semiconductor capable of efficiently exciting the two or more kinds of yttrium-aluminum oxide fluorescent materials activated with cerium of different compositions may be used. The LED chip which is the light emitting component can be made by forming light emitting layer 15 of semiconductor such as AlN, InN, GaN, InGaN or InGaAl on a substrate in the MOCVD process. The semiconductor structure homostructure, heterostructure may be double-heterostructure which have MIS junction, PIN junction or PN junction. It may also be made in a single quantum well structure or multiple quantum well structure where a semiconductor active layer is formed in a thin film where quantum effect can occur. While various wavelengths of emitted light can be selected depending on the property and structure of the semiconductor layer material and the mixed crystal ratio 25 thereof, it is preferable to emit light of a wavelength shorter than the wavelength of light emitted by the phosphor, in order to excite the phosphor more efficiently.

[0030]

When a nitride compound semiconductor is used, sapphire, spinnel, SiC, Si, ZnO, GaN or the like is used as the semiconductor substrate. Use of sapphire substrate is preferable in order to form a nitride compound semiconductor of good crystalinity. Abuffer layer of GaN, AlN, etc. is formed on the sapphire substrate, and a nitride semiconductor having PN junction is formed thereon. The gallium nitride semiconductor has N type conductivity under 10 the condition of not doped with any impurity. In order to form an N type gallium nitride semiconductor having desired properties such as improved light emission efficiency, it is preferably doped with N type dopant such as Si, Ge, Se, Te, and C. In order to form a P type gallium nitride semiconductor, on the other hand, it is preferably doped with P type dopant such as Zn, Mg, Be, Ca, Sr and Ba. Because it is difficult to turn a gallium nitride compound semiconductor to P type simply by doping a P type dopant, it is preferable to anneal the gallium nitride compound semiconductor doped with P type dopant in such process as heating in a furnace, irradiation with low-speed electron beam, plasma irradiation, etc., thereby to turn it to P type. After exposing the surfaces of P type and N type semiconductor layers by etching or other process, electrodes of the desired shapes are formed on the semiconductor layers by sputtering 25

or vapor deposition.

[0031]

Then the semiconductor wafer which has been formed is cut into pieces by means of a dicing saw which has a rotating blade having diamond cutting edge, or separated by an external force after cutting grooves (half-cut) which have width greater than the blade edge width. Or otherwise, the wafer is cut into chips by scribing grid pattern of extremely fine lines on the semiconductor wafer by means of a scriber having a diamond stylus which makes straight reciprocal movement. Thus the LED chips of gallium nitride compound semiconductor can be made.

[0032]

In order to emit white light with the light emitting device of the present invention, wavelength of main light emitted by the light emitting component is preferably from 400 nm to 530 nm inclusive in consideration of the mixing color with the phosphor, and more preferably from 420 nm to 490 nm inclusive. It is further more preferable that the wavelength be from 450 nm to 475 nm inclusive, so as to increase the emission efficiency of the LED chip and the phosphor, respectively.

[0033]

(Conductive wires 103, 303)

The conductive wires should have good electric conductivity, good thermal conductivity and good mechanical connection with the electrodes of the light emitting components

102, 302. Thermal conductivity is preferably 0.01 cal/cm²/cm/°C or higher, and more preferably 0.5 cal/cm²/cm/°C or higher. For workability and other reasons, the diameter of the conductive wire is preferably from  $\Phi 10~\mu$  m to  $\Phi 45~\mu$  m inclusive. The conductive wire may specifically be a metal such as gold, copper, platinum and aluminum or an alloy thereof. Such a conductive wire can be easily connected to the electrodes of the LED chips, the inner lead 306 and the mount lead 305 by means of a wire bonding device.

10 [0034]

(Mount lead 305)

The mount lead 305 is used for mounting of the light emitting component 302, and suffices to have a size enough to load the LED chip 302 with a die bonding equipment or the like.

15 In case a plurality of LED chips are installed and the mount lead is used as common electrode of the LED chips, sufficient electric conductivity and good connecting characteristic with the bonding wires and the like are required. When the LED chip is installed in the cup of the mount lead and the cup is filled with the fluorescent material, erroneous illumination due to light from other light emitting diode mounted nearby can be prevented.

[0035]

Bonding of the LED chip 302 and the mount lead 305 with the cup can be achieved by means of a thermoplastic resin.

Specifically, epoxy resin, acrylic resin and imide resin can be used. When bonding a face-down LED chip and the mount lead and, at the same time, electrically connecting them, Ag paste, carbon paste, metallic bump or the like can be used.

5 [0036]

Further, in order to improve the efficiency of light utilization of the light emitting diode, surface of the mount lead whereon the LED chip 302 is mounted may be mirror-polished to give reflecting function to the surface. In this case, the surface roughness is preferably from 0.1S to 0.8S inclusive. Electric resistance of the mount lead is preferably within 300  $\mu\Omega$ -cm and more preferably within 3  $\mu\Omega$ -cm.

[0037]

When mounting a plurality of LED chips on the mount lead, the LED chips generate significant amount of heat and therefore high thermal conductivity is required. Specifically, the thermal conductivity is preferably 0.01 cal/cm²/cm/°C or higher, and more preferably 0.5 cal/cm²/cm/°C or higher. Materials which satisfy these requirements include iron, copper, iron-containing copper, tin-containing copper and metallized ceramics.

[0038]

(Inner lead 306)

The inner lead 306 provides connection between the LED chip mounted on the mount lead 305 and the conductive wire.

When mounting a plurality of LED chips 302 on the mount lead, it is necessary to employ such a construction that the conductive wires can be arranged so as not to touch each other.

[0039]

Specifically, contact of the conductive wires with each other which connect the inner leads that are more distant from the mount lead can be prevented by increasing the area of the end face where the inner lead 306 is wire-bonded as the distance from the mount lead increases.

10 [0040]

5

Surface roughness of the end face connecting with the conductive wire is preferably from 1.6S to 10S inclusive in consideration of close contact. In order to form the tip of the inner lead in a desired shape, the shape may be formed by punching the lead frame with a die in advance, or by grinding off a part of inner leads at the top after forming all inner leads. Further, after forming by punching the inner leads, desired end face area and height can be formed simultaneously by applying pressure in the direction of end face.

20 [0041]

25

The inner lead is required to have good connectivity with the bonding wires which are conductive wires and good electrical conductivity. Specifically, the electric resistance is preferably within 300  $\mu$   $\Omega$ -cm and more preferably within 3  $\mu$   $\Omega$ -cm. Materials which satisfy these requirements include iron,

copper, iron containing copper, tin containing copper, copper-, gold- or silver-plated aluminum, iron or copper.

[0042]

5

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15

(Coating material 301)

The coating material 301 used in the present invention is provided in the cup of the mount lead 305 in addition to the molding material 304, and includes the phosphor which converts the light emitted by the LED chip 302. As the coating material, transparent resins of excellent weatherability such as epoxy resin, urea resin and silicone and acrylic resin, or inorganic material such as silicon dioxide as a silicide and aluminum oxide are preferably employed. A dispersant may be used together with the phosphor. As the dispersant, barium titanate, titanium oxide, aluminum oxide, silicon dioxide and the like are preferably used.

[0043]

(Molding material 101, 210, 304)

The molding may be provided in order to protect the LED, the conductive wire and the coating material which includes phosphor from external disturbance, depending on the application of the light emitting device. The molding material can be generally made of a resin or glass. The angle of view can be increased by containing the phosphor. And also, the angle of view can be further increased by adding a dispersant, thereby making the directivity of the emission from the LED chip dull.

[0044]

Further, the molding material may be formed in a desired shape having the function of lens to focus or diffuse the light emitted by the LED chip. Therefore, the molding material may be made in a structure of multiple layers laminated. Specifically, it may be a convex lens or a concave lens, and may have an elliptic shape when viewed in the direction of optical axis, or a combination of these.

[0045]

10

As the molding material, transparent resin of excellent weatherability such as epoxy resin, urea resin, silicone resin and acrylic resin, or glass having a low melting point are preferably employed. As the dispersant, barium titanate, titanium oxide, aluminum oxide, silicon dioxide and the like are preferably used. The phosphor may be contained either in the molding material or in the coating material and other part. Or otherwise, the coating may be of other materials such as a resin containing phosphor and the molding material may be glass. In this case, such a light emitting diode can be made that is suited to mass production and is less affected by moisture. The molding and the coating may also be made of the same material in consideration of the refractive index.

[0046]

(Planar light source)

A planar light source which is one of light emitting

devices of the present invention can be made either by turning white light into planar light by means of an optical guide plate when emitting white light as shown in Fig. 2(A), or by converting blue light emitted by the LED chip which emits planar light into white light as shown in Fig. 2(B).

[0047]

When turning white light into planar light by means of an optical guide plate, it can be achieved either by such a construction that a light emitting diode 202 capable of emitting blue light and an optical guide plate 204 are arranged interposing a color conversion material 201 which includes phosphor, or by such a construction that the light emitting diode 202 having nitride semiconductor light emitting component which includes phosphor to be capable of emitting blue light and the optical guide plate 204 are optically coupled in a molding material 210 or the like.

[0048]

When converting blue light emitted by the LED chip 202 which emits planar light into white light, the light emitting diode 202, which includes a nitride semiconductor in the light emitting layer and is capable of emitting blue light, and the optical guide plate 204 are optically coupled and then contained in a diffusion sheet 206 on the optical guide plate 204, or otherwise applied on the diffusion sheet together with a binder resin to form a sheet. Further, such a construction may also

be employed as a binder containing phosphor is formed into dot-shape on the optical guide plate.

[0049]

Specifically, the LED chip which is the light emitting component is fixed in a metal substrate 203 or the like having inverted C shape whereon an insulation layer and a conductive pattern are formed. After electrically connecting the LED chip and the conductive pattern, epoxy resin is applied onto the substrate whereon the LED chip 202 is mounted, thereby to optically couple with an end face of the acrylic optical guide plate 204. Placed on the principal light emitting plane of the optical guide plate 204 is a sheet 201 made by applying a mixture of phosphor and epoxy resin uniformly on a diffusion sheet. The diffusion sheet 206 comprises a layer made by applying epoxy resin containing particles of aluminum oxide, silicon dioxide, titanium oxide or barium titanate as diffusion agent in a base of acrylic resin and a layer containing phosphor.

[0050]

It is preferable that a reflector film 207 containing
a white diffusion agent be arranged on one principal plane
of the optical guide plate for the purpose of preventing
fluorescence wherein intense light is emitted from near the
light emitting diode. Similarly, a reflector 205 is provided
on the entire surface on the back of the optical guide plate
204 and on one end face where the light emitting diode is not

provided, in order to improve the light emission efficiency.

With this construction, a planar light source can be obtained which generates enough luminance even when used as the back light of liquid crystal. Application to a liquid crystal display can be achieved by arranging a polarizer plate on the principal plane of the optical guide plate via liquid crystal injected between glass substrates whereon a translucent conductive pattern not shown in the drawing is formed. Examples of the present invention will be described below. It goes without saying that the present invention is not limited to the Examples.

[0051]

[Examples]

(Example 1)

In_{0.05}Ga_{0.95}N semiconductor having emission peak at
450 nm is used as a light emitting component. A LED chip is
made by flowing TMG (trimethyl gallium) gas, TMI (trimethyl
indium) gas, nitrogen gas and dopant gas together with a carrier
gas on a cleaned sapphire substrate and forming a gallium nitride
compound semiconductor layer in MOCVD process. A gallium
nitride semiconductor layer having N type conductivity and
a gallium nitride semiconductor layer having P type conductivity
are formed by switching SiH4 and Cp₂Mg as dopant gas, thereby
forming a PN junction. For the semiconductor light emitting
component, a contact layer which is gallium nitride semiconductor
having N type conductivity, a clad layer which is gallium nitride

aluminum semiconductor having N type conductivity, a clad layer which is gallium nitride aluminum semiconductor having P type conductivity and a contact layer which is gallium nitride semiconductor having P type conductivity are formed. An active layer of Zn-doped InGaN which makes a double-hetero junction is formed between the clad layer having N type conductivity and the clad layer having P type conductivity. (A buffer layer is provided on the sapphire substrate by forming gallium nitride semiconductor layer at a low temperature. The P type semiconductor is annealed at a temperature of 400 °C or above after forming the film.)

After exposing the surfaces of P type and N type semiconductor layers by etching, electrodes are formed by sputtering. After scribing the semiconductor wafer which has been made as described above, LED chips are made as light emitting components by dividing the wafer with external force.

[0052]

10

The LED chip is mounted on a mount lead which has a cup at the tip of a silver-plated copper lead frame, by die bonding with epoxy resin. Electrodes of the LED chip, the mount lead and inner lead are electrically connected by wire boding with gold wires.

[0053]

The lead frame with the LED chip attached thereon is placed in a bullet-shaped die and sealed with translucent

epoxy resin for molding, which is then cured at 150 °C for 5 hours, thereby to form a blue light emitting diode. The blue light emitting diode is connected to one end face of an acrylic optical guide plate which is polished on all end faces.

On one surface and side face of the acrylic plate, screen printing is applied by using barium titanate dispersed in an acrylic binder as white color reflector, which is then cured.

[0054]

On the other hand, phosphors of green and red colors are made by dissolving rare earth elements of Y, Gd, Ce and La in an acid in stoichiometrical proportions, and coprecipitating the solution with oxalic acid. Oxide of the coprecipitate obtained by sintering this material is mixed with aluminum oxide and gallium oxide, thereby to obtain respective mixture materials. The mixture is then mixed with ammonium fluoride used as a flux, and sintered in a crucible at a temperature of 1400 °C in air for 3 hours. Then the sintered material is ground by ball mill in water, washed, separated, dried and sieved thereby to obtain the desired material.

20 [0055]

120 Parts by weight of the first fluorescent material having a composition of  $Y_3$  (Al_{0.6}Ga_{0.4})₅O₁₂:Ce and capable of emitting green light, 100 parts by weight of the second fluorescent material having a composition of  $(Y_{0.4}Gd_{0.6})_3Al_5O_{12}$ :Ce and capable of emitting red light, prepared in a process similar

to that for the first fluorescent material, are sufficiently mixed with 100 parts by weight of an epoxy resin, to form a slurry. The slurry is applied uniformly onto an acrylic layer of thickness of 0.5 mm by means of a multi-coater and then dried to form a fluorescent material layer used as a color converting material having a thickness of about 30  $\mu$ m. fluorescent material layer is cut into the same size as that of the principal light emitting plane of the optical guide plate, and arranged on the optical guide plate thereby to form the light emitting device. Measurements of chromaticity point and color rendering index of the light emitting device gave values of (0.29, 0.34) for chromaticity point (x, y) and 92.0 for Ra (color rendering index) which are approximate to 3-waveform fluorescent lamp. Light emitting efficiency of 121 m/W comparable to that of an incandescent lamp was obtained. in weatherability tests under conditions energization with a current of 60 mA at room temperature, 20 mA at room temperature and 20 mA at 60 °C with 90% RH, no change due to the fluorescent material was observed.

20 [0056]

(Comparative Example 1)

According to the same manner as that described in Example 1 except for mixing the same quantities of a green organic fluorescent pigment (FA-001, manufactured by Synleuch Chemical Co.) and a red organic fluorescent pigment (FA-005,

manufactured by Synleuch Chemial Co.) which are perylene-derivatives for the first and the second phosphor, the formation of a light emitting diode and weatherability test were conducted. Chromaticity coordinates of the light 5 emitting diode thus formed were (x, y) = (0.34, 0.35). The weatherability test was conducted by irradiating with ultraviolet ray generated by carbon arc for 200 hours, representing equivalent irradiation of sun light over a period of one year, while measuring the luminance retaining ratio 10 and color tone at various times during the test period. In a reliability test, the LED chip was energized to emit light at a constant temperature of 70 °C while measuring the luminance and color tone at different times. The results are shown in Fig. 6 and Fig. 7, together with Example 1.

15 [0057]

(Example 2)

A LED chip having In_{0.05}Ga_{0.95}N with emission peak at 450 nm was formed as a light emitting component according to the same manner as that described in Example 1. The LED chip was mounted on a mount lead which had a cup at the tip of a silver-plated copper lead frame, by die bonding with epoxy resin. Electrodes of the LED chip, the mount lead and inner lead were electrically connected by wire boding with gold wires.

[0058]

25 On the other hand, phosphors of green and red colors

were made by dissolving rare earth elements of Y, Gd and Ce in an acid in stoichiometrical proportions, and coprecipitating the solution with oxalic acid. Oxide of the coprecipitation obtained by sintering it was mixed with aluminum oxide and gallium oxide, thereby to obtain respective mixture materials. The mixture was mixed with ammonium fluoride used as a flux, and sintered in a crucible at a temperature of 1400 °C in air for 3 hours. Then the sintered material was ground by ball mill in water, washed, separated, dried and sieved thereby to obtain the desired material.

[0059]

having a composition of Y₃(Al_{0.5}Ga_{0.5})₅O₁₂:Ce and capable of emitting green light, 40 parts by weight of the second fluorescent material having a composition of (Y_{0.2}Gd_{0.8})₃Al₅O₁₂:Ce and capable of emitting red light and 100 parts by weight of an epoxy resin were sufficiently mixed to form a slurry. The slurry was poured into the cup which is provided on the mount lead wherein the LED chip was placed. Then the resin containing the fluorescent material was cured at 130 °C for 1 hour. Thus a coating layer containing the fluorescent material in thickness of 120 μm was formed on the LED chip. Concentration of the fluorescent material in the coating layer was increased gradually toward the LED chip. Further, the LED chip and the fluorescent material

protection against extraneous stress, moisture and dust. A lead frame with the coating layer of phosphor formed thereon was placed in a bullet-shaped die and mixed with translucent epoxy resin and then cured at 150 °C for 5 hours. Under visual observation of the light emitting diode formed as described above in the direction normal to the light emitting plane, it was found that the central portion was rendered yellowish color due to the body color of the phosphor.

[0060]

Measurements of chromaticity point, color temperature and color rendering index of the light emitting diode which was obtained as described above and capable of emitting white light gave values of (0.32, 0.34) for chromaticity point (x, y), 89.0 for Ra (color rendering index) and light emitting efficiency of 101 m/W. Further in weatherability tests under conditions of energization with a current of 60 mA at room temperature, 20 mA at room temperature and 20 mA at 60 °C with 90% RH, no change due to the phosphor was observed, showing no difference from an ordinary blue light emitting diode in the service life characteristic.

[0061]

(Example 3)

In0.4Ga0.6N semiconductor having an emission peak at 470 nm was used as a light emitting component. A LED chip was made by flowing TMG (trimethyl gallium) gas, TMI (trimethyl

indium) gas, nitrogen gas and dopant gas together with a carrier gas on a cleaned sapphire substrate and forming a gallium nitride compound semiconductor layer in MOCVD process. A gallium nitride semiconductor layer having N type conductivity and a gallium nitride semiconductor layer having P type conductivity were formed by switching SiH4 and Cp2Mg used as the dopant gas, thereby forming a PN junction. For the semiconductor light emitting component, a contact layer which was gallium nitride semiconductor having P type conductivity, a clad layer which was gallium nitride aluminum semiconductor having P type conductivity and a contact layer which was gallium nitride semiconductor having P type conductivity were formed. An active layer of non-doped InGaN which had single quantum well structure with thickness of about 3 nm was formed between the contact layer having N type conductivity and the clad layer having Ptype conductivity. (Abuffer layer was provided on the sapphire substrate by forming a gallium nitride semiconductor layer at a low temperature.)

After exposing the surfaces of P type and N type semiconductor layers by etching, electrodes were formed by sputtering. After scribing the semiconductor wafer which was made as described above, LED chips were made as light emitting components by dividing the wafer with an external force.

[0062]

10

The LED chip was mounted on a mount lead provided

with a cup at the tip of a silver-plated copper lead frame, by die bonding with an epoxy resin. Electrodes of the LED chip, the mount lead and inner lead were electrically connected by wire boding with gold wires.

5 [0063]

The lead frame with the LED chip attached thereon was placed in a bullet-shaped die and sealed with translucent epoxy resin for molding, which was then cured at 150 °C for 5 hours, thereby to form a blue light emitting diode. The 10 blue light emitting diode was connected to one end face of an acrylic optical guide plate which was polished on all end faces thereof. On one surface and side face of the acrylic plate, screen printing was applied by using barium titanate dispersed in acrylic binder as white color reflector, which was then cured.

[0064]

For the phosphor, a fluorescent material capable of emitting yellow light of a relatively short wavelength and a fluorescent material capable of emitting yellow light of a relatively long wavelength were used as two or more kinds of yttrium-aluminum oxide fluorescent material activated with cerium of different compositions. Rare earth elements of Y, Gd and Ce were dissolved in an acid in stoichiometrical proportions, and the solution was coprecipitated with oxalic acid. Oxide of the coprecipitate obtained by sintering the

precipitate was mixed with aluminum oxide. The mixture was mixed with ammonium fluoride used as a flux, and sintered in a crucible at a temperature of 1400 °C in air for 3 hours. Then the sintered material was ground by ball mill in water, washed, separated, dried and sieved thereby to obtain the desired material.

[0065]

100 Parts by weight of the fluorescent material having a composition of  $(Y_{0.8}Gd_{0.2})_3Al_5O_{12}$ :Ce and capable of emitting yellow light of a relatively short wavelength and 100 parts by weight of the fluorescent material having a composition of (Y_{0.4}Gd_{0.6})₃Al₅O₁₂:Ce and capable of emitting yellow light of a relatively long wavelength, prepared in a process similar to that of the former, and 1000 parts by weight of an acrylic resin were well mixed and formed, by extrusion molding, into a fluorescent material layer as color conversion material in thickness of about 180  $\mu m$ . The fluorescent material layer was cut into the same size as the principal light emitting plane of the optical guide plate, and arranged on the optical quide plate thereby to form the light emitting device. Measurements of chromaticity point and color rendering index of the light emitting device gave values of (0.33, 0.34) for chromaticity point (x, y) and 88.0 for Ra (color rendering index). Light emitting efficiency of 101 m/W was obtained. in weatherability tests under conditions 25 Further

energization with a current of 60 mA at room temperature, 20 mA at room temperature and 20 mA at 60 °C with 90% RH, no change due to the fluorescent material was observed. Similarly, desired chromaticity point can be maintained even when the wavelength of light emitted by the light emitting component is changed by changing the concentration of the fluorescent material.

[0066]

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[Effect of the Invention]

According to the present invention, by using a high-output light emitting component of nitride compound semiconductor and two or more kinds of phosphors of different compositions which emit light upon excitation by the light from the light emitting component, a light emitting device which maintains a high light emitting efficiency over a long period of operation with a high luminance and is capable of emitting light of desired color can be made. The light emitting component which excites the fluorescent material emits light of a short wavelength and is capable of exciting the fluorescent material efficiently, and the light radiated isotropically by the fluorescent material is not absorbed by the light emitting layer of the light emitting component. Therefore, even higher efficiency of emitting light is made possible when the light emitting component is arranged on a reflective material. With energy saving performance, high reliability, compact

construction and capability to change color temperature, the present invention can open up new applications containing display and illumination in automobile, aircraft and electric appliances in general, as well as outdoor use such as buoys for harbors and ports and sign and illumination for expressways. Also the light emitting diode of the present invention is better for the human eyes because white light imposes less stimulation to the eye when watched for a long period of time.

[0067]

invention, in particular, makes it possible to obtain a light emitting device capable of emitting white light having desired components with high luminance, with minimum color shift and deterioration in light emission efficiency, even when used over an extended period of time. Also a light emitting device of high color rendering index can be made by using two or more kinds of fluorescent materials of different compositions. Moreover, a light emitting device which has favorable characteristics for mass production and is capable of emitting light of constant color can be made by adjusting the compositions and concentrations of the fluorescent materials, even when the wavelength of light emitted by the light emitting component deviates.

[0068]

25 By making the light emitting device in the specific

construction as described in claim 2 of the present invention, it is made possible to emit desired light with minimum color shift and minimum deterioration in light emission efficiency, even when used over an extended period of time.

5 [0069]

Bymaking the light emitting device in the construction as described in claim 3 of the present invention, it is made possible to emit white light with minimum color shift and minimum deterioration in light emission efficiency, even when used over an extended period of time.

[0070]

By making the light emitting device in the construction as described in claim 4 of the present invention, it is made possible to emit white light with minimum color shift and minimum deterioration in light emission efficiency, even when used over an extended period of time.

[0071]

Bymaking the light emitting device in the construction as described in claim 5 of the present invention, it is made 20 possible to emit desired light with minimum color shift and minimum deterioration in light emission efficiency, even when used over an extended period of time.

[0072]

By making the light emitting device in the construction as described in claim 6 of the present invention, it is made

possible to emit light more efficiently with minimum color shift and minimum deterioration in light emission efficiency, even when used over an extended period of time.

[0073]

5

By making the light emitting device in the construction as described in claim 7 of the present invention, it is made possible to emit white light more uniformly in a planar construction with minimum color shift and minimum deterioration in light emission efficiency, even when used over an extended 10 period of time.

[0074]

By making the light emitting diode in the construction as described in claim 8 of the present invention, it is made possible to emit white light containing RGB components with 15 high luminance, with minimum color shift and minimum deterioration in light emission efficiency, even when used over an extended period of time under outdoor environment. [Brief Description of the Drawings]

- Fig. 1 is a schematic sectional view of the [Fig. 1] light emitting device of the present invention.
  - Fig. 2 is a schematic sectional view of the [Fig. 2] planar light source which is another light emitting device of the present invention, while (A) showing the planar light source having the phosphor between the optical guide plate and the light emitting diode, and (B) showing the planar light

source having the phosphor on the principal plane of the optical guide plate.

- [Fig. 3] Fig. 3 is a schematic sectional view of the light emitting diode which is another light emitting device 5 of the present invention.
  - [Fig. 4] Fig. 4(A) shows an example of absorption spectrum of the first and the second phosphors used in the present invention, and Fig. 4(B) shows an example of emission spectrum of the first and the second phosphors used in the present invention.
- 10 [Fig. 5] Fig. 5 shows an example of emission spectrum of the light emitting component used in the present invention.
  - [Fig. 6] Fig. 6 shows the results of weatherability test for the comparison of the present invention with the reference light emitting device, while (A) shows a relation between the luminance retaining ratio and the time, and (B) is a graph

showing a relation between the color tone and the time.

- [Fig. 7] Fig. 7 shows the results of reliability test for the comparison of the present invention with the reference light emitting device, while (A) shows a relation between the luminance retaining ratio and the time, and (B) is a graph showing a relation between the color tone and the time.
- [Fig. 8] Fig. 8 shows the chromaticity diagram of light which the light emitting device of the present invention can emit. Points A and B indicate the colors of light emitted by the light emitting device and points C and D indicate the colors

of light emitted by two kinds of phosphors.

[Description of the Reference Numerals]

- 101, 210: Molding material wherein phosphor is contained
- 102, 202, 302: Light emitting component
- 5 103, 303: Conductive wire
  - 104: Casing
  - 105: External electrode
  - 201: Color conversion material
  - 203: Support
- 10 204: Optical guide plate
  - 205, 207: Reflective material
  - 206: Diffusion sheet
  - 301: Coating material wherein phosphor is contained
  - 304: Molding material
- 15 305: Mount lead
  - 306: Inner lead

[Document Name] Abstract

[Abstract]

[Object] It is to provide a light emitting device used in back light source, illuminating switch, signal, display, 5 LED display, indicator, etc and particularly to provide a light emitting device which emits light of desirable color with high luminance and high efficiency regardless of the operating environment.

[Means for solving] The light emitting device has a light emitting component using a gallium nitride semiconductor as a light emitting layer and a phosphor which absorbs at least a part of light emitted by the light emitting component to emit light of a wavelength longer than that of the light emitted by the light emitting component. The phosphor is composed of two or more kinds of yttrium-aluminum oxide fluorescent materials activated with cerium having different compositions.

Fig. 1

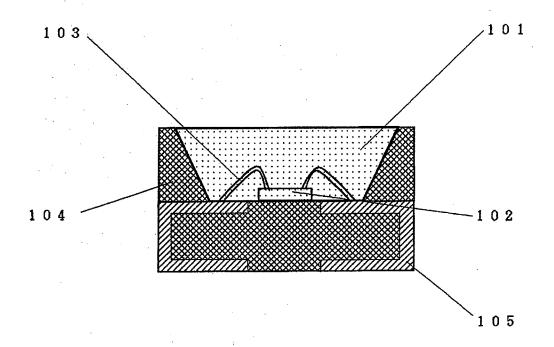
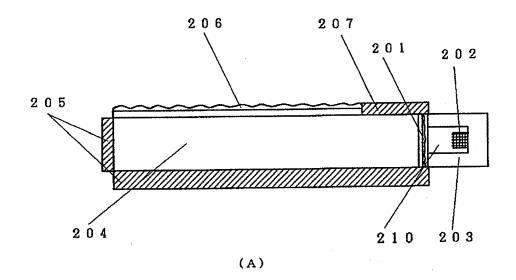


Fig. 2



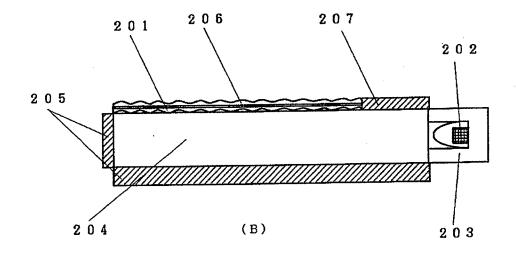
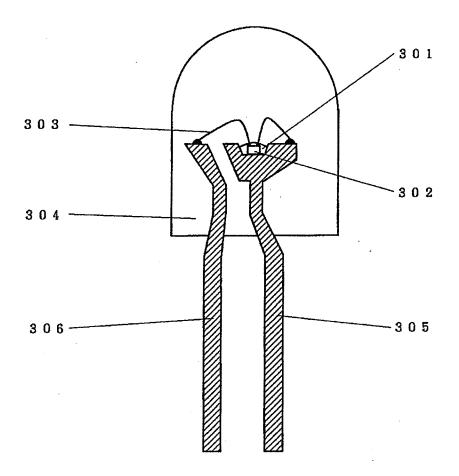
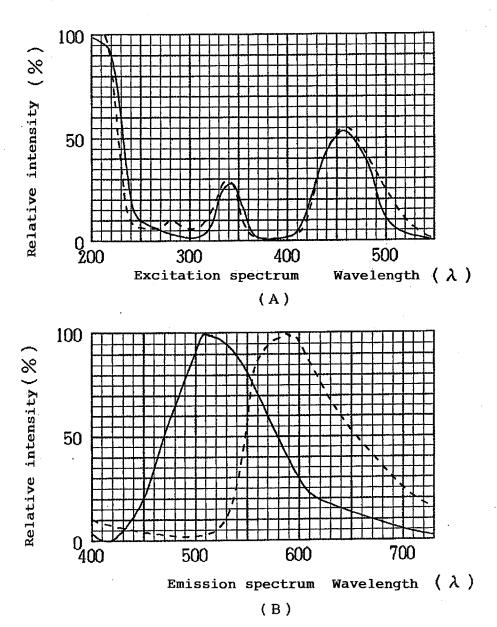
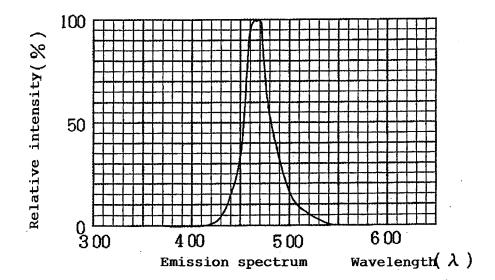


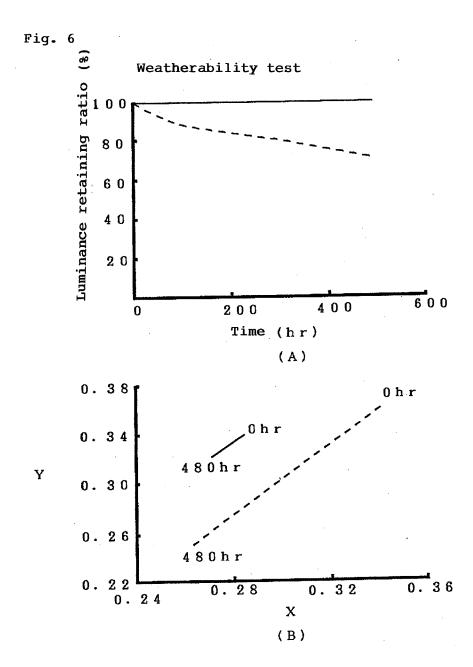
Fig. 3





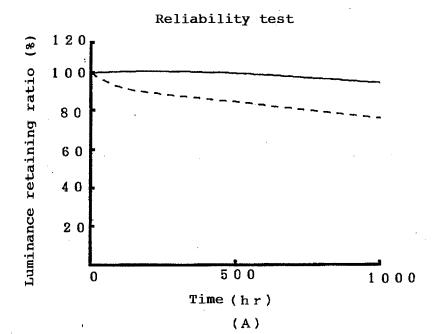








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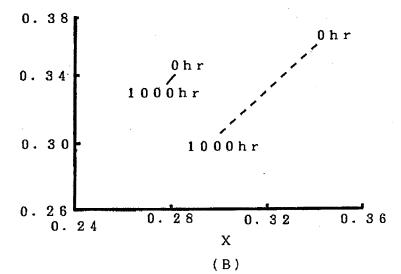
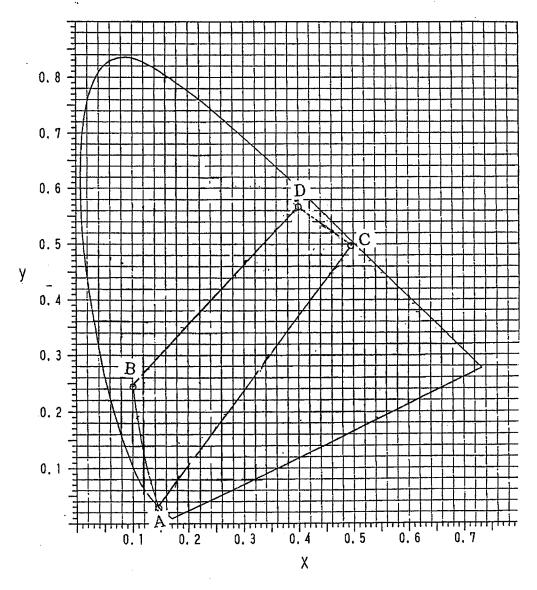


Fig. 8

Fig. 8



Electronic Patent Application Fee Transmittal						
Application Number:	12	942792				
Filing Date:	09	-Nov-2010				
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY					
First Named Inventor/Applicant Name:	Yo	shinori Shimizu				
Filer:	Da	vid Richard Anderso	on/Patti Young	1		
Attorney Docket Number:	00	20-5147PUS12				
Filed as Large Entity						
Utility under 35 USC 111(a) Filing Fees						
Description		Fee Code	Quantity	Amount	Sub-Total in USD(\$)	
Basic Filing:						
Pages:						
Claims:						
Miscellaneous-Filing:						
Petition:						
Patent-Appeals-and-Interference:						
Post-Allowance-and-Post-Issuance:						
Extension-of-Time:						
Extension - 1 month with \$0 paid		1251	1	150	150	

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Miscellaneous:				
	Tot	al in USD	(\$)	150

Electronic Acknowledgement Receipt				
EFS ID:	12895060			
Application Number:	12942792			
International Application Number:				
Confirmation Number:	2357			
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY			
First Named Inventor/Applicant Name:	Yoshinori Shimizu			
Customer Number:	2292			
Filer:	David Richard Anderson/Patti Young			
Filer Authorized By:	David Richard Anderson			
Attorney Docket Number:	0020-5147PUS12			
Receipt Date:	30-MAY-2012			
Filing Date:	09-NOV-2010			
Time Stamp:	16:47:56			
Application Type:	Utility under 35 USC 111(a)			

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1		20120520 Assessed as seek as dif	552057		1.2
1		20120530Amendment.pdf	ff64cf1130886a10386e6912b651d591c4ea 97ab	yes	12
	Multip	part Description/PDF files in .	zip description	'	
	Document De	escription	Start	Ei	nd
	Miscellaneous Inc	1		1	
	Extension o	2	2		
	Amendment/Req. Reconsiderat	3	3		
	Claim	Claims			
	Applicant Arguments/Remarks	s Made in an Amendment	8	12	
Warnings:					
Information:					
2	Miscellaneous Incoming Letter	20120530 Verified English Transl	1877581	no	59
		ation of JP09081010.pdf	01aa2aafa02b5f3d543e9cf39d23cf15e9707 9ba		
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3	3 Fee Worksheet (SB06)		30135	<u>.</u> -	2
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#### New International Application Filed with the USPTO as a Receiving Office

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Approved for use through 01/31/2014. OMB 0651-0032

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(				Complete if Known				
	) A NIC	`		Application Nur	nber	12/942,792	Conf. No.: 2357	
FEE TF	KANS	SIVII I I #	<del>∖</del> ∟ ⊦	Filing Date		November 09, 20	010	
			L	First Named Inventor Yoshinor		Yoshinori SHIMI	ZU	
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	-/	Art Unit		2812				
TOTAL AMOUNT OF PA	YMENT (\$	) 150.00		Attorney Docke	t No.	0020-5147PUS1	2	
METHOD OF PAYME	NT (check a	ll that apply)						
Check Credit	Card	Money Order	None	Other (	please ide	ntify):		
✓ Deposit Account	Check Credit Card Money Order None Other (please identify):  Deposit Account Deposit Account Number: 02-2448  Deposit Account Name: Birch, Stewart, Kolasch & Birch, LLP							
For the above-ider	tified deposit	account, the Direc	tor is here					
Charge fee(	s) indicated b	elow		Charg	je fee(s)	indicated below,	except for the filing fee	
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FEE CALCULATION								
1. BASIC FILING, SEA	RCH, AND	EXAMINATION	FEES					
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Application Type	Fee (\$)	Small Entity Fee (\$)	Fee (\$)	Small Entity Fee (\$)	Fee	Small Entity (\$) Fee (\$)	Fees Paid (\$)	
Utility	380	190	620	310	250			
Design	250	125	120	60	160	80		
Plant	250	125	380	190	200	100		
Reissue	380	190	620	310	750	375		
Provisional	250	125	0	0	0	0		
2. EXCESS CLAIM FE	ES						Small Entity	
<u>Fee Description</u> Each claim over 20	(inaludina T	Paigarrag)				Fee (\$)	Fee (\$)	
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3. APPLICATION SIZE If the specification and	FEE	exceed 100 sheet	s of nane	r (evoludina e	lectroni	cally filed secu	ience or computer	
listings under 37 C	FR 1.52(e)	the application	size fee	due is \$310 (\$	155 for	small entity) for	or each additional 50	
sheets or fraction t	hereof. See	35 U.S.C. 41(a)	(1)(G) an	d 37 CFR 1.1	6(s).	• •		
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4. OTHER FEE(S)				•			Fees Paid (\$)	
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Other (e.g., late filing surcharge): 1251-1 mo. EOT 150.00								
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Signature			Re	gistration No. ₄ tomey/Agent)	0,439	Teleph	one 703-205-8000	
Name (Print/Type) D. Richar	d Anderson					Date N	fay 30, 2012	

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PETITION	FOR EXTENSION OF TIME UNDER	Docket Number (Option 0020-5147PUS12	Docket Number (Optional) 0020-5147PUS12			
Application N	lumber ^{12/942} ,792		Filed November 09, 2010			
For LIGHT	EMITTING DEVICE AND DISPLAY					
Art Unit 2812	2		Examiner A.B. MUSTA	APHA		
This is a requapplication.	uest under the provisions of 37 CFR 1,136	6(a) to extend the per	iod for filing a reply in the	e above identified		
The requeste	ed extension and fee are as follows (check	time period desired	and enter the appropriate	e fee below):		
		<u>Fee</u>	Small Entity Fee	. 150.00		
	One month (37 CFR 1.17(a)(1))	\$150	<b>\$75</b>	\$150.00		
	Two months (37 CFR 1.17(a)(2))	\$560	\$280	\$		
	Three months (37 CFR 1.17(a)(3))	\$1270	\$635	\$		
	Four months (37 CFR 1.17(a)(4))	\$1980	\$990	\$		
	Five months (37 CFR 1.17(a)(5))	\$2690	\$1345	\$		
Applican	t claims small entity status. See 37 CFR 1	1.27.				
A check	in the amount of the fee is enclosed.					
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	assignee of record of the entire Statement under 37 CFR 3.					
	attorney or agent of record. Re	gistration Number_	40,439			
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D. Dieker	Signature			Date		
D. RICHARD	d Anderson  Typed or printed name		703-205-8000 	ne Number		
NOTE: Signature		ire interest or their services	·			
signature is require	s of all the inventors or assignees of record of the enti red, see below.	ire interest or their represer	πατινe(s) are required. Submit n	nultiple forms if more than one		
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INIE	ORMATION	LDICC	COUDE	Application Number	12/942,792		
				Filing Date	11-09-10		
SIA	TEMENT	BY APP	PLICANT	First Named Inventor	Yoshinori Shimizu		
				Art Unit	2812		
	(Use as many sheets as necessary)			Examiner Name	A.B. MUSTAPHA		
Sheet	1	of	2	Attorney Docket Number	0020-5147PUS12		

			U.S. PATE	NT DOCUMENTS	
Examiner initial *	Cite	Document Number	Publication Date	Name of Patentee or	Pages, columns, Lines, Where
initiai "	No.	Number - Kind Code ² (if known)	MM-DD-YYYY	Applicant of Cited Document	Relevant Passages or Relevant Figures Appear
	1	US-2006/0067668 - A1	03-30-2006	KITA	
	2	US-2008/0128735 - A1	06-05-2008	YOO et al.	\$\$\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
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INFOR	MATION D	ISCI	OSLIBE	Application Number	12/942,792	
	MENT BY			Filing Date	11-09-10	
SIAIL	INITIAL DI	AFF	LICANI	First Named Inventor	Yoshinori Shimizu	
(Us	e as many sheets a	s neces	sary)	Art Unit	2812	
				Examiner Name	A.B. MUSTAPHA	
Sheet	2	of	2	Attorney Docket Number	0020-5147PUS12	

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	4	U.S. Office Action, dated January 9, 2012, for U.S. Application No. 12/947,470.	300000		
	5	U.S. Office Action, dated March 13, 2012, for U.S. Application No. 13/210,027.			
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Docket No.: 0020-5147PUS12

(Patent)

# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

12/942,792

Confirmation No.: 2357

Filed:

November 09, 2010

Art Unit:

2812

For:

LIGHT EMITTING DEVICE AND DISPLAY

Examiner:

A.B. MUSTAPHA

# LETTER REGARDING COPENDING APPLICATION

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Commissioner:

Under the provisions of MPEP § 2001.06(b), the Examiner is hereby advised of the following copending U.S. Application:

Appl. No.

Filing Date

Group

13/210,027

August 15, 2011

2812

The subject matter contained in the above-listed copending U.S. application may be deemed to relate to the present application, and thus may be material to the prosecution of this instant application.

The above-listed co-pending application is not to be construed as prior art. By bringing the above-listed application to the attention of the Examiner, Applicants do NOT waive any confidentiality concerning the above-listed co-pending application or this application. See MPEP § 101.

Application No.: 12/942,792 Docket No.: 0020-5147PUS12 Page 2 of 2

If necessary, the Director is hereby authorized in this, concurrent, and future replies to charge any fees required during the pendency of the above-identified application or credit any overpayment to Deposit Account No. 02-2448.

Dated:

APR 5 2012 Respectfully submitted,

D. Richard Anderson

Corvia Canusa 64042

rd Anderson
jon No: 40439

COR INA TANAS A

Registration No.: 40439

BIRCH, STEWART, KOLASCH & BIRCH, LLP

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Electronic Acknowledgement Receipt		
EFS ID:	12466593	
Application Number:	12942792	
International Application Number:		
Confirmation Number:	2357	
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY	
First Named Inventor/Applicant Name:	Yoshinori Shimizu	
Customer Number:	2292	
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# National Stage of an International Application under 35 U.S.C. 371

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# New International Application Filed with the USPTO as a Receiving Office

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Searching PAJ 1/1 ページ

# PATENT ABSTRACTS OF JAPAN

(11)Publication number: 09-116225 (43)Date of publication of application: 02.05.1997

(51)Int.CI. H01S 3/18

(21)Application number: 07–272321 (71)Applicant: HITACHI LTD (22)Date of filing: 20.10.1995 (72)Inventor: NIWA ATSUKO

OTOSHI SO

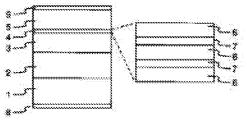
KURODA TAKARO TANAKA TOSHIAKI WATANABE AKISADA

## (54) SEMICONDUCTOR LIGHT EMITTING DEVICE

# (57)Abstract:

PROBLEM TO BE SOLVED: To reduce the threshold carrier density of a gallium nitride—based compound semiconductor laser by reducing the state density of a valence band and increasing the transition probability of the band.

SOLUTION: A quantum well active layer 4 having a biaxial tensile strain is grown on a substrate crystal 1 having plane orientation of (1–100)—plane, (11–20)—plane, or an equivalent plane, and a resonator is constituted in the direction perpendicular to the (0001)—direction. Therefore, the state density of the upper part of a valence band can be reduced and, at the same time, the transition probability of the band can be increased. In addition, a gallium nitride—based compound semiconductor laser can be obtained, because the threshold current density can be reduced.



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#### **CLAIMS**

## [Claim(s)]

[Claim 1]A semiconductor light emitting element comprising material whose grating constant in the state characterized by comprising the following where it is formed on a field or a field equivalent to this, and optically biaxial stress does not have a well layer of the above-mentioned quantum well active layer is smaller than a grating constant of the first crystal of the above. It is a cladding layer of a bilayer of the first conductivity type and the second conductivity type on the first crystal that comprises a compound semiconductor at least and has wurtzite structure.

It is a semiconductor light emitting element which grows epitaxially a quantum well active layer inserted into the above-mentioned cladding layer, and the above-mentioned quantum well active layer is a gap of less than 10 degrees from a field (1-100).

[Claim 2] A semiconductor light emitting element comprising material whose grating constant in the state characterized by comprising the following where it is formed on a field or a field equivalent to this, and optically biaxial stress does not have a well layer of the above-mentioned quantum well active layer is smaller than a grating constant of the first crystal of the above. It is a cladding layer of a bilayer of the first conductivity type and the second conductivity type on the first crystal that comprises a compound semiconductor at least and has wurtzite structure.

It is a semiconductor light emitting element which grows epitaxially a quantum well active layer inserted into the above-mentioned cladding layer, and the above-mentioned quantum well active layer is a gap of less than 10 degrees from a field (11-20).

[Claim 3]A semiconductor light emitting element, wherein a waveguide is formed in the direction vertical to the [0001] directions in a semiconductor light emitting element given in the 1–2nd clauses of a range of claim for patent.

[Claim 4]A semiconductor light emitting element, wherein the above-mentioned quantum well active layer is constituted from InxGayAl1-x-yNzAs1-z (0< x<=1, 0< y<=1, 0< z<=1) in a semiconductor light emitting element of a description by the 1-3rd clauses of a range of claim for patent.

[Claim 5]A semiconductor light emitting element, wherein the first crystal of the above is growing epitaxially on a ZnO board in a semiconductor light emitting element of claim for patent given in the 1–4th clauses of a range.

[Claim 6]A semiconductor light emitting element characterized by oscillation wavelengths being 350 nm - 550 nm in a semiconductor light emitting element of claim for patent given in the 1-5th clauses of a range.

[Translation done.]

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#### **DETAILED DESCRIPTION**

[Detailed Description of the Invention]

[0001]

[Field of the Invention]This invention relates to the light emitting device which used the gallium nitride system compound semiconductor.

[0002]

[Description of the Prior Art]Gallium nitride system compound semiconductors, such as GaN, GaAIN, InGaN, and InGaAIN, are wide gap semiconductors which have a transited [ directly ] type, and are actively studied as a material which constitutes the light emitting device to an ultraviolet area from blue. The present, As a light emitting device using this material. The highintensity blue LED of the double hetero structure which makes a luminous layer Zn dope InGaN layer constituted on silicon on sapphire is known (S. Nakamura et al., Appl. Phys. Lett., 64 (1994) 1687). The gallium nitride system light emitting device which constituted on the ZnO board and decreased the defect by a lattice strain is indicated by the JP,5-206513,A gazette. However, gallium nitride system compound semiconductor laser by current injection was not realized until now.

[0003]

[Problem to be solved by the invention]That the laser oscillation by current injection is difficult in a gallium nitride system compound semiconductor originates in the density of states of the valence band of this material system being large, and threshold carrier density being high. The band structure of the valence-band upper part near gamma point in case [ of wurtzite type GaN / distorted ] there is nothing is shown in drawing 5.

[0004]Incidentally, gamma point is a point that wave number vector k (equivalent to the wave number of the horizontal axis of drawing 5) of the electron inside a crystal is set to "0." Now, in a wurtzite type semiconductor, the split of the energy of gamma point is carried out to three by the crystal field and a spin orbit interaction. In the state of the wave function of gamma point, these three bands are made for convenience to be referred to as hh(heavy hole)1, hh2, and lh (light hole), respectively. The threshold carrier density which the density of states of the valence-band upper part of GaN gives laser oscillation since it is large as compared with common III-V fellows semiconductors, such as GaAs, increased, and the laser oscillation by current injection was difficult. In a wurtzite type semiconductor, since the character of the wave function of hh1 and hh2 is the same, even if it adds distortion, the energy split of hh1 and hh2 hardly changes. For this reason, with a wurtzite type semiconductor, reduction of the density of states by a compressive strain was not able to be expected, either.

[0005]According to the reduction of the density of states of the valence-band upper part and the increase of optical transition probability by the hauling distortion of a gallium nitride system compound semiconductor, this invention reduces threshold carrier density required for laser oscillation, and an object of this invention is to realize the gallium nitride semiconductor laser by current injection.

[0006]

[Means for solving problem]The gallium nitride system semiconductor light emitting device of this invention grows the quantum well active layer which has an optically biaxial hauling distortion on

the field (1–100) of the first crystal with wurtzite structure, and produces a waveguide in a direction vertical to the [0001] axes of the 1st crystal, i.e., the [11–20] direction. The same effect can be acquired also by growing up the active layer which has an optically biaxial hauling distortion on the field (11–20) of the first crystal, and producing a waveguide in a direction vertical to [0001] axes, i.e., the [1–100] direction. The same effect can be acquired also when the plane direction of the first above–mentioned crystal is a field which has a gap of (1–100) or (11–20) to 10 degrees. If it puts in another way, to the surface of a substrate in which an element is formed, the semiconductor light emitting element by this invention has the almost parallel c axis of the crystal which constitutes (1) active layer, and it pulls it to the well layer of (2) active layers, and it has the structural feature that distortion is added.

[0007]For example, the band structure of the valence—band upper part near gamma point at the time of adding 2% of optically biaxial hauling distortion to wurtzite type GaN becomes like <u>drawing 6</u>. By impressing hauling distortion as compared with <u>drawing 5</u> shows that Ih band which consists of a z orbit shifts to the upper part, and the density of states of the valence—band upper part of a direction parallel to c axis, i.e., [0001] axes, decreases substantially. That is, change of the energy (vertical axis) over the wave number (horizontal axis) of a direction parallel to c axis becomes sudden, and density of states is decreasing. Therefore, the density of states of a valence band can be reduced by constituting a quantum well active layer on a direction vertical to [0001] axes, i.e. (1–100), a field, a field, or a field equivalent to this, and considering it as the structure which impressed hauling distortion.

[0008]When a quantum well is formed on a field (1–100) or (11–20) a field, optical transition probability has a polarization direction dependency with quantum well side Uchi's anisotropy. For example, the polarization dependency of the transition-matrix element in gamma point of a quantum well that a plane direction is (1–100) becomes as it is shown in Table 1 as compared with the case of the distortionless quantum well constituted in the field (0001). Table 1 shows the calculation result of the optical matrix element in the band end in a GaN quantum well. [0009]

[Table 1] 表 1

基板面偏光	(0001) 無歪	(1-100) 2%引っ張り歪
TE-₹ド	7.62 eV	13.2 eV (偏光 [0001])
, m. – 1		0.92 eV (偏光 [11-20])
TMモード	0 eV	1.05 eV

[0010] Table 1 shows that transition probability can be enlarged about 2 times in the hauling distortion quantum well on a field (1–100), if a waveguide is formed in a direction vertical to [0001], i.e., the [11–20] direction, (the energy value in front shows the ease of producing of optical transition, and transition probability is so high that it is large). By this, a gain increases, threshold carrier density required for an oscillation is reduced, and a gallium nitride semiconductor laser can be realized.

[0011]

[Mode for carrying out the invention]The first working example of this invention is described using <u>drawing 1</u>.

[0012] This multiplex quantum well laser like a graphic display on the field (1–100) n type ZnO board 1, InGaN buffer layer 2 which carries out lattice matching to the substrate 1, n–InGaAlN layer 3 which doped Si, the active layer 4 which consists of an undoping multiplex quantum well, and p–InGaAlN layer 5 which doped Mg are laminated successively, and is constituted. These

each layers grow epitaxially with a gas source molecular beam grown method. The thickness of the buffer layer 2, n-InGaAlN layer 3, and p-InGaAlN layer 5 is 2 micrometers, 0.15 micrometer, and 0.15 micrometer, respectively. The undoping multiplex quantum well active layer 4 has the double quantum well structure where the In_{0.2}Ga_{0.6}aluminum_{0.2}N barrier layer (8 nm of thickness) 6 and the In_{0.1}Ga_{0.9}N well layer (4 nm of thickness) 7 were laminated by turns, as expanded and shown. The composition ratio of the well layer 7 is set up here so that gap deltaa/a of a future grating constant may be -1.8%, when the grating constant of ZnO is set to a, and an optically biaxial hauling distortion is impressed. After vapor-depositing the n side In electrode 8 at the rear face of the substrate 1 of the wafer produced by making it above and vapor-depositing Al electrode 9 to the p type InGaAlN layer 5, a cleavage is carried out a field (11-20), a resonator about 800 micrometers in length is formed in the [11-20] direction (side side of the active layer 4 of drawing 1), and a semiconductor laser is produced. In the room temperature, continuous oscillation of this semiconductor laser was carried out with about 50 mA of threshold current. The oscillation wavelength was about 420 nm.

[0013]In this example, the plane direction of the ZnO board was made into the field (11–20), and when the semiconductor laser which formed the resonator in the [1-100] direction was produced similarly, what has almost equivalent threshold current and oscillation wavelength was obtained. In this example, the plane direction of the ZnO board was made into Men who inclined 10 degrees in the [0001] directions from the field (1-100), and when the semiconductor laser which formed the resonator in the [11-20] direction was produced similarly, what has almost equivalent threshold current and oscillation wavelength was obtained.

[0014]Next, the second working example of this invention is described using drawing 2. [0015]The presentation x of In1-xGaxN grown-up on the field (1-100) n type ZnO board 1 like a graphic display on the InGaN presentation inclined layer 11 which changes continuously from 0.8 to 0.5, The In_{0.5}Ga_{0.5}N buffer layer 12 which carries out lattice matching to the presentation inclined layer 11, n-InGaAIN layer 13 which doped Si, the active layer 14 which consists of an undoping multiplex quantum well, and p-InGaAIN layer 15 which doped Mg are laminated successively, and is constituted. These each layers grow epitaxially with a gas source molecular beam grown method. The thickness of the buffer layer 12, n-InGaAlN layer 13, and p-InGaAlN layer 15 is 2 micrometers, 0.15 micrometer, and 0.15 micrometer, respectively. The undoping multiplex quantum well active layer 14 has the double quantum well structure where the  $In_{0.35}Ga_{0.5}$ aluminum_{0.15}N barrier layer (5 nm of thickness) 16 and the  $In_{0.2}Ga_{0.8}$ N well layer (3 nm of thickness) 17 were laminated by turns, as expanded and shown. The composition ratio of the well layer 17 is set up here so that gap deltaa/a of a future grating constant may be -2.0%, when the grating constant of an In_{0.5}Ga_{0.5}N buffer layer is set to a, and an optically biaxial hauling distortion is impressed. After vapor-depositing the n side In electrode 8 at the rear face of the substrate 1 of the wafer produced by making it above and vapor-depositing Al electrode 9 to the p type InGaAlN layer 5, a cleavage is carried out a field (11-20), a resonator about 800 micrometers in length is formed in the [11-20] direction, and a semiconductor laser is produced. In the room temperature, continuous oscillation of this semiconductor laser was carried out with about 60 mA of threshold current. The oscillation wavelength was about 450 nm. [0016]Although InGaN was used as a quantum well layer and ZnO was used as a substrate in the above-mentioned working example, composition used for the light emitting device of this invention can be considered as the composition which is not limited to this, for example, is shown in drawing 3 - drawing 4.

[0017]The semiconductor laser shown in drawing 3 on the field (1–100) of the n type ZnO board 1, InGaN buffer layer 2 which carries out lattice matching to the substrate 1 grows, and on this buffer layer 2, n−InGaAlN layer 3, the undoping single quantum well active layer 21, and the p− InGaAIN cladding layer 5 are laminated successively, and are constituted. These each layers grow epitaxially with a gas source molecular beam grown method. The quantum well active layer 21 has here the single quantum well structure where the  $GaN_{0.95}As_{0.05}$  well layer (5 nm of

thickness) 22 was inserted into the  $\rm In_{0.2} \rm Ga_{0.6} \rm aluminum_{0.2} \rm N$  barrier layer (10 nm of thickness) 23, as expanded and shown. The composition ratio of the well layer 22 is set up here so that gap deltaa/a of a future grating constant may be -1.8%, when the grating constant of ZnO is set to a, and an optically biaxial hauling distortion is impressed. After vapor-depositing the n side In electrode 8 at the rear face of the substrate 1 of the wafer produced by making it above and vapor-depositing Al electrode 9 to the p type InGaAlN layer 5, a cleavage is carried out a field (11–20), a resonator about 800 micrometers in length is formed in the [11–20] direction, and a semiconductor laser is produced. In the room temperature, continuous oscillation of this semiconductor laser was carried out with about 50 mA of threshold current. The oscillation wavelength was about 450 nm.

[0018]On the field (1–100) of the silicon on sapphire 31, InGaN buffer layer 2 grows, n–InGaAlN layer 3, the undoping multiplex quantum well active layer 4, and the p–InGaAlN cladding layer 5 are laminated successively, and the semiconductor laser shown in <u>drawing 4</u> is constituted at this buffer layer 2 top. These each layers grow epitaxially by metal–organic chemical vapor deposition. The quantum well active layer 4 has here the multiple quantum well structure by which the In_{0.2}Ga_{0.6}aluminum_{0.2}N barrier layer (8 nm of thickness) 6 and two cycles of

 $In_{0.1}Ga_{0.9}N$  well layers (4 nm of thickness) 7 were laminated by turns, as expanded and shown.

The composition ratio of the well layer 7 is set up here so that gap deltaa/a of a future grating constant may be -1.8%, when the grating constant of an InGaN buffer layer is set to a, and an optically biaxial hauling distortion is impressed. A part of p-InGaAlN cladding layer 5 of a wafer and quantum well active layer 4 produced by making it above are removed by etching, After exposing the n-InGaAlN cladding layer 3 and vapor-depositing Al electrode 9 to p-cladding layer and n-cladding layer, a cleavage is carried out a field (11–20), a resonator about 800 micrometers in length is formed in the [11–20] direction, and a semiconductor laser is produced. In the room temperature, continuous oscillation of this semiconductor laser was carried out with about 70 mA of threshold current. The oscillation wavelength was about 420 nm.

[0019] This invention is applicable not only to the laser structure shown in the working example but various semiconductor lasers, for example, a distributed feedback laser, a distributed Bragg reflector laser, tunable laser, and laser with an external resonator.

[0020]

[Effect of the Invention]As mentioned above, the gallium nitride system compound semiconductor light emitting device of this invention, Since a plane direction grows the quantum well active layer which has an optically biaxial hauling distortion on the base substance crystal which is a field (1–100) or (11–20) a field and is producing the waveguide in the direction vertical to the [0001] directions, transition probability can be small increased in the density of states of the valence–band upper part. Since a gain increases and threshold current density can be reduced by this, gallium nitride system compound semiconductor laser is realizable. [0021]

[Translation done.]

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#### DESCRIPTION OF DRAWINGS

[Brief Description of the Drawings]

[Drawing 1] The block diagram of the semiconductor laser of this invention working example.

[Drawing 2]The block diagram of the semiconductor laser of this invention working example.

[Drawing 3]The block diagram of the semiconductor laser of this invention working example.

Drawing 4]The block diagram of the semiconductor laser of this invention working example.

[Drawing 5]The figure showing the energy dispersion of the valence-band upper part of wurtzite type GaN in case [ distorted ] there is nothing. .

[Drawing 6] The figure showing the energy dispersion of the valence-band upper part of wurtzite type GaN at the time of impressing optically biaxial hauling distortion 2%.

[Explanations of letters or numerals]

1 -- (1-100) field n type ZnO board, 2 -- InGaN buffer layer, 3 -- n-InGaAIN layer, 4 -undoping multiplex quantum well active layer, 5 -- p-InGaAIN layer, 6 -- In_{0.2}Ga_{0.6}aluminum_{0.2}N barrier layer, 7 -- In_{0.1}Ga_{0.9}N well layer, 8 -- In electrode, 9 -- Al electrode, 11 -- InGaN presentation inclined layer, 12 –  $In_{0.5}Ga_{0.5}N$  buffer layer, 13 – n-InGaAIN layer, 14 – undoping multiplex quantum well active layer, 15 -- p-InGaAlN layer, 16 -- In_{0.35}Ga_{0.5}aluminum_{0.15}N barrier layer, 17 — In_{0.2}Ga_{0.8}N well layer, 21 — undoping single quantum well active layer, 22 —  $GaN_{0.95}As_{0.05}$  well layer, 23 —  $In_{0.2}Ga_{0.6}$  aluminum_{0.2}N barrier layer, 31 — silicon on sapphire.

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## (54) 【発明の名称】 半導体発光素子

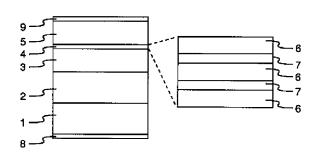
#### (57)【要約】

【課題】窒化ガリウム系化合物半導体レーザでは、価電子帯の状態密度低減と遷移確率増大によるしきい値キャリア密度の低減が必要であった。

【解決手段】面方位が(1-100)面、あるいは(1-20)面、あるいはこれと等価な面である基体結晶上に二軸性の引っ張り歪をもつ量子井戸活性層を成長し、共振器を[0001]方向に垂直な方向に作製する。

【効果】本発明によれば、価電子帯上部の状態密度を低減し、かつ、遷移確率を増大できる。これにより、しきい値電流密度を低減できるため、窒化ガリウム系化合物半導体レーザを実現できる。

## 図1



1

#### 【特許請求の範囲】

【請求項1】少なくとも化合物半導体で構成され、ウルツ鉱構造をもつ第一の結晶上に、第一導電型及び第二導電型の二層のクラッド層と、上記クラッド層に挟まれた量子井戸活性層をエピタキシャル成長してなる半導体発光素子であって、上記量子井戸活性層が(1-100)面から10度以内のずれを有する面、あるいはこれと等価な面上に形成されており、上記量子井戸活性層の井戸層が、二軸性応力の無い状態での格子定数が上記第一の結晶の格子定数より小さい材料で構成されていることを特徴とする半導体発光素子。

【請求項2】少なくとも化合物半導体で構成され、ウルツ鉱構造をもつ第一の結晶上に、第一導電型及び第二導電型の二層のクラッド層と、上記クラッド層に挟まれた量子井戸活性層をエピタキシャル成長してなる半導体発光素子であって、上記量子井戸活性層が(11-20)面から10度以内のずれを有する面、あるいはこれと等価な面上に形成されており、上記量子井戸活性層の井戸層が、二軸性応力の無い状態での格子定数が上記第一の結晶の格子定数より小さい材料で構成されていることを20特徴とする半導体発光素子。

【請求項3】特許請求の範囲第1~2項に記載の半導体発光素子において、[0001]方向と垂直な方向に導波路が形成されていることを特徴とする半導体発光素子。

【請求項4】特許請求の範囲第 $1 \sim 3$ 項に記載の半導体発光素子において、上記量子井戸活性層が $I nxG ayA l1-x-yNzA s1-z (0 < x \le 1 、0 < y \le 1 、0 < z \le 1 )で構成されていることを特徴とする半導体発光素子。$ 

【請求項5】特許請求の範囲第1~4項記載の半導体発 光素子において、上記第一の結晶がZnO基板上にエピ タキシャル成長されていることを特徴とする半導体発光 素子。

【請求項6】特許請求の範囲第1~5項記載の半導体発 光素子において、発振波長が350nm~550nmで あることを特徴とする半導体発光素子。

#### 【発明の詳細な説明】

# [0001]

【発明の属する技術分野】本発明は窒化ガリウム系化合 40 物半導体を用いた発光素子に関する。

# [0002]

【従来の技術】GaN、GaAIN、InGaN、InGaN、InGaAIN等の窒化ガリウム系化合物半導体は直接遷移型を有するワイドギャップ半導体であり、青色から紫外域までの発光素子を構成する材料として盛んに研究されている。現在、この材料を用いた発光素子としてサファイア基板上に構成した<math>ZnドープInGaN層を発光層とするダブルヘテロ構造の高輝度青色LEDが知られている(S.Nakamura et al., Appl. Phys. Lett., 64(199)

4) 1687)。また、ZnO基板上に構成し格子歪による欠陥を減少した窒化ガリウム系発光素子が特開平5-206513公報に開示されている。しかし、これまで電流注入による窒化ガリウム系化合物半導体レーザは実現されていなかった。

## [0003]

【発明が解決しようとする課題】窒化ガリウム系化合物 半導体において電流注入によるレーザ発振が困難である のは、この材料系の価電子帯の状態密度が大きく、しき い値キャリア密度が高いことに起因する。図5にウルツ 鉱型GaNの歪の無い場合のΓ点付近の価電子帯上部の バンド構造を示す。

【0004】因みに、Γ点は結晶内部の電子の波数ベク トルk(図5の横軸の波数に相当)が「0」となる点で ある。さて、ウルツ鉱型半導体では、結晶場とスピン軌 道相互作用によりΓ点のエネルギーは三つにスプリット する。この三つのバンドをΓ点の波動関数の状態で、便 宜的に、それぞれhh (heavy hole) 1、h h2、lh(light hole)と呼ぶことにす る。GaNの価電子帯上部の状態密度はGaAs等の一 般的なIII-V族半導体と比較して大きいため、レー ザ発振を与えるしきい値キャリア密度が増大し、電流注 入によるレーザ発振は困難であった。またウルツ鉱型半 導体では、 h h 1 と h h 2 の波動関数の性質が同じであ るため、歪を加えてもhh1、hh2のエネルギースプ リットはほとんど変化しない。このため、ウルツ鉱型半 導体では圧縮歪による状態密度の低減も期待できなかっ teo

【0005】本発明は窒化ガリウム系化合物半導体の引 30 っ張り歪による価電子帯上部の状態密度の低減と光学遷 移確率の増大により、レーザ発振に必要なしきい値キャ リア密度を低減し、電流注入による窒化ガリウム系半導 体レーザを実現することを目的とする。

#### [0006]

【課題を解決するための手段】本発明の窒化ガリウム系 半導体発光素子は、ウルツ鉱構造をもつ第一の結晶の (1-100) 面上に二軸性の引っ張り歪をもつ量子井 戸活性層を成長し、導波路を第1の結晶の[0001] 軸に垂直な方向、すなわち [11-20] 方向に作製す ることを特徴とする。また、第一の結晶の(11-2 0) 面上に二軸性の引っ張り歪をもつ活性層を成長し、 導波路を [0001] 軸に垂直な方向、すなわち [1-100] 方向に作製することによっても同様の効果を得 ることができる。また、上記の第一の結晶の面方位が (1-100) あるいは(11-20) から10度以内 のずれを有する面である場合にも同様の効果を得ること ができる。換言すれば、本発明による半導体発光素子 は、(1)活性層を構成する結晶の c 軸が素子が形成さ れる基板の表面に対して略平行であり、且つ(2)活性 50 層の井戸層には引っ張り歪が加えられているという構造 3

的な特徴を有する。

【0007】例えばウルツ鉱型GaNに2%の二軸性引 っ張り歪を加えた場合の Γ 点付近の価電子帯上部のバン ド構造は図6のようになる。図5と比較すると、引っ張 り歪を印加することにより z 軌道からなる 1 h バンドが 上側にシフトし c 軸すなわち「0001]軸に平行な方 向の価電子帯上部の状態密度が大幅に低減することがわ かる。即ち、c軸に平行な方向の波数(横軸)に対する エネルギ(縦軸)の変化が急となり、状態密度が低減し ている。したがって、量子井戸活性層を「0001]軸 10 学行列要素の計算結果を示す。 に垂直な方向、すなわち(1-100)面あるいは(1 1-20) 面、またはこれと等価な面上に構成し、引っ*

* 張り歪を印加した構造とすることにより価電子帯の状態 密度を低減することができる。

【0008】また、(1-100)面あるいは(11-20) 面上に量子井戸を形成すると量子井戸面内の異方 性により光学遷移確率は偏光方向依存性をもつ。例え ば、面方位が(1-100)である量子井戸の $\Gamma$ 点にお ける遷移行列要素の偏光依存性は、(0001)面に構 成した無歪の量子井戸の場合と比較すると表1のように なる。表1は、GaN量子井戸におけるバンド端での光

[0009]

【表1】

表 1

基板面偏光	(0001) 無歪	(1-100) 2%引っ張り歪
TEモード	7.62 eV	13.2 eV (偏光 [0001])
,		0.92 eV (偏光 [11-20])
TMモード	0 eV	1.05 eV

【0010】表1より、(1-100)面上の引っ張り 歪量子井戸では導波路を [0001] と垂直な方向、す なわち「11-20]方向に形成すれば、遷移確率を2倍 程度大きくできることがわかる(表中のエネルギ値は光 学遷移の生じ易さを示し、大きいほど遷移確率は高 い)。これにより、利得が増大し、発振に必要なしきい 値キャリア密度が低減され、窒化ガリウム系半導体レー 30 い値電流約50mAで連続発振した。発振波長は約42 ザを実現できる。

# [0011]

【発明の実施の形態】本発明の第一の実施例を図1を用 いて説明する。

【0012】図示のように、この多重量子井戸レーザ は、(1-100)面n型ZnO基板1上に、基板1と 格子整合するInGaNバッファ層2、Siをドープし たn-InGaAIN層3、アンドープ多重量子井戸か らなる活性層4、Mgをドープしたp-InGaAIN 層5が順次積層されて構成される。これらの各層はガス ソース分子線成長法によりエピタキシャル成長される。 バッファ層2、n-InGaAIN層3、p-InGa  $A 1 N 層 5 の 膜厚はそれぞれ、 2 <math>\mu$  m、 0. 1 5  $\mu$  m、 0. 15 μ m である。アンドープ多重量子井戸活性層 4 は、拡大して示したように、Ino.2 Gao.6 Alo.2 N 障壁層(膜厚8nm) 6とIno.1 Gao.9 N井戸層(膜 厚4 nm) 7が交互に積層形成された二重量子井戸構造 を有する。ここで井戸層7の組成比は、ZnOの格子定 数を a としたとき、これからの格子定数のずれ △ a / a が-1.8%となるように設定されており、二軸性の引 っ張り歪が印加されている。以上のようにして得られた ウエハーの基板1の裏面にn側In電極8、p型InG a A 1 N 層 5 に A 1 電極 9 を蒸着したのち、 (11-2 0) 面でへき開し [11-20] 方向(図1の活性層4 の側面側)に長さ約800μmの共振器を形成し半導体 レーザを作製する。本半導体レーザは室温においてしき 0 n mであった。

【0013】本実施例において、ZnO基板の面方位を (11-20) 面とし、共振器を [1-100] 方向に 形成した半導体レーザを同様に作製したところ、しきい 値電流、発振波長はほぼ同等のものが得られた。また、 本実施例において、ZnO基板の面方位を(1-10 0) 面から [0001] 方向に10度傾斜した面とし、 共振器を [11-20] 方向に形成した半導体レーザを 同様に作製したところ、しきい値電流、発振波長はほぼ 40 同等のものが得られた。

【0014】次に本発明第二の実施例を図2を用いて説 明する。

【0015】図示のように、(1-100)面n型Zn O基板 1 上に成長した I n 1-x G a x N の組成 x が 0.8 から0.5まで連続的に変化するInGaN組成傾斜層 11上に、組成傾斜層11に格子整合するIno.5 Ga 0.5 Nバッファ層12、Siをドープしたn-InGa A 1 N層 1 3、アンドープ多重量子井戸からなる活性層 14、Mgをドープしたp-InGaAIN層15が順 次積層されて構成される。これらの各層はガスソース分

子線成長法によりエピタキシャル成長される。バッファ 層12、n-InGaAlN層13、p-InGaAl N層15の膜厚はそれぞれ、 $2 \mu m$ 、 $0.15 \mu m$ 、  $0.15 \mu$  mである。アンドープ多重量子井戸活性層 14は、拡大して示したように、Ino.35 Gao.5 A1 0.15 N障壁層(膜厚5 nm) 16と I n 0.2 G a 0.8 N井 戸層(膜厚3nm)17が交互に積層形成された二重量 子井戸構造を有する。ここで井戸層17の組成比は、 I no.5 Gao.5 Nバッファ層の格子定数をaとしたとき、 これからの格子定数のずれ $\Delta a / a$ が-2.0%となる ように設定されており、二軸性の引っ張り歪が印加され ている。以上のようにして得られたウエハーの基板1の 裏面にn側In電極8、p型InGaAIN層5にAI 電極9を蒸着したのち、(11-20)面でへき開し [11-20] 方向に長さ約800 μ mの共振器を形成 し半導体レーザを作製する。本半導体レーザは室温にお いてしきい値電流約60mAで連続発振した。発振波長 は約450 n mであった。

【0016】上記の実施例では量子井戸層としてInGaN、基板としてZnOを用いたが、本発明の発光素子に使用される構成はこれに限定されず、例えば図3~図4に示す構成とすることができる。

【0017】図3に示した半導体レーザは、n型ZnO 基板1の(1-100)面上に、基板1と格子整合する InGaNバッファ層2が成長され、このバッファ層2 上にn-InGaAIN層3、アンドープ単一量子井戸 活性層21、p-InGaAINクラッド層5が順次積 層されて構成されている。これらの各層はガスソース分 子線成長法によりエピタキシャル成長される。ここで量 子井戸活性層21は、拡大して示したように、GaN 0.95 As 0.05 井戸層 (膜厚5 n m) 22が І n 0.2 Ga 0.6 A 1 0.2 N障壁層(膜厚10nm) 23にはさまれた 単一量子井戸構造を有する。ここで井戸層22の組成比 は、ZnOの格子定数をaとしたとき、これからの格子 定数のずれ $\Delta a/a$ が-1. 8%となるように設定され ており、二軸性の引っ張り歪が印加されている。以上の ようにして得られたウエハーの基板1の裏面にn側In 電極8、p型InGaAIN層5にAI電極9を蒸着し たのち、(11-20) 面でへき開し[11-20] 方 向に長さ約800μmの共振器を形成し半導体レーザを 作製する。本半導体レーザは室温においてしきい値電流 約50mAで連続発振した。発振波長は約450nmで あった。

【0018】図4に示した半導体レーザは、サファイア基板31の(1-100)面上に、InGaNバッファ層2が成長され、このバッファ層2上にn-InGaAIN層3、アンドープ多重量子井戸活性層4、p-InGaAIN分ラッド層5が順次積層されて構成されている。これらの各層は有機金属気相成長法によりエピタキシャル成長される。ここで量子井戸活性層4は、拡大し

【0019】なお、本発明は、実施例に示したレーザ構造に限らず、さまざまな半導体レーザ、例えば分布帰還型レーザ、ブラッグ反射型レーザ、波長可変レーザ、外部共振器付きレーザにも適用できる。

# [0020]

【発明の効果】以上のように、本発明の窒化ガリウム系化合物半導体発光素子は、面方位が(1-100)面、あるいは(11-20)面である基体結晶上に二軸性の引っ張り歪をもつ量子井戸活性層を成長し、導波路を[0001]方向に垂直な方向に作製しているので、価電子帯上部の状態密度を小さく、かつ、遷移確率を増大できる。これにより、利得が増大し、しきい値電流密度を低減できるため、窒化ガリウム系化合物半導体レーザ30を実現できる。

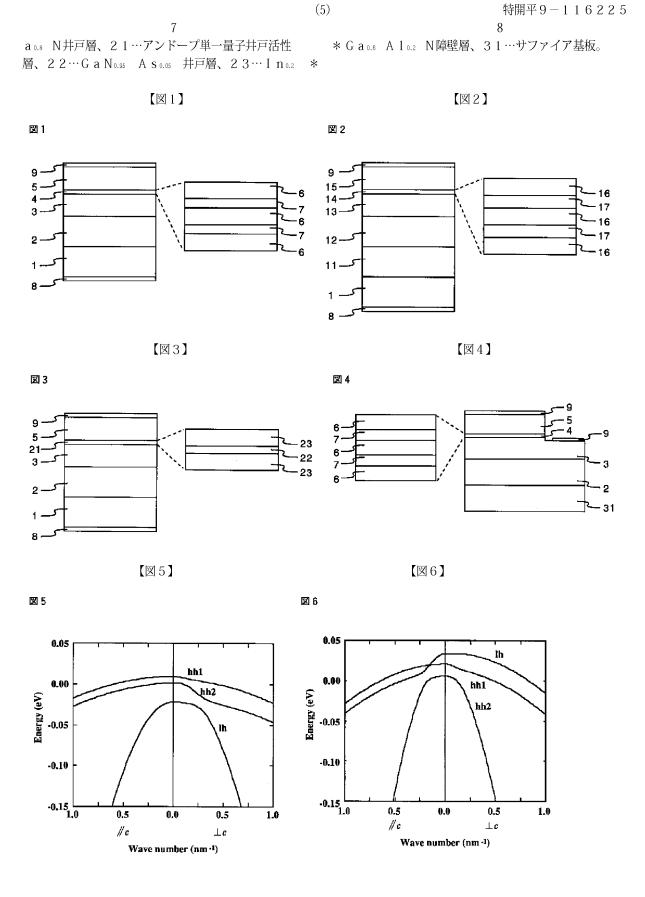
#### [0021]

### 【図面の簡単な説明】

- 【図1】本発明実施例の半導体レーザの構成図。
- 【図2】本発明実施例の半導体レーザの構成図。
- 【図3】本発明実施例の半導体レーザの構成図。
- 【図4】本発明実施例の半導体レーザの構成図。
- 【図5】 歪の無い場合のウルツ鉱型 G a Nの価電子帯上部のエネルギー分散を示す図。。
- 【図6】2%二軸性引っ張り歪を印加した場合のウルツ 40 鉱型GaNの価電子帯上部のエネルギー分散を示す図。

## 【符号の説明】

1 ··· (1-100) 面 n型 Z n O 基板、2 ··· I n G a N バッファ層、3 ··· n - I n G a A I N層、4 ··· アンドープ多重量子井戸活性層、5 ··· p - I n G a A I N層、6 ··· I n o 2 G a o 6 A I o 2 N障壁層、7 ··· I n o 1 G a o 8 N井戸層、8 ··· I n 電極、9 ··· A I 電極、11 ··· I n G a N 組成傾斜層、12 ··· I n o 5 G a o 5 N バッファ層、13 ··· n - I n G a A I N層、14 ··· アンドープ多重量子井戸活性層、15 ··· p - I n G a A I N層、16 ··· I n o 38 G a o 5 A I o 15 N障壁層、17 ··· I n o 2 G



フロントページの続き

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Docket No.: 0020-5147PUS12

(Patent)

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

12/942,792

Confirmation No.: 2357

Filed:

November 09, 2010

Art Unit:

2812

For: LIGHT EMITTING DEVICE AND DISPLAY

Examiner:

A.B. MUSTAPHA

#### INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Commissioner:

Applicant(s) hereby submit(s) an Information Disclosure Statement for consideration by the Examiner.

I. LIST OF PATENTS, PUBLICATIONS OR OTHER INFORMATION

The patents, publications, or other information submitted for consideration by the Office are listed on the attached PTO/SB/08.

- II. COPIES
- a. Copies of foreign patent documents, non-patent literature and other information.
- b. <u>REFERENCES PREVIOUSLY CITED OR SUBMITTED</u>: Copies of any information not provided can be found in one or more of the following applications which has been relied upon for an earlier filing date under 35 U.S.C. § 120:



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Page 2 of 5

# III. CONCISE EXPLANATION OF THE RELEVANCE/OTHER INFORMATION

a. NON-ENGLISH LANGUAGE DOCUMENTS: A concise explanation of the relevance of all non-English language patents, publications, or other information listed is as follows:

An English language abstract is provided (as a partial translation) for the following reference(s): JP-9-116225-A.

A machine generated translation is provided for the following reference(s): JP-9-116225-A.

- b. ENGLISH LANGUAGE SEARCH REPORT OR FOREIGN PATENT OFFICE COMMUNICATION: An English language version of the search report or Foreign Patent Office communication that indicates the degree of relevance is attached.
- ☑ c. OTHER: The following additional information is provided.

A copy of the Office Action, dated January 9, 2012, for copending U.S. Application No. 12/947,470 is provided. US-3,875,456-A, US-5,847,507-A and US-6,600,175-B1, cited in said Office Action, were previously cited in the Information Disclosure Statement filed November 9, 2010. Additionally, US-5,847,507-A was cited by the Examiner in the Office Action dated January 30, 2012, in the present application.

A copy of the Office Action, dated March 13, 2012, for copending U.S. Application No. 13/210,027 is provided. US-5,847,507-A, cited in said Office Action, was previously cited in the Information Disclosure Statement filed November 9, 2012, and was also cited by the Examiner in the Office Action dated January 30, 2012, in the present application.

## IV. STATEMENT UNDER 37 C.F.R. § 1.97(e)

The undersigned hereby states that:

 $\square$  a. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than <u>30</u>

Of

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Page 3 of 5

<u>days</u> prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or

- b. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than **three months** prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or
- C. No item of information contained in the IDS was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing the certification after making reasonable inquiry, no item of IDS was known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of the IDS; or
- d. Some of the items of information in the IDS were cited in a communication from a foreign patent office. Such items were first cited in a communication from a foreign patent office in a counterpart foreign application not more than **three months** prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office. As to the remaining items of information, to the knowledge of the person signing the certification after making reasonable inquiry, such remaining items were not known to any individual designated in 37 C.F.R. § 1.56(c) more than **three months** prior to the filing of this statement.

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 4 of 5

V.	<u>FEES</u>	
	a.	This Information Disclosure Statement is being filed concurrently with the filing
of a n	ew pate	nt application or Request for Continued Examination. No fee is required.
	b.	This Information Disclosure Statement is being filed within three months of the
filing	date of	an application. No fee is required.
	c.	This Information Disclosure Statement is being filed before the mailing date of a
first A	Action o	n the merits. No fee is required. If a first Office Action on the merits has issued,
please	consid	ler this IDS under 37 C.F.R. § 1.97(c) and see the statement under 37 C.F.R.
§ 1.97	(e) abov	ve. If no statement has been made, charge our deposit account for the required fee.
	d.	This Information Disclosure Statement is being filed before the mailing date of a
Final	Office	Action or before the mailing date of a Notice of Allowance (see 37 C.F.R.
§ 1.97	(c)(1)).	
		No statement. The fee as required by 37 C.F.R. § 1.17(p) is provided.
		or
	☑	See the above statement. No fee is required.
	e.	This Information Disclosure Statement is being filed after the mailing date of a
Final (	Office A	Action or <u>after</u> the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(d)),
		ent above. The fee as required by 37 C.F.R. § 1.17(p) is provided.
VI.	PAYM	IENT OF FEES
		The required fee is listed on the attached Fee Transmittal.
	$\square$	No fee is required.

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If the Examiner has any questions concerning this IDS, please contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the USPTO is requested to consider this IDS under the proper rule and charge the appropriate fee to Deposit Account No. 02-2448.

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UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
12/942,792	11/09/2010	Yoshinori Shimizu	0020-5147PUS12	2357	
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FALLS CHURG	CH, VA 22040-0747	ART UNIT PAPER NUMBER			
		2812			
			NOTIFICATION DATE	DELIVERY MODE	
			01/30/2012	ELECTRONIC	

# Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Notice of the Office communication was sent electronically on above-indicated "Notification Date" to the following e-mail address(es):

mailroom@bskb.com

	Application No.	Applicant(s)					
Office Action Commence	12/942,792	SHIMIZU ET AL.					
Office Action Summary	Examiner	Art Unit					
	ABDULFATTAH MUSTAPHA	2812					
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence ad	idress				
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.  - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).							
Status							
1) Responsive to communication(s) filed on 09 No	ovember 2010						
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3) An election was made by the applicant in response		set forth during th	e interview on				
; the restriction requirement and election	·	•					
4) Since this application is in condition for allowan	·		e merits is				
closed in accordance with the practice under E	•						
Disposition of Claims							
5) Claim(s) 1-19 is/are pending in the application.							
5a) Of the above claim(s) is/are withdraw	n from consideration.						
6) Claim(s) is/are allowed.							
7)⊠ Claim(s) <u>1-17 and 19</u> is/are rejected.							
8) Claim(s) 18 is/are objected to.							
9) Claim(s) are subject to restriction and/or	election requirement.						
Application Papers							
10) The specification is objected to by the Examiner							
11)⊠ The drawing(s) filed on 09 November 2010 is/ar	re: a)⊠ accepted or b)□ objecto	ed to by the Exan	niner.				
Applicant may not request that any objection to the o	drawing(s) be held in abeyance. See	e 37 CFR 1.85(a).					
Replacement drawing sheet(s) including the correction	on is required if the drawing(s) is obj	ected to. See 37 C	FR 1.121(d).				
12) ☐ The oath or declaration is objected to by the Exa	aminer. Note the attached Office	Action or form P	ΓΟ-152.				
Priority under 35 U.S.C. § 119							
13) ☐ Acknowledgment is made of a claim for foreign a) ☐ All b) ☐ Some * c) ☐ None of:	priority under 35 U.S.C. § 119(a)	-(d) or (f).					
1. ☐ Certified copies of the priority documents	s have been received.						
2. Certified copies of the priority documents	have been received in Application	on No					
3. Copies of the certified copies of the priority documents have been received in this National Stage							
application from the International Bureau	application from the International Bureau (PCT Rule 17.2(a)).						
* See the attached detailed Office action for a list of the certified copies not received.							
Attachment(s)	🗖						
Notice of References Cited (PTO-892)     Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) ☐ Interview Summary Paper No(s)/Mail Da						
3) X Information Disclosure Statement(s) (PTO/SB/08)	5) 🔲 Notice of Informal P						
Paper No(s)/Mail Date <u>See Continuation Sheet</u> .	6) 🔲 Other:						

Continuation of Attachment(s) 3). Information Disclosure Statement(s) (PTO/SB/08), Paper No(s)/Mail Date :11/10/2011, 08/30/2011, 06/23/2011, 04/12/2011, 12/23/2010 and 11/09/2010.

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#### **DETAILED ACTION**

#### **Priority**

The applicant filed for the priority date of a foreign application and divisional application, but there is no basis in the priority for the following;

- Light emitting component having an active layer of a semiconductor.
- phosphor is a fluorescent material represented by formula  $(Re_{l-r}Sm_r)_3(Al_{l-s}Ga_s)_5O_{12}$ : Ce where  $0 \le r < 1$ ,  $0 \le s \le 1$  and Re is at least one element selected from Y, Gd and La.

The applicant will be given priority consideration for the effective filling date of the application.

#### Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1 – 17 and 19 are rejected under 35 U.S.C. 103(a) as being unpatentable over Butterworth et al. [US 5,847,507], and further in view of Hide et al. [US 5,966,393].

Butterworth et al. disclose preparing a light emitting component having an active layer of a semiconductor (Col. 1; Line 31 – 44, Col. 2; Line 55 - 65, Figures 1 and 2), preparing a phosphor (e.g. phosphor dye in lens 240, Col. 3; Lines 3 – 5) capable of absorbing a part of the blue color light emitted from said light emitting component and

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emitting a yellow color light having a broad emission spectrum comprising a peak wavelength existing around the range from 510 to 600 nm (e.g. shifting to 488nm – 688nm) and a tail continuing beyond 700 nm, wherein selection of said phosphor is controlled based on an emission wavelength of said light emitting component (In re Aller – result effective variable w/ dyes, Col. 3; Lines 58 – 64); and combining said light emitting component and said phosphor so that the blue color light from said light emitting component and the yellow color light from said phosphor are mixed to make a white color light, wherein a chromaticity point of the white color light is on a straight line connecting a point of chromaticity of the blue color light and a point of chromaticity of the yellow color light, and wherein a content of said phosphor in said light emitting device is selected to obtain a desired chromaticity of the white color light (dyes partially absorbing blue and emitting yellow in encapsulating lens (e.g. lens in direct line of LED emissions) combined w/ blue LED emission for "white light" Col. 3; Lines 3 – 5)) (Claim 1).

Butterworth et al. fail to disclose active layer comprising a gallium nitride based semiconductor containing indium and being capable of emitting a blue color light having a spectrum with a peak wavelength within the range from 420 to 490 nm.

Hide et al. disclose active layer comprising a gallium nitride based semiconductor containing indium and being capable of emitting a blue color light having a spectrum

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with a peak wavelength within the range from 420 to 490 nm (Zn-doped InGaN LED, Col. 12; Lines 15 – 20) (Claim 1).

Hide et al. disclose the active layer of said light emitting component has a single quantum well or multi quantum well structure (Col. 14; Lines 7 - 9) (Claim 7).

Hide et al. disclose the active layer of said light emitting component comprises InGaN (Col. 12; Lines 15 – 20) (Claim 8).

It would have been obvious for one of ordinary skill in the art at the time of invention to modify the invention of Butterworth et al. by adding active layer comprising a gallium nitride based semiconductor containing indium and being capable of emitting a blue color light having a spectrum with a peak wavelength within the range from 420 to 490 nm; the active layer of said light emitting component has a single quantum well or multi quantum well structure and comprise of InGaN as taught by Hide et al. in order to obtain efficient white light emission or emission over a wide range of colors (Col. 1; Line 30 - 31).

Butterworth et al. disclose phosphor comprises a garnet fluorescent material activated with cerium (Col. 1; Lines 36 - 38) (Claim 2).

Butterworth et al. disclose phosphor comprises two or more kinds of fluorescent materials (Abstract) (Claim 3).

Butterworth et al. disclose the emission spectrum of said phosphor comprises a peak wavelength existing around the range from 530 to 570 nm (e.g. shifting to 488nm

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- 688nm) and a tail continuing beyond 700 nm (In re Aller – result effective variable w/dyes, Col. 3; Lines 58 – 64) (Claim 4).

Butterworth et al. disclose phosphor comprises an yttrium-aluminum-garnet fluorescent material containing Y and Al (Col. 1; Lines 36 - 38) (Claim 5). Butterworth et al. disclose controlling emission color of said light emitting device by changing a content of said phosphor with respect to a content of a resin in a coating material (In re Aller – result effective variable w/ dyes, Col. 3; Lines 35 – 64) (Claim 10).

Butterworth et al. disclose step of controlling selection of said phosphor is used to reduce variation in the emission wavelength of said light emitting device, by compensating for a variation of the emission wavelength of said light emitting component (In re Aller – result effective variable w/ dyes, Col. 3; Lines 35 – 64) (Claim 11).

Butterworth et al. disclose controlling compositions or quantities of light emitting components and fluorescent materials included in said light emitting device, to control color emitted by said light emitting device (In re Aller – result effective variable w/ dyes, Col. 3; Lines 35 – 64) (Claim 12).

Butterworth et al. disclose the emission wavelength of the fluorescent materials are selected so that said light emitting device produces RGB components with high luminance (In re Aller – result effective variable w/ dyes, RGB colors are produce by different materials, Col. 3; Lines 35 – 64) (Claim 13).

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Butterworth et al. disclose the emission spectrum of one fluorescent material comprises a peak wavelength around 510 nm (e.g. shifting to 488nm – 688nm), and the emission spectrum tails out to around 700 nm (In re Aller – result effective variable w/ dyes), and the emission spectrum of a second fluorescent material comprises a peak wavelength around 600 nm, and the emission spectrum tails out to around 750 nm (In re Aller – result effective variable w/ dyes), so that said light emitting device produces RGB components with high luminance (In re Aller – result effective variable w/ dyes, RGB colors are produce by different materials, Col. 3; Lines 35 – 64) (Claim 14).

Butterworth et al. disclose mixing said two or more kinds of fluorescent materials (Col. 3; Lines 35 – 55) (Claim 15).

Butterworth et al. disclose two or more kinds of fluorescent materials are arranged independently to adjust color by laminating the layers of fluorescent materials (Col. 3; Lines 35 – 55) (Claim 16).

Butterworth et al. disclose one of said fluorescent materials absorbs light of a shorter wavelength and another of said fluorescent materials absorbs light of a longer wavelength, and said fluorescent material that absorbs light of a longer wavelength is arranged away from said light emitting component, while said fluorescent material that absorbs light of a shorter wavelength is arranged near said light emitting component (In re Aller – result effective variable w/ dyes, Col. 3; Lines 35 – 64) (Claim 17).

Butterworth et al. disclose controlling compositions or quantities of light emitting components included in said light emitting device and controlling composition of said

phosphor, to control color emitted by said light emitting device (Col. 3; Lines 35 - 64) (Claim 19).

#### Allowable Subject Matter

Claim 18 objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

"phosphor is a fluorescent material represented by formula  $(R_{l-r}Sm_r)_3(Al_{l-s}Ga_s)_5O_{12}$ : Ce where  $0 \le r < 1$ ,  $0 \le s \le 1$  and Re is at least one element selected from Y, Gd and La" as recite in claim 18.

#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to ABDULFATTAH MUSTAPHA whose telephone number is (571)272-9736. The examiner can normally be reached on Monday, Tuesday, Wednesday, and Friday. (06:00am - 4:00pm).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Charles Garber can be reached on 571-272-2194. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/Abdulfattah Mustapha/ Examiner, Art Unit 2812

/Charles D. Garber/ Supervisory Patent Examiner, Art Unit 2812

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				U.S. PA	ATENT DOCUM	ENTS		•	
*		Document Number Country Code-Number-Kind Code	Date MM-YYYY			Name		Classification	
*	Α	US-5,847,507	12-1998	Butterw	orth et al.			313/512	
*	В	US-5,966,393	10-1999	Hide et	al.			372/23	
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).) Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.

U.S. Patent and Trademark Office PTO-892 (Rev. 01-2001)

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**Notice of References Cited** 

Receipt date: 06/23/2011

PTO/SB/08b (07-09)

Approved for use through 67/31/2012, CMB 0851-0031 U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

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Examiner initial *	Cite No.1	include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	7
/A.M./	1	U.S. Office Action issued in co-pending Application No. 12/575,155, dated April 19, 2011.	
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Exam Signa		/Abdulfattah Mustapha/ Date Considered 12/11/2011	***********

^{*} EXAMINER: Initial if reference considered, whether or not dilation is in conformance with MPEP 609. Draw line through dilation if not in conformance and not considered. Include copy of this form with next consequences on applicant,

If you need assistance in completing the form, call 1-800-PTO-9199 and select option 2.

^{1.} Applicants unique ditation designation number. (optional) 2. Applicant is to prace a check mark here if English language Translation is attached. This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 25 17.5.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering. preparity, and submitting the completed application form the USPTO. Time will very depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chelf Information Officer, U.S. Petent and Trademark Office, P.O. Box 1450 Alexandria, VA 22313-3450, DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SENO TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Receipt date: 08/30/2011

PTC/SB/08s (07-09)

Approved for use through 07/31/2012, OMB 0651-0031

U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE

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	Sheet	1	of	2	Attorney Docket Number	0020-5147PUS12	

	******		U.S. PATE	NT DOCUMENTS	***************************************	
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	No.	Number - Kind Code ² (if known)	MM-DD-YYYY	Applicant of Cited Document	Pages, ociumns, Lines, Where Refevant Passages or Refevant Figures Appear	
/A.M./	1	US-3,623,867	11-30-1971	Saulnier		
/A.M./	2	US-3,842,306	10-15-1974	Henderson et al	7,777	
/A.M./	3	US-5,840,218	06-17-1997	Hasegawa et al.		
/A.M./	4	US-8,870,797	09-23-1997	Okazaki		
/A.M./	5	US-5,316,577 -	10-06-1998	Kurematsu et al.		
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^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 608. Draw line through dilation if not in conformance and not Considered, Include casy of this form with next communication to applicant, 1. Applicant's unique citation design number (optional), 2 See Kinds Codes of USPTO potent Documents, at www.useto gov or MPEP 901.04, 3. Enter Office that issued the document, by the two lietion code (WIPO Standard ST.3), 4. For Japaness patent Cocuments, the indication of the year of the reign of the Emperor must precede the serial number of the patent document, 5. Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST 16 if possible, 8, Applicant is to place a check mark here if English language Translation is attached

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Receipt date: 08/30/2011

PT0/SB/08b (07-09)

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U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

Under the Paperwork reduction Act of 1996, no persons are required to respond to a collection of information unless it contains a valid OME control number

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	MECOM	ATION T	ucri	ASHDE	Application Number	12/942,792	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT					Filling Date	11-09-10	
					First Named Inventor	Yoshinori Shimizu	
	/Use as	many sheets a	as naces	isary)	Art Unit	2812	
					Examiner Name	************** Mustapha	
	Sheet	2	oi	2	Attorney Docket Number	0020-5147PUS12	
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***********		NON PATENT LITERATURE DOCUMENTS	
Examiner initial *	Cite No.1	include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	15
/A.M./	6	U.S. Office Action issued in co-pending application 12/548,614 on June 27, 2011.	
/A.M./	7	U.S. Office Action issued in co-pending application 12/689,681 on June 23, 2011.	
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^{1.} Applicants unique distinct designation number (optional) 2. Applicant is to prace a check mark here if English language Translation is effected.

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Search Notes



Application/Control No.	Applicant(s)/Patent Under Reexamination
12942792	SHIMIZU ET AL.
Examiner	Art Unit
ABDULFATTAH MUSTAPHA	2812

SEARCHED							
Class	Subclass	Date	Examiner				
438	21-27	12/16/2011	MBA				
257	98,E33.044, E33.059	12/16/2011	MBA				
349	69-105	12/16/2011	MBA				

SEARCH NOTES							
Search Notes	Date	Examiner					
East search	12/16/2011	MBA					
References and suggestions provided by SPE C. Garber.	12/30/2011	MBA					

	INTERFERENCE SEARCH		
Class	Subclass	Date	Examiner
	See report.	12/16/2011	MBA

Receipt date: 11/10/2011

PTO/SB/08b (07-09)
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n 1449B/PT0)		Complete if Known		
ATION	DISCLO	SHIDE	Application Number	12/942,792	
			Filing Date	11-09-10	
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		NON PATENT LITERA	TURE DOCUMENTS	
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/A.M./	1	Office Action issued in co-pending US Appl. No. 12	2/575,155 on September 30, 2011.	
/A.M./	2	Request for Invalidation with Notification of Accept 03159595.2 dispatched on August 10, 2011.	ance of Request for Invalidation of Chinese Patent No.	
/A.M./	3	Yao Go et al., Synthesis and Luminescence Galliu PHYSICO-CHIMICA SINICA, Vol.19, No.3, March	m Nitride LED Blue Light Conversion Materials, ACTA 2003, p226 – 229.	ī
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Substitute	for form 1449A/P	то		Complete if Known		
				Application Number	12/942,792	
	RMATION			Filing Date	11-09-10	
STAT	EMENT E	BY AP	PLICANT	First Named Inventor	Yoshinori Shimizu	
				Art Unit	2812	
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Sheet	1	of	2	Attorney Docket Number	0020-5147PUS12	

			U.S. PATE	NT DOCUMENTS	
Examiner initial *	Cite	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or	Pages, columns, Lines, Where Relevant Passages or Relevant
	No.	Number - Kind Code ² (if known)		Applicant of Cited Document	Figures Appear
/A.M./	1	US-2009/0315014-A1	12-24-2009	SHIMIZU et al.	
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Sheet	2	of	2	Attorney Docket Number	0020-5147PUS12				

		NON PATENT LITERATURE DOCUMENTS	
Examiner initial *	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	Т
/A.M./	3	Office Action dated July 7, 2010 for US Application No. 12/548,614.	ľ
/A.M./	4	Office Action dated June 16, 2010 for US Application No. 12/548,621.	ľ
/A.M./	5	Office Action dated November 10, 2010 for US Application No. 12/575,162.	1
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^{1.} Applicants unique citation designation number. (optional) 2. Applicant is to place a check mark here if English language Translation is attached.

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SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

	Application/Control No.	Applicant(s)/Patent Under Reexamination
Index of Claims	12942792	SHIMIZU ET AL.
	Examiner	Art Unit
1	ABDULFATTAH MUSTAPHA	2812

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					Art Unit	2812		
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	140	Number - Kind Code ² (if known)	MM-DD-YYYY	Applicant of Cited Document	Pages, columns, Lines, Where Relevant Passages or Relevant Figures Appear
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Sheet	2	of	2	Attorney Docket Number	0020-5147PUS12			

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Exeminer nitial *	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	1
/A.M./	2	U.S. Office Action issued in Application No. 12/559,042 on March 16, 2011.	
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## **EAST Search History**

## **EAST Search History (Prior Art)**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L4	4	("6600175" "3842306" "3875456" "5126214").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2011/12/16 18:21
L5	12	("6600175" "3842306" "3875456" "5126214").pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/12/16 18:30
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L7	16936281	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/16 18:53
L8	110	L6 and L7	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/16 18:53
L9	1681	(light emit\$3 or LED) with (gallium nitride or GaN) with wavelength	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/16 18:54
L10	7	L8 and L9	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/16 18:54
L11	12	("5798537" "5998925" "6069440" "6608332" "6614179" "7026756" "7071616" "7126274" "7215074" "7329988" "7362048" "7531960").pn.	US-PGPUB; USPAT; USOCR	OR	ON	2011/12/16 18:58

L12	48488	((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/16 18:58
L13	12	L12 and L11	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/16 18:58
L14	0	L8 and L13	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/16 18:59
S1	488	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:32
83	17750983	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:33
S3	47	S1 and S2	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:34
S4	53731	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:35
S5	0	S3 and S4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:35
<del>S</del> 6	464	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO;	ADJ	ON	2009/03/09 09:36

	To the second se		DERWENT; IBM_TDB			
S7	13	S1 and S6	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:37
S8	36	("20010030326"   "3510732"   "3652956"   "3691482"   "3699478"   "3819974"   "3875456"   "4298820"   "4314910"   "4550256"   "4644223"   "4716337"   "4727283"   "4905060"   "5006908"   "5118985"   "5202777"   "5257049"   "5369289"   "5471113"   "5550657"   "5578839"   "5602418"   "5700713"   "5825125"   "5847507"   "5959316"   "6004001"   "6066861"   "6340824"   "6538371"   "6576930"   "6784511"   "6798537"   "6812500").PN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/09 09:40
S9	0	S1 and S8	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:41
S10	2	S6 and S8	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:41
S1 1	1	"20080138918".pn.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/09 09:43
S12	33641	((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:44
S13	159	S12 and S6	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:44
S14	11	S13 and S2	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;	ADJ	ON	2009/03/09 09:44

			IBM_TDB		<u> </u>	
S15	3726370	(oxide or ammonium or fluoride or aluminum)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:47
S16	2125	(ammonium adj3 fluoride) and (aluminum adj3 oxide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:48
S17	2125	S15 and S16	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:48
S18	47	S6 and S17	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:49
S19	2	S1 and S18	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:49
\$20	35	("20010030326"   "3510732"   "3652956"   "3691482"   "3699478"   "3819974"   "3875456"   "4298820"   "4314910"   "4550256"   "4644223"   "4716337"   "4727283"   "4905060"   "5006908"   "5118985"   "5202777"   "5257049"   "5369289"   "5471113"   "5550657"   "5578839"   "5602418"   "5798537"   "5825125"   "5847507"   "5959316"   "6004001"   "6066861"   "6340824"   "6538371"   "6576930"   "6784511"   "6812500").PN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/09 09:55
S21	1	"4644223".pn.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/09 09:56
S22	24	("2143077"   "3294699"   "3595802"   "3925239"   "4174294"   "4319161").PN. OR ("4644223").URPN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/09 09:56
S23	334	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same phosphor	US-PGPUB; USPAT; USOCR; FPRS;	ADJ	ON	2009/03/09 10:00

			EPO; JPO; DERWENT; IBM_TDB			
S24	13	S6 and S23	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 10:00
S25	0	S24 and S2	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 10:00
S26	17750983	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:40
S27	464	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:40
S28	334	((light adj3 emit\$3) or LED) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:40
S29	13	S27 and S28	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:40
S30	0	S26 and S29	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:40
S31	13476	((light adj3 emit\$3) or LED) same nitride	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:42
S32	1482	S26 and S31	US-PGPUB; USPAT;	<b>A</b> DJ	ON	2009/03/09 19:42

			USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
<b>S</b> 33	0	S32 and S27	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:43
S34	53731	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:43
S35	7	S32 and S34	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:43
S36	7	S35 and S35	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:45
S37	7	S35 and S31	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:45
S38	0	S37 and S33	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:45
S39	15	("56016584" "60011069" "3748548" "105061" "4857228" "4991941" "19910307").pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/09 19:49
S40	1833	((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:51

S41	32	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:04
S42	32	S40 and S41	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:05
S43	0	S26 and S42	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:05
S44	696	(light adj3 emit\$3) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:08
S45	9	S26 and S44	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:08
S46	3726370	(oxide or ammonium or fluoride or aluminum)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:58
S47	2125	(ammonium adj3 fluoride) and (aluminum adj3 oxide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:58
S48	2125	S46 and S47	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:58
S49	47	S27 and S48	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO;	ADJ	ON	2009/03/09 20:58

			DERWENT; IBM_TDB			
S50	86160	fir\$3 near3 (oxide or (ammonium adj3 fluoride) or (aluminum adj3 oxide))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:00
S51	45	S49 and S50	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:01
S52	0	S26 and S51	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:01
S53	27176	S26 and S50	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:02
S54	89	S53 and S48	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:03
S55	25	fir\$3 near3 (oxide and (ammonium fluoride) and (aluminum oxide))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:05
S56	1	S26 and S55	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:06
S57	1945	dissolv\$3 near5 stoichiometric\$3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:08
S58	1279	S34 and S57	US-PGPUB; USPAT; USOCR;	<b>A</b> DJ	ON	2009/03/09 21:08

			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S59	674	S26 and S58	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	ON	2009/03/09 21:08
S60	11	S53 and S59	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:09
S61	49	("4924612" "6139162" "5907373" "6014489" "4772780" "5729024" "5786665" "5818062" "5929436" "6036328" "6094404" "5462164" "5519519" "5671028" "5828302" "6102545" "6215535" "6215535" "4405858" "4807026" "4840137" "4864144" "4865196" RE34411 "5266811" "5398170" "5410212" "5467216" "5573107" "5757447" "5841154" "6048071" "6231200" "6249370" "4250575" "4251142" "4259963" "4340292" "4494874" "4616293" "4814948" "4875074" "4916478" "5219418" "5319414" "5408296" "5459000" "5459505" "5471050" "5510869").pn.	US-PGPUB; USPAT; USOCR	OR	ON	2009/03/09 21:44
S62	0	blue color near5 (420-490) adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 18:58
S63	210	blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 18:59
S64	184	blue color near5 ("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:01
S65	5	S63 and S64	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;		ON	2009/10/12 19:02

			IBM_TDB		***************************************	
S66	2	phosphor near5 blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)		ADJ	ON	2009/10/12 19:28
S67	788	(light adj3 emit\$3) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:30
S68	14	S63 and S67	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:30
S69	16927698	@ad< "19960729" or @rlad< "19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:33
S70	0	S68 and S69	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:33
S71	14	S68 and S67	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:34
S72	41	S63 and S69	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:35
S73	0	S64 and S72	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:35
S74	733	NI CHI A CORPORATI ON. as.	US-PGPUB; USPAT; USOCR; FPRS;	<b>A</b> DJ	ON	2009/10/12 19:43

			EPO; JPO; DERWENT; IBM_TDB			
S75	12	NI CHI A KAGAKU KOGYO KABUSHI KI KAI SHA. as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:43
S76	745	S74 or S75	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:44
S77	0	S72 and S76	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:44
S78	0	Yoshinori Shimizu.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:46
S79	0	Kensho Sakano.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:46
S80	0	Yasunobu Noguchi.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:47
S81	0	Toshio Moriguchi.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:47
S89	12	("5798537" "5998925" "6069440" "6608332" "6614179" "7026756" "7071616" "7126274" "7215074" "7329988" "7362048" "7531960").pn.	US-PGPUB; USPAT; USOCR	OR	ON	2009/11/23 09:03
S90	36867	((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS;	ADJ	ON	2009/11/23 09:09

			EPO; JPO; DERWENT; IBM_TDB	-		
S91	12	S90 and S89	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:09
S92	2163	((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:10
S93	40	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:10
S94	40	S92 and S93	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:10
S95	0	S94 and S91	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:10
S96	188	blue color near5 ("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:11
S97	0	S96 and S91	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:11
S98	212	blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:13
S99	0	S98 and S91	US-PGPUB; USPAT;	<b>A</b> DJ	ON	2009/11/23 09:13

			USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
S100	321	blue color near5 (wavelength or wave length) same ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:14
S101	358	blue color near5 (wavelength or wave length) same ("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:15
S102	1	S100 and S91	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:15
S103	1	S101 and S91	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:15
S104	16928194	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	ON	2009/11/23 09:33
S105	0	S94 and S104	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:33
S106	745	NICHIA CORPORATION.as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:39
S107	12	NI CHI A KAGAKU KOGYO KABUSHI KI KAI SHA. as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;	ADJ	ON	2009/11/23 09:39

			IBM_TDB			
S108	757	S106 or S107	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:39
S109	757	S106 or S107	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:40
S110	9	S100 and S109	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:40
S111	5	S101 and S109	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:40
S112	10	S110 or S111	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:40
S113	0	S112 and S104	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:41
S114	17759950	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:20
S115	520	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:21
S116	460	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same phosphor	US-PGPUB; USPAT; USOCR; FPRS;	ADJ	ON	2010/05/31 14:21

			EPO; JPO; DERWENT; IBM_TDB			
S117	13	S115 and S116	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:21
S118	0	S117 and S114	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:21
S119	104	(LED or light emit\$3) near5 spectrum near3 ("420" or "430" or "440" or "450" or "460" or "470" or "480" or "490" or "500" or "510" or "520" or "530" or "540" or "550" or "560" or "570" or "580" or "590" or "600" or "610" or "620" or "630" or "640" or "650" or "660" or "670" or "680" or "690" or "700") adj (nm or nano meter or nano metre)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OX	2010/05/31 14:28
S120	15	S114 and S119	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:29
S121	2506	spectrum near3 phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		ON	2010/05/31 14:29
S122	2	S120 and S121	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:29
S123	108	("20010030326"   "3510732"   "3652956"   "3691482"   "3699478"   "3748548"   "3819974"   "3875456"   "4298820"   "4314910"   "4550256"   "4644223"   "4716337"   "4727283"   "4857228"   "4905060"   "5006908"   "5118985"   "5202777"   "5257049"   "5369289"   "5471113"   "5512210"   "5550657"   "5578839"   "5602418"   "5630741"   "5700713"   "5798537"   "5825113"   "5847507"   "5949182"   "5959316"   "5998925"   "6004001"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	S	2010/05/31 14:32

		"6066511"   "6069440"   "6340824"   "6538371"   "6576930"   "6608332"   "6614179"   "6784511"   "6798537"   "6812500"   "7026756"   "7071616"   "7126274"   "7215074"   "7329988"   "7362048"   "7531960").PN.				
S124	504	((light adj3 emit\$3) or LED) near5 transparent material	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:34
S125	0	S123 and S124	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:34
S126	5	S124 and S121	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:35
S127	0	S120 and S126	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:35
S128	2458	((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:36
S129	46	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:36
S130	46	S128 and S129	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:36
S131	49415	(LCD or liquid crystal display) same color filter	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO;	ADJ	ON	2010/05/31 14:37

			DERWENT; IBM_TDB			
S132	4	S119 and S131	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:37
S133	236146	"257"/\$	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:38
S134	195807	"438"/\$	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:38
S135	115041	S133 and S134	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:39
S136	46352	"349"/\$	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:39
S137	3373	S135 and S136	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:39
S138	125801	"359"/\$	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:39
S139	64206	"313"/\$	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:39
S140	3125	S138 and S139	US-PGPUB; USPAT; USOCR;	ADJ	ON	2010/05/31 14:40

			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S141	186	S131 and S140	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:40
S142	18	S137 and S141	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:40
S143	111	S128 and S131	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:40
S144	1	S142 and S143	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:41
S145	8649	349/69-105.cds.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:07
S146	1822	S131 and S145	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:07
S147	17	S119 and S121	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:08
S148	0	S146 and S147	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		ON	2010/05/31 15:08
S149	5106	(LCD or liquid crystal display) near3	US-PGPUB;	ADJ	ON	2010/05/31

		(glass or transparent) adj (wafer or substrate)	USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			15:11
S150	872	liquid crystal near3 (inject\$3 or introduc\$3 or dispens\$3) near5 (glass or transparent) adj (wafer or substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:14
S151	129	S149 and S150	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:14
S152	0	S119 and S151	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:15
S153	0	("10677382" "12548614" "12548620" "12559042").ap.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 17:39
S154	0	("10/677382" "12/548614" "12/548620" "12/559042").ap.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 17:40
S155	24	("677382" "548614" "548620" "559042").ap.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 17:40
S156	4	("20090315015" "20100001258" "20090315014" "7026756" "7026756").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 17:45
S157	0	"7362048.pn"	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 19:46
S158	0	"7362048.pn."	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 19:46
S159	1	"7362048".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 19:47
S160	894622	phosphor near5 transparent material same (LED or light emit\$3)	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 19:56
S161	227	blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 19:56
S162	198	blue color near5 ("510" or "515" or	US-PGPUB;	<b>A</b> DJ	ON	2010/06/07

		"520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			19:56
S163	7	S161 and S162	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 19:56
S164	67510	("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	USPAT;	ADJ	ON	2010/06/07 20:02
S165	137544	("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:02
S166	31514	S164 and S165	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:02
S167	13207	S160 and S166	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:02
S168	17760117	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:03
S169	16666	((light adj3 emit\$3) or LED) same nitride	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:03
S170	1488	S168 and S169	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;	ADJ	ON	2010/06/07 20:03

			IBM_TDB		<u> </u>	***************************************
S171	5111	(LCD or liquid crystal display) near3 (glass or transparent) adj (wafer or substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:03
S172	873	liquid crystal near3 (inject\$3 or introduc\$3 or dispens\$3) near5 (glass or transparent) adj (wafer or substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:03
S173	129	S171 and S172	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:03
S174	0	S170 and S173	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:04
S175	61	S170 and S167	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:04
S176	0	transparent adj mateial near5 (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:05
S177	1555	transparent adj material near5 (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:05
S178	0	S175 and S177	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:05
S179	2	"5700713".pn.	US-PGPUB; USPAT; USOCR; FPRS;	ADJ	OFF	2010/06/08 13:30

			EPO; JPO; DERWENT; IBM_TDB			
S180	0	bck light near5 (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/08 19:27
S181	2980	back light near5 (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/08 19:27
S182	5397	liquid crystal near5 glass substrate	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/08 19:28
S183	40	S181 and S182	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/08 19:28
S184	17760148	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/08 19:29
S185	16932587	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/08 19:29
S186	3	S183 and S185	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/08 19:30
S187	56	("20010030326"   "20090315014"   "20090315015"   "20100001258"   "3510732"   "3652956"   "3691482"   "3699478"   "3748548"   "3819974"   "3875456"   "4298820"   "4314910"   "4550256"   "4644223"   "4716337"   "4727283"   "4857228"   "4905060"   "5006908"   "5118985"   "5202777"	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/06/19 13:54

		"5257049"   "5369289"   "5471113"   "5512210"   "5550657"   "5578839"   "5602418"   "5630741"   "5700713"   "5798537"   "5825125"   "5847507"   "5949182"   "5959316"   "5998925"   "6004001"   "6066861"   "6069440"   "6340824"   "6538371"   "6575930"   "6608332"   "6614179"   "6784511"   "6798537"   "6812500"   "7026756"   "7071616"   "7126274"   "7215074"   "7329988"   "7362048"   "7531960").PN.				
S188	24	(diameter or radi\$3) near3 (conduct\$3 or wire) near3 ("10" or "15" or "20" or "25" or "30" or "35" or "40" or "45") adj (mu or micro or meter)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 13:59
S189	0	S187 and S188	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 14:02
S190	1	"20090315014".pn.	US-PGPUB; USPAT; USOCR	<b>A</b> DJ	OFF	2010/06/19 14:04
S191	55	S187 and (diameter or radi\$3 or conduct\$3 or wire or ".mu.m" or "10" or "15" or "20" or "25" or "30" or "35" or "40" or "45")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 14:08
S192	75	(LED or Light emit\$3) adj3 chip near5 conduct\$3 adj wire	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 14:44
S193	1	S187 and S192	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 14:44
S194	11	("1305111" or "6340824").pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:13
S195	951	diameter near5 conduct\$3 adj wire	US-PGPUB; USPAT;	ADJ	OFF	2010/06/19 15:16

			USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
S196	14	S191 and S195	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:17
S197	168	phosphor near3 transparent material	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:18
S198	3	S196 and S197	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:18
S199	178048	shimizu.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:19
S200	161	S197 NOT S199	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:20
S201	2	("5949182" "3748548").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/19 15:28
S202	34	("2913632"   "3173101"   "3179542"   "3209214"   "3229104"     "3234057"   "3260902"   "3270235"   "3283160"   "3372069").PN. OR ("3748548").URPN.	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/06/19 15:28
S203	21	("3665241"   "3755704"   "3812559"   "4513308"   "5064396"   "5186670"   "5199917"   "5229331"   "5232549"   "5316979"   "5329207"   "5363021"   "5438240"   "5448132"   "5615143").PN. OR ("5949182").URPN.	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/06/19 15:30
S204	2	("5630741" "4857228").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/19 15:34
S205	2	S192 and S197	US-PGPUB; USPAT;	<b>A</b> DJ	OFF	2010/06/19 15:38

			USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
S206	16932745	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/19 15:41
S207	2	S192 and S206	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:42
S208	318	S195 and S206	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:42
S209	0	S208 and S197	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:43
S210	6	("3699478"   "5221984"   "5594751"   "5801435"   "6015200"   "6600175").PN.	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/10/21 16:00
S211	5	("4001628"   "5208462"   "5706022"   "5743629"   "6600175").PN.	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/10/21 16:09
S212	2	"6600175".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/10/24 13:21
S213	6	("3699478"   "5221984"   "5594751"   "5801435"   "6015200"   "6600175").PN.	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/10/24 13:25
S214	3	"3699478".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/04/21 16:56
S215		("4992704" "20090315014" "5045867").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2011/04/22 14:59
S216	2	("2009/0315014").URPN.	USPAT	<b>A</b> DJ	OFF	2011/04/22

						14:59
S217	581	(conduct\$3 or electric\$3) adj5 (wire or cable) with (diameter or radius or size) with (("10" "15" "20" "25" "30" "35" "40" "45") adj(".mu.m" or micro or micron or meter or metre))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/04/22 15:19
S218	16934970	@ad< "19960729" or @rlad< "19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:20
S219	82	S217 and S218	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:20
S220	19216	((light adj3 emit\$3) or LED) same nitride	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:21
S221	1245	S218 and S220	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:22
S222	0	S219 and S221	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:22
S223	7	((light adj3 emit\$3) or LED) and \$219	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:22
S224	0	(transparent\$3 or visibl\$3) adj5 material with (LED or light emit\$3 diode or light emit\$3) and \$219	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:24
S225	0	(transparent\$3 or visibl\$3) adj5 material with phosphor and \$219	US-PGPUB; USPAT; USOCR; FPRS;	ADJ	ON	2011/04/22 15:25

			EPO; JPO; DERWENT; IBM_TDB			
S226	2	"4992704".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/13 16:16
S227	2	"20090315015".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 11:44
S228	3	("2009/0315015").URPN.	USPAT	<b>A</b> DJ	OFF	2011/05/17 11:51
\$229	550	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius) with (("10" or "15" or "20" or "25" or "30" or "35" or "40" or "45") adj (".mu.m" or micron or nm or mm))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 15:40
\$230	2267282	((LCD or liquid crystal display or liquid crystal) or (LED or light emitting diode or light emit\$3) or (bak light))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 15:48
\$231	227	S229 and S230	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 15:48
\$232	16935137	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/05/17 15:49
\$233	18	S232 and S231	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/05/17 15:50
\$234	47	phosphor near3 transparent material with (light emit\$3 or LED)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 15:54

S235	0	\$233 and \$234	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 15:54
S236	12	\$234 and \$231	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/05/17 15:54
S237	950368	phosphor near5 transparent material same (LED or light emit\$3)	US-PGPUB; USPAT; USOCR	OR	OFF	2011/05/17 16:55
S238	40	S234 and S237	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/05/17 16:56
S239	0	\$233 and \$238	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 16:57
S240	195589	S232 and S237	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/05/17 16:57
S241	6	S231 and S240	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/05/17 16:58
S242	283	(wir\$3 or (conduct\$3 adj wire)) near3 (diameter or radius) with (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 13:15
S243	74	(wir\$3 or (conduct\$3 adj wire)) near3 (diameter or radius) with (LED or light emit\$3) and @ad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 13:15
S244	74	(wir\$3 or (conduct\$3 adj wire)) near3 (diameter or radius) with (LED	US-PGPUB; USPAT;	<b>A</b> DJ	OFF	2011/06/03 14:44

		or light emit\$3) and @ad< "19970331"	USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
S245	13	S244 and (light emit\$3 or light emit\$3 diode or light emit\$3 display)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 14:44
S246	74	S244 and (LED or light emit\$3 or light emit\$3 diode or light emit\$3 display)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 14:47
\$247	16	(wir\$3 or (conduct\$3 adj wire)) with (diameter or radius) with (light emit\$3 or light emit\$3 diode or light emit\$3 display) and @ad< "19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 15:22
S248	93	(wir\$3 or (conduct\$3 adj wire) or conduct\$3) near3 (diameter or radius) with (LED or light emit\$3) and @ad< "19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 16:05
S249	122	(wir\$3 or (conduct\$3 adj wire) or conduct\$3) near3 (diameter or radi\$3) with (LED or light emit\$3) and @ad< "19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 16:05
S250	20	(wir\$3 or (conduct\$3 adj wire) or conduct\$3) near3 (diameter or radi\$3) with (light emit\$3 or light emit\$3 diode or light emit\$3 display) and @ad< "19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 16:06
S251	20	(wir\$3 or (conduct\$3 adj wire) or conduct\$3) near3 (diameter or radi\$3) with (light emit\$3 or light emit\$3 diode or light emit\$3 display) and @ad< "19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 16:06
S252	20	S250 and S251	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 16:06

S253	6501	257/98.ccls.	US-PGPUB; USPAT;	<b>A</b> DJ	OFF	2011/06/08 10:27
			USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
S254	6501	(257/98).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/08 10:27
\$255	4900	(257/99).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/08 10:27
S256	1730	(257/100).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/08 10:29
S257	78	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and S253	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 10:30
S258	6	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and \$253 and @ad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 10:30
S259	6	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and \$254 and @ad< "19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 10:33
S260	7	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and \$255 and @ad< "19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 10:34
S261	1	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and \$256 and @ad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO;	ADJ	OFF	2011/06/08 10:35

			DERWENT; IBM_TDB		University of the Control of the Con	
S262	0	438/106-127.ccls. and light near2 emitting near2 diode and (lead wire wiring conductor) near4 (thickness thick diameter)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 13:33
S263	56	438/106-127.ccls. and light near2 emitting near2 diode and (lead wire wiring conductor) near4 (thickness thick diameter)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/08 13:33
S264	3	("4347655" "5125153" "5885893").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2011/06/08 13:34
S265	1730	(257/100).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/08 13:35
S266	0	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and \$265 and \$264	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 13:35
S267	3	S264 and (wir\$3 or LED or light or emit\$3 or diameter or thick\$3)	US-PGPUB; USPAT; USOCR	OR	OFF	2011/06/08 13:38
S268	6501	257/98.cds.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 13:46
S269	6501	257/98.cds. and \$268	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 13:46
S270	119519	quantum well and S268	US-PGPUB; USPAT; USOCR	OR	OFF	2011/06/08 13:47
S271	1489	quantum well and S268	US-PGPUB; USPAT; USOCR	ADJ	OFF	2011/06/08 13:47
S272	50	quantum well and S268 and @ad<"19970331"	US-PGPUB; USPAT; USOCR	ADJ	OFF	2011/06/08 13:48
S273	25	((single or multi\$3) adj quantum	US-PGPUB;	<b>A</b> DJ	OFF	2011/06/08

		well) and \$268 and @ad<"19970331"	USPAT; USOCR			13:55
S274	27356	liquid crystal with (glass adj substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:10
S275	17763698	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:10
S276	4812	S274 and S275	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:11
S277	6515	257/98.cds.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:11
S278	1493	quantum well and \$277	US-PGPUB; USPAT; USOCR	<b>A</b> DJ	OFF	2011/06/09 12:11
S279	0	\$278 and \$276	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:11
\$280	3	S277 and S276	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:11
\$281	1071	(inject\$3 or introduc\$3 or insert\$3) with liquid crystal with (glass adj substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:16
\$282	0	S281 and S275 and S277	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:16

S283		(inject\$3 or introduc\$3 or insert\$3) with liquid crystal with (glass adj substrate) and color filter	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		OFF	2011/06/09 12:19
S284	123	S275 and S283	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:20
S285	0	S277 and S284	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:20
S286	3	(inject\$3 or introduc\$3 or insert\$3) with liquid crystal with (glass adj substrate) and color filter with (LED or light emitting diode or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:22
S287	144	(inject\$3 or introduc\$3 or insert\$3) with liquid crystal with (glass adj substrate) and color filter and (LED or light emitting diode or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:22
S288	55	S275 and S287	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:25
S289	7280	liquid crystal with (glass adj substrate) and color filter	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:25
S290	55	S288 and S289	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:25
S291	0	S277 and S290	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO;	ADJ	ON	2011/06/09 12:26

			DERWENT; IBM_TDB			
S292	2596	liquid crystal with (glass adj substrate) with color filter	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:33
S293	19	S290 and S292	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:33
S294	17764738	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/04 17:14
S295	4	("3623867"   "3842306"   "5816677").PN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2011/11/04 17:17
S296	17764740	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:05
S297	4	("3623867"   "3842306"   "5816677").PN.	US-PGPUB; USPAT; USOCR	<b>A</b> DJ	ON	2011/11/05 13:06
S298	1	("3875456").PN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2011/11/05 13:13
\$299	17764740	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:51
\$300	568	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:51
\$301	47842	((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:51

\$302	239	S301 and S300	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:51
\$303	11	S302 and S299	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:51
S304	11176	phosphor with (concentrat\$3 or quatity or quality or different or mix\$3) with (LED or light or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:04
\$305	1869	S296 and S304	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:04
S306	773	S301 and S305	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:04
S307	21084	((light adj3 emit\$3) or LED) same nitride	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:04
\$308	984	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S309	4468235	(oxide or ammonium or fluoride or aluminum)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S310	2933	(ammonium adj3 fluoride) and (aluminum adj3 oxide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO;	ADJ	ON	2011/11/05 14:05

			DERWENT; IBM_TDB			
S311	2933	S309 and S310	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S312	80	S300 and S311	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S313	3	S308 and S312	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S314	12	("5798537" "5998925" "6069440" "6608332" "6614179" "7026756" "7071616" "7126274" "7215074" "7329988" "7362048" "7531960").pn.	US-PGPUB; USPAT; USOCR	OR	ON	2011/11/05 14:05
S315	47842	((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S316	12	S315 and S314	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S317	260	blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S318	961	NI CHI A CORPORATI ON. as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S319	12	NI CHI A KAGAKU KOGYO KABUSHI KI KAI SHA. as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO;	ADJ	ON	2011/11/05 14:05

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***************************************	S320	973	S318 or S319	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05

## **EAST Search History (Interference)**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S82	469	NI CHI A CORPORATI ON. as.	USPAT; UPAD	<b>A</b> DJ	ON	2009/10/12 19:51
S83	: :	NICHIA KAGAKU KOGYO KABUSHIKI KAISHA.as.	USPAT; UPAD	ADJ	ON	2009/10/12 19:51
S84	99	blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	USPAT; UPAD	ADJ	ON	2009/10/12 19:51
S85	94	blue color near5 ("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	USPAT; UPAD	ADJ	ON	2009/10/12 19:51
S86	0	S82 and S83	USPAT; UPAD	<b>A</b> DJ	ON	2009/10/12 19:52
S87	1	S84 and S85	USPAT; UPAD	<b>A</b> DJ	ON	2009/10/12 19:52
S88	0	phosphor near5 blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	USPAT; UPAD	ADJ	ON	2009/10/12 19:57

12/16/2011 6:59:32 PM

 $\textbf{C:} \ \textbf{Users} \ \textbf{amustapha} \ \textbf{Documents} \ \textbf{EAST} \ \textbf{Workspaces} \ \textbf{12_942792.wsp}$ 

## **EAST Search History**

## **EAST Search History (Prior Art)**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L31	7317	(light emit\$3 or LED) with (gallium nitride or GaN) with ((blue or yellow) near3 light)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/12/11 19:13
L32	7474	(light emit\$3 or LED) with (gallium nitride or GaN) with ((blue or yellow) near3 light)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/12/11 19:16
L33	7317	L31 and L32	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/12/11 19:17
L34	2117	(light emit\$3 or LED) with (gallium nitride or GaN) with ((blue or yellow) near3 light)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/11 19:17
L35	11512	phosphor with ((blue or yellow) near3 light)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/12/11 19:20
L36	11512	phosphor with ((blue or yellow) near3 light)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/11 19:21
L37	11512	L35 and L36	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/12/11 19:21
L38	1438	L33 and L37	US-PGPUB;	OR	ON	2011/12/11

			USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			19:22
L39	15	L38 and @ad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/11 19:22
L40	13	L38 and @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/11 19:23
L41	21	L39 or L40	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/11 19:24
L42	9274	(light emit\$3 or LED) with (gallium nitride or GaN) with wavelength	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/12/11 20:05
L43	0	L41 and L42	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/12/11 20:05
L44	489836	(light emit\$3 or LED) with wavelength	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/12/11 20:05
L45	14	L41 and L44	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/12/11 20:12
L46	123715	(light emit\$3 or LED) with (wavelength near3 nm)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;	OR	OFF	2011/12/11 20:46

			IBM_TDB			
L47	0	L41 and L46	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/12/11 20:47
L48	575	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/11 20:48
L49	755	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/11 20:48
L50	15	L48 and L49	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/11 20:48
L51	13794	L46 and @ad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/11 21:12
L52	3379	L51 and @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/12/11 21:13
L53	0	L41 and L52	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/12/11 21:21
L54	3379	L51 and L52	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/12/11 21:21
L55	65	L42 and L54	US-PGPUB; USPAT; USOCR; FPRS;	OR	OFF	2011/12/11 21:21

			EPO; JPO; DERWENT; IBM_TDB			
L56	73	("20100001258"   "3510732"   "5512210"   "5847507"   "6608332"   "6812500"   "5670797"   "4001628"   "4314910"   "5208462"   "5550657"   "5578839"   "5594751"   "5602418"   "5825125"   "5959316"   "6066861"   "6538371"   "7329988"   "7362048"   "7531960"   "4716337"   "5202777"   "5257049"   "5369289"   "6015200"   "6600175"   "7126274"   "20090315015"   "3691482"   "4298820"   "4644223"   "4727283"   "5471113"   "7215074"   "7682848"   "5045867"   "3623867"   "4550256"   "4905060"   "5706022"   "5801435"   "7026756"   "20090315014"   "3842306"   "5640216"   "5816677"   "3652956"   "3875456"   "4857228"   "5998925"   "6784511"   "20010030326"   "3699478"   "3819974"   "5630741"   "5700713"   "5949182"   "6004001"   "6069440"   "6340824"   "6576930"   "6614179"   "4992704"   "3748548"   "5006908"   "5118985"   "5221984"   "7071616").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2011/12/11 21:24
L57	28	L46 and L56	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/12/11 21:25
S1	488	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:32
S2	17750983	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		ON	2009/03/09 09:33
S3	47	S1 and S2	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:34
S4	53731	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3)	US-PGPUB; USPAT;	<b>A</b> DJ	ON	2009/03/09 09:35

			USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
S5	0	S3 and S4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:35
S6	464	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:36
S7	13	S1 and S6	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:37
<b>S</b> 8	36	("20010030326"   "3510732"   "3652956"   "3691482"   "3699478"   "3819974"   "3875456"   "4298820"   "4314910"   "4550256"   "4644223"   "4716337"   "4727283"   "4905060"   "5006908"   "5118985"   "5202777"   "5257049"   "5369289"   "5471113"   "5550657"   "5578839"   "5602418"   "5700713"   "5825125"   "5847507"   "5959316"   "6004001"   "6066861"   "6340824"   "6538371"   "6576930"   "6784511"   "6798537"   "6812500").PN.	US-PGPUB; USPAT; USOCR	ADJ	<b>S</b>	2009/03/09 09:40
S9	0	S1 and S8	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:41
S10	2	S6 and S8	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:41
S11	1	"20080138918".pn.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/09 09:43
S12	33641	((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR;	ADJ	ON	2009/03/09 09:44

			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S13	159	S12 and S6	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:44
S14	11	S13 and S2	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:44
S15	3726370	(oxide or ammonium or fluoride or aluminum)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:47
S16	2125	(ammonium adj3 fluoride) and (aluminum adj3 oxide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:48
S17	2125	S15 and S16	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		ON	2009/03/09 09:48
S18	47	S6 and S17	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:49
S19	2	S1 and S18	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 09:49
S20	35	("20010030326"   "3510732"   "3652956"   "3691482"   "3699478"   "3819974"   "3875456"   "4298820"   "4314910"   "4550256"   "4644223"   "4716337"   "4727283"   "4905060"   "5006908"   "5118985"   "5202777"   "5257049"   "5369289"   "5471113"	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/09 09:55

		"5550657"   "5578839"   "5602418"   "5798537"   "5825125"   "5847507"   "5959316"   "6004001"   "6066861"   "6340824"   "6538371"   "6576930"   "6784511"   "6812500").PN.				
S21	1	"4644223".pn.	US-PGPUB; USPAT; USOCR	<b>A</b> DJ	ON	2009/03/09 09:56
S22	24	("2143077"   "3294699"   "3595802"   "3925239"   "4174294"   "4319161").PN. OR ("4644223").URPN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/09 09:56
S23	334	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 10:00
S24	13	S6 and S23	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 10:00
S25	0	S24 and S2	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 10:00
S26	17750983	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:40
\$27	464	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:40
\$28	334	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:40
\$29	13	\$27 and \$28	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;		ON	2009/03/09 19:40

		1	IBM_TDB	L	***************************************	
S30	0	S26 and S29	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:40
S31	13476	((light adj3 emit\$3) or LED) same nitride	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	<b>A</b> DJ	ON	2009/03/09 19:42
S32	1482	S26 and S31	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:42
S33	0	S32 and S27	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:43
S34	53731	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	<b>A</b> DJ	ON	2009/03/09 19:43
S35	7	S32 and S34	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:43
S36	7	S35 and S35	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:45
S37	7	S35 and S31	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:45
S38	0	S37 and S33	US-PGPUB; USPAT; USOCR; FPRS;	ADJ	ON	2009/03/09 19:45

			EPO; JPO; DERWENT; IBM_TDB			
S39	15	("56016584" "60011069" "3748548" "105061" "4857228" "4991941" "19910307").pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/09 19:49
S40	1833	((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 19:51
S41	32	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:04
S42	32	S40 and S41	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:05
S43	0	S26 and S42	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:05
S44	696	(light adj3 emit\$3) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:08
S45	9	S26 and S44	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:08
S46	3726370	(oxide or ammonium or fluoride or aluminum)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:58
S47	2125	(ammonium adj3 fluoride) and (aluminum adj3 oxide)	US-PGPUB; USPAT;	<b>A</b> DJ	ON	2009/03/09 20:58

			USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
S48	2125	S46 and S47	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:58
S49	47	S27 and S48	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 20:58
S50	86160	fir\$3 near3 (oxide or (ammonium adj3 fluoride) or (aluminum adj3 oxide))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:00
S51	45	S49 and S50	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:01
S52	0	S26 and S51	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:01
S53	27176	S26 and S50	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:02
S54	89	S53 and S48	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:03
S55	25	fir\$3 near3 (oxide and (ammonium fluoride) and (aluminum oxide))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:05

S56	1	S26 and S55	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:06
S57	1945	dissolv\$3 near5 stoichiometric\$3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:08
S58	1279	S34 and S57	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:08
S59	674	S26 and S58	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:08
S60	11	S53 and S59	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/09 21:09
S61	49	("4924612" "6139162" "5907373" "6014489" "4772780" "5729024" "5786665" "5818062" "5929436" "6036328" "6094404" "5462164" "5519519" "5671028" "5828302" "6102545" "6215535" "6215535" "4405858" "4807026" "4840137" "4864144" "4865196" RE34411 "5266811" "5398170" "5410212" "5467216" "5573107" "5757447" "5841154" "6048071" "6231200" "6249370" "4250575" "4251142" "4259963" "4340292" "4494874" "4616293" "4814948" "4875074" "4916478" "5219418" "5319414" "5408296" "5459000" "5459505" "5471050" "5510869").pn.	US-PGPUB; USPAT; USOCR	OR	ON	2009/03/09 21:44
S62	0	blue color near5 (420-490) adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 18:58
S63	210	blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or	US-PGPUB; USPAT; USOCR;	ADJ	ON	2009/10/12 18:59

		"485" or "490") adj (nm or nanometre or nano meter or ANG)	FPRS; EPO; JPO; DERWENT; IBM_TDB			
S64	184	blue color near5 ("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:01
S65	5	S63 and S64	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:02
S66	2	phosphor near5 blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:28
S67	788	(light adj3 emit\$3) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:30
S68	14	S63 and S67	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:30
S69	16927698	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:33
S70	0	S68 and S69	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:33
S71	14	S68 and S67	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:34
S72	41	S63 and S69	US-PGPUB;	<b>A</b> DJ	ON	2009/10/12

			USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			19:35
S73	0	S64 and S72	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:35
S74	733	NI CHI A CORPORATION. as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:43
S75	12	NI CHI A KAGAKU KOGYO KABUSHIKI KAISHA.as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:43
S76	745	S74 or S75	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:44
S77	0	S72 and S76	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	ON	2009/10/12 19:44
S78	0	Yoshinori Shimizu.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:46
S79	0	Kensho Sakano.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:46
S80	0	Yasunobu Noguchi.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;	ADJ	ON	2009/10/12 19:47

<b></b>			IBM_TDB			
S81	0	Toshio Moriguchi.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/10/12 19:47
S89	12	("5798537" "5998925" "6069440" "6608332" "6614179" "7026756" "7071616" "7126274" "7215074" "7329988" "7362048" "7531960").pn.	US-PGPUB; USPAT; USOCR	OR	ON	2009/11/23 09:03
S90	36867	((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:09
S91	12	S90 and S89	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:09
S92	2163	((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:10
S93	40	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:10
S94	40	S92 and S93	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:10
S95	0	S94 and S91	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:10
S96	188	blue color near5 ("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;		ON	2009/11/23 09:11

		nano meter or ANG)	IBM_TDB		1	
S97	0	S96 and S91	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:11
S98	212	blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:13
S99	0	S98 and S91	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:13
S100	321	blue color near5 (wavelength or wave length) same ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:14
S101	358	blue color near5 (wavelength or wave length) same ("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:15
S102	1	S100 and S91	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:15
S103	1	S101 and S91	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:15
S104	16928194	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:33
S105	0	S94 and S104	US-PGPUB; USPAT; USOCR;	ADJ	ON	2009/11/23 09:33

			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S106	745	NI CHI A CORPORATI ON. as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:39
S107	12	NI CHI A KAGAKU KOGYO KABUSHIKI KAI SHA.as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:39
S108	757	S106 or S107	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:39
S109	757	S106 or S107	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	ON	2009/11/23 09:40
S110	9	S100 and S109	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	ON	2009/11/23 09:40
S111	5	S101 and S109	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:40
S112	10	S110 or S111	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/11/23 09:40
	0	S112 and S104	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		ON	2009/11/23 09:41
S114	17759950	@ad<"19970331" or	US-PGPUB;	<b>A</b> DJ	ON	2010/05/31

		@rlad<"19970331"	USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			14:20
S115	520	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:21
S116	460	(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:21
S117	13	S115 and S116	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:21
S118	0	S117 and S114	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:21
S119	104	(LED or light emit\$3) near5 spectrum near3 ("420" or "430" or "440" or "450" or "460" or "470" or "480" or "490" or "500" or "510" or "520" or "530" or "540" or "550" or "560" or "570" or "580" or "590" or "600" or "610" or "620" or "630" or "640" or "650" or "660" or "670" or "680" or "690" or "700") adj (nm or nano meter or nano metre)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:28
S120	15	S114 and S119	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:29
S121	2506	spectrum near3 phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:29
S122	2	S120 and S121	US-PGPUB; USPAT; USOCR;	ADJ	ON	2010/05/31 14:29

			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S123	108	("20010030326"   "3510732"   "3652956"   "3691482"   "3699478"   "3748548"   "3819974"   "3875456"   "4298820"   "4314910"   "4550256"   "4644223"   "4716337"   "4727283"   "4857228"   "4905060"   "5006908"   "5118985"   "5202777"   "5257049"   "5369289"   "5471113"   "5512210"   "5550657"   "5578839"   "5602418"   "5630741"   "5700713"   "5798537"   "5825113"   "5847507"   "5949182"   "5959316"   "5998925"   "6004001"   "6066511"   "6069440"   "6340824"   "6538371"   "6576930"   "6608332"   "6614179"   "6784511"   "6798537"   "6812500"   "7026756"   "7071616"   "7126274"   "7215074"   "7329988"   "7362048"   "7531960").PN.	US-PGPUB USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:32
S124	504	((light adj3 emit\$3) or LED) near5 transparent material	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:34
S125	0	S123 and S124	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:34
S126	5	S124 and S121	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:35
S127	0	S120 and S126	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		ON	2010/05/31 14:35
S128	2458	((light adj3 emit\$3) or LED) same (phosphor and nitri\$3)	US-PGPUB: USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		ON	2010/05/31 14:36
S129		(adjust\$3 or align\$3 or alin\$3) near5 ((light adj3 emit\$3) or LED) same	US-PGPUB; USPAT;	<b>A</b> DJ	ON	2010/05/31 14:36

		(phosphor and nitri\$3)	USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
S130	46	S128 and S129	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:36
S131	49415	(LCD or liquid crystal display) same color filter	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:37
S132	4	S119 and S131	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:37
S133	236146	"257"/\$	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:38
S134	195807	"438"/\$	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:38
S135	115041	S133 and S134	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:39
S136	46352	"349"/\$	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:39
S137	3373	S135 and S136	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 14:39

				38	8
S138	125801	"359"/\$	US-PGPUB; ADJ USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ON	2010/05/31 14:39
S139	64206	"313"/\$	US-PGPUB; ADJ USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ON	2010/05/31 14:39
S140	3125	S138 and S139	US-PGPUB; ADJ USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ON	2010/05/31 14:40
S141	186	S131 and S140	US-PGPUB; ADJ USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ON	2010/05/31 14:40
S142	18	S137 and S141	US-PGPUB; ADJ USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ON	2010/05/31 14:40
S143	111	S128 and S131	US-PGPUB; ADJ USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ON	2010/05/31 14:40
S144	1	S142 and S143	US-PGPUB; ADJ USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ON	2010/05/31 14:41
S145	8649	349/69-105.cds.	US-PGPUB; ADJ USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ON	2010/05/31 15:07
S146	1822	S131 and S145	US-PGPUB; ADJ USPAT; USOCR; FPRS; EPO; JPO;	ON	2010/05/31 15:07

			DERWENT; IBM_TDB			
S147	17	S119 and S121	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:08
S148	0	S146 and S147	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:08
S149	5106	(LCD or liquid crystal display) near3 (glass or transparent) adj (wafer or substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:11
S150	872	liquid crystal near3 (inject\$3 or introduc\$3 or dispens\$3) near5 (glass or transparent) adj (wafer or substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:14
S151	129	S149 and S150	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	ON	2010/05/31 15:14
S152	0	S119 and S151	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/31 15:15
S153	0	("10677382" "12548614" "12548620" "12559042").ap.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 17:39
S154	0	("10/677382" "12/548614" "12/548620" "12/559042").ap.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 17:40
S155	24	("677382" "548614" "548620" "559042").ар.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 17:40
S156	4	("20090315015" "20100001258" "20090315014" "7026756" "7026756").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 17:45
S157	0	"7362048.pn"	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 19:46
S158	0	"7362048.pn."	US-PGPUB;	OR	OFF	2010/06/07

			USPAT; USOCR		Department	19:46
S159	1	"7362048".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 19:47
S160	894622	phosphor near5 transparent material same (LED or light emit\$3)	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/07 19:56
S161	227	blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 19:56
S162	198	blue color near5 ("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 19:56
S163	7	S161 and S162	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 19:56
S164	67510	("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:02
S165	137544	("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:02
S166	31514	S164 and S165	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:02
S167	13207	S160 and S166	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:02
S168	17760117	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR;	ADJ	ON	2010/06/07 20:03

			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S169	16666	((light adj3 emit\$3) or LED) same nitride	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:03
S170	1488	S168 and S169	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:03
S171	5111	(LCD or liquid crystal display) near3 (glass or transparent) adj (wafer or substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:03
S172	873	liquid crystal near3 (inject\$3 or introduc\$3 or dispens\$3) near5 (glass or transparent) adj (wafer or substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:03
S173	129	S171 and S172	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:03
S174	0	S170 and S173	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:04
S175	61	S170 and S167	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:04
S176	0	transparent adj mateial near5 (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		ON	2010/06/07 20:05
S177	1555	transparent adj material near5 (LED	US-PGPUB;	<b>A</b> DJ	ON	2010/06/07

		or light emit\$3)	USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			20:05
S178	0	S175 and S177	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/07 20:05
S179	2	"5700713".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/08 13:30
S180	0	bck light near5 (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/08 19:27
S181	2980	back light near5 (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/08 19:27
S182	5397	liquid crystal near5 glass substrate	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	OFF	2010/06/08 19:28
S183	40	S181 and S182	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/08 19:28
S184	17760148	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/08 19:29
S185	16932587	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;	ADJ	ON	2010/06/08 19:29

			IBM_TDB			
S186	3	S183 and S185	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/08 19:30
S187	56	("20010030326"   "20090315014"   "20090315015"   "20100001258"   "3510732"   "3652956"   "3691482"   "3699478"   "3748548"   "3819974"   "3875456"   "4298820"   "4314910"   "4550256"   "4644223"   "4716337"   "4727283"   "4857228"   "4905060"   "5006908"   "5118985"   "5202777"   "5257049"   "5369289"   "5471113"   "5512210"   "5550657"   "5578839"   "5602418"   "5578839"   "5602418"   "5825125"   "5847507"   "5825125"   "5847507"   "5949182"   "5959316"   "5998925"   "6004001"   "6066861"   "6069440"   "6340824"   "6538371"   "6575930"   "6608332"   "6614179"   "6784511"   "6798537"   "6812500"   "7026756"   "7071616"   "7126274"   "7215074"   "7329988"   "7362048"	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/06/19 13:54
S188	24	(diameter or radi\$3) near3 (conduct\$3 or wire) near3 ("10" or "15" or "20" or "25" or "30" or "35" or "40" or "45") adj (mu or micro or meter)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 13:59
S189	0	S187 and S188	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 14:02
S190	1	"20090315014".pn.	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/06/19 14:04
S191	55	S187 and (diameter or radi\$3 or conduct\$3 or wire or ".mu.m" or "10" or "15" or "20" or "25" or "30" or "35" or "40" or "45")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 14:08
S192	75	(LED or Light emit\$3) adj3 chip near5 conduct\$3 adj wire	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 14:44

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S193	1	S187 and S192	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 14:44
S194	11	("1305111" or "6340824").pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:13
S195	951	diameter near5 conduct\$3 adj wire	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:16
S196	14	S191 and S195	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:17
S197	168	phosphor near3 transparent material	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:18
S198	3	S196 and S197	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:18
S199	178048	shimizu.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:19
S200	161	S197 NOT S199	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:20
S201	2	("5949182" "3748548").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/19 15:28
S202	34	("2913632"   "3173101"   "3179542"	US-PGPUB;	<b>A</b> DJ	OFF	2010/06/19

		"3209214"   "3229104"   "3234057"   "3260902"   "3270235"   "3283160"   "3372069").PN. OR ("3748548").URPN.	USPAT; USOCR			15:28
S203	21	("3665241"   "3755704"   "3812559"   "4513308"   "5064396"     "5186670"   "5199917"   "5229331"   "5232549"   "5316979"     "5329207"   "5363021"   "5438240"   "5448132"   "5615143").PN. OR ("5949182").URPN.	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/06/19 15:30
S204	2	("5630741" "4857228").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2010/06/19 15:34
S205	2	S192 and S197	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:38
S206	16932745	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/06/19 15:41
S207	2	S192 and S206	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:42
S208	318	S195 and S206	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB	ADJ	OFF	2010/06/19 15:42
S209	0	S208 and S197	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2010/06/19 15:43
S210	6	("3699478"   "5221984"   "5594751"   "5801435"   "6015200"   "6600175").PN.	US-PGPUB; USPAT; USOCR	<b>A</b> DJ	OFF	2010/10/21 16:00
S211	5	("4001628"   "5208462"   "5706022"   "5743629"   "6600175").PN.	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/10/21 16:09
S212	2	"6600175".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO;	ADJ	OFF	2010/10/24 13:21

			DERWENT; IBM_TDB			
S213	6	("3699478"   "5221984"   "5594751"   "5801435"   "6015200"   "6600175").PN.	US-PGPUB; USPAT; USOCR	ADJ	OFF	2010/10/24 13:25
S214	3	"3699478".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/04/21 16:56
S215	3	("4992704" "20090315014" "5045867").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2011/04/22 14:59
S216	2	("2009/0315014").URPN.	USPAT	<b>A</b> DJ	OFF	2011/04/22 14:59
S217	581	(conduct\$3 or electric\$3) adj5 (wire or cable) with (diameter or radius or size) with (("10" "15" "20" "25" "30" "35" "40" "45") adj(".mu.m" or micro or micron or meter or metre))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/04/22 15:19
S218	16934970	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:20
S219	82	S217 and S218	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:20
S220	19216	((light adj3 emit\$3) or LED) same nitride	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:21
S221	1245	S218 and S220	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:22
S222		S219 and S221	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		ON	2011/04/22 15:22
S223	7	((light adj3 emit\$3) or LED) and	US-PGPUB;	<b>A</b> DJ	ON	2011/04/22

		\$219	USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			15:22
S224	0	(transparent\$3 or visibl\$3) adj5 material with (LED or light emit\$3 diode or light emit\$3) and \$219	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:24
S225	0	(transparent\$3 or visibl\$3) adj5 material with phosphor and S219	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/04/22 15:25
S226	2	"4992704".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/13 16:16
S227	2	"20090315015".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 11:44
S228	3	("2009/0315015").URPN.	USPAT	<b>A</b> DJ	OFF	2011/05/17 11:51
\$229	550	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius) with (("10" or "15" or "20" or "25" or "30" or "35" or "40" or "45") adj (".mu.m" or micron or nm or mm))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 15:40
\$230	2267282	((LCD or liquid crystal display or liquid crystal) or (LED or light emitting diode or light emit\$3) or (bak light))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 15:48
\$231	227	S229 and S230	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 15:48
S232	16935137	@ad<"19960729" or @rlad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS;	ADJ	ON	2011/05/17 15:49

			EPO; JPO; DERWENT; IBM_TDB			
S233	18	S232 and S231	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/05/17 15:50
S234	47	phosphor near3 transparent material with (light emit\$3 or LED)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 15:54
S235	0	S233 and S234	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 15:54
S236	12	S234 and S231	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/05/17 15:54
S237	950368	phosphor near5 transparent material same (LED or light emit\$3)	US-PGPUB; USPAT; USOCR	OR	OFF	2011/05/17 16:55
S238	40	S234 and S237	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/05/17 16:56
S239	0	S233 and S238	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/05/17 16:57
S240	195589	S232 and S237	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/05/17 16:57
S241	6	S231 and S240	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;		ON	2011/05/17 16:58

			IBM_TDB			
S242	283	(wir\$3 or (conduct\$3 adj wire)) near3 (diameter or radius) with (LED or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 13:15
S243	74	(wir\$3 or (conduct\$3 adj wire)) near3 (diameter or radius) with (LED or light emit\$3) and @ad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 13:15
S244	74	(wir\$3 or (conduct\$3 adj wire)) near3 (diameter or radius) with (LED or light emit\$3) and @ad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 14:44
S245	13	S244 and (light emit\$3 or light emit\$3 diode or light emit\$3 display)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 14:44
S246	74	S244 and (LED or light emit\$3 or light emit\$3 diode or light emit\$3 display)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 14:47
S247	16	(wir\$3 or (conduct\$3 adj wire)) with (diameter or radius) with (light emit\$3 or light emit\$3 diode or light emit\$3 display) and @ad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 15:22
S248	93	(wir\$3 or (conduct\$3 adj wire) or conduct\$3) near3 (diameter or radius) with (LED or light emit\$3) and @ad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 16:05
S249	122	(wir\$3 or (conduct\$3 adj wire) or conduct\$3) near3 (diameter or radi\$3) with (LED or light emit\$3) and @ad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 16:05
S250	20	(wir\$3 or (conduct\$3 adj wire) or conduct\$3) near3 (diameter or radi\$3) with (light emit\$3 or light emit\$3 diode or light emit\$3 display)	US-PGPUB; USPAT; USOCR; FPRS;	ADJ	OFF	2011/06/03 16:06

		and @ad<"19970331"	EPO; JPO; DERWENT; IBM_TDB			
S251	20	(wir\$3 or (conduct\$3 adj wire) or conduct\$3) near3 (diameter or radi\$3) with (light emit\$3 or light emit\$3 diode or light emit\$3 display) and @ad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 16:06
S252	20	\$250 and \$251	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/03 16:06
S253	6501	257/98.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 10:27
S254	6501	(257/98).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/08 10:27
S255	4900	(257/99).OCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/08 10:27
S256	1730	(257/100).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ÖFF	2011/06/08 10:29
S257	78	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and S253	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 10:30
S258	6	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and \$253 and @ad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 10:30
S259	6	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter	US-PGPUB; USPAT;	<b>A</b> DJ	OFF	2011/06/08 10:33

		or radius or thick\$3) and \$254 and @ad< "19960729"	USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
S260	7	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and \$255 and @ad< "19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 10:34
S261	1	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and \$256 and @ad<"19960729"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 10:35
S262	0	438/106-127.ccls. and light near2 emitting near2 diode and (lead wire wiring conductor) near4 (thickness thick diameter)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 13:33
S263	56	438/106-127.ccls. and light near2 emitting near2 diode and (lead wire wiring conductor) near4 (thickness thick diameter)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/08 13:33
S264	3	("4347655" "5125153" "5885893").pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2011/06/08 13:34
S265	1730	(257/100).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/08 13:35
S266	0	(conduct\$3 or connect\$3) adj3 (wire or lead or electrode) with (diameter or radius or thick\$3) and \$265 and \$264	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 13:35
S267	3	\$264 and (wir\$3 or LED or light or emit\$3 or diameter or thick\$3)	US-PGPUB; USPAT; USOCR	OR	OFF	2011/06/08 13:38
S268	6501	257/98.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 13:46

S269	6501	257/98.cds. and \$268	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/08 13:46
S270	119519	quantum well and S268	US-PGPUB; USPAT; USOCR	OR	OFF	2011/06/08 13:47
S271	1489	quantum well and S268	US-PGPUB; USPAT; USOCR	ADJ	OFF	2011/06/08 13:47
S272	50	quantum well and S268 and @ad<"19970331"	US-PGPUB; USPAT; USOCR	ADJ	OFF	2011/06/08 13:48
S273	25	((single or multi\$3) adj quantum well) and \$268 and @ad<"19970331"	US-PGPUB; USPAT; USOCR	ADJ	OFF	2011/06/08 13:55
S274	27356	liquid crystal with (glass adj substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:10
S275	17763698	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:10
S276	4812	S274 and S275	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:11
S277	6515	257/98.cds.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:11
S278	1493	quantum well and \$277	US-PGPUB; USPAT; USOCR	ADJ	OFF	2011/06/09 12:11
S279	0	S278 and S276	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:11
S280	3	S277 and S276	US-PGPUB; USPAT; USOCR;	<b>A</b> DJ	ON	2011/06/09 12:11

			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S281	1071	(inject\$3 or introduc\$3 or insert\$3) with liquid crystal with (glass adj substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:16
S282	0	\$281 and \$275 and \$277	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:16
S283	505	(inject\$3 or introduc\$3 or insert\$3) with liquid crystal with (glass adj substrate) and color filter	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:19
S284	123	\$275 and \$283	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:20
S285	0	\$277 and \$284	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:20
S286	3	(inject\$3 or introduc\$3 or insert\$3) with liquid crystal with (glass adj substrate) and color filter with (LED or light emitting diode or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:22
\$287	144	(inject\$3 or introduc\$3 or insert\$3) with liquid crystal with (glass adj substrate) and color filter and (LED or light emitting diode or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:22
\$288		\$275 and \$287	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		ON	2011/06/09 12:25
S289	7280	liquid crystal with (glass adj	US-PGPUB;	<b>A</b> DJ	OFF	2011/06/09

		substrate) and color filter	USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			12:25
S290	55	\$288 and \$289	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:25
S291	0	\$277 and \$290	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/09 12:26
S292	2596	liquid crystal with (glass adj substrate) with color filter	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:33
S293	19	\$290 and \$292	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2011/06/09 12:33
S294	17764738	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/04 17:14
S295	4	("3623867"   "3842306"   "5816677").PN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2011/11/04 17:17
S296	17764740	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:05
S297	4	("3623867"   "3842306"   "5816677").PN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2011/11/05 13:06
S298	1	("3875456").PN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2011/11/05 13:13
\$299	17764740	@ad<"19970331" or @rlad<"19970331"	US-PGPUB; USPAT; USOCR;	ADJ	ON	2011/11/05 13:51

			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S300	568	stoichiometri\$3 and (coprecipitat\$3 or precipitat\$3) same phosphor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:51
S301	47842	((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:51
S302	239	S301 and S300	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:51
S303	11	S302 and S299	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 13:51
S304	11176	phosphor with (concentrat\$3 or quatity or quality or different or mix\$3) with (LED or light or light emit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:04
S305	1869	S296 and S304	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:04
S306	773	S301 and S305	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:04
S307	21084	((light adj3 emit\$3) or LED) same nitride	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:04
S308	984	(adjust\$3 or align\$3 or alin\$3) near5	US-PGPUB;	ADJ	ON	2011/11/05

		((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			14:05
S309	4468235	(oxide or ammonium or fluoride or aluminum)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S310	2933	(ammonium adj3 fluoride) and (aluminum adj3 oxide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S311	2933	S309 and S310	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S312	80	S300 and S311	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S313	3	S308 and S312	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S314	12	("5798537" "5998925" "6069440" "6608332" "6614179" "7026756" "7071616" "7126274" "7215074" "7329988" "7362048" "7531960").pn.	US-PGPUB; USPAT; USOCR	OR	ON	2011/11/05 14:05
S315	47842	((light adj3 emit\$3) or LED) same (phosphor or nitri\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
	12	S315 and S314	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB		ON	2011/11/05 14:05
S317	260	blue color near5 ("420" or "425" or	US-PGPUB;	<b>A</b> DJ	ON	2011/11/05

		"460" or "470" or "475" or "480" or "485" or "490") adj (nm or	USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			14:05
S318	961	NI CHI A CORPORATI ON. as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S319	12	NICHIA KAGAKU KOGYO KABUSHIKI KAISHA.as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05
S320	973	S318 or S319	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/11/05 14:05

## **EAST Search History (Interference)**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S82	469	NI CHI A CORPORATI ON. as.	USPAT; UPAD	<b>A</b> DJ	ON	2009/10/12 19:51
S83	1 3	NICHIA KAGAKU KOGYO KABUSHIKI KAISHA.as.	USPAT; UPAD	<b>A</b> DJ	ON	2009/10/12 19:51
S84		blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	USPAT; UPAD	ADJ	ON	2009/10/12 19:51
S85	94	blue color near5 ("510" or "515" or "520" or "525" or "530" or "535" or "540" or "545" or "550" or "555" or "560" or "565" or "570" or "575" or "580" or "585" or "590" or "595" or "600") adj (nm or nanometre or nano meter or ANG)	USPAT; UPAD	ADJ	ON	2009/10/12 19:51
S86	0	S82 and S83	USPAT; UPAD	<b>A</b> DJ	ON	2009/10/12 19:52
S87	1	S84 and S85	USPAT; UPAD	<b>A</b> DJ	ON	2009/10/12 19:52
S88	0	phosphor near5 blue color near5 ("420" or "425" or "430" or "435" or "440" or "445" or "460" or "470" or "475" or "480" or "485" or "490") adj (nm or nanometre or nano meter or ANG)	USPAT; UPAD	ADJ	ON	2009/10/12 19:57

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0020-5147PUS12

Mustapha

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Application Number

Filing Date

First Named Inventor

Art Unit

1.2.942792

First Named Inventor

Yoshinori SHIMIZU

Art Unit

2812

Examiner Name

Attorney Docket Number

(Use as many sheets as necessary)

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0000	AB*	US-5,257,049	10-26-1993	Van Peteghem	
	AC*	US-6,812,500	11-02-2004	Reeh et al.	
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	AE*	US-6,576,930	06-10-2003	Reeh et al.	
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	AG*	US-6,066,861	05-23-2000	Hohn et al.	
0000	АН"	US-5,959,316	09-28-1999	Lowery	
	Al*	US-5,118,985-A	06-02-1992	Patton et al.	
80000	AJ*	US-4,644,223	02-17-1987	de Hair et al.	
	AK*	US-6,538,371	03-25-2003	Duggal et al.	
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	AN"	US-5,550,657	08-27-1996	Tanaka et al.	
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/A.M./	ВА	JP-2002-270020-A	09-20-2002	CASIO COMPUTER CO LTD					
	BB	JP-7-321407	12-08-1995						
	BC	JP-6-115158	04-26-1994	AGFA GEVAERT NV		<u> </u>			
	BD	JP-61-158606	07-18-1986	The state of the s		<u> </u>			
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/A.M./	BF	JP-07-288341	10-31-1995	NICHIA CHEM IND LTD		<u> </u>			

Examiner	/Abdulfattah Mustapha/		
	/Abdulfattah Mustapha/	Date	10/11/0011
Signature	<u> </u>	Considered	12/11/2011
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				Application Number	12/942792	1
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S	STATEMENT BY APPLICANT		First Named Inventor	Yoshinori SHIMIZU		
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	(Use as many sheets as necessary)				Mustapha Mustapha	
Sheet	2	of	12	Attorney Docket Number	0020-5147PUS12	

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	AV*	US-4,727,283	02-23-1988	van Kemenade et al.	
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	AX*	US-3,699,478	10-17-1972	Pinnow et al.	
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	AZ*	US-5,202,777	04-13-1993	Sluzky et al.	
	AA1*	US-3,819,974	06-25-1974	Stevenson et al.	
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	AC1*	US-3,691,482	09-12-1972	Pinnow et al.	
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	AE1*	US-4,716,337		Huiskes et al.	
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	AG1*	US-5,825,125-A	10-20-1998	Ligthart et al.	
	AH1*	US-5,602,418-A	02-11-1997	Imai et al.	
	Al1*	US-5,998,925-A	12-07-1999	Shimizu et al.	
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S	STATEMENT BY APPLICANT	PPLICANT	First Named Inventor	Yoshinori SHIMIZU		
				Art Unit	2812	
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Sheet	3	of	12	Attorney Docket Number	0020-5147PUS12	1

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	BQ	GB-2 000 173	01-04-1979			-
/A.	MBR	EP-0 383 215-A	08-22-1990			_

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	INFORMATION DISCLOSURE			Filing Date	Concurrently Herewith 11/09,
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/A.	MBX	JP-02-111922-A	04-24-1990		

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INF	INFORMATION DISCLOSURE			Filing Date	Concurrently berewith 11/09/2	
STA	STATEMENT BY APPLICANT		First Named Inventor	Yoshinori SHIMIZU		
	///aa aa			Art Unit	<b>144</b> 2812	
	(Use as many sheets as necessary)		Examiner Name	Net Yet Assigned		
Sheet	5	of	12	Attorney Docket Number	0020-5147PUS12	

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xaminer	Cite	Foreign Patent Document	Publication Date	Name of Patentee or	Pages, Columns, Lines,	
tials*	No.1	Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)	MM-DD-YYYY	Applicant of Cited Document	Where Relevant Passages Or Relevant Figures Appear	
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INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Application Number	12/942792	
				Filing Date	Concurrently Horawith 11/09	
			APPLICANT	First Named Inventor	Yoshinori SHIMIZU	
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(Use as many sheets as necessary)			s necessary)	Examiner Name	Not Vet Assigned Mustapha	
Sheet	6	of	12	Attorney Docket Number		

Examiner	Cite	Foreign Patent Document	Publication Date MM-DD-YYYY		Pages Columns Line	
Initials*	No.1	Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)		Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages Or Relevant Figures Appear	
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/A.N	/BM4	EP-0-550-937-A1	09-02-1992			Ļ

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. * CITE NO.: Those application(s) which are marked with an single asterisk (*) next to the Cite No. are not supplied (under 37 CFR 1.98(a)(2)(iii)) because that application was filed after June 30, 2003 or is available in the IFW. Applicant's unique citation designation number (optional). * See Kinds Codes of USPTO Patent Documents at <a href="www.uspto.gov">www.uspto.gov</a> or MPEP 901.04. * Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). * For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. * Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. * Applicant is to place a check mark here if English language Translation is attached.



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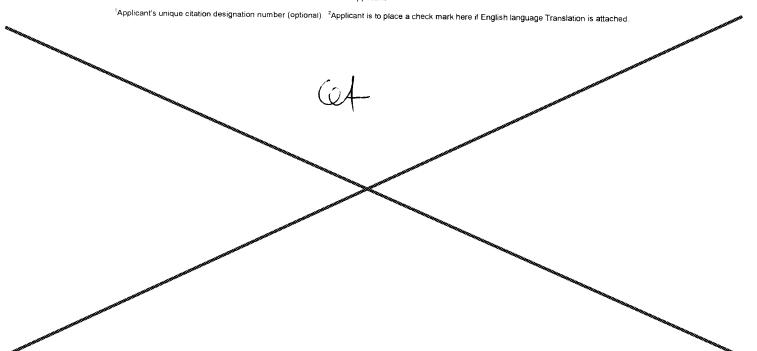
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				Application Number	NEW 12/942792
IN	INFORMATION DISCLOSURE STATEMENT BY APPLICANT			Filing Date	Concurrently Herewith 11/09/
S.				First Named Inventor	Yoshinori SHIMIZU
	44			Art Unit	2812
	(Use as many sheets as necessary)			Examiner Name	Not Yet Assigned Mustapha
Sheet	7	of	12	Attorney Docket Number	0020-5147PUS12

		NON PATENT LITERATURE DOCUMENTS	
Examiner Initials	Cile No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
/A.M.	CA	"White LED lamp: Efficient light-emitting; Manufacture cost half", Nikkei Sangyo Shimbun, September 13, 1996, Published by Nihon Keizai Shimbunsha.	
2000000000	СВ	"SIMENS SMT-TOPLED fur die Oberflachenmontage" Frank Mollmer et al. Simens Components, 29 (1991) Hfet 4.	
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Signature	/Abdulfattah Mustapha/	Date	12/11/2011
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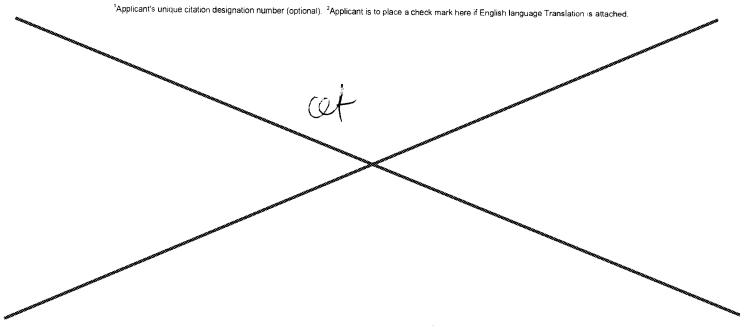
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	INFORMATION DISCLOSURE			Application Number	<b>₩</b> ₩ 12/942792
IN				Filing Date	Concurrently Herewith 11/09
S	STATEMENT BY APPLICANT		First Named Inventor	Yoshinori SHIMIZU	
	(Use as many sheets as necessary)			Art Unit	<b>***</b> 2812
				Examiner Name	Not Yet Assigned Mustapha
Sheet	8	of	12	Attorney Docket Number	0020-5147PUS12

		NON PATENT LITERATURE DOCUMENTS	
Examiner Cite No.1  /A.M./ CK		Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
		W.W. Holloway, Jr. et at., "Optical Properties of Cerium-Activated Garnet Crystals", 1969 Journal of the Optical Society of America, Vol. 59, No. 1, pp. 60-63	
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10 1	/Abdulfattah Mustapha/	Date	
Signature	/Abdulfattah Mustapha/	Considered	12/11/2011
		Considered	

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Complete if Known Substitute for form 1449/PTO ₩**EW** 12/942792 Application Number INFORMATION DISCLOSURE Filing Date <del>Concurrently-lerewith</del> 11/09 2010 STATEMENT BY APPLICANT First Named Inventor Yoshinori SHIMIZU Art Unit ******** 2812 (Use as many sheets as necessary) <del>Not Yet Assigned</del> Mustapha Examiner Name Sheet 9 of 12 Attorney Docket Number 0020-5147PUS12

Examiner	Cite	NON PATENT LITERATURE DOCUMENTS  Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of	Г
nitials	No.1	the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue	Т
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Examiner Signature	/Abdulfattah Mustapha/	Date Considered	12/11/2011
		Considered	

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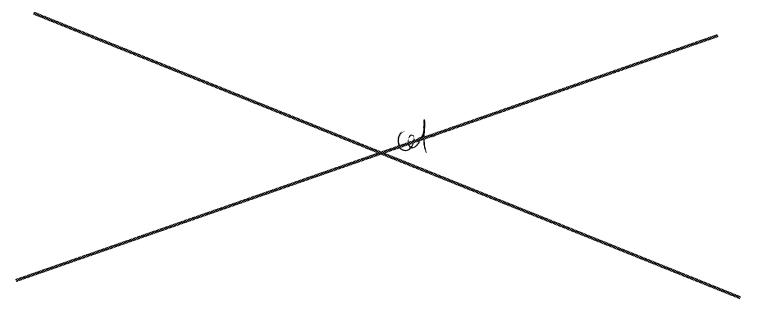
Complete if Known Substitute for form 1449/PTO Application Number **ઌૺઌૺૄૼ૽ઌૺઌ૾** 12/942792 INFORMATION DISCLOSURE Concurrently Herewith 11/09/2010 Filing Date STATEMENT BY APPLICANT First Named Inventor Yoshinori SHIMIZU Art Unit 2812 (Use as many sheets as necessary) Examiner Name Not Yet Assigned Mustapha Sheet 10 of 12 Attorney Docket Number 0020-5147PUS12

F		NON PATENT LITERATURE DOCUMENTS	_
Examiner Cite No.1  /A.M./ CI2		Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	<b>T</b> ²
		Office Action issued February 28, 2006, in U.S. Application No. 10/677,382 (U.S. Patent 7,026,756).	
200000000000000000000000000000000000000	CJ2	Notice of Allowance and Examiner's Comments on Allowance issued February 13, 2008, in connection with U.S. Application No. 10/609,402 (U.S. Patent 7,362,048).	
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CL2 CM2		Notice of Allowance and Examiner's Comments on Allowance issued March 10, 2006, in U.S. Application No. 10/864,544 (U.S. Patent 7,126,274).	
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**************************************	CP2	Notice of Allowance and Examiner's Comments on Allowance issued March 26, 2003, in U.S. Application No. 09/458,024 (U.S. Patent 6,614,179).	
000000000	CQ2	Notice of Allowance and Examiner's Comments on Allowance issued September 25, 2007, in U.S. Application No. 11/653,275 (U.S. Patent 5,998,925).	
/A.M./	CR:2	Notice of Allowance and Examiner's Comments on Allowance issued March 8, 1999, in U.S. Application No. 09/300,315 (U.S. Patent 6,069,440).	<u> </u>

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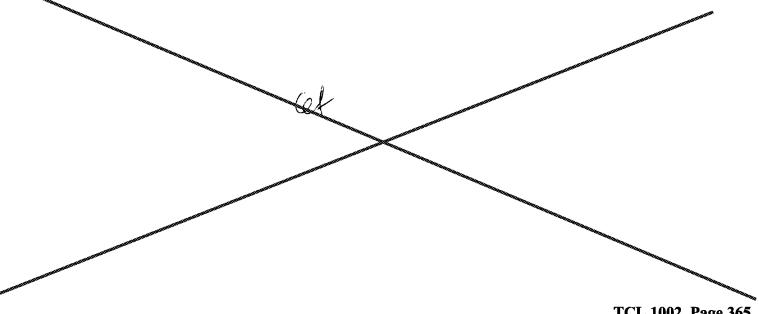
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	(Use as many sheets as necessary)			Art Unit	<b>MA</b> 2812
				Examiner Name	Not Yet Assigned Mustapha
Sheet	11	of	12	Attorney Docket Number	0020-5147PUS12

Examiner Initials	Cite Nc.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
/A.M./	CS2	Notice of Allowance and Examiner's Comments on Allowance issued January 28, 1999, in U.S. Application No. 08/902,725 (U.S. Patent 5,998,925).	
200000000	CT2	Office Action issued November 17, 2000, in U.S. Application No. 08/902,725 (U.S. Patent 5,998,925).	
000000000000000000000000000000000000000	CU2	Notice of Allowance and Examiner's Comments on Allowance issued September 22, 2005, in U.S. Application No. 10/677,382 (U.S. Patent 7,026,756).	
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		Office Action issued April 4, 2007, in U.S. Application 11/653,275 (U.S. Patent 7,329,988 B2).	┢┈
	CX:2	Notice of Allowance and Examiner's Comments on Allowance issued February 13, 2008, in U.S. Application No. 10/609,402 (U.S. Patent 7,362,048).	
000000000000000000000000000000000000000	CY:2	Notice of Allowance and Examiner's Comments on Allowance issued September 25, 2007, in U.S. Application No. 11/653,275 (U.S. Patent 7,329,988).	
	CZ2	Notice of Allowance and Examiner's Comments on Allowance issued October 8, 1999, in U.S. Application No. 09/300,315 (U.S. Patent 6,069,440).	
000000000	CA3	Office Action issUed October 20, 2009, in Japanese Patent Application No. 2009-065948 with partial English translation.	
/A.N	<b>СВ</b> 3	Hide et al., "White light from InGaN/conjugated polymer hybrid light-emitting diodes," Appl. Phys. Lett., Vol. 70 (20), May 19, 1997, http://apl.aip.org/apl/copyright.jsp, pp. 2664-2666.	

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Signature / Abdulfattah Mustapha/	Considered	12/11/20/11
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¹Applicant's unique citation designation number (optional). ²Applicant is to place a check mark here if English language Translation is attached.



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Substitute for form 1449/PTO					Complete if Known
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INF	ORMATI	ON DIS	CLOSURE	Filing Date	Concurrently Herewith
STATEMENT BY APPLICANT			PPLICANT	First Named Inventor	Yoshinori SHIMIZU 11/09/2
	41.			Art Unit	<b>***</b> 2812
(Use as many sheets as necessary)			necessary)	Examiner Name	Not Yet Assigned
Sheet	12	of	12	Attorney Docket Number	0020-5147PUS12

Examiner	Cite	NON PATENT LITERATURE DOCUMENTS  Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of	Т.
nitlals	No.1	the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
/A.M./	CC3	NAKAMURA et al., "High-Brightness InGaN Blue, Green and Yellow Light-Emitting Diodes with Quantum Well Structures", Japanese Journal of Applied Physics, Vol. 34, No. 7A, Part 2, July 1, 1995, pp. L797-L799 XP000702022	
20000000	CD3	Non-Final Office Action issued August 2, 2010, in co-pending U.S. Application Serial No. 12/559,042.	
	CD4	Hoffman, Journal of les, pp. 89-91 (1977).	
	CD5	H. Shinoda et al., Color Research & Application, Vol. 18, No. 5, October 1993, pp. 326-333.	1
	CD6	G. BLASSE et al., "Investigation of Some Ce3+-Activated Phosphors", Journal of Chemical Physics, Vol. 47, No. 12, 15 December 1967.	
	CD7	E.F. GIBBONS et al., "Some Factors Influencing the Luminous Decay characteristics of Y3Al5O12:Ce3+", J. Electrochem. Soc., Vol. 120, No. 6, June 1973.	
000000	CD8	D.J. ROBBINS et al., "Lattice Defects and Energy Transfer Phenomena in Y3Al5O12;Ce3+", pp. 1004-1013, printed June 19, 2001.	
33300000000000000000000000000000000000	CD9	Bando et al., Development and applications of highbright white LED lamps, November 29, 1996, The 264 th Proceedings of the Institute of Phosphor Society, pages 4-16 of the English translation.	
	CD10	Office Action issued December 13, 2005, in U.S. Application No. 11/208,729 (U.S. Patent No. 7,215,074).	
000000000000000000000000000000000000000	CD11	Office Action issued March 13, 2001, in U.S. Application No. 09/458,024 (U.S. Patent No. 6,614,179).	
888888888	CD12	Office Action issued August 14, 2002, in U.S. Application No. 09/736,425 (U.S. Patent No. 6,608,332).	
×0000000000000000000000000000000000000	CD13	Office Action issued August 19, 2005, in U.S. Application No. 10/609,402 (U.S. Patent No. 7,362,048).	
<b>8</b> 200000	CD14	Office Action issued July 27, 2007, in U.S. Application No. 10/609,402 (U.S. Patent No. 7,362,048).	
700000	CD15	Office Action issued January 2, 2008, in U.S. Application No. 10/609,402 (U.S. Patent No. 7,362,048).	Ī
90000000	CD16	Office Action issued April 8, 2005, in U.S. Application No. 10/677,382 (U.S. Patent No. 7,026,756).	
/A.M./	CD17	Office Action issued September 7, 2005, in U.S. Application No. 10/864,544 (U.S. Patent No. 7,126,274).	

Examiner	(6 to al. 18 at al. 8 5 at a land	Date	
Signature	/Abdulfattah Mustapha/	Considered	12/11/2011

^{*}EXAMINER. Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹Applicant's unique citation designation number (optional). ²Applicant is to place a check mark here if English language Translation is attached.



PTO/68/08b (07-09) Approved for use through 07/81/2012, OM8 0651-0031

U.S. Patent and Trademark Office, U.S. DEPARTMENT OF COMMERCE

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	Substitute for	form 14498/PTO			C	omplete if Known	
	INFOR	MATION	nisci	OSHRE	Application Number	12/942,792	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				~~~~~~	Filing Date	11-09-10	***************************************
(Use as many sheets as necessary)					First Named Inventor	Yoshinori Shimizu	***************************************
					Art Unit	2812	
				***************************************	Examiner Name	A. Mustapha	***************************************
Sheet 1 of 1				1	Aftorney Docket Number	0020-5147PUS12	

	*******	NON PATENT LITERATURE DOCUMENTS	**********
Examiner initial *	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	7.2
	1	U.S. Office Action issued in co-pending application 12/689,681 on December 5, 2011.	
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If you need assisstance in completing the form, call 1-800-PTO-9199 and select option 2



^{*} EXAMINEE: initial if reference considered, whether or not citation is in conformance with MPEP ISB. Draw line through citation if not in conformance and not considered, include copy of this form with next communication to applicant.

^{1.} Applicants unique citation designation number. (optional) 2. Applicant is to place a check mark here if English tanguage Translation is attached.

This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to tile (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete. Including gethering, preparing, and submitting the completed application from the USPTO. Time will vary depending upon the individual case. Any communits on the amount of time you require to complete this form end/or suggestions for inducing this burden, strough be sent to the Chef Information Officer, U.S. Parent and Trademark Office, P.O. Box 1450 Alexandria, VA 2313-1460 DC ROT ISBND FEES OR COMPLETED FORMS TO THIS ADDRESS.

SEND TO: Commissioner for Parents, P.O. Box 1450, Alexandria, VA 2313-1450.

Electronic Acl	knowledgement Receipt
EFS ID:	11886558
Application Number:	12942792
International Application Number:	
Confirmation Number:	2357
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY
First Named Inventor/Applicant Name:	Yoshinori Shimizu
Customer Number:	2292
Filer:	David Richard Anderson/Patti Young
Filer Authorized By:	David Richard Anderson
Attorney Docket Number:	0020-5147PUS12
Receipt Date:	20-JAN-2012
Filing Date:	09-NOV-2010
Time Stamp:	15:57:20
Application Type:	Utility under 35 USC 111(a)

# **Payment information:**

Submitted with Payment	no
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# File Listing:

Document Number	Document Description	File Name	File Size(Bytes)/ Message Digest	Multi Part /.zip	Pages (if appl.)
1		20120120IDS.pdf	2465793	ves	6
		201201201D3.pdf	1485e6c1728440ba7166156ec402f9d0a46f b0ea	, l	0

	Multipart Description/PDF files in .zip description					
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Information:						
2	Non Patent Literature	USOA12689681dated120511.	59363 <b>8</b> 9	no	12	
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		Total Files Size (in bytes)	84	02182		

This Acknowledgement Receipt evidences receipt on the noted date by the USPTO of the indicated documents, characterized by the applicant, and including page counts, where applicable. It serves as evidence of receipt similar to a Post Card, as described in MPEP 503.

#### New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

#### National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

#### New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.

Docket No.: 0020-5147PUS12

(Patent)

### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

12/942,792

Confirmation No.: 2357

Filed:

November 09, 2010

Art Unit:

2812

For:

LIGHT EMITTING DEVICE AND DISPLAY

Examiner:

A. Mustapha

# INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Commissioner:

Applicant(s) hereby submit(s) an Information Disclosure Statement for consideration by the Examiner.

#### 1. LIST OF PATENTS, PUBLICATIONS OR OTHER INFORMATION

The patents, publications, or other information submitted for consideration by the Office are listed on the attached PTO/SB/08.

- II. COPIES
- $\square$ Copies of foreign patent documents, non-patent literature and other information.
- $\Box$ 5 REFERENCES PREVIOUSLY CITED OR SUBMITTED: Copies of any information not provided can be found in one or more of the following applications which has been relied upon for an earlier filing date under 35 U.S.C. § 120:

U.S. Application No. and U.S. Filing Date 12/548,614 filed August 27, 2009



Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 2 of 5

# III. CONCISE EXPLANATION OF THE RELEVANCE/OTHER INFORMATION

a. NON-ENGLISH LANGUAGE DOCUMENTS: A concise explanation of the relevance of all non-English language patents, publications, or other information listed is as follows:

☐ b. ENGLISH LANGUAGE SEARCH REPORT OR FOREIGN PATENT OFFICE COMMUNICATION: An English language version of the search report or Foreign Patent Office communication that indicates the degree of relevance is attached.

☑ c. OTHER: The following additional information is provided.

A U.S. Office Action issued in co-pending application 12/689,681 on December 5, 2011 is attached. The references discussed in the Office Action were previously submitted to the USPTO in an IDS.

# IV. STATEMENT UNDER 37 C.F.R. § 1.97(e)

The undersigned hereby states that:

a. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than 30 days prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or

b. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or

QX:

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 3 of 5

© c. No item of information contained in the IDS was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing the certification after making reasonable inquiry, no item of IDS was known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of the IDS; or

d. Some of the items of information in the IDS were cited in a communication from a foreign patent office. Such items were first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office. As to the remaining items of information, to the knowledge of the person signing the certification after making reasonable inquiry, such remaining items were not known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of this statement.

### V. FEES

- a. This Information Disclosure Statement is being filed concurrently with the filing of a new patent application or Request for Continued Examination. No fee is required.
- D b. This Information Disclosure Statement is being filed within three months of the filing date of an application. No fee is required.
- C. This Information Disclosure Statement is being filed before the mailing date of a first Action on the merits. No fee is required. If a first Office Action on the merits has issued, please consider this IDS under 37 C.F.R. § 1.97(c) and see the statement under 37 C.F.R. § 1.97(e) above. If no statement has been made, charge our deposit account for the required fee.

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đ. This Information Disclosure Statement is being filed before the mailing date of a Final Office Action or before the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(c)(1)). No statement. The fee as required by 37 C.F.R. § 1.17(p) is provided.  $\alpha$ See the above statement. No fee is required. e. This Information Disclosure Statement is being filed after the mailing date of a Final Office Action or after the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(d)), see the statement above. The fee as required by 37 C.F.R. § 1.17(p) is provided. VI. PAYMENT OF FEES The required fee is listed on the attached Fee Transmittal.

Application No.: 12/942,792

V

No fee is required.

Docket No.: 0020-5147PUS12

Page 4 of 5

Application No.: 12/942,792 Docket No.: 6026-5147PUS12
Page 5 of 5

If the Examiner has any questions concerning this IDS, please contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the USPTO is requested to consider this IDS under the proper rule and charge the appropriate fee to Deposit Account No. 02-2448.

Data	od January 20 7817	Damastfully with it is
Day	ed: January 20, 2012	By D. Richard Anderson Registration No.: 40,439 BIRCH, STEWART, KOLASCH & BIRCH, LLP 8110 Gatchouse Road, Suite 100 East P.O. Box 747
		Falls Church, VA 22040-0747
		703-205-8000
Atta	whment(s):	
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$\boxtimes$	Document(s)	
	Foreign Patent Office Communication	
	Foreign Search Report	
	Fee	
	Other:	

PTO/SB/08b (07-09) Approved for use through 07/31/2012. OMB 0651-0031

U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

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	NEODN	ATION	DISCL	SCUDE	Application Number			
-	INFORMATION DISCLOSURE STATEMENT BY APPLICANT  (Use as many sheets as necessary)				Filing Date	11-09-10		
					First Named Inventor	Yoshinori Shimizu		
					Art Unit	2812		
	(000 a	o mony onco		·· 77	Examiner Name	Not Yet Assigned		
	Sheet	1	of	1	Attorney Docket Number	0020-5147PUS12		
	1							

		NON PATENT LITERATURE DOCUMENTS	
Examiner initial *	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	т2
	1	Office Action issued in co-pending US Appl. No. 12/575,155 on September 30, 2011.	
	2	Request for Invalidation with Notification of Acceptance of Request for Invalidation of Chinese Patent No. 03159595.2 dispatched on August 10, 2011.	
	3	Yao Go et al., Synthesis and Luminescence Gallium Nitride LED Blue Light Conversion Materials, ACTA PHYSICO-CHIMICA SINICA, Vol.19, No.3, March 2003, p226 – 229.	V
Exan	niner	Date	
Signa		Considered	

SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

If you need assisstance in completing the form, call 1-800-PTO-9199 and select option 2.

^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

^{1.} Applicants unique citation designation number. (optional) 2. Applicant is to place a check mark here if English language Translation is attached. This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Cheif Information Officer, U.S. Patent and Trademark Office, P.O. Box 1450 Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS.

Electronic Ac	knowledgement Receipt
EFS ID:	11383732
Application Number:	12942792
International Application Number:	
Confirmation Number:	2357
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY
First Named Inventor/Applicant Name:	Yoshinori Shimizu
Customer Number:	2292
Filer:	David Richard Anderson
Filer Authorized By:	
Attorney Docket Number:	0020-5147PUS12
Receipt Date:	10-NOV-2011
Filing Date:	09-NOV-2010
Time Stamp:	18:37:10
Application Type:	Utility under 35 USC 111(a)

# **Payment information:**

Submitted with Payment	no
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# File Listing:

Document Number	Document Description	File Name	File Size(Bytes)/ Message Digest	Multi Part /.zip	Pages (if appl.)
1		IDS SB08.pdf	257314	yes	6
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	Document Des	scription	Start	End	
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	Information Disclosure Staten	nent (IDS) Form (SB08)	6	6	i
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Information	:				
2	Non Patent Literature	IDSUSOA_12575155_dated_20	708084	no	13
	Tron ratent Enclatare	11-09-30.pdf	d0c257dbb4b398b06ac2264a835c05dd35 7858c3		
Warnings:					
Information	1:				
3	Information Disclosure Statement (IDS)	IDSNotice_Of_Acceptance_Of_ Request_For_Invalidation_CN0	1357114	no	30
	Form (SB08)	31595952.pdf	7c761b4264449ec7aa355f0a80a88cb2f269 e084		
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4	Non Patent Literature	IDCNIDI Va a C a 2204205 mdf	559568		0
4	Non Patent Literature	IDSNPL_YaoGo_2384305.pdf	89e6e59ca0678accec4b6ad1b52d1d7ef08 c85d0	no	8
Warnings:			-	'	
Information	1:				
		Total Files Size (in bytes)	288	32080	

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#### New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

#### National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

#### New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.

Docket No.: 0020-5147PUS12

(Patent)

#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

12/942,792

Confirmation No.: 2357

Filed:

November 09, 2010

Art Unit:

2812

For:

LIGHT EMITTING DEVICE AND DISPLAY

Examiner:

Not Yet Assigned

# INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Applicants hereby submit an Information Disclosure Statement for consideration by the Examiner.

### I. LIST OF PATENTS, PUBLICATIONS OR OTHER INFORMATION

The patents, publications, or other information submitted for consideration by the Office are listed on the attached PTO/SB/08.

# II. <u>COPIES</u>

a. Copies of foreign patent documents, non-patent literature and other information.

b. REFERENCES PREVIOUSLY CITED OR SUBMITTED: Copies of any information not provided can be found in one or more of the following applications which has been relied upon for an earlier filing date under 35 U.S.C. § 120:

U.S. Application No. and U.S. Filing Date

12/028,062 filed February 8, 2008

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Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 2 of 5

### III. CONCISE EXPLANATION OF THE RELEVANCE/OTHER INFORMATION

a. NON-ENGLISH LANGUAGE DOCUMENTS: A concise explanation of the relevance of all non-English language patents, publications, or other information listed is as follows:

b. ENGLISH LANGUAGE SEARCH REPORT OR FOREIGN PATENT OFFICE COMMUNICATION: An English language version of the search report or Foreign Patent Office communication that indicates the degree of relevance is attached.

☑ c. OTHER: The following additional information is provided.

The publication by Yao Go submitted herein was cited in the Request for Invalidation of Chinese Patent No. 03159595.2 submitted herein. Chinese Patent No. 03159595.2 is a counterpart foreign application of the present US application. The Request for Invalidation submitted herein was submitted to the Chinese Patent Office by a third party and then the Chinese Patent Office dispatched a Notification of Acceptance of Request for Invalidation, submitted herein, for informing the fact that a third party submitted a Request for Invalidation.

A concise explanation regarding publication by Yao Go and the Request for Invalidation is submitted herein, as follows. The publication by Yao Go cited in the Request for Invalidation is alleged to describe that a crystal structure of the garnet will have a defect and a light emitting characteristics will be suddenly changed if all Y is replaced with Gd. This concise explanation corresponds to a portion of the publication by Yao Go cited in the Request for Invalidation.

All references discussed and cited in the US Office Action of co-pending Appl. No. 12/575,155 submitted herein were previously submitted to USPTO.

### IV. STATEMENT UNDER 37 C.F.R. § 1.97(e)

The undersigned hereby states that:

Cob

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 3 of 5

a. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than <u>30</u> <u>days</u> prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or

b. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than **three months** prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or

o. No item of information contained in the IDS was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing the certification after making reasonable inquiry, no item of IDS was known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of the IDS.

cet

d. Some of the items of information in the IDS were cited in a communication from a foreign patent office. Such items were first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office. As to the remaining items of information, to the knowledge of the person signing the certification after making reasonable inquiry, such remaining items were not known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of this statement.

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 4 of 5

V.	<u>FEES</u>	
	a.	This Information Disclosure Statement is being filed concurrently with the filing
of a ne	w paten	t application or Request for Continued Examination. No fee is required.
	b.	This Information Disclosure Statement is being filed within three months of the
filing	date of a	n application. No fee is required.
	c.	This Information Disclosure Statement is being filed before the mailing date of a
		n the merits. No fee is required. If a first Office Action on the merits has issued,
_		er this IDS under 37 C.F.R. § 1.97(c) and see the statement under 37 C.F.R.
§ 1.97	(e) abov	e. If no statement has been made, charge our deposit account for the required fee.
_		This Information Displayure Statement is being filed before the mailing date of a
Ц	d.	This information Disclosure Statement is being fined before the making date of a
Final	Office	Action or before the mailing date of a Notice of Allowance (see 37 C.F.R.
§ 1.97	(c)(1)).	
		No statement. The fee as required by 37 C.F.R. § 1.17(p) is provided.
		or
	-	See the above statement. No fee is required.
	e.	This Information Disclosure Statement is being filed after the mailing date of a
		Action or <u>after</u> the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(d)),
see th	e statem	ent above. The fee as required by 37 C.F.R. § 1.17(p) is provided.
VI.	PAYN —	MENT OF FEES
		The required fee is listed on the attached Fee Transmittal.
		No fee is required.

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 5 of 5

If the Examiner has any questions concerning this IDS, please contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the USPTO is requested to consider this IDS under the proper rule and charge the appropriate fee to Deposit Account No.

02-2448.

Dated: November 10, 2011

Respectfully submitted,

D. Richard Anderson

Registration No.: 40439

BIRCH, STEWART, KOLASCH & BIRCH, LLP

8110 Gatehouse Road, Suite 100 East

P.O. Box 747

Falls Church, VA 22040-0747

703-205-8000

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☑ Document(s)

☐ Foreign Patent Office Communication

☐ Foreign Search Report

☐ Fee

Other: (1) Request for Invalidation with Notification of Acceptance of Request for Invalidation of Chinese Patent No. 03159595.2 dispatched on August 10, 2011.

(2) Office Action issued in co-pending US Appl. No. 12/575,155 on September 30, 2011.



U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE

Under the Paperwork reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number,

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	33.55.05.05.	2 & & ~~ 5 ~~ A \$	~.~~	^.~	Application Number	12/942,792	
				LOSURE	Filing Date	11-09-10	
	STATE	MENTE	iy ap	PLICANT	First Named Inventor	Yoshinori Shirnizu	
					Art Unit	2812	
	(Use as many sheets as necessary)				Examiner Name	Not Yet Assigned	
<b></b>	Sheet	1	of	2	Attorney Docket Number	0020-5147PUS12	

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Examiner initial *	Cite	Decument Number	Publication Date	Name of Patentée or	Pages, columns, Lines Where
	No.	Number - Kind Code ² (if known)	MM-DO-YYYY	Applicant of Cited Document	Pages, columns, Lines, Where Relevant Passages or Relevant Figures Appear
	1	US-3,623,867	11-30-1971	Saulnier	
	2	US-3,842,306	10-15-1974	Henderson et al	
	3	US-5,840,218	06-17-1997	Hasegawa et al.	***************************************
	4	US-8,670,797	09-23-1997	Okszaki	***************************************
	5	US-5,816,677 -	10-06-1998	Kurematsu et al.	***************************************
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Examiner	Date	
Signature	Considered	

This collection of information is required by 37 CFR 1.97 and 1.96. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentially is governed by \$6 U.S.C. 122 and \$7 OFR 1.14. This collection is estimated to take 2 hours to complete. including gathering, preparing, and submitting the completed application form the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you registre to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Cifficer, U.S. Patern and Trademark Office, P.C. Sex 1950 Alexandria, VA 22313-1450, DO NOT SEND FIES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

If you need assessence in completing the form, call 1-800-PTO-9198 (1-800-786.9199) and select option 2

^{*} EXAMINER: tritial if reference considered, whether or not citation is in conformance with MPEP 608. Draw line through dilation if not in conformance and not Considered, Include casy of this form with next communication to applicant, 4. Applicant's unique cliation design number (optional), 2. See Kinds Codes of USPTO potent Documents, at www.useto gov or MPEP 901.04, 3. Enter Office that issued the document, by the two lieties code (WIPO Standard ST.3), 4. For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. 5. Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST 16 if possible, 6, Applicant is to place a check mark here if English language Translation is attached

PTO/SB/08b (07-09)

Approved for use through 07/31/2012, OMB 0661-0031

U.S. Patient and Trademark Office: U.S. DEPARTMENT OF COMMERCE

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NATURE OF THE PARTY OF THE PART	Substitute for	form 14	498/PTO			C	omplete if Known
INFORMATION DISCLOSURE				isci	OSLIBE	Application Number	12/942,792
					LICANT	Filing Date	11-09-10
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	******	,		<b>.</b>	***************************************	Examiner Name	Not Yet Assigned
	Sheet 2 of 2			2	Attorney Docket Number	0020-5147PUS12	
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		NON PATENT LITERATURE DOCUMENTS	
Examiner initial *	Cite No. 1	include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	7 2
	6	U.S. Office Action issued in co-pending application 12/548,614 on June 27, 2011.	
	7	U.S. Office Action issued in co-pending application 12/689,681 on June 23, 2011.	
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If you need assissiance in completing the form, call 1-809-PTO-9199 and select option 2.

SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.



considered, Include copy of the form with next communication to applicant.

1. Applicants unique district designation number, (optional) 2. Applicant is to prace a check mark here if English language Translation is effected.

This collection is information is required by 37 OFP, 197 and 1,98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 36 U.S.C. 122 and 37 OFP, 1,147. This collection is estimated to take 2 hours to complete, including patheting, preparing, and submitting the completed application from the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for rectuoning this bordon, should be sent to the Chell information Officer, U.S. Patent and Trademark Office, P.O. 80x 1460 Alexandria, VA 22318-1460, DO NOT SEND FEES OR COMPLETED FORMS, TO THIS ADDRESS.

Docket No.: 0020-5147PUS12

(Patent)

#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

12/942,792

Confirmation No.: 2357

Filed:

November 09, 2010

Art Unit:

2812

For: LIGHT EMITTING DEVICE AND DISPLAY

Examiner:

Not Yet Assigned

# RESPONSE TO NOTICE REGARDING POWER OF ATTORNEY

MS Missing Parts Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir

A USPTO Notice dated November 23, 2010 indicated that the Power of Attorney filed on November 9, 2010 is improper under 37 C.F.R. 1.32. Applicants respectfully submit the following to cure the above-mentioned issues with the Power of Attorney:

- Attached is a copy of the Notice Regarding Power of Attorney.
- Under the provisions of 37 C.F.R. §§ 1.41(c) and 1.53(f), attached hereto is the executed Declaration of the inventor(s) (□ original ☑ photocopy), which was submitted to USPTO on November 9, 2010 and included the Power of Attorney.
- The undersigned hereby declares that "Attorney Docket No. 20-4260P" on page 1 of the attached inventors' Declaration, corresponds to Appl. No. 08/902,725, filed July 29, 1997, now US Patent 5,998,925, entitled "LIGHT EMITTING DEVICE HAVING A NITRIDE COMPOUND SEMICONDUCTOR AND A PHOSPHOR CONTAINING A GARNET FLUORESCENT MATERIAL", and which is a priority document in the domestic priority chain of the present application.

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 2 of 3

### 37 C.F.R. 1.32(e)(3)

A power of attorney may only name as representative ten (10) or fewer practitioners, stating the name and registration number of each patent practitioner. Under this rule the following ten (10) or fewer practitioners to be recognized by the Office are listed herein below:

Name	Reg. No.	Name	Reg. No.
Andrew D. Meikle	32,868	Terrell C. Birch	19,382
Joseph A. Kolasch	22,463	James M. Slattery	28,380
Michael K. Mutter	29,680	Charles Gorenstein	29,271
Leonard R. Svensson	30,330	Gerald M. Murphy, Jr.	28,977

Applicants submit that the correction above addresses the issue concerning the Power of Attorney. Applicants respectfully request that the Power of Attorney in the present application be accepted.

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 3 of 3

### Conclusion

If necessary, the Commissioner is hereby authorized in this, concurrent, and future replies, to charge payment or credit any overpayment to our Deposit Account No. 02-2448 for any additional fees required under 37 C.F.R. § 1.16 or under § 1.17; particularly, extension of time fees.

Dated:

AUG 3 0 2011

Respectfully submitted,

By

Andfew D. Meikle Registration No.: 32,868

8110 Gatehouse Road, Suite 100 East

Falls Church, VA 22040-0747

703-205-8000



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PO 80X 747

### United States Patent and Trademark Office

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APPLICATION MUMBER

FILING OR 371(C) DATE

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ATTY DOCKET NO/TITLE

12/942,792

BIRCH STEWART KOLASCH & BIRCH

FALLS CHURCH, VA 22040-0747

11/09/2010

Yoshinori Shimicu

0020-5147PUS12 CONFIRMATION NO. 2357

IMPROPER CPOA LETTER

Date Mailed: 11/23/2010

#### NOTICE REGARDING POWER OF ATTORNEY

This is in response to the Power of Attorney filed 11/09/2010. The Power of Attorney in this application is not accepted for the reason(s) listed below:

The Power of Attorney you provided did not comply with the new Power of Attorney rules that became
effective on June 25, 2004. See 37 CFR 1.32.

	/ema/
***************************************	

Office of Data Management, Application Assistance Unit (571) 272-4000, or (571) 272-4200, or 1-888-786-0101

# BIRE STEWART, KOLASCH & B. H, LLP



PLEASE NOTE: YOU MEST COMPLETE THE FOLLOWING: COMBINED . , CLARATION AND POWER OF ATTORNS  $\rightarrow$ FOR PATENT AND DESIGN APPLICATIONS

ATTORNEY DOCKET NO.

20-4260P

As a below named inventor, I hereby declare that: my residence, post office address and differenship are as stated next to my name; that I verily believe that I am the original, first and sole inventor (if only one inventor is named below) or an original, first and joint inventor (if plural inventors are named below) of the

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	my or our invention theref	of, or more than one year o	scribed in any printed publicati rior to this application, that th	on m any commy (cioac e same was not in public
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	no application for patent or United States of America follows.	r inventor's certificate on the prior to this application by	is invention has been filed in a me or my legal representati	by country foreign to the res or assigns, except as
		n priority benefits under Ti	tie 35, United States Code, §1	19 (a)-(d) of any forcien
	application(s) for patent of	r inventor's certificate list	ed below and have also iden a filing date before that of	ified below any foreign
	Prior Foreign Application	ı(s)		Priority Claimed
Seeser Princity	P 08-198585	Japan	07/29/1996	
information (if appropriate)	(Number)	(Country)	(Month/Day/Yest Filed)	Yes No
	P 08-244339 .	Japan	09/17/1996	Yes No
	(Number)	(Country)	(Month/Day/Year Filed)	Yes No
	P 08-245381	Japan	09/18/1996	X
	(Number) P 08~359004	(Country) Japan	(Month/Day/Year Filed) 12/27/1996	
	(Number)	(Country)	(Month/Day/Year Filed)	∑ □ Yes No
	P 09-081010	Japan	03/31/1997	
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	(Application Number)		(Filing Date)	
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	All Foreign Applications,	if any, for any Patent or I	nventor's Certificate Filed M	orc Than 12 Months (6
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	listed below and, insofar as	the subject matter of each	of the claims of this application	n is not disclosed in the
s	SITT I acknowledge the du	on in the manner provided to the disclose information w	by the first paragraph of Tide which is material to patentabili	ou, cance states cour, or as defined in Title 37
	Code of Federal Regulation	s, §1.56 which became avi	vilable between the filing date	of the prior application
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20-4260P

I hereby at the following attorneys to prosecute application and/or an international application based his application and to transact all busin jin the Patent and Trademark Office connected therewith had in connection with the resulting patent ased on instructions received from the entity who first sent the application papers to the attorneys identified below, unless the inventor(s) or assignee provides said attorneys with a written notice to the contrary:

RAYMOND C, STEWART (Reg. No. 21,066) JOSEPH A. KOLASCH (Reg. No. 22,463) JAMES M. SLATTERY (Reg. No. 28,380)

CHARLES GORENSTEIN (Reg. No. 29,271)
LEONARD R. SVENSSON (Reg. No. 30,330)
MARC S. WEINER (Reg. No. 32,181)
JOE McKINNEY MUNCY (Reg. No. 32,334)
C. JOSEPH FARACI (Reg. No. 32,350)

TERRELL C. BIRCH (Reg. No. 19,382)
ANTHONY L. BIRCH (Reg. No. 26,122)
BERNARD L. SWEENEY (Reg. No. 24,448)
MICHAEL K. MUTTER (Reg. No. 29,680)
GERALD M. MURPHY, JR. (Reg. No. 28,977)
TERRY L. CLARK (Reg. No. 32,644)
ANDREW D. MEIKLE (Reg. No. 32,868)
ANDREW F. REISH (Reg. No. 33,443)

PLEASE NOTE: YOU MUST COMPLETE THE FOLLOWING:

(CISPTO Anomous VAD)

Send Correspondence to: BIRCH, STEWART, KOLASCH AND BIRCH, LLP

F.O. Box 747
Falls Church, Virginia 22040-0747
Telephone: (703) 205-8000
Facsimile: (703) 205-8050

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Fill Marse of First or Sole investmen	GIVEN NAME FAMILY NAME	INVENTOR'S SIGNATURE	0 0	DATE"
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Sewert Part Office Address 8	POST OFFICE ADDRESS (Complete Street Address inc c/o Nichia Kagaku: Kogyo Kabusi Anan-shi, TOKUSHIMA 774 JAPAN	kuding Cay, State & County) Niki Kaisha, 491–100	), Oka, Kamina	
Foli News of Socred Townsian, if anyt	GIVEN NAME FAMILY NAME	INVENTOR'S SIGNATURE		DATE* 07/22/1997
sex scheme	Kensho SAKANO	Konshe Sak		011 821 1331
	Residence (City, State & Country)		CHIZENSHIP	
	Anan-shi, Tokushima, Japan		Japan	
	PCST OFFICE ADDRESS (Complete Street Address inc c/o Nichia Kagaku Kogyo Kabusi Anan-shi, TOKUSHIMA 774 JAPAN	kuding Cây, State & Country) 11ki Kaisha, 491–100	), Oka, Kamina	kado,
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Full Name of Fourth	GIVEN NAME FAMILY NAME	INVENTOR'S SIGNATURE		DATE"
inventor, d'angu see above	Toshic MORIGUCHI	Joskie Honique	ki J	07/22/1997
	Residence (City, State & Country)	/	CITIZENSHIP	
	Aman-shi, Tokushima, Japan	· ·	Japan	<b>.</b>
	POST OFFICE ADDRESS (Complete Street Address Including City, State & Country) c/o Nichia Kagaku Kogyo Kabushiki Kaisha, 491-100, Oka, Kaminakacho, Anan-shi, TOKUSHIMA 774 JAPAN			
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see above	<u>.                                    </u>			~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~
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Daniel S. ml. O	***************************************			

Electronic Acl	Electronic Acknowledgement Receipt				
EFS ID:	10843325				
Application Number:	12942792				
International Application Number:					
Confirmation Number:	2357				
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY				
First Named Inventor/Applicant Name:	Yoshinori Shimizu				
Customer Number:	02292				
Filer:	David Richard Anderson/Patti Young				
Filer Authorized By:	David Richard Anderson				
Attorney Docket Number:	0020-5147PUS12				
Receipt Date:	30-AUG-2011				
Filing Date:	09-NOV-2010				
Time Stamp:	14:30:26				
Application Type:	Utility under 35 USC 111(a)				

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2	Non Patent Literature	USOA12548614dated062711.	507237	no	13
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3	Non Patent Literature	USOA12689681dated062311.	3229187	no	8
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4	Miscellaneous Incoming Letter	20110830Response.pdf	3066182	no	6
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This Acknowledgement Receipt evidences receipt on the noted date by the USPTO of the indicated documents, characterized by the applicant, and including page counts, where applicable. It serves as evidence of receipt similar to a Post Card, as described in MPEP 503.

#### New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

#### National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

#### New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.

Docket No.: 0020-5147PUS12

(Patent)

### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

12/942,792

Confirmation No.: 2357

Filed:

November 09, 2010

Art Unit:

2812

For: LIGHT EMITTING DEVICE AND DISPLAY

Examiner:

Not Yet Assigned

### INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Applicant(s) hereby submit(s) an Information Disclosure Statement for consideration by the Examiner.

### I. LIST OF PATENTS, PUBLICATIONS OR OTHER INFORMATION

The patents, publications, or other information submitted for consideration by the Office are listed on the attached PTO/SB/08.

### II. COPIES

a. Copies of foreign patent documents, non-patent literature and other information.

b. REFERENCES PREVIOUSLY CITED OR SUBMITTED: Copies of any information not provided can be found in one or more of the following applications which has been relied upon for an earlier filing date under 35 U.S.C. § 120:

U.S. Application No. and U.S. Filing Date 12/548.614 filed August 27, 2009

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 2 of 5

# CONCISE EXPLANATION OF THE RELEVANCE/OTHER INFORMATION 111. NON-ENGLISH LANGUAGE DOCUMENTS: A concise explanation of the relevance of all non-English language patents, publications, or other information listed is as follows: b. ENGLISH LANGUAGE SEARCH REPORT OR FOREIGN PATENT OFFICE COMMUNICATION: An English language version of the search report or Foreign Patent Office communication that indicates the degree of relevance is attached. $\square$ OTHER: The following additional information is provided. U.S. 3,623,867, U.S. 3,842,306 and U.S. 5,816,677 were cited in a U.S. Office Action issued in co-pending application 12/689,681 on June 23, 2011; and U.S. 5,670,797 and U.S. 5,640,216 were cited in a U.S. Office Action issued in co-pending application 12/548,614 on June 27, 2011. IV. STATEMENT UNDER 37 C.F.R. § 1.97(e) The undersigned hereby states that: Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than 30 days prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or Each item of information contained in the IDS was first cited in any

communication from a foreign patent office in a counterpart foreign application not more than

three months prior to the filing of this IDS. This statement does not relate to English language

counterparts not listed in a communication from the foreign patent office. Such English language

J.

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 3 of 5

counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or

- C. No item of information contained in the IDS was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing the certification after making reasonable inquiry, no item of IDS was known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of the IDS.
- d. Some of the items of information in the IDS were cited in a communication from a foreign patent office. Such items were first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office. As to the remaining items of information, to the knowledge of the person signing the certification after making reasonable inquiry, such remaining items were not known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of this statement.

#### V. FEES

- a. This Information Disclosure Statement is being filed concurrently with the filing of a new patent application or Request for Continued Examination. No fee is required.
- b. This Information Disclosure Statement is being filed within three months of the filing date of an application. No fee is required.
- © c. This Information Disclosure Statement is being filed before the mailing date of a first Action on the merits. No fee is required. If a first Office Action on the merits has issued,

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 4 of 5

please consider this IDS under 37 C.F.R. § 1.97(c) and see the statement under 37 C.F.R. § 1.97(e) above. If no statement has been made, charge our deposit account for the required fee. d. This Information Disclosure Statement is being filed before the mailing date of a Final Office Action or before the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(c)(1)). No statement. The fee as required by 37 C.F.R. § 1.17(p) is provided. Of See the above statement. No fee is required. €. This Information Disclosure Statement is being filed after the mailing date of a Final Office Action or after the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(d)), see the statement above. The fee as required by 37 C.F.R. § 1.17(p) is provided. VI. PAYMENT OF FEES The required fee is listed on the attached Fee Transmittal.  $\boxtimes$ No fee is required.

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 5 of 5

If the Examiner has any questions concerning this IDS, please contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the USPTO is requested to consider this IDS under the proper rule and charge the appropriate fee to Deposit Account No.

02-2448.

Attachment(s):

Other:

Dated: August 30, 2011

Respectfully submitted

D. Richard Anderson

Registration No.: 40,439

BIRCH, STEWART, KOLASCH & BIRCH, LLP

8110 Gatehouse Road, Suite 100 East

P.O. Box 747

Falls Church, VA 22040-0747

703-205-8000

M	PTO/SB/08
$\square$	Document(s)
	Foreign Patent Office Communication
	Foreign Search Report
	Fee

(A)

PTO/3B/08b (97-09)

Approved for use through 67/31/2012, CMB 0851-0031 U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

Under the Paperwork reduction Act of 1990, no persons are required to respond to a collection of information unless it contains a valid OMB control number.

NON PATENT LITERATURE DOCUMENTS						
Examiner initial *						
	1	U.S. Office Action issued in co-pending Application No. 12/575,155, dated April 19, 2011.				
*****						
Exam Signa	,	Date Considered	***********			

If you need assistance in completing the form, call 1-800-PTO-9199 and select option 2,



^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through distion it not in conformance and not considered. Include copy of this form with next consequences on applicant,

^{1.} Applicants unique citation designation number, (optional) 2. Applicant is to place a check mark here if English lenguage Translation is attached. This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 25 17.5.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering. preparity, and submitting the completed application form the USPTO. Time will very depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Cheff Information Officer, U.S. Petent and Trademark Office, P.O. Box 1450 Alexandria, VA 22313-1450, DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SENO TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Electronic Acknowledgement Receipt			
EFS ID:	10375325		
Application Number:	12942792		
International Application Number:			
Confirmation Number:	2357		
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY		
First Named Inventor/Applicant Name:	Yoshinori Shimizu		
Customer Number:	02292		
Filer:	David Richard Anderson/Patti Young		
Filer Authorized By:	David Richard Anderson		
Attorney Docket Number:	0020-5147PUS12		
Receipt Date:	23-JUN-2011		
Filing Date:	09-NOV-2010		
Time Stamp:	16:46:17		
Application Type:	Utility under 35 USC 111(a)		

# **Payment information:**

Submitted with Payment	no
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# File Listing:

Document Number	Document Description	File Name	File Size(Bytes)/ Message Digest	Multi Part /.zip	Pages (if appl.)
1		20110623IDS.pdf	2562207	yes	6
·		201100201801801	5b6eddcc7eff98b253b605b017c169ed434 af29b	, i	· ·

	Multipart Description/PDF files in .zip description				
	Document De	Start	E	nd	
	Transmittal Letter		1		5
	Information Disclosure Stater	ment (IDS) Form (SB08)	6		6
Warnings:					
Information:					
2	Non Patent Literature	USOA04192011.pdf	3827626	no	8
_	Tron ratem Enclatare	030/101132011.pdi	00eb2900654f1c54de8c1d07baf9dd9d1e7 5b997	110	
Warnings:					
Information:					
		Total Files Size (in bytes)	: 63	89833	

This Acknowledgement Receipt evidences receipt on the noted date by the USPTO of the indicated documents, characterized by the applicant, and including page counts, where applicable. It serves as evidence of receipt similar to a Post Card, as described in MPEP 503.

### New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

#### National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

## New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.

Docket No.: 0020-5147PUS12

(Patent)

# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

12/942,792

Confirmation No.: 2357

Filed:

November 09, 2010

Art Unit:

2812

For

LIGHT EMITTING DEVICE AND DISPLAY

Examiner:

Not Yet Assigned

# INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Applicant(s) hereby submit(s) an Information Disclosure Statement for consideration by the Examiner.

#### Ĭ. LIST OF PATENTS, PUBLICATIONS OR OTHER INFORMATION

The patents, publications, or other information submitted for consideration by the Office are listed on the attached PTO/SB/08.

#### П. COPIES

V Copies of foreign patent documents, non-patent literature and other information.

b. REFERENCES PREVIOUSLY CITED OR SUBMITTED: Copies of any information not provided can be found in one or more of the following applications which has been relied upon for an earlier filing date under 35 U.S.C. § 120:

U.S. Application No. and U.S. Filing Date

12/548,614 filed 08-27-2009

Application No.: 12/942,792 Docket No.: 0020-5147PUS12

Page 2 of 5

III. CONCISE EXPLANATION OF THE RELEVANCE/OTHER INFORMATION NON-ENGLISH LANGUAGE DOCUMENTS: A concise explanation of the relevance of all non-English language patents, publications, or other information listed is as follows: Ъ. ENGLISH LANGUAGE SEARCH REPORT OR FOREIGN PATENT OFFICE COMMUNICATION: An English language version of the search report or Foreign Patent Office communication that indicates the degree of relevance is attached.  $\boxtimes$ OTHER: The following additional information is provided. A U.S. Office Acton issued in co-pending Application No. 12/575,155, dated April 19, 2011 is submitted herein. All references cited in the Office Action have previously been submitted to USPTO. IV. STATEMENT UNDER 37 C.F.R. § 1.97(e) The undersigned hereby states that: Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than 30 days prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or

b. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or

QÀ

Application No.: 12/942,792 Docket No.: 0020-5147PUS12

Page 3 of 5

© c. No item of information contained in the IDS was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing the certification after making reasonable inquiry, no item of IDS was known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of the IDS.

d. Some of the items of information in the IDS were cited in a communication from a foreign patent office. Such items were first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office. As to the remaining items of information, to the knowledge of the person signing the certification after making reasonable inquiry, such remaining items were not known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of this statement.

# V. FEES

- a. This Information Disclosure Statement is being filed concurrently with the filing of a new patent application or Request for Continued Examination. No fee is required.
- b. This Information Disclosure Statement is being filed within three months of the filing date of an application. No fee is required.
- c. This Information Disclosure Statement is being filed before the mailing date of a first Action on the merits. No fee is required. If a first Office Action on the merits has issued, please consider this IDS under 37 C.F.R. § 1.97(c) and see the statement under 37 C.F.R. § 1.97(e) above. If no statement has been made, charge our deposit account for the required fee.

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 4 of 5

	d.	This Information Disclosure Statement is being filed before the mailing date of a
Final	Office	Action or before the mailing date of a Notice of Allowance (see 37 C.F.R.
§ 1.97	7(c)(1)).	
		No statement. The fee as required by 37 C.F.R. § 1.17(p) is provided.
		O.L.
		See the above statement. No fee is required.
	e.	This Information Disclosure Statement is being filed after the mailing date of a
Final	Office /	Action or <u>after</u> the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(d)),
see th	e statem	ent above. The fee as required by 37 C.F.R. § 1.17(p) is provided.
VI.	<u>PAYN</u>	MENT OF FEES
		The required fee is listed on the attached Fee Transmittal.
	図	No fee is required.

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 5 of 5

If the Examiner has any questions concerning this IDS, please contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the USPTO is requested to consider this IDS under the proper rule and charge the appropriate fee to Deposit Account No.

02-2448.

Dated: June 23, 2011

Respectfully submitted,

D. Richard Anderson

Registration No.: 40,439

BIRCH, STEWART, KOLASCH & BIRCH, LLP

8110 Gatehouse Road, Suite 100 East

P.O. Box 747

Falls Church, VA 22040-0747

703-205-8000

Attac	hment(	s)	
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$\mathbf{M}$	PTO/SB/08

☑ Document(s)

☐ Foreign Patent Office Communication

☐ Foreign Search Report

□ Fee

Other:

ON

Doc Code: TRAN.LET

Document Description: Transmittal Letter

PTO/SR/21 (07:09) Approved for use through 07/31/2012, OMB 0651-0631 U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE Under the Papenwals Reduction Act of 1995, no persons are required to respond to a collection of information unless it displays a velid OMB control number Application Number 12/942,792 Conf. No.: 2357 TRANSMITTAL Filing Date November 08, 2010 First Named inventor FORM Yoshinori SHINIZU Art Unit 2812 Examiner Name Not Yet Assigned (to be used for all correspondence after initial filing) Attorney Docket Number 0020-5147PUS12 Total Number of Pages in This Submission ENCLOSURES (Check all that apply) After Allowance Communication to TC Fee Transmittel Form Drawing(s) Appeal Communication to Board Licensing-related Papers Fee Attached of Appeals and Interferences Appeal Communication to TC Petition Amendment/Reply (Appeal Notice, Brief, Reply Brief) Petition to Convert to a After Final Proprietary information Provisional Application Power of Attorney, Revocation Afficiavits/declaration(s) Status Letter Change of Correspondence Address Other Enclosure(s) (please Identify Terminal Disclaimer Extension of Time Request below); Request for Conscied Official Filing Receipt; Request for Refund Express Abandonment Request Supplemental ADS to correct first inventor's name on U.S. Publication No. 2011/0053299 CD, Number of CD(s) Information Disclosure Statement Landscape Table on CD Certified Copy of Priority Remarks J Document(s) Reply to Missing Parts/ Incomplete Application Reply to Missing Parts under 37 CFR 1.52 or 1.53 SIGNATURE OF APPLICANT, ATTORNEY, OR AGENT Firm Name M, KOLÁSCH &BIRGH, LLP BIRGH, STEWAR Signature Printed name D. Richard Anderson Date Reg. No. April 29, 2011 40,439 CERTIFICATE OF TRANSMISSION/MAILING I hereby cartify that this correspondence is being facsimile transmitted to the USPTO or deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1460, Alexandria, VA 22313-1450 on the date shown below: Signature Typed or printed name

This collection of information is required by 37 CFR 1.5. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO) to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.11 end1.14. This collection is estimated to 2 hours to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you mustire to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commence, P.O. Box 1450, Alexandria, VA 22313-1450, DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS, SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

If you need assistance in completing the form, cell 1-800-PTO-9199 and select option 2.



Docket No.: 020-5147PUS12

(Patent)

# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

12/942,792

Confirmation No.: 2357

Filed:

November 09, 2010

Art Unit:

2812

For:

LIGHT EMITTING DEVICE AND DISPLAY

Examiner:

Not Yet Assigned

# REQUEST FOR CORRECTED OFFICIAL FILING RECEIPT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Attached is the Official Filing Receipt for the above-identified application.

# THE FOLLOWING CORRECTION IS RESPECTFULLY REQUESTED:

First inventor's last name should be changed from Shimieu to --Shimizu--.

Support for the correction(s) is readily apparent on the attached copy of the Declaration and Power of Attorney. It is respectfully requested that the USPTO provide a new Official Filing Receipt with the correction indicated above.

Application No.: 12/942,792 Docket No.: 0020-5147PUS12

Page 2 of 2

If necessary, the Director is hereby authorized in this, concurrent, and future replies to charge any fees required during the pendency of the above-identified application or credit any overpayment to Deposit Account No. 02-2448.

Dated: April 29, 2011

Respectfully submitted.

By D. Richard Anderson

Registration No.: 40,439

BIRCH, STEWART, KOLASCH & BIRCH, LLP

8110 Gatehouse Road, Suite 100 East

P.O. Box 747

Falis Church, VA 22040-0747

703-205-8000

Attachments: marked-up Filing Receipt

Copy of Declaration Supplemental ADS

Q[†]

# Supplemental Application Data Sheet

# Application Information

Application Type:: Regular Subject Matter:: Utility Suggested Group Art Unit:: 2812 CD-ROM or CD-R?:: None Sequence submission?:: None Computer Readable Form (CRF)?::

Title:: LIGHT EMITTING DEVICE AND DISPLAY

No

Attorney Docket Number:: 0020-5147PUS12

Request for Early Publication?:: No Request for Non-Publication?:: No Small Entity?:: No Petition included?:: No Secrecy Order in Parent Appl.?:: No

# Applicant Information

Applicant 1

Applicant Authority Type:: Inventor Primary Citizenship Country:: Japan

Status:: Full Capacity

Given Name:: Yoshinori Family name:: SHIMIZU City of Residence:: Anan-shi State or Province of Residence:: Tokushima

Country of Residence:: Japan

Street of Mailing address:: c/o Nichia Kagaku Kogyo Kabushiki Kaisha 491-

100, Oka, Kaminakacho

City of Mailing Address:: Anan-shi

State or Province of Mailing Address:: Tokushima

Page#1

Country of Mailing Address:: Japan
Postal or Zip Code of Mailing Address:: 774

Applicant 2

Applicant Authority Type:: Inventor
Primary Citizenship Country:: Japan

Status:: Full Capacity

Given Name:: Kensho
Family name:: SAKANO
City of Residence:: Anan-shi
State or Province of Residence:: Tokushima

Country of Residence:: Japan

Street of Mailing address:: c/o Nichia Kagaku Kogyo Kabushiki Kaisha 491-

100, Oka, Kaminakacho

City of Mailing Address:: Anan-shi
State or Province of Mailing Address:: Tokushima

Country of Mailing Address:: Japan
Postal or Zip Code of Mailing Address:: 774

Applicant 3

Applicant Authority Type:: Inventor
Primary Citizenship Country:: Japan

Status:: Full Capacity

Given Name:: Yasunobu
Family name:: NOGUCHI
City of Residence:: Anan-shi
State or Province of Residence:: Tokushima

Country of Residence:: Japan

Street of Mailing address:: c/o Nichia Kagaku Kogyo Kabashiki Kaisha 491-

100, Oka, Kaminakacho

City of Mailing Address:: Anan-shi

State or Province of Mailing Address:: Tokushima

Country of Mailing Address:: Japan
Postal or Zip Code of Mailing Address:: 774

Applicant 4

Applicant Authority Type:: Inventor
Primary Citizenship Country:: Japan

Status:: Full Capacity

Given Name:: Toshio

Family name:: MORIGUCHI

City of Residence:: Anan-shi

State or Province of Residence:: Tokushima

Country of Residence:: Japan

Street of Mailing address:: c/o Nichia Kagaku Kogyo Kabushiki Kaisha 491-

100, Oka, Kaminakacho

City of Mailing Address:: Anan-shi

State or Province of Mailing Address:: Tokushima

Country of Mailing Address:: Japan

Postal or Zip Code of Mailing Address:: 774

Correspondence Information

Correspondence Customer Number:: 02292

Representative Information

Representative Customer Number:: 02292

# Domestic Priority Information

Application::	Continuity Type::	Parent Application::	Parent Filing Date::
This Application	Division of	12/548,614	08/27/09
12/548,614	Division of	12/028,062	02/08/08
12/028,062	Division of	10/609,402	07/01/03
10/609,402	Division of	09/458,024	12/10/99
09/458,024	Division of	09/300,315	04/28/99
09/300,315	Division of	08/902,725	07/29/97

# Foreign Priority Information

Country::	Application number::	Filing Date::	***************************************
Japan	P 08-198585	07/29/96	Yes
Japan	P 08-244339	09/17/96	Yes
Japan	P 08-245381	09/18/96	Yes
Japan	P 08-359004	12/27/96	Yes
Japan	P 09-081010	03/31/97	Yes

# **Assignee Information**

Assignee 1

Assignee Name:: NICHIA CORPORATION

Street of Mailing address:: 491-100, Oka, Kaminaka-cho

City of Mailing Address:: Anan-shi

State or Province of Mailing Address:: Tokushima

Country of Mailing Address:: Japan

Postal or Zip Code of Mailing Address: 774-0044





## United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCIE United States Potent and Tradermork Office Address COMMINGLER FOR PATRICTS FO Box 1-50 Accorded, Vigoria 22313-1450 800 (1990) 289

			*********************	***************************************		
APPLICATION	FILING or	CRP ART			1	{
NUMBER	371(a) DATH	UNIT	FIL FEE RECD	ATTY.DOCKET.900	TOT CLAIMS	END CLAIMS
12/042 702	11/00/2010	2870	1000	0008_\$1 <i>8</i> 797530	E()	······································

**CONFIRMATION NO. 2357** 

2292 BIRCH STEWART KOLASCH & BIRCH PO BOX 747 FALLS CHURCH, VA 22040-0747

FILING RECEIPT

CC0000004488850

Date Mailed: 11/23/2010

Receipt is acknowledged of this non-provisional patent application. The application will be taken up for examination in due course. Applicant will be notified as to the results of the examination. Any correspondence concerning the application must include the following identification information: the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filling Receipt, please submit a written request for a Filling Receipt Correction. Please provide a copy of this Filling Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filling Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filling Receipt incorporating the requested corrections

Applican((s)

Shim Zu

Yoshinori Shimieu; Naka-gun, JAPAN; Kensho Sakano, Anan-shi, JAPAN; Yasunobu Noguchi, Naka-gun, JAPAN; Toshio Moriguchi, Anan-shi, JAPAN;

Power of Attorney: Name

Domestic Priority data as claimed by applicant

This application is a DIV of 12/548,614 08/27/2009 which is a DIV of 12/028,062 02/08/2008 PAT 7,682,848 which is a DIV of 10/609,402 07/01/2003 PAT 7,362,048 which is a DIV of 09/458,024 12/10/1999 PAT 6,614,179 which is a DIV of 09/300,315 04/28/1999 PAT 6,069,440 which is a DIV of 08/902,725 07/29/1997 PAT 5,998,925

Foreign Applications

JAPAN P 08-198585 07/29/1996 JAPAN P 08-244339 09/17/1996 JAPAN P 08-245381 09/18/1996 JAPAN P 08-359004 12/27/1996 JAPAN P 09-081010 03/31/1997

Request to Retrieve - This application either claims priority to one or more applications filed in an intellectual property Office that participates in the Priority Document Exchange (PDX) program or contains a proper Request to

Retrieve Electronic Priority Application(s) (PTO/SB/38 or its equivalent). Consequently, the USPTO will attempt to electronically retrieve these priority documents.

If Required, Foreign Filing License Granted: 11/19/2010

The country code and number of your priority application, to be used for filing abroad under the Paris Convention, is US 12/942.792

Projected Publication Date: 03/03/2011

Non-Publication Request: No Early Publication Request: No

Title

LIGHT EMITTING DEVICE AND DISPLAY

Preliminary Class

313

### PROTECTING YOUR INVENTION OUTSIDE THE UNITED STATES

Since the rights granted by a U.S. patent extend only throughout the territory of the United States and have no effect in a foreign country, an inventor who wishes patent protection in another country must apply for a patent in a specific country or in regional patent offices. Applicants may wish to consider the filling of an international application under the Patent Cooperation Treaty (PCT). An international (PCT) application generally has the same effect as a regular national patent application in each PCT-member country. The PCT process simplifies the filling of patent applications on the same invention in member countries, but does not result in a grant of "an international patent" and does not eliminate the need of applicants to file additional documents and fees in countries where patent protection is desired.

Almost every country has its own patent law, and a person desiring a patent in a particular country must make an application for patent in that country in accordance with its particular laws. Since the laws of many countries differ in various respects from the patent law of the United States, applicants are advised to seek guidance from specific foreign countries to ensure that patent rights are not lost prematurely.

Applicants also are advised that in the case of inventions made in the United States, the Director of the USPTO must issue a license before applicants can apply for a patent in a foreign country. The filing of a U.S. patent application serves as a request for a foreign filing license. The application's filing receipt contains further information and guidance as to the status of applicant's license for foreign filing.

Applicants may wish to consult the USPTO booklet, "General information Concerning Patents" (specifically, the section entitled "Treaties and Foreign Patents") for more information on timeframes and deadlines for filing foreign patent applications. The guide is available either by contacting the USPTO Contact Center at 800-786-9199, or it can be viewed on the USPTO website at http://www.uspto.gov/web/offices/pac/doc/general/index.html.

For information on preventing theft of your intellectual property (patents, trademarks and copyrights), you may wish to consult the U.S. Government website, http://www.stopfakes.gov. Part of a Department of Commerce initiative, this website includes self-help "toolkits" giving innovators guidance on how to protect intellectual property in specific countries such as China, Korea and Mexico. For questions regarding patent enforcement issues, applicants may call the U.S. Government hotline at 1-866-999-HALT (1-866-999-4158).

# LICENSE FOR FOREIGN FILING UNDER Title 35, United States Code, Section 184 Title 37, Code of Federal Regulations, 5.11 & 5.15

#### GRANTED

The applicant has been granted a license under 35 U.S.C. 184, if the phrase "IF REQUIRED, FOREIGN FILING LICENSE GRANTED" followed by a date appears on this form. Such licenses are issued in all applications where the conditions for issuance of a license have been met, regardless of whether or not a license may be required as set forth in 37 CFR 5.15. The scope and limitations of this license are set forth in 37 CFR 5.15(a) unless an earlier license has been issued under 37 CFR 5.15(b). The license is subject to revocation upon written notification. The date indicated is the effective date of the license, unless an earlier license of similar scope has been granted under 37 CFR 5.13 or 5.14.

This license is to be retained by the licensee and may be used at any time on or after the effective date thereof unless it is revoked. This license is automatically transferred to any related applications(s) filed under 37 GFR 1.53(d). This license is not retroactive.

The grant of a license does not in any way lessen the responsibility of a licensee for the security of the subject matter as imposed by any Government contract or the provisions of existing laws relating to espionage and the national security or the export of technical data. Licensees should apprise themselves of current regulations especially with respect to certain countries, of other agencies, particularly the Office of Defense Trade Controls, Department of State (with respect to Arms, Munitions and Implements of War (22 CFR 121-128)); the Bureau of Industry and Security, Department of Commerce (15 CFR parts 730-774); the Office of Foreign AssetsControl, Department of Treasury (31 CFR Parts 500+) and the Department of Energy.

### NOT GRANTED

No license under 35 U.S.C. 184 has been granted at this time, if the phrase "IF REQUIRED, FOREIGN FILING LICENSE GRANTED" DOES NOT appear on this form. Applicant may still petition for a license under 37 CFR 5.12, if a license is desired before the expiration of 6 months from the filing date of the application. If 6 months has lapsed from the filing date of this application and the licensee has not received any indication of a secrecy order under 35 U.S.C. 181, the licensee may foreign file the application pursuant to 37 CFR 5.15(b).

# BIRC ) STEWART, KOLASCH & B. H. LLP



PLEASE NOTE: YOU MUST COMPLETE YES FOLLOWING

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COMBINED. CLARATION AND POWER OF ATTORNA FOR PATENT AND DESIGN APPLICATIONS

ATTORNEY DOCKET NO.

20~4260P

As a below named inventor, I hereby declare that: my residence, post office address and citizenship are as stated next to my name; that I verily believe that I am the original, first and sole inventor (if only one inventor is named below) or an original, first and joint inventor (if plural inventors are named below) of the

subject matter which is claimed and for which a patent is sought on the invention entitled:* LIGHT EMITTING DEVICE AND DISPLAY Socret Mile Check Sex E the specification of which is attached hereto unless the following box is checked: Specification was filed on___ States Application Number___ PCT International Application Number_ and was amended on ____ (if applicable). I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, §1.56. I do not know and do not believe the same was ever known or used in the United States of America before my or our invention thereof, or patented or described in any printed publication in any country before my or our invention thereof, or more than one year prior to this application, that the same was not in public use or on sale in the United States of America more than one year prior to this application, that the invention has not been patented or made the subject of an inventor's certificate issued before the date of this application in any country foreign to the United States of America on an application filed by me or my legal representatives or assigns more than twelve months (six months for designs) prior to this application, and that no application for patent or inventor's certificate on this invention has been filed in any country foreign to the United States of America prior to this application by me or my legal representatives or assigns, except as I hereby claim foreign priority benefits under Title 35, United States Code, §119 (a)-(d) of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed: Prior Foreign Application(s) Priority Claimed Descri Princip 2 08-198585 Japan 07/29/1996 Sections M opercents (Number) (Country) (Month/Day/Year Filed) No P 08-244339 Japan 09/17/1996 (Number) (Month/Day/Year Filed) (Country) No P 08-245381 Japan 09/18/1996 Ŭ No (Country) (Number) (Month/Day/Year Filed) 08-359004 Japan 12/27/1996 (Number) (Country) (Month/Day/Year Filed) 09-081010 Japan 03/31/1997 (Country) (Month/Day/Year Filed) I hereby claim the benefit under Title 35, United States Code, § 119(e) of any United States provisional application(s) listed below. (Application Number) Filing Date) (Filing Date) All Foreign Applications, if any, for any Patent or Inventor's Certificate Filed More Than 12 Months (6 Months for Designs) Prior To The Filing Date of This Application: Date of Filing (Month/Day/Year) I hereby claim the benefit under Title 35, United States Code, §120 of any United States application(s) issted below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, \$112, I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, \$1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application: (Application Number) (Filing Date) (Status -- patented, pending, ahandoned)

20-42602

I hereby at the following attorneys to prosecute application and/or an international application based this application and to transact all busin jin the Patent and Trademark Office connected therewith and in connection with the resulting patent ased on instructions received from the entity who first sent the application papers to the attorneys identified below, unless the inventor(s) or assignee provides said attorneys with a written notice to the contrary:

RAYMOND C, STEWART (Reg. No. 21,066)
JOSEPH A. KOLASCH (Reg. No. 22,463)
JAMES M. SLATTERY (Reg. No. 28,380)
CHARLES GORENSTEIN (Reg. No. 29,271)
LEONARD R. SVENSSON (Reg. No. 30,330)
MARC S. WEINER (Reg. No. 32,181)
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TERRY L. CLARK (Reg. No. 32,644)
ANDREW D. MEIKLE (Reg. No. 32,868)
ANDREW F. REISH (Reg. No. 33,443)

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RESPICE Appropriate FLOOR

Send Correspondence to: BIRCH, STEWART, KOLASCH AND BIRCH, LLP

P.O. Box 747 Falix Church, Virginia 22648-9747 Telephone: (763) 265-8**998** Vacsimile: (763) 205-8056

I bereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Suscingues Sensingues on Superior 2008		GIVEN NAME	Family Nam	Æ	INVENTOR'S SIGNATURE	A & .	DATE		
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Full Name of Second Seventor, if any:		GIVEN NAME	FAMILY NAM		INVENTOR'S SIGNATURE	**********************	DATE"		
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Page 2 5/2									

Electronic Ac	knowledgement Receipt
EFS ID:	9990212
Application Number:	12942792
International Application Number:	
Confirmation Number:	2357
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY
First Named Inventor/Applicant Name:	Yoshinori Shimizu
Customer Number:	02292
Filer:	David Richard Anderson/Patti Young
Filer Authorized By:	David Richard Anderson
Attorney Docket Number:	0020-5147PUS12
Receipt Date:	29-APR-2011
Filing Date:	09-NOV-2010
Time Stamp:	16:45:22
Application Type:	Utility under 35 USC 111(a)

# **Payment information:**

Submitted with Payment	no
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# File Listing:

Document Number	Document Description	File Name	File Size(Bytes)/ Message Digest	Multi Part /.zip	Pages (if appl.)
1		20110429 Supplemental ADS.	6200798	ves	12
ı		pdf	08eedd0bed5f3db67b4bf0e9f36820a99da 8349d	1	

	Multipart Description/PDF files in .zip description							
	Document Description	Start	End					
	Miscellaneous Incoming Letter	1	1					
	Request for Corrected Filing Receipt	2	3					
	Application Data Sheet	4	12					
Warnings:		1	1					

Information:

Total Files Size (in bytes): 6200798

This Acknowledgement Receipt evidences receipt on the noted date by the USPTO of the indicated documents, characterized by the applicant, and including page counts, where applicable. It serves as evidence of receipt similar to a Post Card, as described in MPEP 503.

### New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

### National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

#### New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.

U.S. Patent and Trademark Office, U.S. DEPARTMENT OF COMMERCE

Under the Paperwork reduction Act of 1995, no persona are required to respond to a collection of information unless it contains a valid OMB control number.

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	( 10 ) 0 ~ 0 ~ 0 ~ 0 ~ 0	a a waxaa aa	x mxmx	e o menero e x menero	Application Number	12/942,792	
				CLOSURE	Filing Date	11-09-10	
	STATE	MENT	BY AF	PLICANT	First Named Inventor	Yoshinori Shimizu	
					Art Unit	2812	
	(Usi	as many si	heets as ne	oessary)	Examiner Name	Not Yet Assigned	
·	Sheet	·····	of	2	Attorney Docket Number	0020-5147PUS12	
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	*********		U.S. PATE	NT DOCUMENTS		
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	No	Number - Kind Code ² (iCknown)	MM-DD-YYYY	Applicant of Cited Decument	Pages, columns, Lines, Where Relevant Passages or Relevant Figures Appear	
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	No. 1	Country ³ Number ⁴ Kind Code (if)mown) ⁵ Code	MM-DD-YYYY	Applicant of Cited Document	Relevant Passages or Relevant Figures Appear	Showward
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Signature		Considered	
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This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S. C. 122 and 37 CFR 1.14. This collection is estimated in take 2 hours to complete, including gathering, preparing, and submitting the completed application from the USPTO. Time with vary depending upon the individual case. Any comments on amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Creef Information Officer, U.S. Petent and Trademark Office, P.G. Sox 1450 Alexandria, VA 22313-1460, DO NOT SEND THES OR COMPLETED FORMS TO THIS ADDRESS.
SEND TO: Commissioner for Patents, P.D. Box 1459, Alexandria, VA 22313-1450.

If you need assistance in completing the form, call 1-800-PTO-9199 (1-800-786.9199) and select option 2.

(JA--

^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPIEP 609, Draw line through citation if not in conformance and not Considered, Include copy of this form with next communication to applicant. I. Applicant's unique citation design number (optional), 2 See Kinds Codes of USPTO patent Documents at wow.uspin gov or MPEP 901.04, 3. Enter Office that issued the document, by the two-letter code (WIPC) Standard ST.13), 4. For Japanese patent documents, the indication of the year of the reign of the Emperic must proceed the senial number of the patent document. 5. Kind of document by the appropriate symbols as indicated on the document under WIPC Standard ST. 15 if possible. 6. Applicant is to place a check mark here if English language. Translation is affectived.

PTO/SB/08b (07-09)

Approved for use through 07/31/2012, OM8 5651-5031

U.S. Patent and Trademark Office, U.S. CEPARTMENT OF COMMERCE

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	INIENE	MATION D	isci	ASHDE	Application Number	12/942,792		
		EMENT BY			Filing Date	11-09-10		
	~ 1 m 1 1		<i></i> 65 S	~1~3~141	First Named Inventor	Yoshinori Shimizu		
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	***************************************		*******		Examiner Name	Not Yet Assigned		
	Sheet	2	of	2	Attorney Docket Number	0020-5147PUS12		

	***************************************	NON PATENT LITERATURE DOCUMENTS	**************
Exeminer initial *	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	72
	2	U.S. Office Action issued in Application No. 12/559,042 on March 16, 2011.	
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If you need assissiance in completing the form, call 1-800-PTO-9199 and select option 2.



^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 809. Draw line through citation if not in conformance and not nonsidered, include copy of this form with next communication to applicant.

^{1.} Applicants unique citation designation number. (optional) 2. Applicant is to place a check mark here if English lenguage Translation is attached. This collection of information is required by 37 CFR 1.57 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO for process) an application. Confidentiality is governed by 35 U.S.C. 132 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the complete upplication from the USPTO. Time will very depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions bit reducing bis burden, should be sent to the Cheft Information Officer, U.S. Patent and Trademerk Office, P.O. Box 1450, Alexandria, VA 22313-1450, DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS.

SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Electronic Acknowledgement Receipt				
EFS ID:	9863382			
Application Number:	12942792			
International Application Number:				
Confirmation Number:	2357			
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY			
First Named Inventor/Applicant Name:	Yoshinori Shimieu			
Customer Number:	02292			
Filer:	David Richard Anderson/Patti Young			
Filer Authorized By:	David Richard Anderson			
Attorney Docket Number:	0020-5147PUS12			
Receipt Date:	12-APR-2011			
Filing Date:	09-NOV-2010			
Time Stamp:	16:04:19			
Application Type:	Utility under 35 USC 111(a)			

Payment information:

File Listing:

Document Number	Document Description	File Name	File Size(Bytes)/ Message Digest	Multi Part /.zip	Pages (if appl.)
1		20110412IDS.pdf	3234344	yes	7
			66ac1a60bf5f42bb48e0620179fbfe6363ea 4aac		

	Multipart Description/PDF files in .zip description						
	Document Description Start End						
	Transmitta	1		5			
	Information Disclosure State	6	7				
Warnings:							
Information:							
2	NPL Documents	USOA12559042.pdf	888635	no	21		
-	THE BOCAMENTS	030/(12333012.pu)	a537372abdad9f254504d7ab09f2279e555 d82c3	110			
Warnings:							
Information:							
		Total Files Size (in bytes)	41	22979			

This Acknowledgement Receipt evidences receipt on the noted date by the USPTO of the indicated documents, characterized by the applicant, and including page counts, where applicable. It serves as evidence of receipt similar to a Post Card, as described in MPEP 503.

New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.

Docket No.: 0020-5147PUS12

(Patent)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.: 12/942,792

Confirmation No.: 2357

Filed:

Nevember 09, 2010

Art Unit:

2812

LIGHT EMITTING DEVICE AND DISPLAY For:

Examiner:

Not Yet Assigned

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Applicant(s) hereby submit(s) an Information Disclosure Statement for consideration by the Examiner.

Ĭ. LIST OF PATENTS, PUBLICATIONS OR OTHER INFORMATION

The patents, publications, or other information submitted for consideration by the Office are listed on the attached PTO/SB/08.

II. COPIES

V Copies of foreign patent documents, non-patent literature and other information.

b. REFERENCES PREVIOUSLY CITED OR SUBMITTED: Copies of any information not provided can be found in one or more of the following applications which has been relied upon for an earlier filing date under 35 U.S.C. § 120:

U.S. Application No. and U.S. Filing Date

12/548,614 filed August 27, 2009

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 2 of 5

	111	CONCISE EXPI	ANATION OF	THE RELEVANCE/OTHER	INFORMATION
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a. NON-ENGLISH LANGUAGE DOCUMENTS: A concise explanation of the relevance of all non-English language patents, publications, or other information listed is as follows:

☐ b. ENGLISH LANGUAGE SEARCH REPORT OR FOREIGN PATENT OFFICE COMMUNICATION: An English language version of the search report or Foreign Patent Office communication that indicates the degree of relevance is attached.

C. OTHER: The following additional information is provided.
U.S. Patent No. 4,992,704 cited in the present IDS was cited in a U.S. Office Action issued in co-pending Application No. 12/559,042 on March 16, 2011 which is also submitted herein.

IV. STATEMENT UNDER 37 C.F.R. § 1.97(e)

The undersigned hereby states that:

a. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than 30 days prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or

b. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 3 of 5

☑ c. No item of information contained in the IDS was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing the certification after making reasonable inquiry, no item of IDS was known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of the IDS.

d. Some of the items of information in the IDS were cited in a communication from a foreign patent office. Such items were first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office. As to the remaining items of information, to the knowledge of the person signing the certification after making reasonable inquiry, such remaining items were not known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of this statement.

V. FEES

- a. This Information Disclosure Statement is being filed concurrently with the filing of a new patent application or Request for Continued Examination. No fee is required.
- b. This Information Disclosure Statement is being filed within three months of the filing date of an application. No fee is required.
- ☑ c. This Information Disclosure Statement is being filed before the mailing date of a first Action on the merits. No fee is required. If a first Office Action on the merits has issued, please consider this IDS under 37 C.F.R. § 1.97(e) and see the statement under 37 C.F.R. § 1.97(e) above. If no statement has been made, charge our deposit account for the required fee.

A

□ d. This Information Disclosure Statement is being filed before the mailing date of a Final Office Action or before the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(c)(1)).
 □ No statement. The fee as required by 37 C.F.R. § 1.17(p) is provided.
 or
 □ See the above statement. No fee is required.
 □ e. This Information Disclosure Statement is being filed after the mailing date of a Final Office Action or after the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(d)), see the statement above. The fee as required by 37 C.F.R. § 1.17(p) is provided.

VI. PAYMENT OF FEES

Application No.: 12/942,792

- The required fee is listed on the attached Fee Transmittal.
- ☑ No fee is required.

Docket No.: 0020-5147PUS12

Page 4 of 5

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 5 of 5

If the Examiner has any questions concerning this IDS, please contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the USPTO is requested to consider this IDS under the proper rule and charge the appropriate fee to Deposit Account No.

02-2448.

Dated: April 12, 2011

Respectfully submitted,

D. Richard Anderson

Registration No.: 40,439

BIRCH, STEWART, KOLASCH & BIRCH, LLP

8110 Gatehouse Road, Suite 100 East

P.O. Box 747

Falls Church, VA 22040-0747

703-205-8000

Attachment(s):	
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\square	PTO/SB/08

Document(s)

☐ Foreign Patent Office Communication

☐ Foreign Search Report

□ Fee

□ Other:

(1844m



12/942,792

United States Patent and Trademark Office

11/09/2010

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APPLICATION NUMBER FILING OR 371(C) DATE

FIRST NAMED APPLICANT
Yoshinori Shimieu

ATTY. DOCKET NO./TITLE 0020-5147PUS12

CONFIRMATION NO. 2357

PUBLICATION NOTICE

2292 BIRCH STEWART KOLASCH & BIRCH PO BOX 747 FALLS CHURCH, VA 22040-0747

Title:LIGHT EMITTING DEVICE AND DISPLAY

Publication No.US-2011-0053299-A1 Publication Date:03/03/2011

NOTICE OF PUBLICATION OF APPLICATION

The above-identified application will be electronically published as a patent application publication pursuant to 37 CFR 1.211, et seq. The patent application publication number and publication date are set forth above.

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The publication process established by the Office does not provide for mailing a copy of the publication to applicant. A copy of the publication may be obtained from the Office upon payment of the appropriate fee set forth in 37 CFR 1.19(a)(1). Orders for copies of patent application publications are handled by the USPTO's Office of Public Records. The Office of Public Records can be reached by telephone at (703) 308-9726 or (800) 972-6382, by facsimile at (703) 305-8759, by mail addressed to the United States Patent and Trademark Office, Office of Public Records, Alexandria, VA 22313-1450 or via the Internet.

In addition, information on the status of the application, including the mailing date of Office actions and the dates of receipt of correspondence filed in the Office, may also be accessed via the Internet through the Patent Electronic Business Center at www.uspto.gov using the public side of the Patent Application Information and Retrieval (PAIR) system. The direct link to access this status information is currently http://pair.uspto.gov/. Prior to publication, such status information is confidential and may only be obtained by applicant using the private side of PAIR.

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Office of Data Managment, Application Assistance Unit (571) 272-4000, or (571) 272-4200, or 1-888-786-0101

U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

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Substitute	for form 1449A/PTC)		Complete if Known		
				Application Number	12/942,792	
	RMATION I			Filing Date	11-09-10	
STATEMENT BY APPLICANT				First Named Inventor	Yoshinori Shimizu	
				Art Unit	2812	
(Use as many sheets as necessary)			cessary)	Examiner Name	Not Yet Assigned	
Sheet	1	of	2	Attorney Docket Number	0020-5147PUS12	

U.S. PATENT DOCUMENTS						
Examiner	Cite	Document Number	Publication Date	Name of Patentee or	Pages, columns, Lines, Where Relevant Passages or Relevant	
initial *	No.	Number - Kind Code ² (if known)	MM-DD-YYYY	Applicant of Cited Document	Relevant Passages or Relevant Figures Appear	
	1	US-2009/0315014-A1	12-24-2009	SHIMIZU et al.	······································	
	2	US-5,045,867-A	09-03-1991	FUSE	***************************************	
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	FOREIGN PATENT DOCUMENTS							
Examiner	Cite	Foreign Patent Document			Pages, columns, Lines, Where			
Initial *	No. 1	Country ³ Number ⁴ Kind Code (if known) ⁵	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited	Relevant Passages or Relevant			
		Country ³ Number ⁴ Kind Code (if known) ⁵		Document	Figures Appear	Т		
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Examiner	Date	
Signature	Considered	

This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, P.O. Box 1450 Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS.

SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

If you need assisstance in completing the form, call 1-800-PTQ-9199 (1-800-786.9199) and select option 2.



^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not Considered. Include copy of this form with next communication to applicant. 1. Applicant's unique citation design number (optional). 2 See Kinds Codes of USPTO patent Documents. at www.uspto.gov or MPEP 901.04. 3. Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). 4. For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. 5. Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. 6. Applicant is to place a check mark here if English language

PTO/SB/08b (07-09)

Approved for use through 07/31/2012. OMB 0651-0031 U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

Under the Paperwork reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number.

Substitute for	form 1449B/PTO			Complete if Known		
INFOE	DRAKTION D	ICCI	OSLIDE	Application Number	12/942,792	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Filing Date	11-09-10	
STATEMENT BY APPLICANT		LICANI	First Named Inventor	Yoshinori Shimizu		
(Use as many sheets as necessary)			ssarv)	Art Unit	2812	
(0.	oo ao many onooto a	0110000		Examiner Name	Not Yet Assigned	
Sheet	2	of	2	Attorney Docket Number	0020-5147PUS12	

NON PATENT LITERATURE DOCUMENTS					
Examiner initial *	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²		
	3	Office Action dated July 7, 2010 for US Application No. 12/548,614.	- Secure		
	4	Office Action dated June 16, 2010 for US Application No. 12/548,621.	<i></i>		
	5	Office Action dated November 10, 2010 for US Application No. 12/575,162.	******		
	6	Office Action dated November 15, 2010 for US Application No. 12/548,614.	***************************************		
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Examiner		Date	
Signature		Considered	

^{1.} Applicants unique citation designation number. (optional) 2. Applicant is to place a check mark here if English language Translation is attached.
This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Cheif Information Officer, U.S. Patent and Trademark Office, P.O. Box 1450 Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS.

SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.





^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Docket No.: 0020-5147PUS12

(Patent)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

12/942,792

Confirmation No.: 2357

Filed:

November 09, 2010

Art Unit:

2812

For: LIGHT EMITTING DEVICE AND DISPLAY

Examiner:

Not Yet Assigned

LETTER REGARDING COPENDING APPLICATIONS

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Under the provisions of MPEP § 2001.06(b), the Examiner is hereby advised of the following copending U.S. Applications:

Appl. No.	Filing Date	Group
12/575,155	October 7, 2009	2811
12/947,470	November 16, 2010	2812
12/831,586	July 7, 2010	2811
12/689,681	January 19, 2010	2812
12/559,042	September 14, 2009	2814
12/548,618	August 27, 2009	2822
12/548,614	August 27, 2009	2812
12/548,620	August 27, 2009	2811
12/575,162	October 7, 2009	2892
12/548,621	August 27, 2009	2812



Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 2 of 2

The subject matter contained in the above-listed copending U.S. applications may be deemed to relate to the present application, and thus may be material to the prosecution of this instant application.

The above-listed co-pending applications are not to be construed as prior art. By bringing the above-listed applications to the attention of the Examiner, Applicants do NOT waive any confidentiality concerning the above-listed co-pending applications or this application. See MPEP § 101.

If necessary, the Director is hereby authorized in this, concurrent, and future replies to charge any fees required during the pendency of the above-identified application or credit any overpayment to Deposit Account No. 02-2448.

Dated:

DEC 23 2010

D. Richard Anderson
Registration No.: 40439
BIRCH, STEWART, KOLASCH & BIRCH, LLP
8110 Gatehouse Road, Suite 100 East
P.O. Box 747

Falls Church, VA 22040-0747 703-205-8000

Respectfull submitted,

(0)

Docket No.: 0020-5147PUS12

(Patent)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

12/942,792

Confirmation No.: 2357

Filed:

November 09, 2010

Art Unit:

2812

For: LIGHT EMITTING DEVICE AND DISPLAY

Examiner:

Not Yet Assigned

LETTER REGARDING COPENDING APPLICATIONS

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

This letter submits potential relevant information advising the Examiner of the following co-pending U.S. Applications which claim the benefit of U.S. Patent 6,600,175 (by Baretz et al., issued on 07/29/2003) which was submitted to USPTO in an IDS on November 9, 2010.

Appl. No.	Filing Date	<u>Group</u>	
90/010,940 (Reexamination of USP 6,600,175)	May 6, 2010	3992	
11/264,124	November 1, 2005	2814	
12/131,118	June 1, 2008	2814	
12/131,119	June 1, 2008	2879	

The subject matter contained in the above-listed copending U.S. applications may be deemed to relate to the present application, and thus may be material to the prosecution of this instant application.

The above-listed co-pending applications are not to be construed as prior art. By bringing the above-listed applications to the attention of the Examiner, Applicants do NOT waive any

cot

Application No.: 12/942,792 Docket No.: 0020-5147PUS12

Page 2 of 2

confidentiality concerning the above-listed co-pending applications or this application. See MPEP § 101.

If necessary, the Director is hereby authorized in this, concurrent, and future replies to charge any fees required during the pendency of the above-identified application or credit any

Dated:

DEC 23 2010

overpayment to Deposit Account No. 02-2448.

By

Respectfully submitted,

D. Richard Anderson Registration No.: 40439

BIRCH, STEWART, KOLASCH & BIRCH, LLP

8110 Gatehouse Road, Suite 100 East

P.O. Box 747

Falls Church, VA 22040-0747

703-205-8000

Electronic Acknowledgement Receipt				
EFS ID:	9109314			
Application Number:	12942792			
International Application Number:				
Confirmation Number:	2357			
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY			
First Named Inventor/Applicant Name:	Yoshinori Shimieu			
Customer Number:	02292			
Filer:	David Richard Anderson			
Filer Authorized By:				
Attorney Docket Number:	0020-5147PUS12			
Receipt Date:	23-DEC-2010			
Filing Date:	09-NOV-2010			
Time Stamp:	16:44:57			
Application Type:	Utility under 35 USC 111(a)			

Payment information:

File Listing:

Document Number	Document Description	File Name	File Size(Bytes)/ Message Digest	Multi Part /.zip	Pages (if appl.)
1		00205147PUS12IDS.PDF	363257	ves	7
'		002031471 0312103.1 01	cee347a13a5236c4bd0608f193a216854f03 6b58	, l	,

	Multipart Description/PDF files in .zip description					
	Document Description		Start	Er	End	
	Transmittal Letter		1	5		
	Information Disclosure State	ment (IDS) Filed (SB/08)	6	7		
Warnings:						
Information:						
2	Miscellaneous Incoming Letter	00205147PUS12LTR.PDF	60237	no	2	
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3	Miccellaneous Incoming Letter	00205147PUS12LTR2.PDF	58647	no	2	
	3 Miscellaneous Incoming Letter		8a1bed46bd5171606fa71a59d8b7f5facbfe 0fe0	no		
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4	NPL Documents	OfficeActionUS12548614dated 2010July7.pdf	941491	no	19	
4	NI L Documents		2af61e61edb21d155d31c7cbde8b095d838 b11c2	no		
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5	NPL Documents	OfficeActionUS12548621.pdf	907741	no	16	
	NI E BOCGINENCS		56bca57646256469bb927db584bcf273aa1 e862a	110		
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Information:						
6	NPL Documents	OfficeActionUS12575162.pdf	1362575	no	21	
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Warnings:						
Information:						
		Total Files Size (in bytes)	432	27954		

This Acknowledgement Receipt evidences receipt on the noted date by the USPTO of the indicated documents, characterized by the applicant, and including page counts, where applicable. It serves as evidence of receipt similar to a Post Card, as described in MPEP 503.

New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.

Docket No.: 0020-5147PUS12

(Patent)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

12/942,792

Confirmation No.: 2357

Filed:

November 09, 2010

Art Unit:

2812

For:

LIGHT EMITTING DEVICE AND DISPLAY

Examiner:

Not Yet Assigned

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Applicant(s) hereby submit(s) an Information Disclosure Statement for consideration by the Examiner.

I. <u>LIST OF PATENTS, PUBLICATIONS OR OTHER INFORMATION</u>

The patents, publications, or other information submitted for consideration by the Office are listed on the attached PTO/SB/08.

II. COPIES

- a. Copies of foreign patent documents, non-patent literature and other information.
- □ b. REFERENCES PREVIOUSLY CITED OR SUBMITTED: Copies of any information not provided can be found in one or more of the following applications which has been relied upon for an earlier filing date under 35 U.S.C. § 120:



Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 2 of 5

III. CONCISE EXPLANATION OF THE RELEVANCE/OTHER INFORMATION NON-ENGLISH LANGUAGE DOCUMENTS: A concise explanation of the a. relevance of all non-English language patents, publications, or other information listed is as follows: b. ENGLISH LANGUAGE SEARCH REPORT OR FOREIGN PATENT OFFICE COMMUNICATION: An English language version of the search report or Foreign Patent Office communication that indicates the degree of relevance is attached. $\overline{\mathbf{Q}}$ OTHER: The following additional information is provided. C. Copies of the Office Actions dated July 7, 2010 and November 15, 2010 for US Application No. 12/548,614, a copy of the Office Action dated June 16, 2010 for US Application No. 12/548,621 and a copy of the Office Action dated November 10, 2010 for US Application No. 12/575,162 are attached. All of the references cited in the attached US Office Actions except US-5,045,867-A and US-2009/0315014-A1 were previously cited in the IDS filed November 19, 2010. STATEMENT UNDER 37 C.F.R. § 1.97(e) IV. The undersigned hereby states that: Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than 30 days prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or П Each item of information contained in the IDS was first cited in any b. communication from a foreign patent office in a counterpart foreign application not more than

three months prior to the filing of this IDS. This statement does not relate to English language

Application No.: 12/942,792 Docket No.: 0020-5147PUS12
Page 3 of 5

counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or

- □ c. No item of information contained in the IDS was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing the certification after making reasonable inquiry, no item of IDS was known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of the IDS.
- d. Some of the items of information in the IDS were cited in a communication from a foreign patent office. Such items were first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office. As to the remaining items of information, to the knowledge of the person signing the certification after making reasonable inquiry, such remaining items were not known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of this statement.

V. FEES

- a. This Information Disclosure Statement is being filed concurrently with the filing of a new patent application or Request for Continued Examination. No fee is required.
- ☑ b. This Information Disclosure Statement is being filed within three months of the filing date of an application. No fee is required.

c. This Information Disclosure Statement is being filed before the mailing date of a first Action on the merits. No fee is required. If a first Office Action on the merits has issued, please consider this IDS under 37 C.F.R. § 1.97(c) and see the statement under 37 C.F.R. § 1.97(e) above. If no statement has been made, charge our deposit account for the required fee. d. This Information Disclosure Statement is being filed before the mailing date of a Final Office Action or before the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(c)(1)). No statement. The fee as required by 37 C.F.R. § 1.17(p) is provided. or See the above statement. No fee is required. e. This Information Disclosure Statement is being filed after the mailing date of a Final Office Action or <u>after</u> the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(d)), see the statement above. The fee as required by 37 C.F.R. § 1.17(p) is provided. VI. PAYMENT OF FEES The required fee is listed on the attached Fee Transmittal. \square No fee is required.

Application No.: 12/942,792

Docket No.: 0020-5147PUS12

Page 4 of 5

Application No.: 12/942,792 Docket No.: 0020-5147PUS12

Page 5 of 5

If the Examiner has any questions concerning this IDS, please contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the USPTO is requested to consider this IDS under the proper rule and charge the appropriate fee to Deposit Account No.

Dated:

02-2448.

DEC 23 2010

Respectfully submitted,

D. Richard Anderson

Registration No.: 40439

BIRCH, STEWART, KOLASCH & BIRCH, LLP

8110 Gatehouse Road, Suite 100 East

P.O. Box 747

Falls Church, VA 22040-0747

703-205-8000

Attachment(s):

\checkmark	P	ΤО	/SB	/08

Document(s)

☐ Foreign Patent Office Communication

☐ Foreign Search Report

☐ Fee

☑ Other: Four (4) US Office Actions



JAPAN PATENT OFFICE

別紙添付の書類に記載されている事項は下記の出願書類に記載されている事項と同一であることを証明する。

This is to certify that the annexed is a true copy of the following application as filed with this Office.

出願年月日 Date of Application:

1996年 7月29日

出 Application Number:

8年特許願第198585号

パリ条約による外国への出願 に用いる優先権の主張の基礎 となる出願の国コードと出願 番号

The country code and number of your priority application, to be used for filing abroad under the Paris Convention, is JP1996-198585

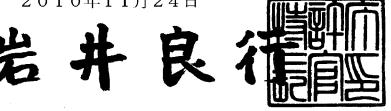
願 出 人

Applicant(s):

口亜化学工業株式会社

2010年11月24日

特許庁長官 Commissioner, Japan Patent Office



【書類名】特許願

【整理番号】P96ST13

【提出日】平成8年7月29日

【あて先】特許庁長官 荒川 寿光 殿

【国際特許分類】

H01L 33/00

【発明の名称】発光ダイオード及びそれを用いた表示装置

【請求項の数】 4

【発明者】

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【特許出願人】

【識別番号】000226057

【郵便番号】774

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【代表者】小川 英治

【電話番号】0884-22-2311

【手数料の表示】

【予納台帳番号】010526

【納付金額】21,000

【提出物件の目録】

【物件名】明細書 1

【物件名】図面 1

【物件名】要約書 1 【プルーフの要否】要

【書類名】 明細書

【発明の名称】 発光ダイオード及びそれを用いた表示装置

【特許請求の範囲】

【請求項1】

発光層が窒化ガリウム系化合物半導体であるLEDチップと、該LEDチップ からの発光の少なくとも一部を吸収し波長変換して発光するフォトルミネセンス 蛍光体と、を有する発光ダイオードであって、

前記LEDチップの発光スペクトルのピークが400nmから530nmの発光波長を有すると共に、前記フォトルミネセンス蛍光体がRE $_3$ (A1, Ga) $_5$ O $_{12}$: Ceであることを特徴とする発光ダイオード。

但し、REは、Y, Gd, Smから選択される少なくとも一種である。

【請求項2】

マウント・リードのカップ内に配置させたLEDチップと、該LEDチップと 導電性ワイヤーを用いて電気的に接続させたインナー・リードと、前記カップ内 に充填させたコーティング部材と、該コーティング部材、LEDチップ、導電性 ワイヤー及びマウント・リードとインナー・リードの少なくとも一部を被覆する モールド部材と、を有する発光ダイオードであって、

前記LEDチップが窒化ガリウム系化合物半導体であり、且つ前記コーティング部材がRE $_3$ (A $_1$,G $_a$) $_5$ O $_1$ 2:C $_2$ 2:C $_3$ 7 大化樹脂であることを特徴とする発光ダイオード。

但し、REは、Y、Gd、Smから選択される少なくとも一種である。

【請求項3】

前記フォトルミネセンス蛍光体の組成が次の一般式で示されることを特徴とする請求項1又は請求項2記載の発光ダイオード。

 $(Y_{1-p-q-r}Gd_pCe_qSm_r)_3 (Al_{1-s}Ga_s)_5O_{12}$ 但し、 $0 \le p \le 0.8$

0. $003 \le q \le 0.2$

0. $0003 \le r \le 0.08$

 $0 \le s \le 1$

【請求項4】

請求項2記載の発光ダイオードをマトリックス状に配置したLED表示器と、 該LED表示器と電気的に接続させた駆動回路と、を有するLED表示装置。

【発明の詳細な説明】

[0001]

【産業上の利用分野】

本願発明は、LEDディスプレイ、バックライト光源、信号機、照光式スイッチ及び各種インジケータなどに利用される発光ダイオードに係わり、特に発光素子であるLEDチップからの発光を変換して発光させるフォトルミネセンス蛍光体を有し使用環境によらず高輝度、高効率な発光ダイオード及びそれを用いた表示装置に関する。

[0002]

【従来技術】

発光ダイオード(以下、LEDともいう)は、小型で効率が良く鮮やかな色の発光をする。また、半導体素子であるため球切れなどの心配がない。初期駆動特性が優れ、振動やON/OFF点灯の繰り返しに強いという特徴を有する。そのため各種インジケータや種々の光源として利用されている。最近、超高輝度高効率な発光ダイオードとしてRGB(赤、緑、青色)などの発光ダイオードがそれぞれ開発された。これに伴いRGBの三原色を利用したLEDディスプレイが省電力、長寿命、軽量などの特長を生かして飛躍的に発展を遂げつつある。

[0003]

発光ダイオードは使用される発光層の半導体材料、形成条件などによって紫外から赤外まで種々の発光波長を放出させることが可能である。また、優れた単色性ピーク波長を有する。

[0004]

しかしながら、発光ダイオードは優れた単色性ピーク波長を有するが故に白色系発光光源などとさせるためには、RGBなどが発光可能な各LEDチップをそれぞれ近接して発光させ拡散混色させる必要がある。このような発光ダイオードは、種々の色を自由に発光させる発光装置としては有効であるが、白色系などの

色のみを発光させる場合においても赤色系、緑色系及び青色系の発光ダイオード、或いは青緑色系及び黄色系の発光ダイオードをそれぞれ使用せざるを得ない。 LEDチップは、半導体であり色調や輝度のバラツキもまだ相当ある。また、半 導体発光素子であるLEDチップがそれぞれ異なる材料を用いて形成されている 場合、各LEDチップの駆動電力などが異なり個々に電源を確保する必要がある 。そのため、各半導体ごとに電流などを調節して白色系を発光させなければなら ない。同様に、半導体発光素子であるため個々の温度特性の差や経時変化が異な り、色調が種々変化してしまう。さらに、LEDチップからの発光を均一に混色 させなければ色むらを生ずる場合がある。

[0005]

そこで、本出願人は先にLEDチップの発光色を蛍光体で色変換させた発光ダイオードとして特開平5-152609号公報、特開平7-99345号公報などに記載された発光ダイオードを開発した。これらの発光ダイオードによって、1種類のLEDチップを用いて白色系など他の発光色を発光させることができる

[0006]

具体的には、発光層のエネルギーバンドギャップが大きいLEDチップをリードフレームの先端に設けられたカップ上などに配置する。LEDチップは、LEDチップが設けられたメタルステムやメタルポストとそれぞれ電気的に接続させる。そして、LEDチップを被覆する樹脂モールド部材中などにLEDチップからの光を吸収し波長変換する蛍光体を含有させて形成させてある。

[0007]

LEDチップからの発光を波長変換した発光ダイオードとして、青色系の発光 ダイオードの発光と、その発光を吸収し黄色系を発光する蛍光体からの発光との 混色により白色系が発光可能な発光ダイオードなどとすることができる。これら の発光ダイオードは、白色系を発光する発光ダイオードとして利用した場合にお いても十分な輝度を発光する発光ダイオードとすることができる。

[8000]

【発明が解決する課題】

発光ダイオードによって励起される蛍光体は、蛍光染料、蛍光顔料さらには有機、無機化合物などから様々なものが挙げられる。また、蛍光体は、発光素子からの発光波長を波長の短いものから長い波長へと変換する、或いは発光素子からの発光波長を波長の長いものから短い波長へと変換するものとがある。

[0009]

しかしながら、波長の長いものから短い波長へと変換する場合、変換効率が極 めて悪く実用に向かない。また、LEDチップ周辺に近接して配置された蛍光体 は、太陽光よりも約30倍から40倍にも及ぶ強照射強度の光線にさらされる。 特に、発光素子であるLEDチップを高エネルギーバンドギャップを有する半導 体を用い蛍光体の変換効率向上や蛍光体の使用量を減らした場合においては、L EDチップから発光した光が可視光域にあるといっても光エネルギーが必然的に 高くなる。この場合、発光強度を更に高め長期に渡って使用すると、蛍光体自体 が劣化しやすい。蛍光体が劣化すると色調がずれる、或いは蛍光体が黒ずみ光の 外部取り出し効率が低下する場合がある。同様にLEDチップの近傍に設けられ た蛍光体は、LEDチップの昇温や外部環境からの加熱など高温にもさらされる 。さらに、発光ダイオードは、一般的に樹脂モールドに被覆されてはいるものの 外部環境からの水分の進入などを完全に防ぐことや製造時に付着した水分を完全 に除去することはできない。蛍光体によっては、このような水分が発光素子から の高エネルギー光や熱によって蛍光体物質の劣化を促進する場合もある。また、 イオン性の有機染料に至ってはチップ近傍では直流電界により電気泳動を起こし 、色調が変化する可能性がある。したがって、本願発明は上記課題を解決し、よ り高輝度、長時間の使用環境下においても発光光率の低下や色ずれの極めて少な い発光ダイオードを提供することを目的とする。

[0010]

【課題を解決するための手段】

本願発明は、発光層が窒化ガリウム系化合物半導体であるLEDチップと、該 LEDチップからの発光の少なくとも一部を吸収し波長変換して発光するフォトルミネセンス蛍光体と、を有する発光ダイオードであって、前記LEDチップの 発光スペクトルのピークが400nmから530nmの発光波長を有すると共に 、前記フォトルミネセンス蛍光体が RE_3 (Al, Ga) $_5O_{12}$:Ceである。但し、REは、Y, Gd, Smから選択される少なくとも一種である。

[0011]

また、マウント・リードのカップ内に配置させたLEDチップと、該LEDチップと導電性ワイヤーを用いて電気的に接続させたインナー・リードと、前記カップ内に充填させたコーティング部材と、該コーティング部材、LEDチップ、導電性ワイヤー及びマウント・リードとインナー・リードの少なくとも一部を被覆するモールド部材と、を有する発光ダイオードであって、前記LEDチップが窒化ガリウム系化合物半導体であり、且つ前記コーティング部材がRE $_3$ (A1, $Ga)_5O_{12}$:Ceフォトルミネセンス蛍光体を有する透光性樹脂でもある。但し、REは、Y,Gd,Smから選択される少なくとも一種である。

[0012]

さらに、前記フォトルミネセンス蛍光体の組成が次の一般式で示される発光ダイオードでもある。 $(Y_{1-p-q-r}Gd_pCe_qSm_r)_3(Al_{1-s}Ga_s)_5O_{12}$ 但 し、 $0\le p\le 0$. 8、0.003 $\le q\le 0$.2、0.0003 $\le r\le 0$.08、 $0\le s\le 1$

[0013]

また、請求項2記載の発光ダイオードをマトリックス状に配置したLED表示器と、該LED表示器と電気的に接続させた駆動回路と、を有するLED表示装置である。

[0014]

【発明の実施の態様】

本願発明者は、種々の実験の結果、可視光域における光エネルギーが比較的高いLEDチップからの発光光をフォトルミネセンス蛍光体によって色変換させる発光ダイオードにおいて、特定の半導体及び蛍光体を選択することにより高輝度、長時間の使用時における光効率低下や色ずれを防止できることを見出し本願発明を成すに至った。

[0015]

即ち、発光ダイオードに用いられるフォトルミネセンス蛍光体としては、

1. 耐光性に優れていることが要求される。特に、半導体発光素子などの微小領域から強放射されるために太陽光の約30倍から40倍にもおよぶ強照射強度にも十分耐える必要がある。2. 発光素子との混色を利用するため紫外線ではなく青色系発光で効率よく発光すること。3. 混色を考慮して緑色系から赤色系の光が発光可能なこと。4. 発光素子近傍に配置されるため温度特性が良好であること。5. 色調が組成比或いは複数の蛍光体の混合比で連続的に変えられること。6. 発光ダイオードの利用環境に応じて耐候性があることなどの特徴を有することが求められる。

[0016]

これらの条件を満たすものとして本願発明は、発光素子として発光層に高エネルギーバンドギャップを有する窒化ガリウム系化合物半導体素子を、フォトルミネセンス蛍光体としてRE3(A1,Ga)5O12:Ce蛍光体を用いる。これにより発光素子から放出された可視光域における高エネルギー光を長時間近傍で高輝度に照射した場合であっても発光色の色ずれや発光輝度の低下が極めて少ない発光ダイオードとすることができるものである。

[0017]

具体的な発光ダイオードの一例として、チップタイプLEDを図2に示す。チップタイプLEDの筐体204内に窒化ガリウム系半導体を用いたLEDチップ202をエポキシ樹脂などを用いて固定させてある。導電性ワイヤー203として金線をLEDチップ202の各電極と筐体に設けられた各電極205とにそれぞれ電気的に接続させてある。RE3(A1,Ga)5〇12:Ce蛍光体をエポキシ樹脂中に混合分散させたものをLEDチップ、導電性ワイヤーなどを外部応力などから保護するモールド部材201として均一に硬化形成させる。このような発光ダイオードに電力を供給させることによってLEDチップ202を発光させる。LEDチップ202からの発光と、その発光によって励起されたフォトルミネセンス蛍光体からの発光光との混色により白色系などが発光可能な発光ダイオードとすることができる。以下、本願発明の構成部材について詳述する。

[0018]

(蛍光体)

本願発明に用いられるフォトルミネセンス蛍光体としては、半導体発光層から 発光された可視光及び紫外線で励起されて発光するフォトルミネセンス蛍光体を いう。具体的なフォトルミネセンス蛍光体としては、RE3(A1, Ga)₅ O_{12} : C e (但し、R E は、Y, G d, S m から選択される少なくとも一種) である 。窒化ガリウム系化合物半導体を用いたLEDチップから発光した光と、ボディ ーカラーが黄色でありフォトルミネセンス蛍光体から発光する光が補色関係など にある場合、LEDチップからの発光と、フォトルミネセンス蛍光体からの発光 と、を混色表示させると白色系の発光色表示を行うことができる。そのため発光 ダイオード外部には、LEDチップからの発光とフォトルミネセンス蛍光体から の発光とがモールド部材を透過する必要がある。したがって、フォトルミネセン ス蛍光体のバルク層内などにLEDチップを閉じこめ、フォトルミネセンス蛍光 体層にLEDチップからの光が透過する開口部を1乃至2以上有する構成の発光 ダイオードとしても良い。また、フォトルミネセンス蛍光体の粉体を樹脂や硝子 中に含有させLEDチップからの光が透過する程度に薄く形成させても良い。フ オトルミネセンス蛍光体と樹脂などとの比率や塗布、充填量を種々調整すること 及び発光素子の発光波長を選択することにより自色を含め電球色など任意の色調 を提供させることができる。

[0019]

さらに、フォトルミネセンス蛍光体の含有分布は、混色性や耐久性にも影響する。すなわち、フォトルミネセンス蛍光体が含有されたコーティング部やモールド部材の表面側からLEDチップに向かってフォトルミネセンス蛍光体の分布濃度が高い場合は、外部環境からの水分などの影響をより受けにくく水分による劣化を抑制しやすい。他方、フォトルミネセンス蛍光体の含有分布をLEDチップからモールド部材表面側に向かって分布濃度が高くなると外部環境からの水分の影響を受けやすいがLEDチップからの発熱、照射強度などの影響がより少なくフォトルミネセンス蛍光体の劣化を抑制することができる。このような、フォトルミネセンス蛍光体の分布は、フォトルミネセンス蛍光体を含有する部材、形成温度、粘度やフォトルミネセンス蛍光体の形状、粒度分布などを調整させることによって種々形成させることができる。したがって、使用条件などにより蛍光体

の分布濃度を、種々選択することができる。

[0020]

本願発明のフォトルミネセンス蛍光体は、特にLEDチップと接する或いは近接して配置され放射照度として(Ee)= $3W \cdot cm^{-2}$ 以上 $10W \cdot cm^{-2}$ 以下においても高効率に上分な耐光性有する発光ダイオードとすることができる。

[0021]

本願発明に用いられるフォトルミネセンス蛍光体は、ガーネット構造のため、熱、光及び水分に強く、励起スペクトルのピークが450nm付近にさせることができる。また、発光ピークも530nm付近にあり700nmまで裾を引くブロードな発光スペクトルを持つ。しかも、組成のA1の一部をGaで置換することで発光波長が短波長にシフトし、また組成のYの一部をGdで置換することで、発光波長が短波長へシフトする。このように組成を変化することで発光色を連続的に調節することが可能である。したがって、長波長側の強度がGdの組成比で連続的に変えられるなど窒化物半導体の青色系発光を白色系発光に変換するための理想条件を備えている。

[0022]

また、窒化ガリウム系半導体を用いたLEDチップと、セリウムで付活された イットリウム・アルミニウム・ガーネット蛍光体(YAG)に希土類元素のサマ リウム(Sm)を含有させたフォトルミネセンス蛍光体と、を有する発光ダイオ ードとすることによりさらに光効率を向上させることができる。

[0023]

このようなフォトルミネセンス蛍光体は、Y、Gd、Ce、Sm、A1及びGaの原料として酸化物、又は高温で容易に酸化物になる化合物を使用し、それらを化学量論比で十分に混合して原料を得る。又は、Y、Gd、Ce、Smの希土類元素を化学量論比で酸に溶解した溶解液を蓚酸で共沈したものを焼成して得られる共沈酸化物と、酸化アルミニウム、酸化ガリウムとを混合して混合原料を得る。これにフラックスとしてフッ化アンモニウム等のフッ化物を適量混合して坩堝に詰め、空気中1350~1450°Cの温度範囲で2~5時間焼成して焼成品を得、次に焼成品を水中でボールミルして、洗浄、分離、乾燥、最後に篩を通

すことで得ることができる。

[0024]

 $(Y_{1-p-q-r}Gd_pCe_qSm_r)_3A1_5O_{12}$ フォトルミネセンス蛍光体は、結晶中にGdを含有することにより、特に460nm以上の長波長域の励起発光効率を高くすることができる。ガドリニウムの含有量の増加により、発光ピーク波長が、530nmから570nmまで長波長に移動し、全体の発光波長も長波長側にシフトする。赤みの強い発光色が必要な場合、Gdの置換量を多くすることで達成できる。一方、Gdが増加すると共に、青色光によるフォトルミネセンスの発光輝度は徐々に低下する。したがって、pは0.8以下であることが好ましく、0.7以下であることがより好ましい。さらに好ましくは0.6以下である。

[0025]

Smを含有する($Y_{1-p-q-r}Gd_pCe_qSm_r$) $_3Al_5O_{12}$ 蛍光体は、Gd の含有量の増加に関わらず温度特性の低下が少ない。このようにS mを含有させることにより、高温度におけるフォトルミネセンス蛍光体の発光輝度は大幅に改善される。その改善される程度はGd の含有量が高くなるほど大きくなる。すなわち、Gd を増加してフォトルミネセンス蛍光体の発光色調に赤みを付与した組成ほどS mの含有による温度特性改善に効果的であることが分かった。(なお、ここでの温度特性とは、450 n m の青色光による常温(25°C)における励起発光輝度に対する、同蛍光体の高温(200°C)における発光輝度の相対値(%)で表している。)

[0026]

Smの含有量は $0.0003 \le r \le 0.08$ の範囲で温度特性が 6.0%以上となり好ましい。この範囲より r が小さいと、温度特性改良の効果が小さくなる。また、この範囲より r が大きくなると温度特性は逆に低下してくる。0.000 $7 \le r \le 0.02$ の範囲では温度特性は 8.0%以上となり最も好ましい。

[0027]

Ceは0.003 \leq q \leq 0.2の範囲で相対発光輝度が70%以上となる。qが0.003以下では、Ceによるフォトルミネセンスの励起発光中心の数が減少することで輝度低下し、逆に、0.2より大きくなると濃度消光が生ずる。

[0028]

本願発明の発光ダイオードにおいてこのようなフォトルミネセンス蛍光体は、 2種類以上のRE $_3$ (A $_1$,G $_a$) $_5$ O $_1$ 2:Ceフォトルミネセンス蛍光体を混合させてもよい。即ち、A $_1$ 、G $_a$ 、Y及びG $_d$ やS $_m$ の含有量が異なる2種類以上のRE $_3$ (A $_1$,G $_a$) $_5$ O $_1$ 2:Ceフォトルミネセンス蛍光体を混合させてRGBの波長成分を増やすことができる。これに、カラーフィルターを用いることによりフルカラー液晶表示装置用としても利用できる。

[0029]

(LEDfy7102, 202, 702)

本願発明に用いられるLEDチップとは、RE $_3$ (A $_1$,Ga) $_5$ O $_12$:Ce蛍光体を効率良く励起できる窒化物系化合物半導体が挙げられる。発光素子であるLEDチップは、MOCVD法等により基板上に $_1$ nGaN等の半導体を発光層として形成させる。半導体の構造としては、 $_1$ S接合、 $_2$ PIN接合や $_3$ PN接合などを有するホモ構造、 $_3$ PIN接合や $_3$ PN接合などを有するホモ構造、 $_3$ PIN接合や $_3$ PN接合などを有するホモ構造、 $_3$ PIN接合や $_3$ PIN接合や $_4$ PN接合などを有するホモ構造、 $_3$ PIN接合を $_4$ PIN接合を $_5$ PIN接合を $_5$ PIN接合を $_5$ PIN接合を $_5$ PIN接合などを有するホモ構造、 $_5$ PIN接合ないはダブルヘテロ構成のものが挙げられる。半導体層の材料やその混晶度によって発光波長を種々選択することができる。また、半導体活性層を量子効果が生ずる薄膜に形成させた単一量子井戸構造や多重量子井戸構造とすることもできる。

[0030]

窒化ガリウム系化合物半導体を使用した場合、半導体基板にはサファイヤ、スピネル、SiC、Si、ZnO等の材料が用いられる。結晶性の良い窒化ガリウムを形成させるためにはサファイヤ基板を用いることが好ましい。このサファイヤ基板上にGaN、A1N等のバッファー層を形成しその上にPN接合を有する窒化ガリウム半導体を形成させる。窒化ガリウム系半導体は、不純物をドープしない状態でN型導電性を示す。発光効率を向上させるなど所望のN型窒化ガリウム半導体を形成させる場合は、N型ドーパントとしてSi、Ge、Se、Te、C等を適宜導入することが好ましい。一方、P型窒化ガリウム半導体を形成させる場合は、P型ドーパンドであるZn、Mg、Be、Ca、Sr、Ba等をドープさせる。窒化ガリウム系化合物半導体は、P型ドーパントをドープしただけではP型化しにくいためP型ドーパント導入後に、低電子線照射させたり、プラズ

マ照射等によりアニールすることでP型化させることが好ましい。エッチングなどによりP型半導体及びN型半導体の露出面を形成させた後、半導体層上にスパッタリング法や真空蒸着法などを用いて所望の形状の各電極を形成させる。

[0031]

次に、形成された半導体ウエハー等をダイヤモンド製の刃先を有するブレードが回転するダイシングソーにより直接フルカットするか、又は刃先幅よりも広い幅の溝を切り込んだ後(ハーフカット)、外力によって半導体ウエハーを割る。あるいは、先端のダイヤモンド針が往復直線運動するスクライバーにより半導体ウエハーに極めて細いスクライブライン(経線)を例えば碁盤目状に引いた後、外力によってウエハーを割り半導体ウエハーからチップ状にカットする。このようにして窒化ガリウム系化合物半導体であるLEDチップを形成させることができる。

[0032]

本願発明の発光ダイオードにおいて白色系を発光させる場合は、フォトルミネセンス蛍光体との補色等を考慮して発光素子の発光波長は400nm以上530nm以下が好ましく、420nm以上490nm以下がより好ましい。LEDチップとフォトルミネセンス蛍光体との効率をそれぞれより向上させるためには、450nm以上475nm以下がさらに好ましい。本願発明の白色系発光ダイオードの発光スペクトルを図3に示す。450nm付近にピークを持つ発光がLEDチップによって励起されたフォトルミネセンスの発光である。

[0033]

(導電性ワイヤー103、203)

導電性ワイヤー103、203としては、LEDチップ102、202の電極とのオーミック性、機械的接続性、電気伝導性及び熱伝導性がよいものが求められる。熱伝導度としては0.01cal/cm²/cm/ \mathbb{C} 以上が好ましく、より好ましくは0.5cal/cm²/cm/ \mathbb{C} 以上である。また、作業性などを考慮して導電性ワイヤーの直径は、好ましくは、 Φ 10 μ m以上、 Φ 45 μ m以下である。このような導電性ワイヤーとして具体的には、金、銅、白金、アルミ

ニウム等の金属及びそれらの合金を用いた導電性ワイヤーが挙げられる。このような導電性ワイヤーは、各LEDチップの電極と、インナー・リード及びマウント・リードなどと、をワイヤーボンディング機器によって容易に接続させることができる。

[0034]

(マウント・リード105)

マウント・リード105としては、LEDチップ102を配置させるものであり、ダイボンド機器などで積載するのに十分な大きさがあれば良い。また、LEDチップを複数設置しマウント・リードをLEDチップの共通電極として利用する場合においては、十分な電気伝導性とボンディングワイヤー等との接続性が求められる。また、マウント・リード上のカップ内にLEDチップを配置すると共に蛍光体を内部に充填させる場合は、近接して配置させた別の発光ダイオードからの光により疑似点灯することを防止することができる。

[0035]

LEDチップ102とマウント・リード105のカップとの接着は熱硬化性樹脂などによって行うことができる。具体的には、エポキシ樹脂、アクリル樹脂やイミド樹脂などが挙げられる。また、フェースダウンLEDチップなどによりマウント・リードと接着させると共に電気的に接続させるためにはAgペースト、カーボンペースト、金属バンプ等を用いることができる。さらに、発光ダイオードの光利用効率を向上させるためにLEDチップが配置されるマウント・リードの表面を鏡面状とし、表面に反射機能を持たせても良い。この場合の表面粗さは、0.1 S以上0.8 S以下が好ましい。また、マウント・リードの具体的な電気抵抗としては300 μ Ω -c m以下が好ましく、より好ましくは、3 μ Ω -c m以下である。また、マウント・リード上に複数のLEDチップを積置する場合は、LEDチップからの発熱量が多くなるため熱伝導度がよいことが求められる。具体的には、0.01 cal/cm²/cm/℃以上が好ましくより好ましくは 0.5 cal/cm²/cm/℃以上である。これらの条件を満たす材料としては、鉄、銅、鉄入り銅、錫入り銅、メタライズパターン付きセラミック等が挙げられる。

[0036]

(インナー・リード106)

インナー・リード106としては、マウント・リード105上に配置されたLEDチップ102と接続された導電性ワイヤー103との接続を図るものである。マウント・リード上に複数のLEDチップを設けた場合は、各導電性ワイヤー同士が接触しないよう配置できる構成とする必要がある。具体的には、マウント・リードから離れるに従って、インナー・リードのワイヤーボンディングさせる端面の面積を大きくすることなどによってマウント・リードからより離れたインナー・リードと接続させる導電性ワイヤーの接触を防ぐことができる。導電性ワイヤーとの接続端面の粗さは、密着性を考慮して1.6S以上10S以下が好ましい。インナー・リードの先端部を種々の形状に形成させるためには、あらかじめリードフレームの形状を型枠で決めて打ち抜き形成させてもよく、或いは全てのインナー・リードを形成させた後にインナー・リード上部の一部を削ることによって形成させても良い。さらには、インナ・リードを打ち抜き形成後、端面方向から加圧することにより所望の端面の面積と端面高さを同時に形成させることもできる。

[0037]

インナー・リードは、導電性ワイヤーであるボンディングワイヤー等との接続性及び電気伝導性が良いことが求められる。具体的な電気抵抗としては、300 $\mu\Omega-c$ m以下が好ましく、より好ましくは $3\mu\Omega-c$ m以下である。これらの条件を満たす材料としては、鉄、銅、鉄入り銅、錫入り銅及び銅、金、銀をメッキしたアルミニウム、鉄、銅等が挙げられる。

[0038]

(コーティング部101)

本願発明に用いられるコーティング部101とは、モールド部材104とは別にマウント・リードのカップに設けられるものでありLEDチップの発光を変換するフォトルミネセンス蛍光体が含有されるものである。コーティング部の具体的材料としては、エポキシ樹脂、ユリア樹脂、シリコーンなどの耐候性に優れた透明樹脂や硝子などが好適に用いられる。また、フォトルミネセンス蛍光体と共

に拡散剤を含有させても良い。具体的な拡散剤としては、チタン酸バリウム、酸 化チタン、酸化アルミニウム、酸化珪素等が好適に用いられる。

[0039]

(モールド部材104)

モールド部材104は、発光ダイオードの使用用途に応じてLEDチップ10 2、導電性ワイヤー103、フォトルミネセンス蛍光体が含有されたコーティン グ部101などを外部から保護するために設けることができる。モールド部材は 般には樹脂を用いて形成させることができる。また、フォトルミネセンス蛍 光体を含有させることによって視野角を増やすことができるが、樹脂モールドに 拡散剤を含有させることによってLEDチップ102からの指向性を緩和させ視 野角をさらに増やすことができる。更にまた、モールド部材104を所望の形状 にすることによってLEDチップからの発光を集束させたり拡散させたりするレ ンズ効果を持たせることができる。従って、モールド部材104は複数積層した 構造でもよい。具体的には、凸レンズ形状、凹レンズ形状さらには、発光観測面 から見て楕円形状やそれらを複数組み合わせた物である。モールド部材104の 具体的材料としては、主としてエポキシ樹脂、ユリア樹脂、シリコーンなどの耐 候性に優れた透明樹脂や硝子などが好適に用いられる。また、拡散剤としては、 チタン酸バリウム、酸化チタン、酸化アルミニウム、酸化珪素等が好適に用いら れる。さらに、拡散剤に加えてモールド部材中にもフォトルミネセンス蛍光体を 含有させることもできる。したがって、フォトルミネセンス蛍光体はモールド部 材中に含有させてもそれ以外のコーティング部などに含有させて用いてもよい。 また、コーティング部をフォトルミネセンス蛍光体が含有された樹脂、モールド 部材を硝子などとした異なる部材を用いて形成させても良い。この場合、生産性 良くより水分などの影響が少ない発光ダイオードとすることができる。また、屈 折率を考慮してモールド部材とコーティング部とを同じ部材を用いて形成させて も良い。

[0040]

(表示装置)

本願発明の発光ダイオードをLED表示器に利用した場合、RGBをそれぞれ

発光する発光ダイオードの組み合わせだけによるLED表示器よりも、より高精細に白色系表示させることができる。すなわち、各発光ダイオードを組み合わせて白色系などを混色表示させるためにはRGBの各発光ダイオードをそれぞれ同時に発光せざるを得ない。そのため赤色系、緑色系、青色系のそれぞれ単色表示した場合に比べて一画素あたりの表示が大きくなる。したがって、白色系の表示の場合においてはRGB単色表示と比較して高精細に表示させることができない。また、白色系の表示は各発光ダイオードを調節して表示させるため各半導体の温度特性などを考慮し種々調整しなければならない。さらに、混色による表示であるが故にLED表示器の視認する方向や角度によって、RGBの発光ダイオードをRGBの発光ダイオードに加えて利用することにより、より高精細化が可能となると共に白色系の発光が安定し色むらをなくすこともできる。また、RGBの各発光ダイオードともに発光させることにより輝度を向上させることもできる。

[0041]

本願発明の発光ダイオードを用いて表示装置の1つとして、RGBの各発光ダイオードに加えて白色系発光ダイオードを1絵素として利用し、標識やマトリクス状など任意の形状に配置させたLED表示器の概略構成を示す。LED表示器は、駆動回路である点灯回路などと電気的に接続させる。駆動回路からの出力パルスによって種々の画像が表示可能なデイスプレイ等とすることができる。駆動回路としては、入力される表示データを一時的に記憶させるRAM(Random、Access、Memory)と、RAMに記憶されるデータから各発光ダイオードを所定の明るさに点灯させるための階調信号を演算する階調制御回路と、階調制御回路の出力信号でスイッチングされて、各発光ダイオードを点灯させるドライバーとを備える。階調制御回路は、RAMに記憶されるデータから発光ダイオードの点灯時間を演算してパルス信号を出力する。ここで、白色系の表示を行う場合は、RGB各発光ダイオードのパルス信号を短くする、パルス高を低くする或いは全く点灯させない。他方、それを補償するように白色系発光ダイオードにパルス信号を出力する。これにより、LED表示器の白色を表示する。

[0042]

したがって、白色系発光ダイオードを所望の輝度で点灯させるためのパルス信号を演算する階調制御回路としてCPUを別途備えることが好ましい。階調制御回路から出力されるパルス信号は、白色系発光ダイオードのドライバーに入力されてドライバをスイッチングさせる。ドライバーがオンになると白色系発光ダイオードが点灯され、オフになると消灯される。

[0043]

また、本願発明の発光ダイオードを用いた別のLED表示器を示す。本願発明の白色系発光ダイオードのみを用い白黒用のLED表示装置とすることもできる。白黒用のLED表示器は、本願発明の発光ダイオード501のみをマトリックス状などに配置し構成することができる。RGBのそれぞれの駆動回路の代わりに白色発光可能な本願発明の発光ダイオード用駆動回路のみとしてLED表示器を構成させることができる。LED表示器は、駆動回路である点灯回路などと電気的に接続させる。駆動回路からの出力パルスによって種々の画像が表示可能なデイスプレイ等とすることができる。駆動回路としては、入力される表示データを一時的に記憶させるRAM(Random、Access、Memory)と、RAMに記憶されるデータから発光ダイオードを所定の明るさに点灯させるための階調信号を演算する階調制御回路と、階調制御回路の出力信号でスイッチングされて、発光ダイオードを点灯させるドライバーとを備える。階調制御回路は、RAMに記憶されるデータから発光ダイオードの点灯時間を演算してバルス信号を出力する。

[0044]

したがって、白黒用のLED表示器はRGBのフルカラー表示器と異なり当然 回路構成を簡略化できると共に高精細化できる。そのため、安価にRGBの発光 ダイオードの特性に伴う色むらなどのないディスプレイとすることができるもの である。また、従来の赤色、緑色のみを用いたLED表示器に比べ人間の目に対 する刺激が少なく長時間の使用に適している。

[0045]

(信号機)

本願発明の発光ダイオードを表示装置の1種である信号機として利用した場合

、長時間安定して発光させることが可能であると共に発光ダイオードの一部が消 灯しても色むらなどが生じないという特徴がある。本願発明の発光ダイオードを 用いた信号機の概略構成として、導電性パターンが形成された基板上に白色系発 光ダイオードを配置させる。このような発光ダイオードを直列又は直並列に接続 された発光ダイオードの回路を発光ダイオード群として扱う。発光ダイオード群 を2つ以上用いそれぞれ渦巻き状に発光ダイオードを配置させる。全ての発光ダ イオードが配置されると円状に全面に配置される。各発光ダイオード及び基板か ら外部電力と接続させる電源コードをそれぞれ、ハンダにより接続させた後、鉄 道用信号用の筐体内に固定させる。LED表示器は、遮光部材が付いたアルミダ イキャストの筐体内に配置され表面にシリコーンゴムの充填材で封止されている 。筐体の表示面は、白色レンズを設けてある。また、LED表示器の電気的配線 は、筐体の裏面からゴムパッキンを通し筐体内を密閉する。これにより白色系信 号機を形成することができる。本願発明の発光ダイオードを、複数の群に分け中 心部から外側に向け輪を描く渦巻き状などに配置し、並列接続させることでより 信頼性が高い信号機とさせることができる。中心部から外側に向け輪を描くとは 連続的に輪を描くものも断続的に配置するものをも含む。したがって、LED表 示器の表示面積などにより配置される発光ダイオードの数や発光ダイオード群の 数を種々選択することができる。この信号機により、一方の発光ダイオード群や ―部の発光ダイオードが何らかのトラブルにより消灯したとしても他方の発光ダ イオード群や残った発光ダイオードにより信号機を円形状に均一に発光させるこ とが可能となるものである。また、色ずれが生ずることもない。渦巻き状に配置 してあることから中心部を密に配置することができ電球発光の信号と何ら違和感 なく駆動させることができる。

[0046]

(面状発光光源)

本願発明の発光ダイオードを用いて図7の如く面状発光光源を構成することができる。面状発光光源の場合、フォトルミネセンス蛍光体をコーティング部や導 光板上の散乱シート706に含有させる。或いはバインダー樹脂と共に散乱シート706に塗布などさせシート状701に形成しモールド部材を省略しても良い 。具体的には、絶縁層及び導電性バターンが形成されたコの字形状の金属基板703内にLEDチップ702を固定する。LEDチップと導電性パターンとの電気的導通を取った後、フォトルミネセンス蛍光体をエボキシ樹脂と混合撹拌しLEDチップ702が積載された基板703上に充填させ発光ダイオードを形成させる。こうして形成された発光ダイオードは、アクリル性導光板704の端面にエポキシ樹脂などで固定される。導光板704の一方の主面上には、蛍現象防止のため白色散乱剤が含有されたフィルム状の反射部材707を配置させてある。同様に、導光板の裏面側全面や発光ダイオードが配置されていない端面上にも反射部材705を設け発光光率を向上させてある。これにより、LCDのバックライトとして十分な明るさを得られる面状発光光源とすることができる。液晶表示装置として利用する場合は、導光板704の主面上に不示図の透光性導電性パターンが形成された硝子基板間に注入された液晶装置を介して配された偏光板により構成させることができる。以下、本願発明の実施例について説明するが、本願発明は具体的実施例のみに限定されるものではないことは言うまでもない。

[0047]

【実施例】

(実施例1)

発光素子として発光ピークが450nmのGaInN半導体を用いた。LEDチップは、洗浄させたサファイヤ基板上にTMG(トリメチルガリウム)ガス、TMA(トリメチルアルミニウム)ガス、窒素ガス及びドーパントガスをキャリアガスと共に流し、MOCVD法で窒化ガリウム系化合物半導体を成膜させることにより形成させた。ドーパントガスとして SiH_4 と Cp_2 Mgと、を切り替えることによってN型導電性を有する窒化ガリウム半導体とP型導電性を有する窒化ガリウム半導体とP型導電性を有する窒化ガリウム半導体とP型導電性を有する窒化ガリウム半導体を形成しPN接合を形成させた。(なお、P型半導体は、成膜後400C以上でアニールさせてある。)

[0048]

エッチングによりPN各半導体表面を露出させた後、スパッタリングにより各電極をそれぞれ形成させた。こうして出来上がった半導体ウエハーをスクライブラインを引いた後、外力により分割させ発光素子としてLEDチップを形成させ

た。

[0049]

銀メッキした銅製リードフレームの先端にカップを有するマウント・リードに LEDチップをエポキシ樹脂でダイボンディングした。LEDチップの各電極と マウント・リード及びインナー・リードと、をそれぞれ金線でワイヤーボンディ ングし電気的導通を取った。

[0050]

方、フォトルミネセンス蛍光体は、Y、Gd、Ceの希土類元素を化学量論 比で酸に溶解した溶解液を蓚酸で共沈させた。これを焼成して得られる共沈酸化 物と、酸化アルミニウム、酸化ガリウムと混合して混合原料を得る。これにフラ ックスとしてフッ化アンモニウムを混合して坩堝に詰め、空気中1400°Cの 温度範囲で3時間焼成して焼成品を得た。焼成品を水中でボールミルして、洗浄 、分離、乾燥、最後に篩を通して形成させた。

[0051]

形成された(Y_{1.2}Gd_{0.8})A₁₃O₁₂: Ce蛍光体80重量部、エポキシ樹脂100重量部をよく混合してスリラーとさせた。このスリラーをLEDチップが配置されたマウント・リード上のカップ内に注入させた。注入後、フォトルミネセンス蛍光体が含有された樹脂を130℃1時間で硬化させた。こうしてLEDチップ上に厚さ120μのフォトルミネセンス蛍光体が含有されたコーティング部が形成された。なお、コーティング部には、LEDチップに向かってフォトルミネセンス蛍光体が徐々に多くしてある。その後、さらにLEDチップやフォトルミネセンス蛍光体を外部応力、水分及び塵芥などから保護する目的でモールド部材として透光性エポキシ樹脂を形成させた。モールド部材は、砲弾型の型枠の中にフォトルミネセンス蛍光体のコーティング部が形成されたリードフレームを挿入し透光性エポシキ樹脂を混入後、150℃5時間にて硬化させた。こうして形成された発光ダイオードは、発光観測正面から視認するとフォトルミネセンス蛍光体のボディーカラーにより中央部が黄色っぽく着色していた。

[0052]

こうして得られた白色系が発光可能な発光ダイオードの色度点、色温度、演色

性指数を測定した。それぞれ、色度点(x=0. 302、y=0. 280)、色温度8080K、Ra(演色性指数)=87. 5と三波長型蛍光灯に近い性能を示した。また、発光光率は9. $51\,\text{m/w}$ と白色電球並であった。さらに耐侯試験として空温 $60\,\text{m}$ A通電、空温 $20\,\text{m}$ A通電、 $60\,\text{C}90\,\text{N}$ RH下で $20\,\text{m}$ A通電の各試験においても蛍光体に起因する変化は観測されず通常の青色発光ダイオードと寿命特性に差がないことが確認できた。

[0053]

(比較例1)

フォトルミネセンス蛍光体を($Y_{1.2}Gd_{0.8}$) $Al_{3}O_{12}$:Ceから(ZnCd の S:Cu、Alとした以外は、実施例1と同様にして発光ダイオードの形成 及び耐侯試験を行った。形成された発光ダイオードは通電直後、実施例1と同様 白色系の発光が確信されたが輝度が低かった。また、耐侯試験においては、約100時間で出力がゼロになった。劣化原因を解析した結果、蛍光体が黒化していた。

[0054]

これは、発光素子の発光光と蛍光体に付着していた水分或いは外部環境から進入した水分により光分解し蛍光体結晶表面にコロイド状亜鉛金属を析出し外観が 黒色に変色したものと考えられる。

[0055]

(実施例2)

LEDチップの窒化物系化合物半導体を実施例1よりもInの含有量を増やし発光ピークを460nmとした。同様にフォトルミネセンス蛍光体として実施例1よりもGdの含有量を増やした以外は実施例1と同様にして発光ダイオードを100個形成し耐侯試験を行った。

[0056]

こうして得られた白色系が発光可能な発光ダイオードの色度点、色温度、演色性指数を測定した。それぞれ、色度点($\mathbf{x}=0$. 375、 $\mathbf{y}=0$. 370)、色温度4400K、Ra(演色性指数)=86.0であった。さらに耐侯試験においては、形成させた発光ダイオード100個平均で行った。耐候性試験前の光度

を100%とし1000時間経過後における平均光度を調べた。耐候性試験後も98.8%であり特性に差がないことが確認できた。

[0057]

(実施例3)

[0058]

(実施例4)

本願発明の発光ダイオードを図5の如くLED表示器の1つであるディスプレイに利用した。実施例1と同様にして形成させた発光ダイオードを銅パターンを形成させたセラミックス基板上に、16×16のマトリックス状に配置させた。基板と発光ダイオードとは自動ハンダ実装装置を用いてハンダ付けを行った。次にフェノール樹脂によって形成された筐体504内部に配置し固定させた。遮光部材505は、筐体と一体成形させてある。発光ダイオードの先端部を除いて筐体、発光ダイオード、基板及び遮光部材の一部をピグメントにより黒色に着色したシリコンゴム406によって充填させた。その後、常温、72時間でシリコンゴムを硬化させLED表示器を形成させた。このLED表示器と、入力される表示データを一時的に記憶させるRAM(Random、Access、Memory)及びRAMに記憶されるデータから発光ダイオードを所定の明るさに点灯させるための階調信号を演算する階調制御回路と階調制御回路の出力信号でスイッチングされて発光ダイオードを点灯させるドライバーとを備えたCPUの駆動手段と、を電気的に接続させてLED表示装置を構成した。LED表示器を駆動させ白黒LED表示装置として駆動できることを確認した。

[0059]

【発明の効果】

本願発明の構成とすることにより高出力の窒化物系化合物半導体の発光素子と

、RE $_3$ (A $_1$,G $_a$) $_5$ O $_{12}$:Ce蛍光体と、を利用した発光ダイオードとすることにより長時間高輝度時の使用においても発光効率が高い発光ダイオードとすることができる。さらに、信頼性や省電力化、小型化さらには色温度の可変性など車載や航空産業、一般電気機器に表示の他に照明として新たな用途を開くことができる。また、白色は人間の目で長時間視認する場合には刺激が少なく目に優しい発光ダイオードとすることができる。

[0060]

特に、本願発明の請求項1に記載の構成とすることにより高輝度、長時間の使用においても色ずれ、発光光率の低下が極めて少ない白色系が発光可能な発光ダイオードなど種々の発光ダイオードとすることができる。

[0061]

本願発明の請求項2の構成とすることにより、高輝度、長時間の使用においても色ずれ、発光光率の低下が極めて少ない発光ダイオードなど種々の発光ダイオードとすることができることに加えて、発光ダイオードを複数近接して配置した場合においても他方の発光ダイオードからの光により蛍光体が励起され疑似点灯されることを防止させることができる。また、LEDチップ自体の発光むらを蛍光体により分散することができるためより均一な発光光を有する発光ダイオードとすることができる。

[0062]

本願発明の請求項3の構成とすることにより、より温度依存性の少ない発光ダイオードとすることができる。

[0063]

本願発明の請求項4の構成とすることにより、比較的安価で高精細なLED表示装置や視認角度によって色むらの少ないLED表示装置とすることができる。

[0064]

【図面の簡単な説明】

【図1】

図1は、本願発明の発光ダイオードの模式的断面図である。

【図2】

図2は、本願発明の他の発光ダイオードの模式的断面図である。

【図3】

図3は、本願発明の発光ダイオードの発光スペクトルの一例を示した図である

【図4】

図4 (A) は、本願発明に使用されるフォトルミネセンス蛍光体の吸収スペクトルの一例を示し、図4 (B) は、本願発明に使用されるフォトルミネセンス蛍光体の発光スペクトルの一例を示した図である。

【図5】

図5は、本願発明の発光ダイオードを用いたLED表示装置の模式図である。

【図6】

図6は、図5に用いられるLED表示装置のブロック図である。

【図7】

図7は、本願発明の発光ダイオードを用いた別のLED表示装置の模式図である。

【符号の説明】

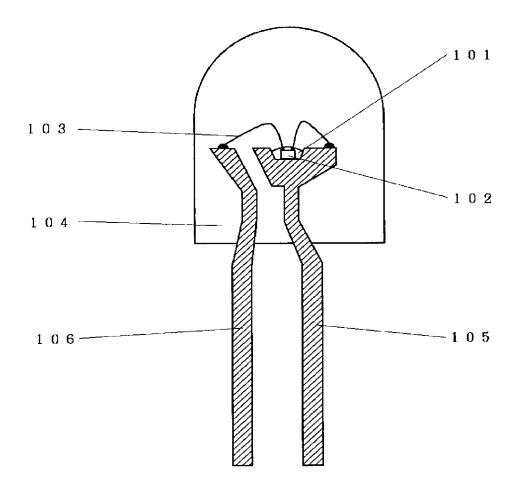
- 101、701・・・フォトルミネセンスが含有されたコーティング部
- 102、202、702・・・LEDチップ
- 103、203・・・導電性ワイヤー
- 104・・・モールド部材
- 105・・・マウント・リード
- 106・・・インナー・リード
- 201・・・フォトルミネセンスが含有されたモールド部材
- 204・・・筐体
- 205・・・筐体に設けられた電極
- 501・・・発光ダイオード
- 504・・・筐体
- 505・・・ 遮光部材
- 506・・・充填材

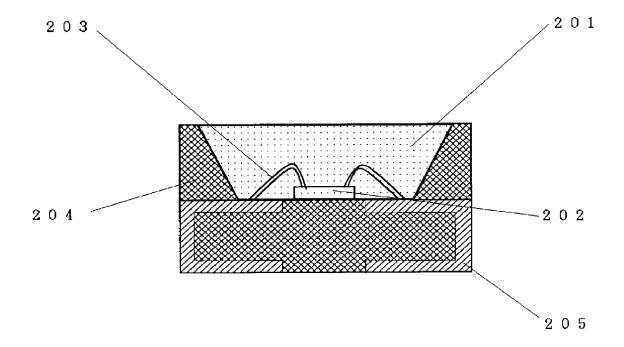
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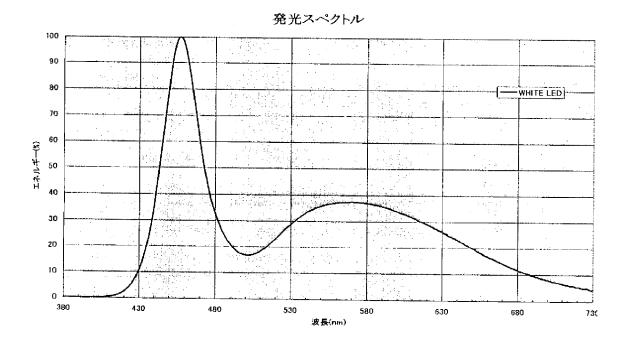
704・・・導光板

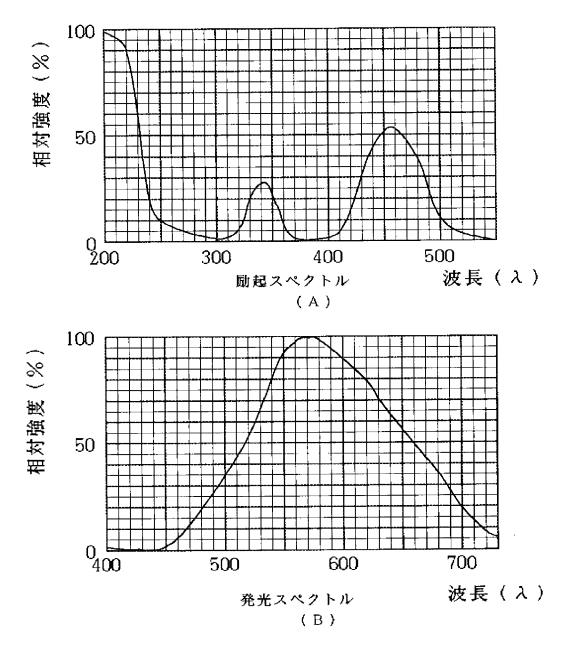
705、707・・・反射部材

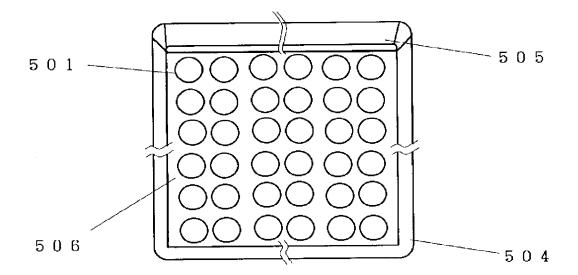
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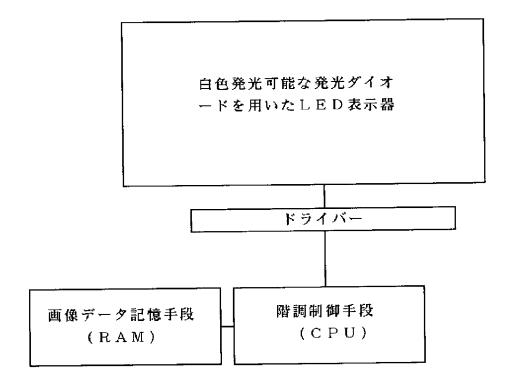


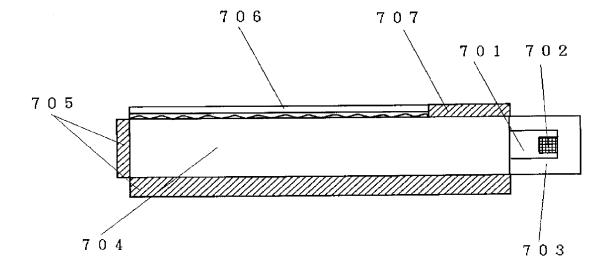












【書類名】 要約書

【課題】

本願発明は、LEDチップからの発光を変換して発光させるフォトルミネセンス蛍光体を有し使用環境によらず高輝度、高効率に発光可能な発光ダイオード及びそれを用いた表示装置に関する。

【解決手段】

本願発明は、発光層が窒化ガリウム系化合物半導体であるLEDチップと、該LEDチップからの発光の少なくとも一部を吸収し波長変換して発光するフォトルミネセンス蛍光体と、を有する発光ダイオードであって、前記LEDチップの発光スペクトルのピークが400nmから530nmの発光波長を有すると共に、前記フォトルミネセンス蛍光体がRE $_3$ (A1, Ga) $_5$ O $_1$ 2:Ceである発光ダイオード。但し、REは、Y, Ga, Smから選択される少なくとも一種である。

【選択図】図1

【書類名】 職権訂正データ

【訂正書類】 特許願

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The country code and number of your priority application, to be used for filing abroad under the Paris Convention, is JP1996-244339

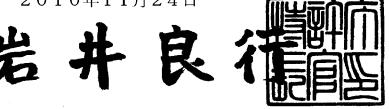
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Applicant(s):

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【請求項の数】 5

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【物件名】図面 1

【物件名】要約書 1 【プルーフの要否】要

【書類名】 明細書

【発明の名称】 発光装置

【特許請求の範囲】

【請求項1】

発光層が窒化ガリウム系化合物半導体であるLEDチップと、該LEDチップからの発光の少なくとも一部を吸収し波長変換して発光するフォトルミネセンス 蛍光体と、を有する発光装置であって、

前記LEDチップの主発光ピークが400nmから530nm内であると共に、前記フォトルミネセンス蛍光体が Y_3 (A_1 , G_a) $_5O_{12}$: C_e である第1の蛍光体と、 $RE_3A_1_5O_{12}$: C_e であって第1の蛍光体の主発光波長よりも長波長側に主発光波長がある第2の蛍光体とであることを特徴とする発光装置。但し、REは、Y, G_d , L_a から選択される少なくとも一種である。

【請求項2】

発光層が窒化ガリウム系化合物半導体であるLEDチップと、該LEDチップ からの発光の少なくとも一部を吸収し波長変換して発光するフォトルミネセンス 蛍光体と、を有する発光装置であって、

前記LEDチップの主発光ピークが400nmから530nm内であると共に、前記フォトルミネセンス蛍光体は $Y_3Al_5O_{12}$: Ceの主発光波長よりも短波長側に主発光波長がある Y_3 (Al, Ga) $_5O_{12}$: Ceと $Y_3Al_5O_{12}$: Ceの主発光波長よりも長波長側に主発光波長があるRE $_3Al_5O_{12}$: Ceであることを特徴とする発光装置。

但し、REは、Y, Gd, Laから選択される少なくとも一種である。

【請求項3】

LEDチップからの発光により励起されて蛍光を発するフォトルミネセンス蛍 光体が含有された蛍光体層を介して光学的に接続されたLEDチップと、透光性 導光板と、を有する面状光源であって、

前記LEDチップの発光層が400nmから530nm内に主発光波長を有する窒化ガリウム系化合物半導体であり、前記フォトルミネセンス蛍光体が Y_3 (Al, Ga) $_5O_{12}$:Ceである第1の蛍光体と、RE $_3$ Al $_5O_{12}$:Ceであっ

て前記第1の蛍光体の主発光波長よりも長波長側に主発光波長がある第2の蛍光体であることを特徴とする面状光源。

但し、REは、Y、Gd、Laから選択される少なくとも一種である。

【請求項4】

透光性導光板の端面の少なくとも一箇所にLEDチップが光学的に接続されており、前記導光板の主面のいずれか一方に、前記LEDチップの発光により励起されて蛍光を発するフォトルミネセンス蛍光体が含有された蛍光部材を有する面状光源であって、

前記LEDチップの発光層が400nmから530nm内に主発光波長を有する窒化ガリウム系化合物半導体であり、前記フォトルミネセンス蛍光体が Y_3 (Al, Ga) $5O_{12}$: Ceである第1の蛍光体と、RE $_3$ Al $_5O_{12}$: Ceであって前第1の蛍光体の主発光波長よりも長波長側に主発光波長がある第2の蛍光体とであることを特徴とする面状光源。

但し、REは、Y, Gd, Laから選択される少なくとも一種である。

【請求項5】

マウント・リードのカップ内に配置させたLEDチップと、該LEDチップと 導電性ワイヤーを用いて電気的に接続させたインナー・リードと、前記カップ内 に充填させたコーティング部材と、該コーティング部材、LEDチップ、導電性 ワイヤー及びマウント・リードとインナー・リードの少なくとも一部を被覆する モールド部材と、を有する発光ダイオードであって、

前記LEDチップが窒化ガリウム系化合物半導体であり、且つ前記コーティング部材が第1のフォトルミネセンス蛍光体である Y_3 (A_1 , G_a) $_5O_{12}$: C_e と、 $RE_3Al_5O_{12}$: C_e であって前記第1の蛍光体の主発光波長よりも長波長側に主発光波長を有する第2の蛍光体である $RE_3Al_5O_{12}$: C_e とを有する透光性樹脂であることを特徴とする発光ダイオード。

但し、REは、Y, Gd, Laから選択される少なくとも一種である。

【発明の詳細な説明】

[0001]

【産業上の利用分野】

本願発明は、バックライト光源、照光式スイッチ、信号機、表示器、LEDディスプレイ及び各種インジケータなどに利用される発光装置に係わり、特に使用環境によらず高輝度、高効率にRGB(赤、緑、青色系)成分が発光可能な発光装置に関する。

[0002]

【従来技術】

LEDチップを用いた発光装置は、小型で効率が良く鮮やかな色の発光をする。また、半導体素子であるため球切れなどの心配がない。初期駆動特性が優れ、振動やON/OFF点灯の繰り返しに強いという特徴を有する。そのため各種インジケータや種々の光源として利用されている。最近、超高輝度高効率な発光ダイオードとしてRGBなどの発光ダイオードがそれぞれ開発された。これに伴いRGBの三原色を利用した液晶用バックライトなどに使用可能なフルカラー用面状発光装置が省電力、長寿命、軽量などの特長を生かして研究されてきている。

[0003]

LEDチップは使用される発光層の半導体材料、形成条件などによって紫外から赤外まで種々の発光波長を放出させることが可能である。また、優れた単色性ピーク波長を有する。

[0004]

しかしながら、LEDチップを用いた発光装置は優れた単色性ピーク波長を有するが故に白色系発光光源などとさせるためには、RGBなどが発光可能な各LEDチップをそれぞれ近接して発光させ拡散混色させる必要がある。このような発光ダイオードは、種々の色を自由に発光させる発光装置としては有効であるが、白色系などの色のみを発光させる場合においても赤色系、緑色系及び青色系の発光ダイオードなどをそれぞれ使用せざるを得ない。LEDチップは、半導体であり色調や輝度のバラツキもまだ相当ある。また、同一半導体材料を用いて高輝度にRGBが発光可能なLEDチップが未だ開発されていない。そのため、それぞれ異なる材料を用いて形成させざるを得ず、各LEDチップの駆動電力などが異なるため個々に電源などを確保する必要がある。白色系を発光させるためには、各半導体ごとに電流などを調節して発光させなければならない。同様に、半導

体発光素子であるため個々の温度特性の差や経時変化が異なり、色調が種々変化してしまう。さらに、LEDチップからの発光を均一に混色させなければ、色むらを生ずる場合がある。

[0005]

そこで、本出願人は先にLEDチップの発光色を蛍光物質で色変換させた発光 ダイオードや面状発光装置として特開平5-152609号公報、特開平7-1 76794号公報、特開平8-8614号公報などに記載された発光ダイオード や面状発光光源を開発した。これらの発光ダイオードや面状発光光源によって、 1種類のLEDチップを用いて白色系など他の発光色を発光させることができる

具体的には、青色が発光可能なLEDチップを透明な導光板の一端に接続させ LEDチップから発光された発光を導光板上に設けられた蛍光物質含有層によっ て緑色及び赤色などに色変換させ白色系の発光とさせるものである。これらは、 RGB発光成分を有する白色系が発光可能な発光装置として利用した場合におい ても十分な輝度を長時間に渡って発光する発光装置とすることができる。

[0006]

【発明が解決しようとする課題】

LEDチップからの発光によって励起される蛍光物質は、蛍光染料、蛍光顔料さらには有機、無機化合物などから様々なものが挙げられる。蛍光体の励起波長や発光波長によっても種々のものが挙げられる。また、蛍光体は、発光素子からの発光波長を波長の短いものから長い波長へと変換する、或いは発光素子からの発光波長を波長の長いものから短い波長へと変換するものとがある。

[0007]

しかしながら、波長の長いものから短い波長へと変換する場合、変換効率が極めて悪く実用に向かない。また、発光装置を直射日光など外部環境下で使用する場合や蛍光体をLEDチップ周辺に近接して配置させた場合は、紫外線など様々な高エネルギー光が蛍光体などに長期間に渡って強照射され続ける。特に、発光素子であるLEDチップを高エネルギーバンドギャップを有する半導体を用い蛍光体の変換効率向上や蛍光体の使用量を減らした場合においては、LEDチップ

から発光した光が可視光域にあるといっても光エネルギーが必然的に高くなり、 太陽光などの外来光からとの相乗作用で蛍光体自体が劣化しやすい。

[8000]

蛍光体が劣化すると色調がずれる、或いは蛍光体が黒ずみ光の外部取り出し効率が低下する場合がある。同様に蛍光体は、LEDチップの昇温や外部環境からの加熱など高温にもさらされる。さらに、発光装置は一般的に樹脂ケースに被覆されてはいるものの外部環境からの水分の進入などを完全に防ぐことや、製造時に付着した水分を完全に除去することはできない。蛍光体によっては、このような水分が発光素子からの高エネルギー光や熱によって蛍光体物質の劣化を促進する場合もある。また、イオン性の有機染料に至ってはチップ近傍では直流電界により電気泳動を起こし、色調が変化する可能性がある。したがって、本願発明は上記課題を解決し、野外の使用時などにおいてもより長時間、発光光率の低下や色ずれが極めて少なくRGBの発光成分を高輝度に発光可能な発光装置を提供することを目的とする。

[0009]

【課題を解決するための手段】

本願発明は、発光層が窒化ガリウム系化合物半導体であるLEDチップと、該LEDチップからの発光の少なくとも一部を吸収し波長変換して発光するフォトルミネセンス蛍光体と、を有する発光装置であって、前記LEDチップの主発光ピークが400nmから530nm内であると共に、前記フォトルミネセンス蛍光体が Y_3 (A_1 , G_a) $_5O_{12}$: C_e である第1の蛍光体と、 $RE_3A_1_5O_{12}$: C_e であって第1の蛍光体の主発光波長よりも長波長側に主発光波長がある第2の蛍光体とである発光装置である。(但し、REは、Y, G_d , L_a から選択される少なくとも一種である。)

[0010]

また、発光層が窒化ガリウム系化合物半導体であるLEDチップと、該LEDチップからの発光の少なくとも一部を吸収し波長変換して発光するフォトルミネセンス蛍光体と、を有する発光装置であって、前記LEDチップの主発光ピークが400nmから530nm内であると共に、前記フォトルミネセンス蛍光体は

 $Y_3Al_5O_{12}$: Ceo主発光波長よりも短波長側に主発光波長がある Y_3 (Al_5O_{12} : Ceと $Y_3Al_5O_{12}$: Ceの主発光波長よりも長波長側に主発光波長がある $RE_3Al_5O_{12}$: Ceである発光装置である。

但し、REは、Y, Gd, Laから選択される少なくとも一種である。

[0011]

さらに、LEDチップからの発光により励起されて蛍光を発するフォトルミネセンス蛍光体が含有された蛍光体層を介して光学的に接続されたLEDチップと、透光性導光板とを有する面状光源であって、前記LEDチップの発光層が400nmから530nm内に主発光波長を有する窒化ガリウム系化合物半導体であり、前記フォトルミネセンス蛍光体が Y_3 (A_1 , G_a) $_5O_{12}$: C_e である第1の蛍光体と、 $RE_3A_15O_{12}$: C_e であって前記第1の蛍光体の主発光波長よりも長波長側に主発光波長がある第2の蛍光体とである面状光源である。(但し、REは、Y, G_d , L_a から選択される少なくとも一種である。)

[0012]

さらにまた、透光性導光板の端面の少なくとも一箇所にLEDチップが光学的に接続されており、前記導光板の主面のいずれか一方に、前記LEDチップの発光により励起されて蛍光を発するフォトルミネセンス蛍光体が含有された蛍光部材を有する面状光源であって、前記LEDチップの発光層が400nmから530nm内に主発光波長を有する窒化ガリウム系化合物半導体であり、前記フォトルミネセンス蛍光体が Y_3 (A_1 , G_a) $5O_{12}$: C_e である第1の蛍光体と、RE $_3A_15O_{12}$: C_e であって前第1の蛍光体の主発光波長よりも長波長側に主発光波長がある第2の蛍光体とである面状光源である。(但し、REは、Y, Gd, Laから選択される少なくとも一種である。)

[0013]

また、マウント・リードのカップ内に配置させたLEDチップと、該LEDチップと導電性ワイヤーを用いて電気的に接続させたインナー・リードと、前記カップ内に充填させたコーティング部材と、該コーティング部材、LEDチップ、導電性ワイヤー及びマウント・リードとインナー・リードの少なくとも一部を被覆するモールド部材と、を有する発光ダイオードであって、前記LEDチップが

室化ガリウム系化合物半導体であり、且つ前記コーティング部材が第1のフォトルミネセンス蛍光体である Y_3 (A_1 , G_a) $_5O_{12}$: C_e と、 $RE_3A_1_5O_{12}$: C_e であって前記第1の蛍光体の主発光波長よりも長波長側に主発光波長を有する第2の蛍光体である $RE_3A_1_5O_{12}$: C_e とを有する透光性樹脂である発光ダイオードでもある。(但し、REは、Y, G_d , L_a から選択される少なくとも一種である。)

[0014]

【発明の実施の態様】

本願発明者は、種々の実験の結果、可視光域における光エネルギーが比較的高いLEDチップからの発光光をフォトルミネセンス蛍光体によって緑系色及び赤系色に色変換させる発光装置において、特定の半導体及び蛍光体を選択することにより高輝度、長時間の使用時における光効率低下や色ずれを防止できることを見出し本願発明を成すに至った。

[0015]

即ち、発光ダイオードに用いられるフォトルミネセンス蛍光体としては、
1. 耐光性に優れていることが要求される。特に、様々な高エネルギー光が照射される直射日光などから長時間耐える必要がある。また、発光ダイオードとして使用する場合は半導体発光素子などの微小領域から強放射されるために(Ee) = 3 W・c m⁻²以上にも及ぶ強照射強度にも耐える必要がある。2. 発光素子との混色を利用するため紫外線ではなく青色系発光で効率よく発光すること。3. 混色を考慮して緑色系及び赤色系の光が高輝度に発光可能なこと。4. 外部環境下や発光素子近傍に配置されるため温度特性が良好であること。5. 色調が組成比或いは緑色系及び赤色系の蛍光体の混合比で連続的に変えられること。6. 発光装置の利用環境に応じて耐候性があることなどの特徴を有することが求められる。

[0016]

これらの条件を満たすものとして本願発明は、発光素子として発光層に高エネルギーバンドギャップを有する窒化ガリウム系化合物半導体素子を、フォトルミネセンス蛍光体として Y_3 (A_1 , G_a) $_5$ O $_1_2$: C_9 蛍光体及び R_2 E_3 (A_1)

Ga)5O12:Ce蛍光体(但し、REは、Y, Gd, Laから選択される少なくとも一種である。)を用いる。これにより発光素子から放出された可視光域における高エネルギー光を長時間近傍で高輝度に照射した場合や外部環境の使用下においても発光色の色ずれや発光輝度の低下が極めて少ない高輝度にRGBの発光成分を有する発光装置とすることができるものである。

[0017]

具体的な発光装置の一例として、チップタイプLEDを図1に示す。チップタイプLEDの筐体内に窒化ガリウム系半導体を用いたLEDチップをエポキシ樹脂などを用いて固定させてある。導電性ワイヤーとして金線103をLEDチップ102の各電極と筐体に設けられた各電極105とにそれぞれ電気的に接続させてある。緑色系のフォトルミネセンス蛍光体としてY3(A1, Ga)5O12:Ce蛍光体をまた赤色系のフォトルミネセンス蛍光体としてRE3A15O12:Ce蛍光体(但し、REは、Y, Gd, Laから選択される少なくとも一種である。)をアクリル樹脂中に混合分散させたものをLEDチップ、導電性ワイヤーなどを外部応力などから保護するモールド部材101として均一に硬化形成させる。このような発光装置に電力を供給させることによってLEDチップを発光させる。LEDチップからの青色系の発光と、その発光によって励起された緑色系及び赤色系をそれぞれ高輝度に発光可能な2種類以上のフォトルミネセンス蛍光体からの発光光との混色により白色系などが発光可能な発光装置の一例である発光ダイオードとすることができる。以下、木願発明の構成部材について詳述する。

[0018]

(蛍光体)

本願発明に用いられるフォトルミネセンス蛍光体としては、半導体発光層から発光された可視光や紫外線で励起されて発光するフォトルミネセンス蛍光体をいう。フォトルミネセンス蛍光体として赤色系が高輝度に発光可能な蛍光体と緑色系が高輝度に発光可能な蛍光体とを用いる。具体的なフォトルミネセンス蛍光体としては、赤色系がRE $_3$ Al $_5$ O $_1$ 2: Ce蛍光体(但し、REは、Y, Gd, Laから選択される少なくとも一種)であり、緑色系がY $_3$ (Al, Ga) $_5$ O $_1$ 2: Ce蛍光体である。窒化ガリウム系化合物半導体を用いたLEDチップから発光

した青色系の光と、ボディーカラーが黄色であるフォトルミネセンス蛍光体から発光する緑色系及び赤色系の光と、を混色表示させると白色系の発光色表示を行うことができる。発光装置はこの混色を起こさせるためにフォトルミネセンス蛍光体の粉体やバルクを樹脂や硝子中に含有させLEDチップからの光が透過する程度に薄く形成させたドット状のものや層状ものなど用途に応じて種々用いることができる。フォトルミネセンス蛍光体と樹脂などとの比率や塗布、充填量を種々調整すること及び発光素子の発光波長を選択することにより白色を含め電球色など任意の色調を提供させることができる。

[0019]

このような、フォトルミネセンス蛍光体の分布は、フォトルミネセンス蛍光体を含有する部材、形成温度、粘度やフォトルミネセンス蛍光体の形状、粒度分布などを調整させることによって種々形成させることができる。したがって、使用条件などにより蛍光体の分布濃度を、種々選択することができる。

[0020]

本願発明のフォトルミネセンス蛍光体を使用すると、放射照度として(Ee) $=3W\cdot c\ m^{-2}$ 以上 $10W\cdot c\ m^{-2}$ 以下のLEDチップと接する或いは近接して配置された場合においても高効率に十分な耐光性を有する発光装置とすることができる。

[0021]

本願発明に用いられる緑色系が発光可能な第1のフォトルミネセンス蛍光体は、ガーネット構造のため、熱、光及び水分に強く、図4 (A)の実線の例の如く励起スペクトルのピークが450nm付近にさせることができる。また、発光ピークも図4 (B)の実線の例の如く510nm付近にあり700nmまで裾を引くブロードな発光スペクトルを持つ。一方、赤色系が発光可能な第2のフォトルミネセンス蛍光体も、ガーネット構造であり熱、光及び水分に強く、図4 (A)の波線の例の如く励起スペクトルのピークが450nm付近にさせることができる。また、発光ピークも図4 (B)の波線の例の如く600nm付近にあり750nmまで裾を引くブロードな発光スペクトルを持つ。

[0022]

ガーネット構造を持ったYAG蛍光体の組成の内、A1の一部をGaで置換することで発光波長が短波長にシフトし、また組成のYの一部をGd及び/又はLaで置換することで、発光波長が短波長へシフトする。A1のGaへの置換は、発光効率と発光波長を考慮してGa:A1=1:1から4:6が好ましい。同様に、Yの一部をGd及び/又はLaで置換することは、Y:Gd及び/又はLa=9:1から1:9であり、より好ましくは、Y:Gd及び/又はLa=2:3から1:4である。置換が6割未満では、緑色成分が大きく赤色成分が少なくなる。また、8割以上では、赤み成分が増えるものの輝度が急激に低下する。

[0023]

[0024]

(LEDfy7102, 202, 302)

本願発明に用いられるLEDチップとは、第1及び第2のフォトルミネセンス 蛍光体をそれぞれ効率良く励起できる窒化物系化合物半導体が挙げられる。発光 素子であるLEDチップは、MOCVD法等により基板上にInGaN等の半導 体を発光層として形成させる。半導体の構造としては、MIS接合、PIN接合 やPN接合などを有するホモ構造、ヘテロ構造あるいはダブルヘテロ構成のもの が挙げられる。半導体層の材料やその混晶度によって発光波長を種々選択するこ とができる。また、半導体活性層を量子効果が生ずる薄膜に形成させた単一量子 井戸構造や多重量子井戸構造とすることもできる。

[0025]

窒化ガリウム系化合物半導体を使用した場合、半導体基板にはサファイヤ、スピネル、SiC、Si、ZnO等の材料が用いられる。結晶性の良い窒化ガリウムを形成させるためにはサファイヤ基板を用いることが好ましい。このサファイヤ基板上にGaN、AlN等のバッファー層を形成しその上にPN接合を有する窒化ガリウム系半導体を形成させる。窒化ガリウム系半導体は、不純物をドープしない状態でN型導電性を示す。発光効率を向上させるなど所望のN型窒化ガリウム半導体を形成させる場合は、N型ドーパントとしてSi、Ge、Se、Te、C等を適宜導入することが好ましい。一方、P型窒化ガリウム半導体を形成させる場合は、P型ドーパンドであるZn、Mg、Be、Ca、Sr、Ba等をドープさせる。窒化ガリウム系化合物半導体は、P型ドーパントをドープしただけではP型化しにくいためP型ドーパント導入後に、低電子線照射させたり、プラズマ照射等によりアニールすることでP型化させることが好ましい。エッチングなどによりP型半導体及びN型半導体の露出面を形成させた後、半導体層上にスパッタリング法や真空蒸着法などを用いて所望の形状の各電極を形成させる。

[0026]

次に、形成された半導体ウエハー等をダイヤモンド製の刃先を有するブレードが回転するダイシングソーにより直接フルカットするか、又は刃先幅よりも広い幅の溝を切り込んだ後(ハーフカット)、外力によって半導体ウエハーを割る。あるいは、先端のダイヤモンド針が往復直線運動するスクライバーにより半導体ウエハーに極めて細いスクライブライン(経線)を例えば碁盤目状に引いた後、外力によってウエハーを割り半導体ウエハーからチップ状にカットする。このようにして窒化ガリウム系化合物半導体であるLEDチップを形成させることができる。

[0027]

本願発明の発光ダイオードにおいて白色系を発光させる場合は、フォトルミネセンス蛍光体との混色等を考慮して発光素子の主発光波長は400nm以上530nm以下内にあることが好ましく、420nm以上490nm以下内にあることがより好ましい。LEDチップとフォトルミネセンス蛍光体との効率をそれぞれより向上させるためには、450nm以上475nm以下内にあることがさら

に好ましい。

[0028]

(導電性ワイヤー103、303)

導電性ワイヤーとしては、LEDチップ102、302の電極とのオーミック性、機械的接続性、電気伝導性及び熱伝導性がよいものが求められる。熱伝導度としては0.01ca1/cm²/cm/℃以上が好ましく、より好ましくは0.5ca1/cm²/cm/℃以上である。また、作業性などを考慮して導電性ワイヤーの直径は、好ましくは、Φ10μm以上、Φ45μm以下である。このような導電性ワイヤーとして具体的には、金、銅、白金、アルミニウム等の金属及びそれらの合金を用いた導電性ワイヤーが挙げられる。このような導電性ワイヤーは、各LEDチップの電極と、インナー・リード306及びマウント・リード305などと、をワイヤーボンディング機器によって容易に接続させることができる。

[0029]

(マウント・リード305)

マウント・リード305としては、LEDチップ302を配置させるものであり、ダイボンド機器などでLEDチップ302を積載するのに十分な大きさがあれば良い。また、LEDチップを複数設置しマウント・リードをLEDチップの共通電極として利用する場合においては、十分な電気伝導性とボンディングワイヤー等との接続性が求められる。また、マウント・リード上のカップ内にLEDチップを配置すると共に蛍光体を内部に允填させる場合は、近接して配置させた別の発光ダイオードからの光により疑似点灯することを防止させることができる

[0030]

LEDチップ302とマウント・リード305のカップとの接着は熱硬化性樹脂などによって行うことができる。具体的には、エポキシ樹脂、アクリル樹脂やイミド樹脂などが挙げられる。また、フェースダウンLEDチップなどによりマウント・リードと接着させると共に電気的に接続させるためにはAgペースト、カーボンペースト、金属バンプ等を用いることができる。

[0031]

さらに、発光ダイオードの光利用効率を向上させるためにLEDチップ302が配置されるマウント・リードの表面を鏡面状とし、表面に反射機能を持たせても良い。この場合の表面粗さは、0.1 S以上0.8 S以下が好ましい。また、マウント・リードの具体的な電気抵抗としては3 O O μ Ω - c m以下が好ましく、より好ましくは、3 μ Ω - c m以下である。

[0032]

また、マウント・リード上に複数のLEDチップを積置する場合は、LEDチップからの発熱量が多くなるため熱伝導度がよいことが求められる。具体的には、 $0.01ca1/cm^2/cm/^{\mathbb{C}}$ 以上が好ましく、より好ましくは $0.5ca1/cm^2/cm/^{\mathbb{C}}$ 以上である。これらの条件を満たす材料としては、鉄、銅、鉄入り銅、錫入り銅、メタライズパターン付きセラミック等が挙げられる。

[0033]

(インナー・リード306)

インナー・リード306としては、マウント・リード305上に配置されたLEDチップと接続された導電性ワイヤーとの接続を図るものである。マウント・リード上に複数のLEDチップ302を設けた場合は、各導電性ワイヤー同士が接触しにくい構成とすることが好ましい。

[0034]

具体的には、マウント・リード305から離れるに従って、インナー・リード306のワイヤーボンディングさせる端面の面積を大きくすることなどによってマウント・リードからより離れたインナー・リードと接続させる導電性ワイヤーの接触を防ぐことができる。

[0035]

また、導電性ワイヤーとの接続端面の粗さは、密着性を考慮して1.6 S以上10 S以下が好ましい。インナー・リードの先端部を種々の形状に形成させるためには、あらかじめリードフレームの形状を型枠で決めて打ち抜き形成させてもよく、或いは全てのインナー・リードを形成させた後にインナー・リード上部の一部を削ることによって形成させても良い。さらには、インナ・リードを打ち抜

き形成後、端面方向から加圧することにより所望の端面の面積と端面高さを同時に形成させることもできる。

[0036]

[0037]

(コーティング部材301)

本願発明に用いられるコーティング部材301とは、モールド部材304とは別にマウント・リード305のカップに設けられるものでありLEDチップ302の発光を変換するフォトルミネセンス蛍光体が含有されるものである。コーティング部の具体的材料としては、エポキシ樹脂、ユリア樹脂、シリコーンやアクリル樹脂などの耐候性に優れた透明樹脂や硝子などが好適に用いられる。また、フォトルミネセンス蛍光体と共に拡散剤を含有させても良い。具体的な拡散剤としては、チタン酸バリウム、酸化チタン、酸化アルミニウム、酸化珪素等が好適に用いられる。

[0038]

(モールド部材101、210、304)

モールド部材は、発光装置の使用用途に応じてLEDチップ、導電性ワイヤー、フォトルミネセンス蛍光体が含有されたコーティング部材などを外部から保護するために設けることができる。モールド部材は、樹脂や硝子を用いて形成させることができる。モールド部材中にフォトルミネセンス蛍光体を含有させることによって視野角を増やすことができる。また、拡散剤を加えることによってLEDチップからの指向性を緩和させ視野角をさらに増やすこともできる。

[0039]

更に、モールド部材を所望の形状にすることによってLEDチップからの発光 を集束させたり拡散させたりするレンズ効果を持たせることができる。従って、 モールド部材は複数積層した構造でもよい。具体的には、凸レンズ形状、凹レンズ形状さらには、発光観測面から見て楕円形状やそれらを複数組み合わせた物である。

[0040]

モールド部材の具体的材料としては、主としてエポキシ樹脂、ユリア樹脂、シリコーン、アクリル樹脂などの耐候性に優れた透明樹脂や低融点硝子などが好適に用いられる。また、拡散剤としては、チタン酸バリウム、酸化チタン、酸化アルミニウム、酸化珪素等が好適に用いられる。フォトルミネセンス蛍光体はモールド部材中に含有させてもそれ以外のコーティング部などに含有させて用いてもよい。また、コーティング部をフォトルミネセンス蛍光体が含有された樹脂、モールド部材を硝子などとした異なる部材を用いて形成させても良い。この場合、生産性良くより水分などの影響が少ない発光ダイオードとすることができる。屈折率を考慮してモールド部材とコーティング部とを同じ部材を用いて形成させても良い。

[0041]

(面状光源)

本願発明の発光装置の一つである面状光源の場合、図2(A)の如く白色光を発光させるためには白色光を導光板によって面状とさせ方法と、図2(B)の如く面状に発光したLEDチップからの青色系光を白色光に変換させる方法がある

[0042]

白色光を導光板によって面状とさせる場合には、フォトルミネセンス蛍光体が含有された色変換層201を介して青色系が発光可能な発光ダイオード202と、導光板204と、を配置させた構成、或いはモールド部材中210などにフォトルミネセンス蛍光体を含有させ青色系が発光可能な窒化物半導体発光素子を有する発光ダイオード202と導光板204を光学的に接続させた構成をとることができる。

[0043]

他方、面状に発光したLEDチップ202からの青色系光を白色光に変換させ

る場合は、窒化物半導体を発光層に有する青色系が発光可能な発光ダイオード202と導光板204とを光学的に接続させた後、導光板204上の散乱シート206に含有させる。或いはバインダー樹脂と共に散乱シートに塗布などさせシート状に形成させる。さらには、導光板上にフォトルミネセンス蛍光体含有のバインダーをドット状に直接形成させる構成をとることができる。

[0044]

具体的には、絶縁層及び導電性パターンが形成されたコの字形状の金属基板203内などにLEDチップを固定する。LEDチップと導電性パターンとの電気的導通を取った後、エポキシ樹脂をLEDチップ202が積載された基板上に充填させアクリル性導光板204の端面と光学的に接続させる。導光板204の発光主面上には、フォトルミネセンス蛍光体をエポキシ樹脂中に混合撹拌し予め拡散シート上に均一塗布したシート部材201を積置させてある。この拡散シート部材206は、アクリル樹脂をベースに拡散剤として酸化アルミニウム、酸化珪素、酸化チタン、チタン酸バリウムの粒子などを含有させたエポキシ樹脂を塗布させた層と、フォトルミネセンス蛍光体を含有させた層とに分かれている。

[0045]

導光板の一方の主面上には、蛍現象防止のため白色散乱剤が含有されたフィルム状の反射部材207を配置させてあることが好ましい。同様に、導光板204の裏面側全面や発光ダイオードが配置されていない端面上にも反射部材205を設け発光光率を向上させてある。これにより、LCDのバックライトなどとして使用した場合においても十分な明るさを得られる面状光源とすることができる。液晶表示装置として利用する場合は、導光板の主面上に不示図の透光性導電性パターンが形成された硝子基板間に注入された液晶を介して配された偏光板により構成させることができる。以下、本願発明の実施例について説明するが、本願発明は具体的実施例のみに限定されるものではないことは言うまでもない。

[0046]

【実施例】

(実施例1)

発光素子として発光ピークが450nmのGaInN半導体を用いた。LED

チップは、洗浄させたサファイヤ基板上にTMG(トリメチルガリウム)ガス、TMA(トリメチルアルミニウム)ガス、窒素ガス及びドーパントガスをキャリアガスと共に流し、MOCVD法で窒化ガリウム系化合物半導体を成膜させることにより形成させた。ドーパントガスとして SiH_4 と Cp_2 Mgと、を切り替えることによってN型導電性を有する窒化ガリウム半導体とP型導電性を有する窒化ガリウム半導体を形成しPN接合を形成させた。(なお、P型半導体は、成膜後400℃以上でアニールさせてある。)

[0047]

エッチングによりPN各半導体表面を露出させた後、スパッタリングにより各電極をそれぞれ形成させた。こうして出来上がった半導体ウエハーをスクライブラインを引いた後、外力により分割させ発光素子としてLEDチップを形成させた。

[0048]

銀メッキした銅製リードフレームの先端にカップを有するマウント・リードに LEDチップをエポキシ樹脂でダイボンディングした。LEDチップの各電極と マウント・リード及びインナー・リードと、をそれぞれ金線でワイヤーボンディ ングし電気的導通を取った。

[0049]

モールド部材は、砲弾型の型枠の中にLEDチップが配置されたリードフレームを挿入し透光性エポシキ樹脂を混入後、150℃5時間にて硬化させ青色系発光ダイオードを形成させた。青色系発光ダイオードを端面が全て研磨されたアクリル性導光板の一端面に接続させた。アクリル板の片面及び側面は、白色反射部材としてチタン酸バリウムをアクリル系バインダー中に分散したものでスクリーン印刷及び硬化させるた。

[0050]

一方、フォトルミネセンス蛍光体は、緑色系及び赤色系をそれぞれ必要なY、Gd、Ce、Laの希土類元素を化学量論比で酸に溶解した溶解液を蓚酸で共沈させた。これを焼成して得られる共沈酸化物と、酸化アルミニウム、酸化ガリウムと混合して混合原料をそれぞれ得る。これにフラックスとしてフッ化アンモ

ニウムを混合して坩堝に詰め、空気中1400°Cの温度範囲で3時間焼成して 焼成品を得た。焼成品をそれぞれ水中でボールミルして、洗浄、分離、乾燥、最 後に篩を通して形成させた。

[0051]

形成された組成が Y_3 ($A_{10.6}$ Gao.4) $_5$ O12:Ceであり緑色系が発光可能な第1の蛍光体120重量部と同様の工程で形成され組成が($Y_{0.4}$ Gdo.6)3 A_{15} O12:Ceであり赤色系が発光可能な第2の蛍光体100重量部を、エポキシ樹脂100重量部とよく混合してスリラーとさせた。このスリラーを厚さ0.5 mmのアクリル層上にマルチコーターを用いて均等に塗布、乾燥し、厚さ約30 μ mの色変換層として蛍光体層を形成させた。蛍光体層を導光板の主発光面と同じ大きさに切断し導光板上に配置させることにより発光装置を形成させた。発光装置の色度点、色温度、演色性指数を測定した。それぞれ、色度点(x=0.29, y=0.34)、色温度7000K、Ra(演色性指数)=80と三波長型蛍光灯に近い性能を示した。また、発光光率は12m/wと白色電球並であった。さらに耐侯試験として室温60mA通電、室温20mA通電、60℃90%RH下で20mA通電の各試験においても蛍光体に起因する変化は観測されなかった。

[0052]

(比較例1)

第1及び第2のフォトルミネセンス蛍光体をそれぞれペリレン系誘導体である緑色有機蛍光顔料(シンロイヒ化学製FA-001)と赤色有機蛍光顔料(シンロイヒ化学製FA-005)として同量で混合撹拌した以外は、実施例1と同様にして発光ダイオードの形成及び耐侯試験を行った。形成された発光ダイオードの色度座標は、(X,Y)=(0.34,0.35)であった。耐侯性試験として、カーボンアークで紫外線量を200hrで太陽光の1年分とほぼ同等とさせ時間と共に輝度の保持率及び色調を測定した。また、信頼性試験としてLEDチップを発光させ70℃一定における時間と共に発光輝度及び色調を測定した。この結果を実施例1と共に図6及び図7にそれぞれ示す。

[0053]

(実施例2)

発光素子として発光ピークが450nmのGaInN半導体を用いた。LEDチップは、洗浄させたサファイヤ基板上にTMG(トリメチルガリウム)ガス、TMA(トリメチルアルミニウム)ガス、窒素ガス及びドーパントガスをキャリアガスと共に流し、MOCVD法で窒化ガリウム系化合物半導体を成膜させることにより形成させた。ドーパントガスとして SiH_4 と Cp_2 Mgと、を切り替えることによってN型導電性を有する窒化ガリウム半導体とP型導電性を有する窒化ガリウム半導体とP型導電性を有する窒化ガリウム半導体とP型導電性を有する窒化ガリウム半導体を形成しPN接合を形成させた。(なお、P型半導体は、成膜後400C以上でアニールさせてある。)

[0054]

エッチングによりPN各半導体表面を露出させた後、スパッタリングにより各電極をそれぞれ形成させた。こうして出来上がった半導体ウエハーをスクライブラインを引いた後、外力により分割させ発光素子としてLEDチップを形成させた。

[0055]

銀メッキした銅製リードフレームの先端にカップを有するマウント・リードに LEDチップをエポキシ樹脂でダイボンディングした。LEDチップの各電極と マウント・リード及びインナー・リードと、をそれぞれ金線でワイヤーボンディ ングし電気的導通を取った。

[0056]

一方、フォトルミネセンス蛍光体は、緑色系及び赤色系をそれぞれ必要なY、Gd、Ceの希土類元素を化学量論比で酸に溶解した溶解液を蓚酸で共沈させた。これを焼成して得られる共沈酸化物と、酸化アルミニウム、酸化ガリウムと混合して混合原料をそれぞれ得る。これにフラックスとしてフッ化アンモニウムを混合して坩堝に詰め、空気中1400°Cの温度範囲で3時間焼成してそれぞれ焼成品を得た。焼成品を水中でボールミルして、洗浄、分離、乾燥、最後に篩を通して形成させた。

[0057]

形成された組成が Y_3 (Alo, $5Ga_{0,5}$) $5O_{1,2}$:Ceであり緑色系が発光可能

な第1の蛍光体と(Y_{0.2}Gd_{0.8})3A1₅O1₂: Ceであり赤色系が発光可能な第2の蛍光体をそれぞれ40重量部、エポキシ樹脂100重量部をよく混合してスリラーとさせた。このスリラーをLEDチップが配置されたマウント・リード上のカップ内に注入させた。注入後、フォトルミネセンス蛍光体が含有された樹脂を130℃1時間で硬化させた。こうしてLEDチップ上に厚さ120μのフォトルミネセンス蛍光体が含有されたコーティング部材が形成された。なお、コーティング部材には、LEDチップに向かってフォトルミネセンス蛍光体が徐々に多くしてある。その後、さらにLEDチップやフォトルミネセンス蛍光体を外部応力、水分及び塵芥などから保護する目的でモールド部材として透光性エポキシ樹脂を形成させた。モールド部材は、砲弾型の型枠の中にフォトルミネセンス蛍光体のコーティング部が形成されたリードフレームを挿入し透光性エポシキ樹脂を混入後、150℃5時間にて硬化させた。こうして形成された発光ダイオードは、発光観測正面から視認するとフォトルミネセンス蛍光体のボディーカラーにより中央部が黄色っぽく着色していた。

[0058]

こうして得られた白色系が発光可能な発光ダイオードの色度点、色温度、演色性指数を測定した。それぞれ、色度点(x=0. 32, y=0. 34)、色温度 6000 K、R a(演色性指数)=72、発光光率は101 m/wであった。 さらに耐侯試験として室温60 m A 通電、室温20 m A 通電、60 C90 % R H 下で20 m A 通電の各試験においてもフォトルミネセンス蛍光体に起因する変化は観測されず通常の青色系発光ダイオードと寿命特性に差がないことが確認できた。

[0059]

【発明の効果】

本願発明の構成とすることにより高出力の窒化物系化合物半導体の発光素子と、赤色系及び緑色系が発光可能なフォトルミネセンス蛍光体と、を利用した発光装置とすることにより長時間高輝度時の使用においても発光効率が高い発光ダイオードとすることができる。さらに、信頼性や省電力化、小型化さらには色温度の可変性など車載や航空産業、一般電気機器に港内のブイ表示用や高速道路の標

識照明など屋外での表示や照明として新たな用途を開くことができる。また、白色は人間の目で長時間視認する場合には刺激が少なく目に優しい発光ダイオードとすることができる。

[0060]

特に、本願発明の請求項1に記載の構成とすることにより長時間の使用においても色ずれ、発光光率の低下が極めて少なく高輝度にRGBの発光成分を有する白色系が発光可能な発光装置とすることができる。

[0061]

本願発明の請求項2に記載の構成とすることにより長時間の使用においても色ずれ、発光光率の低下が極めて少なくより白昼色に近い光が発光可能な発光装置とすることができる。

[0062]

本願発明の請求項3に記載の構成とすることにより長時間の使用においても色ずれ、発光光率の低下が極めて少なく白色系の光を面状に発光させることができる。

[0063]

本願発明の請求項4に記載の構成とすることにより長時間の使用においても色ずれ、発光光率の低下が極めて少なく白色系の光をより均一に面状に発光させることができる。

[0064]

本願発明の請求項5に記載の構成とすることにより外部環境下においても長時間の使用においても色ずれ、発光光率の低下が極めて少なく高輝度にRGBの発光成分を有する白色系が発光可能な発光ダイオードとすることができる。

[0065]

【図面の簡単な説明】

【図1】

図1は、本願発明の発光装置の模式的断面図である。

【図2】

図2は、本願発明の他の発光装置である面状光源の模式的断面図を示し、(A

)は、導光板と発光ダイオードとの間にフォトルミネセンス蛍光体を有する面状 光源であり、(B)は、導光板の主面上にフォトルミネセンス蛍光体を有する面 状光源である。

【図3】

図3は、本願発明の他の発光装置である発光ダイオードの模式的断面図である

【図4】

図4 (A) は、本願発明に用いられる第1及び第2のフォトルミネセンス蛍光体の吸収スペクトルの一例を示し、図5 (B) は、本願発明に使用される第1及び第2のフォトルミネセンス蛍光体の発光スペクトルの一例を示した図である。

【図5】

図5は、本願発明に用いられる発光素子の発光スペクトル例を示した図である

【図6】

図6は、本願発明と、比較のために示した発光装置との耐候性試験における結果を示し(A)は輝度保持率と時間との関係、(B)は色調と時間との関係を示したグラフである。

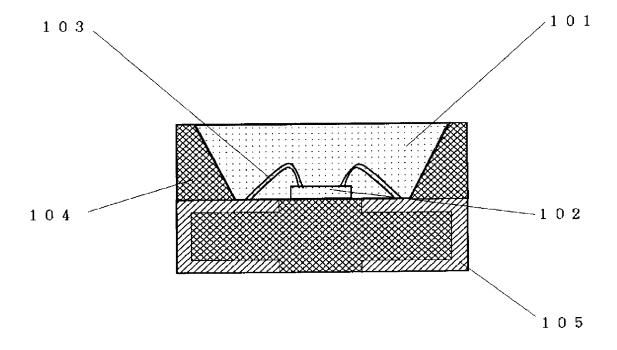
【図7】

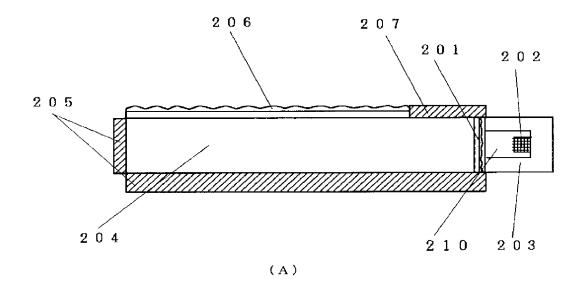
図7は、本願発明と、比較のために示した発光装置との信頼性試験における結果を示し(A)は輝度保持率と時間との関係、(B)は色調と時間との関係を示したグラフである。

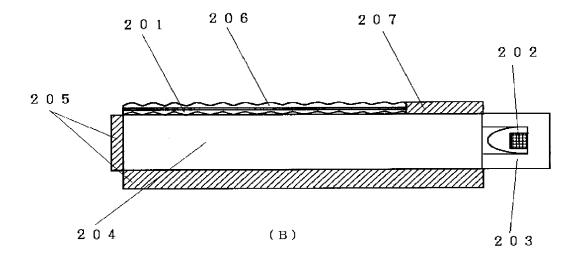
【符号の説明】

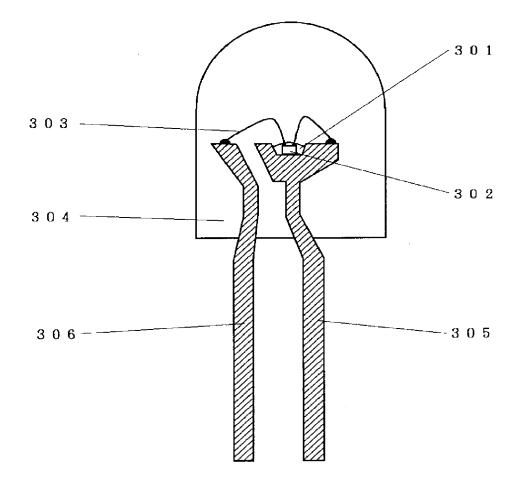
- 101、210・・・フォトルミネセンス蛍光体が含有されたモールド部材
- 102、202、302・・・LEDチップ
- 103、303・・・導電性ワイヤー
- 104・・・ 筐体
- 105・・・外部電極
- 201・・・色変換層
- 203. . . . 基板

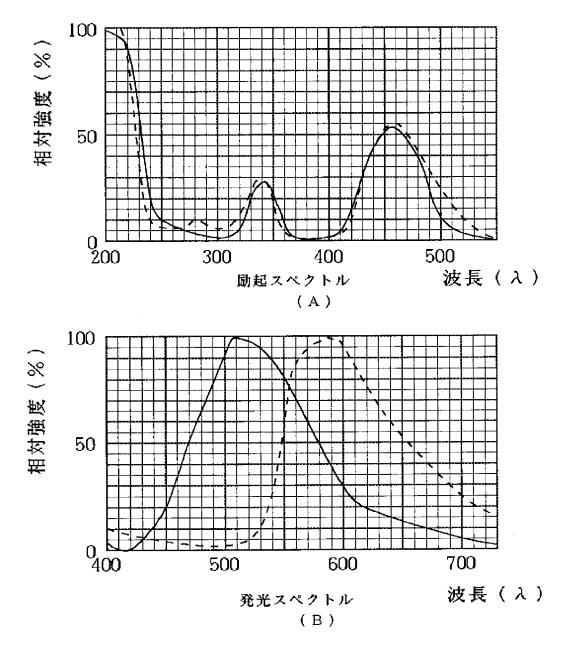
- 204・・・導光板
- 205、207・・・反射部材
- 206・・・散乱シート
- 301・・・フォトルミネセンス蛍光体が含有されたコーティング部材
- 304・・・モールド部材
- 305・・・マウント・リード
- 306・・・インナー・リード

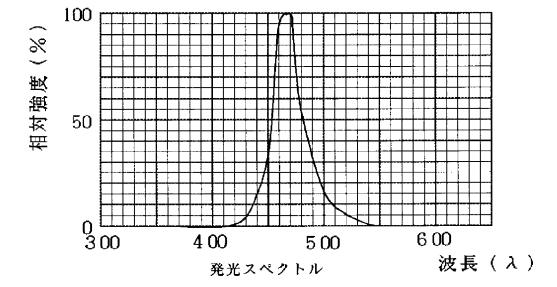




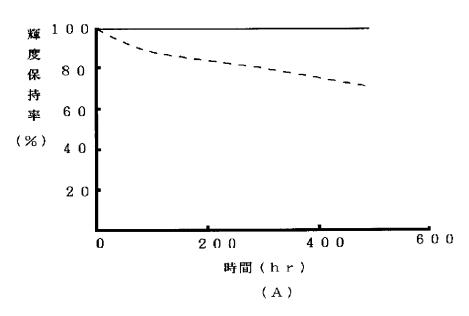


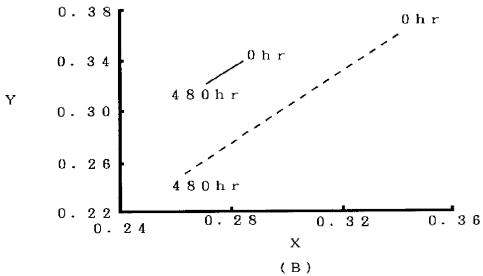




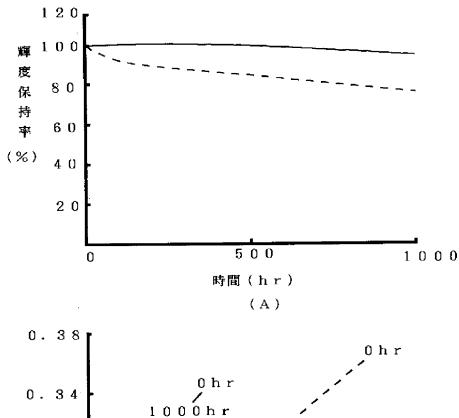


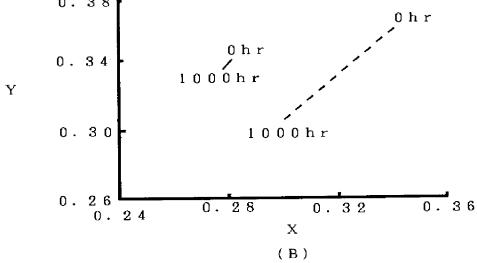












【書類名】 要約書

【課題】

本願発明は、使用環境によらず高輝度、高効率にRGB(赤、緑、青色系)成分が発光可能な発光装置を提供することにある。

【解決手段】

本願発明は、発光層が窒化ガリウム系化合物半導体であるLEDチップと、該LEDチップからの発光の少なくとも一部を吸収し波長変換して発光するフォトルミネセンス蛍光体と、を有する発光装置であって、前記LEDチップの主発光ピークが400nmから530nm内であると共に、前記フォトルミネセンス蛍光体が Y_3 (A_1 , G_a) $_5$ O $_1$ 2: C_e である第1の蛍光体と、 RE_3A_1 5O $_1$ 2: C_e であって第1の蛍光体の主発光波長よりも長波長側に主発光波長がある第2の蛍光体とである発光装置である。(但し、REは、Y, G_d , L_a から選択される少なくとも一種)

【選択図】図1

【書類名】 職権訂正データ

【訂正書類】 特許願

<認定情報・付加情報>

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【書類名】手続補正書

【提出日】平成8年11月25日

【あて先】特許庁長官 荒井 寿光 殿

【事件の表示】

【出願番号】平成 8年特許願第244339号

【補正をする者】

【事件との関係】特許出願人

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【電話番号】0884-22-2311

【発送番号】032481

【手続補正 1】

【補正対象書類名】明細書

【補正対象項目名】図面の簡単な説明

【補止方法】変更

【補正の内容】1

【プルーフの要否】要

【図面の簡単な説明】

【図1】

図1は、本願発明の発光装置の模式的断面図である。

【図2】

図2は、本願発明の他の発光装置である面状光源の模式的断面図を示し、(A)は、導光板と発光ダイオードとの間にフォトルミネセンス蛍光体を有する面状光源であり、(B)は、導光板の主面上にフォトルミネセンス蛍光体を有する面状光源である。

【図3】

図3は、本願発明の他の発光装置である発光ダイオードの模式的断面図である

【図4】

図4 (A)は、本願発明に用いられる第1及び第2のフォトルミネセンス蛍光体の吸収スペクトルの一例を示し、<u>図4 (B)</u>は、本願発明に使用される第1及び第2のフォトルミネセンス蛍光体の発光スペクトルの一例を示した図である。

【図5】

図5は、本願発明に用いられる発光素子の発光スペクトル例を示した図である

【図6】

図6は、本願発明と、比較のために示した発光装置との耐候性試験における結果を示し(A)は輝度保持率と時間との関係、(B)は色調と時間との関係を示したグラフである。

【図7】

図7は、本願発明と、比較のために示した発光装置との信頼性試験における結果を示し(A)は輝度保持率と時間との関係、(B)は色調と時間との関係を示したグラフである。

【書類名】 職権訂正データ

【訂正書類】 手続補正書

<認定情報・付加情報>

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出願人履歴

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新規登録

徳島県阿南市上中町岡491番地100 日亜化学工業株式会社

JAPAN PATENT OFFICE

別紙添付の書類に記載されている事項は下記の出願書類に記載されている事項と同一であることを証明する。

This is to certify that the annexed is a true copy of the following application as filed with this Office.

出願年月日 Date of Application:

1996年 9月18日

出

8年特許願第245381号 Application Number:

パリ条約による外国への出願 に用いる優先権の主張の基礎 となる出願の国コードと出願 番号

The country code and number of your priority application, to be used for filing abroad under the Paris Convention, is JP1996-245381

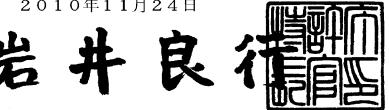
願 出 人

Applicant(s):

口亜化学工業株式会社

2010年11月24日

特許庁長官 Commissioner, Japan Patent Office



【書類名】特許願

【整理番号】P96ST13-2

【提出日】平成8年9月18日

【あて先】特許庁長官 荒川 寿光 殿

【国際特許分類】

H01L 33/00

【発明の名称】発光ダイオード及びそれを用いた表示装置

【請求項の数】 4

【発明者】

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【代表者】小川 英治

【電話番号】0884-22-2311

【先の出願に基づく優先権の主張】

【出願番号】平成8年特許願第198585号

【出願日】平成8年7月29日

【手数料の表示】

【予納台帳番号】010526

【納付金額】21,000

【提出物件の目録】

【物件名】明細書 1

【物件名】図面 1

【物件名】要約書 1

【プルーフの要否】要

【書類名】 明細書

【発明の名称】 発光ダイオード及びそれを用いた表示装置

【特許請求の範囲】

【請求項1】

発光層が窒化ガリウム系化合物半導体であるLEDチップと、該LEDチップ からの発光の少なくとも一部を吸収し波長変換して発光するフォトルミネセンス 蛍光体と、を有する発光ダイオードであって、

前記LEDチップの発光スペクトルの主ピークが400nmから530nm内の発光波長を有すると共に、前記フォトルミネセンス蛍光体がRE $_3$ (A1, Ga) $_5O_{12}$:Ceであることを特徴とする発光ダイオード。

但し、REは、Y, Gd, Smから選択される少なくとも一種である。

【請求項2】

マウント・リードのカップ内に配置させたLEDチップと、該LEDチップと 導電性ワイヤーを用いて電気的に接続させたインナー・リードと、前記カップ内 に充填させたコーティング部材と、該コーティング部材、LEDチップ、導電性 ワイヤー及びマウント・リードとインナー・リードの少なくとも一部を被覆する モールド部材と、を有する発光ダイオードであって、

前記LEDチップが窒化ガリウム系化合物半導体であり、且つ前記コーティング部材がRE $_3$ (A $_1$,G $_a$) $_5$ O $_1$ $_2$:C $_e$ フォトルミネセンス蛍光体を有する透光性樹脂であることを特徴とする発光ダイオード。

但し、REは、Y、Gd、Smから選択される少なくとも一種である。

【請求項3】

前記フォトルミネセンス蛍光体の組成が次の一般式で示されることを特徴とする請求項1又は請求項2記載の発光ダイオード。

 $(Y_{1-p-q-r}Gd_pCe_qSm_r)_3 (Al_{1-s}Ga_s)_5O_{12}$ 但し、 $0 \le p \le 0.8$

0. $003 \le q \le 0.2$

0. $0003 \le r \le 0.08$

 $0 \le s \le 1$

【請求項4】

請求項2記載の発光ダイオードをマトリックス状に配置したLED表示器と、 該LED表示器と電気的に接続させた駆動回路と、を有するLED表示装置。

【発明の詳細な説明】

[0001]

【産業上の利用分野】

本願発明は、LEDディスプレイ、バックライト光源、信号機、照光式スイッチ及び各種インジケータなどに利用される発光ダイオードに係わり、特に発光素子であるLEDチップからの発光を変換して発光させるフォトルミネセンス蛍光体を有し使用環境によらず高輝度、高効率な発光装置である発光ダイオード及びそれを用いた表示装置に関する。

[0002]

【従来技術】

発光ダイオード(以下、LEDともいう)は、小型で効率が良く鮮やかな色の発光をする。また、半導体素子であるため球切れなどの心配がない。初期駆動特性が優れ、振動やON/OFF点灯の繰り返しに強いという特徴を有する。そのため各種インジケータや種々の光源として利用されている。最近、超高輝度高効率な発光ダイオードとしてRGB(赤、緑、青色)などの発光ダイオードがそれぞれ開発された。これに伴いRGBの三原色を利用したLEDディスプレイが省電力、長寿命、軽量などの特長を生かして飛躍的に発展を遂げつつある。

[0003]

発光ダイオードは使用される発光層の半導体材料、形成条件などによって紫外から赤外まで種々の発光波長を放出させることが可能である。また、優れた単色性ピーク波長を有する。

[0004]

しかしながら、発光ダイオードは優れた単色性ピーク波長を有するが故に白色 系発光光源などとさせるためには、RGBなどが発光可能な各LEDチップをそれぞれ近接して発光させ拡散混色させる必要がある。このような発光ダイオードは、種々の色を自由に発光させる発光装置としては有効であるが、白色系などの 色のみを発光させる場合においても赤色系、緑色系及び青色系の発光ダイオード、或いは青緑色系及び黄色系の発光ダイオードをそれぞれ使用せざるを得ない。 LEDチップは、半導体であり色調や輝度のバラツキもまだ相当ある。また、半 導体発光素子であるLEDチップがそれぞれ異なる材料を用いて形成されている 場合、各LEDチップの駆動電力などが異なり個々に電源を確保する必要がある 。そのため、各半導体ごとに電流などを調節して白色系を発光させなければなら ない。同様に、半導体発光素子であるため個々の温度特性の差や経時変化が異な り、色調が種々変化してしまう。さらに、LEDチップからの発光を均一に混色 させなければ色むらを生ずる場合がある。

[0005]

そこで、本出願人は先にLEDチップの発光色を蛍光体で色変換させた発光ダイオードとして特開平5-152609号公報、特開平7-99345号公報などに記載された発光ダイオードを開発した。これらの発光ダイオードによって、1種類のLEDチップを用いて白色系など他の発光色を発光させることができる

[0006]

具体的には、発光層のエネルギーバンドギャップが大きいLEDチップをリードフレームの先端に設けられたカップ上などに配置する。LEDチップは、LEDチップが設けられたメタルステムやメタルポストとそれぞれ電気的に接続させる。そして、LEDチップを被覆する樹脂モールド部材中などにLEDチップからの光を吸収し波長変換する蛍光体を含有させて形成させてある。

[0007]

LEDチップからの発光を波長変換した発光ダイオードとして、青色系の発光 ダイオードの発光と、その発光を吸収し黄色系を発光する蛍光体からの発光との 混色により白色系が発光可能な発光ダイオードなどとすることができる。これら の発光ダイオードは、白色系を発光する発光ダイオードとして利用した場合にお いても十分な輝度を発光する発光ダイオードとすることができる。

[8000]

【発明が解決する課題】

発光ダイオードによって励起される蛍光体は、蛍光染料、蛍光顔料さらには有機、無機化合物などから様々なものが挙げられる。また、蛍光体は、発光素子からの発光波長を波長の短いものから長い波長へと変換する、或いは発光素子からの発光波長を波長の長いものから短い波長へと変換するものとがある。

[0009]

しかしながら、波長の長いものから短い波長へと変換する場合、変換効率が極 めて悪く実用に向かない。また、LEDチップ周辺に近接して配置された蛍光体 は、太陽光よりも約30倍から40倍にも及ぶ強照射強度の光線にさらされる。 特に、発光素子であるLEDチップを高エネルギーバンドギャップを有する半導 体を用い蛍光体の変換効率向上や蛍光体の使用量を減らした場合においては、L EDチップから発光した光が可視光域にあるといっても光エネルギーが必然的に 高くなる。この場合、発光強度を更に高め長期に渡って使用すると、蛍光体自体 が劣化しやすい。蛍光体が劣化すると色調がずれる、或いは蛍光体が黒ずみ光の 外部取り出し効率が低下する場合がある。同様にLEDチップの近傍に設けられ た蛍光体は、LEDチップの昇温や外部環境からの加熱など高温にもさらされる 。さらに、発光ダイオードは、一般的に樹脂モールドに被覆されてはいるものの 外部環境からの水分の進入などを完全に防ぐことや製造時に付着した水分を完全 に除去することはできない。蛍光体によっては、このような水分が発光素了から の高エネルギー光や熱によって蛍光体物質の劣化を促進する場合もある。また、 イオン性の有機染料に至ってはチップ近傍では直流電界により電気泳動を起こし 、色調が変化する可能性がある。したがって、本願発明は上記課題を解決し、よ り高輝度、長時間の使用環境下においても発光光率の低下や色ずれの極めて少な い発光ダイオードを提供することを目的とする。

[0010]

【課題を解決するための手段】

本願発明は、発光層が窒化ガリウム系化合物半導体であるLEDチップと、該 LEDチップからの発光の少なくとも一部を吸収し波長変換して発光するフォトルミネセンス蛍光体と、を有する発光ダイオードであって、前記LEDチップの 発光スペクトルの主ピークが400 n mから530 n m内の発光波長を有すると 共に、前記フォトルミネセンス蛍光体が RE_3 (Al, Ga) $_5O_{12}$:Ceである。但し、REは、Y, Gd, Smから選択される少なくとも一種である。

[0011]

また、マウント・リードのカップ内に配置させたLEDチップと、該LEDチップと導電性ワイヤーを用いて電気的に接続させたインナー・リードと、前記カップ内に充填させたコーティング部材と、該コーティング部材、LEDチップ、導電性ワイヤー及びマウント・リードとインナー・リードの少なくとも一部を被覆するモールド部材と、を有する発光ダイオードであって、前記LEDチップが窒化ガリウム系化合物半導体であり、且つ前記コーティング部材がRE $_3$ (A1, $Ga)_5O_{12}$:Ceフォトルミネセンス蛍光体を有する透光性樹脂でもある。但し、REは、Y,Gd,Smから選択される少なくとも一種である。

[0012]

さらに、前記フォトルミネセンス蛍光体の組成が次の一般式で示される発光ダイオードでもある。 $(Y_{1-p-q-r}Gd_pCe_qSm_r)_3(Al_{1-s}Ga_s)_5O_{12}$ 但 し、 $0\le p\le 0$. 8、0.003 $\le q\le 0$.2、0.0003 $\le r\le 0$.08、 $0\le s\le 1$

[0013]

また、請求項2記載の発光ダイオードをマトリックス状に配置したLED表示器と、該LED表示器と電気的に接続させた駆動回路と、を有するLED表示装置である。

[0014]

【発明の実施の形態】

本願発明者は、種々の実験の結果、可視光域における光エネルギーが比較的高いLEDチップからの発光光をフォトルミネセンス蛍光体によって色変換させる発光ダイオードにおいて、特定の半導体及び蛍光体を選択することにより高輝度、長時間の使用時における光効率低下や色ずれを防止できることを見出し本願発明を成すに至った。

[0015]

即ち、発光ダイオードに用いられるフォトルミネセンス蛍光体としては、

1. 耐光性に優れていることが要求される。特に、半導体発光素子などの微小領域から強放射されるために太陽光の約30倍から40倍にもおよぶ強照射強度にも十分耐える必要がある。2. 発光素子との混色を利用するため紫外線ではなく青色系発光で効率よく発光すること。3. 混色を考慮して緑色系から赤色系の光が発光可能なこと。4. 発光素子近傍に配置されるため温度特性が良好であること。5. 色調が組成比或いは複数の蛍光体の混合比で連続的に変えられること。6. 発光ダイオードの利用環境に応じて耐候性があることなどの特徴を有することが求められる。

[0016]

これらの条件を満たすものとして本願発明は、発光素子として発光層に高エネルギーバンドギャップを有する窒化ガリウム系化合物半導体素子を、フォトルミネセンス蛍光体としてRE3(A1,Ga)5O12:Ce蛍光体を用いる。これにより発光素子から放出された可視光域における高エネルギー光を長時間近傍で高輝度に照射した場合であっても発光色の色ずれや発光輝度の低下が極めて少ない発光ダイオードとすることができるものである。

[0017]

具体的な発光ダイオードの一例として、チップタイプLEDを図2に示す。チップタイプLEDの筐体204内に窒化ガリウム系半導体を用いたLEDチップ202をエポキシ樹脂などを用いて固定させてある。導電性ワイヤー203として金線をLEDチップ202の各電極と筐体に設けられた各電極205とにそれぞれ電気的に接続させてある。RE3(A1,Ga)5〇12:Ce蛍光体をエポキシ樹脂中に混合分散させたものをLEDチップ、導電性ワイヤーなどを外部応力などから保護するモールド部材201として均一に硬化形成させる。このような発光ダイオードに電力を供給させることによってLEDチップ202を発光させる。LEDチップ202からの発光と、その発光によって励起されたフォトルミネセンス蛍光体からの発光光との混色により白色系などが発光可能な発光ダイオードとすることができる。以下、本願発明の構成部材について詳述する。

[0018]

(蛍光体)

本願発明に用いられるフォトルミネセンス蛍光体としては、半導体発光層から 発光された可視光及び紫外線で励起されて発光するフォトルミネセンス蛍光体を いう。具体的なフォトルミネセンス蛍光体としては、RE3(A1, Ga)₅ O_{12} : C e (但し、R E は、Y, G d, S m から選択される少なくとも一種) である 。窒化ガリウム系化合物半導体を用いたLEDチップから発光した光と、ボディ ーカラーが黄色でありフォトルミネセンス蛍光体から発光する光が補色関係など にある場合、LEDチップからの発光と、フォトルミネセンス蛍光体からの発光 と、を混色表示させると白色系の発光色表示を行うことができる。そのため発光 ダイオード外部には、LEDチップからの発光とフォトルミネセンス蛍光体から の発光とがモールド部材を透過する必要がある。したがって、フォトルミネセン ス蛍光体のバルク層内などにLEDチップを閉じこめ、フォトルミネセンス蛍光 体層にLEDチップからの光が透過する開口部を1乃至2以上有する構成の発光 ダイオードとしても良い。また、フォトルミネセンス蛍光体の粉体を樹脂や硝子 中に含有させLEDチップからの光が透過する程度に薄く形成させても良い。フ オトルミネセンス蛍光体と樹脂などとの比率や塗布、充填量を種々調整すること 及び発光素子の発光波長を選択することにより自色を含め電球色など任意の色調 を提供させることができる。

[0019]

さらに、フォトルミネセンス蛍光体の含有分布は、混色性や耐久性にも影響する。すなわち、フォトルミネセンス蛍光体が含有されたコーティング部やモールド部材の表面側からLEDチップに向かってフォトルミネセンス蛍光体の分布濃度が高い場合は、外部環境からの水分などの影響をより受けにくく水分による劣化を抑制しやすい。他方、フォトルミネセンス蛍光体の含有分布をLEDチップからモールド部材表面側に向かって分布濃度が高くなると外部環境からの水分の影響を受けやすいがLEDチップからの発熱、照射強度などの影響がより少なくフォトルミネセンス蛍光体の劣化を抑制することができる。このような、フォトルミネセンス蛍光体の分布は、フォトルミネセンス蛍光体を含有する部材、形成温度、粘度やフォトルミネセンス蛍光体の形状、粒度分布などを調整させることによって種々形成させることができる。したがって、使用条件などにより蛍光体

の分布濃度を、種々選択することができる。

[0020]

本願発明のフォトルミネセンス蛍光体は、特にLEDチップと接する或いは近接して配置され放射照度として(Ee)=3W・c m $^{-2}$ 以上1OW・c m $^{-2}$ 以下においても高効率に十分な耐光性有する発光ダイオードとすることができる。

[0021]

本願発明に用いられるフォトルミネセンス蛍光体は、ガーネット構造のため、熱、光及び水分に強く、励起スペクトルのピークが450nm付近にさせることができる。また、発光ピークも530nm付近にあり700nmまで裾を引くブロードな発光スペクトルを持つ。しかも、組成のA1の一部をGaで置換することで発光波長が短波長にシフトし、また組成のYの一部をGdで置換することで、発光波長が長波長へシフトする。このように組成を変化することで発光色を連続的に調節することが可能である。したがって、長波長側の強度がGdの組成比で連続的に変えられるなど窒化物半導体の青色系発光を白色系発光に変換するための理想条件を備えている。

[0022]

また、窒化ガリウム系半導体を用いたLEDチップと、セリウムで付活された イットリウム・アルミニウム・ガーネット蛍光体(YAG)に希土類元素のサマ リウム(Sm)を含有させたフォトルミネセンス蛍光体と、を有する発光ダイオ ードとすることによりさらに光効率を向上させることができる。

[0023]

このようなフォトルミネセンス蛍光体は、Y、Gd、Ce、Sm、A1及びGaの原料として酸化物、又は高温で容易に酸化物になる化合物を使用し、それらを化学量論比で十分に混合して原料を得る。又は、Y、Gd、Ce、Smの希土類元素を化学量論比で酸に溶解した溶解液を蓚酸で共沈したものを焼成して得られる共沈酸化物と、酸化アルミニウム、酸化ガリウムとを混合して混合原料を得る。これにフラックスとしてフッ化アンモニウム等のフッ化物を適量混合して坩堝に詰め、空気中1350~1450°Cの温度範囲で2~5時間焼成して焼成品を得、次に焼成品を水中でボールミルして、洗浄、分離、乾燥、最後に篩を通

すことで得ることができる。

[0024]

 $(Y_{1-p-q-r}Gd_pCe_qSm_r)_3A1_5O_{12}$ フォトルミネセンス蛍光体は、結晶中にGdを含有することにより、特に460nm以上の長波長域の励起発光効率を高くすることができる。ガドリニウムの含有量の増加により、発光ピーク波長が、530nmから570nmまで長波長に移動し、全体の発光波長も長波長側にシフトする。赤みの強い発光色が必要な場合、Gdの置換量を多くすることで達成できる。一方、Gdが増加すると共に、青色光によるフォトルミネセンスの発光輝度は徐々に低下する。したがって、pは0.8以下であることが好ましく、0.7以下であることがより好ましい。さらに好ましくは0.6以下である。

[0025]

Smを含有する($Y_{1-p-q-r}Gd_pCe_qSm_r$) $_3Al_5O_{12}$ 蛍光体は、Gd の含有量の増加に関わらず温度特性の低下が少ない。このようにS mを含有させることにより、高温度におけるフォトルミネセンス蛍光体の発光輝度は大幅に改善される。その改善される程度はGd の含有量が高くなるほど大きくなる。すなわち、Gd を増加してフォトルミネセンス蛍光体の発光色調に赤みを付与した組成ほどS mの含有による温度特性改善に効果的であることが分かった。(なお、ここでの温度特性とは、450 n mの青色光による常温(25° C)における励起発光輝度に対する、同蛍光体の高温(200° C)における発光輝度の相対値(%)で表している。)

[0026]

Smの含有量は $0.0003 \le r \le 0.08$ の範囲で温度特性が 6.0%以上となり好ましい。この範囲より r が小さいと、温度特性改良の効果が小さくなる。また、この範囲より r が大きくなると温度特性は逆に低下してくる。0.000 $7 \le r \le 0.02$ の範囲では温度特性は 8.0%以上となり最も好ましい。

[0027]

Ceは0.003 \leq q \leq 0.2の範囲で相対発光輝度が70%以上となる。qが0.003以下では、Ceによるフォトルミネセンスの励起発光中心の数が減少することで輝度低下し、逆に、0.2より大きくなると濃度消光が生ずる。

[0028]

本願発明の発光ダイオードにおいてこのようなフォトルミネセンス蛍光体は、 2種類以上のRE $_3$ (A $_1$,G $_a$) $_5$ O $_1$ 2:Ceフォトルミネセンス蛍光体を混合させてもよい。即ち、A $_1$ 、G $_a$ 、Y及びG $_d$ やS $_m$ の含有量が異なる2種類以上のRE $_3$ (A $_1$,G $_a$) $_5$ O $_1$ 2:Ceフォトルミネセンス蛍光体を混合させてRGBの波長成分を増やすことができる。これに、カラーフィルターを用いることによりフルカラー液晶表示装置用としても利用できる。

[0029]

(LEDfy7102, 202, 702)

本願発明に用いられるLEDチップとは、RE $_3$ (A $_1$,Ga) $_5$ O $_1$ 2:Ce蛍光体を効率良く励起できる窒化物系化合物半導体が挙げられる。発光素子であるLEDチップは、MOCVD法等により基板上にInGaN等の半導体を発光層として形成させる。半導体の構造としては、MIS接合、PIN接合やPN接合などを有するホモ構造、ヘテロ構造あるいはダブルヘテロ構成のものが挙げられる。半導体層の材料やその混晶度によって発光波長を種々選択することができる。また、半導体活性層を量子効果が生ずる薄膜に形成させた単一量子井戸構造や多重量子井戸構造とすることもできる。

[0030]

窒化ガリウム系化合物半導体を使用した場合、半導体基板にはサファイヤ、スピネル、SiC、Si、ZnO等の材料が用いられる。結晶性の良い窒化ガリウムを形成させるためにはサファイヤ基板を用いることが好ましい。このサファイヤ基板上にGaN、AlN等のバッファー層を形成しその上にPN接合を有する窒化ガリウム半導体を形成させる。窒化ガリウム系半導体は、不純物をドープしない状態でN型導電性を示す。発光効率を向上させるなど所望のN型窒化ガリウム半導体を形成させる場合は、N型ドーパントとしてSi、Ge、Se、Te、C等を適宜導入することが好ましい。一方、P型窒化ガリウム半導体を形成させる場合は、P型ドーパンドであるZn、Mg、Be、Ca、Sr、Ba等をドープさせる。窒化ガリウム系化合物半導体は、P型ドーパントをドープしただけではP型化しにくいためP型ドーパント導入後に、炉による加熱、低速電子線照射

やプラズマ照射等によりアニールすることでP型化させることが好ましい。エッチングなどによりP型半導体及びN型半導体の露出面を形成させた後、半導体層上にスパッタリング法や真空蒸着法などを用いて所望の形状の各電極を形成させる。

[0031]

次に、形成された半導体ウエハー等をダイヤモンド製の刃先を有するブレードが回転するダイシングソーにより直接フルカットするか、又は刃先幅よりも広い幅の溝を切り込んだ後(ハーフカット)、外力によって半導体ウエハーを割る。あるいは、先端のダイヤモンド針が往復直線運動するスクライバーにより半導体ウエハーに極めて細いスクライブライン(経線)を例えば碁盤目状に引いた後、外力によってウエハーを割り半導体ウエハーからチップ状にカットする。このようにして窒化ガリウム系化合物半導体であるLEDチップを形成させることができる。

[0032]

本願発明の発光ダイオードにおいて白色系を発光させる場合は、フォトルミネセンス蛍光体との補色関係や樹脂劣化等を考慮して発光素子の発光波長は400 nm以上530nm以下が好ましく、420nm以上490nm以下がより好ましい。LEDチップとフォトルミネセンス蛍光体との効率をそれぞれより向上させるためには、450nm以上475nm以下がさらに好ましい。本願発明の白色系発光ダイオードの発光スペクトルを図3に示す。450nm付近にピークを持つ発光がLEDチップからの発光であり、570nm付近にピークを持つ発光がLEDチップによって励起されたフォトルミネセンスの発光である。

[0033]

(導電性ワイヤー103、203)

導電性ワイヤー103、203としては、LEDチップ102、202の電極とのオーミック性、機械的接続性、電気伝導性及び熱伝導性がよいものが求められる。熱伝導度としては0.01cal/cm²/cm/ $^{\circ}$ C以上が好ましく、より好ましくは0.5cal/cm²/cm/ $^{\circ}$ C以上である。また、作業性などを考慮して導電性ワイヤーの直径は、好ましくは、 $^{\circ}$ 10 $^{\circ}$ m以上、 $^{\circ}$ 45 $^{\circ}$ m以

下である。このような導電性ワイヤーとして具体的には、金、銅、白金、アルミニウム等の金属及びそれらの合金を用いた導電性ワイヤーが挙げられる。このような導電性ワイヤーは、各LEDチップの電極と、インナー・リード及びマウント・リードなどと、をワイヤーボンディング機器によって容易に接続させることができる。

[0034]

(マウント・リード105)

マウント・リード105としては、LEDチップ102を配置させるものであり、ダイボンド機器などで積載するのに十分な大きさがあれば良い。また、LEDチップを複数設置しマウント・リードをLEDチップの共通電極として利用する場合においては、十分な電気伝導性とボンディングワイヤー等との接続性が求められる。また、マウント・リード上のカップ内にLEDチップを配置すると共に蛍光体を内部に充填させる場合は、近接して配置させた別の発光ダイオードからの光により疑似点灯することを防止することができる。

[0035]

LEDチップ102とマウント・リード105のカップとの接着は熱硬化性樹脂などによって行うことができる。具体的には、エポキシ樹脂、アクリル樹脂やイミド樹脂などが挙げられる。また、フェースダウンLEDチップなどによりマウント・リードと接着させると共に電気的に接続させるためにはAgベースト、カーボンペースト、金属バンプ等を用いることができる。さらに、発光ダイオードの光利用効率を向上させるためにLEDチップが配置されるマウント・リードの表面を鏡面状とし、表面に反射機能を持たせても良い。この場合の表面粗さは、0.1S以上0.8S以下が好ましい。また、マウント・リードの具体的な電気抵抗としては300μΩーcm以下が好ましく、より好ましくは、3μΩーcm以下である。また、マウント・リード上に複数のLEDチップを積置する場合は、LEDチップからの発熱量が多くなるため熱伝導度がよいことが求められる。具体的には、0.01ca1/cm²/cm/℃以上が好ましくより好ましくは 0.5ca1/cm²/cm/℃以上である。これらの条件を満たす材料としては、鉄、銅、鉄入り銅、錫入り銅、メタライズパターン付きセラミック等が挙

げられる。

[0036]

(インナー・リード106)

インナー・リード106としては、マウント・リード105上に配置されたLEDチップ102と接続された導電性ワイヤー103との接続を図るものである。マウント・リード上に複数のLEDチップを設けた場合は、各導電性ワイヤー同士が接触しないよう配置できる構成とする必要がある。具体的には、マウント・リードから離れるに従って、インナー・リードのワイヤーボンディングさせる端面の面積を大きくすることなどによってマウント・リードからより離れたインナー・リードと接続させる導電性ワイヤーの接触を防ぐことができる。導電性ワイヤーとの接続端面の粗さは、密着性を考慮して1.6S以上10S以下が好ましい。インナー・リードの先端部を種々の形状に形成させるためには、あらかじめリードフレームの形状を型枠で決めて打ち抜き形成させてもよく、或いは全てのインナー・リードを形成させた後にインナー・リード上部の一部を削ることによって形成させても良い。さらには、インナ・リードを打ち抜き形成後、端面方向から加圧することにより所望の端面の面積と端面高さを同時に形成させることもできる。

[0037]

インナー・リードは、導電性ワイヤーであるボンディングワイヤー等との接続性及び電気伝導性が良いことが求められる。具体的な電気抵抗としては、300 $\mu\Omega-c$ m以下が好ましく、より好ましくは $3\mu\Omega-c$ m以下である。これらの条件を満たす材料としては、鉄、銅、鉄入り銅、錫入り銅及び銅、金、銀をメッキしたアルミニウム、鉄、銅等が挙げられる。

[0038]

(コーティング部101)

本願発明に用いられるコーティング部101とは、モールド部材104とは別にマウント・リードのカップに設けられるものでありLEDチップの発光を変換するフォトルミネセンス蛍光体が含有されるものである。コーティング部の具体的材料としては、エポキシ樹脂、ユリア樹脂、シリコーンなどの耐候性に優れた

透明樹脂や硝子などが好適に用いられる。また、フォトルミネセンス蛍光体と共に拡散剤を含有させても良い。具体的な拡散剤としては、チタン酸バリウム、酸化チタン、酸化アルミニウム、酸化珪素等が好適に用いられる。

[0039]

(モールド部材104)

モールド部材104は、発光ダイオードの使用用途に応じてLEDチップ10 2、導電性ワイヤー103、フォトルミネセンス蛍光体が含有されたコーティン グ部101などを外部から保護するために設けることができる。モールド部材は 、一般には樹脂を用いて形成させることができる。また、フォトルミネセンス蛍 光体を含有させることによって視野角を増やすことができるが、樹脂モールドに 拡散剤を含有させることによってLEDチップ102からの指向性を緩和させ視 野角をさらに増やすことができる。更にまた、モールド部材104を所望の形状 にすることによってLEDチップからの発光を集束させたり拡散させたりするレ ンズ効果を持たせることができる。従って、モールド部材104は複数積層した 構造でもよい。具体的には、凸レンズ形状、凹レンズ形状さらには、発光観測面 から見て楕円形状やそれらを複数組み合わせた物である。モールド部材104の 具体的材料としては、主としてエポキシ樹脂、ユリア樹脂、シリコーンなどの耐 候性に優れた透明樹脂や硝子などが好適に用いられる。また、拡散剤としては、 チタン酸バリウム、酸化チタン、酸化アルミニウム、酸化珪素等が好適に用いら れる。さらに、拡散剤に加えてモールド部材中にもフォトルミネセンス蛍光体を 含有させることもできる。したがって、フォトルミネセンス蛍光体はモールド部 材中に含有させてもそれ以外のコーティング部などに含有させて用いてもよい。 また、コーティング部をフォトルミネセンス蛍光体が含有された樹脂、モールド 部材を硝子などとした異なる部材を用いて形成させても良い。この場合、生産性 良くより水分などの影響が少ない発光ダイオードとすることができる。また、屈 折率を考慮してモールド部材とコーティング部とを同じ部材を用いて形成させて も良い。

[0040]

(表示装置)

本願発明の発光ダイオードをLED表示器に利用した場合、RGBをそれぞれ発光する発光ダイオードの組み合わせだけによるLED表示器よりも、より高精細に白色系表示させることができる。すなわち、各発光ダイオードを組み合わせて白色系などを混色表示させるためにはRGBの各発光ダイオードをそれぞれ同時に発光せざるを得ない。そのため赤色系、緑色系、青色系のそれぞれ単色表示した場合に比べて一画素あたりの表示が大きくなる。したがって、白色系の表示の場合においてはRGB単色表示と比較して高精細に表示させることができない。また、白色系の表示は各発光ダイオードを調節して表示させるため各半導体の温度特性などを考慮し種々調整しなければならない。さらに、混色による表示であるが故にLED表示器の視認する方向や角度によって、RGBの発光ダイオードをRGBの発光ダイオードに加えて利用することにより、より高精細化が可能となると共に白色系の発光が安定し色むらをなくすこともできる。また、RGBの各発光ダイオードともに発光させることにより輝度を向上させることもできる。

[0041]

本願発明の発光ダイオードを用いて表示装置の1つとして、RGBの各発光ダイオードに加えて白色系発光ダイオードを1絵素として利用し、標識やマトリクス状など任意の形状に配置させたLED表示器の概略構成を示す。LED表示器は、駆動回路である点灯回路などと電気的に接続させる。駆動回路からの出力パルスによって種々の画像が表示可能なデイスプレイ等とすることができる。駆動回路としては、入力される表示データを一時的に記憶させるRAM(Random、Access、Memory)と、RAMに記憶されるデータから各発光ダイオードを所定の明るさに点灯させるための階調信号を演算する階調制御回路と、階調制御回路の出力信号でスイッチングされて、各発光ダイオードを点灯させるドライバーとを備える。階調制御回路は、RAMに記憶されるデータから発光ダイオードの点灯時間を演算してパルス信号を出力する。ここで、白色系の表示を行う場合は、RGB各発光ダイオードのパルス信号を短くする、パルス高を低くする或いは全く点灯させない。他方、それを補償するように白色系発光ダイオードにパルス信号を出力する。これにより、LED表示器の白色を表示する。

[0042]

したがって、白色系発光ダイオードを所望の輝度で点灯させるためのパルス信号を演算する階調制御回路としてCPUを別途備えることが好ましい。階調制御回路から出力されるパルス信号は、白色系発光ダイオードのドライバーに入力されてドライバをスイッチングさせる。ドライバーがオンになると白色系発光ダイオードが点灯され、オフになると消灯される。

[0043]

また、本願発明の発光ダイオードを用いた別のLED表示器を示す。本願発明の白色系発光ダイオードのみを用い白黒用のLED表示装置とすることもできる。白黒用のLED表示器は、本願発明の発光ダイオード501のみをマトリックス状などに配置し構成することができる。RGBのそれぞれの駆動回路の代わりに白色発光可能な本願発明の発光ダイオード用駆動回路のみとしてLED表示器を構成させることができる。LED表示器は、駆動回路である点灯回路などと電気的に接続させる。駆動回路からの出力パルスによって種々の画像が表示可能なデイスプレイ等とすることができる。駆動回路としては、入力される表示データを一時的に記憶させるRAM(Random、Access、Memory)と、RAMに記憶されるデータから発光ダイオードを所定の明るさに点灯させるための階調信号を演算する階調制御回路と、階調制御回路の出力信号でスイッチングされて、発光ダイオードを点灯させるドライバーとを備える。階調制御回路は、RAMに記憶されるデータから発光ダイオードの点灯時間を演算してパルス信号を出力する。

[0044]

したがって、白黒用のLED表示器はRGBのフルカラー表示器と異なり当然 回路構成を簡略化できると共に高精細化できる。そのため、安価にRGBの発光 ダイオードの特性に伴う色むらなどのないディスプレイとすることができるもの である。また、従来の赤色、緑色のみを用いたLED表示器に比べ人間の目に対 する刺激が少なく長時間の使用に適している。

[0045]

(信号機)

本願発明の発光ダイオードを表示装置の1種である信号機として利用した場合 、長時間安定して発光させることが可能であると共に発光ダイオードの一部が消 灯しても色むらなどが生じないという特徴がある。本願発明の発光ダイオードを 用いた信号機の概略構成として、導電性パターンが形成された基板上に白色系発 光ダイオードを配置させる。このような発光ダイオードを直列又は直並列に接続 された発光ダイオードの回路を発光ダイオード群として扱う。発光ダイオード群 を2つ以上用いそれぞれ渦巻き状に発光ダイオードを配置させる。全ての発光ダ イオードが配置されると円状に全面に配置される。各発光ダイオード及び基板か ら外部電力と接続させる電源コードをそれぞれ、ハンダにより接続させた後、鉄 道用信号用の筐体内に固定させる。LED表示器は、遮光部材が付いたアルミダ イキャストの筐体内に配置され表面にシリコーンゴムの充填材で封止されている 。筐体の表示面は、白色レンズを設けてある。また、LED表示器の電気的配線 は、筐体の裏面からゴムパッキンを通し筐体内を密閉する。これにより白色系信 号機を形成することができる。本願発明の発光ダイオードを、複数の群に分け中 心部から外側に向け輪を描く渦巻き状などに配置し、並列接続させることでより 信頼性が高い信号機とさせることができる。中心部から外側に向け輪を描くとは 連続的に輪を描くものも断続的に配置するものをも含む。したがって、LED表 示器の表示面積などにより配置される発光ダイオードの数や発光ダイオード群の 数を種々選択することができる。この信号機により、一方の発光ダイオード群や 一部の発光ダイオードが何らかのトラブルにより消灯したとしても他方の発光ダ イオード群や残った発光ダイオードにより信号機を円形状に均一に発光させるこ とが可能となるものである。また、色ずれが生ずることもない。渦巻き状に配置 してあることから中心部を密に配置することができ電球発光の信号と何ら違和感 なく駆動させることができる。

[0046]

(面状発光光源)

本願発明の発光ダイオードを用いて図7の如く面状発光光源を構成することができる。面状発光光源の場合、フォトルミネセンス蛍光体をコーティング部や導 光板上の散乱シート706に含有させる。或いはバインダー樹脂と共に散乱シー ト706に塗布などさせシート状701に形成しモールド部材を省略しても良い。具体的には、絶縁層及び導電性パターンが形成されたコの字形状の金属基板703内にLEDチップ702を固定する。LEDチップと導電性パターンとの電気的導通を取った後、フォトルミネセンス蛍光体をエポキシ樹脂と混合撹拌しLEDチップ702が積載された基板703上に充填させ発光ダイオードを形成させる。こうして形成された発光ダイオードは、アクリル性導光板704の端面にエポキシ樹脂などで固定される。導光板704の一方の主面上には、蛍現象防止のため白色散乱剤が含有されたフィルム状の反射部材707を配置させてある。同様に、導光板の裏面側全面や発光ダイオードが配置されていない端面上にも反射部材705を設け発光光率を向上させてある。これにより、LCDのバックライトとして十分な明るさを得られる面状発光光源とすることができる。液晶表示装置として利用する場合は、導光板704の主面上に不示図の透光性導電性パターンが形成された硝子基板間に注入された液晶装置を介して配された偏光板により構成させることができる。以下、本願発明の実施例について説明するが、本願発明は具体的実施例のみに限定されるものではないことは言うまでもない。

[0047]

【実施例】

(実施例1)

発光素子として発光ピークが450nmのGaInN半導体を用いた。LEDチップは、洗浄させたサファイヤ基板上にTMG(トリメチルガリウム)ガス、TMA(トリメチルアルミニウム)ガス、窒素ガス及びドーパントガスをキャリアガスと共に流し、MOCVD法で窒化ガリウム系化合物半導体を成膜させることにより形成させた。ドーパントガスとして SiH_4 と Cp_2 Mgと、を切り替えることによってN型導電性を有する窒化ガリウム半導体とP型導電性を有する窒化ガリウム半導体を形成しPN接合を形成させた。(なお、P型半導体は、成膜後400C以上でアニールさせてある。)

[0048]

エッチングによりPN各半導体表面を露出させた後、スパッタリングにより各電極をそれぞれ形成させた。こうして出来上がった半導体ウエハーをスクライブ

ラインを引いた後、外力により分割させ発光素子としてLEDチップを形成させた。

[0049]

銀メッキした銅製リードフレームの先端にカップを有するマウント・リードに LEDチップをエポキシ樹脂でダイボンディングした。LEDチップの各電極と マウント・リード及びインナー・リードと、をそれぞれ金線でワイヤーボンディ ングし電気的導涌を取った。

[0050]

一方、フォトルミネセンス蛍光体は、Y、Gd、Ceの希土類元素を化学量論 比で酸に溶解した溶解液を蓚酸で共沈させた。これを焼成して得られる共沈酸化 物と、酸化アルミニウム、酸化ガリウムと混合して混合原料を得る。これにフラ ックスとしてフッ化アンモニウムを混合して坩堝に詰め、空気中1400°Cの 温度で3時間焼成して焼成品を得た。焼成品を水中でボールミルして、洗浄、分 離、乾燥、最後に篩を通して形成させた。

[0051]

形成された(Y_{0.8}Gd_{0.2})₃Al₅O₁₂: Ce蛍光体80重量部、エポキシ樹脂100重量部をよく混合してスリラーとさせた。このスリラーをLEDチップが配置されたマウント・リード上のカップ内に注人させた。注人後、フォトルミネセンス蛍光体が含有された樹脂を130℃1時間で硬化させた。こうしてLEDチップ上に厚さ120μのフォトルミネセンス蛍光体が含有されたコーティング部が形成された。なお、コーティング部には、LEDチップに向かってフォトルミネセンス蛍光体が徐々に多くしてある。その後、さらにLEDチップやフォトルミネセンス蛍光体を外部応力、水分及び磨芥などから保護する目的でモールド部材として透光性エポキシ樹脂を形成させた。モールド部材は、砲弾型の型枠の中にフォトルミネセンス蛍光体のコーティング部が形成されたリードフレームを挿入し透光性エポシキ樹脂を混入後、150℃5時間にて硬化させた。こうして形成された発光ダイオードは、発光観測正面から視認するとフォトルミネセンス蛍光体のボディーカラーにより中央部が黄色っぽく着色していた。

[0052]

こうして得られた白色系が発光可能な発光ダイオードの色度点、色温度、演色性指数を測定した。それぞれ、色度点(x=0. 302、y=0. 280)、色温度 8080 K、R a(演色性指数)= 87. 5 と三波長型蛍光灯に近い性能を示した。また、発光光率は 9. 51 m/w と白色電球並であった。さらに寿命試験として温度 25 $\mathbb{C}60$ m A 通電、温度 25 $\mathbb{C}20$ m A 通電、温度 60 $\mathbb{C}90$ % R H 下で 20 m A 通電の各試験においても蛍光体に起因する変化は観測されず通常の青色発光ダイオードと寿命特性に差がないことが確認できた。

[0053]

(比較例1)

フォトルミネセンス蛍光体を($Y_{0.8}Gd_{0.2}$) $_3Al_5O_{12}$:Ceから(ZnCd)S:Cu、Alとした以外は、実施例 $_1$ と同様にして発光ダイオードの形成及び寿命試験を行った。形成された発光ダイオードは通電直後、実施例 $_1$ と同様白色系の発光が確信されたが輝度が低かった。また、寿命試験においては、約 $_1$ 00時間で出力がゼロになった。劣化原因を解析した結果、蛍光体が黒化していた。

[0054]

これは、発光素子の発光光と蛍光体に付着していた水分或いは外部環境から進入した水分により光分解し蛍光体結晶表面にコロイド状亜鉛金属を析出し外観が 黒色に変色したものと考えられる。温度25℃20mA通電、温度60℃90% RH下で20mA通電の寿命試験結果を実施例1と共に図8に示す。輝度は初期 値を基準にしそれぞれの相対値を示す。また、実線が実施例1であり波線が比較 例1を示す。

[0055]

(実施例2)

LEDチップの窒化物系化合物半導体を実施例 1 よりも 1 n の含有量を増やし発光ピークを 4 6 0 n m とした。同様にフォトルミネセンス蛍光体として実施例 1 よりも G d の含有量を増やし(Y 0 . 6 G d 0 . 4) 3 A 1 5 O 1 2 : C e とした以外は実施例 1 と同様にして発光ダイオードを 1 O 0 個形成し寿命試験を行った。

[0056]

こうして得られた白色系が発光可能な発光ダイオードの色度点、色温度、演色性指数を測定した。それぞれ、色度点(x=0. 375、y=0. 370)、色温度4400K、Ra(演色性指数)=86.0であった。さらに寿命試験においては、形成させた発光ダイオード100個平均で行った。寿命試験前の光度を100%とし1000時間経過後における平均光度を調べた。寿命試験後も98.8%であり特性に差がないことが確認できた。

[0057]

(実施例3)

[0058]

(実施例4)

本願発明の発光ダイオードを図5の如くLED表示器の1つであるディスプレイに利用した。実施例1と同様にして形成させた発光ダイオードを銅パターンを形成させたセラミックス基板上に、16×16のマトリックス状に配置させた。基板と発光ダイオードとは自動ハンダ実装装置を用いてハンダ付けを行った。次にフェノール樹脂によって形成された筐体504内部に配置し固定させた。遮光部材505は、筐体と一体成形させてある。発光ダイオードの先端部を除いて筐体、発光ダイオード、基板及び遮光部材の一部をピグメントにより黒色に着色したシリコンゴム406によって充填させた。その後、常温、72時間でシリコンゴムを硬化させLED表示器を形成させた。このLED表示器と、入力される表示データを一時的に記憶させるRAM(Random、Access、Memory)及びRAMに記憶されるデータから発光ダイオードを所定の明るさに点灯させるための階調信号を演算する階調制御回路と階調制御回路の出力信号でスイッチングされて発光ダイオードを点灯させるドライバーとを備えたCPUの駆動手段と、を電気的に接続させてLED表示装置を構成した。LED表示器を駆動

させ白黒LED表示装置として駆動できることを確認した。

[0059]

【発明の効果】

本願発明の構成とすることにより高出力の窒化物系化合物半導体の発光素子と、RE $_3$ (A $_1$,G $_a$) $_5$ O $_{12}$:Ce蛍光体と、を利用した発光ダイオードとすることにより長時間高輝度時の使用においても発光効率が高い発光ダイオードとすることができる。さらに、信頼性や省電力化、小型化さらには色温度の可変性など車載や航空産業、 般電気機器に表示の他に照明として新たな用途を開くことができる。また、白色は人間の目で長時間視認する場合には刺激が少なく目に優しい発光ダイオードとすることができる。

[0060]

特に、本願発明の請求項1に記載の構成とすることにより高輝度、長時間の使用においても色ずれ、発光光率の低下が極めて少ない白色系が発光可能な発光ダイオードなど種々の発光ダイオードとすることができる。また、樹脂劣化に伴う輝度の低下も抑制させることができる。

[0061]

本願発明の請求項2の構成とすることにより、高輝度、長時間の使用においても色ずれ、発光光率の低下が極めて少ない発光ダイオードなど種々の発光ダイオードとすることができることに加えて、発光ダイオードを複数近接して配置した場合においても他方の発光ダイオードからの光により蛍光体が励起され疑似点灯されることを防止させることができる。また、LEDチップ自体の発光むらを蛍光体により分散することができるためより均一な発光光を有する発光ダイオードとすることができる。

[0062]

本願発明の請求項3の構成とすることにより、より温度依存性の少ない発光ダイオードとすることができる。

[0063]

本願発明の請求項4の構成とすることにより、比較的安価で高精細なLED表示装置や視認角度によって色むらの少ないLED表示装置とすることができる。

[0064]

【図面の簡単な説明】

【図1】

図1は、本願発明の発光ダイオードの模式的断面図である。

【図2】

図2は、本願発明の他の発光ダイオードの模式的断面図である。

【図3】

図3は、本願発明の発光ダイオードの発光スペクトルの一例を示した図である

【図4】

図4 (A)は、本願発明に使用されるフォトルミネセンス蛍光体の吸収スペクトルの一例を示し、図4 (B)は、本願発明に使用されるフォトルミネセンス蛍光体の発光スペクトルの一例を示した図である。

【図5】

図5は、本願発明の発光ダイオードを用いたLED表示装置の模式図である。

【図6】

図6は、図5に用いられるLED表示装置のブロック図である。

【図7】

図7は、本願発明の発光ダイオードを用いた別のLED表示装置の模式図である。

【図8】

図8(A)は、本願発明の実施例1と比較のために示した比較例1の発光ダイオードとの温度25 \mathbb{C} 20 \mathbb{C} A 通電における寿命試験を示し、図8(B)は、本願発明の実施例1と比較のために示した比較例1の発光ダイオードとの温度60 \mathbb{C} 90 \mathbb{C} RH下で20 \mathbb{C} A 通電における寿命試験を示したグラフである。

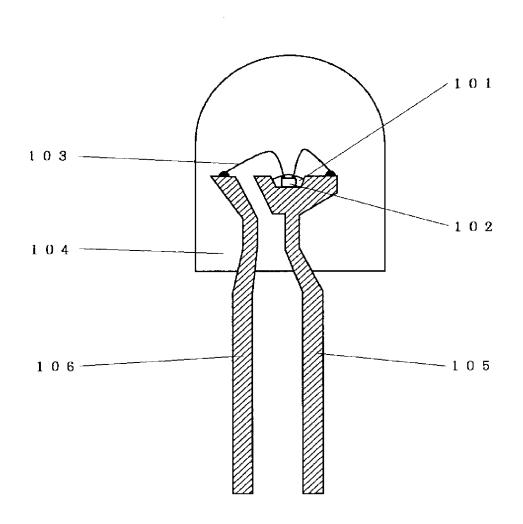
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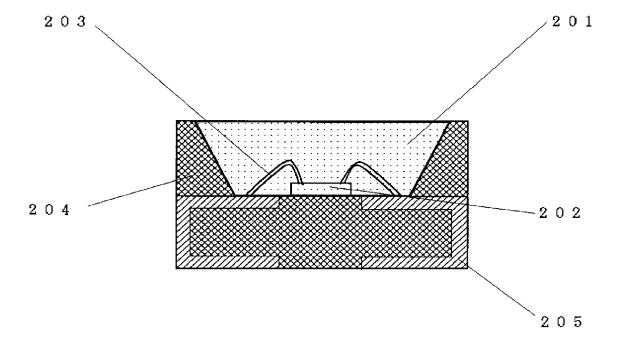
101、701・・・フォトルミネセンスが含有されたコーティング部

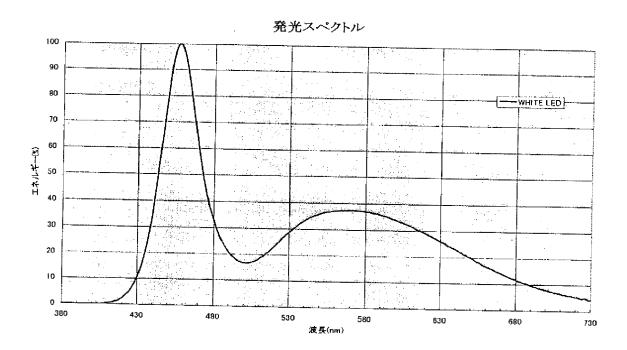
102、202、702・・・LEDチップ

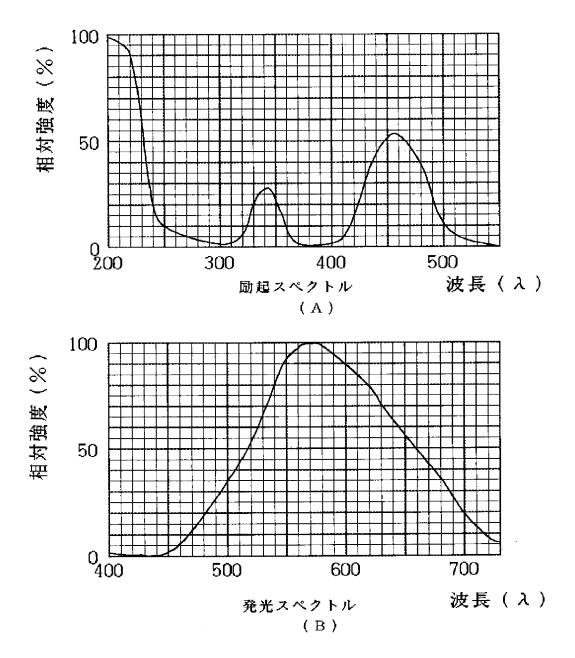
103、203・・・導電性ワイヤー

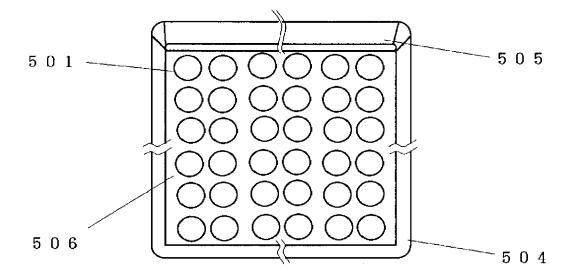
- 104・・・モールド部材
- 105・・・マウント・リード
- 106・・・インナー・リード
- 201・・・フォトルミネセンスが含有されたモールド部材
- 204・・・筐体
- 205・・・筐体に設けられた電極
- 501・・・発光ダイオード
- 504・・・筐体
- 505・・・遮光部材
- 506・・・充填材
- 703・・・金属製基板
- 704・・・導光板
- 705、707・・・反射部材
- 706・・・散乱シート

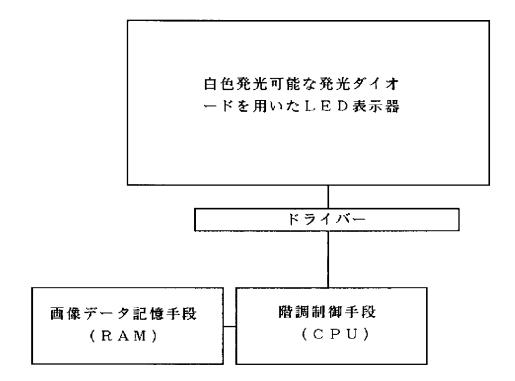


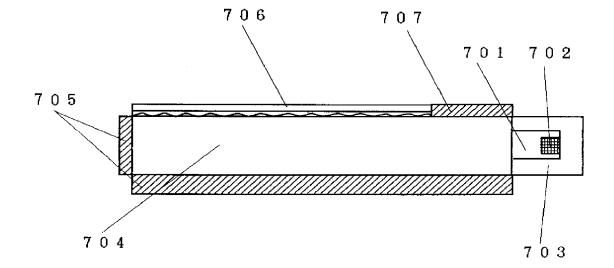


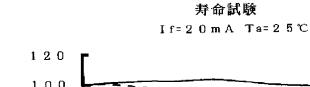


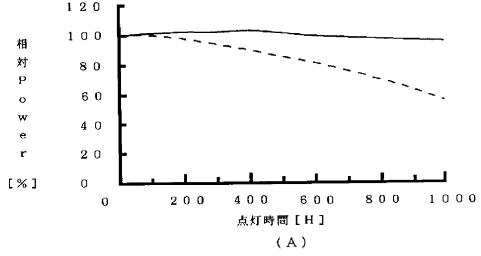


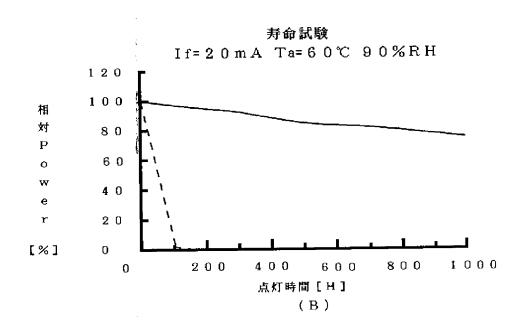












【書類名】 要約書

【課題】

本願発明は、LEDチップからの発光を変換して発光させるフォトルミネセンス蛍光体を有し使用環境によらず高輝度、高効率に発光可能な発光ダイオード及びそれを用いた表示装置に関する。

【解決手段】

本願発明は、発光層が窒化ガリウム系化合物半導体であるLEDチップと、該LEDチップからの発光の少なくとも一部を吸収し波長変換して発光するフォトルミネセンス蛍光体と、を有する発光ダイオードであって、前記LEDチップの発光スペクトルの主ピークが400nmから530nm内の発光波長を有すると共に、前記フォトルミネセンス蛍光体がRE $_3$ (A $_1$,G $_4$) $_5$ O $_1$ 2:Ceである発光ダイオード。但し、REは、Y,G $_4$,S $_5$ 0 $_4$ 2:Ceであるである。

【選択図】図1

【書類名】 職権訂正データ

【訂正書類】 特許願

<認定情報・付加情報>

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JAPAN PATENT OFFICE

別紙添付の書類に記載されている事項は下記の出願書類に記載されている事項と同一であることを証明する。

This is to certify that the annexed is a true copy of the following application as filed with this Office.

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1996年12月27日

出

Application Number:

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The country code and number of your priority application, to be used for filing abroad under the Paris Convention, is JP1996-359004

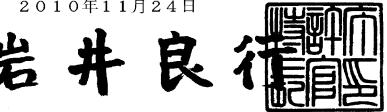
願 出 人

Applicant(s):

口亜化学工業株式会社

2010年11月24日

特許庁長官 Commissioner, Japan Patent Office



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【あて先】特許庁長官 荒井 寿光 殿

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H01L 33/00

【発明の名称】発光ダイオード及びそれを用いた表示装置

【請求項の数】 7

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【出願日】平成 8年 9月18日

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【予納台帳番号】015141

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【物件名】明細書 1

【物件名】図面 1

【物件名】要約書 1

【包括委任状番号】9007362

【書類名】 明細書

【発明の名称】 発光ダイオード及びそれを用いた表示装置【特許請求の範囲】

【請求項1】 LEDチップと、該LEDチップからの発光の少なくとも一部を吸収し波長変換して発光するフォトルミネセンス蛍光体とを有する発光ダイオードにおいて、

前記LEDチップが窒化物系化合物半導体で、前記フォトルミネセンス蛍光体がセリウムで付活されたイットリウム・アルミニウム・ガーネット系蛍光体であることを特徴とする発光ダイオード。

【請求項2】 前記窒化物系化合物半導体であるLEDチップの発光スペクトルの主ピークが400nmから530nm内の発光波長を有する請求項1に記載される発光ダイオード。

【請求項3】 LEDチップと、該LEDチップからの発光の少なくとも一部を吸収し波長変換して発光するフォトルミネセンス蛍光体とを有する発光ダイオードにおいて、

前記LEDチップが窒化ガリウム系化合物半導体で、前記フォトルミネセンス 蛍光体が(RE $_{1-x}$ Sm $_x$) $_3$ (Al $_y$ Ga $_{1-y}$) $_5$ O $_{12}$:Ce蛍光体であることを特徴とする発光ダイオード。

ただし、 $0 \le x < 1$ 、 $0 \le y \le 1$ 、REは、Y、Gdから選択される少なくとも一種である。

【請求項4】 前記窒化ガリウム系化合物半導体であるLEDチップの発光 スペクトルの主ピークが400nmから530nm内の発光波長を有する請求項 3に記載される発光ダイオード。

【請求項5】 マウント・リードのカップ内に配置させたLEDチップと、該LEDチップと導電性ワイヤーを用いて電気的に接続させたインナー・リードと、前記カップ内に充填させたコーティング部材と、該コーティング部材、LEDチップ、導電性ワイヤー及びマウント・リードとインナー・リードの少なくとも一部を被覆するモールド部材と、を有する発光ダイオードであって、

前記LEDチップが窒化ガリウム系化合物半導体であり、かつ前記コーティン

グ部材が(RE $_{1-x}$ Sm $_x$) $_3$ (Al $_y$ Ga $_{1-y}$) $_5$ O $_{12}$:Ce蛍光体を有する透光性 樹脂であることを特徴とする発光ダイオード。

ただし、 $0 \le x < 1$ 、 $0 \le y \le 1$ 、REは、Y、Gdから選択される少なくとも一種である。

【請求項6】 前記フォトルミネセンス蛍光体の組成が次の一般式で示されることを特徴とする請求項1、請求項3又は請求項5記載の発光ダイオード。

$$(Y_{1-p-q-r}Gd_pCe_qSm_r)_3$$
 (Al_{1-s}Ga_s) 5O₁₂
ただし、 0≤p≤0. 8

0. $003 \le q \le 0.2$

0. $0003 \le r \le 0.08$

 $0 \le s \le 1$

【請求項7】 請求項5記載の発光ダイオードをマトリックス状に配置した LED表示器と、該LED表示器と電気的に接続させた駆動回路と、を有するL ED表示装置。

【発明の詳細な説明】

[0001]

【発明の属する技術分野】

本願発明は、LEDディスプレイ、バックライト光源、信号機、照光式スイッチ及び各種インジケータなどに利用される発光ダイオードに係わり、特に発光素子であるLEDチップからの発光を変換して発光させるフォトルミネセンス蛍光体を有し使用環境によらず高輝度、高効率な発光装置である発光ダイオード及びそれを用いた表示装置に関する。

[0002]

【従来の技術】

発光ダイオード(以下、LEDともいう)は、小型で効率が良く鮮やかな色の 発光をする。また、半導体素子であるため球切れなどの心配がない。初期駆動特性が優れ、振動やON/OFF点灯の繰り返しに強いという特長を有する。そのため 各種インジケータや種々の光源として利用されている。最近、超高輝度高効率な 発光ダイオードとしてRGB(赤、緑、青色)などの発光ダイオードがそれぞれ 開発された。これに伴いRGBの三原色を利用したLEDディスプレイが省電力 、長寿命、軽量などの特長を生かして飛躍的に発展を遂げつつある。

[0003]

発光ダイオードは使用される発光層の半導体材料、形成条件などによって紫外から赤外まで種々の発光波長を放出させることが可能である。また、優れた単色性ピーク波長を有する。

[0004]

しかしながら、発光ダイオードは優れた単色性ピーク波長を有するが故に白色系発光光源などとさせるためには、RGBなどが発光可能な各LEDチップをそれぞれ近接して発光させ拡散混色させる必要がある。このような発光ダイオードは、種々の色を自由に発光させる発光装置としては有効であるが、白色系などの色のみを発光させる場合においても赤色系、緑色系及び青色系の発光ダイオード、あるいは青緑色系及び黄色系の発光ダイオードをそれぞれ使用せざるを得ない。LEDチップは、半導体であり色調や輝度のバラツキもまだ相当ある。また、半導体発光素子であるLEDチップがそれぞれ異なる材料を用いて形成されている場合、各LEDチップの駆動電力などが異なり個々に電源を確保する必要がある。そのため、各半導体ごとに電流などを調節して白色系を発光させなければならない。同様に、半導体発光素子であるため個々の温度特性の差や経時変化が異なり、色調が種々変化してしまう。さらに、LEDチップからの発光を均一に混色させなければ色むらを生ずる場合がある。

[0005]

そこで、本出願人は先にLEDチップの発光色を蛍光体で色変換させた発光ダイオードとして特開平5-152609号公報、特開平7-99345号公報などに記載された発光ダイオードを開発した。これらの発光ダイオードによって、1種類のLEDチップを用いて白色系など他の発光色を発光させることができる

[0006]

具体的には、発光層のエネルギーバンドギャップが大きいLEDチップをリードフレームの先端に設けられたカップ上などに配置する。LEDチップは、LE

Dチップが設けられたメタルステムやメタルポストとそれぞれ電気的に接続させる。そして、LEDチップを被覆する樹脂モールド部材中などにLEDチップからの光を吸収し波長変換する蛍光体を含有させて形成させてある。

[0007]

LEDチップからの発光を波長変換した発光ダイオードとして、青色系の発光 ダイオードの発光と、その発光を吸収し黄色系を発光する蛍光体からの発光との 混色により白色系が発光可能な発光ダイオードなどとすることができる。これら の発光ダイオードは、白色系を発光する発光ダイオードとして利用した場合にお いても十分な輝度を発光する発光ダイオードとすることができる。

[0008]

【発明が解決する課題】

発光ダイオードによって励起される蛍光体は、蛍光染料、蛍光顔料さらには有機、無機化合物などから様々なものが挙げられる。また、蛍光体は、発光素子からの発光波長を波長の短いものから長い波長へと変換する、あるいは発光素子からの発光波長を波長の長いものから短い波長へと変換するものとがある。

[0009]

しかしながら、波長の長いものから短い波長へと変換する場合、変換効率が極めて悪く実用に向かない。また、LEDチップ周辺に近接して配置された蛍光体は、太陽光よりも約30倍から40倍にも及ぶ強照射強度の光線にさらされる。特に、発光素子であるLEDチップを高エネルギーバンドギャップを有する半導体を用い蛍光体の変換効率向上や蛍光体の使用量を減らした場合においては、LEDチップから発光した光が可視光域にあるといっても光エネルギーが必然的に高くなる。この場合、発光強度を更に高め長期にわたって使用すると、蛍光体自体が劣化しやすい。蛍光体が劣化すると色調がずれる、あるいは蛍光体が黒ずみ光の外部取り出し効率が低下する場合がある。同様にLEDチップの近傍に設けられた蛍光体は、LEDチップの昇温や外部環境からの加熱など高温にもさらされる。さらに、発光ダイオードは、一般的に樹脂モールドに被覆されてはいるものの外部環境からの水分の進入などを完全に防ぐことや製造時に付着した水分を完全に除去することはできない。蛍光体によっては、このような水分が発光素子

からの高エネルギー光や熱によって蛍光体物質の劣化を促進する場合もある。また、イオン性の有機染料に至ってはチップ近傍では直流電界により電気泳動を起こし、色調が変化する可能性がある。したがって、本願発明は上記課題を解決し、より高輝度、長時間の使用環境下においても発光光率の低下や色ずれの極めて少ない発光ダイオードを提供することを目的とする。

[0010]

【課題を解決するための手段】

本願発明の請求項1の発光ダイオードは、LEDチップと、このLEDチップからの発光の少なくとも一部を吸収し波長変換して発光するフォトルミネセンス蛍光体とを有する。LEDチップは、窒化物系化合物半導体で、フォトルミネセンス蛍光体は、セリウムで付活されたイットリウム・アルミニウム・ガーネット系蛍光体である。

[0011]

また、本発明の請求項 3 の発光ダイオードは、LEDチップを窒化ガリウム系化合物半導体とし、フォトルミネセンス蛍光体を、(RE $_{1-x}$ Sm $_x$) $_3$ (A 1_y G a $_{1-y}$) $_5$ O $_1$ $_2$: C e 蛍光体とする。ただし、 $0 \le x < 1$ 、 $0 \le y \le 1$ 、REは、Y、G d から選択される少なくとも一種である。

[0012]

さらにまた、本発明の請求項2と請求項4に記載する発光ダイオードは、窒化 ガリウム系化合物半導体であるLEDチップの発光スペクトルの主ピークを、4 00nmから530nm内の発光波長とする。

[0013]

また、本発明の請求項 5 の発光ダイオードは、マウント・リードのカップ内に配置させたLEDチップと、該LEDチップと導電性ワイヤーを用いて電気的に接続させたインナー・リードと、前記カップ内に充填させたコーティング部材と、該コーティング部材、LEDチップ、導電性ワイヤー及びマウント・リードとインナー・リードの少なくとも一部を被覆するモールド部材とを有する。この発光ダイオードは、前記LEDチップを窒化ガリウム系化合物半導体とし、かつ前記コーティング部材に、(RE1-x S m_x)。 (A 1 y G a 1-y) 5 O 1 2 : C e 蛍光体

を含む透光性樹脂を使用する。ただし、 $0 \le x < 1$ 、 $0 \le y \le 1$ 、REは、Y、Gdから選択される少なくとも一種である。

[0014]

さらに、本発明の請求項6に記載する発光ダイオードは、前記フォトルミネセンス蛍光体を、次の組成のものとする。

 $(Y_{1-p-q-r}Gd_pCe_qSm_r)_3 (Al_{1-s}Ga_s)_5O_{12}$ $ttl. 0 \le p \le 0.8$

0. $003 \le q \le 0.2$

0. $0003 \le r \le 0.08$

 $0 \le s \le 1$

[0015]

また、請求項7記載の表示装置は、前記請求項5に記載する発光ダイオードをマトリックス状に配置したLED表示器と、該LED表示器と電気的に接続させた駆動回路と、を有する。

[0016]

【発明の実施の形態】

本願発明者は、種々の実験の結果、可視光域における光エネルギーが比較的高いLEDチップからの発光光をフォトルミネセンス蛍光体によって色変換させる発光ダイオードにおいて、特定の半導体及び蛍光体を選択することにより高輝度、長時間の使用時における光効率低下や色ずれを防止できることを見出し本願発明を成すに至った。

[0017]

すなわち、発光ダイオードに用いられるフォトルミネセンス蛍光体としては、

- 1. 耐光性に優れていることが要求される。特に、半導体発光素子などの微小領域から強放射されるために太陽光の約30倍から40倍にもおよぶ強照射強度にも十分耐える必要がある。
- 2. 発光素子との混色を利用するため紫外線ではなく青色系発光で効率よく発光すること。
- 3. 混色を考慮して緑色系から赤色系の光が発光可能なこと。

- 4. 発光素子近傍に配置されるため温度特性が良好であること。
- 5. 色調が組成比あるいは複数の蛍光体の混合比で連続的に変えられること。
- 6. 発光ダイオードの利用環境に応じて耐候性があることなどの特長を有することが求められる。

[0018]

これらの条件を満たすものとして本願発明の発光ダイオードは、発光層に高エネルギーバンドギャップを有する窒化ガリウム系化合物半導体素子と、フォトルミネセンス蛍光体であるセリウムで付活されたイットリウム・アルミニウム・ガーネット系蛍光体とを組み合わせる。これにより発光素子から放出された可視光域における高エネルギー光を長時間その近傍で高輝度に照射した場合であっても発光色の色ずれや発光輝度の低下が極めて少ない発光ダイオードとすることができるものである。

[0019]

具体的な発光ダイオードの一例を図1に示し、さらに、チップタイプLEDのの断面図を図2に示す。チップタイプLEDの筐体204内に窒化ガリウム系半導体を用いたLEDチップ202をエポキシ樹脂などを用いて固定させてある。 導電性ワイヤー203として金線をLEDチップ202の各電極と筐体に設けられた各電極205とにそれぞれ電気的に接続させてある。 $(RE_{1-x}Sm_x)_3$ ($Al_yGa_{1-y})_5O_{12}$: Ce 蛍光体をエポキシ樹脂中に混合分散させたものをLEDチップ、導電性ワイヤーなどを外部応力などから保護するモールド部材201として均一に硬化形成させる。このような発光ダイオードに電力を供給させることによってLEDチップ202を発光させる。LEDチップ202からの発光と、その発光によって励起されたフォトルミネセンス蛍光体からの発光光との混色により白色系などが発光可能な発光ダイオードとすることができる。以下、本願発明の構成部材について詳述する。

[0020]

(蛍光体)

本願発明の発光ダイオードに用いられるフォトルミネセンス蛍光体は、半導体 発光層から発光された可視光や紫外線で励起されて発光するフォトルミネセンス 蛍光体である。具体的なフォトルミネセンス蛍光体として、セリウムで付活され たイットリウム・アルミニウム・ガーネット系蛍光体である。更に詳しくは、($RE_{1-x}Sm_x)$ 3 (Al_yGa_{1-y}) 5 O_{12} : Ce (但し、 $0 \le x < 1$ 、 $0 \le y \le 1$ 、REは、Y、Gdから選択される少なくとも一種)である。窒化ガリウム系化 合物半導体を用いたLEDチップから発光した光と、ボディーカラーが黄色であ るフォトルミネセンス蛍光体から発光する光が補色関係などにある場合、LED チップからの発光と、フォトルミネセンス蛍光体からの発光とを混色表示させる と、白色系の発光色表示を行うことができる。そのため発光ダイオード外部には 、LEDチップからの発光とフォトルミネセンス蛍光体からの発光とがモールド 部材を透過する必要がある。したがって、フォトルミネセンス蛍光体のバルク層 内などにLEDチップを閉じこめ、フォトルミネセンス蛍光体層にLEDチップ からの光が透過する開口部を1ないし2以上有する構成の発光ダイオードとして も良い。また、フォトルミネセンス蛍光体の粉体を樹脂や硝子中に含有させLE Dチップからの光が透過する程度に薄く形成させても良い。フォトルミネセンス 蛍光体と樹脂などとの比率や塗布、充填量を種々調整すること及び発光素子の発 光波長を選択することにより自色を含め電球色など任意の色調を提供させること ができる。

[0021]

さらに、フォトルミネセンス蛍光体の含有分布は、混色性や耐久性にも影響する。すなわち、フォトルミネセンス蛍光体が含有されたコーティング部やモールド部材の表面側からLEDチップに向かってフォトルミネセンス蛍光体の分布濃度が高い場合は、外部環境からの水分などの影響をより受けにくく水分による劣化を抑制しやすい。他方、フォトルミネセンス蛍光体の含有分布をLEDチップからモールド部材表面側に向かって分布濃度が高くなると外部環境からの水分の影響を受けやすいがLEDチップからの発熱、照射強度などの影響がより少なくフォトルミネセンス蛍光体の劣化を抑制することができる。このような、フォトルミネセンス蛍光体の分布は、フォトルミネセンス蛍光体を含有する部材、形成温度、粘度やフォトルミネセンス蛍光体の形状、粒度分布などを調整させることによって種々形成させることができる。したがって、使用条件などにより蛍光体

の分布濃度を、種々選択することができる。

[0022]

本願発明のフォトルミネセンス蛍光体は、特にLEDチップと接する、あるいは近接して配置され放射照度として(Ee) $=3W \cdot c m^{-2}$ 以上 $10W \cdot c m^{-2}$ 以下においても高効率に十分な耐光性を有し、優れた発光特性の発光ダイオードとすることができる。

[0023]

本願発明に用いられるフォトルミネセンス蛍光体は、ガーネット構造のため、熱、光及び水分に強く、図4に示すように、励起スペクトルのピークを450nm付近にさせることができる。また、発光ピークも図4に示すように、530nm付近にあり700nmまで裾を引くブロードな発光スペクトルを持つ。しかも、組成のA1の一部をGaで置換することで発光波長が短波長にシフトし、また組成のYの一部をGdで置換することで発光波長が長波長へシフトする。このように組成を変化することで発光色を連続的に調節することが可能である。また、254nmや365nmなどのHg輝線ではほとんど励起されず450nm付近などの青色系LEDチップからの光による励起効率が高い。したがって、長波長側の強度がGdの組成比で連続的に変えられるなど窒化物半導体の青色系発光を自色系発光に変換するための理想条件を備えている。

[0024]

また、窒化ガリウム系半導体を用いたLEDチップと、セリウムで付活された イットリウム・アルミニウム・ガーネット蛍光体(YAG)に希土類元素のサマ リウム(Sm)を含有させたフォトルミネセンス蛍光体と、を有する発光ダイオ ードとすることによりさらに光効率を向上させることができる。

[0025]

このようなフォトルミネセンス蛍光体は、Y、Gd、Ce、Sm、A1及びGaの原料として酸化物、又は高温で容易に酸化物になる化合物を使用し、それらを化学量論比で十分に混合して原料を得る。又は、Y、Gd、Ce、Smの希土類元素を化学量論比で酸に溶解した溶解液を蓚酸で共沈したものを焼成して得られる共沈酸化物と、酸化アルミニウム、酸化ガリウムとを混合して混合原料を得

る。これにフラックスとしてフッ化アンモニウム等のフッ化物を適量混合して坩堝に詰め、空気中 $1350\sim1450^\circ$ Cの温度範囲で $2\sim5$ 時間焼成して焼成品を得、次に焼成品を水中でボールミルして、洗浄、分離、乾燥、最後に篩を通すことで得ることができる。

[0026]

($Y_{1-p-q-r}Gd_pCe_qSm_r$) $_3Al_5O_{12}$ フォトルミネセンス蛍光体は、結晶中にGdを含有することにより、特に460nm以上の長波長域の励起発光効率を高くすることができる。ガドリニウムの含有量の増加により、発光ピーク波長が、530nmから570nmまで長波長に移動し、全体の発光波長も長波長側にシフトする。赤みの強い発光色が必要な場合、Gdの置換量を多くすることで達成できる。一方、Gdが増加すると共に、青色光によるフォトルミネセンスの発光輝度は徐々に低下する。したがって、pは0. 8以下であることが好ましく、0. 7以下であることがより好ましい。さらに好ましくは0. 6以下である。

[0027]

Smを含有する($Y_{1-p-q-r}Gd_pCe_qSm_r$) $_3A1_5O_{12}$ 蛍光体は、Gdの含有量の増加に関わらず温度特性の低下が少ない。このようにSmを含有させることにより、高温度におけるフォトルミネセンス蛍光体の発光輝度は大幅に改善される。その改善される程度はGdの含有量が高くなるほど大きくなる。すなわち、Gdを増加してフォトルミネセンス蛍光体の発光色調に赤みを付与した組成ほどSmの含有による温度特性改善に効果的であることが分かった。(なお、ここでの温度特性とは、450nmの青色光による常温(25° C)における励起発光輝度に対する、同蛍光体の高温(200° C)における発光輝度の相対値(%)で表している。)

[0028]

Smの含有量は $0.003 \le r \le 0.08$ の範囲で温度特性が 6.0%以上となり好ましい。この範囲より r が小さいと、温度特性改良の効果が小さくなる。また、この範囲より r が大きくなると温度特性は逆に低下してくる。0.000 $7 \le r \le 0.02$ の範囲では温度特性は 8.0%以上となり最も好ましい。

[0029]

Ceは0.003 \leq q \leq 0.2の範囲で相対発光輝度が70%以上となる。qが0.003以下では、Ceによるフォトルミネセンスの励起発光中心の数が減少することで輝度低下し、逆に、0.2より大きくなると濃度消光が生ずる。

[0030]

本願発明の発光ダイオードにおいてこのようなフォトルミネセンス蛍光体は、 2種類以上の(RE $_{1-x}$ Sm $_{x}$) $_3$ (Al $_{y}$ Ga $_{1-y}$) $_5$ O $_{12}$:Ceフォトルミネセンス蛍光体を混合させてもよい。すなわち、Al、Ga、Y及びGdやSmの含有量が異なる2種類以上の(RE $_{1-x}$ Sm $_{x}$) $_3$ (Al $_{y}$ Ga $_{1-y}$) $_5$ O $_{12}$:Ceフォトルミネセンス蛍光体を混合させてRGBの波長成分を増やすことができる。これに、カラーフィルターを用いることによりフルカラー液晶表示装置用としても利用できる。

[0031]

(LED # y 2 1 0 2 \ 2 0 2 \ 7 0 2)

LEDチップは、図1に示すように、モールド部材104に埋設されることが好ましい。本願発明の発光ダイオードに用いられるLEDチップとは、セリウムで付活されたイットリウム・アルミニウム・ガーネット系蛍光体を効率良く励起できる窒化物系化合物半導体である。発光素子であるLEDチップは、MOCVD法等により基板上にInGaN等の半導体を発光層として形成させる。半導体の構造としては、MIS接合、PIN接合やPN接合などを有するホモ構造、ヘテロ構造あるいはダブルヘテロ構成のものが挙げられる。半導体層の材料やその混晶度によって発光波長を種々選択することができる。また、半導体活性層を量子効果が生ずる薄膜に形成させた単一量子井戸構造や多重量子井戸構造とすることもできる。特に、本願発明においては、LEDチップの活性層をInGaNの単一量子井戸構造とすることにより、フォトルミネセンス蛍光体の劣化がなく、より高輝度に発光する発光ダイオードとして利用することができる。

[0032]

窒化ガリウム系化合物半導体を使用した場合、半導体基板にはサファイヤ、スピネル、SiC、Si、ZnO等の材料が用いられる。結晶性の良い窒化ガリウムを形成させるためにはサファイヤ基板を用いることが好ましい。このサファイ

ヤ基板上にGaN、A1N等のバッファー層を形成しその上にPN接合を有する 窒化ガリウム半導体を形成させる。窒化ガリウム系半導体は、不純物をドープし ない状態でN型導電性を示す。発光効率を向上させるなど所望のN型窒化ガリウ ム半導体を形成させる場合は、N型ドーパントとしてSi、Ge、Se、Te、 C等を適宜導入することが好ましい。一方、P型窒化ガリウム半導体を形成させ る場合は、P型ドーパンドであるZn、Mg、Be、Ca、Sr、Ba等をドー プさせる。窒化ガリウム系化合物半導体は、P型ドーパントをドープしただけで はP型化しにくいためP型ドーパント導入後に、炉による加熱、低速電子線照射 やプラズマ照射等によりP型化させることが好ましい。エッチングなどによりP 型半導体及びN型半導体の露出面を形成させた後、半導体層上にスパッタリング 法や真空蒸着法などを用いて所望の形状の各電極を形成させる。

[0033]

次に、形成された半導体ウエハー等をダイヤモンド製の刃先を有するブレードが回転するダイシングソーにより直接フルカットするか、又は刃先幅よりも広い幅の溝を切り込んだ後(ハーフカット)、外力によって半導体ウエハーを割る。あるいは、先端のダイヤモンド針が往復直線運動するスクライバーにより半導体ウエハーに極めて細いスクライブライン(経線)を例えば碁盤目状に引いた後、外力によってウエハーを割り半導体ウエハーからチップ状にカットする。このようにして窒化ガリウム系化合物半導体であるLEDチップを形成させることができる。

[0034]

本願発明の発光ダイオードにおいて白色系を発光させる場合は、フォトルミネセンス蛍光体との補色関係や樹脂劣化等を考慮して発光素子の発光波長は400 nm以上530nm以下が好ましく、420nm以上490nm以下がより好ましい。LEDチップとフォトルミネセンス蛍光体との効率をそれぞれより向上させるためには、450nm以上475nm以下がさらに好ましい。本願発明の白色系発光ダイオードの発光スペクトルを図3に示す。450nm付近にピークを持つ発光がLEDチップからの発光であり、570nm付近にピークを持つ発光がLEDチップによって励起されたフォトルミネセンスの発光である。なお、本

願発明のLEDチップに加えて、蛍光体を励起しないLEDチップを一緒に用いることもできる。

[0035]

(導電性ワイヤー103、203)

導電性ワイヤー103、203としては、LEDチップ102、202の電極とのオーミック性、機械的接続性、電気伝導性及び熱伝導性がよいものが求められる。熱伝導度としては0.01ca1/cm²/cm/℃以上が好ましく、より好ましくは0.5ca1/cm²/cm/℃以上である。また、作業性などを考慮して導電性ワイヤーの直径は、好ましくは、Φ10μm以上、Φ45μm以下である。このような導電性ワイヤーとして具体的には、金、銅、白金、アルミニウム等の金属及びそれらの合金を用いた導電性ワイヤーが挙げられる。このような導電性ワイヤーは、各LEDチップの電極と、インナー・リード及びマウント・リードなどと、をワイヤーボンディング機器によって容易に接続させることができる。

[0036]

(マウント・リード105)

マウント・リード105としては、LEDチップ102を配置させるものであり、ダイボンド機器などで積載するのに十分な大きさがあれば良い。また、LEDチップを複数設置しマウント・リードをLEDチップの共通電極として利用する場合においては、十分な電気伝導性とボンディングワイヤー等との接続性が求められる。また、マウント・リード上のカップ内にLEDチップを配置すると共に蛍光体を内部に充填させる場合は、近接して配置させた別の発光ダイオードからの光により疑似点灯することを防止することができる。

[0037]

LEDチップ102とマウント・リード105のカップとの接着は熱硬化性樹脂などによって行うことができる。具体的には、エポキシ樹脂、アクリル樹脂やイミド樹脂などが挙げられる。また、フェースダウンLEDチップなどによりマウント・リードと接着させると共に電気的に接続させるためにはAgペースト、カーボンペースト、金属バンプ等を用いることができる。さらに、発光ダイオー

ドの光利用効率を向上させるためにLEDチップが配置されるマウント・リードの表面を鏡面状とし、表面に反射機能を持たせても良い。この場合の表面粗さは、0.1 S以上0.8 S以下が好ましい。また、マウント・リードの具体的な電気抵抗としては300 μ Ω -c m以下が好ましく、より好ましくは、3 μ Ω -c m以下である。また、マウント・リード上に複数のLEDチップを積置する場合は、LEDチップからの発熱量が多くなるため熱伝導度がよいことが求められる。具体的には、0.01 c a 1/c m 2/c m 1/c m 1/c

[0038]

(インナー・リード106)

インナー・リード106としては、マウント・リード105上に配置されたLEDチップ102と接続された導電性ワイヤー103との接続を図るものである。マウント・リード上に複数のLEDチップを設けた場合は、各導電性ワイヤー同士が接触しないよう配置できる構成とする必要がある。具体的には、マウント・リードから離れるに従って、インナー・リードのワイヤーボンディングさせる端面の面積を大きくすることなどによってマウント・リードからより離れたインナー・リードと接続させる導電性ワイヤーの接触を防ぐことができる。導電性ワイヤーとの接続端面の粗さは、密着性を考慮して1.6 S以上10 S以下が好ましい。インナー・リードの先端部を種々の形状に形成させるためには、あらかじめリードフレームの形状を型枠で決めて打ち抜き形成させてもよく、<u>あるい</u>は全てのインナー・リードを形成させた後にインナー・リード上部の一部を削ることによって形成させても良い。さらには、インナー・リードを打ち抜き形成後、端面方向から加圧することにより所望の端面の面積と端面高さを同時に形成させることもできる。

[0039]

インナー・リードは、導電性ワイヤーであるボンディングワイヤー等との接続 性及び電気伝導性が良いことが求められる。具体的な電気抵抗としては、300 $\mu\Omega$ -c m以下が好ましく、より好ましくは 3 $\mu\Omega$ -c m以下である。これらの条件を満たす材料としては、鉄、銅、鉄入り銅、錫入り銅及び銅、金、銀をメッキしたアルミニウム、鉄、銅等が挙げられる。

[0040]

(コーティング部101)

本願発明に用いられるコーティング部101とは、モールド部材104とは別にマウント・リードのカップに設けられるものでありLEDチップの発光を変換するフォトルミネセンス蛍光体が含有されるものである。コーティング部の具体的材料としては、エポキシ樹脂、ユリア樹脂、シリコーンなどの耐候性に優れた透明樹脂や硝子などが好適に用いられる。また、フォトルミネセンス蛍光体と共に拡散剤を含有させても良い。具体的な拡散剤としては、チタン酸バリウム、酸化チタン、酸化アルミニウム、酸化珪素等が好適に用いられる。

[0041]

(モールド部材104)

モールド部材104は、発光ダイオードの使用用途に応じてLEDチップ102、導電性ワイヤー103、フォトルミネセンス蛍光体が含有されたコーティング部101などを外部から保護するために設けることができる。モールド部材は、一般には樹脂を用いて形成させることができる。また、フォトルミネセンス蛍光体を含有させることによって見野角を増やすことができるが、樹脂モールドに拡散剤を含有させることによってLEDチップ102からの指向性を緩和させ視野角をさらに増やすことができる。更にまた、モールド部材104を所望の形状にすることによってLEDチップからの発光を集束させたり拡散させたりするレンズ効果を持たせることができる。従って、モールド部材104は複数積層した構造でもよい。具体的には、凸レンズ形状、凹レンズ形状さらには、発光観測面から見て楕円形状やそれらを複数組み合わせた物である。モールド部材104の具体的材料としては、主としてエポキシ樹脂、ユリア樹脂、シリコーン樹脂などの耐候性に優れた透明樹脂や硝子などが好適に用いられる。また、拡散剤としては、チタン酸バリウム、酸化チタン、酸化アルミニウム、酸化珪素等が好適に用いられる。さらに、拡散剤に加えてモールド部材中にもフォトルミネセンス蛍光

体を含有させることもできる。したがって、フォトルミネセンス蛍光体はモールド部材中に含有させてもそれ以外のコーティング部などに含有させて用いてもよい。また、コーティング部をフォトルミネセンス蛍光体が含有された樹脂、モールド部材を硝子などとした異なる部材を用いて形成させても良い。この場合、生産性良くより水分などの影響が少ない発光ダイオードとすることができる。また、屈折率を考慮してモールド部材とコーティング部とを同じ部材を用いて形成させても良い。本願発明においてモールド部材に拡散剤や着色剤を含有させることは、発光観測面側から見た蛍光体の着色を隠すことができると共により混色性を向上させることもできる。

[0042]

(表示装置)

本願発明の発光ダイオードをLED表示器に利用した場合、RGBをそれぞれ発光する発光ダイオードの組み合わせだけによるLED表示器よりも、より高精細に白色系表示させることができる。従来の装置が、3個の発光ダイオードで白色表示できるからである。すなわち、従来の表示装置は、発光ダイオードを組み合わせて白色系などを混色表示させるためには、RGBの各発光ダイオードをそれぞれ同時に発光せざるを得ない。そのため赤色系、緑色系、青色系のそれぞれ単色表示した場合に比べて、一画素あたりの表示領域が大きくなる。したがって、白色系の表示の場合においては、RGB単色のモノクローム表示に比較して、高精細に表示させることができない。また、白色系の表示は各発光ダイオードの発光出力を調節して表示させるため、各半導体の温度特性などを考慮し種々調整しなければならない。さらに、混色による表示であるが故にLED表示器の視認する方向や角度によって、RGBの発光ダイオードが部分的に遮光され表示色が変わる場合もある。

本願発明の発光ダイオードをRGBの発光ダイオードに代えて使用する表示装置は、より高精細化が可能となると共に、安定して白色系に発光でき、さらに、色むらを少なくできる特長がある。また、本発明の発光ダイオードは、RGBの各発光ダイオードとともに使用することもできる。この表示装置は、輝度を向上

させることができる。

[0043]

また、本願発明の発光ダイオードを用いたLED表示器を図5に示す。この図のLED表示器は、本願発明の白色系発光ダイオードのみを用いて、白黒用のLED表示装置に使用される。白黒用のLED表示器は、本願発明の発光ダイオード501のみをマトリックス状などに配置している。この図のLED表示器を備える表示装置は、RGBの発光ダイオードを備えない。このため、RGB発光ダイオード用の複数の駆動回路を必要としない。複数の駆動回路に代わって、白色系発光ダイオード用の駆動回路で、LED表示器を駆動できる。

[0044]

LED表示器は、駆動回路である点灯回路などと電気的に接続させる。駆動回路からの出力パルスによって種々の画像が表示可能なデイスプレイ等とすることができる。駆動回路を図6に示す。駆動回路は、入力される表示データを一時的に記憶させる画像データー記憶手段であるRAM(Random、Access、Memory)603と、RAM603に記憶されるデータから、LED表示器1のそれぞれの発光ダイオードを所定の明るさに点灯させるための階調信号を演算する階調制御回路604と、階調制御回路604の出力信号でスイッチングされて、発光ダイオードを点灯させるドライバー602とを備える。階調制御回路604は、RAM603に記憶されるデータからLED表示器1の発光ダイオード点灯時間を演算して点滅させるパルス信号を出力する。

[0045]

したがって、白黒用のLED表示器は、RGBのフルカラー表示器と異なり、 回路構成を簡略化できると共に高精細化できる。そのため、安価にRGBの発光 ダイオードの特性に伴う色むらなどのないディスプレイとすることができるもの である。また、従来の赤色、緑色のみを用いたLED表示器に比べ人間の目に対 する刺激が少なく長時間の使用に適している。

[0046]

本願発明の発光ダイオードは、RGBに発光する発光ダイオードに加えて使用することもできる。このLED表示器は、駆動回路である点灯回路などと電気的

に接続させる。駆動回路からの出力パルスによって種々の画像が表示可能なデイスプレイ等とすることができる。駆動回路は、モノクロームの表示装置と同じように、入力される表示データを一時的に記憶させる、画像データー記憶手段であるRAM(Random、Access、Memory)と、RAMに記憶されるデータから各発光ダイオードを所定の明るさに点灯させるための階調信号を演算する階調制御回路と、階調制御回路の出力信号でスイッチングされて、各発光ダイオードを点灯させるドライバーとを備える。ただし、この駆動回路は、RGBと白色系に発光する発光ダイオードに専用の回路を必要とする。階調制御回路は、RAMに記憶されるデータから、それぞれの発光ダイオードの点灯時間を演算して、点滅させるパルス信号を出力する。ここで、白色系の表示を行う場合は、RGB各発光ダイオードを点灯するバルス信号のパルス幅を短く、あるいは、パルス信号のピーク値を低く、あるいは全くバルス信号を出力しない。他方、それを補償するように白色系発光ダイオードにバルス信号を出力する。これにより、LED表示器の白色を表示する。

[0047]

したがって、白色系発光ダイオードを所望の輝度で点灯させるためのパルス信号を演算する階調制御回路としてCPUを別途備えることが好ましい。階調制御回路から出力されるパルス信号は、白色系発光ダイオードのドライバーに入力されてドライバをスイッチングさせる。ドライバーがオンになると白色系発光ダイオードが点灯され、オフになると消灯される。

[0048]

(信号機)

本願発明の発光ダイオードを表示装置の1種である信号機として利用した場合、長時間安定して発光させることが可能であると共に発光ダイオードの一部が消灯しても色むらなどが生じないという特長がある。本願発明の発光ダイオードを用いた信号機の概略構成として、導電性パターンが形成された基板上に白色系発光ダイオードを配置させる。このような発光ダイオードを直列又は直並列に接続された発光ダイオードの回路を発光ダイオード群として扱う。発光ダイオード群を2つ以上用いそれぞれ渦巻き状に発光ダイオードを配置させる。全ての発光ダ

イオードが配置されると円状に全面に配置される。各発光ダイオード及び基板か ら外部電力と接続させる電源コードをそれぞれ、ハンダにより接続させた後、鉄 道用信号用の筐体内に固定させる。LED表示器は、遮光部材が付いたアルミダ イキャストの筐体内に配置され表面にシリコーンゴムの充填材で封止されている 。筐体の表示面は、白色レンズを設けてある。また、LED表示器の電気的配線 は、筐体の裏面からゴムパッキンを通し筐体内を密閉する。これにより白色系信 号機を形成することができる。本願発明の発光ダイオードを、複数の群に分け中 心部から外側に向け輪を描く渦巻き状などに配置し、並列接続させることでより 信頼性が高い信号機とさせることができる。中心部から外側に向け輪を描くとは 連続的に輪を描くものも断続的に配置するものをも含む。したがって、LED表 示器の表示面積などにより配置される発光ダイオードの数や発光ダイオード群の 数を種々選択することができる。この信号機により、一方の発光ダイオード群や ―部の発光ダイオードが何らかのトラブルにより消灯したとしても他方の発光ダ イオード群や残った発光ダイオードにより信号機を円形状に均一に発光させるこ とが可能となるものである。また、色ずれが生ずることもない。渦巻き状に配置 してあることから中心部を密に配置することができ電球発光の信号と何ら違和感 なく駆動させることができる。

[0049]

(面状発光光源)

本願発明の発光ダイオードは、図7に示すように、面状発光光源とすることもできる。図に示す面状発光光源の発光ダイオードは、フォトルミネセンス蛍光体をコーティング部や導光板上の散乱シート706に含有させる。あるいはバインダー樹脂と共に散乱シート706に塗布などさせシート状701に形成しモールド部材を省略しても良い。具体的には、絶縁層及び導電性パターンが形成されたコの字形状の金属基板703内にLEDチップ702を固定する。LEDチップと導電性パターンとの電気的導通を取った後、フォトルミネセンス蛍光体をエポキシ樹脂と混合撹拌しLEDチップ702が積載された金属基板703上に充填させる。こうして固定されたLEDチップは、アクリル性導光板704の端面にエポキシ樹脂などで固定される。導光板704の一方の主面上には、蛍現象防止

のため白色散乱剤が含有されたフィルム状の反射部材707を配置させてある。 同様に、導光板の裏面側全面やLEDチップが配置されていない端面上にも反射 部材705を設け発光効率を向上させてある。これにより、LCDのバックライトとして十分な明るさを得られる面状発光光源の発光ダイオードとすることができる。液晶表示装置として利用する場合は、導光板704の主面上に不示図の透光性導電性パターンが形成された硝子基板間に注入された液晶装置を介して配された偏光板により構成させることができる。以下、本願発明の実施例について説明するが、本願発明は具体的実施例のみに限定されるものではないことは言うまでもない。

[0050]

【実施例】

(実施例1)

発光素子として発光ピークが450nmのGaInN半導体を用いた。LEDチップは、洗浄させたサファイヤ基板上にTMG(トリメチルガリウム)ガス、TMI(トリメチルインジュウム)ガス、窒素ガス及びドーパントガスをキャリアガスと共に流し、MOCVD法で窒化ガリウム系化合物半導体を成膜させることにより形成させた。ドーパントガスとしてSiH4とCp2Mgと、を切り替えることによってN型導電性を有する窒化ガリウム半導体とP型導電性を有する窒化ガリウム半導体とP型導電性を有する窒化ガリウム半導体を形成しPN接合を形成させた。(なお、P型半導体は、成膜後400℃以上でアニールさせてある。)

[0051]

エッチングによりPN各半導体表面を露出させた後、スパッタリングにより各電極をそれぞれ形成させた。こうして出来上がった半導体ウエハーをスクライブラインを引いた後、外力により分割させ発光素子としてLEDチップを形成させた。

[0052]

銀メッキした銅製リードフレームの先端にカップを有するマウント・リードに LEDチップをエポキシ樹脂でダイボンディングした。LEDチップの各電極と マウント・リード及びインナー・リードと、をそれぞれ金線でワイヤーボンディ ングし電気的導通を取った。

[0053]

一方、フォトルミネセンス蛍光体は、Y、Gd、Ceの希土類元素を化学量論 比で酸に溶解した溶解液を蓚酸で共沈させた。これを焼成して得られる共沈酸化 物と、酸化アルミニウムを混合して混合原料を得る。これにフラックスとしてフ ッ化アンモニウムを混合して坩堝に詰め、空気中1400°Cの温度で3時間焼 成して焼成品を得た。焼成品を水中でボールミルして、洗浄、分離、乾燥、最後 に篩を通して形成させた。

[0054]

形成された(Y_{0.8}Gd_{0.2})₃A1₅O₁₂: Ce蛍光体80重量部、エポキシ樹脂100重量部をよく混合してスラリーとさせた。このスラリーをLEDチップが配置されたマウント・リード上のカップ内に注入させた。注入後、フォトルミネセンス蛍光体が含有された樹脂を130℃1時間で硬化させた。こうしてLEDチップ上に厚さ120μのフォトルミネセンス蛍光体が含有されたコーティング部が形成された。なお、コーティング部には、LEDチップに向かってフォトルミネセンス蛍光体が徐々に多くしてある。その後、さらにLEDチップやフォトルミネセンス蛍光体を外部応力、水分及び塵芥などから保護する目的でモールド部材として透光性エポキシ樹脂を形成させた。モールド部材は、砲弾型の型枠の中にフォトルミネセンス蛍光体のコーティング部が形成されたリードフレームを挿入し透光性エポシキ樹脂を混入後、150℃5時間にて硬化させた。こうして形成された発光ダイオードは、発光観測正面から視認するとフォトルミネセンス蛍光体のボディーカラーにより中央部が黄色っぽく着色していた。

[0055]

こうして得られた白色系が発光可能な発光ダイオードの色度点、色温度、演色性指数を測定した。それぞれ、色度点(x=0. 302、y=0. 280)、色温度 8080 K、R a(演色性指数)=87. 5 と三波長型蛍光灯に近い性能を示した。また、発光効率は 9. 51 m/w と白色電球並であった。さらに寿命試験として温度 25 $\mathbb{C}60$ m A 通電、温度 25 $\mathbb{C}20$ m A 通電、温度 60 $\mathbb{C}90$ % R H 下で 20 m A 通電の各試験においても蛍光体に起因する変化は観測されず通

常の青色発光ダイオードと寿命特性に差がないことが確認できた。

[0056]

(比較例1)

フォトルミネセンス蛍光体を($Y_{0.8}Gd_{0.2}$) $_3Al_5O_{12}$:Ceから(ZnCd)S:Cu、Alとした以外は、実施例 $_1$ と同様にして発光ダイオードの形成及び寿命試験を行った。形成された発光ダイオードは通電直後、実施例 $_1$ と同様白色系の発光が確信されたが輝度が低かった。また、寿命試験においては、約 $_1$ 00時間で出力がゼロになった。劣化原因を解析した結果、蛍光体が黒化していた。

[0057]

これは、発光素子の発光光と蛍光体に付着していた水分あるいは外部環境から 進入した水分により光分解し蛍光体結晶表面にコロイド状亜鉛金属を析出し外観 が黒色に変色したものと考えられる。温度25℃20mA通電、温度60℃90 %RH下で20mA通電の寿命試験結果を実施例1と共に図8に示す。輝度は初 期値を基準にしそれぞれの相対値を示す。また、実線が実施例1であり波線が比 較例1を示す。

[0058]

(実施例2)

[0059]

こうして得られた白色系が発光可能な発光ダイオードの色度点、色温度、演色性指数を測定した。それぞれ、色度点(x=0. 375、y=0. 370)、色温度4400K、Ra(演色性指数)=86.0であった。さらに寿命試験においては、形成させた発光ダイオード100個平均で行った。寿命試験前の光度を100%とし1000時間経過後における平均光度を調べた。寿命試験後も98.8%であり特性に差がないことが確認できた。

[0060]

(実施例3)

[0061]

(実施例4)

本願発明の発光ダイオードを図5のごとくLED表示器の1つであるディスプレイに利用した。実施例1と同様にして形成させた発光ダイオードを銅バターンを形成させたセラミックス基板上に、16×16のマトリックス状に配置させた。基板と発光ダイオードとは自動ハンダ実装装置を用いてハンダ付けを行った。次にフェノール樹脂によって形成された筐体504内部に配置し固定させた。遮光部材505は、筐体と一体成形させてある。発光ダイオードの先端部を除いて筐体、発光ダイオード、基板及び遮光部材の一部をピグメントにより黒色に着色したシリコンゴム406によって充填させた。その後、常温、72時間でシリコンゴムを硬化させLED表示器を形成させた。このLED表示器と、人力される表示データを一時的に記憶させるRAM(Random、Access、Memory)及びRAMに記憶されるデータから発光ダイオードを所定の明るさに点灯させるための階調信号を演算する階調制御回路と階調制御回路の出力信号でスイッチングされて発光ダイオードを点灯させるドライバーとを備えたCPUの駆動手段と、を電気的に接続させてLED表示装置を構成した。LED表示器を駆動させ白黒LED表示装置として駆動できることを確認した。

[0062]

【発明の効果】

本願発明の発光ダイオードは、窒化物系化合物半導体の発光素子と、セリウムで付活されたイットリウム・アルミニウム・ガーネット系蛍光体や(RE $_{1-x}$ S m_x) $_3$ (A l_v G a $_{1-v}$) $_5$ O $_1$ $_2$:C e 蛍光体を組み合わせることにより長時間高

輝度時の使用においても発光効率が高い発光ダイオードを実現する。さらに、本願発明の発光ダイオードは、信頼性や省電力化、小型化さらには色温度の可変性など車載や航空産業、一般電気機器に表示の他に照明として新たな用途を開くことができる。特に、本願発明に用いられるフォトルミネセンス蛍光体は、短残光であり120 nsecという応答速度を有する光源などとして利用することもできる。また、発光色を白色にして、人間の目で長時間視認する場合には刺激が少なく目に優しい発光ダイオードとすることができる。

[0063]

特に、本願発明の請求項1または3に記載の構成とすることにより高輝度、長時間の使用においても色ずれ、発光効率の低下が極めて少ない白色系が発光可能な発光ダイオードなど種々の発光ダイオードとすることができる。また、樹脂劣化に伴う輝度の低下も抑制させることができる。

[0064]

本願発明の請求項5の構成とすることにより、高輝度、長時間の使用においても色ずれ、発光効率の低下が極めて少ない発光ダイオードなど種々の発光ダイオードとすることができることに加えて、発光ダイオードを複数近接して配置した場合においても他方の発光ダイオードからの光により蛍光体が励起され疑似点灯されることを防止させることができる。また、LEDチップ自体の発光むらを蛍光体により分散することができるためより均一な発光光を有する発光ダイオードとすることができる。

[0065]

本願発明の請求項6の構成とすることにより、より温度依存性の少ない発光ダイオードとすることができる。

[0066]

本願発明の請求項7の構成とすることにより、比較的安価で高精細なLED表示装置や視認角度によって色むらの少ないLED表示装置とすることができる。

[0067]

【図面の簡単な説明】

【図1】

図1は、本願発明の発光ダイオードの模式的断面図である。

【図2】

図2は、本願発明の他の発光ダイオードの模式的断面図である。

【図3】

図3は、本願発明の発光ダイオードの発光スペクトルの一例を示した図である

【図4】

図4 (A) は、本願発明に使用されるフォトルミネセンス蛍光体の吸収スペクトルの一例を示し、図4 (B) は、本願発明に使用されるフォトルミネセンス蛍光体の発光スペクトルの一例を示した図である。

【図5】

図5は、本願発明の発光ダイオードを用いたLED表示装置の模式図である。 【図6】

図6は、図5に用いられるLED表示装置のブロック図である。

【図7】

図7は、本願発明の発光ダイオードを用いた別のLED表示装置の模式図である。

【8区】

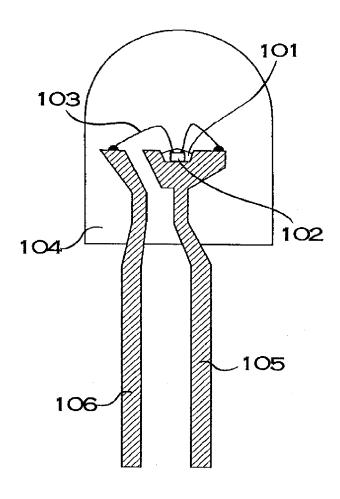
図8(A)は、本願発明の実施例1と比較のために示した比較例1の発光ダイオードとの温度25 \mathbb{C} 20 m A 通電における寿命試験を示し、図8(B)は、本願発明の実施例1と比較のために示した比較例1の発光ダイオードとの温度60 \mathbb{C} 90 \mathbb{C} \mathbb{C}

【符号の説明】

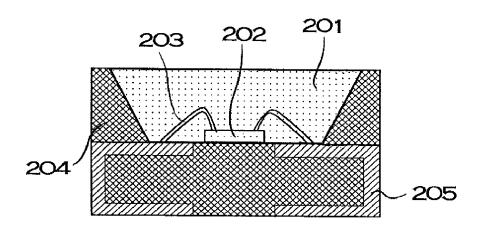
- 101、701・・・フォトルミネセンスが含有されたコーティング部
- 102、202、702・・・LEDチップ
- 103、203・・・導電性ワイヤー
- 104・・・モールド部材
- 105・・・マウント・リード
- 106・・・インナー・リード

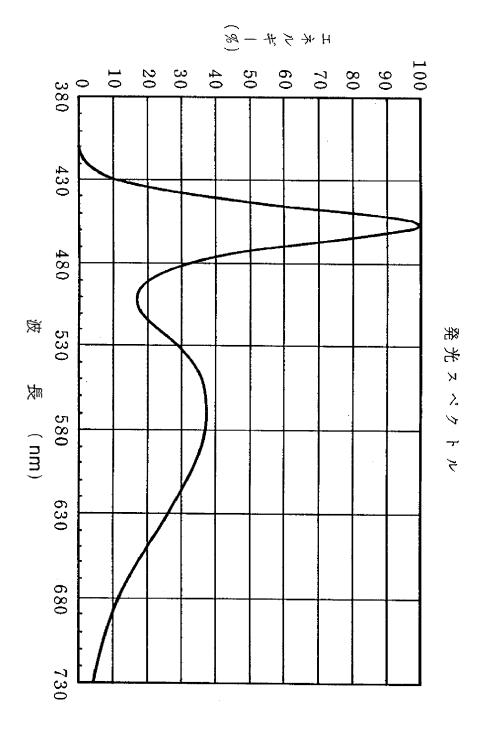
- 201・・・フォトルミネセンスが含有されたモールド部材
- 204・・・筐体
- 205・・・筐体に設けられた電極
- 501・・・発光ダイオード
- 504・・・筐体
- 505・・・遮光部材
- 506・・・充填材
- 601···LED表示器
- 602・・・ドライバー
- 603 · · · RAM
- 604・・・階調制御手段
- 703・・・金属製基板
- 704・・・導光板
- 705、707・・・反射部材
- 706・・・散乱シート

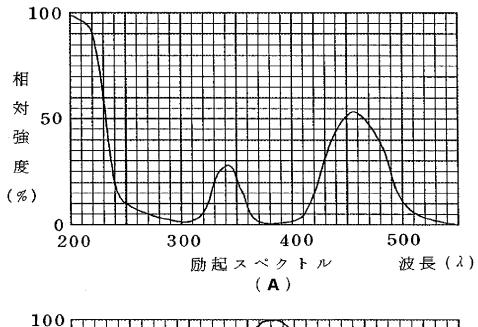


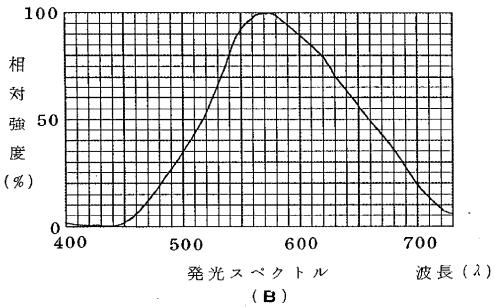


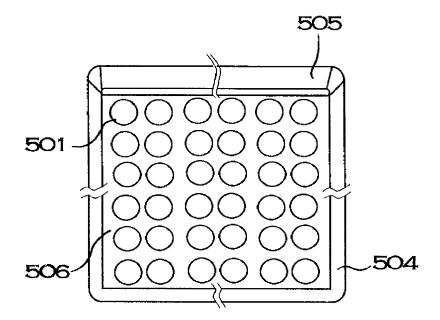
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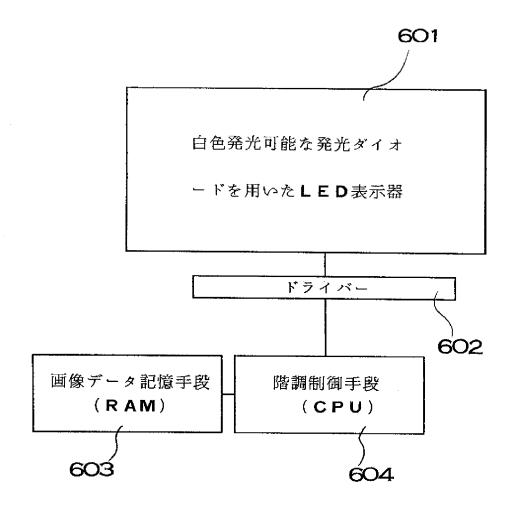




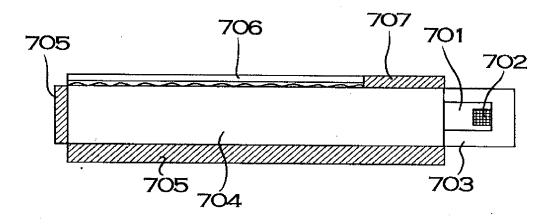


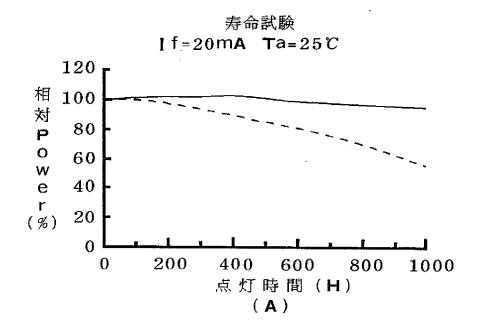


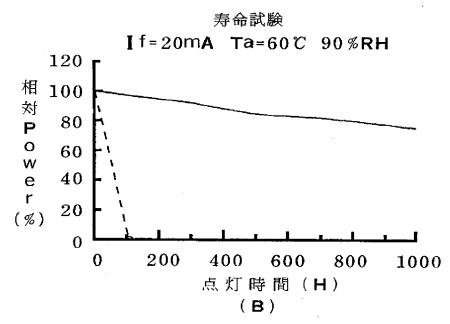




【図7】







【書類名】 要約書

【要約】

【課題】 高輝度、長時間の使用環境下においても発光光率の低下や色ずれを少なくする。

【解決手段】発光ダイオードは、LEDチップと、LEDチップからの発光の少なくとも一部を吸収し波長変換して発光するフォトルミネセンス蛍光体とを有する。LEDチップは、窒化物系化合物半導体で、フォトルミネセンス蛍光体がセリウムで付活されたイットリウム・アルミニウム・ガーネット系蛍光体である。

【書類名】 職権訂正データ

【訂正書類】 特許願

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The country code and number of your priority application, to be used for filing abroad under the Paris Convention, is JP1997-081010

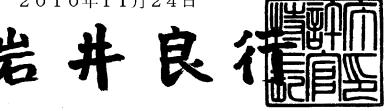
願 出 人

Applicant(s):

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特許庁長官 Commissioner, Japan Patent Office



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【請求項の数】 8

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【物件名】図面 1

【物件名】要約書 1

【プルーフの要否】要

【書類名】 明細書

【発明の名称】 発光装置

【特許請求の範囲】

【請求項1】

発光層が窒化物系化合物半導体である発光素子と、該発光素子からの発光の少なくとも一部を吸収し前記発光素子からの発光よりも長波長光を発光するフォトルミネセンス蛍光体と、を有する発光装置であって、

前記フォトルミネセンス蛍光体が組成の異なる2種類以上のセリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体であることを特徴とする発光装置。

【請求項2】

前記セリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体が(R $e_x Sm_{1-x}$) $_3$ ($Al_y Ga_{1-y}$) $_5 Ol_2: Ce$ である請求項1記載の発光装置。但し、 $0 < x \le 1$ 、 $0 \le y \le 1$ 、Reは、Y、Gd、Laから選択される少なくとも一種である。

【請求項3】

前記セリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体は、 $Y_3A1_5O_{12}$: Ceo主発光波長よりも短波長側に主発光波長があるセリウムで付活されたイットリウム・アルニミウム酸化物系蛍光体と、 $Y_3A1_5O_{12}$: Ceo主発光波長よりも長波長側に主発光波長があるセリウムで付活されたイットリウム・アルニミウム酸化物系蛍光体である請求項1記載の発光装置。

【請求項4】

前記セリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体は、Y $_3$ (Al $_y$ Ga $_{1-y}$) $_5$ O $_{12}$: Ceである第 $_1$ の蛍光体と、Re $_3$ Al $_5$ O $_{12}$: Ceであって第 $_1$ の蛍光体の主発光波長よりも長波長側に主発光波長がある第 $_2$ の蛍光体である請求項 $_1$ 記載の発光装置。

但し、 $0 \le y \le 1$ 、Reは、Y、Gd、Laから選択される少なくとも一種である。

【請求項5】

前記組成が異なる2種類以上のセリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体は、Gdを有する第3の蛍光体と、第3の蛍光体よりもGdの組成比が高い第4の蛍光体である請求項1記載の発光装置。

【請求項6】

前記発光素子の主発光ピークが400nmから530nm内にある請求項1記載の発光装置。

【請求項7】

前記発光素子と光学的に接続された導光板上に配置されたフォトルミネッセンス蛍光体を有する色変換部材、或いは前記フォトルミネッセンス蛍光体を有する 色変換部材を介して発光素子と導光板とが光学的に接続されることによって面状 に発光可能な請求項1記載の発光装置。

【請求項8】

マウント・リードのカップ内に配置させた発光素子と、該発光素子と導電性ワイヤーを用いて電気的に接続させたインナー・リードと、前記カップ内に充填させたコーティング部材と、該コーティング部材、発光素子、導電性ワイヤー及びマウント・リードとインナー・リードの少なくとも一部を被覆するモールド部材と、を有する発光ダイオードであって、

前記発光素子の発光層が窒化物系化合物半導体であり、且つ前記コーティング 部材が前記発光素子からの発光の少なくとも一部を吸収し前記発光素子からの発 光よりも長波長光を発光する組成の異なる2種類以上のセリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体を有することを特徴とする発光装置。

【発明の詳細な説明】

[0001]

【産業上の利用分野】

本願発明は、バックライト光源、照光式スイッチ、信号機、表示器、LEDディスプレイ及び各種インジケータなどに利用される発光装置に係わり、特に使用環境によらず高輝度、高効率に所望の色に発光可能な発光装置に関する。

[0002]

【従来技術】

発光素子であるLEDチップを用いた発光装置は、小型で効率が良く鮮やかな色の発光をする。また、半導体素子であるため球切れなどの心配がない。初期駆動特性が優れ、振動やON/OFF点灯の繰り返しに強いという特徴を有する。そのため各種インジケータ、センサーや種々の光源として利用されている。最近、超高輝度高効率な発光ダイオードとして1000mcdにも及ぶ発光ダイオードがRGB(赤色系、緑色系、青色系)ともそれぞれ開発された。これに伴いRGBの三原色を利用した液晶用バックライトなどに使用可能なフルカラー用面状発光装置が省電力、長寿命、軽量などの特長を生かして研究されてきている。

[0003]

LEDチップは使用される発光層の半導体材料、形成条件などによって紫外から赤外まで種々の発光波長を放出させることが可能である。また、優れた単色性ピーク波長を有する。

[0004]

しかしながら、LEDチップを用いた発光装置は優れた単色性ビーク波長を有するが故に白色系発光光源などとさせるためには、RGBなどが発光可能な各LEDチップをそれぞれ近接して発光させ拡散混色させる必要がある。このような発光ダイオードは、種々の色を自由に発光させる発光装置としては有効であるが、白色系などの色のみを発光させる場合においても赤色系、緑色系及び青色系の発光ダイオードなどをそれぞれ使用せざるを得ない。LEDチップは、半導体であり色調や輝度のバラツキもまだ相当ある。また、同一半導体材料を用いて高輝度にRGBなどが発光可能なLEDチップは、未だ開発されていない。そのため、それぞれ異なる材料を用いて形成させざるを得ず、各LEDチップの駆動電力などが異なるため個々に電源などを確保する必要がある。白色系を発光させるためには、各半導体ごとに電流などを調節して発光させなければならない。同様に、半導体発光素子であるため個々の温度特性の差や経時変化が異なり、色調が種々変化してしまう。さらに、LEDチップからの発光を均一に混色させなければ、色むらを生ずる場合がある。

[0005]

そこで、本出願人は先にLEDチップの発光色を蛍光物質で色変換させた発光

ダイオードや面状発光装置として特開平5-152609号公報、特開平7-176794号公報、特開平8-8614号公報などに記載された発光ダイオードや面状発光光源を開発した。これらの発光ダイオードや面状発光光源によって、1種類のLEDチップを用いて白色系など他の発光色を発光させることができる

[0006]

具体的には、青色が発光可能なLEDチップを透明な導光板の一端に接続させ LEDチップから発光された発光を導光板上に設けられた蛍光物質含有層によっ て緑色及び赤色などに色変換させ白色系の発光とさせるものである。これらは、 RGB発光成分を有する白色系が発光可能な発光装置として利用した場合におい ても十分な輝度を長時間に渡って発光する発光装置とすることができる。

[0007]

【発明が解決しようとする課題】

LEDチップからの発光によって励起される蛍光物質は、蛍光染料、蛍光顔料さらには有機、無機化合物などから様々なものが挙げられる。蛍光体の励起波長や発光波長によっても種々のものが挙げられる。また、蛍光体は、発光素子からの発光波長を波長の短いものから長い波長へと変換する、或いは発光素子からの発光波長を波長の長いものから短い波長へと変換するものとがある。

[0008]

しかしながら、波長の長いものから短い波長へと変換する場合、変換効率が極めて悪く実用に向かない。また、発光装置を直射日光など外部環境下で使用する場合や蛍光体をLEDチップ周辺に近接して配置させた場合は、紫外線など様々な高エネルギー光が蛍光体などに長期間に渡って強照射され続ける。特に、蛍光物質を励起し且つ二次的な放出を行うのに十分に高いエネルギーを放出可能な高エネルギーバンドギャップを有する半導体発光素子からの光エネルギーは、必然的に高くなる。そのため、太陽光などの外来光からとの相乗作用でも蛍光物質自体が劣化しやすい。

[0009]

蛍光物質が劣化すると色調がずれる、或いは蛍光物質が黒ずみ光の外部取り出

し効率が低下する場合がある。同様に蛍光物質は、LEDチップの昇温や外部環境からの加熱など高温にもさらされる。さらに、発光装置は一般的に樹脂ケースに被覆されてはいるものの外部環境からの水分の進入などを完全に防ぐことや、製造時に付着した水分を完全に除去することはできない。蛍光物質によっては、このような水分が発光素子からの高エネルギー光や熱によって蛍光物質の劣化を促進する場合もある。また、イオン性の有機染料に至ってはチップ近傍では直流電界により電気泳動を起こし、色調が変化する可能性がある。したがって、本願発明は上記課題を解決し、野外の使用時などにおいてもより長時間、発光効率の低下や色ずれが極めて少なく所望の発光成分を高輝度に発光可能な発光装置を提供することを目的とする。

[0010]

【課題を解決するための手段】

本願発明の発光装置は、発光層が窒化物系化合物半導体である発光素子と、該 発光素子からの発光の少なくとも一部を吸収し前記発光素子からの発光よりも長 波長光を発光するフォトルミネセンス蛍光体と、を有すると共に、フォトルミネ センス蛍光体が組成の異なる2種類以上のセリウムで付活されたイットリウム・ アルミニウム酸化物系蛍光体である。

[0011]

本願発明の請求項 2 に記載の発光装置は、前記セリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体が(Re_xSm_{1-x}) $_3$ (Al_yGa_{1-y}) $_5O_{12}$: Ce である。(但し、0 < x \leq 1 、0 \leq y \leq 1 、Re は、Y 、Gd 、La から 選択される少なくとも一種である。)

本願発明の請求項3に記載の発光装置は、前記セリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体が、 $Y_3Al_5O_{12}$: Ceo主発光波長よりも短波長側に主発光波長があるセリウムで付活されたイットリウム・アルニミウム酸化物系蛍光体と、 $Y_3Al_5O_{12}$: Ceo主発光波長よりも長波長側に主発光波長があるセリウムで付活されたイットリウム・アルニミウム酸化物系蛍光体である。

[0012]

本願発明の請求項4に記載の発光装置は、セリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体が、 Y_3 (Al_yGa_{1-y}) $_5O_{12}$: Ceである第1の蛍光体と、 $Re_3Al_5O_{12}$: Ceであって第1の蛍光体の主発光波長よりも長波長側に主発光波長がある第2の蛍光体である。(但し、 $0 \le y \le 1$ 、Reは、Y、Gd、Laから選択される少なくとも一種である。)

本願発明の請求項5記載の発光装置は、セリウムで付活されたイットリウム・ アルミニウム酸化物系蛍光体は、Gdを有する第3の蛍光体と、第3の蛍光体よりもGdが多い第4の蛍光体である。

[0013]

本願発明の請求項6に記載の発光装置は、発光素子の主発光ピークが400nmから530nm内である。

[0014]

本願発明の請求項7に記載の発光装置は、発光素子と光学的に接続された導光 板上に配置されたフォトルミネッセンス蛍光体を有する色変換部材、或いは前記 フォトルミネッセンス蛍光体を有する色変換部材を介して発光素子と導光板とが 光学的に接続されることによって面状に発光可能な発光装置である。

[0015]

本願発明の請求項8に記載の発光装置は、マウント・リードのカップ内に配置させた発光素子と、該発光素子と導電性ワイヤーを用いて電気的に接続させたインナー・リードと、前記カップ内に充填させたコーティング部材と、該コーティング部材、発光素子、導電性ワイヤー及びマウント・リードとインナー・リードの少なくとも一部を被覆するモールド部材と、を有する発光ダイオードであって

前記発光素子の発光層が窒化物系化合物半導体であり、且つ前記コーティング 部材が前記発光素子からの発光の少なくとも一部を吸収し前記発光素子からの発 光よりも長波長光を発光する組成の異なる2種類以上のセリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体を有する。

[0016]

【作用】

本願発明の発光装置は、発光素子と、発光素子からの光によって励起されそれよりも長波長側の光を発光する蛍光物質とを有している。蛍光物質は、組成の異なる2種類以上のイットリウム・アルミニウム酸化物系蛍光体を用いている。これによって、所望の発光色が効率よく発光可能な発光装置とすることができる。即ち、半導体発光素子から放出される発光波長がその半導体発光素子毎によって図8のA点からB点の範囲であるとすると、組成の異なる2種類以上のイットリウム・アルミニウム酸化物系蛍光体の色度点である図8のC点及びD点で囲まれた斜線内にある任意の発光色を発光させることができる。特に、発光素子、蛍光体の組成或いはその量を種々選択させることができる。特に、発光素子の発光ばらつきを蛍光体を種々選択させることによって吸収させ所望の発光波長が得られる発光装置とすることができる。また、蛍光物質の発光波長を選択させることによってRGBの発光成分を高輝度に含んだ発光装置とさせることができる。

[0017]

さらに、イットリウム・アルミニウム酸化物系蛍光体は、長時間高輝度に発光可能な発光装置として利用することができる。また、発光素子からの光よりもより長波長側に発光する蛍光物質とさせることによって、効率よく発光可能である。また、変換された光は発光チップから放出される光よりも長波長側になっているために、発光チップのバンドギャップよりも小さく発光素子に吸収されにくい。そのため蛍光体が等方的に発光して発光素子側に向かったとしても発光素子に吸収されず効率よく発光可能となる。

[0018]

【発明の実施の形態】

本願発明者は、種々の実験の結果、可視光域における光エネルギーが比較的高いLEDチップからの発光光をフォトルミネセンス蛍光体によって色変換させる発光装置において、特定の半導体及び蛍光体を選択することにより高輝度、長時間の使用時における光効率低下や色ずれを防止できること及び歩留まりの高い発光装置が形成できることを見出し本願発明を成すに至った。

[0019]

即ち、本願発明の発光装置に用いられるフォトルミネセンス蛍光体としては、1. 耐光性に優れていることが要求される。特に、様々な高エネルギー光が照射される直射日光などから長時間耐える必要もある。また、発光ダイオードとして使用する場合、半導体発光素子などの微小領域から強放射されるために(Ee)=3W・cm⁻²以上にも及ぶ強照射強度にも耐える必要がある。2. 発光素子との混色を利用するため紫外線ではなく青色系発光などの可視光で効率よく発光すること。3. 混色を考慮して緑色系及び赤色系の光などが高輝度に発光可能なこと。4. 外部環境下や発光素子近傍に配置されるため温度特性が良好であること。5. 色調が組成比或いは緑色系や赤色系などの蛍光体の混合比で連続的に変えられること。6. 発光装置の利用環境に応じて耐候性があることなどの特徴を有することが求められる。

[0020]

上記の条件を満たすものとして本願発明は、発光素子として発光層に高エネルギーバンドギャップを有する窒化物系化合物半導体素子を、フォトルミネセンス蛍光体として組成の異なる2種類以上のフォトルミネセンス蛍光体が、セリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体を用いる。これにより本願発明は、発光素子の製造工程などによって発光素子から放出される発光波長が所望値からずれたとしても2種類以上の蛍光体を調節させることによって所望の色調を持った発光装置とできる。より具体的には、セリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体として(RexSm1-x)3(AlyGa1-y)5〇12:Ceを用いる。(但し、O<x \le 1、O \le y \le 1、Reは、Y、Gd、Laから選択される少なくとも一種である。)これにより発光素子から放出された可視光域における高エネルギー光を長時間近傍で高輝度に照射した場合や外部環境の使用下においても発光色の色ずれや発光輝度の低下が極めて少ない高輝度に所望の発光成分を有する発光装置とすることができるものである。

[0021]

以下、具体的な発光装置の一例として、チップタイプLEDを図1に示す。チップタイプLEDの筐体内に窒化ガリウム系半導体を用いたLEDチップ102 をエポキシ樹脂などを用いて固定させてある。LEDチップ102は、470 n mのIno 4Gao 6N半導体発光層を有する発光素子を用いた。発光素子は、サ ファイア基板上にN型導電性を有する窒化ガリウム半導体であるコンタクト層、 P型導電性を有する窒化ガリウムアルミニウム半導体であるクラッド層、P型導 電性を有する窒化ガリウム半導体であるコンタクト層を形成させた。N型導電性 を有するコンタクト層とP型導電性を有するクラッド層との間に厚さ約3nmで あり、単一量子井戸構造とされるノンドープInGaNの活性層を形成させた。 (なお、サファイア基板上には、低温で窒化ガリウム半導体を形成させバッファ 層とさせてある。)このような発光素子102の電極と筐体に設けられた各電極 105とを導電性ワイヤーである金線103でそれぞれ電気的に接続させてある 。緑色系のフォトルミネセンス蛍光体としてYaAl5〇12:Ce蛍光体をまた赤 色系のフォトルミネセンス蛍光体として(Y_{0.8}Gd_{0.2})₃Al₅O₁₂:Ce蛍光 体をアクリル樹脂中に混合分散させたものを発光素子であるLEDチップ、導電 性ワイヤーなどを外部応力などから保護するモールド部材101として均一に硬 化形成させる。このような発光装置に電力を供給させることによってLEDチッ プを発光させる。LEDチップからの青色系の発光と、その発光によって励起さ れそれぞれ高輝度に発光可能な2種類以上のフォトルミネセンス蛍光体からの発 光光との混色により白色系などが発光可能な発光装置の一例である発光ダイオー ドとすることができる。また、このように形成された発光ダイオードは、蛍光体 が含有されない発光ダイオードにおいて通常発光時に見られる発光パターンがな い。LEDチップの発光面状に形成された電極などが陰になることによって形成 される発光パターンは、蛍光物質の散乱などによって均一にされる。そのためよ り均一発光が可能な発光ダイオードともなる。以下、本願発明の構成部材につい て詳述する。

[0022]

(フォトルミネセンス蛍光体)

本願発明に用いられるフォトルミネセンス蛍光体としては、半導体発光素子から発光された可視光や紫外線で励起されて発光するフォトルミネセンス蛍光体をいう。特に本願発明においては、フォトルミネセンス蛍光体が組成の異なる2種類以上のセリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体を利

用する。発光層に窒化物系化合物半導体を用いた発光素子から発光した青色系の光と、青色光を吸収させるためボディーカラーが黄色であるフォトルミネセンス 蛍光体から発光する緑色系及び赤色系の光と、或いは、黄色系の光であってより 緑色系及びより赤色系の光を混色表示させると所望の白色系発光色表示を行うことができる。発光装置はこの混色を起こさせるためにフォトルミネセンス蛍光体の粉体やバルクをエポキシ樹脂、アクリル樹脂或いはシリコーン樹脂などの各種 樹脂や酸化珪素、酸化アルミニウムなどの無機物中に含有させることが好ましい。このようにフォトルミネセンス蛍光体が含有されたものは、LEDチップからの光が透過する程度に薄く形成させたドット状のものや層状ものなど用途に応じて種々用いることができる。フォトルミネセンス蛍光体と樹脂などとの比率や塗布、充填量を種々調整すること及び発光素子の発光波長を選択することにより白色を含め電球色など任意の色調を提供させることができる。

[0023]

また、フォトルミネセンス蛍光体の分布を種々変えることによって耐候性の強い発光装置など種々の特性を持たせることができる。このような分布はフォトルミネセンス蛍光体を含有する部材、形成温度、粘度やフォトルミネセンス蛍光体の形状、粒度分布などを調整させることによって種々調整させることができる。したがって、使用条件などにより蛍光体の分布濃度を、種々選択することができる。また、2種類以上の蛍光体をそれぞれ発光素子からの入射光に対して順に配置させることによって効率よく発光可能な発光装置とすることができる。即ち、反射部材を有する発光素子上には、長波長側に吸収波長があり長波長に発光可能な蛍光体が含有された色変換部材と、それよりも長波長側に吸収波長がありより長波長に発光可能な色変換部材とを積層などさせることで反射光を有効利用することができる。

[0024]

本願発明のフォトルミネセンス蛍光体を使用すると、放射照度として(Ee) $=3W\cdot c\ m^{-2}$ 以上 $10W\cdot c\ m^{-2}$ 以下のLEDチップと接する或いは近接して配置された場合においても高効率に十分な耐光性を有する発光装置とすることができる。

[0025]

本願発明に用いられるセリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体である緑色系が発光可能なYAG系蛍光体では、ガーネット構造のため、熱、光及び水分に強く、図4(A)の実線の例の如く励起スペクトルのピークが450mm付近にさせることができる。また、発光ピークも図4(B)の実線の例の如く510mm付近にあり700mmまで裾を引くブロードな発光スペクトルを持つ。一方、セリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体である赤色系が発光可能なYAG系蛍光体でも、ガーネット構造であり熱、光及び水分に強く、図4(A)の波線の例の如く励起スペクトルのピークが450mm付近にさせることができる。また、発光ピークも図4(B)の波線の例の如く600mm付近にあり750mmまで裾を引くブロードな発光スペクトルを持つ。

[0026]

ガーネット構造を持ったYAG系蛍光体の組成の内、A1の一部をGaで置換することで発光波長が短波長側にシフトし、また組成のYの一部をGd及び/又はLaで置換することで、発光波長が長波長側へシフトする。A1のGaへの置換は、発光効率と発光波長を考慮してGa:A1=1:1から4:6が好ましい。同様に、Yの一部をGd及び/乂はLaで置換することは、Y:Gd及び/乂はLa=9:1から1:9であり、より好ましくは、Y:Gd及び/又はLa=1:4から2:3である。置換が2割未満では、緑色成分が大きく赤色成分が少なくなる。また、8割以上では、赤み成分が増えるものの輝度が急激に低下する

[0027]

このようなフォトルミネセンス蛍光体は、Y、Gd、Ce、La、A1、Sm 及びGaの原料として酸化物、又は高温で容易に酸化物になる化合物を使用し、それらを化学量論比で十分に混合して原料を得る。又は、Y、Gd、Ce、La、Smの希土類元素を化学量論比で酸に溶解した溶解液を蓚酸で共沈したものを 焼成して得られる共沈酸化物と、酸化アルミニウム、酸化ガリウムとを混合して混合原料を得る。これにフラックスとしてフッ化アンモニウム等のフッ化物を適

量混合して坩堝に詰め、空気中1350~1450°Cの温度範囲で2~5時間 焼成して焼成品を得、次に焼成品を水中でボールミルして、洗浄、分離、乾燥、 最後に篩を通すことで得ることができる。

[0028]

組成の異なる2種類以上のセリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体は、混合させて用いても良いし、それぞれ独立して配置させても良い。蛍光体をそれぞれ独立して配置させる場合、発光素子から光をより短波波長側で吸収発光しやすい蛍光体、それよりも長波長側で吸収発光しやすい蛍光体の順に配置させることが好ましい。これによって効率よく吸収及び発光させることができる。

[0029]

(発光素子102、202、302)

本願発明に用いられる発光素子とは、組成の異なる2種類以上のセリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体をそれぞれ効率良く励起できる窒化物系化合物半導体が挙げられる。発光素子であるLEDチップは、MOCVD法等により基板上にAIN、InN、GaN、InGaNやInGaAIN等の半導体を発光層として形成させることができる。半導体の構造としては、MIS接合、PIN接合やPN接合などを有するホモ構造、ヘテロ構造あるいはダブルヘテロ構成のものが挙げられる。また、半導体活性層を量子効果が生ずる薄膜に形成させた単一量子井戸構造や多重量子井戸構造とすることもできる。半導体層の材料、構造やその混晶度によって発光波長を種々選択することができるが、フォトルミネセンス蛍光物質を効率よく励起させるためにフォトルミネセンス蛍光物質の発光波長よりも短い発光波長を発光することが好ましい。

[0030]

半導体基板にはサファイヤ、スピネル、SiC、Si、ZnO、GaN等の材料が好適に用いられる。結晶性の良い窒化物系化合物半導体を形成させるためにはサファイヤ基板を用いることが好ましい。このサファイヤ基板上にGaN、A1N等のバッファー層を形成しその上にPN接合を有する窒化物系化合物半導体を形成させることができる。窒化ガリウム系半導体は、不純物をドープしない状

態でN型導電性を示す。発光効率を向上させるなど所望のN型窒化ガリウム半導体を形成させる場合は、N型ドーパントとしてSi、Ge、Se、Te、C等を適宜導入することが好ましい。一方、P型窒化ガリウム半導体を形成させる場合は、P型ドーパンドであるZn、Mg、Be、Ca、Sr、Ba等をドープさせる。窒化ガリウム系化合物半導体は、P型ドーパントをドープしただけではP型化しにくいためP型ドーパント導入後に、炉による加熱、低電子線照射、プラズマ照射等によりアニールすることでP型化させることが好ましい。エッチングなどによりP型半導体及びN型半導体の露出面を形成させた後、半導体層上にスパッタリング法や真空蒸着法などを用いて所望の形状の各電極を形成させる。

[0031]

次に、形成された半導体ウエハー等をダイヤモンド製の刃先を有するブレードが回転するダイシングソーにより直接フルカットするか、又は刃先幅よりも広い幅の溝を切り込んだ後(ハーフカット)、外力によって半導体ウエハーを割る。あるいは、先端のダイヤモンド針が往復直線運動するスクライバーにより半導体ウエハーに極めて細いスクライブライン(経線)を例えば碁盤目状に引いた後、外力によってウエハーを割り半導体ウエハーからチップ状にカットする。このようにして窒化ガリウム系化合物半導体である発光素子を形成させることができる

[0032]

本願発明の発光装置において白色系を発光させる場合は、フォトルミネセンス 蛍光体との混色等を考慮して発光素子の主発光波長は400 n m以上530 n m 以下内にあることが好ましく、420 n m以上490 n m以下内にあることがよ り好ましい。LEDチップとフォトルミネセンス蛍光体との効率をそれぞれより 向上させるためには、450 n m以上475 n m以下内にあることがさらに好ま しい。このような発光素子は、単色性ピーク波長を持つといってもある程度のス ペクトル幅を持つため演色性の高い発光装置を形成させることができる。

[0033]

(導電性ワイヤー103、303)

導電性ワイヤーとしては、発光素子102、302の電極とのオーミック性、

機械的接続性、電気伝導性及び熱伝導性がよいものが求められる。熱伝導度としては0.01 cal/cm²/cm/℃以上が好ましく、より好ましくは0.5 cal/cm²/cm/℃以上である。また、作業性などを考慮して導電性ワイヤーの直径は、好ましくは、Φ10μm以上、Φ45μm以下である。このような導電性ワイヤーとして具体的には、金、銅、白金、アルミニウム等の金属及びそれらの合金を用いた導電性ワイヤーが挙げられる。このような導電性ワイヤーは、各LEDチップの電極と、インナー・リード306及びマウント・リード305などと、をワイヤーボンディング機器によって容易に接続させることができる。

[0034]

(マウント・リード305)

マウント・リード305としては、発光素子302を配置させるものであり、 ダイボンド機器などで発光素子であるLEDチップ302を積載するのに十分な 大きさがあれば良い。また、LEDチップを複数設置しマウント・リードをLE Dチップの共通電極として利用する場合においては、十分な電気伝導性とボンディングワイヤー等との接続性が求められる。また、マウント・リード上のカップ 内にLEDチップを配置すると共に蛍光体を内部に充填させる場合は、近接して 配置させた別の発光ダイオードからの光により疑似点灯することを防止させることができる。

[0035]

LEDチップ302とマウント・リード305のカップとの接着は熱硬化性樹脂などによって行うことができる。具体的には、エポキシ樹脂、アクリル樹脂やイミド樹脂などが挙げられる。また、フェースダウンLEDチップなどによりマウント・リードと接着させると共に電気的に接続させるためにはAgペースト、カーボンペースト、金属バンプ等を用いることができる。

[0036]

さらに、発光ダイオードの光利用効率を向上させるためにLEDチップ302 が配置されるマウント・リードの表面を鏡面状とし、表面に反射機能を持たせて も良い。この場合の表面粗さは、0.1S以上0.8S以下が好ましい。また、 マウント・リードの具体的な電気抵抗としては $300\mu\Omega$ -c m以下が好ましく、より好ましくは、 $3\mu\Omega$ -c m以下である。

[0037]

また、マウント・リード上に複数のLEDチップを積置する場合は、LEDチップからの発熱量が多くなるため熱伝導度がよいことが求められる。具体的には、 $0.01ca1/cm^2/cm/^{\mathbb{C}}$ 以上が好ましく、より好ましくは $0.5ca1/cm^2/cm/^{\mathbb{C}}$ 以上である。これらの条件を満たす材料としては、鉄、銅、鉄入り銅、錫入り銅、メタライズパターン付きセラミック等が挙げられる。

[0038]

(インナー・リード306)

インナー・リード306としては、マウント・リード305上に配置されたLEDチップと接続された導電性ワイヤーとの接続を図るものである。マウント・リード上に複数のLEDチップ302を設けた場合は、各導電性ワイヤー同士が接触しにくい構成とすることが好ましい。

[0039]

具体的には、マウント・リード305から離れるに従って、インナー・リード306のワイヤーボンディングさせる端面の面積を大きくする或いは、マウント・リードから離れるに従って端面の高さを高くさせることなどによってマウント・リードからより離れたインナー・リードと接続させる導電性ワイヤーの接触を防ぐことができる。

[0040]

また、導電性ワイヤーとの接続端面の粗さは、密着性を考慮して1.6 S以上10 S以下が好ましい。インナー・リードの先端部を種々の形状に形成させるためには、あらかじめリードフレームの形状を型枠で決めて打ち抜き形成させてもよく、或いは全てのインナー・リードを形成させた後にインナー・リード上部の一部を削ることによって形成させても良い。さらには、インナー・リードを打ち抜き形成後、端面方向から加圧することにより所望の端面の面積と端面高さを同時に形成させることもできる。

[0041]

インナー・リードは、導電性ワイヤーであるボンディングワイヤー等との接続性及び電気伝導性が良いことが求められる。具体的な電気抵抗としては、300 $\mu\Omega-c$ m以下が好ましく、より好ましくは $3\mu\Omega-c$ m以下である。これらの条件を満たす材料としては、鉄、銅、鉄入り銅、錫入り銅及び銅、金、銀をメッキしたアルミニウム、鉄、銅等が挙げられる。

[0042]

(コーティング部材301)

本願発明に用いられるコーティング部材301とは、モールド部材304とは別にマウント・リード305のカップに設けられるものであり発光素子302の発光を変換するフォトルミネセンス蛍光体が含有されるものである。コーティング部の具体的材料としては、エポキシ樹脂、ユリア樹脂、シリコーンやアクリル樹脂などの耐候性に優れた透明樹脂やケイ化物である酸化珪素、酸化アルミなどの無機物質などが好適に用いられる。また、フォトルミネセンス蛍光体と共に拡散剤を含有させても良い。具体的な拡散剤としては、チタン酸バリウム、酸化チタン、酸化アルミニウム、酸化珪素等が好適に用いられる。さらに、光安定化剤として紫外線吸収剤を含有させても良い。

[0043]

(モールド部材101、210、304)

モールド部材は、発光装置の使用用途に応じてLEDチップ、導電性ワイヤー、フォトルミネセンス蛍光体が含有されたコーティング部材などを外部から保護するために設けることができる。モールド部材は、樹脂などの有機物質や硝子などの無機物質を用いて形成させることができる。モールド部材中にフォトルミネセンス蛍光体を含有させることによって視野角を増やすことができる。また、拡散剤を加えることによってLEDチップからの指向性を緩和させ視野角をさらに増やすこともできる。さらに安定発光させるために紫外線吸収剤などの光安定化剤を含有させても良い。

[0044]

更に、モールド部材を所望の形状にすることによってLEDチップからの発光 を集束させたり拡散させたりするレンズ効果を持たせることができる。従って、 モールド部材は複数積層した構造でもよい。具体的には、凸レンズ形状、凹レンズ形状さらには、発光観測面から見て楕円形状やそれらを複数組み合わせたものが学げられる。

[0045]

モールド部材の具体的材料としては、主としてエポキシ樹脂、ユリア樹脂、シリコーン、アクリル樹脂などの耐候性に優れた透明樹脂や低融点硝子などが好適に用いられる。また、拡散剤としては、チタン酸バリウム、酸化チタン、酸化アルミニウム、酸化珪素等が好適に用いられる。フォトルミネセンス蛍光体はモールド部材中に含有させてもそれ以外のコーティング部などに含有させて用いてもよい。また、コーティング部をフォトルミネセンス蛍光体が含有された樹脂、モールド部材を硝子などとした異なる部材を用いて形成させても良い。この場合、生産性良くより水分などの影響が少ない発光ダイオードとすることができる。屈折率を考慮してモールド部材とコーティング部とを同じ部材を用いて形成させても良い。

[0046]

(面状光源)

本願発明の発光装置の一つである面状光源の場合、図2(A)の如く白色光を 発光させるためには白色光を導光板によって面状とさせ方法と、図2(B)の如 く面状に発光したLEDチップからの青色系光を白色光に変換させる方法がある

[0047]

白色光を導光板によって面状とさせる場合には、フォトルミネセンス蛍光体が 含有された色変換部材201を介して青色系が発光可能な発光ダイオード202 と、導光板204と、を配置させた構成、或いはモールド部材中210などにフ ォトルミネセンス蛍光体を含有させ青色系が発光可能な窒化物半導体発光素子を 有する発光ダイオード202と導光板204を光学的に接続させた構成をとるこ とができる。

[0048]

面状に発光したLEDチップ202からの青色系光を白色光に変換させる場合

は、窒化物半導体を発光層に有する青色系が発光可能な発光ダイオード202と 導光板204とを光学的に接続させた後、導光板204上の散乱シート206に 含有させる。或いはバインダー樹脂と共に散乱シートに塗布などさせシート状に 形成させる。さらには、導光板上にフォトルミネセンス蛍光体含有のバインダー をドット状に直接形成させる構成をとることができる。

[0049]

具体的には、絶縁層及び導電性パターンが形成されたコの字形状の金属基板203内などに発光素子であるLEDチップを固定する。LEDチップと導電性パターンとの電気的導通を取った後、エポキシ樹脂をLEDチップ202が積載された基板上に充填させアクリル性導光板204の端面と光学的に接続させる。導光板204の発光主面上には、フォトルミネセンス蛍光体をエポキシ樹脂中に混合撹拌し予め拡散シート上に均一塗布したシート部材201を積置させてある。この拡散シート部材206は、アクリル樹脂をベースに拡散剤として酸化アルミニウム、酸化珪素、酸化チタン、チタン酸バリウムの粒子などを含有させたエポキシ樹脂を塗布させた層と、フォトルミネセンス蛍光体を含有させた層とに分かれている。

[0050]

導光板の一方の主面上には、発光ダイオード近傍からの光が強発光する蛍現象防止のため白色散乱剤が含有されたフィルム状の反射部材207を配置させてあることが好ましい。同様に、導光板204の裏面側全面や発光ダイオードが配置されていない端面上にも反射部材205を設け発光効率を向上させてある。これにより、液晶のバックライトなどとして使用した場合においても十分な明るさを得られる面状光源とすることができる。液晶表示装置として利用する場合は、導光板の主面上に不示図の透光性導電性パターンが形成された硝子基板間に注入された液晶を介して配された偏光板により構成させることができる。以下、本願発明の実施例について説明するが、本願発明は具体的実施例のみに限定されるものではないことは言うまでもない。

[0051]

【実施例】

(実施例1)

発光素子として発光ピークが450nmのIn_{0.05}Ga_{0.95}N半導体を用いた。LEDチップは、洗浄させたサファイヤ基板上にTMG(トリメチルガリウム)ガス、TMI(トリメチルインジュウム)ガス、窒素ガス及びドーパントガスをキャリアガスと共に流し、MOCVD法で窒化ガリウム系化合物半導体を成膜させることにより形成させた。ドーパントガスとしてSiH₄とCp₂Mgと、を切り替えることによってN型導電性を有する窒化ガリウム半導体とP型導電性を有する窒化ガリウム半導体を形成しPN接合を形成させる。半導体発光素子としては、N型導電性を有する窒化ガリウム半導体であるコンタクト層、N型導電性を有する窒化ガリウムアルミニウム半導体であるクラッド層、P型導電性を有する窒化ガリウムアルミニウム半導体であるクラッド層、P型導電性を有する窒化ガリウムアルミニウム半導体であるクラッド層、P型導電性を有する窒化ガリウムアルミニウム半導体であるクラッド層、P型導電性を有する窒化ガリウムド導体であるコンタクト層を形成させた。N型導電性を有するクラッド層とP型導電性を有するクラッド層とP型導電性を有するクラッド層との間にダブルヘテロ接合となるZnドープInGaNの活性層を形成させた。(なお、サファイア基板上には、低温で窒化ガリウム半導体を形成させバッファ層とさせてある。P型半導体は、成膜後400℃以上でアニールさせてある。)

エッチングによりPN各半導体表面を露出させた後、スパッタリングにより各電極をそれぞれ形成させた。こうして出来上がった半導体ウエハーをスクライブラインを引いた後、外力により分割させ発光素子としてLEDチップを形成させた。

[0052]

銀メッキした銅製リードフレームの先端にカップを有するマウント・リードに LEDチップをエポキシ樹脂でダイボンディングした。LEDチップの各電極と マウント・リード及びインナー・リードと、をそれぞれ金線でワイヤーボンディ ングし電気的導通を取った。

[0053]

モールド部材は、砲弾型の型枠の中にLEDチップが配置されたリードフレームを挿入し透光性エポシキ樹脂を混入後、150℃5時間にて硬化させ青色系発光ダイオードを形成させた。青色系発光ダイオードを端面が全て研磨されたアク

リル性導光板の一端面に接続させた。アクリル板の片面及び側面は、白色反射部材としてチタン酸バリウムをアクリル系バインダー中に分散したものでスクリーン印刷及び硬化させた。

[0054]

一方、フォトルミネセンス蛍光体は、緑色系及び赤色系をそれぞれ必要なY、Gd、Ce、Laの希土類元素を化学量論比で酸に溶解した溶解液を蓚酸で共沈させた。これを焼成して得られる共沈酸化物と、酸化アルミニウム、酸化ガリウムと混合して混合原料をそれぞれ得る。これにフラックスとしてフッ化アンモニウムを混合して坩堝に詰め、空気中1400°Cの温度範囲で3時間焼成して焼成品を得た。焼成品をそれぞれ水中でボールミルして、洗浄、分離、乾燥、最後に篩を通して形成させた。

[0055]

形成された組成が Y_3 ($Al_{0.6}Ga_{0.4}$) $_5O_{12}$:Ceであり緑色系が発光可能な第1の蛍光体120重量部と同様の工程で形成され組成が($Y_{0.4}Gd_{0.6}$)3 Al_5O_{12} :Ceであり赤色系が発光可能な第2の蛍光体100重量部を、エポキシ樹脂100重量部とよく混合してスラリーとさせた。このスラリーを厚さ0.5 mmのアクリル層上にマルチコーターを用いて均等に塗布、乾燥し、厚さ約 30μ mの色変換部材として蛍光体層を形成させた。蛍光体層を導光板の主発光面と同じ大きさに切断し導光板上に配置させることにより発光装置を形成させた。発光装置の色度点、演色性指数を測定した。それぞれ、色度点(x=0.29,y=0.34)、Ra(演色性指数)=92.0と三波長型蛍光灯に近い性能を示した。また、発光効率は121m/wと白色電球並であった。さらに耐伏試験として室温60mA通電、室温20mA通電、60C90%RH下で20m

[0056]

(比較例1)

第1及び第2のフォトルミネセンス蛍光体をそれぞれペリレン系誘導体である 緑色有機蛍光顔料(シンロイヒ化学製FA-001)と赤色有機蛍光顔料(シン ロイヒ化学製FA-005)として同量で混合撹拌した以外は、実施例1と同様 にして発光ダイオードの形成及び耐侯試験を行った。形成された発光ダイオードの色度座標は、(X,Y)=(0.34,0.35)であった。耐侯性試験として、カーボンアークで紫外線量を200hrで太陽光の1年分とほぼ同等とさせ時間と共に輝度の保持率及び色調を測定した。また、信頼性試験としてLEDチップを発光させ70 $\mathbb C$ 一定における時間と共に発光輝度及び色調を測定した。この結果を実施例1と共に図6及び図7にそれぞれ示す。

[0057]

(実施例2)

[0058]

一方、フォトルミネセンス蛍光体は、緑色系及び赤色系をそれぞれ必要なY、Gd、Ceの希土類元素を化学量論比で酸に溶解した溶解液を蓚酸で共沈させた。これを焼成して得られる共沈酸化物と、酸化アルミニウム、酸化ガリウムと混合して混合原料をそれぞれ得る。これにフラックスとしてフッ化アンモニウムを混合して坩堝に詰め、空気中1400°Cの温度範囲で3時間焼成してそれぞれ焼成品を得た。焼成品を水中でボールミルして、洗浄、分離、乾燥、最後に篩を通して形成させた。

[0059]

形成された組成が Y_3 ($A_{10.5}Ga_{0.5}$) $_5O_{12}$:Ceであり緑色系が発光可能な第1の蛍光体と($Y_{0.2}Gd_{0.8}$) $_3A_{15}O_{12}$:Ceであり赤色系が発光可能な第2の蛍光体をそれぞれ $_4$ 0重量部、エポキシ樹脂 $_100$ 重量部をよく混合してスリラーとさせた。このスリラーをLEDチップが配置されたマウント・リード上のカップ内に注入させた。注入後、フォトルミネセンス蛍光体が含有された樹脂を $_130$ 1時間で硬化させた。こうしてLEDチップ上に厚さ $_120$ 4のフォトルミネセンス蛍光体が含有されたコーティング部材が形成された。なお、コ

ーティング部材には、LEDチップに向かってフォトルミネセンス蛍光体が徐々に多くしてある。その後、さらにLEDチップやフォトルミネセンス蛍光体を外部応力、水分及び塵芥などから保護する目的でモールド部材として透光性エポキシ樹脂を形成させた。モールド部材は、砲弾型の型枠の中にフォトルミネセンス蛍光体のコーティング部が形成されたリードフレームを挿入し透光性エポシキ樹脂を混入後、150℃5時間にて硬化させた。こうして形成された発光ダイオードは、発光観測正面から視認するとフォトルミネセンス蛍光体のボディーカラーにより中央部が黄色っぽく着色していた。

[0060]

こうして得られた白色系が発光可能な発光ダイオードの色度点、色温度、演色性指数を測定した。それぞれ、色度点(x=0. 32, y=0. 34)、Ra(演色性指数)=89. 0、発光効率は10 1 m/wであった。さらに耐侯試験として室温60 m A 通電、室温20 m A 通電、60 C90 % R H下で20 m A 通電の各試験においてもフォトルミネセンス蛍光体に起因する変化は観測されず通常の青色系発光ダイオードと寿命特性に差がないことが確認できた。

[0061]

(実施例3)

発光素子として発光ピークが470nmのIn_{0.4}Ga_{0.6}N半導体を用いた。LEDチップは、洗浄させたサファイヤ基板上にTMG(トリメチルガリウム)ガス、TMI(トリメチルインジュウム)ガス、窒素ガス及びドーパントガスをキャリアガスと共に流し、MOCVD法で窒化ガリウム系化合物半導体を成膜させることにより形成させた。ドーパントガスとしてSiH₄とCp₂Mgと、を切り替えることによってN型導電性を有する窒化ガリウム半導体とP型導電性を有する窒化ガリウム半導体を形成しPN接合を形成させる。半導体発光素子としては、N型導電性を有する窒化ガリウム半導体であるコンタクト層、P型導電性を有する窒化ガリウムアルミニウム半導体であるクラッド層、P型導電性を有する窒化ガリウム半導体であるコンタクト層を形成させた。N型導電性を有するコンタクト層とP型導電性を有するカラッド層との間に厚さ約3nmであり、単一量子井戸構造とされるノンドープInGaNの活性層を形成させた。(なお、サフ

ァイア基板上には、低温で窒化ガリウム半導体を形成させバッファ層とさせてある。)

エッチングによりPN各半導体表面を露出させた後、スパッタリングにより各電極をそれぞれ形成させた。こうして出来上がった半導体ウエハーをスクライブラインを引いた後、外力により分割させ発光素子としてLEDチップを形成させた。

[0062]

銀メッキした銅製リードフレームの先端にカップを有するマウント・リードに LEDチップをエポキシ樹脂でダイボンディングした。LEDチップの各電極と マウント・リード及びインナー・リードと、をそれぞれ金線でワイヤーボンディ ングし電気的導通を取った。

[0063]

モールド部材は、砲弾型の型枠の中にLEDチップが配置されたリードフレームを挿入し透光性エポシキ樹脂を混入後、150℃5時間にて硬化させ青色系発光ダイオードを形成させた。青色系発光ダイオードを端面が全て研磨されたアクリル性導光板の一端面に接続させた。アクリル板の片面及び側面は、白色反射部材としてチタン酸バリウムをアクリル系バインダー中に分散したものでスクリーン印刷及び硬化させた。

[0064]

一方、フォトルミネセンス蛍光体は、組成の異なる2種類以上のセリウムで付活されたイットリウム・アルミニウム酸化物系蛍光物質として比較的短波長側の黄色系が発光可能な蛍光体と、比較的長波長側の黄色系が発光可能な蛍光体を用いた。それぞれ必要なY、Gd、Ceの希土類元素を化学量論比で酸に溶解した溶解液を蓚酸で共沈させた。これを焼成して得られる共沈酸化物と、酸化アルミニウムと混合して混合原料をそれぞれ得る。これにフラックスとしてフッ化アンモニウムを混合して坩堝に詰め、空気中1400° Cの温度範囲で3時間焼成して焼成品を得た。焼成品をそれぞれ水中でボールミルして、洗浄、分離、乾燥、最後に篩を通して形成させた。

[0065]

形成された組成が($Y_{0.8}Gd_{0.2}$) $_3Al_5Ol_2$:Ceであり比較的短波長側の黄色系が発光可能な蛍光体100重量部と同様の工程で形成され組成が($Y_{0.4}Gd_{0.6}$) $_3Al_5Ol_2$:Ceであり比較的長波長側の黄色系が発光可能な蛍光体100重量部を、 $_7Ol_2$ に $_7Ol$

[0066]

【発明の効果】

高出力の窒化物系化合物半導体の発光素子と、この発光素子からの光によって 励起され発光する組成の異なる2種類以上のフォトルミネセンス蛍光体と、を利 用した本願発明の発光装置とすることにより、長時間高輝度時の使用においても 発光効率が高く所望の色が発光可能な発光装置とすることができる。特に、蛍光 体を励起する発光素子の発光波長が短く効率的に蛍光体が励起可能であると共に 蛍光体によって等法的に放出された光は発光素子の発光層に吸収されることなく 発光可能である。そのため、発光素子が反射性の部材の上に配置されるとより効 率よく発光可能となる。さらに、信頼性や省電力化、小型化さらには色温度の可 変性など車載や航空産業、一般電気機器に港内のブイ表示用や高速道路の標識照 明など屋外での表示や照明として新たな用途を開くことができる。また、白色は 人間の目で長時間視認する場合には刺激が少なく目に優しい発光ダイオードとす ることができる。

[0067]

特に、本願発明の請求項1に記載の構成とすることにより長時間の使用におい

ても色ずれ、発光効率の低下が極めて少なく高輝度に所望の発光成分を有する白色系が発光可能な発光装置とすることができる。また、2種類以上の組成の異なる蛍光体を利用することによって演色性が高い発光装置とすることができる。さらに、発光素子の発光波長がずれたとしても蛍光体の組成や含有量を調整させることによって一定の発光色が発光可能な量産性の良い発光装置とすることができる。

[0068]

本願発明の請求項2に記載のより具体的な構成とすることにより、長時間の使用においても色ずれ、発光効率の低下が極めて少なくより所望の光が発光可能な 発光装置とすることができる。

[0069]

本願発明の請求項3に記載の構成とすることにより、長時間の使用においても 色ずれ、発光効率の低下が極めて少なく白色系の光を発光させることができる。

[0070]

本願発明の請求項4に記載の構成とすることにより、長時間の使用においても 色ずれ、発光効率の低下が極めて少なく白色系の光を発光させることができる。

[0071]

本願発明の請求項5に記載の構成とすることにより、長時間の使用においても 色ずれ、発光効率の低下が極めて少なくより所望の光が発光可能な発光装置とす ることができる。

[0072]

本願発明の請求項6に記載の構成とすることにより、より効率よく長時間の使用においても色ずれ、発光効率の低下が極めて少なく発光装置とすることができる。

[0073]

本願発明の請求項7に記載の構成とすることにより、長時間の使用においても 色ずれ、発光効率の低下が極めて少なく白色系の光をより均一に面状に発光させ ることができる。

[0074]

本願発明の請求項8に記載の構成とすることにより、外部環境下においても長時間の使用においても色ずれ、発光効率の低下が極めて少なく高輝度にRGBの発光成分を有する白色系が発光可能な発光ダイオードとすることができる。

【図面の簡単な説明】

【図1】

図1は、本願発明の発光装置の模式的断面図である。

【図2】

図2は、本願発明の他の発光装置である面状光源の模式的断面図を示し、(A)は、導光板と発光ダイオードとの間にフォトルミネセンス蛍光体を有する面状光源であり、(B)は、導光板の主面上にフォトルミネセンス蛍光体を有する面状光源である。

【図3】

図3は、本願発明の他の発光装置である発光ダイオードの模式的断面図である

【図4】

図4 (A) は、本願発明に用いられる第1及び第2のフォトルミネセンス蛍光体の吸収スペクトルの一例を示し、図4 (B) は、本願発明に使用される第1及び第2のフォトルミネセンス蛍光体の発光スペクトルの一例を示した図である。

【図5】

図5は、木願発明に用いられる発光素子の発光スペクトル例を示した図である

【図6】

図6は、本願発明と、比較のために示した発光装置との耐候性試験における結果を示し(A)は輝度保持率と時間との関係、(B)は色調と時間との関係を示したグラフである。

【図7】

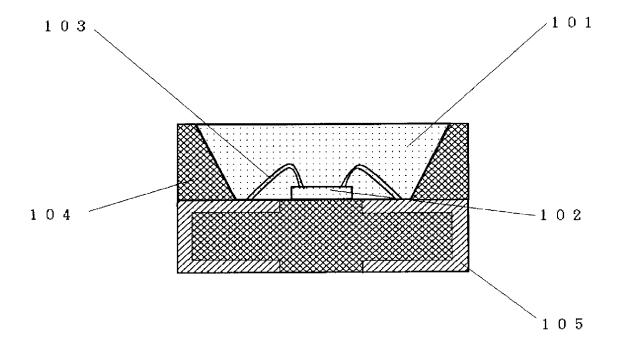
図7は、本願発明と、比較のために示した発光装置との信頼性試験における結果を示し(A)は輝度保持率と時間との関係、(B)は色調と時間との関係を示したグラフである。

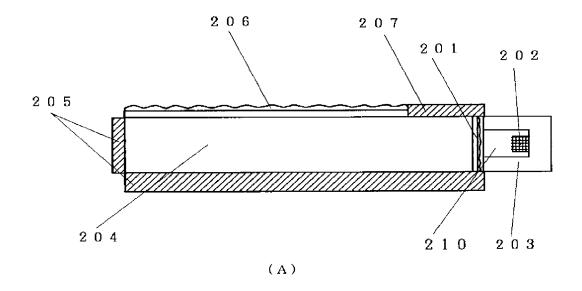
【図8】

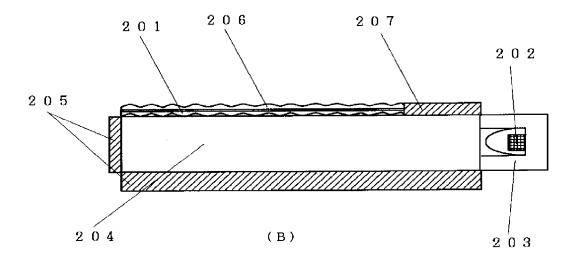
図8は、本願発明の発光装置が発光可能な色度図を表す。A及びB点は発光素子が発光する発光色を表し、C点、D点は、それぞれ2種類のフォトルミネッセンス蛍光体からの発光色を表す。

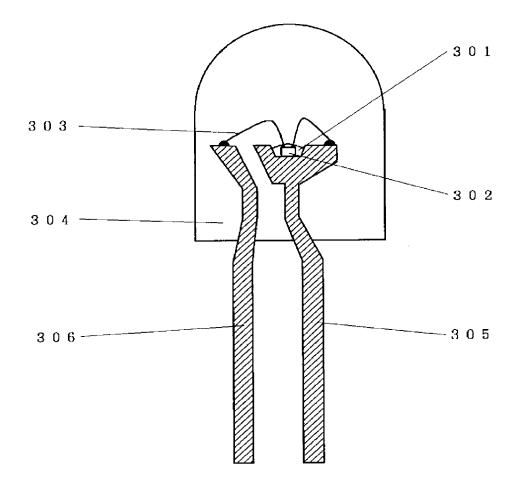
【符号の説明】

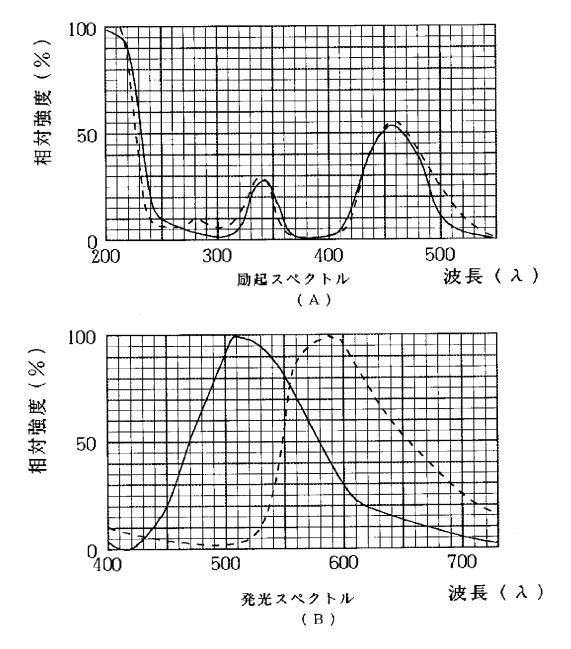
- 101、210・・・フォトルミネセンス蛍光体が含有されたモールド部材
- 102、202、302・・・発光素子
- 103、303・・・導電性ワイヤー
- 104・・・筐体
- 105・・・外部電極
- 201・・・色変換部材
- 203・・・支持体
- 204・・・導光板
- 205、207・・・反射部材
- 206・・・散乱シート
- 301・・・フォトルミネセンス蛍光体が含有されたコーティング部材
- 304・・・モールド部材
- 305・・・マウント・リード
- 306・・・インナー・リード

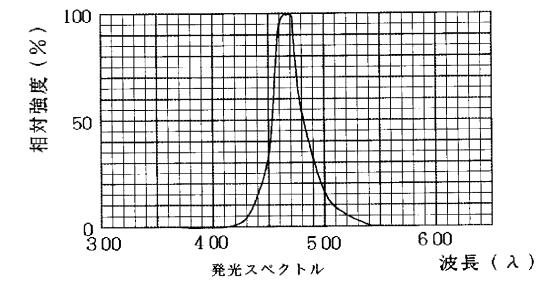




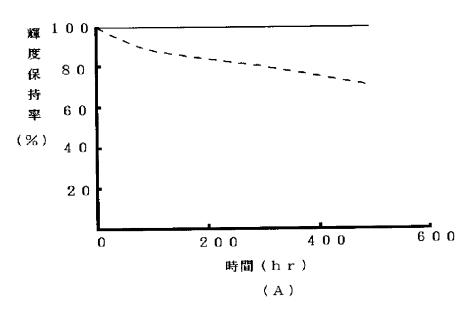


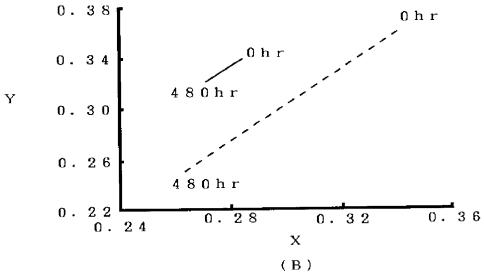




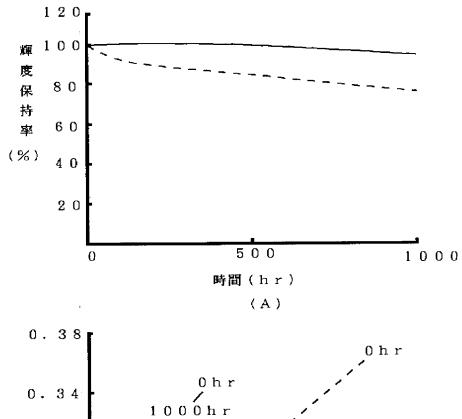


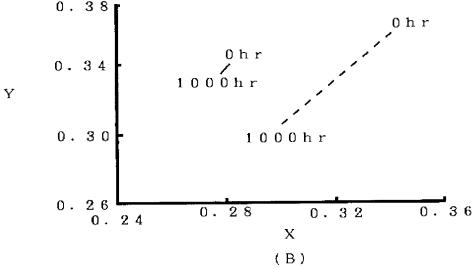


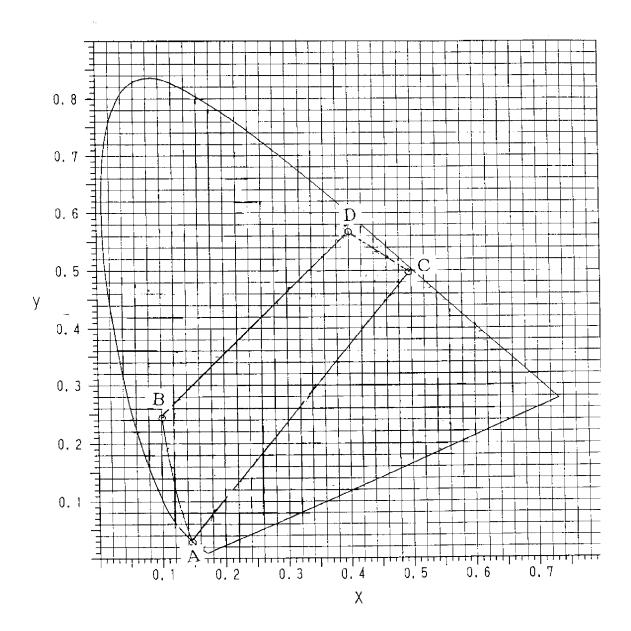












【書類名】 要約書

【要約】

【課題】

本発明は、バックライト光源、照光式スイッチ、信号機、表示器、LEDディスプレイ及び各種インジケータなどに利用される発光装置に係わり、特に使用環境によらず高輝度、高効率に所望の色に発光可能な発光装置に関する。

【解決手段】

本発明は、発光層が窒化物系化合物半導体である発光素子と、該発光素子からの発光の少なくとも一部を吸収し前記発光素子からの発光よりも長波長光を発光するフォトルミネセンス蛍光体と、を有する発光装置である。フォトルミネセンス蛍光体は、組成の異なる2種類以上のセリウムで付活されたイットリウム・アルミニウム酸化物系蛍光体である。

【選択図】図1

【書類名】 職権訂正データ

【訂正書類】 特許願

<認定情報・付加情報>

【特許出願人】 申請人

【識別番号】 000226057

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【氏名又は名称】 日亜化学工業株式会社

出願人履歴

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19900818

新規登録

徳島県阿南市上中町岡491番地100 日亜化学工業株式会社



UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION	FILING or	GRP ART				
NUMBER	371(c) DATE	UNIT	FIL FEE REC'D	ATTY.DOCKET.NO	TOT CLAIMS	IND CLAIMS
12/942.792	11/09/2010	2879	1090	0020-5147PUS12	19	1

CONFIRMATION NO. 2357

2292 BIRCH STEWART KOLASCH & BIRCH PO BOX 747 FALLS CHURCH, VA 22040-0747



FILING RECEIPT

Date Mailed: 11/23/2010

Receipt is acknowledged of this non-provisional patent application. The application will be taken up for examination in due course. Applicant will be notified as to the results of the examination. Any correspondence concerning the application must include the following identification information: the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please submit a written request for a Filing Receipt Correction. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections

Applicant(s)

Yoshinori Shimieu, Naka-gun, JAPAN; Kensho Sakano, Anan-shi, JAPAN; Yasunobu Noguchi, Naka-gun, JAPAN; Toshio Moriguchi, Anan-shi, JAPAN;

Power of Attorney: None

Domestic Priority data as claimed by applicant

This application is a DIV of 12/548,614 08/27/2009 which is a DIV of 12/028,062 02/08/2008 PAT 7,682,848 which is a DIV of 10/609,402 07/01/2003 PAT 7,362,048 which is a DIV of 09/458,024 12/10/1999 PAT 6,614,179 which is a DIV of 09/300,315 04/28/1999 PAT 6,069,440 which is a DIV of 08/902,725 07/29/1997 PAT 5,998,925

Foreign Applications

JAPAN P 08-198585 07/29/1996 JAPAN P 08-244339 09/17/1996 JAPAN P 08-245381 09/18/1996 JAPAN P 08-359004 12/27/1996 JAPAN P 09-081010 03/31/1997

Request to Retrieve - This application either claims priority to one or more applications filed in an intellectual property Office that participates in the Priority Document Exchange (PDX) program or contains a proper **Request to**

Retrieve Electronic Priority Application(s) (PTO/SB/38 or its equivalent). Consequently, the USPTO will attempt to electronically retrieve these priority documents.

If Required, Foreign Filing License Granted: 11/19/2010

The country code and number of your priority application, to be used for filing abroad under the Paris Convention, is **US 12/942,792**

Projected Publication Date: 03/03/2011

Non-Publication Request: No Early Publication Request: No

Title

LIGHT EMITTING DEVICE AND DISPLAY

Preliminary Class

313

PROTECTING YOUR INVENTION OUTSIDE THE UNITED STATES

Since the rights granted by a U.S. patent extend only throughout the territory of the United States and have no effect in a foreign country, an inventor who wishes patent protection in another country must apply for a patent in a specific country or in regional patent offices. Applicants may wish to consider the filing of an international application under the Patent Cooperation Treaty (PCT). An international (PCT) application generally has the same effect as a regular national patent application in each PCT-member country. The PCT process **simplifies** the filing of patent applications on the same invention in member countries, but **does not result** in a grant of "an international patent" and does not eliminate the need of applicants to file additional documents and fees in countries where patent protection is desired.

Almost every country has its own patent law, and a person desiring a patent in a particular country must make an application for patent in that country in accordance with its particular laws. Since the laws of many countries differ in various respects from the patent law of the United States, applicants are advised to seek guidance from specific foreign countries to ensure that patent rights are not lost prematurely.

Applicants also are advised that in the case of inventions made in the United States, the Director of the USPTO must issue a license before applicants can apply for a patent in a foreign country. The filing of a U.S. patent application serves as a request for a foreign filing license. The application's filing receipt contains further information and guidance as to the status of applicant's license for foreign filing.

Applicants may wish to consult the USPTO booklet, "General Information Concerning Patents" (specifically, the section entitled "Treaties and Foreign Patents") for more information on timeframes and deadlines for filing foreign patent applications. The guide is available either by contacting the USPTO Contact Center at 800-786-9199, or it can be viewed on the USPTO website at http://www.uspto.gov/web/offices/pac/doc/general/index.html.

For information on preventing theft of your intellectual property (patents, trademarks and copyrights), you may wish to consult the U.S. Government website, http://www.stopfakes.gov. Part of a Department of Commerce initiative, this website includes self-help "toolkits" giving innovators guidance on how to protect intellectual property in specific countries such as China, Korea and Mexico. For questions regarding patent enforcement issues, applicants may call the U.S. Government hotline at 1-866-999-HALT (1-866-999-4158).

LICENSE FOR FOREIGN FILING UNDER

Title 35, United States Code, Section 184

Title 37, Code of Federal Regulations, 5.11 & 5.15

GRANTED

The applicant has been granted a license under 35 U.S.C. 184, if the phrase "IF REQUIRED, FOREIGN FILING LICENSE GRANTED" followed by a date appears on this form. Such licenses are issued in all applications where the conditions for issuance of a license have been met, regardless of whether or not a license may be required as set forth in 37 CFR 5.15. The scope and limitations of this license are set forth in 37 CFR 5.15(a) unless an earlier license has been issued under 37 CFR 5.15(b). The license is subject to revocation upon written notification. The date indicated is the effective date of the license, unless an earlier license of similar scope has been granted under 37 CFR 5.13 or 5.14.

This license is to be retained by the licensee and may be used at any time on or after the effective date thereof unless it is revoked. This license is automatically transferred to any related applications(s) filed under 37 CFR 1.53(d). This license is not retroactive.

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No license under 35 U.S.C. 184 has been granted at this time, if the phrase "IF REQUIRED, FOREIGN FILING LICENSE GRANTED" DOES NOT appear on this form. Applicant may still petition for a license under 37 CFR 5.12, if a license is desired before the expiration of 6 months from the filing date of the application. If 6 months has lapsed from the filing date of this application and the licensee has not received any indication of a secrecy order under 35 U.S.C. 181, the licensee may foreign file the application pursuant to 37 CFR 5.15(b).



UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NUMBER FILING OR 371(C) DATE FIRST NAMED APPLICANT ATTY. DOCKET NO./TITLE

12/942,792 11/09/2010 Yoshinori Shimieu

0020-5147PUS12

2292 BIRCH STEWART KOLASCH & BIRCH PO BOX 747 FALLS CHURCH, VA 22040-0747 CONFIRMATION NO. 2357 IMPROPER CPOA LETTER



Date Mailed: 11/23/2010

NOTICE REGARDING POWER OF ATTORNEY

This is in response to the Power of Attorney filed 11/09/2010. The Power of Attorney in this application is not accepted for the reason(s) listed below:

• The Power of Attorney you provided did not comply with the new Power of Attorney rules that became effective on June 25, 2004. See 37 CFR 1.32.

	/cma/								
O(f) (D) 1		A 1: .:	 	070 4000	(574) 070	4000	4 000	700 0	

Office of Data Management, Application Assistance Unit (571) 272-4000, or (571) 272-4200, or 1-888-786-0101

PTO/SB/05 (08-08)
Approved for use through 06/30/2010. OMB 0651-0032
U.S. Patent and Trademark Office. U.S. DEPARTMENT OF COMMERCE

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UTILITY PATENT APPLICATION TRANSMITTAL

(Only for new nonprovisional applications under 37 CFR 1.53(b))

Attorney Docket No.	0020-5147PUS12
First Inventor	Yoshinori SHIMIZU
Title	LIGHT EMITTING DEVICE AND DISPLAY
Express Mail Label No.	

APPLICATION ELEMENTS See MPEP chapter 600 concerning utility patent application contents.	ADDRESS TO: Commissioner for Patents P.O. Box 1450 Alexandria VA 22313-1450		
1. Fee Transmittal Form (e.g., PTO/SB/17)	ACCOMPANYING APPLICATION PARTS		
2. Applicant claims small entity status. See 37 CFR 1.27. Specification [Total Pages 61] Both the claims and abstract must start on a new page (For information on the preferred arrangement, see MPEP 608.01(a))	9. Assignment Papers (cover sheet (PTO-1595) & document(s)) Name of Assignee		
4	10. 37 CFR 3.73(b) Statement Power of Attorney 11. English Translation Document (if applicable) 12. Information Disclosure Statement (PTO/SB/08 or PTO-1449)		
name in the prior application, see 37 CFR 1.63(d)(2) and 1.33(b). 6. Application Data Sheet. See 37 CFR 1.76	Copies of foreign patent documents, publications, & other information		
	13. Preliminary Amendment		
7. CD-ROM or CD-R in duplicate, large table or Computer Program (Appendix) Landscape Table on CD	14. Return Receipt Postcard (MPEP 503) (Should be specifically itemized)		
8. Nucleotide and/or Amino Acid Sequence Submission (if applicable, items a. – c. are required) a. Computer Readable Form (CRF) b. Specification Sequence Listing on:	 15. Certified Copy of Priority Document(s) (if foreign priority is claimed) 16. Nonpublication Request under 35 U.S.C. 122(b)(2)(B)(i). Applicant must attach form PTO/SB/35 or equivalent. 		
i.	17. Other: Copy of Letter submitting priority documents from		
c. Statements verifying identity of above copies	parent application.		
18. If a CONTINUING APPLICATION, check appropriate box, and sup specification following the title, or in an Application Data Sheet under 3	ply the requisite information below and in the first sentence of the		
	ation-in-part (CIP) of prior application No.: 12/548,614 Art Unit: 2812		
19. CORRESPON	DENCE ADDRESS		
The address associated with Customer Number:	OR Correspondence address below		
Name			
Address			
City	Zip Code		
Country	Email Email		
Signature	Date November 9, 2010		
Name (Print/Type) D. Richard Anderson	Registration No. (Attorney/Agent) 40,439		

This collection of information is required by 37 CFR 1.53(b). The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.11 and 1.14. This collection is estimated to take 12 minutes to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450. If you need assistance in completing the form, call 1-800-PTO-9199 and select option 2.

Docket No.: 0020-5147PUS12

(Patent)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

NEW

Confirmation No.: N/A

Filed:

November 9, 2010

Art Unit:

N/A

For: LIGHT EMITTING DEVICE AND DISPLAY

Examiner:

N/A

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Applicant(s) hereby submit(s) an Information Disclosure Statement for consideration by the Examiner.

I. <u>LIST OF PATENTS, PUBLICATIONS OR OTHER INFORMATION</u>

The patents, publications, or other information submitted for consideration by the Office are listed on the attached PTO/SB/08.

II. <u>COPIES</u>

a. Copies of foreign patent documents, non-patent literature and other information.

b. REFERENCES PREVIOUSLY CITED OR SUBMITTED: Copies of any information not provided can be found in one or more of the following applications which has been relied upon for an earlier filing date under 35 U.S.C. § 120:

U.S. Application No. and U.S. Filing Date 12/548,614, filed August 27, 2009

Application No.: NEW Docket No.: 0020-5147PUS12

Page 2 of 5

12/028,062, filed February 8, 2008, now U.S. Patent 7,682,848 10/609,402, filed July 1, 2003, now U.S. Patent 7,362,048 09/458,024, filed December 10, 1999, now U.S. Patent 6,614,179 09/300,315, filed April 28, 1999, now U.S. Patent 6,069,440 08/902,725, filed July 29, 1997, now U.S. Patent 5,998,925.

III. CONCISE EXPLANATION OF THE RELEVANCE/OTHER INFORMATION

a. NON-ENGLISH LANGUAGE DOCUMENTS: A concise explanation of the relevance of all non-English language patents, publications, or other information listed is as follows:

b. ENGLISH LANGUAGE SEARCH REPORT OR FOREIGN PATENT OFFICE COMMUNICATION: An English language version of the search report or Foreign Patent Office communication that indicates the degree of relevance is attached.

c. OTHER: The following additional information is provided.

All references were cited during prosecution of parent Application No. 12/548,614, filed August 27, 2009.

IV. STATEMENT UNDER 37 C.F.R. § 1.97(e)

The undersigned hereby states that:

a. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than <u>30</u> <u>days</u> prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or

Application No.: NEW Docket No.: 0020-5147PUS12

Page 3 of 5

b. Each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office; or

C. No item of information contained in the IDS was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing the certification after making reasonable inquiry, no item of IDS was known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of the IDS.

d. Some of the items of information in the IDS were cited in a communication from a foreign patent office. Such items were first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this IDS. This statement does not relate to English language counterparts not listed in a communication from the foreign patent office. Such English language counterparts are provided to aid the Examiner's consideration of non-English items first cited in the communication from the foreign patent office. As to the remaining items of information, to the knowledge of the person signing the certification after making reasonable inquiry, such remaining items were not known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of this statement.

V. FEES

a. This Information Disclosure Statement is being filed concurrently with the filing of a new patent application or Request for Continued Examination. No fee is required.

b. This Information Disclosure Statement is being filed within three months of the filing date of an application. No fee is required.

Application No.: NEW

Docket No.: 0020-5147PUS12

Page 4 of 5

	c.	This Information Disclosure Statement is being filed before the mailing date of a
first A please	Action of	on the merits. No fee is required. If a first Office Action on the merits has issued, the der this IDS under 37 C.F.R. § 1.97(c) and see the statement under 37 C.F.R.
		ve. If no statement has been made, charge our deposit account for the required fee.
	d. Office 7(c)(1)).	This Information Disclosure Statement is being filed <u>before</u> the mailing date of a Action or <u>before</u> the mailing date of a Notice of Allowance (see 37 C.F.R.
		No statement. The fee as required by 37 C.F.R. § 1.17(p) is provided. or
		See the above statement. No fee is required.
□ Final see the	e. Office A	This Information Disclosure Statement is being filed <u>after</u> the mailing date of a Action or <u>after</u> the mailing date of a Notice of Allowance (see 37 C.F.R. § 1.97(d)), tent above. The fee as required by 37 C.F.R. § 1.17(p) is provided.
VI.	PAYN	MENT OF FEES
		The required fee is listed on the attached Fee Transmittal.
		No fee is required.

Application No.: NEW Docket No.: 0020-5147PUS12

If the Examiner has any questions concerning this IDS, please contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the USPTO is requested to consider this IDS under the proper rule and charge the appropriate fee to Deposit Account No.

02-2448.

Dated: November 9, 2010

Respectfully submitted,

D. Richard Anderson

Registration No.: 40,439

BIRCH, STEWART, KOLASCH & BIRCH, LLP

Page 5 of 5

8110 Gatehouse Road, Suite 100 East

P.O. Box 747

Falls Church, VA 22040-0747

703-205-8000

Attacl	hment	(s):
_		

	PTO/SB/08
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 \square Document(s)

☐ Foreign Patent Office Communication

☐ Foreign Search Report

□ Fee

□ Other:

(4)

Approved for use through 07/31/2012. OMB 0651-0031
U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of informati

Substitute for form 1449/PTO				Complete if Known		
				Application Number	NEW	
	NFORMATIC			Filing Date	Concurrently Herewith	
S	TATEMENT	BY A	PPLICANT	First Named Inventor	Yoshinori SHIMIZU	
	(1150.00	-64-		Art Unit	N/A	
(Use as many sheets as necessary)			necessary)	Examiner Name	Not Yet Assigned	
Sheet	1	of	12	Attorney Docket Number	0020-5147PUS12	

			U.S. PA	TENT DOCUMENTS	
Examiner Initials*	Cite No.1	Document Number Number-Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
	AA*	US-5,700,713-A	12-23-1997	Yamazaki et al.	
	AB*	US-5,257,049	10-26-1993	Van Peteghem	
	AC*	US-6,812,500	11-02-2004	Reeh et al.	
	AD*	US-2001-0030326- A1	10-18-2001	Reeh et al.	
	AE'	US-6,576,930	06-10-2003	Reeh et al.	
	AF*	US-6,784,511	08-31-2004	Kunihara et al.	
	AG*	US-6,066,861	05-23-2000	Hohn et al.	
	АН"	US-5,959,316	09-28-1999	Lowery	
	Al*	US-5,118,985-A	06-02-1992	Patton et al.	
	AJ*	US-4,644,223	02-17-1987	de Hair et al.	
	AK*	US-6,538,371	03-25-2003	Duggal et al.	
	AL*	US-3,875,456	04-01-1975	Kano et al.	
	АМ*	US-3,510,732	05-05-1970	R.L. Amans	
	AN*	US-5,550,657	08-27-1996	Tanaka et al.	
	AO*	US-5,578,839	11-26-1996	Nakamura et al.	
	AP*	US-6,004,001-A	12-21-1999	Noll	
	AQ*	US-4,905,060	02-27-1990	Chinone et al.	
	AR*	US-3,652,956	03-28-1972	Pinnow et al.	
	AS*	US-4,314,910	02-09-1982	Barnes	

		FOREI	GN PATENT	DOCUMENTS		
Examiner	Clte	Foreign Patent Document	Publication	Name (Date)	Pages, Columns, Lines,	
Initials*	No.1	Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)	Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Where Relevant Passages Or Relevant Figures Appear	T ⁶
	BA	JP-2002-270020-A	09-20-2002	CASIO COMPUTER CO LTD		
	BB	JP-7-321407	12-08-1995	FUJI ELECTRIC CO LTD.		
	BC	JP-6-115158		AGFA GEVAERT NV		
	BD	JP-61-158606	07-18-1986	The state of the s		
	BE	JP-2000-512806-A	09-26-2000			
L	BF	JP-07-288341		NICHIA CHEM IND LTD		<u> </u>

Evaminar		
Examiner	Date	$\overline{}$
Signature		
s-g-races 1	Considered 1	

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. * CITE NO.: Those application(s) which are marked with an single asterisk (*) next to the Cite No. are not supplied (under 37 CFR 1.98(a)(2)(iii)) because that application was filed after June 30, 2003 or is available in the IFW. ¹ Applicant's unique citation designation number (optional). ² See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.



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Sub	ostitute for form 1449/PT	го		Complete if Known			
				Application Number	NEW		
			SCLOSURE	Filing Date	Concurrently Herewith		
S	TATEMENT	r by A	APPLICANT	First Named Inventor	Yoshinori SHIMIZU		
	(Usa sa manu			Art Unit	N/A		
(Use as many sheets as necessary)			necessary)	Examiner Name	Not Yet Assigned		
Sheet	2	of	12	Attorney Docket Number	0020-5147PUS12		

U.S. PATENT DOCUMENTS								
Examiner Initials*	Cite No.1	Document Number	Publication Date MM-DD-YYYY	Name of Datasta	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear			
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STA	STATEMENT BY APPLICANT			First Named Inventor	Yoshinori SHIMIZU		
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S	STATEMENT	BY AP	PLICANT	First Named Inventor	Yoshinori SHIMIZU	
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Sheet	7	of	12	Attorney Docket Number	0020-5147PUS12	

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Examiner Initials	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
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	CC1	P. Schlouer et al. "Luminescence Conversion of Blue Light Emitting Diodes", Applied Physics Letter, vol. 46, p. 417-418, February 1997	
	CD1	Nikkei Sangyo Shin-bun of September 13, 1996.	-
	CE1	Nakamura, SPIE, Vol. 3002, pp. 26-35 (1997)	-
	CF1	Mitsubishi Electric Company Technical Report, Vol. 48, No. 9, 1974, pp. 1121-1124.	
	CG1	M.F. YAN et al., "Preparation of Y3Al5O12-Based Phosphor Powders, J. Electrochem. Soc., Vol. 134, No. 2.	
	CH1	M.F. YAN et al., "Preparation of Y3Al5O12-Based Phosphor Powders, J. Electrochem. Soc., Vol. 134, No. 2, Feb. 1987.	
	CI1	M. Ikeda, Journal of the Illumination Society, Vol. 71, No. 10, 1987, pp. 612-617 and English Abstract.	
	CJ1	M. Ikeda et al., Color Research & Application, Vol. 16, No. 2, April 1991, pp. 72-80.	<u> </u>
	CK1	M. Ikeda et al., Color Research & Application, Vol. 14, No. 4, August 1989, pp. 198-206	
	CL1	Kozo OSAMURA et al., "Preparation and optical properties of Ga1-xlnxN thin films", Journal of Applied Physics, Vol. 46, No. 8, August 1975, pp. 3432-3437.	
	CM1	Journal of the Television Society, Vol. 47, No. 5, 1993, pp. 753-764.	
	CN1	J.M. Robertson, et al., "Colourshift of the Ce3+ Emission in Monocrystalline Epitaxially Grown Garnet Layers", 1981 Philips J. Res. 36, pp. 15-30	

Examiner	Date	
Signature	Considered	

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹Applicant's unique citation designation number (optional). ²Applicant is to place a check mark here if English language Translation is attached.



Substitu	ute for form 1449/PT	го		Complete if Known		
				Application Number	NEW	
INF	ORMATIC	ON DISC	CLOSURE	Filing Date	Concurrently Herewith	
ST	ATEMEN?	「BY AP	PLICANT	First Named Inventor	Yoshinori SHIMIZU	
1	41			Art Unit	N/A	
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Sheet	10	of	12	Attorney Docket Number	0020-5147PUS12	

		NON PATENT LITERATURE DOCUMENTS	
Examiner Initials	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
	CI2	Office Action issued February 28, 2006, in U.S. Application No. 10/677,382 (U.S. Patent 7,026,756).	
	CJ2	Notice of Allowance and Examiner's Comments on Allowance issued February 13, 2008, in connection with U.S. Application No. 10/609,402 (U.S. Patent 7,362,048).	
	CK2	Notice of Allowance and Examiner's Comments on Allowance issued February 11, 2009, in U.S. Application No. 11/682,014 (U.S. Patent 7,531,960).	
	CL2	Notice of Allowance and Examiner's Comments on Allowance issued March 10, 2006, in U.S. Application No. 10/864,544 (U.S. Patent 7,126,274).	
	CM2	Notice of Allowance and Examiner's Comments on Allowance issued September 7, 2006, in U.S. Application No. 11/208,729 (U.S. Patent 7,215,074).	
	CN2	Notice of Allowance and Examiner's Comments on Allowance issued May 4, 2005, in U.S. Application No. 10/609,503 (U.S. Patent 7,071,616).	
	CO:2	Notice of Allowance and Examiner's Comments on Allowance issued March 25, 2003, in U.S. Application No. 09/736,425 (U.S. Patent 6,608,332).	
	CP2	Notice of Allowance and Examiner's Comments on Allowance issued March 26, 2003, in U.S. Application No. 09/458,024 (U.S. Patent 6,614,179).	
	CQ:2	Notice of Allowance and Examiner's Comments on Allowance issued September 25, 2007, in U.S. Application No. 11/653,275 (U.S. Patent 5,998,925).	
	CR2	Notice of Allowance and Examiner's Comments on Allowance issued March 8, 1999, in U.S. Application No. 09/300,315 (U.S. Patent 6,069,440).	<u> </u>

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ST	STATEMENT BY APPLICANT			First Named Inventor	Yoshinori SHIMIZU	
				Art Unit	N/A	
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Sheet	11	of	12	Attorney Docket Number	0020-5147PUS12	

		NON PATENT LITERATURE DOCUMENTS	
Examiner Initials	Cite Nc.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
	CS2	Notice of Allowance and Examiner's Comments on Allowance issued January 28, 1999, in U.S. Application No. 08/902,725 (U.S. Patent 5,998,925).	
	CT2	Office Action issued November 17, 2000, in U.S. Application No. 08/902,725 (U.S. Patent 5,998,925).	
	CU2	Notice of Allowance and Examiner's Comments on Allowance issued September 22, 2005, in U.S. Application No. 10/677,382 (U.S. Patent 7,026,756).	
	CV2	Office Action issed October 20, 2009, in Japanese Patent Application No. 2009-065948 with partial English translation.	
	CW2	Office Action issued April 4, 2007, in U.S. Application 11/653,275 (U.S. Patent 7,329,988 B2).	
· · · · · ·	CX:2	Notice of Allowance and Examiner's Comments on Allowance issued February 13, 2008, in U.S. Application No. 10/609,402 (U.S. Patent 7,362,048).	
	CY:2	Notice of Allowance and Examiner's Comments on Allowance issued September 25, 2007, in U.S. Application No. 11/653,275 (U.S. Patent 7,329,988).	
	CZ2	Notice of Allowance and Examiner's Comments on Allowance issued October 8, 1999, in U.S. Application No. 09/300,315 (U.S. Patent 6,069,440).	
	CA3	Office Action issUed October 20, 2009, in Japanese Patent Application No. 2009-065948 with partial English translation.	
! 	СВЗ	Hide et al., "White light from InGaN/conjugated polymer hybrid light-emitting diodes," Appl. Phys. Lett., Vol. 70 (20), May 19, 1997, http://apl.aip.org/apl/copyright.jsp, pp. 2664-2666.	

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Substit	tute for form 1449/P7	ro			Complete if Known
				Application Number	NEW
INF	FORMATIC	ON DISC	CLOSURE	Filing Date	Concurrently Herewith
ST	ATEMEN	ΓBY AF	PLICANT	First Named Inventor	Yoshinori SHIMIZU
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Sheet	12	of	12	Attorney Docket Number	0020-5147PUS12

		NON PATENT LITERATURE DOCUMENTS	
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	CC3	NAKAMURA et al., "High-Brightness InGaN Blue, Green and Yellow Light-Emitting Diodes with Quantum Well Structures", Japanese Journal of Applied Physics, Vol. 34, No. 7A, Part 2, July 1, 1995, pp. L797-L799 XP000702022	
	CD3	Non-Final Office Action issued August 2, 2010, in co-pending U.S. Application Serial No. 12/559,042.	
	CD4	Hoffman, Journal of les, pp. 89-91 (1977).	<u> </u>
	CD5	H. Shinoda et al., Color Research & Application, Vol. 18, No. 5, October 1993, pp. 326-333.	<u> </u>
	CD6	G. BLASSE et al., "Investigation of Some Ce3+-Activated Phosphors", Journal of Chemical Physics, Vol. 47, No. 12, 15 December 1967.	
	CD7	E.F. GIBBONS et al., "Some Factors Influencing the Luminous Decay characteristics of Y3Al5O12:Ce3+", J. Electrochem. Soc., Vol. 120, No. 6, June 1973.	
	CD8	D.J. ROBBINS et al., "Lattice Defects and Energy Transfer Phenomena in Y3Al5O12:Ce3+", pp. 1004-1013, printed June 19, 2001.	
	CD9	Bando et al., Development and applications of highbright white LED lamps, November 29, 1996, The 264 th Proceedings of the Institute of Phosphor Society, pages 4-16 of the English translation.	
	CD10	Office Action issued December 13, 2005, in U.S. Application No. 11/208,729 (U.S. Patent No. 7,215,074).	
	CD11	Office Action issued March 13, 2001, in U.S. Application No. 09/458,024 (U.S. Patent No. 6,614,179).	
	CD12	Office Action issued August 14, 2002, in U.S. Application No. 09/736,425 (U.S. Patent No. 6,608,332).	
	CD13	Office Action issued August 19, 2005, in U.S. Application No. 10/609,402 (U.S. Patent No. 7,362,048).	
	CD14	[7,362,048).	
	CD15	Office Action issued January 2, 2008, in U.S. Application No. 10/609,402 (U.S. Patent No. 7,362,048).	
	CD16	Office Action issued April 8, 2005, in U.S. Application No. 10/677,382 (U.S. Patent No. 7,026,756).	
	CD17	Office Action issued September 7, 2005, in U.S. Application No. 10/864,544 (U.S. Patent No. 7,126,274).	

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Docket No.: 0020-5147PUS12

(Patent)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application of:

Yoshinori SHIMIZU et al.

Application No.:

NEW

Confirmation No.: N/A

Filed:

November 9, 2010

Art Unit:

N/A

For:

LIGHT EMITTING DEVICE AND DISPLAY

Examiner:

N/A

LETTER REGARDING COPENDING APPLICATIONS

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Under the provisions of MPEP § 2001.06(b), the Examiner is hereby advised of the following copending U.S. Application(s):

Filing Date	Group
August 27, 2009	2812
August 27, 2009	2812
August 27, 2009	2811
September 14, 2009	2814
August 27, 2009	2812
October 7, 2009	2811
October 7, 2009	2892
January 19, 2010	2812
July 7, 2010	2812
July 1, 2010	2812
	August 27, 2009 August 27, 2009 August 27, 2009 September 14, 2009 August 27, 2009 October 7, 2009 October 7, 2009 January 19, 2010 July 7, 2010

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Application No.: NEW Docket No.: 0020-5147PUS12
Page 2 of 2

The subject matter contained in the above-listed copending U.S. applications may be deemed to relate to the present application, and thus may be material to the prosecution of this instant application.

The above-listed co-pending applications are not to be construed as prior art. By bringing the above-listed applications to the attention of the Examiner, Applicants do NOT waive any confidentiality concerning the above-listed co-pending applications or this application. See MPEP § 101.

If necessary, the Director is hereby authorized in this, concurrent, and future replies to charge any fees required during the pendency of the above-identified application or credit any overpayment to Deposit Account No. 02-2448.

Dated: November 9, 2010

D. Richard Anderson

Registration No.: 40,439

BIRCH, STEWART, KOLASCH & BIRCH, LLP

8110 Gatehouse Road, Suite 100 East

\submitted.

P.O. Box 747

Respectfully

Falls Church, VA 22040-0747

703-205-8000

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant(s): SHIMIZU, Yoshinori et al

Serial No.:

Group:

COPY

Filed:

July 29, 1997

Examiner:

For:

LIGHT EMITTING DEVICE AND DISPLAY

LETTER

Assistant Commissioner for Patents Box Patent Application July 29, 1997

0020-4260P

Washington, D.C. 20231

Sir:

Under the provisions of 35 USC 119 and 37 CFR 1.55(a), the applicant hereby claims the right of priority based on the following application(s):

Country	Application No.	Filed
JAPAN	8-198585	07/29/96
JAPAN	8-244339	09/17/96
JAPAN	8-245381	09/18/96
JAPAN	8-359004	12/27/96
JAPAN	9-081010	03/31/97

A certified copy of the above-noted application(s) is(are) attached hereto.

Please charge any fees under 37 CFR 1.16 - 1.21 (h) or credit any overpayment to Deposit Account No. 02-2448.

Respectfully submitted,

BIRCH, STEWART, KOLASCH & BIRCH, LLP

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\ttachment 703) 205-8000

LIGHT EMITTING DEVICE AND DISPLAY

CROSS-REFERENCE TO RELATED APPLICATIONS

[0001] This application is a divisional of U.S. Application No. 12/548,614 filed August 27, 2009 which is a divisional of U.S. Application No. 12/028,062 filed February 8, 2008, now U.S. Patent 7,682,848 which is a divisional of U.S. Application No. 10/609,402 filed July 1, 2003, now U.S. Patent 7,362,048, which is a divisional of U.S. Application No. 09/458,024, filed December 10, 1999, now U.S. Patent 6,614,179, which is a divisional of U.S. Application No. 09/300,315, filed on April 28, 1999, now U.S. Patent 6,069,440, which is a divisional of U.S. Application No. 08/902,725, filed on July 29, 1997, now U.S. Patent 5,998,925, which also claims priority on Japanese Patent Application Nos. P 08-198585 filed July 29, 1996; P 08-244339 filed September 17, 1996; P 08-245381 filed September 18, 1996; P 08-359004 filed December 27, 1996; and P 09-081010 filed March 31, 1997. The entire contents of each of these applications are hereby incorporated by reference.

BACKGROUND OF THE INVENTION

(Field of the Invention)

[0002] The present invention relates to a light emitting diode used in LED display, back light source, traffic signal, trailway signal, illuminating switch, indicator, etc. More particularly, it relates to a light emitting device (LED) comprising a phosphor, which converts the wavelength of light emitted by a light emitting component and emits light, and a display device using the light emitting device.

Description of Related Art

[0003] A light emitting diode is compact and emits light of clear color with high efficiency. It is also free from such a trouble as burn-out and has good initial drive characteristic, high vibration resistance and durability to endure repetitive ON/OFF

operations, because it is a semiconductor element. Thus it has been used widely in such applications as various indicators and various light sources. Recently light emitting diodes for RGB (red, green and blue) colors having ultra-high luminance and high efficiency have been developed, and large screen LED displays using these light emitting diodes have been put into use. The LED display can be operated with less power and has such good characteristics as light weight and long life, and is therefore expected to be more widely used in the future.

[0004]Recently, various attempts have been made to make white light sources by using light emitting diodes. Because the light emitting diode has a favorable emission spectrum to generate monochromatic light, making a light source for white light requires it to arrange three light emitting components of R, G and B closely to each other while diffusing and mixing the light emitted by them. When generating white light with such an arrangement, there has been such a problem that white light of the desired tone cannot be generated due to variations in the tone, luminance and other factors of the light emitting component. Also when the light emitting components are made of different materials, electric power required for driving differs from one light emitting diode to another, making it necessary to apply different voltages different light emitting components, which leads to complex drive circuit. Moreover, because the light emitting components are semiconductor light emitting components, color tone is subject to variation due to the difference in temperature characteristics, chronological changes and operating environment, or unevenness in color may be caused due to failure in uniformly mixing the light emitted by the light emitting components. Thus light emitting diodes are effective as light emitting devices for generating individual colors, although a satisfactory light source capable of emitting white light by using light emitting components has not been obtained so far.

[0005] In order to solve these problems, the present applicant previously developed light emitting diodes which convert the color of light, which is emitted by light

emitting components, by means of a fluorescent material disclosed in Japanese Patent Kokai Nos. 5-152609, 7-99345, 7-176794 and 8-7614. The light emitting diodes disclosed in these publications are such that, by using light emitting components of one kind, are capable of generating light of white and other colors, and are constituted as follows.

[0006] The light emitting diode disclosed in the above gazettes are made by mounting a light emitting component, having a large energy band gap of light emitting layer, in a cup provided at the tip of a lead frame, and having a fluorescent material that absorbs light emitted by the light emitting component and emits light of a wavelength different from that of the absorbed light (wavelength conversion), contained in a resin mold which covers the light emitting component.

[0007] The light emitting diode disclosed as described above capable of emitting white light by mixing the light of a plurality of sources can be made by using a light emitting component capable of emitting blue light and molding the light emitting component with a resin including a fluorescent material that absorbs the light emitted by the blue light emitting diode and emits yellowish light.

[0008] However, conventional light emitting diodes have such problems as deterioration of the fluorescent material leading to color tone deviation and darkening of the fluorescent material resulting in lowered efficiency of extracting light. Darkening here refers to, in the case of using an inorganic fluorescent material such as (Cd, Zn)S fluorescent material, for example, part of metal elements constituting the fluorescent material precipitate or change their properties leading to coloration, or, in the case of using an organic fluorescent material, coloration due to breakage of double bond in the molecule. Especially when a light emitting component made of a semiconductor having a high energy band gap is used to improve the conversion efficiency of the fluorescent material (that is, energy of light emitted by the semiconductor is increased and number of photons having energies above a threshold which can be absorbed by the fluorescent

material increases, resulting in more light being absorbed), or the quantity of fluorescent material consumption is decreased (that is, the fluorescent material is irradiated with relatively higher energy), light energy absorbed by the fluorescent material inevitably increases resulting in more significant degradation of the fluorescent material. Use of the light emitting component with higher intensity of light emission for an extended period of time causes further more significant degradation of the fluorescent material.

[0009] Also the fluorescent material provided in the vicinity of the light emitting component may be exposed to a high temperature such as rising temperature of the light emitting component and heat transmitted from the external environment (for example, sunlight in case the device is used outdoors).

[0010] Further, some fluorescent materials are subject to accelerated deterioration due to combination of moisture entered from the outside or introduced during the production process, the light and heat transmitted from the light emitting component.

[0011] When it comes to an organic dye of ionic property, direct current electric field in the vicinity of the chip may cause electrophoresis, resulting in a change in the color tone.

SUMMARY OF THE INVENTION

[0012] Thus, an object of the present invention is to solve the problems described above and provide a light emitting device which experiences only extremely low degrees of deterioration in emission light intensity, light emission efficiency and color shift over a long time of use with high luminance.

[0013] The present applicant completed the present invention through researches based on the assumption that a light emitting device having a light emitting component and a fluorescent material must meet the following requirements to achieve the above-mentioned object.

[0014] The light emitting component must be capable of emitting light of high luminance with light emitting characteristic which is stable over a long time of use.

[0015] The fluorescent material being provided in the vicinity of the high-luminance light emitting component, must show excellent resistance against light and heat so that the properties thereof do not change even when used over an extended period of time while being exposed to light of high intensity emitted by the light emitting component (particularly the fluorescent material provided in the vicinity of the light emitting component is exposed to light of a radiation intensity as high as about 30 to 40 times that of sunlight according to our estimate, and is required to have more durability against light as light emitting component of higher luminance is used).

[0016] With regard to the relationship with the light emitting component, the fluorescent material must be capable of absorbing with high efficiency the light of high monochromaticity emitted by the light emitting component and emitting light of a wavelength different from that of the light emitted by the light emitting component.

[0017] Thus the present invention provides a light emitting device, comprising a light emitting component and a phosphor capable of absorbing a part of light emitted by the light emitting component and emitting light of wavelength different from that of the absorbed light;

[0018] wherein said light emitting component comprises a nitride compound semiconductor represented by the formula: $In_iGa_jAl_kN$ where $0\le i$, $0\le j$, $0\le k$ and i+j+k=1) and said phosphor contains a garnet fluorescent material comprising at least one element selected from the group consisting of Y, Lu, Sc, La, Gd and Sm, and at least one element selected from the group consisting of Al, Ga and In, and being activated with cerium.

[0019] The nitride compound semiconductor (generally represented by chemical formula $In_iGa_jAl_kN$ where $0\le i$, $0\le j$, $0\le k$ and i+j+k=1) mentioned above contains various materials including InGaN and GaN doped with various impurities.

[0020] The phosphor mentioned above contains various materials defined as described above, including Y₃Al₅O₁₂:Ce and Gd₃In₅O₁₂:Ce.

[0021] Because the light emitting device of the present invention uses the light emitting component made of a nitride compound semiconductor capable of emitting light with high luminance, the light emitting device is capable of emitting light with high luminance. Also the phosphor used in the light emitting device has excellent resistance against light so that the fluorescent properties thereof experience less change even when used over an extended period of time while being exposed to light of high intensity. This makes it possible to reduce the degradation of characteristics during long period of use and reduce deterioration due to light of high intensity emitted by the light emitting component as well as extraneous light (sunlight including ultraviolet light, etc.) during outdoor use, thereby to provide a light emitting device which experiences extremely less color shift and less luminance decrease. The light emitting device of the present invention can also be used in such applications that require response speeds as high as 120 nsec., for example, because the phosphor used therein allows after glow only for a short period of time.

[0022] The phosphor used in the light emitting diode of the present invention preferably contains an yttrium-aluminum-garnet fluorescent material that contains Y and Al, which enables it to increase the luminance of the light emitting device.

[0023] In the light emitting device of the present invention, the phosphor may be a fluorescent material represented by a general formula $(Re_{1-r}Sm_r)_3(Al_{1-s}Ga_s)_5O_{12}$:Ce, where $0 \le r < 1$ and $0 \le s \le 1$ and Re is at least one selected from Y and Gd, in which case good characteristics can be obtained similarly to the case where the yttrium-aluminum-garnet fluorescent material is used.

[0024] Also in the light emitting device of the present invention, it is preferable, for the purpose of reducing the temperature dependence of light emission characteristics (wavelength of emitted light, intensity of light emission, etc.), to use a fluorescent

material represented by a general formula $(Y_{1-p-q-r}Gd_pCe_qSm_r)_3(Al_{1-s}Ga_s)_5O_{12}$ as the phosphor, where $0 \le p \le 0.8$, $0.003 \le q \le 0.2$, $0.0003 \le r \le 0.08$ and $0 \le s \le 1$.

[0025] Also in the light emitting device of the present invention, the phosphor may contain two or more yttrium-aluminum-garnet fluorescent materials, activated with cerium, of different compositions including Y and Al. With this configuration, light of desired color can be emitted by controlling the emission spectrum of the phosphor according to the property (wavelength of emitted light) of the light emitting component.

[0026] Further in the light emitting device of the present invention, in order to have light of a specified wavelength emitted by the light emitting device, it is preferable that the phosphor contains two or more fluorescent materials of different compositions represented by general formula $(Re_{1-r}Sm_r)_3(Al_{1-s}Ga_s)_5O_{12}$: Ce, where $0 \le r < 1$ and $0 \le s \le 1$ and Re is at least one selected from Y and Gd.

[0027] Also in the light emitting device of the present invention, in order to control the wavelength of emitted light, the phosphor may contain a first fluorescent material represented by general formula $Y_3(Al_{1-s}Ga_s)_5O_{12}$:Ce and a second fluorescent material represented by general formula $Re_3Al_5O_{12}$:Ce, where $0 \le s \le 1$ and Re is at least one selected from Y, Gd and La.

[0028] Also in the light emitting device of the present invention, in order to control the wavelength of emitted light, the phosphor may be an yttrium-aluminum-garnet fluorescent material containing a first fluorescent material and a second fluorescent material, with different parts of each yttrium being substituted with gadolinium.

[0029] Further in the light emitting device of the present invention, it is preferable that main emission peak of the light emitting component is set within the range from 400 nm to 530 nm and main emission wavelength of the phosphor is set to be longer than the main emission peak of the light emitting component. This makes it possible to efficiently emit white light.

[0030] Further in the light emitting device of the present invention, it is preferable that the light emitting layer of the light emitting component contains a gallium nitride semiconductor which contains In, and the phosphor is an yttrium-aluminum-garnet fluorescent material wherein a part of Al in the yttrium-aluminum-garnet fluorescent is substituted by Ga so that the proportion of Ga:Al is within the range from 1:1 to 4:6 and a part of Y in the yttrium-aluminum-garnet fluorescent is substituted by Gd so that the proportion of Y:Gd is within the range from 4:1 to 2:3. Absorption spectrum of the phosphor which is controlled as described above shows good agreement with that of light emitted by the light emitting component which contains gallium nitride semiconductor including In as the light emitting layer, and is capable of improving the conversion efficiency (light emission efficiency). Also the light, generated by mixing blue light emitted by the light emitting component and fluorescent light of the fluorescent material, is a white light of good color rendering and, in this regard, an excellent light emitting device can be provided.

[0031] The light emitting device according to one embodiment of the present invention comprises a substantially rectangular optical guide plate provided with the light emitting component mounted on one side face thereof via the phosphor and surfaces of which except for one principal surface are substantially covered with a reflective material, wherein a light emitted by the light emitting component is turned into a planar light by the phosphor and the optical guide plate and to be an output from the principal surface of the optical guide plate.

[0032] The light emitting device according to another embodiment of the present invention has a substantially rectangular optical guide plate, which is provided with the light emitting component mounted on one side face thereof and the phosphor installed on one principal surface with surfaces thereof and except for the principal surface being substantially covered with a reflective material, wherein a light emitted by the light

emitting component is turned into a planar light by the optical guide plate and the phosphor, to be an output from the principal surface of the optical guide plate.

[0033] The LED display device according to the present invention has an LED display device comprising the light emitting devices of the present invention arranged in a matrix and a drive circuit which drives the LED display device according to display data which is input thereto. This configuration makes it possible to provide a relatively low-priced LED display device which is capable of high-definition display with less color unevenness due to the viewing angle.

[0034] The light emitting diode according to one embodiment of the present invention comprises:

[0035] a mount lead having a cup and a lead;

[0036] an LED chip mounted in the cup of the mount lead with one of electrodes being electrically connected to the mount lead;

[0037] a transparent coating material filling the cup to cover the LED chip; and

[0038] a light emitting diode having a molding material which covers the LED chip covered with the coating material including the cup of the mount lead, the inner lead and another electrode of the LED chip, wherein

[0039] the LED chip is a nitride compound semiconductor and the coating material contains at least one element selected from the group consisting of Y, Lu, Sc, La, Gd and Sm, at least one element selected from the group consisting of Al, Ga and In and a phosphor made of garnet fluorescent material activated with cerium.

[0040] The phosphor used in the light emitting diode of the present invention preferably contains an yttrium-aluminum-garnet fluorescent material that contains Y and Al.

[0041] In the light emitting diode of the present invention, the phosphor may be a fluorescent material represented by a general formula $(Re_{1-r}Sm_r)_3(Al_{1-s}Ga_s)_5O_{12}$:Ce, where $0 \le r < 1$ and $0 \le s \le 1$ and Re is at least one selected from Y and Gd.

- [0042] Also in the light emitting diode of the present invention, a fluorescent material represented by a general formula $(Y_{1-p-q-r}Gd_pCe_qSm_r)_3(Al_{1-s}Ga_s)_5O_{12}$ may be used as the phosphor, where $0 \le p \le 0.8$, $0.003 \le q \le 0.2$, $0.0003 \le r \le 0.08$ and $0 \le s \le 1$.
- [0043] In the light emitting diode of the present invention, the phosphor preferably contain two or more yttrium-aluminum-garnet fluorescent materials, activated with cerium, of different compositions including Y and Al, in order to control the emitted light to a desired wavelength.
- [0044] In the light emitting diode of the present invention, similarly, two or more fluorescent materials of different compositions represented by a general formula (Re₁. $_rSm_r$)₃(Al_{1-s}Ga_s)₅O₁₂:Ce, where 0≤r<1 and 0≤s≤1 and Re is at least one selected from Y and Gd may be used as the phosphor in order to control the emitted light to a desired wavelength.
- [0045] In the light emitting diode of the present invention, similarly, a first fluorescent material represented by a general formula $Y_3(Al_{1-s}Ga_s)_5O_{12}$:Ce and a second fluorescent material represented by a general formula $Re_3Al_5O_{12}$:Ce, may be used as the phosphor where $0 \le s \le 1$ and Re is at least one selected from Y, Gd and La, in order to control the emitted light to a desired wavelength.
- [0046] In the light emitting diode of the present invention, similarly, yttrium-aluminum-garnet fluorescent material a first fluorescent material and a second fluorescent material may be used wherein a part of yttrium in the first and second fluorescent materials is substituted with gadolinium to different degrees of substitution as the phosphor, in order to control the emitted light to a desired wavelength.
- [0047] Generally, a fluorescent material which absorbs light of a short wavelength and emits light of a long wavelength has higher efficiency than a fluorescent material which absorbs light of a long wavelength and emits light of a short wavelength. It is preferable to use a light emitting component which emits visible light than a light emitting component which emits ultraviolet light that degrades resin (molding material,

coating material, etc.). Thus for the light emitting diode of the present invention, for the purpose of improving the light emitting efficiency and ensure long life, it is preferable that main emission peak of the light emitting component be set within a relatively short wavelength range of 400 nm to 530 nm in the visible light region, and main emission wavelength of the phosphor be set to be longer than the main emission peak of the light emitting component. With this arrangement, because light converted by the fluorescent material has longer wavelength than that of light emitted by the light emitting component, it will not be absorbed by the light emitting component even when the light emitting component is irradiated with light which has been reflected and converted by the fluorescent material (since the energy of the converted light is less than the band gap energy). Thus the light which has been reflected by the fluorescent material or the like is reflected by the cup wherein the light emitting component is mounted, making higher efficiency of emission possible.

BRIEF DESCRIPTION OF THE DRAWINGS

[0048] Fig. 1 is a schematic sectional view of a lead type light emitting diode according to the embodiment of the present invention.

[0049] Fig. 2 is a schematic sectional view of a tip type light emitting diode according to the embodiment of the present invention.

[0050] Fig. 3A is a graph showing the excitation spectrum of the garnet fluorescent material activated by cerium used in the first embodiment of the present invention.

[0051] Fig. 3B is a graph showing the emission spectrum of the garnet fluorescent material activated by cerium used in the first embodiment of the present invention.

[0052] Fig. 4 is a graph showing the emission spectrum of the light emitting diode of the first embodiment of the present invention.

- [0053] Fig. 5A is a graph showing the excitation spectrum of the yttrium-aluminum-garnet fluorescent material activated by cerium used in the second embodiment of the present invention.
- [0054] Fig. 5B is a graph showing the emission spectrum of the yttrium-aluminum-garnet fluorescent material activated by cerium used in the second embodiment of the present invention.
- [0055] Fig. 6 shows the chromaticity diagram of light emitted by the light emitting diode of the second embodiment, while
- [0056] points A and B indicate the colors of light emitted by the light emitting component and points C and D indicate the colors of light emitted by two kinds of phosphors.
- [0057] Fig. 7 is a schematic sectional view of the planar light source according to another embodiment of the present invention.
- [0058] Fig. 8 is a schematic sectional view of another planar light source different from that of Fig. 7.
- [0059] Fig. 9 is a schematic sectional view of another planar light source different from those of Fig. 7 and Fig. 8.
- [0060] Fig. 10 is a block diagram of a display device which is an application of the present invention.
- [0061] Fig. 11 is a plan view of the LED display device of the display device of Fig. 10.
- [0062] Fig. 12 is a plan view of the LED display device wherein one pixel is constituted from four light emitting diodes including the light emitting diode of the present invention and those emitting RGB colors.
- [0063] Fig. 13A shows the results of durable life test of the light emitting diodes of Example 1 and Comparative Example 1, showing the results at 25°C and Fig. 13B

shows the results of durable life test of the light emitting diodes of Example 1 and Comparative Example 1, showing the results at 60°C and 90%RH.

[0064] Fig. 14A shows the results of weatherability test of Example 9 and Comparative Example 2 showing the change of luminance retaining ratio with time and Fig. 14B shows the results of weatherability test of Example 9 and Comparative Example 2 showing the color tone before and after the test.

[0065] Fig. 15A shows the results of reliability test of Example 9 and Comparative Example 2 showing the relationship between the luminance retaining ratio and time, and Fig. 15B is a graph showing the relationship between color tone and time.

[0066] Fig. 16 is a chromaticity diagram showing the range of color tone which can be obtained with a light emitting diode which combines the fluorescent materials shown in Table 1 and blue LED having peak wavelength at 465 nm.

[0067] Fig. 17 is a chromaticity diagram showing the change in color tone when the concentration of fluorescent material is changed in the light emitting diode which combines the fluorescent materials shown in Table 1 and blue LED having peak wavelength at 465 nm.

[0068] Fig. 18A shows the emission spectrum of the phosphor $(Y_{0.6}Gd_{0.4})_3Al_5O_{12}$:Ce of Example 18A.

[0069] Fig. 18B shows the emission spectrum of the light emitting component of Example 18B having the emission peak wavelength of 460nm.

[0070] Fig. 18C shows the emission spectrum of the light emitting diode of Example 2.

[0071] Fig. 19A shows the emission spectrum of the phosphor $(Y_{0.2}Gd_{0.8})_3Al_5O_{12}$:Ce of Example 5.

[0072] Fig. 19B shows the emission spectrum of the light emitting component of Example 5 having the emission peak wavelength of 450nm.

[0073] Fig. 19C shows the emission spectrum of the light emitting diode of Example 5.

[0074] Fig. 20A shows the emission spectrum of the phosphor Y₃Al₅O₁₂:Ce of Example 6.

[0075] Fig. 20B shows the emission spectrum of the light emitting component of Example 6 having the emission peak wavelength of 450nm.

[0076] Fig. 20C shows the emission spectrum of the light emitting diode of Example 6.

[0077] Fig. 21A shows the emission spectrum of the phosphor $Y_3(Al_{0.5}Ga_{0.5})_5O_{12}$:Ce of the seventh embodiment of the present invention

[0078] Fig. 21B shows the emission spectrum of the light emitting component of Example 7 having the emission peak wavelength of 450nm.

[0079] Fig. 21C shows the emission spectrum of the light emitting diode of Example 7.

[0080] Fig. 22A shows the emission spectrum of the phosphor $(Y_{0.8}Gd_{0.2})_3Al_5O_{12}$:Ce of Example 11.

[0081] Fig. 22B shows the emission spectrum of the phosphor $(Y_{0.4}Gd_{0.6})_3Al_5O_{12}$:Ce of Example 11.

[0082] Fig. 22C shows the emission spectrum of the light emitting component of Example 11 having the emission peak wavelength of 470nm.

[0083] Fig. 23 shows the emission spectrum of the light emitting diode of Example 11.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS

[0084] Now referring to the attached drawings, preferred embodiments of the present invention will be described below.

[0085] A light emitting diode 100 of Fig. 1 is a lead type light emitting diode having a mount lead 105 and an inner lead 106, wherein a light emitting component 102 is installed on a cup 105a of the mount lead 105, and the cup 105a is filled with a coating resin 101 which contains a specified phosphor to cover the light emitting component 102 and is molded in resin. An n electrode and a p electrode of the light emitting component 102 are connected to the mount lead 105 and the inner lead 106, respectively, by means of wires 103.

[0086] In the light emitting diode constituted as described above, part of light emitted by the light emitting component (LED chip) 102 (hereinafter referred to as LED light) excites the phosphor contained in the coating resin 101 to generate fluorescent light having a wavelength different from that of LED light, so that the fluorescent light emitted by the phosphor and LED light which is output without contributing to the excitation of the phosphor are mixed and output. As a result, the light emitting diode 100 also outputs light having a wavelength different from that of LED light emitted by the light emitting component 102.

[0087] Fig. 2 shows a chip type light emitting diode, wherein light emitting diode (LED chip) 202 is installed in a recess of a casing 204 which is filled with a coating material which contains a specified phosphor to form a coating 201. The light emitting component 202 is fixed by using an epoxy resin or the like which contains Ag, for example, and an n electrode and a p electrode of the light emitting component 202 are connected to metal terminals 205 installed on the casing 204 by means of conductive wires 203. In the chip type light emitting diode constituted as described above, similarly to the lead type light emitting diode of Fig. 1, fluorescent light emitted by the phosphor and LED light which is transmitted without being absorbed by the phosphor are mixed and output, so that the light emitting diode 200 also outputs light having a wavelength different from that of LED light emitted by the light emitting component 202.

[0088] The light emitting diode containing the phosphor as described above has the following features.

[0089] Light emitted by a light emitting component (LED) is usually emitted through an electrode which supplies electric power to the light emitting component. Emitted light is partly blocked by the electrode formed on the light emitting component resulting in a particular emission pattern, and is therefore not emitted uniformly in every direction. The light emitting diode which contains the fluorescent material, however, can emit light uniformly over a wide range without forming undesirable emission pattern because the light is emitted after being diffused by the fluorescent material.

[0090] Although light emitted by the light emitting component (LED) has a monochromatic peak, the peak is broad and has high color rendering property. This characteristic makes an indispensable advantage for an application which requires wavelengths of a relatively wide range. Light source for an optical image scanner, for example, is desirable to have a wider emission peak.

[0091] The light emitting diodes of the first and second embodiments to be described below have the configuration shown in Fig. 1 or Fig. 2 wherein a light emitting component which uses nitride compound semiconductor having relatively high energy in the visible region and a particular phosphor are combined, and have such favorable properties as capability to emit light of high luminance and less degradation of light emission efficiency and less color shift over an extended period of use.

[0092] In general, a fluorescent material which absorbs light of a short wavelength and emits light of a long wavelength has higher efficiency than a fluorescent material which absorbs light of a long wavelength and emits light of a short wavelength, and therefore it is preferable to use a nitride compound semiconductor light emitting component which is capable of emitting blue light of short wavelength. It needs not to say that the use of a light emitting component having high luminance is preferable.

- [0093] A phosphor to be used in combination with the nitride compound semiconductor light emitting component must have the following requirements:
- [0094] 1. Excellent resistance against light to endure light of a high intensity for a long period of time, because the fluorescent material is installed in the vicinity of the light emitting components 102, 202 and is exposed to light of intensity as high as about 30 to 40 times that of sun light.
- [0095] 2. Capability to efficiently emit light in blue region for the excitation by means of the light emitting components 102, 202. When mixing of colors is used, should be capable of emitting blue light, not ultraviolet ray, with a high efficiency.
- [0096] 3. capability to emit light from green to red regions for the purpose of mixing with blue light to generate white light.
- [0097] 4. Good temperature characteristic suitable for location in the vicinity of the light emitting components 102, 202 and the resultant influence of temperature difference due to heat generated by the chip when lighting.
- [0098] 5. Capability to continuously change the color tone in terms of the proportion of composition or ratio of mixing a plurality of fluorescent materials.
 - [0099] 6. Weatherability for the operating environment of the light emitting diode.

Embodiment 1

[0100] The light emitting diode of the first embodiment of the present invention employs a gallium nitride compound semiconductor element which has high-energy band gap in the light emitting layer and is capable of emitting blue light, and a garnet phosphor activated with cerium in combination. With this configuration, the light emitting diode of the first embodiment can emit white light by blending blue light emitted by the light emitting components 102, 202 and yellow light emitted by the phosphor excited by the blue light.

[0101] Because the garnet phosphor activated with cerium which is used in the light emitting diode of the first embodiment has light resistance and weatherability, it can emit light with extremely small degrees of color shift and decrease in the luminance of emitted light even when irradiated by very intense light emitted by the light emitting components 102, 202 located in the vicinity over a long period of time.

[0102] Components of the light emitting diode of the first embodiment will be described in detail below.

(Phosphor)

phosphor which, when excited by visible light or ultraviolet ray emitted by the semiconductor light emitting layer, emits light of a wavelength different from that of the exciting light. The phosphor is specifically garnet fluorescent material activated with cerium which contains at least one element selected from Y, Lu, Sc, La, Gd and Sm and at least one element selected from Al, Ga and In. According to the present invention, the fluorescent material is preferably yttrium-aluminum-garnet fluorescent material (YAG phosphor) activated with cerium, or a fluorescent material represented by general formula $(Re_{1-r}Sm_r)_3(Al_{1-s}Ga_s)_5O_{12}$:Ce, where $0 \le r < 1$ and $0 \le s \le 1$, and Re is at least one selected from Y and Gd. In case the LED light emitted by the light emitting component employing the gallium nitride compound semiconductor and the fluorescent light emitted by the phosphor having yellow body color are in the relation of complementary colors, white color can be output by blending the LED light and the fluorescent light.

[0104] In the first embodiment, because the phosphor is used by blending with a resin which makes the coating resin 101 and the coating material 201 (detailed later), color tone of the light emitting diode can be adjusted including white and incandescent lamp color by controlling the mixing proportion with the resin or the quantity used in

filling the cup 105 or the recess of the casing 204 in accordance to the wavelength of light emitted by the gallium nitride light emitting component.

[0105] Distribution of the phosphor concentration has influence also on the color blending and durability. That is, when the concentration of phosphor increases from the surface of the coating or molding where the phosphor is contained toward the light emitting component, it becomes less likely to be affected by extraneous moisture thereby making it easier to suppress the deterioration due to moisture. On the other hand, when the concentration of phosphor increases from the light emitting component toward the surface of the molding, it becomes more likely to be affected by extraneous moisture, but less likely to be affected by the heat and radiation from the light emitting component, thus making it possible to suppress the deterioration of the phosphor. Such distributions of the phosphor concentration can be achieved by selecting or controlling the material which contains the phosphor, forming temperature and viscosity, and the configuration and particle size distribution of the phosphor.

[0106] By using the phosphor of the first embodiment, light emitting diode having excellent emission characteristics can be made, because the fluorescent material has enough light resistance for high-efficient operation even when arranged adjacent to or in the vicinity of the light emitting components 102, 202 with radiation intensity

[0107] (Ee) within the range from 3 Wcm^{-2} to 10 Wcm^{-2} .

[0108] The phosphor used in the first embodiment is, because of garnet structure, resistant to heat, light and moisture, and is therefore capable of absorbing excitation light having a peak at a wavelength near 450 nm as shown in Fig. 3A. It also emits light of broad spectrum having a peak near 580 nm tailing out to 700 nm as shown in Fig. 3B. Moreover, efficiency of excited light emission in a region of wavelengths 460 nm and higher can be increased by including Gd in the crystal of the phosphor of the first embodiment. When the Gd content is increased, emission peak wavelength is shifted toward longer wavelength and the entire emission spectrum is shifted toward longer

wavelengths. This means that, when emission of more reddish light is required, it can be achieved by increasing the degree of substitution with Gd. When the Gd content is increased, luminance of light emitted by photoluminescence under blue light tends to decrease.

[0109] Especially when part of Al is substituted with Ga among the composition of YAG fluorescent material having garnet structure, wavelength of emitted light shifts toward shorter wavelength and, when part of Y is substituted with Gd, wavelength of emitted light shifts toward longer wavelength.

[0110] Table 1 shows the composition and light emitting characteristics of YAG fluorescent material represented by general formula $(Y_{1-a}Gd_a)_3(Al_{1-b}Ga_b)_5O_{12}$:Ce.

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Table 1

Gd content	Ga content	CIE chromaticity	aticity	Luminance Y	Efficiency
a (molar ratio)	b (molar ratio)	coordinates	ates		
		X	y		
0.0	0.0	0.41	0.56	100	100
0.0	0.4	0.32	0.56	61	63
0.0	0.5	0.29	0.54	55	67
0.2	0.0	0.45	0.53	102	108
0.4	0.0	0.47	0.52	102	113
9.0	0.0	0.49	0.51	97	113
0.8	0.0	0.50	0.50	72	98

[0111] Values shown in Table 1 were measured by exciting the fluorescent material with blue light of 460nm. Luminance and efficiency in Table 1 are given in values relative to those of material No. 1 which are set to 100.

[0112]When substituting Al with Ga, the proportion is preferably within the range from Ga: Al=1:1 to 4:6 in consideration of the emission efficiency and emission wavelength. Similarly, when substituting Y with Gd, the proportion is preferably within the range from Y: Gd=9:1 to 1:9, and more preferably from 4:1 to 2:3. It is because a degree of substitution with Gd below 20% results in a color of greater green component and less red component, and a degree of substitution with Gd above 60% results in increased red component but rapid decrease in luminance. When the ratio Y:Gd of Y and Gd in the YAG fluorescent material is set within the range from 4:1 to 2:3, in particular, a light emitting diode capable of emitting white light substantially along the black body radiation locus can be made by using one kind of yttrium-aluminum-garnet fluorescent material, depending on the emission wavelength of the light emitting component. When the ratio Y:Gd of Y and Gd in the YAG fluorescent material is set within the range from 2:3 to 1:4, a light emitting diode capable of emitting light of incandescent lamp can be made though the luminance is low. When the content (degree of substitution) of Ce is set within the range from 0.003 to 0.2, the relative luminous intensity of light emitting diode of not less than 70% can be achieved. When the content is less than 0.003, luminous intensity decreases because the number of excited emission centers of photoluminescence due to Ce decreases and, when the content is greater than 0.2, density quenching occurs.

[0113] Thus the wavelength of the emitted light can be shifted to a shorter wavelength by substituting part of Al of the composition with Ga, and the wavelength of the emitted light can be shifted to a longer wavelength by substituting part of Y of the composition with Gd. In this way, the light color of emission can be changed continuously by changing the composition. Also the fluorescent material is hardly excited by Hg emission lines which have such wavelengths as 254 nm and 365 nm, but is

excited with higher efficiency by LED light emitted by a blue light emitting component having a wavelength around 450 nm. Thus the fluorescent material has ideal characteristics for converting blue light of nitride semiconductor light emitting component into white light, such as the capability of continuously changing the peak wavelength by changing the proportion of Gd.

[0114] According to the first embodiment, the efficiency of light emission of the light emitting diode can be further improved by combining the light emitting component employing gallium nitride semiconductor and the phosphor made by adding rare earth element samarium (Sm) to yttrium-aluminum-garnet fluorescent materials (YAG) activated with cerium.

[0115] Material for making such a phosphor is made by using oxides of Y, Gd, Ce, Sm, Al and Ga or compounds which can be easily converted into these oxides at high temperature, and sufficiently mixing these materials in stoichiometrical proportions. This mixture is mixed with an appropriate quantity of a fluoride such as ammonium fluoride used as a flux, and fired in a crucible at a temperature from 1350 to 1450°C in air for 2 to 5 hours. Then the fired material is ground by a ball mill in water, washed, separated, dried and sieved thereby to obtain the desired material.

[0116] In the producing process described above, the mixture material may also be made by dissolving rare earth elements Y, Gd, Ce and Sm in stoichiometrical proportions in an acid, coprecipitating the solution with oxalic acid and firing the coprecipitate to obtain an oxide of the coprecipitate, and then mixing it with aluminum oxide and gallium oxide.

[0117] The phosphor represented by the general formula (Y_{1-p-q-r}Gd_pCe_qSm_r)₃Al₅O₁₂ can emit light of wavelengths 460nm and longer with higher efficiency upon excitation, because Gd is contained in the crystal. When the content of gadolinium is increased, peak wavelength of emission shifts from 530nm to a longer wavelength up to 570nm, while the entire emission spectrum also shifts to longer

wavelengths. When light of stronger red shade is needed, it can be achieved by increasing the amount of Gd added for substitution. When the content of Gd is increased, luminance of photoluminescence with blue light gradually decreases. Therefore, value of p is preferably 0.8 or lower, or more preferably 0.7 or lower. Further more preferably it is 0.6 or lower.

[0118] (Y_{1-p-q}) The phosphor represented by the general formula rGdpCeqSmr)3Al5O12 including Sm can be made subject to less dependence on temperature regardless of the increased content of Gd. That is, the phosphor, when Sm is contained, has greatly improved emission luminance at higher temperatures. Extent of the improvement increases as the Gd content is increased. Temperature characteristic can be greatly improved particularly by the addition of Sm in the case of fluorescent material of such a composition as red shade is strengthened by increasing the content of Gd, because it has poor temperature characteristics. The temperature characteristic mentioned here is measured in terms of the ratio (%) of emission luminance of the fluorescent material at a high temperature (200°C) relative to the emission luminance of exciting blue light having a wavelength of 450nm at the normal temperature (25°C).

[0119] The proportion of Sm is preferably within the range of $0.0003 \le r \le 0.08$ to give temperature characteristic of 60% or higher. The value of r below this range leads to less effect of improving the temperature characteristic. When the value of r is above this range, on the contrary, the temperature characteristic deteriorates. The range of $0.0007 \le r \le 0.02$ for the proportion of Sm where temperature characteristic becomes 80% or higher is more desirable.

[0120] The proportion q of Ce is preferably in a range of $0.003 \le q \le 0.2$, which makes relative emission luminance of 70% or higher possible. The relative emission luminance refers to the emission luminance in terms of percentage to the emission luminance of a fluorescent material where q=0.03.

[0121] When the proportion q of Ce is 0.003 or lower, luminance decreases because the number of excited emission centers of photoluminescence due to Ce decreases and, when the q is greater than 0.2, density quenching occurs. Density quenching refers to the decrease in emission intensity which occurs when the concentration of an activation agent added to increase the luminance of the fluorescent material is increased beyond an optimum level.

[0122] For the light emitting diode of the present invention, a mixture of two or more kinds of phosphors having compositions of $(Y_{1-p-q-r}Gd_pCe_qSm_r)_3Al_5O_{12}$ having different contents of Al, Ga, Y and Gs or Sm may also be used. This increases the RGB components and enables the application, for example, for a full-color liquid crystal display device by using a color filter.

(Light emitting components 102, 202)

[0123] The light emitting component is preferably embedded in a molding material as shown in Fig. 1 and Fig. 2. The light emitting component used in the light emitting diode of the present invention is a gallium nitride compound semiconductor capable of efficiently exciting the garnet fluorescent materials activated with cerium. The light emitting components 102, 202 employing gallium nitride compound semiconductor are made by forming a light emitting layer of gallium nitride semiconductor such as InGaN on a substrate in the MOCVD process. The structure of the light emitting component may be homostructure, heterostructure or double-heterostructure which have MIS junction, PIN junction or PN junction. Various wavelengths of emission can be selected depending on the material of the semiconductor layer and the crystallinity thereof. It may also be made in a single quantum well structure or multiple quantum well structure where a semiconductor activation layer is formed as thin as quantum effect can occur. According to the present invention, a light emitting diode capable of emitting with higher luminance without deterioration of the phosphor

can be made by making the activation layer of the light emitting component in single quantum well structure of InGaN.

When a gallium nitride compound semiconductor is used, while sapphire, [0124]spinnel, SiC, Si, ZnO or the like may be used as the semiconductor substrate, use of sapphire substrate is preferable in order to form gallium nitride of good crystallinity. A gallium nitride semiconductor layer is formed on the sapphire substrate to form a PN junction via a buffer layer of GaN, AlN, etc. The gallium nitride semiconductor has N type conductivity under the condition of not doped with any impurity, although in order to form an N type gallium nitride semiconductor having desired properties (carrier concentration, etc.) such as improved light emission efficiency, it is preferably doped with N type dopant such as Si, Ge, Se, Te, and C. In order to form a P type gallium nitride semiconductor, on the other hand, it is preferably doped with P type dopant such as Zn, Mg, Be, Ca, Sr and Ba. Because it is difficult to turn a gallium nitride compound semiconductor to P type simply by doping a P type dopant, it is preferable to treat the gallium nitride compound semiconductor doped with P type dopant in such process as heating in a furnace, irradiation with low-speed electron beam and plasma irradiation, thereby to turn it to P type. After exposing the surfaces of P type and N type gallium nitride semiconductors by the etching or other process, electrodes of the desired shapes are formed on the semiconductor layers by sputtering or vapor deposition.

[0125] Then the semiconductor wafer which has been formed is cut into pieces by means of a dicing saw, or separated by an external force after cutting grooves (half-cut) which have width greater than the blade edge width. Or otherwise, the wafer is cut into chips by scribing grid pattern of extremely fine lines on the semiconductor wafer by means of a scriber having a diamond stylus which makes straight reciprocal movement. Thus the light emitting component of gallium nitride compound semiconductor can be made.

[0126] In order to emit white light with the light emitting diode of the first embodiment, wavelength of light emitted by the light emitting component is preferably from 400nm to 530nm inclusive in consideration of the complementary color relationship with the phosphor and deterioration of resin, and more preferably from 420nm to 490nm inclusive. It is further more preferable that the wavelength be from 450nm to 475nm, in order to improve the emission efficiency of the light emitting component and the phosphor. Emission spectrum of the white light emitting diode of the first embodiment is shown in Fig. 4. The light emitting component shown here is of lead type shown in Fig. 1, which employs the light emitting component and the phosphor of the first embodiment to be described later. In Fig. 4, emission having a peak around 450 nm is the light emitted by the light emitting component, and emission having a peak around 570 nm is the photoluminescent emission excited by the light emitting component.

[0127] Fig. 16 shows the colors which can be represented by the white light emitting diode made by combining the fluorescent material shown in Table 1 and blue LED (light emitting component) having peak wavelength 465nm. Color of light emitted by this white light emitting diode corresponds to a point on a straight line connecting a point of chromaticity generated by the blue LED and a point of chromaticity generated by the fluorescent material, and therefore the wide white color region (shaded portion in Fig. 16) in the central portion of the chromaticity diagram can be fully covered by using the fluorescent materials 1 to 7 in Table 1. Fig. 17 shows the change in emission color when the contents of fluorescent materials in the white light emitting diode is changed. Contents of fluorescent materials are given in weight percentage to the resin used in the coating material. As will be seen from Fig. 17, color of the light approaches that of the fluorescent materials when the content of fluorescent material is increased and approaches that of blue LED when the content of fluorescent material decreased.

[0128] According to the present invention, a light emitting component which does not excite the fluorescent material may be used together with the light emitting

component which emits light that excites the fluorescent material. Specifically, in addition to the fluorescent material which is a nitride compound semiconductor capable of exciting the fluorescent material, a light emitting component having a light emitting layer made of gallium phosphate, gallium aluminum arsenide, gallium arsenic phosphate or indium aluminum phosphate is arranged together. With this configuration, light emitted by the light emitting component which does not excite the fluorescent material is radiated to the outside without being absorbed by the fluorescent material, making a light emitting diode which can emit red/white light.

[0129] Other components of the light emitting diodes of Fig. 1 and Fig. 2 will be described below.

(Conductive wires 103, 203)

[0130] The conductive wires 103, 203 should have good electric conductivity, good thermal conductivity and good mechanical connection with the electrodes of the light emitting components 102, 202. Thermal conductivity is preferably 0.01 cal/(s)(cm²)(°C/cm) or higher, and more preferably 0.5 cal/(s)(cm²)(°C/cm) or higher. For workability, diameter of the conductive wire is preferably from 10µm to 45µm inclusive. Even when the same material is used for both the coating including the fluorescent material and the molding, because of the difference in thermal expansion coefficient due to the fluorescent material contained in either of the above two materials, the conductive wire is likely to break at the interface. For this reason, diameter of the conductive wire is preferably not less than 25µm and, for the reason of light emitting area and ease of handling, preferably within 35µm. The conductive wire may be a metal such as gold, copper, platinum and aluminum or an alloy thereof. When a conductive wire of such material and configuration is used, it can be easily connected to the electrodes of the light emitting components, the inner lead and the mount lead by means of a wire bonding device.

(Mount lead 105)

[0131] The mount lead 105 comprises a cup 105a and a lead 105b, and it suffices to have a size enough for mounting the light emitting component 102 with the wire bonding device in the cup 105a. In case a plurality of light emitting components are installed in the cup and the mount lead is used as common electrode for the light emitting component, because different electrode materials may be used, sufficient electrical conductivity and good conductivity with the bonding wire and others are required. When the light emitting component is installed in the cup of the mount lead and the cup is filled with the fluorescent material, light emitted by the fluorescent material is, even if isotropic, reflected by the cup in a desired direction and therefore erroneous illumination due to light from other light emitting diode mounted nearby can be prevented. Erroneous illumination here refers to such a phenomenon as other light emitting diode mounted nearby appearing as though lighting despite not being supplied with power.

When a face-down light emitting component 102 and the mount lead 105 with the cup 105a can be achieved by means of a thermoplastic resin such as epoxy resin, acrylic resin and imide resin. When a face-down light emitting component (such a type of light emitting component as emitted light is extracted from the substrate side and is configured for mounting the electrodes to oppose the cup 105a) is used, Ag paste, carbon paste, metallic bump or the like can be used for bonding and electrically connecting the light emitting component and the mount lead at the same time. Further, in order to improve the efficiency of light utilization of the light emitting diode, surface of the cup of the mount lead whereon the light emitting component is mounted may be mirror-polished to give reflecting function to the surface. In this case, the surface roughness is preferably from 0.1S to 0.8 S inclusive. Electric resistance of the mount lead is preferably within $300\mu\Omega$ ·cm and more preferably within $3\mu\Omega$ ·cm. When mounting a plurality of light emitting components on the mount lead, the light emitting components generate significant amount of heat and therefore high thermal conductivity is required.

Specifically, the thermal conductivity is preferably 0.01 cal/(s)(cm²)(°C/cm) or higher, and more preferably 0.5 cal/(s)(cm²)(°C/cm) or higher. Materials which satisfy these requirements contain steel, copper, copper-clad steel, copper-clad tin and metallized ceramics.

(Inner lead 106)

[0133] The inner lead 106 is connected to one of electrodes of the light emitting component 102 mounted on the mount lead 105 by means of conductive wire or the like. In the case of a light emitting diode where a plurality of the light emitting components are installed on the mount lead, it is necessary to arrange a plurality of inner leads 106 in such a manner that the conductive wires do not touch each other. For example, contact of the conductive wires with each other can be prevented by increasing the area of the end face where the inner lead is wire-bonded as the distance from the mount lead increases so that the space between the conductive wires is secured. Surface roughness of the inner lead end face connecting with the conductive wire is preferably from 1.6 S to 10 S inclusive in consideration of close contact.

In order to form the inner lead in a desired shape, it may be punched by means of a die. Further, it may be made by punching to form the inner lead then pressurizing it on the end face thereby to control the area and height of the end face.

[0134] The inner lead is required to have good connectivity with the bonding wires which are conductive wires and have good electrical conductivity. Specifically, the electric resistance is preferably within $300\mu\Omega$ ·cm and more preferably within $3\mu\Omega$ ·cm. Materials which satisfy these requirements contain iron, copper, iron-containing copper, tin-containing copper, copper-, gold- or silver-plated aluminum, iron and copper.

(Coating material 101)

[0135] The coating material 101 is provided in the cup of the mount lead apart from the molding material 104 and, in the first embodiment, contains the phosphor which converts the light emitted by the light emitting component. The coating material may be a transparent material having good weatherability such as epoxy resin, urea resin and silicone or glass. A dispersant may be used together with the phosphor. As the dispersant, barium titanate, titanium oxide, aluminum oxide, silicon dioxide and the like are preferably used. When the fluorescent material is formed by sputtering, coating material may be omitted. In this case, a light emitting diode capable of bending colors can be made by controlling the film thickness or providing an aperture in the fluorescent material layer.

(Molding material 104)

[0136] The molding 104 has the function to protect the light emitting component 102, the conductive wire 103 and the coating material 101 which contains phosphor from external disturbance. According to the first embodiment, it is preferable that the molding material 104 further contain a dispersant, which can unsharpen the directivity of light from the light emitting component 102, resulting in increased angle of view. The molding material 104 has the function of lens to focus or diffuse the light emitted by the light emitting component. Therefore, the molding material 104 may be made in a configuration of convex lens or concave lens, and may have an elliptic shape when viewed in the direction of optical axis, or a combination of these. Also the molding material 104 may be made in a structure of multiple layers of different materials being laminated. As the molding material 104, transparent materials having high weatherability such as epoxy resin, urea resin, silicone resin or glass is preferably employed. As the dispersant, barium titanate, titanium oxide, aluminum oxide, silicon dioxide and the like can be used. In addition to the dispersant, phosphor may also be contained in the

molding material. Namely, according to the present invention, the phosphor may be contained either in the molding material or in the coating material. When the phosphor is contained in the molding material, angle of view can be further increased. The phosphor may also be contained in both the coating material and the molding material. Further, a resin including the phosphor may be used as the coating material while using glass, different from the coating material, as the molding material. This makes it possible to manufacture a light emitting diode which is less subject to the influence of moisture with good productivity. The molding and the coating may also be made of the same material in order to match the refractive index, depending on the application. According to the present invention, adding the dispersant and/or a coloration agent in the molding material has the effects of masking the color of the fluorescent material obscured and improving the color mixing performance. That is, the fluorescent material absorbs blue component of extraneous light and emits light thereby to give such an appearance as though colored in yellow. However, the dispersant contained in the molding material gives milky white color to the molding material and the coloration agent renders a desired color. Thus the color of the fluorescent material will not be recognized by the observer. In case the light emitting component emits light having main wavelength of 430nm or over, it is more preferable that ultraviolet absorber which serves as light stabilizer be contained.

Embodiment 2

[0137] The light emitting diode of the second embodiment of the present invention is made by using an element provided with gallium nitride compound semiconductor which has high-energy band gap in the light emitting layer as the light emitting component and a fluorescent material including two or more kinds of phosphors of different compositions, or preferably yttrium-aluminum-garnet fluorescent materials activated with cerium as the phosphor. With this configuration, a light emitting diode which allows to give a desired color tone by controlling the contents of the two or more

fluorescent materials can be made even when the wavelength of the LED light emitted by the light emitting component deviates from the desired value due to variations in the production process. In this case, emission color of the light emitting diode can be made constantly using a fluorescent material having a relatively short emission wavelength for a light emitting component of a relatively short emission wavelength and using a fluorescent material having a relatively long emission wavelength for a light emitting component of a relatively long emission wavelength.

[0138] As for the fluorescent material, a fluorescent material represented by general formula (Re_{1-r}Sm_r)₃(Al_{1-s}Ga_s)₅O₁₂:Ce may also be used as the phosphor. Here 0≤r<1 and 0≤s≤1, and Re is at least one selected from Y, Gd and La. This configuration makes it possible to minimize the denaturing of the fluorescent material even when the fluorescent material is exposed to high-intensity high-energy visible light emitted by the light emitting component for a long period of time or when used under various environmental conditions, and therefore a light emitting diode which is subject to extremely insignificant color shift and emission luminance decrease and has the desired emission component of high luminance can be made.

(Phosphor of the second embodiment)

[0139] Now the phosphor used in the light emitting component of the second embodiment will be described in detail below. The second embodiment is similar to the first embodiment, except that two or more kinds of phosphors of different compositions activated with cerium are used as the phosphor, as described above, and the method of using the fluorescent material is basically the same.

[0140] Similarly to the case of the first embodiment, the light emitting diode can be given high weatherability by controlling the distribution of the phosphor (such as tapering the concentration with the distance from the light emitting component). Such a distribution of the phosphor concentration can be achieved by selecting or controlling the

material which contains the phosphor, forming temperature and viscosity, and the configuration and particle size distribution of the phosphor. Thus, according to the second embodiment, distribution of the fluorescent material concentration is determined according to the operating conditions. Also, according to the second embodiment, efficiency of light emission can be increased by designing the arrangement of the two or more kinds of fluorescent materials (for example, arranging in the order of nearness to the light emitting component) according to the light generated by the light emitting component.

[0141] With the configuration of the second embodiment, similarly to the first embodiment, light emitting diode has high efficiency and enough light resistance even when arranged adjacent to or in the vicinity of relatively high-output light emitting component with radiation intensity (Ee) within the range from 3 Wcm⁻² to 10 Wcm⁻² can be made.

[0142] The yttrium-aluminum-garnet fluorescent material activated with cerium (YAG fluorescent material) used in the second embodiment has garnet structure similarly to the case of the first embodiment, and is therefore resistant to heat, light and moisture. The peak wavelength of excitation of the yttrium-aluminum-garnet fluorescent material of the second embodiment can be set near 450nm as indicated by the solid line in Fig. 5A, and the peak wavelength of emission can be set near 510nm as indicated by the solid line in Fig. 5B, while making the emission spectrum so broad as to tail out to 700nm. This makes it possible to emit green light. The peak wavelength of excitation of another yttrium-aluminum-garnet fluorescent material activated with cerium of the second embodiment can be set near 450nm as indicated by the dashed line in Fig. 5A, and the peak wavelength of emission can be set near 600nm as indicated by the dashed line in Fig. 5B, while making the emission spectrum so broad as to tail out to 750nm. This makes it possible to emit red light.

- [0143] Wavelength of the emitted light is shifted to a shorter wavelength by substituting part of Al, among the constituents of the YAG fluorescent material having garnet structure, with Ga, and the wavelength of the emitted light is shifted to a longer wavelength by substituting part of Y with Gd and/or La. Proportion of substituting Al with Ga is preferably from Ga:Al=1:1 to 4:6 in consideration of the light emitting efficiency and the wavelength of emission. Similarly, proportion of substituting Y with Gd and/or La is preferably from Y:Gd and/or La=9:1 to 1:9, or more preferably from Y:Gd and/or La=4:1 to 2:3. Substitution of less than 20% results in an increase of green component and a decrease of red component. Substitution of 80% or greater part, on the other hand, increases red component but decreases the luminance steeply.
- [0144] Material for making such a phosphor is made by using oxides of Y, Gd, Ce, La, Al, Sm and Ga or compounds which can be easily converted into these oxides at high temperature, and sufficiently mixing these materials in stoichiometrical proportions. Or either, mixture material is obtained by dissolving rare earth elements Y, Gd, Ce, La and Sm in stoichiometrical proportions in acid, coprecipitating the solution oxalic acid and firing the coprecipitate to obtain an oxide of the coprecipitate, which is then mixed with aluminum oxide and gallium oxide. This mixture is mixed with an appropriate quantity of a fluoride such as ammonium fluoride used as a flux, and fired in a crucible at a temperature from 1350 to 1450 °C in air for 2 to 5 hours. Then the fired material is ground by a ball mill in water, washed, separated, dried and sieved thereby to obtain the desired material.
- [0145] In the second embodiment, the two or more kinds of yttrium-aluminum-garnet fluorescent materials activated with cerium of different compositions may be either used by mixing or arranged independently (laminated, for example). When the two or more kinds of fluorescent materials are mixed, color converting portion can be formed relatively easily and in a manner suitable for mass production. When the two or more kinds of fluorescent materials are arranged independently, color can be adjusted after

forming it by laminating the layers until a desired color can be obtained. Also when arranging the two or more kinds of fluorescent materials independently, it is preferable to arrange a fluorescent material that absorbs light from the light emitting component of a shorter wavelength near to the LED element, and a fluorescent material that absorbs light of a longer wavelength away from the LED element. This arrangement enables efficient absorption and emission of light.

The light emitting diode of the second embodiment is made by using two [0146] or more kinds of yttrium-aluminum-garnet fluorescent materials of different compositions as the fluorescent materials, as described above. This makes it possible to make a light emitting diode capable of emitting light of desired color efficiently. That is, when wavelength of light emitted by the semiconductor light emitting component corresponds to a point on the straight line connecting point A and point B in the chromaticity diagram of Fig. 6, light of any color in the shaded region enclosed by points A, B, C and D in Fig. 6 which is the chromaticity points (points C and D) of the two or more kinds of yttrium-aluminum-garnet fluorescent materials of different compositions can be emitted. According to the second embodiment, color can be controlled by changing the compositions or quantities of the LED elements and fluorescent materials. In particular, a light emitting diode of less variation in the emission wavelength can be made by selecting the fluorescent materials according to the emission wavelength of the LED element, thereby compensating for the variation of the emission wavelength of the LED element. Also a light emitting diode including RGB components with high luminance can be made by selecting the emission wavelength of the fluorescent materials.

[0147] Moreover, because the yttrium-aluminum-garnet (YAG) fluorescent material used in the second embodiment has garnet structure, the light emitting diode of the second embodiment can emit light of high luminance for a long period of time. Also the light emitting diodes of the first embodiment and the second embodiment are provided with light emitting component installed via fluorescent material. Also because

the converted light has longer wavelength than that of the light emitted by the light emitting component, energy of the converted light is less than the band gap of the nitride semiconductor, and is less likely to be absorbed by the nitride semiconductor layer. Thus, although the light emitted by the fluorescent material is directed also to the LED element because of the isotropy of emission, the light emitted by the fluorescent material is never absorbed by the LED element, and therefore the emission efficiency of the light emitting diode will not be decreased.

(Planar light source)

[0148] A planar light source which is another embodiment of the present invention is shown in Fig. 7.

[0149] In the planar light source shown in the Fig. 7, the phosphor used in the first embodiment or the second embodiment is contained in a coating material 701. With this configuration, blue light emitted by the gallium nitride semiconductor is color-converted and is output in planar state via an optical guide plate 704 and a dispersive sheet 706.

[0150] Specifically, a light emitting component 702 of the planar light source of Fig. 7 is secured in a metal substrate 703 of inverted C shape whereon an insulation layer and a conductive pattern (not shown) are formed. After electrically connecting the electrode of the light emitting component and the conductive pattern, phosphor is mixed with epoxy resin and applied into the inverse C-shaped metal substrate 703 whereon the light emitting component 702 is mounted. The light emitting component thus secured is fixed onto an end face of an acrylic optical guide plate 704 by means of an epoxy resin. A reflector film 707 containing a white diffusion agent is arranged on one of principal planes of the optical guide plate 704 where the dispersive sheet 706 is not formed, for the purpose of preventing fluorescence.

- [0151] Similarly, a reflector 705 is provided on the entire surface on the back of the optical guide plate 704 and on one end face where the light emitting component is not provided, in order to improve the light emission efficiency. With this configuration, light emitting diodes for planar light emission which generates enough luminance for the back light of LCD can be made.
- [0152] Application of the light emitting diode for planar light emission to a liquid crystal display can be achieved by arranging a polarizer plate on one principal plane of the optical guide plate 704 via liquid crystal injected between glass substrates (not shown) whereon a translucent conductive pattern is formed.
- [0153] Now referring to Fig. 8 and Fig. 9, a planar light source according to another embodiment of the present invention will be described below. The light emitting device shown in Fig. 8 is made in such a configuration that blue light emitted by the light emitting diode 702 is converted to white light by a color converter 701 which contains phosphor and is output in planar state via an optical guide plate 704.
- [0154] The light emitting device shown in Fig. 9 is made in such a configuration that blue light emitted by the light emitting component 702 is turned to planar state by the optical guide plate 704, then converted to white light by a dispersive sheet 706 which contains phosphor formed on one of the principal plane of the optical guide plate 704, thereby to output white light in planar state. The phosphor may be either contained in the dispersive sheet 706 or formed in a sheet by spreading it together with a binder resin over the dispersive sheet 706. Further, the binder including the phosphor may be formed in dots, not sheet, directly on the optical guide plate 704.

<Application>

(Display device)

[0155] Now a display device according to the present invention will be described below. Fig. 10 is a block diagram showing the configuration of the display device

according to the present invention. As shown in Fig. 10, the display device comprises an LED display device 601 and a drive circuit 610 having a driver 602, video data storage means 603 and tone control means 604. The LED display device 601, having white light emitting diodes 501 shown in Fig. 1 or Fig. 2 arranged in matrix configuration in a casing 504 as shown in Fig. 11, is used as monochromatic LED display device. The casing 504 is provided with a light blocking material 505 being formed integrally therewith.

[0156] The drive circuit 610 has the video data storage means (RAM) 603 for temporarily storing display data which is input, the tone control means 604 which computes and outputs tone signals for controlling the individual light emitting diodes of the LED display device 601 to light with the specified brightness according to the data read from RAM 603, and the driver 602 which is switched by signals supplied from the tone control means 604 to drive the light emitting diode to light. The tone control circuit 604 retrieves data from the RAM 603 and computes the duration of lighting the light emitting diodes of the LED display device 601, then outputs pulse signals for turning on and off the light emitting diodes to the LED display device 601. In the display device constituted as described above, the LED display device 601 is capable of displaying images according to the pulse signals which are input from the drive circuit, and has the following advantages.

[0157] The LED display device which displays with white light by using light emitting diodes of three colors, RGB, is required to display while controlling the light emission output of the R, G and B light emitting diodes and accordingly must control the light emitting diodes by taking the emission intensity, temperature characteristics and other factors of the light emitting diodes into account, resulting in complicate configuration of the drive circuit which drives the LED display device. In the display device of the present invention, however, because the LED display device 601 is constituted by using light emitting diodes 501 of the present invention which can emit white light without using light emitting diodes of three kinds, RGB, it is not necessary for

the drive circuit to individually control the R, G and B light emitting diodes, making it possible to simplify the configuration of the drive circuit and make the display device at a low cost.

[0158] With an LED display device which displays in white light by using light emitting diodes of three kinds, RGB, the three light emitting diodes must be illuminated at the same time and the light from the light emitting diodes must be mixed in order to display white light by combining the three RGB light emitting diodes for each pixel, resulting in a large display area for each pixel and making it impossible to display with high definition. The LED display device of the display device according to the present invention, in contrast, can display with white light can be done with a single light emitting diode, and is therefore capable of display with white light of higher definition. Further, with the LED display device which displays by mixing the colors of three light emitting diodes, there is such a case as the display color changes due to blocking of some of the RGB light emitting diodes depending on the viewing angle, the LED display device of the present invention has no such problem.

[0159] As described above, the display device provided with the LED display device employing the light emitting diode of the present invention which is capable of emitting white light is capable of displaying stable white light with higher definition and has an advantage of less color unevenness. The LED display device of the present invention which is capable of displaying with white light also imposes less stimulation to the eye compared to the conventional LED display device which employs only red and green colors, and is therefore suited for use over a long period of time.

(Embodiment of another display device employing the light emitting diode of the present invention)

[0160] The light emitting diode of the present invention can be used to constitute an LED display device wherein one pixel is constituted of three RGB light emitting

diodes and one light emitting diode of the present invention, as shown in Fig. 12. By connecting the LED display device and a specified drive circuit, a display device capable of displaying various images can be constituted. The drive circuit of this display device has, similarly to a case of monochrome display device, video data storage means (RAM) for temporarily storing the input display data, a tone control circuit which processes the data stored in the RAM to compute tone signals for lighting the light emitting diodes with specified brightness and a driver which is switched by the output signal of the tone control circuit to cause the light emitting diodes to illuminate. The drive circuit is required exclusively for each of the RGB light emitting diodes and the white light emitting diode. The tone control circuit computes the duration of lighting the light emitting diodes from the data stored in the RAM, and outputs pulse signals for turning on and off the light emitting diodes. When displaying with white light, width of the pulse signals for lighting the RGB light emitting diodes is made shorter, or peak value of the pulse signal is made lower or no pulse signal is output at all. On the other hand, a pulse signal is given to the white light emitting diode in compensation thereof. This causes the LED display device to display with white light.

[0161] As described above, brightness of display can be improved by adding the white light emitting diode to the RGB light emitting diodes. When RGB light emitting diodes are combined to display white light, one or two of the RGB colors may be enhanced resulting in a failure to display pure white depending on the viewing angle, such a problem is solved by adding the white light emitting diode as in this display device.

[0162] For the drive circuit of such a display device as described above, it is preferable that a CPU be provided separately as a tone control circuit which computes the pulse signal for lighting the white light emitting diode with specified brightness. The pulse signal which is output from the tone control circuit is given to the white light emitting diode driver thereby to switch the driver. The white light emitting diode illuminates when the driver is turned on, and goes out when the driver is turned off.

(Traffic signal)

When the light emitting diode of the present invention is used as a traffic [0163] signal which is a kind of display device, such advantages can be obtained as stable illumination over a long period of time and no color unevenness even when part of the light emitting diodes go out. The traffic signal employing the light emitting diode of the present invention has such a configuration as white light emitting diodes are arranged on a substrate whereon a conductive pattern is formed. A circuit of light emitting diodes wherein such light emitting diodes are connected in series or parallel is handled as a set of light emitting diodes. Two or more sets of the light emitting diodes are used, each having the light emitting diodes arranged in spiral configuration. When all light emitting diodes are arranged, they are arranged over the entire area in circular configuration. After connecting power lines by soldering for the connection of the light emitting diodes and the substrate with external power supply, it is secured in a chassis of railway signal. The LED display device is placed in an aluminum diecast chassis equipped with a light blocking member and is sealed on the surface with silicone rubber filler. The chassis is provided with a white color lens on the display plane thereof. Electric wiring of the LED display device is passed through a rubber packing on the back of the chassis, for sealing off the inside of the chassis from the outside, with the inside of the chassis closed. Thus a signal of white light is made. A signal of higher reliability can be made by dividing the light emitting diodes of the present invention into a plurality of groups and arranging them in a spiral configuration swirling from a center toward outside, while connecting them in parallel. The configuration of swirling from the center toward outside may be either continuous or intermittent. Therefore, desired number of the light emitting diodes and desired number of the sets of light emitting diodes can be selected depending on the display area of the LED display device. This signal is, even when one of the sets of light emitting diodes or part of the light emitting diodes fail to illuminate due to some trouble, capable of illuminate evenly in a circular configuration without color shift by means of the remaining set of light emitting diodes or remaining light emitting diodes. Because the light emitting diodes are arranged in a spiral configuration, they can be arranged more densely near the center, and driven without any different impression from signals employing incandescent lamps.

<Examples>

[0164] The following Examples further illustrate the present invention in detail but are not to be construed to limit the scope thereof.

(Example 1)

Example 1 provides a light emitting component having an emission peak [0165] at 450nm and a half width of 30nm employing a GaInN semiconductor. The light emitting component of the present invention is made by flowing TMG (trimethyl gallium) gas, TMI (trimethyl indium) gas, nitrogen gas and dopant gas together with a carrier gas on a cleaned sapphire substrate and forming a gallium nitride compound semiconductor layer in MOCVD process. A gallium nitride semiconductor having N type conductivity and a gallium nitride semiconductor having P type conductivity are formed by switching SiH₄ and Cp₂Mg as dopant gas. The LED element of Example 1 has a contact layer which is a gallium nitride semiconductor having N type conductivity, a clad layer which is a gallium nitride aluminum semiconductor having P type conductivity and a contact layer which is a gallium nitride semiconductor having P type conductivity, and formed between the contact layer having N type conductivity and the clad layer having P type conductivity is a non-doped InGaN activation layer of thickness about 3 nm for making a single quantum well structure. The sapphire substrate has a gallium nitride semiconductor layer formed thereon under a low temperature to make a buffer layer. The P type semiconductor is annealed at a temperature of 400°C or above after forming the film.

[0166] After exposing the surfaces of P type and N type semiconductor layers by etching, n and p electrodes are formed by sputtering. After scribing the semiconductor wafer which has been made as described above, light emitting components are made by dividing the wafer with external force.

[0167] The light emitting component made in the above process is mounted in a cup of a mount lead which is made of silver-plated steel by die bonding with epoxy resin. Then electrodes of the light emitting component, the mount lead and the inner lead are electrically connected by wire boding with gold wires 30µm in diameter, to make a light emitting diode of lead type.

[0168] A phosphor is made by dissolving rare earth elements of Y, Gd and Ce in an acid in stoichiometrical proportions, and coprecipitating the solution with oxalic acid. Oxide of the coprecipitate obtained by firing this material is mixed with aluminum oxide, thereby to obtain the mixture material. The mixture was then mixed with ammonium fluoride used as a flux, and fired in a crucible at a temperature of 1400°C in air for 3 hours. Then the fired material is ground by a ball mill in water, washed, separated, dried and sieved thereby to obtained the desired material. Phosphor made as describe above is yttrium-aluminum-garnet fluorescent material represented by general formula $(Y_{0.8}Gd_{0.2})_3Al_5O_{12}$:Ce where about 20% of Y is substituted with Gd and substitution ratio of Ce is 0.03.

[0169] 80 Parts by weight of the fluorescent material having a composition of (Y_{0.8}Gd_{0.2})₃Al₅O₁₂:Ce which has been made in the above process and 100 parts by weight of epoxy resin are sufficiently mixed to turn into slurry. The slurry is poured into the cup provided on the mount lead whereon the light emitting component is mounted. After pouring, the slurry is cured at 130°C for one hour. Thus a coating having a thickness of 120μm, which contains the phosphor, is formed on the light emitting component. In Example 1, the coating is formed to contain the phosphor in gradually increasing concentration toward the light emitting component. Irradiation intensity is about

3.5W/cm². The light emitting component and the phosphor are molded with translucent epoxy resin for the purpose of protection against extraneous stress, moisture and dust. A lead frame with the coating layer of phosphor formed thereon is placed in a bullet-shaped die and mixed with translucent epoxy resin and then cured at 150 °C for 5 hours.

[0170] Under visual observation of the light emitting diode formed as described above in the direction normal to the light emitting plane, it was found that the central portion was rendered yellowish color due to the body color of the phosphor.

[0171] Measurements of chromaticity point, color temperature and color rendering index of the light emitting diode made as described above and capable of emitting white light gave values of (0.302, 0.280) for chromaticity point (x, y), color temperature of 8080 K and 87.5 for color rendering index (Ra) which are approximate to the characteristics of a 3-waveform fluorescent lamp. Light emitting efficiency was 9.5 lm/W, comparable to that of an incandescent lamp. Further in life tests under conditions of energization with a current of 60mA at 25°C, 20mA at 25°C and 20mA at 60°C with 90% RH, no change due to the fluorescent material was observed, proving that the light emitting diode had no difference in service life from the conventional blue light emitting diode.

(Comparative Example 1)

[0172] Formation of a light emitting diode and life tests thereof were conducted in the same manner as in Example 1 except for changing the phosphor from $(Y_{0.8}Gd_{0.2})_3Al_5O_{12}$:Ce to (ZnCd)S:Cu, Al. The light emitting diode which had been formed showed, immediately after energization, emission of white light but with low luminance. In a life test, the output diminished to zero in about 100 hours. Analysis of the cause of deterioration showed that the fluorescent material was blackened.

[0173] This trouble is supposed to have been caused as the light emitted by the light emitting component and moisture which had caught on the fluorescent material or

entered from the outside brought about photolysis to make colloidal zinc to precipitate on the surface of the fluorescent material, resulting in blackened surface. Results of life tests under conditions of energization with a current of 20mA at 25 °C and 20mA at 60 °C with 90% RH are shown in Fig. 13 together with the results of Example 1. Luminance is given in terms of relative value with respect to the initial value as the reference. A solid line indicates Example 1 and a wavy line indicates Comparative Example 1 in Fig. 13.

(Example 2)

[0174] In Example 2, a light emitting component was made in the same manner as in Example 1 except for increasing the content of In in the nitride compound semiconductor of the light emitting component to have the emission peak at 460 nm and increasing the content of Gd in phosphor than that of Example 1 to have a composition of $(Y_{0.6}Gd_{0.4})_3Al_5O_{12}$:Ce.

[0175] Measurements of chromaticity point, color temperature and color rendering index of the light emitting diode, which were made as described above and capable of emitting white light, gave values of (0.375, 0.370) for chromaticity point (x, y), color temperature of 4400 K and 86.0 for color rendering index (Ra). Fig. 18A, Fig. 18B and Fig. 18C show the emission spectra of the phosphor, the light emitting component and the light emitting diode of Example 2, respectively.

[0176] 100 pieces of the light emitting diodes of Example 2 were made and average luminous intensities thereof were taken after lighting for 1000 hours. In terms of percentage of the luminous intensity value before the life test, the average luminous intensity after the life test was 98.8%, proving no difference in the characteristic.

(Example 3)

[0177] 100 light emitting diodes were made in the same manner as in Example 1 except for adding Sm in addition to rare earth elements Y, Gd and Ce in the phosphor to make a fluorescent material with composition of $(Y_{0.39}Gd_{0.57}Ce_{0.03}Sm_{0.01})_3Al_5O_{12}$. When the light emitting diodes were made illuminate at a high temperature of 130 °C, average temperature characteristic about 8% better than that of Example 1 was obtained.

(Example 4)

[0178] LED display device of Example 4 is made of the light emitting diodes of Example 1 being arranged in a 16 x 16 matrix on a ceramics substrate whereon a copper pattern is formed as shown in Fig. 11. In the LED display device of Example 4, the substrate whereon the light emitting diodes are arranged is placed in a chassis 504 which is made of phenol resin and is provided with a light blocking member 505 being formed integrally therewith. The chassis, the light emitting diodes, the substrate and part of the light blocking member, except for the tips of the light emitting diodes, are covered with silicone rubber 506 colored in black with a pigment. The substrate and the light emitting diodes are soldered by means of an automatic soldering machine.

RAM which temporarily stores the input display data, a tone control circuit which processes the data stored in the RAM to compute tone signals for lighting the light emitting diodes with specified brightness and drive means which is switched by the output signal of the tone control circuit to cause the light emitting diodes to illuminate are electrically connected to make an LED display device. By driving the LED display devices, it was verified that the apparatus can be used as black and white LED display device.

(Example 5)

[0180] The light emitting diode of Example 5 was made in the same manner as in Example 1 except for using phosphor represented by general formula $(Y_{0.2}Gd_{0.8})_3Al_5O_{12}$:Ce. 100 pieces of the light emitting diodes of Example 5 were made and measured for various characteristics.

[0181] Measurement of chromaticity point gave values of (0.450, 0.420) in average for chromaticity point (x, y), and light of incandescent lamp color was emitted. Fig. 19A, Fig. 19B and Fig. 19C show the emission spectra of the phosphor, the light emitting component and the light emitting diode of Example 5, respectively. Although the light emitting diodes of Example 5 showed luminance about 40% lower than that of the light emitting diodes of Example 5, showed good weatherability comparable to that of Example 1 in life test.

(Example 6)

[0182] The light emitting diode of Example 6 was made in the same manner as in Example 1 except for using phosphor represented by general formula Y₃Al₅O₁₂:Ce. 100 pieces of the light emitting diodes of Example 6 were made and measured for various characteristics.

[0183] Measurement of chromaticity point slightly yellow-greenish white light compared to Example 1 was emitted. The light emitting diode of Example 6 showed good weatherability similar to that of Example 1 in life test. Fig. 20A, Fig. 20B and Fig. 20C show the emission spectra of the phosphor, the light emitting component and the light emitting diode of Example 6, respectively.

(Example 7)

[0184] The light emitting diode of Example 7 was made in the same manner as in Example 1 except for using phosphor represented by general formula

Y₃(Al_{0.5}Ga_{0.5})₅O₁₂:Ce. 100 pieces of the light emitting diodes of Example 7 were made and measured for various characteristics.

[0185] Although the light emitting diodes of Example 7 showed a low luminance, emitted greenish white light and showed good weatherability similar to that of Example 1 in life test. Fig. 21A, Fig. 21B and Fig. 21C show the emission spectra of the phosphor, the light emitting component and the light emitting diode of Example 7, respectively.

(Example 8)

[0186] The light emitting diode of Example 8 was made in the same manner as in Example 1 except for using phosphor represented by general formula $Gd_3(Al_{0.5}Ga_{0.5})_5O_{12}$:Ce which does not contain Y. 100 pieces of the light emitting diodes of Example 8 were made and measured for various characteristics.

[0187] Although the light emitting diodes of Example 8 showed a low luminance, showed good weatherability similar to that of Example 1 in life test.

(Example 9)

[0188] Light emitting diode of Example 9 is planar light emitting device having the configuration shown in Fig. 7.

[0189] In _{0.05}Ga_{0.95}N semiconductor having emission peak at 450nm is used as a light emitting component. Light emitting components are made by flowing TMG (trimethyl gallium) gas, TMI (trimethyl indium) gas, nitrogen gas and dopant gas together with a carrier gas on a cleaned sapphire substrate and forming a gallium nitride compound semiconductor layer in MOCVD process. A gallium nitride semiconductor layer having N type conductivity and a gallium nitride semiconductor layer having P type conductivity are formed by switching SiH₄ and Cp₂Mg as dopant gas, thereby forming a PN junction. For the semiconductor light emitting component, a contact layer which is gallium nitride semiconductor having N type conductivity, a clad layer which is gallium

nitride aluminum semiconductor having N type conductivity, a clad layer which is gallium nitride aluminum semiconductor having P type conductivity and a contact layer which is gallium nitride semiconductor having P type conductivity are formed. An activation layer of Zn-doped InGaN which makes a double-hetero junction is formed between the clad layer having N type conductivity and the clad layer having P type conductivity. A buffer layer is provided on the sapphire substrate by forming gallium nitride semiconductor layer at a low temperature. The P type nitride semiconductor layer is annealed at a temperature of 400°C or above after forming the film.

[0190] After forming the semiconductor layers and exposing the surfaces of P type and N type semiconductor layers by etching, electrodes are formed by sputtering. After scribing the semiconductor wafer which has been made as described above, light emitting components are made as light emitting components by dividing the wafer with external force.

[0191] The light emitting component is mounted on a mount lead which has a cup at the tip of a silver-plated copper lead frame, by die bonding with epoxy resin. Electrodes of the light emitting component, the mount lead and the inner lead are electrically connected by wire boding with gold wires having a diameter of 30 µm.

[0192] The lead frame with the light emitting component attached thereon is placed in a bullet-shaped die and sealed with translucent epoxy resin for molding, which is then cured at 150°C for 5 hours, thereby to form a blue light emitting diode. The blue light emitting diode is connected to one end face of an acrylic optical guide plate which is polished on all end faces. On one surface and side face of the acrylic plate, screen printing is applied by using barium titanate dispersed in an acrylic binder as white color reflector, which is then cured.

[0193] Phosphor of green and red colors are made by dissolving rare earth elements of Y, Gd, Ce and La in acid in stoichiometrical proportions, and coprecipitating the solution with oxalic acid. Oxide of the coprecipitate obtained by firing this material

is mixed with aluminum oxide and gallium oxide, thereby to obtain respective mixture materials. The mixture is then mixed with ammonium fluoride used as a flux, and fired in a crucible at a temperature of 1400 °C in air for 3 hours. Then the fired material is ground by a ball mill in water, washed, separated, dried and sieved thereby to obtained the desired material.

[0194] 120 parts by weight of the first fluorescent material having a composition of Y₃(Al_{0.6}Ga_{0.4})₅O₁₂:Ce and capable of emitting green light prepared as described above and 100 parts by weight of the second fluorescent material having a composition of (Y_{0.4}Gd_{0.6})₃Al₅O₁₂:Ce and capable of emitting red light prepared in a process similar to that for the first fluorescent material, are sufficiently mixed with 100 parts by weight of epoxy resin, to form a slurry. The slurry is applied uniformly onto an acrylic layer having a thickness of 0.5 mm by means of a multi-coater, and dried to form a fluorescent material layer to be used as a color converting material having a thickness of about 30μm. The fluorescent material layer is cut into the same size as that of the principal light emitting plane of the optical guide plate, and arranged on the optical guide plate thereby to form the planar light emitting device. Measurements of chromaticity point and color rendering index of the light emitting device gave values of (0.29, 0.34) for chromaticity point (x, y) and 92.0 for color rendering index (Ra) which are approximate to the properties of 3-waveform fluorescent lamp. Light emitting efficiency of 12 lm/W comparable to that of an incandescent lamp was obtained. Further in weatherability tests under conditions of energization with a current of 60mA at room temperature, 20mA at room temperature and 20mA at 60°C with 90% RH, no change due to the fluorescent material was observed.

(Comparative Example 2)

[0195] Forming of light emitting diode and weatherability tests thereof were conducted in the same manner as in Example 9 except for mixing the same quantities of a

green organic fluorescent pigment (FA-001 of Synleuch Chemisch) and a red organic fluorescent pigment (FA-005 of Synleuch Chemisch) which are perylene-derivatives, instead of the first fluorescent material represented by general formula $Y_3(Al_{0.6}Ga_{0.4})_5O_{12}$:Ce capable of emitting green light and the second fluorescent material represented by general formula $(Y_{0.4}Gd_{0.6})_3Al_5O_{12}$:Ce capable of emitting red light of Example 9. Chromaticity coordinates of the light emitting diode of Comparative Example 1 thus formed were (x, y) = (0.34, 0.35). Weatherability test was conducted by irradiating with ultraviolet ray generated by carbon arc for 200 hours, representing equivalent irradiation of sun light over a period of one year, while measuring the luminance retaining ratio and color tone at various times during the test period. In a reliability test, the light emitting component was energized to emit light at a constant temperature of 70°C while measuring the luminance and color tone at different times. The results are shown in Fig. 14 and Fig. 15, together with Example 9. As will be clear from Fig. 14 and Fig. 15, the light emitting component of Example 9 experiences less deterioration than Comparative Example 2.

(Example 10)

[0196] The light emitting diode of Example 10 is a lead type light emitting diode.

[0197] In the light emitting diode of Example 10, the light emitting component having a light emitting layer of In_{0.05}Ga_{0.95}N with emission peak at 450nm which is made in the same manner as in Example 9 is used. The light emitting component is mounted in the cup provided at the tip of a silver-plated copper mount lead, by die bonding with epoxy resin. Electrodes of the light emitting component, the mount lead and the inner lead were electrically connected by wire boding with gold wires.

[0198] Phosphor is made by mixing a first fluorescent material represented by general formula Y₃(Al_{0.5}Ga_{0.5})₅O₁₂:Ce capable of emitting green light and a second fluorescent material represented by general formula (Y_{0.2}Gd_{0.8})₃Al₅O₁₂:Ce capable of

emitting red light prepared as follows. Namely, rare earth elements of Y, Gd and Ce are solved in acid in stoichiometrical proportions, and coprecipitating the solution with oxalic acid. Oxide of the coprecipitation obtained by firing it is mixed with aluminum oxide and gallium oxide, thereby to obtain respective mixture materials. The mixture is mixed with ammonium fluoride used as a flux, and fired in a crucible at a temperature of 1400°C in air for 3 hours. Then, the fired material is ground by a ball mill in water, washed, separated, dried and sieved thereby to obtained the first and second fluorescent materials of the specified particle size distribution.

10199] 40 parts by weight of the first fluorescent material, 40 parts by weight of the second fluorescent material and 100 parts by weight of epoxy resin are sufficiently mixed to form a slurry. The slurry is poured into the cup which is provided on the mount lead wherein the light emitting component is placed. Then the resin including the phosphor is cured at 130°C for 1 hour. Thus a coating layer including the phosphor in thickness of 120μm is formed on the light emitting component. Concentration of the phosphor in the coating layer is increased gradually toward the light emitting component. Further, the light emitting component and the phosphor are sealed by molding with translucent epoxy resin for the purpose of protection against extraneous stress, moisture and dust. A lead frame with the coating layer of phosphor formed thereon is placed in a bullet-shaped die and mixed with translucent epoxy resin and then cured at 150°C for 5 hours. Under visual observation of the light emitting diode formed as described above in the direction normal to the light emitting plane, it was found that the central portion was rendered yellowish color due to the body color of the phosphor.

[0200] Measurements of chromaticity point, color temperature and color rendering index of the light emitting diode of Example 10 which was made as described above gave values of (0.32, 0.34) for chromaticity point (x, y), 89.0 for color rendering index (Ra) and light emitting efficiency of 10 lm/W. Further in weatherability tests under conditions of energization with a current of 60mA at room temperature, 20mA at room

temperature and 20mA at 60°C with 90% RH, no change due to the phosphor was observed, showing no difference from an ordinary blue light emitting diode in the service life characteristic.

(Example 11)

[0201] In_{0.4}Ga_{0.6}N semiconductor having an emission peak at 470nm is used as an LED element. Light emitting components are made by flowing TMG (trimethyl gallium) gas, TMI (trimethyl indium) gas, nitrogen gas and dopant gas together with a carrier gas on a cleaned sapphire substrate thereby to form a gallium nitride compound semiconductor layer in the MOCVD process. A gallium nitride semiconductor layer having N type conductivity and a gallium nitride semiconductor layer having P type conductivity were formed by switching SiH₄ and Cp₂Mg used as the dopant gas, thereby forming a PN junction. For the LED element, a contact layer which is gallium nitride semiconductor having N type conductivity, a clad layer which is gallium nitride aluminum semiconductor having P type conductivity and a contact layer which is gallium nitride semiconductor having P type conductivity are formed. An activation layer of nondoped InGaN with thickness of about 3nm is formed between the contact layer having N type conductivity and the clad layer having P type conductivity, thereby to make single quantum well structure. A buffer layer is provided on the sapphire substrate by forming a gallium nitride semiconductor layer at a low temperature.

[0202] After forming the layers and exposing the surfaces of P type and N type semiconductor layers by etching, electrodes are formed by sputtering. After scribing the semiconductor wafer which is made as described above, light emitting components are made by dividing the wafer with an external force.

[0203] The light emitting component is mounted in a cup at the tip of a silverplated copper mount lead by die bonding with epoxy resin. Electrodes of the light emitting component, the mount lead and the inner lead are electrically connected by wire boding with gold wires having a diameter of 30µm.

[0204] The lead frame with the light emitting component attached thereon is placed in a bullet-shaped die and sealed with translucent epoxy resin for molding, which is then cured at 150°C for 5 hours, thereby to form a blue light emitting diode. The blue light emitting diode is connected to one end face of an acrylic optical guide plate which is polished on all end faces. On one surface and side face of the acrylic plate, screen printing is applied by using barium titanate dispersed in an acrylic binder as white color reflector, which is then cured.

[0205]Phosphor is made by mixing a fluorescent material represented by general formula (Y_{0.8}Gd_{0.2})₃Al₅O₁₂:Ce capable of emitting yellow light of relatively short represented wavelength and fluorescent material by general (Y_{0.4}Gd_{0.6})₃Al₅O₁₂:Ce capable of emitting yellow light of relatively long wavelength prepared as follows. Namely, rare earth elements of Y, Gd and Ce are solved in acid in stoichiometrical proportions, and coprecipitating the solution with oxalic acid. Oxide of the coprecipitation obtained by firing it is mixed with aluminum oxide, thereby to obtain respective mixture material. The mixture is mixed with ammonium fluoride used as a flux, and fired in a crucible at a temperature of 1400°C in air for 3 hours. Then the fired material is ground by a ball mill in water, washed, separated, dried and sieved.

[0206] 100 parts by weight of yellow fluorescent material of relatively short wavelength and 100 parts by weight of yellow fluorescent material of relatively long wavelength which are made as described above are sufficiently mixed with 1000 parts by weight of acrylic resin and extruded, thereby to form a fluorescent material film to be used as color converting material of about 180μm in thickness. The fluorescent material film is cut into the same size as the principal emission plane of the optical guide plate and arranged on the optical guide plate, thereby to make a light emitting device. Measurements of chromaticity point and color rendering index of the light emitting

device of Example 3 which is made as described above gave values of (0.33, 0.34) for chromaticity point (x, y), 88.0 for color rendering index (Ra) and light emitting efficiency of 101 m/W. Fig. 22A, Fig. 22B and Fig. 22C show emission spectra of the fluorescent material represented by (Y_{0.8}Gd_{0.2})₃Al₅O₁₂:Ce and a fluorescent material represented by general formula (Y_{0.4}Gd_{0.6})₃Al₅O₁₂:Ce used in Example 11. Fig. 23 shows emission spectrum of the light emitting diode of Example 11. Further in life tests under conditions of energization with a current of 60mA at room temperature, 20mA at room temperature and 20mA at 60°C with 90% RH, no change due to the fluorescent material was observed. Similarly, desired chromaticity can be maintained even when the wavelength of the light emtting component is changed by changing the content of the fluorescent material.

(Example 12)

[0207] The light emitting diode of Example 12 was made in the same manner as in Example 1 except for using phosphor represented by general formula $Y_3In_5O_{12}$:Ce. 100 pieces of the light emitting diode of Example 12 were made. Although the light emitting diode of Example 12 showed luminance lower than that of the light emitting diodes of Example 1, showed good weatherability comparable to that of Example 1 in life test.

[0208] As described above, the light emitting diode of the present invention can emit light of a desired color and is subject to less deterioration of emission efficiency and good weatherability even when used with high luminance for a long period of time. Therefore, application of the light emitting diode is not limited to electronic appliances but can open new applications including display for automobile, aircraft and buoys for harbors and ports, as well as outdoor use such as sign and illumination for expressways.

WHAT IS CLAIMED IS:

1. A method for manufacturing a light emitting device comprising:

preparing a light emitting component having an active layer of a semiconductor, said active layer comprising a gallium nitride based semiconductor containing indium and being capable of emitting a blue color light having a spectrum with a peak wavelength within the range from 420 to 490 nm;

preparing a phosphor capable of absorbing a part of the blue color light emitted from said light emitting component and emitting a yellow color light having a broad emission spectrum comprising a peak wavelength existing around the range from 510 to 600 nm and a tail continuing beyond 700 nm, wherein selection of said phosphor is controlled based on an emission wavelength of said light emitting component; and

combining said light emitting component and said phosphor so that the blue color light from said light emitting component and the yellow color light from said phosphor are mixed to make a white color light, wherein a chromaticity point of the white color light is on a straight line connecting a point of chromaticity of the blue color light and a point of chromaticity of the yellow color light, and

wherein a content of said phosphor in said light emitting device is selected to obtain a desired chromaticity of the white color light.

- 2. The method for manufacturing a light emitting device according to claim 1, wherein said phosphor comprises a garnet fluorescent material activated with cerium.
- 3. The method for manufacturing a light emitting device according to claim 1, wherein said phosphor comprises two or more kinds of fluorescent materials.
- 4. The method for manufacturing a light emitting device according to claim 1, wherein

the emission spectrum of said phosphor comprises a peak wavelength existing around the range from 530 to 570 nm and a tail continuing beyond 700 nm.

- 5. The method for manufacturing a light emitting device according to claim 1, wherein said phosphor comprises an yttrium-aluminum-garnet fluorescent material containing Y and Al.
- 6. The method for manufacturing a light emitting device according to claim 1, wherein said phosphor has a crystal structure.
- 7. The method for manufacturing a light emitting device according to claim 1, wherein the active layer of said light emitting component has a single quantum well or multi quantum well structure.
- 8. The method for manufacturing a light emitting device according to claim 1, wherein the active layer of said light emitting component comprises InGaN.
- 9. The method for manufacturing a light emitting device according to claim 1, wherein said light emitting device is capable of emitting white light substantially along the black body radiation locus.
- 10. The method for manufacturing a light emitting device according to claim 1, further comprising:

controlling emission color of said light emitting device by changing a content of said phosphor with respect to a content of a resin in a coating material.

11. The method for manufacturing a light emitting device according to claim 1, wherein

said step of controlling selection of said phosphor is used to reduce variation in the emission wavelength of said light emitting device, by compensating for a variation of the emission wavelength of said light emitting component.

12. The method for manufacturing a light emitting device according to claim 3, further comprising:

controlling compositions or quantities of light emitting components and fluorescent materials included in said light emitting device, to control color emitted by said light emitting device.

- 13. The method for manufacturing a light emitting device according to claim 3, wherein the emission wavelength of the fluorescent materials are selected so that said light emitting device produces RGB components with high luminance.
- 14. The method for manufacturing a light emitting device according to claim 13, wherein the emission spectrum of one fluorescent material comprises a peak wavelength around 510 nm, and the emission spectrum tails out to around 700 nm, and

the emission spectrum of a second fluorescent material comprises a peak wavelength around 600 nm, and the emission spectrum tails out to around 750 nm, so that said light emitting device produces RGB components with high luminance.

- 15. The method for manufacturing a light emitting device according to claim 3, further comprising mixing said two or more kinds of fluorescent materials.
- 16. The method for manufacturing a light emitting device according to claim 3, wherein said two or more kinds of fluorescent materials are arranged independently to adjust color by laminating the layers of fluorescent materials.

- 17. The method for manufacturing a light emitting device according to claim 3, wherein one of said fluorescent materials absorbs light of a shorter wavelength and another of said fluorescent materials absorbs light of a longer wavelength, and said fluorescent material that absorbs light of a longer wavelength is arranged away from said light emitting component, while said fluorescent material that absorbs light of a shorter wavelength is arranged near said light emitting component.
- 18. The method for manufacturing a light emitting device according to claim 1, wherein said phosphor is a fluorescent material represented by formula $(Re_{1-r}Sm_r)_3$ $(Al_{1-s}Ga_s)_5O_{12}$:Ce where $0 \le r < 1$, $0 \le s \le 1$ and Re is at least one element selected from Y, Gd and La.
- 19. The method for manufacturing a light emitting device according to claim 1, further comprising:

controlling compositions or quantities of light emitting components included in said light emitting device and controlling composition of said phosphor, to control color emitted by said light emitting device.

ABSTRACT OF THE DISCLOSURE

A method for manufacturing a light emitting device comprises: preparing a light emitting component having an active layer of a semiconductor, the active layer comprising a gallium nitride based semiconductor containing indium and being capable of emitting a blue color light; preparing a phosphor capable of absorbing a part of the blue color light emitted from the light emitting component and emitting a yellow color light, wherein selection of the phosphor is controlled based on an emission wavelength of the light emitting component; and combining the light emitting component and the phosphor so that the blue color light from the light emitting component and the yellow color light from the phosphor are mixed to make a white color light.

BIRE STEWART, KOLASCH & B. H, LLP



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	Information	(Number)	Japan (Country)	(Month/Day/Year Filed)	X
	(if appropriate)	P 08-244339 .	Japan	09/17/1996	Yes No
		(Number)	(Country)	(Month/Day/Year Filed)	Yes No
		P 08-245381	Japan	09/18/1996	X
		(Number)	(Country)	(Month/Day/Year Filed)	Yes No
	•	P 08-359004	Japan	12/27/1996	X \square
		(Number) P 09-081010	(Country)	(Month/Day/Year Filed) 03/31/1997	Yes No
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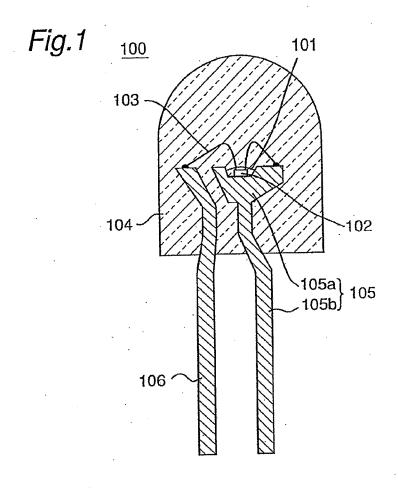
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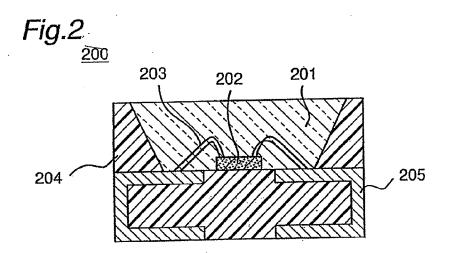
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Insert Post Office Address	POST OFFICE ADDRESS (Complete Street Address indiction of Nichia Kagaku Kogyo Kabush Anan-shi, TOKUSHIMA 774 JAPAN	uding City. State & Country) iki Kaisha, 491–100	O, Oka, Kamina	kacho,
Full Name of Second Inventor, if any:	GIVEN NAME FAMILY NAME	INVENTOR'S SIGNATURE		DATE* 07/22/1997
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Full Name of Third Inventor, if any:	GIVEN NAME FAMILY NAME	INVENTOR'S SIGNATURE		DATE*
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App No.: NEW Docket No.: Inventor: Yoshinori SHIMIZU et al.
Title: LIGHT EMITTING DEVICE AND DISPLAY Docket No.: 0020-5147PUS12

Sheet 1 of 19





Docket No.: 0020-5147PUS12 App No.: NEW Inventor: Yoshinori SHIMIZU et al.

Title: LIGHT EMITTING DEVICE AND DISPLAY

Sheet 2 of 19

Fig.3A

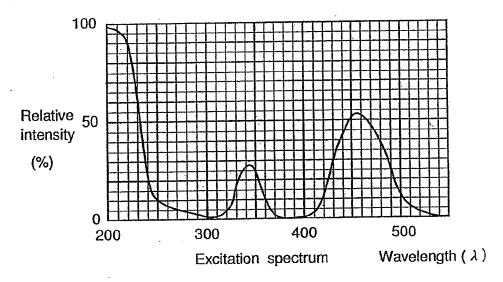
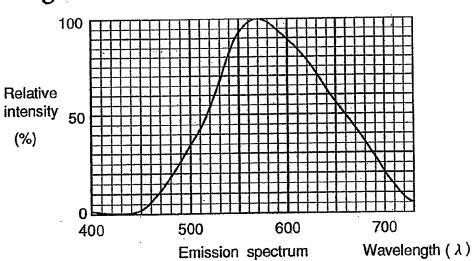
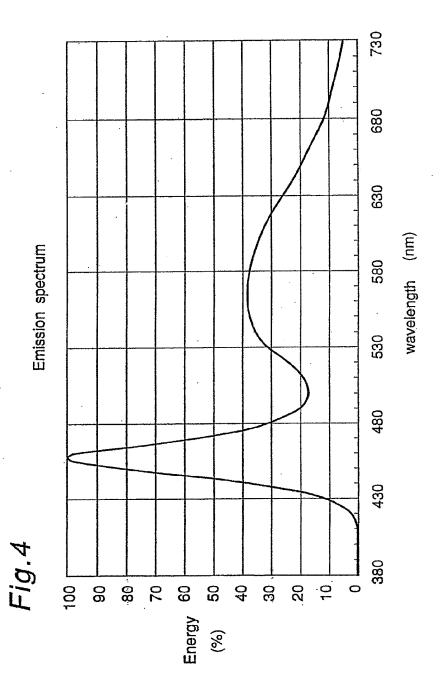


Fig.3B



App No.: NEW Docket No.: Inventor: Yoshinori SHIMIZU et al. Title: LIGHT EMITTING DEVICE AND DISPLAY Sheet 3 of 19 Docket No.: 0020-5147PUS12



0020-5147PUS12 App No.: NEW Docket No.:

Inventor: Yoshinori SHIMIZU et al.
Title: LIGHT EMITTING DEVICE AND DISPLAY

Sheet 4 of 19

Fig.5A

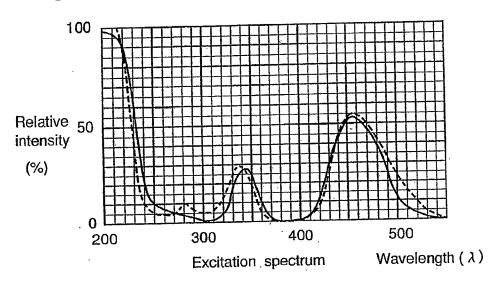
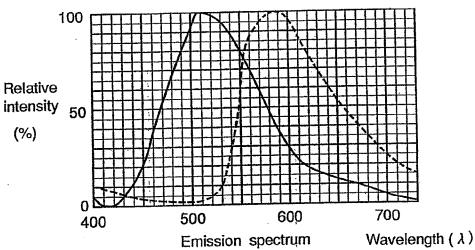


Fig.5B

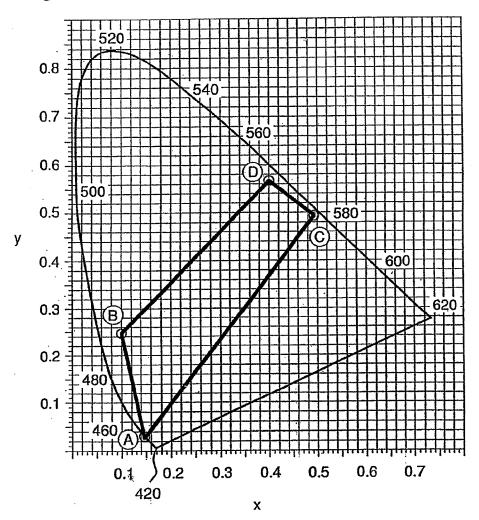


Docket No.: 0020-5147PUS12

App No.: NEW Docket No.: Inventor: Yoshinori SHIMIZU et al. Title: LIGHT EMITTING DEVICE AND DISPLAY

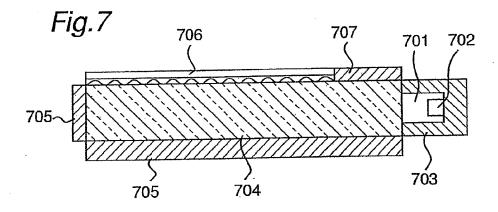
Sheet 5 of 19

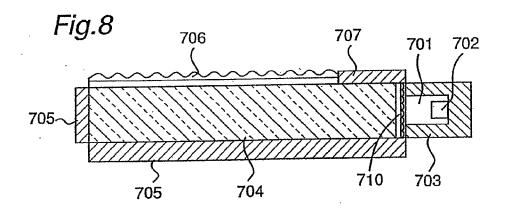
Fig.6

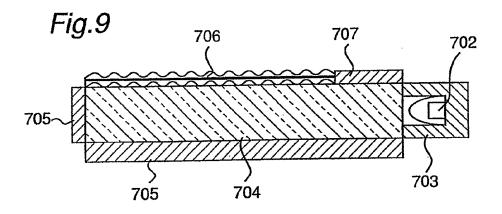


Docket No.: 0020-5147PUS12

App No.: NEW Docket No.: Inventor: Yoshinori SHIMIZU et al.
Title: LIGHT EMITTING DEVICE AND DISPLAY Sheet 6 of 19



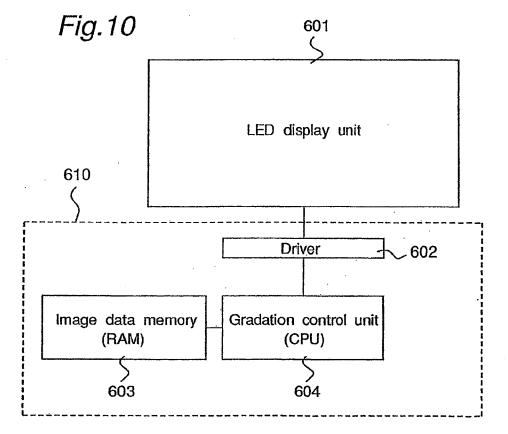




App No.: NEW Inventor: Yoshinori SHIMIZU et al. Docket No.: 0020-5147PUS12

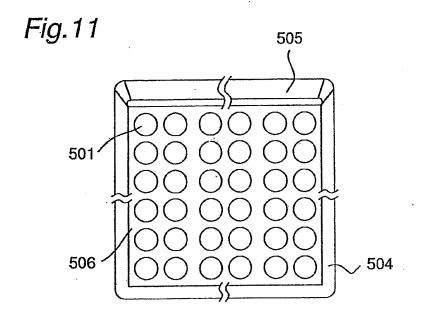
Title: LIGHT EMITTING DEVICE AND DISPLAY

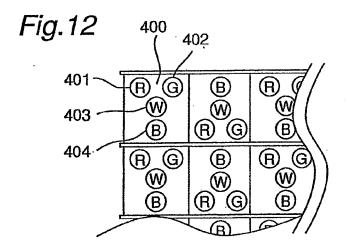
Sheet 7 of 19



App No.: NEW Docket No.: Inventor: Yoshinori SHIMIZU et al. Title: LIGHT EMITTING DEVICE AND DISPLAY Docket No.: 0020-5147PUS1

Sheet 8 of 19

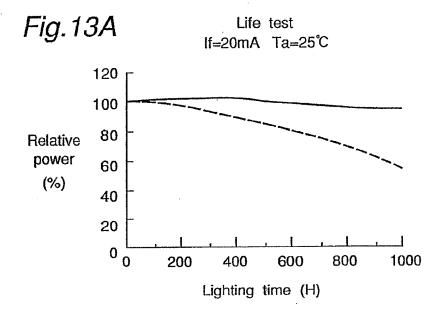


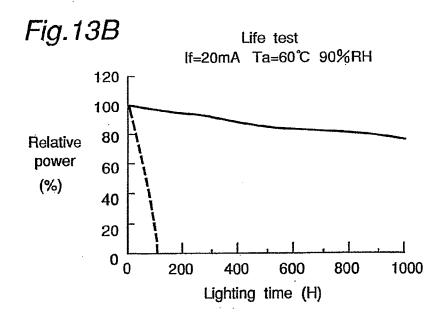


Inventor: Yoshinori SHIMIZU et al.

Title: LIGHT EMITTING DEVICE AND DISPLAY

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Title: LIGHT EMITTING DEVICE AND DISPLAY

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Fig.14A

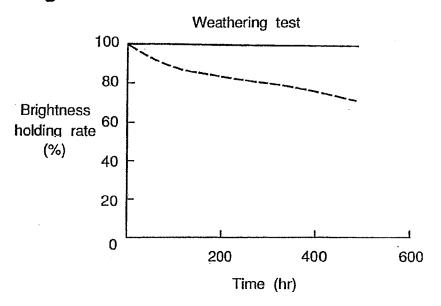
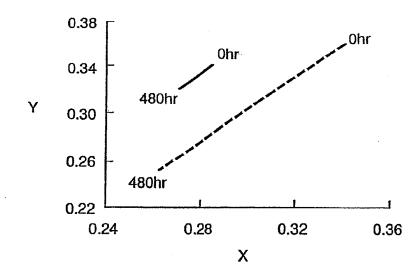


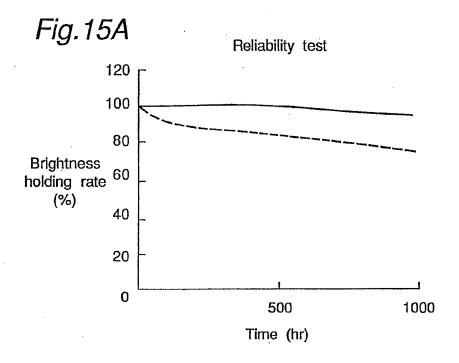
Fig.14B

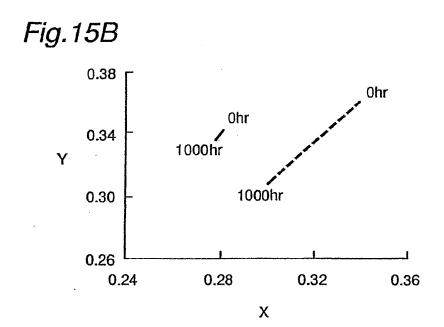


Docket No.: 0020-5147PUS12 App No.: NEW

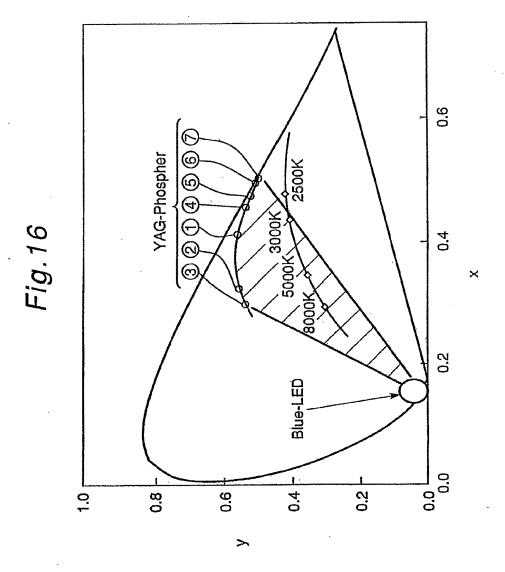
Inventor: Yoshinori SHIMIZU et al.
Title: LIGHT EMITTING DEVICE AND DISPLAY

Sheet 11 of 19

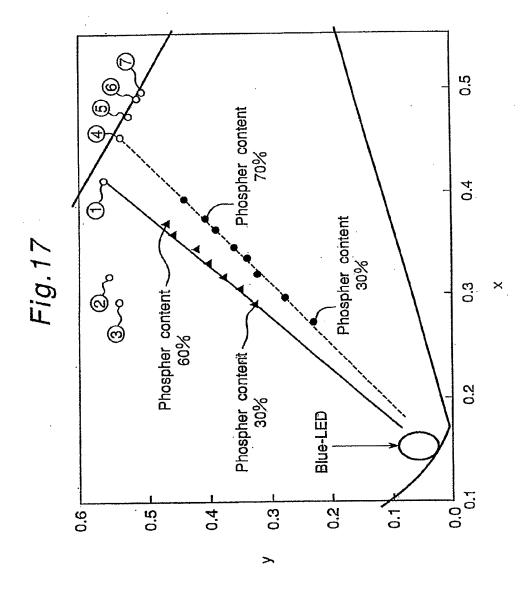




App No.: NEW Docket No.: Inventor: Yoshinori SHIMIZU et al. Title: LIGHT EMITTING DEVICE AND DISPLAY Sheet 12 of 19 Docket No.: 0020-5147PUS12



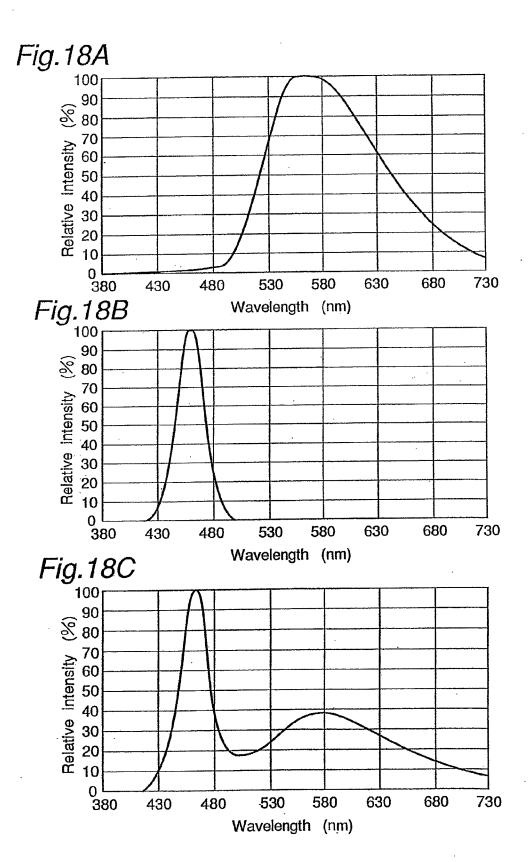
Docket No.: 0020-5147PUS12 App No.: NEW Docket No.: Inventor: Yoshinori SHIMIZU et al.
Title: LIGHT EMITTING DEVICE AND DISPLAY Sheet 13 of 19



Inventor: Yoshinori SHIMIZU et al.

Title: LIGHT EMITTING DEVICE AND DISPLAY

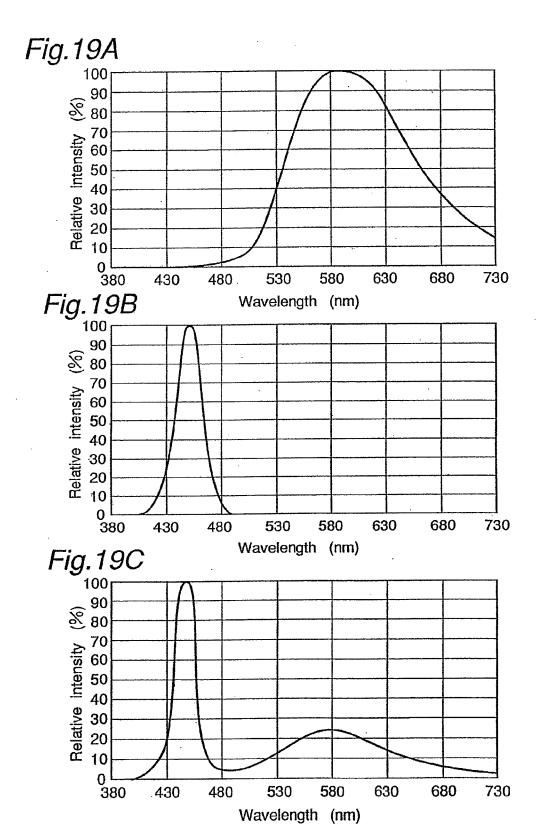
Sheet 14 of 19



Inventor: Yoshinori SHIMIZU et al.

Title: LIGHT EMITTING DEVICE AND DISPLAY

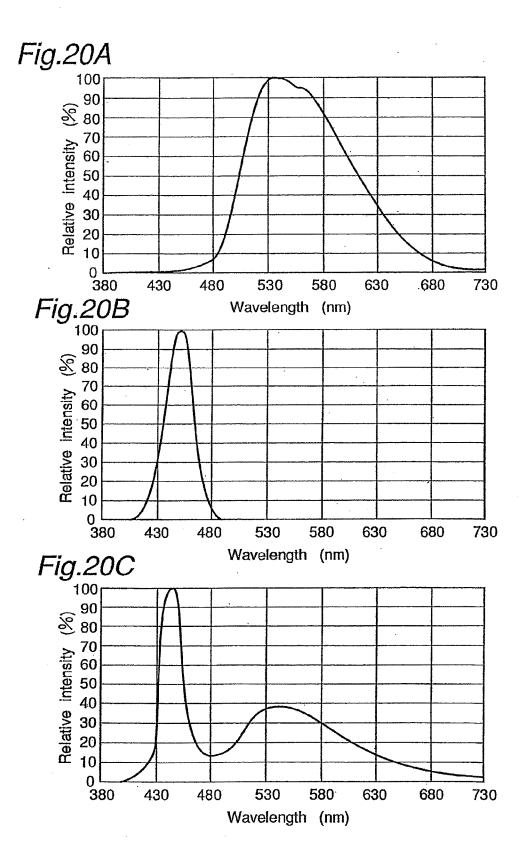
Sheet 15 of 19



Inventor: Yoshinori SHIMIZU et al.

Title: LIGHT EMITTING DEVICE AND DISPLAY

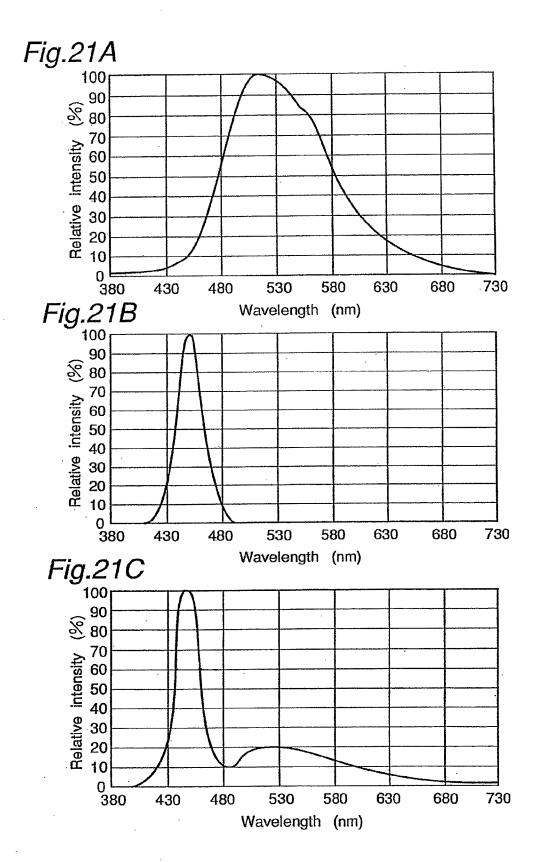
Sheet 16 of 19



Inventor: Yoshinori SHIMIZU et al.

Title: LIGHT EMITTING DEVICE AND DISPLAY

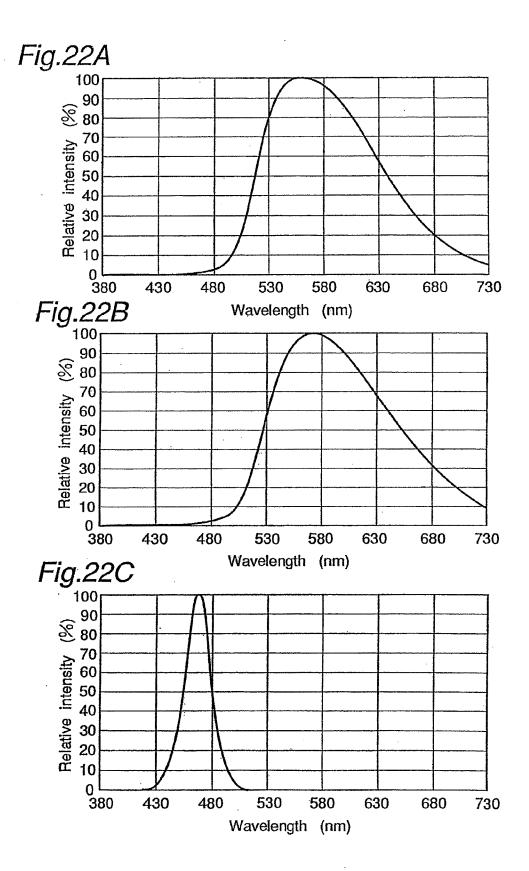
Sheet 17 of 19



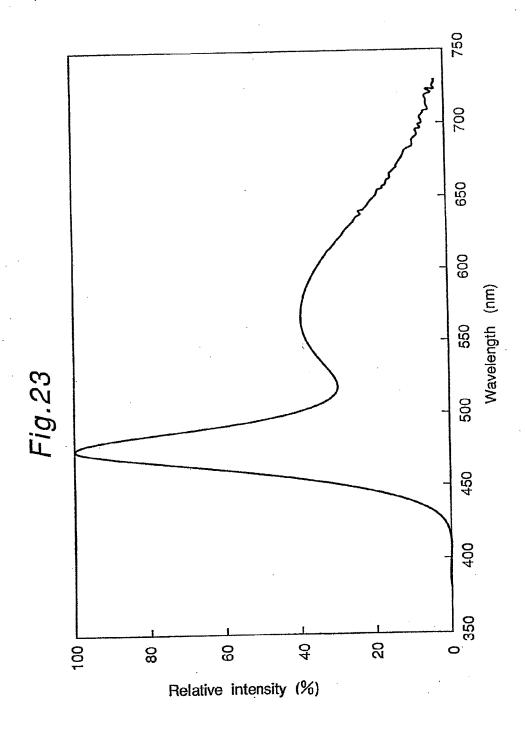
Inventor: Yoshinori SHIMIZU et al.

Title: LIGHT EMITTING DEVICE AND DISPLAY

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App No.: NEW Docket No.: Inventor: Yoshinori SHIMIZU et al. Title: LIGHT EMITTING DEVICE AND DISPLAY Sheet 19 of 19 Docket No.: 0020-5147PUS12



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Application Number:						
Filing Date:						
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY Yoshinori SHIMIZU					
First Named Inventor/Applicant Name:	Yoshinori SHIMIZU					
Filer:	David Richard Anderson/Patti Young					
Attorney Docket Number:	0020-5	147PUS12				
Filed as Large Entity						
Utility under 35 USC 111(a) Filing Fees						
Description		Fee Code	Quantity	Amount	Sub-Total in USD(\$)	
Basic Filing:						
Utility application filing		1011	1	330	330	
Utility Search Fee		1111	1	540	540	
Utility Examination Fee		1311	1	220	220	
Pages:						
Claims:						
Miscellaneous-Filing:						
Petition:						
Patent-Appeals-and-Interference:			-			

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Post-Allowance-and-Post-Issuance:				
Extension-of-Time:				
Miscellaneous:				
	Tot	al in USD	(\$)	1090

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EFS ID:	8803171						
Application Number:	12942792						
International Application Number:							
Confirmation Number:	2357						
Title of Invention:	LIGHT EMITTING DEVICE AND DISPLAY						
First Named Inventor/Applicant Name:	Yoshinori SHIMIZU						
Customer Number:	02292						
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Filer Authorized By:	David Richard Anderson						
Attorney Docket Number:	0020-5147PUS12						
Receipt Date:	09-NOV-2010						
Filing Date:							
Time Stamp:	17:47:10						
Application Type:	Utility under 35 USC 111(a)						

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Payment was successfully received in RAM	\$1090
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Applicant claims small entity	status. Se	ee 37 CFR 1.27		N/A		
TOTAL AMOUNT OF PAYMENT	(\$)	1,090.00	Art Unit		ZDLIC40	
			Attorney Docket	No. 10020-5147	PUS12	
METHOD OF PAYMENT (ch	eck all tha	it apply)				
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FEE CALCULATION						
1. BASIC FILING, SEARCH,						
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Provisional 22	20 1	10 0	0	0	0 _	
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listings under 37 CFR 1	.52(e)), th	ne application size t	fee due is \$270 (\$	135 for small e	ntity) for each	additional 50
sheets or fraction thereo	of. See 35	U.S.C. 41(a)(1)(G	and 37 CFR 1.1	6(s).		
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Other (e.g. late filing sur	charge _					
SUBMITTED BY						
Signature	$\sqrt{\chi}$	/	Registration No. 4	0,439	Telephone 70)3-205-8000
Name (Print/Type) D. Richard And	derson		(Attorney/Agent)		Date Novem	
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Applicant claims small e	entity status.	See 37 CFR 1.27		Examiner Name	N/A		
				Art Unit	N/A		
TOTAL AMOUNT OF PAYM	ENT (\$)	1,090.00		Attorney Docket I	No. 0020-5	5147PUS12	
METHOD OF PAYMENT	(check all	that apply)					
Check Credit C	ard $\square_{ m N}$	Money Order	None	e Other (pl	ease identify):		
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under 37 CFR WARNING: Information on this	form may be	come public. Credit	card info		, ,		rovide credit card
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FEE CALCULATION							
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	FILING F S	mall Entity	SEAR	CH FEES Small Entity		TION FEES	
Application Type	Fee (\$)	Fee (\$)	Fee (\$)	Fee (\$)	Fee (\$)	Fee (\$)	Fees Paid (\$)
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Design	220	110	100	50	140	70	
Plant	220	110	330	165	170	85	
Reissue	330	165	540	270	650	325	
Provisional	220	110	0	0	0	0	
2. EXCESS CLAIM FEE	s						Small Entity
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Name (Print/Type) D. Richard	Anderson			1		Date N	ovember 9, 2010

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APPLICATION SIZE FEE (37 CFR 1.16(s))			sheets of \$270 (\$1 50 sheet	paper, the appli							
U	TIPLE DEPENI	DENT CLAIM P	RESENT	(37 CFR 1.16	S(j))		195			390	
f th	ne difference in d	column 1 is less	s than ze	ro, enter "0" in	column 2.	Т	OTAL			TOTAL	1090
AMENDINEN A		REMAINING AFTER AMENDMENT			PRESENT EXTRA	X X	= = N/A	ADDI- TIONAL FEE (\$)	OR OR OR	x = x = N/A	ADDI- TIONAL FEE (\$)
		(Column 1)		(Column 2)	(Column 3)	TOTA ADD'T	L		OR OR	TOTAL ADD'T FEE	
		CLAIMS REMAINING AFTER AMENDMENT		HIGHEST NUMBER PREVIOUSLY PAID FOR	PRESENT EXTRA	R	ATE (\$)	ADDI- TIONAL FEE (\$)		RATE (\$)	ADDI- TIONAL FEE (\$)
	Total (37 CFR 1.16(i))	*	Minus	**	=	х	=		OR	x =	
	Independent (37 CFR 1.16(h))	*	Minus	***	=	х	=		OR	x =	
		e Fee (37 CFR							1		
	FIRST PRESENT	ATION OF MULT	IPLE DEP	PENDENT CLAIN	1 (37 CFR 1.16(j))	<u> </u>	N/A		OR	N/A	
	- ·					TOTA ADD'T			OR	TOTAL ADD'T FEE	
	If the "Highest If the "Highest	Number Previo Number Previo	usly Paid usly Paid	For" IN THIS	n 2, write "0" in colun SPACE is less than 2 SPACE is less than 3 ndependent) is the hi	20, enter "2 3, enter "3"		in the appropris	ite box in	. column 1	

This collection of information is required by 37 CFR 1.16. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 12 minutes to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Pater and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.